Particle Detection with Drift Chambers

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Particle Detection with Drift Chambers



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Preface to the First Edition

A drift chamber is an apparatus for measuring the space coordinates of the trajectory of a charged particle. This is achieved by detecting the ionization electrons produced by the charged particle in the gas of the chamber and by measuring their drift times and arrival positions on sensitive electrodes.

When the multiwire proportional chamber, or 'Charpak chamber' as we used to call it, was introduced in 1968, its authors had already noted that the time of a signal could be useful for a coordinate determination, and first studies with a drift chamber were made by Bressani, Charpak, Rahm and Zupančič in 1969. When the first operational drift-chamber system with electric circuitry and readout was built by Walenta, Heintze and Schürlein in 1971, a new instrument for particle experiments had appeared. A broad study of the behaviour of drifting electrons in gases began in laboratories where there was interest in the detection of particles.

Diffusion and drift of electrons and ions in gases were at that time well-established subjects in their own right. The study of the influence of magnetic fields on these processes was completed in the 1930s and all fundamental equations were contained in the article by W.P. Allis in the *Encyclopedia of Physics* [ALL 56]. It did not take very long until the particle physicists learnt to apply the methods of the Maxwell–Boltzmann equations and of the electron-swarm experiments that had been developed for the study of atomic properties. The article by Palladino and Sadoulet [PAL 75] recorded some of these methods for use with particle-physics instruments.

F. Sauli gave an academic training course at CERN in 1975/76, in order to inform a growing number of users of the new devices. He published lecture notes [SAU 77], which were a major source of information for particle physicists who began to work with drift chambers.

When the authors of this book began to think about a large drift chamber for the ALEPH experiment, we realized that there was no single text to introduce us to those questions about drift chambers that would allow us to determine their ultimate limits of performance. We wanted to have a text, not on the technical details, but on the fundamental processes, so that a judgement about the various alternatives for building a drift chamber would be on solid ground. We needed some insight into the consequences of different geometries and how to distinguish between the behaviour of different gases, not so much a complete table of their properties. We wanted to understand on what trajectories the ionization electrons would drift to the proportional wires and to what extent the tracks would change their shape.

Paths to the literature were also required – just a few essential ones – so that an entry point to every important subject existed; they would not have to be a comprehensive review of 'everything'.

In some sense we have written the book that we wanted at that time. The text also contains a number of calculations that we made concerning the statistics of ionization and the fundamental limits of measuring accuracy that result from it, geometrical fits to curved tracks, and electrostatics of wire grids and field cages. Several experiments that we undertook during the construction time of the ALEPH experiment found their way into the book; they deal mainly with the drift and diffusion of electrons in gases under various field conditions, but also with the statistics of the ionization and amplification processes.

The book is nonetheless incomplete in some respects. We are aware that it lacks a chapter on electronic signal processing. Also some of the calculations are not yet backed up in detail by measurements as they will eventually have to be. Especially the parameter N_{eff} of the ionization process which governs the achievable accuracy should be accurately known and supported by measurements with interesting gases. We hope that workers in this field will direct their efforts to such questions. We would welcome comments about any other important omissions.

It was our intention to make the book readable for students who are interested in particle detectors. Therefore, we usually tried to explain in some detail the arguments that lead up to a final result. One may say that the book represents a cross between a monograph and an advanced textbook. Those who require a compendious catalogue of existing or proposed drift chambers may find useful the proceedings of the triannual Vienna Wire Chamber Conferences [VIE] or of the annual IEEE Symposia on Instrumentation for Nuclear Science [IEE].

Parts of the material have been presented in summer schools and guest lectures, and we thank H.D. Dahmen (Herbstschule Maria Laach), E. Fernandez (Universita Autonoma, Barcelona) and L. Bertocchi (ICTP, Trieste) for their hospitality.

We thank our colleagues from the ALEPH TPC group, and especially J. May and F. Ragusa, for many stimulating discussions on the issues of this book. We are also obliged to H. Spitzer (Hamburg) who read and commented on an early version of the manuscript. Special thanks are extended to Mrs. Heininger in Munich who produced most of the drawings.

Geneva 1 April 1993 W. Blum L. Rolandi

Preface to the Second Edition

The first edition has continuously served many students and researchers in the field. Now we have enlarged and improved the book, essentially in three ways: (1) The chapter on electronic signal processing was added, and (2) the chapter on the creation of the signal was rewritten and based on the principle of current induction. This was made possible because our team was complemented with a new young co-author (W.R.). (3) Also there are various modernizations throughout the book including some of the recent chambers capable to measure tracks at very high fluences that one could not imagine 15 years ago. Four of the chapters were left untouched. The development of drift chambers in the last 15 years was driven by the idea that their performance should be pushed towards the limits of the laws of physics. The concept of the book matches very well this trend because it is the basic principles of drift chambers rather than their technical design solutions that are in focus. The most modern design solutions, among them the ones developed for the experiments of the Large Hadron Collider, can be found e.g. in the proceedings of the IEEE Symposia [IEE] and of the Vienna Wire Chamber Conferences [VIE].

During the last two decades, the development and optimization of drift chambers has increasingly relied on simulation programs, which in some sense 'encode' the physics processes described in this book. The program GARFIELD, written by Rob Veenhof, is the most widely used tool for drift chamber simulation. It allows calculation of electric fields, electron and ion drift lines, induced signals, electrostatic wire displacements and many more features of drift chambers. For calculation of the primary ionization of fast particles in gases, the program HEED, written by Igor Smirnov, is widely used. A very popular program for calculation of electron transport properties in different gas mixtures is the program MAGBOLTZ, written by Steve Biagi. MAGBOLTZ and HEED are directly interfaced to GARFIELD, which therefore allows a complete simulation of the drift chamber processes, from the passage of the charged particle to the detector output signal. Clearly a thorough understanding of drift chambers, which is subject of this book, is a necessary precondition for efficient use of these simulation programs.

Despite the development of the fine grained silicon detectors which now outperform the wire chambers near the interaction point, the large detector volumes surrounding modern experiments have to rely on drift chambers because of their simplicity and also because their measurement accuracy in relation to their size is better than it is in any other instrument. Time Projection Chambers with electron drift lengths up to 2.5 m are the most important tools for studying heavy ion collisions, because of their very low material budget, channel number economy and particle identification capabilities. TPCs are also studied as principle detectors for future electron colliders. 36 years after the first working drift chamber, these instruments are still going strong.

Geneva	W. Blum
April 2008	W. Riegler
	L. Rolandi

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	following year
[PAL 75]	V. Palladino and B. Sadoulet, Application of classical theory of electrons in gases to
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[VIE]	The Vienna Wire Chamber Conferences were held in February of the years 1978,
	1980, 1983, 1986, 1989, 1992, 1995, 1998, 2001, 2004, 2007, and they were published
	mostly the same years in Nuclear Instruments and Methods in the following volumes:
	135, 176, 217, A 252, A 283, A 323, A 367, A 419, A 478, A 535. Since 2001 they

are called Vienna Conference on Instrumentation.

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Chapter 1 Gas Ionization by Charged Particles and by Laser Rays

Charged particles can be detected in drift chambers because they ionize the gas along their flight path. The energy required for them to do this is taken from their kinetic energy and is very small, typically a few keV per centimetre of gas in normal conditions.

The ionization electrons of every track segment are drifted through the gas and amplified at the wires in avalanches. Electrical signals that contain information about the original location and ionization density of the segment are recorded.

Our first task is to review how much ionization is created by a charged particle (Sects. 1.1 and 1.2). This will be done using the method of Allison and Cobb, but the historic method of Bethe and Bloch with the Sternheimer corrections is also discussed. Special emphasis is given to the fluctuation phenomena of ionization.

Pulsed UV lasers are sometimes used for the creation of straight ionization tracks in the gas of a drift chamber. Here the ionization mechanism is quite different from the one that is at work with charged particles, and we present an account of the two-photon rate equations as well as of some of the practical problems encountered when working with laser tracks (Sect. 1.3).

1.1 Gas Ionization by Fast Charged Particles

1.1.1 Ionizing Collisions

A charged particle that traverses the gas of a drift chamber leaves a track of ionization along its trajectory. The encounters with the gas atoms are purely random and are characterized by a mean free flight path λ between ionizing encounters given by the ionization cross-section per electron σ_I and the density *N* of electrons:

$$\lambda = 1/(N\sigma_{\rm I}). \tag{1.1}$$

Therefore, the number of encounters along any length *L* has a mean of L/λ , and the frequency distribution is the Poisson distribution

1 Gas Ionization by Charged Particles and by Laser Rays

$$P(L/\lambda,k) = \frac{(L/\lambda)^k}{k!} \exp(-L/\lambda).$$
(1.2)

It follows that the probability distribution f(l)dl of the free flight paths l between encounters is an exponential, because the probability of finding zero encounters in the interval l times the probability of one encounter in dl is equal to

$$f(l)dl = P(1/\lambda, 0)P(dl/\lambda, 1)$$

= (1/\lambda) exp(-l/\lambda)dl.

From (1.2) we obtain the probability of having zero encounters along a track length L:

$$P(L/\lambda, 0) = \exp(-L/\lambda). \tag{1.3}$$

Equation (1.3) provides a method for measuring λ . If a gas counter with sensitive length *L* is set up so that the presence of even a single electron in *L* will always give a signal, then its inefficiency may be identified with expression (1.3), thus measuring λ . This method has been used with streamer, spark, and cloud chambers, as well as with proportional counters and Geiger–Müller tubes. A correction must be applied when a known fraction of single electrons remains below the threshold.

Table 1.1 shows a collection of measured values of $1/\lambda$ with fast particles whose relativistic velocity factor γ is quoted as well, because λ depends on the particle velocity (see Sect. 1.2.6); in fact, $1/\lambda$ goes through a minimum near $\gamma = 4$.

Gas	$1cm/\lambda$	γ
H ₂	$5.32 \pm 0.06 \\ 4.55 \pm 0.35 \\ 5.1 \pm 0.8$	4.0 3.2 3.2
Не	$\begin{array}{c} 5.02 \pm 0.06 \\ 3.83 \pm 0.11 \\ 3.5 \pm 0.2^a \end{array}$	4.0 3.4 3.6
Ne	$\begin{array}{c} 12.4 \pm 0.13 \\ 11.6 \pm 0.3^a \end{array}$	4.0 3.6
Ar	$\begin{array}{c} 27.8 \pm 0.3 \\ 28.6 \pm 0.5 \\ 26.4 \pm 1.8 \end{array}$	4.0 3.5 3.5
Xe	44	4.0
N ₂	19.3	4.9
O ₂	22.2 ± 2.3	4.3
Air	$\begin{array}{c} 25.4\\ 18.5\pm1.3 \end{array}$	9.4 3.5

Table 1.1 Measured numbers of ionizing collisions per centimetre of track length in various gases at normal density [ERM 69]. The relativistic velocity factor γ is also indicated

^a[SÖC 79].

Gas	$\sigma_p(10^{-20}\text{cm}^2)$	$\gamma_{ m min}$	Gas	$\sigma_{\rm p}(10^{-20}{\rm cm}^2)$	γ_{\min}
H ₂	18.7	3.81	<i>i</i> -C ₄ H ₁₀	333	3.56
He	18.6	3.68	$n-C_5H_{12}$	434	3.56
Ne	43.3	3.39	neo-C ₅ H ₁₂	433	3.45
Ar	90.3	3.39	<i>n</i> -C ₆ H ₁₄	526	3.51
Xe	172	3.39	C_2H_2	126	3.60
O_2	92.1	3.43	C_2H_4	161	3.58
$\overline{CO_2}$	132	3.51	CH ₃ OH	155	3.65
C_2H_6	161	3.58	C ₂ H ₅ OH	230	3.51
C_3H_8	269	3.47	$(CH_3)_2CO$	277	3.54

Table 1.2 Minimal primary ionization cross-sections σ_p for charged particles in some gases, and relativistic velocity factor γ_{min} of the minimum, according to measurements done by Rieke and Prepejchal [RIE 72]

In Table 1.2 we present additional measurements of a larger number of gases that are employed in drift chambers. These primary ionization cross-sections σ_p were measured by Rieke and Prepejchal [RIE 72] in the vicinity of the minimum at different values of γ and interpolated to the minimum γ_p^{min} at γ^{min} , using the parametrization of the Bethe–Bloch formula (see Sect. 1.2.7). The mean free path λ is related to σ_p by the number density N_m of molecules:

$$\lambda = 1/(N_{\rm m}\sigma_{\rm p}).$$

The measurement errors are within $\pm 4\%$ (see the original paper for details). In comparison with the values presented in Table 1.1, the measurements are in rough agreement, except for argon.

1.1.2 Different Ionization Mechanisms

We distinguish between primary and secondary ionization. In primary ionization, one or sometimes two or three electrons are ejected from the atom A encountered by the fast particle, say a π meson:

$$\pi A \to \pi A^+ e^-, \ \pi A^{++} e^- e^-, \dots$$
 (1.4)

Most of the charge along a track is from secondary ionization where the electrons are ejected from atoms not encountered by the fast particle. This happens either in collisions of ionization electrons with atoms,

$$e^{-}A \rightarrow e^{-}A^{+}e^{-}, e^{-}A^{++}e^{-}e^{-},$$
 (1.5)

or through intermediate excited states A^{*}. An example is the following chain of reactions involving the collision of the excited state with a second species, B, of atoms or molecules that is present in the gas:

$$\pi A \to \pi A^*$$
 (1.6a)

or

$$e^{-}A \rightarrow e^{-}A^{*},$$
 (1.6b)

$$A^*B \to AB^+e^-. \tag{1.7}$$

Reaction (1.7) occurs if the excitation energy of A^* is above the ionization potential of B. In drift chambers, A^* is often the metastable state of a noble gas created in reaction (1.6b), and B is one of the molecular additives (quenchers) that are required for the stability of proportional wire operation; A^* may also be an optical excitation with a long lifetime due to resonance trapping. These effects are known under the names of *Penning effect* (involving metastables) and *Jesse effect* (involving optical excitations, also used more generally); obviously they depend very strongly on the gas composition and density.

Another example of secondary ionization through intermediate excitation has been observed in pure rare gases where an excited molecule A_2^* has a stable ionized ground state A_2^+ :

$$\mathbf{A}^* \mathbf{A} \to \mathbf{A}_2^* \to \mathbf{A}_2^+ \mathbf{e}^-. \tag{1.8}$$

The different contributions of processes (1.5–1.8) are in most cases unknown. For further references, we recommend the proceedings of the conferences dedicated to these phenomena, for example the Symposium on the Jesse Effect and Related Phenomena [PRO 74].

A pictorial summary of the processes discussed is given in Fig. 1.1.

1.1.3 Average Energy Required to Produce One Ion Pair

Only a certain fraction of all the energy lost by the fast particle is spent in ionization. The total amount of ionization from all processes is characterized by the energy W that is spent, on the average, on the creation of one free electron. We write

$$W\langle N_{\rm I}\rangle = L\left\langle \frac{\mathrm{d}E}{\mathrm{d}x} \right\rangle,$$
 (1.9)

where $\langle N_{\rm I} \rangle$ is the average number of ionization electrons created along a trajectory of length *L*, and $\langle dE/dx \rangle$ is the average total energy loss per unit path length of the fast particle; *W* must be measured for every gas mixture.

Many measurements of W have been performed since the advent of radioactivity, using radioactive and artificial sources of radiation. The amount of ionization produced by particles that lose all their energy in the gas is measured by ionization chambers or proportional counters. The value of W in this case is the ratio of the initial energy to the number of ion pairs. The energy W depends on the gas – its composition and density – and on the nature of the particle. Experimentally it is found that W is independent of the initial energy above a few keV for electrons and a few MeV for alpha-particles, which is a remarkable fact.



When a relativistic particle traverses a layer of gas, the energy deposit is such a small fraction of its total energy that it cannot be measured as the difference between initial and final energy. Therefore, there is no direct determination of the appropriate value of W, and we have to rely on extrapolations from fully stopped electrons.

A critical review of the average energy required to produce an ion pair is given in a report of the International Commission on Radiation Units and Measurements [INT 79]. A treatment in a wider context is provided by the book of Christophorou [CHR 71] and by the review by Inokuti [INO 75]; see also the references quoted in these three works. For pure noble gases, *W* varies between 46 eV for He and 22 eV for Xe; for pure organic vapours the range between 23 and 30 eV is typical. Ionization potentials are smaller by factors that are typically between 1.5 and 3. Table 1.3 contains a small selection of *W*-values for various gases.

Values of W measured with photons and with electrons are the same. Values of W measured with α -sources are similar to those measured with β -sources: W_{α}/W_{β} is 1 for noble gases but can reach 1.15 for some organic vapours [CHR 71]. In pure

Gas	$W_{\alpha}(\mathrm{eV})$	$W_{\beta}(\mathrm{eV})$	<i>I</i> (eV)	Gas mixture ^a	$W_{\alpha}(\mathrm{eV})$
H ₂	36.4	36.3	15.43	Ar $(96.5\%) + C_2H_6 (3.5\%)$	24.4
He	46.0	42.3	24.58	Ar $(99.6\%) + C_2 H_2 (0.4\%)$	20.4
Ne	36.6	36.4	21.56	Ar $(97\%) + CH_4 (3\%)$	26.0
Ar	26.4	26.3	15.76	Ar $(98\%) + C_3 H_8 (2\%)$	23.5
Kr	24.0	24.05	14.00	Ar $(99.9\%) + C_6 H_6 (0.1\%)$	22.4
Xe	21.7	21.9	12.13	Ar $(98.8\%) + C_3H_6(1.2\%)$	23.8
CO_2	34.3	32.8	13.81	$Kr(99.5\%) + C_4H_8 - 2(0.5\%)$	22.5
CH ₄	29.1	27.1	12.99	$Kr(93.2\%) + C_2H_2(6.8\%)$	23.2
C_2H_6	26.6	24.4	11.65	$Kr(99\%) + C_3H_6(1\%)$	22.8
C_2H_2	27.5	25.8	11.40		
Air	35.0	33.8	12.15		
H_2O	30.5	29.9	12.60		

Table 1.3 Energy W spent, on the average, for the creation of one ionization electron in various gases and gas mixtures [CHR 71]; W_{α} and W_{β} are from measurements using α or β sources, respectively. The lowest ionization potential is also indicated

^a The quoted concentration is the one that gave the smallest W.

argon, the value of W for very slow electrons such as the ones emitted in primary ionization processes (1.5) is greater than for fast electrons. Figure 1.2 contains measurements reported by Combecher [COM 77].

From Table 1.3 it is apparent that the total ionization in a noble gas can be increased by adding a small concentration of molecules with low ionization potential. The extra ionization comes *later*, depending on the de-excitation rate of the A^{*} involved. For example, a contamination of 3×10^{-4} nitrogen in neon–helium gas has



Fig. 1.2 Average energy *W* spent for the creation of one ionization electron in pure argon and in pure xenon as a function of the energy *E* of the ionizing particle, which is an electron fully stopped [COM 77]. The *dashed lines* represent the values W_β from Table 1.2 measured at larger *E*

caused secondary retarded ionization that amounted to 60% of the primary, with mean retardation times around 1 µs [BLU 74].

Whether the number of primary encounters that lead to ionization can be increased in the same manner is not so clear; the fast particle would have to excite the state A^* in a primary collision (reaction (1.6a)). A metastable state does not have a dipole transition to the ground state and is therefore not easily excited by the fast particle.

1.1.4 The Range of Primary Electrons

Primary electrons are emitted almost perpendicular to the track as their momentum remains very small compared to the one of the track. They lose their kinetic energy E in collisions with the gas molecules, scattering almost randomly and producing secondary electrons, until they have lost their kinetic energy. A practical range R can be defined as the thickness of the layer of material they cross before being stopped. The empirical relation

$$R(E) = AE\left(1 - \frac{B}{1 + CE}\right) \tag{1.10}$$

with $A = 5.37 \times 10^{-4}$ g cm⁻² keV⁻¹, B = 0.9815, and $C = 3.1230 \times 10^{-3}$ keV⁻¹ is shown in Fig. 1.3 and compared with experimental data in the range between 300 eV and 20 MeV. It is shown in [KOB 68] that the parametrization (1.10) is applicable to all materials with low and intermediate atomic number Z. In the absence of lowenergy data this curve may be taken as a basis for an extrapolation to lower E. Below 1 keV the relation reads

$$R(E) = 9.93 \left(\frac{\mu g}{\mathrm{cm}^2 \,\mathrm{keV}}\right) E.$$

In argon N.T.P. an electron of 1 keV is stopped in about $30\mu m$, and one of 10 keV in about 1.5 mm. Only 0.05% of the collisions between the particle and the gas molecules produce primary electrons with kinetic energy larger than 10 keV. We will compute these probabilities in Sect. 1.2.4.

1.1.5 The Differential Cross-section $d\sigma/dE$

Every act of ionization is a quantum mechanical transition initiated by the field of the fast particle and the field created indirectly by the neighbouring polarizable atoms. A complete calculation would involve the transition amplitudes of all the atomic states and does not exist.

For the detection of particles, what we have to know in the first place is the amount of ionization along the track and the associated fluctuation phenomena. For



Fig. 1.3 Practical range versus kinetic energy for electrons in aluminium. The data points are from various authors, which can be traced back consulting [KOB 68]. The curve is a parametrization according to (1.10)

this it is sufficient to determine for an act of primary ionization with what probabilities it will result in a total ionization of 1, 2, ..., or *n* electrons. The total ionization over a piece of track and its frequency distribution can then be determined by summing over all the primary encounters in that piece.

Using the concept of the average energy W required to produce one ion pair – be it a constant as in (1.9) or a function of the energy of the primary electron as in Fig. 1.2 – the problem is reduced to finding the energy spectrum F(E)dE of the primary electrons, or, equivalently, the corresponding differential cross-section $d\sigma/dE$. Once this is known, we obtain λ and F(E) with the relations

$$1/\lambda = \int N \frac{\mathrm{d}\sigma}{\mathrm{d}E} \mathrm{d}E$$

and

$$F(E) = \frac{N(\mathrm{d}\sigma/\mathrm{d}E)}{1/\lambda},$$

where *N* is the electron number density in the gas and $d\sigma/dE$ the differential crosssection per electron to produce a primary electron with an energy between *E* and E + dE.

1.2 Calculation of Energy Loss

In order to calculate $d\sigma/dE$ we will begin by investigating the average total energy loss per unit distance, $\langle dE/dx \rangle$, of a moving charged particle in a polarizable medium. Here a classical calculation is appropriate in which the medium is treated as a continuum characterized by a complex dielectric constant $\varepsilon = \varepsilon_1 + i\varepsilon_2$. Later on we will interpret the resulting integral over the lost energy in a quantum mechanical sense.

1.2.1 Force on a Charge Travelling Through a Polarizable Medium

It is the field E_{long} opposite to its direction of motion, created by the moving particle in the medium at its own space point, which produces the force equal to the energy loss per unit distance

$$\langle \mathrm{d}E/\mathrm{d}x \rangle = eE_{\mathrm{long}},$$

where e is the charge of the moving particle. We follow the method of Landau and Lifshitz [LAN 60] in the form used by Allison and Cobb [ALL 80].

Maxwell's equations in an isotropic, homogeneous, non-magnetic medium are

$$\nabla \cdot \boldsymbol{H} = 0,$$

$$\nabla \times \boldsymbol{E} = -\frac{1}{c} \frac{\partial \boldsymbol{H}}{\partial t},$$

$$\nabla \cdot (\boldsymbol{\varepsilon} \boldsymbol{E}) = 4\pi \cdot,$$

$$\nabla \times \boldsymbol{H} = \frac{1}{c} \frac{\partial (\boldsymbol{\varepsilon} \boldsymbol{E})}{\partial t} + \frac{4\pi}{c} \boldsymbol{j}.$$

(1.11)

Since there will be no confusion between the electric field vector E and the energy lost, E, we will use the customary symbols.

The charge density and the flux are given by the particle moving with velocity βc :

• =
$$e\delta^3(\mathbf{r} - \beta ct), \ \mathbf{j} = \beta c$$
•. (1.12)

We work in the Coulomb gauge and introduce the potentials ϕ and A:

$$H = \nabla \times A,$$

$$\nabla \cdot A = 0,$$

$$E = -\frac{1}{c} \frac{\partial A}{\partial t} - \nabla \phi.$$
(1.13)

Equations (1.11), expressed in terms of the potentials, are

$$\nabla \cdot (\varepsilon \nabla \phi) = -4\pi e \delta^3 (\mathbf{r} - \beta ct),$$

$$-\nabla^2 \mathbf{A} = -\frac{1}{c^2} \frac{\partial}{\partial t} \left(\varepsilon \frac{\partial \mathbf{A}}{\partial t} \right) \frac{1}{c} \frac{\partial}{\partial t} (\varepsilon \nabla \phi) + 4\pi e \beta \delta^3 (\mathbf{r} - \beta ct).$$
 (1.14)

The solutions can be found in terms of the Fourier transforms $\phi(\mathbf{k}, \omega)$ and $\mathbf{A}(\mathbf{k}, \omega)$ of the potentials.

The Fourier transform $F(\mathbf{k}, \omega)$ of a vector field $F(\mathbf{r}, t)$ is given by

$$F(\mathbf{k}, \boldsymbol{\omega}) = \frac{1}{(2\pi)^2} \int d^3 r \, dt \, F(\mathbf{r}, t) \exp(i\mathbf{k} \cdot \mathbf{r} - i\omega t),$$

$$F(\mathbf{r}, t) = \frac{1}{(2\pi)^2} \int d^3 k \, d\omega \, F(\mathbf{k}, \boldsymbol{\omega}) \exp(i\mathbf{k} \cdot \mathbf{r} - i\omega t).$$
(1.15)

The solutions of (1.14) are

$$\phi(\mathbf{k}, \boldsymbol{\omega}) = 2e\delta(\boldsymbol{\omega} - \mathbf{k} \cdot \boldsymbol{\beta}c)/k^{2}\varepsilon,$$

$$\mathbf{A}(\mathbf{k}, \boldsymbol{\omega}) = 2e\frac{\boldsymbol{\omega}\mathbf{k}/k^{2}c - \boldsymbol{\beta}}{(-k^{2} + \varepsilon\boldsymbol{\omega}^{2}/c^{2})}\delta(\boldsymbol{\omega} - \mathbf{k} \cdot \boldsymbol{\beta}c).$$
(1.16)

Using the third of (1.13), the electric field for every point is calculated according to

$$\boldsymbol{E}(\boldsymbol{r},t) = \frac{1}{(2\pi)^2} \int \frac{\mathrm{i}\omega}{c} \{\boldsymbol{A}(\boldsymbol{k},\omega) - \mathrm{i}\boldsymbol{k}\phi(\boldsymbol{k},\omega)\exp[\mathrm{i}(\boldsymbol{k}\cdot\boldsymbol{r}-\omega t)]\}\mathrm{d}^3\boldsymbol{k}\,\mathrm{d}\omega,\quad(1.17)$$

and the energy loss per unit length is

$$\langle \mathrm{d}E/\mathrm{d}x \rangle = e E(\beta ct, t) \cdot \beta/\beta,$$
 (1.18)

which is independent of t because the field created in the medium is travelling with the particle. This may be seen by inserting (1.16) into (1.17).

In the evaluation of (1.17) with the help of (1.16) we integrate over the two directions of k using the fact that the isotropic medium has a scalar ε . We further use $\varepsilon(-\omega) = \varepsilon^*(\omega)$ and obtain finally

$$\left\langle \frac{\mathrm{d}E}{\mathrm{d}x} \right\rangle = \frac{2e^2}{\beta^2 \pi} \int_0^\infty \mathrm{d}\omega \int_{\omega/\beta c}^\infty \mathrm{d}k \left[\omega k \left(\beta^2 - \frac{\omega^2}{k^2 c^2} \right) \right. \\ \left. \times \mathrm{Im} \frac{1}{-k^2 c^2 + \varepsilon \omega^2} - \frac{\omega}{kc^2} \mathrm{Im} \left(\frac{1}{\varepsilon} \right) \right].$$
(1.19)

The lower limit of the integral over k depends on the particle velocity βc and is explained later.

The energy loss is determined by the manner in which the complex dielectric constant ε depends on the wave number k and the frequency ω . Once $\varepsilon(k, \omega)$ is specified, $\langle dE/dx \rangle$ can be calculated for every $\beta; \varepsilon(k, \omega)$ is, in principle, given by the structure of the atoms of the medium. In practice, a simplifying model is sufficient.

1.2.2 The Photo-Absorption Ionization Model

Allison and Cobb [ALL 80] have made a model of $\varepsilon(k, \omega)$ based on the measured photo-absorption cross-section $\sigma_{\gamma}(\omega)$. A plane light-wave travelling along *x* is attenuated in the medium if the imaginary part of the dielectric constant is larger than zero. The wave number *k* is related to the frequency ω by

$$k = \sqrt{\varepsilon}\omega/c \ (\varepsilon = \varepsilon_1 + \mathrm{i}\varepsilon_2). \tag{1.20}$$

It causes a damping factor $e^{-\alpha x/2}$ in the propagation function and $e^{-\alpha x}$ in the intensity with

$$\alpha = 2(\omega/c) \operatorname{Im} \sqrt{\varepsilon} \approx (\omega/c) \varepsilon_2. \tag{1.21}$$

The second equality holds if $\varepsilon_1 - 1$, $\varepsilon_2 \ll 1$ such as for gases.

In terms of free photons traversing a medium that has electron density N and atomic charge Z, the attenuation is given by the photo-absorption cross-section $\sigma_{\gamma}(\omega)$:

$$\sigma_{\gamma}(\omega) = \frac{Z}{N} \alpha \approx \frac{Z}{N} \frac{\omega}{c} \varepsilon_2(\omega). \tag{1.22}$$

The cross-section $\sigma_{\gamma}(\omega)$, and therefore $\varepsilon_2(\omega)$, is known, for many gases, from measurements using synchrotron radiation. The real part of ε is then derived from the dispersion relation

$$\varepsilon_1(\omega) - 1 = \frac{2}{\pi} P \int_0^{\infty} \frac{x \varepsilon_2(x)}{x^2 - \omega^2} \mathrm{d}x \tag{1.23}$$

(*P* = principal value). Figures 1.4 and 1.5 show graphs of σ_{γ} and ε_1 for argon.

In the quantum picture, the (ω, k) plane appears as the kinematic domain of energy $E = \hbar \omega$ and momentum $p = \hbar k$ exchanged between the moving particle and the atoms and electrons of the medium. The exchanged photons are not free, not 'on the mass shell', i.e. they have a relation between *E* and *p* that is different from $E = pc/\sqrt{\varepsilon}$ implied by (1.20). Their relationship may be understood in terms of the kinematic constraints: for example, the photons exchanged with free electrons at rest have $E = p^2/2m$, the photons exchanged with bound electrons (binding energy E_1 , approximate momentum *q*) have $E \approx E_1 + (p+q)^2/2m$. The minimum momentum transfer at each energy *E* depends on the velocity β of the moving particle and is equal to $p_{\min} = E/\beta c$. It delimits the kinematic domain and is the lower limit of integration in the integral (1.19).

Figure 1.5 presents a picture of the (E, p) plane. The solution of the integral (1.19) requires a knowledge of $\varepsilon(k, \omega)$ over the kinematic domain. From (1.22) and (1.23) it is known only for free photons, i.e. outside, along the line $p_{f\gamma}$ in Fig. 1.6.

The model of Allison and Cobb (photo-absorption ionization, or PAI model) consists in extending the knowledge of ε into the kinematic domain. For small *k* in the resonance region below the free-electron line, they take

$$\varepsilon(k,\omega) = \varepsilon(\omega),$$
 (1.24)



Fig. 1.4 Total photo-ionization cross-section of Ar as a function of the photon energy, as compiled by Marr and West [MAR 76]. The imaginary part of the dielectric constant is calculated from this curve using (1.22)

independent of k and equal to the value derived by (1.22) and (1.23). On the free-electron line, they take a δ function to represent point-like scattering in the absorption:

$$\varepsilon_2(k,\omega) = C\delta(\omega - k^2/2m). \tag{1.25}$$

The normalizing constant C is determined in such a way that the total coupling strength satisfies the Bethe sum rule for each k:

$$\int \omega \varepsilon_2(k,\omega) \, \mathrm{d}\omega = \frac{2\pi^2 N e^2}{m}.$$
(1.26)

For a justification of this procedure and a more detailed discussion, the reader is referred to the original article [ALL 80].



Fig. 1.5 The real part of ε as a function of *E*, calculated from Fig. 1.4 using (1.23) [LAP 80]

1.2 Calculation of Energy Loss

Fig. 1.6 Kinematic domain of (ω, k) or (E, p) of the electromagnetic radiation exchanged between the fast particle (β) and the medium. The minimum momentum exchanged is $p = E/\beta c$; the momentum exchanged to a free electron is $p_{fe} = \sqrt{2mE/c^2}$. The momenta exchanged with bound electrons are smeared out around the free-electron line; p_{min} delimits the physical domain, $p_{f\gamma}$ is the free photon line



Using (1.22–1.25), we are now able to integrate expression (1.19) for $\langle dE/dx \rangle$ over *k*. What remains is an integral over ω :

$$\left\langle \frac{\mathrm{d}E}{\mathrm{d}x} \right\rangle = \int_{0}^{\infty} \mathrm{d}\omega \frac{e^{2}}{\beta^{2}c^{2}\pi} \left[\frac{Nc}{Z} \sigma_{\gamma}(\omega) \ln \frac{2mc^{2}\beta^{2}}{\hbar\omega[(1-\beta^{2}\varepsilon_{1})^{2}+\beta^{4}\varepsilon_{2}^{2}]^{1/2}} + \omega \left(\beta^{2}-\frac{\varepsilon_{1}}{|\varepsilon|^{2}}\right) \theta + \frac{1}{Z\omega} \int_{0}^{\omega} \sigma_{\gamma}(\omega') \mathrm{d}\omega' \right].$$
(1.27)

Here we have obtained the energy loss per unit path length in the framework of the electrodynamics of a continuous medium, although our knowledge of $\varepsilon(k, \omega)$ was actually inspired by a picture of photon absorption and collision.

At this point we leave the frame given by the classical theory and recognize the energy loss as being caused by a number of discrete collisions per unit length, each with an energy transfer $E = \hbar \omega$. Therefore, we reinterpret the integrand of (1.27) to mean *E* times a probability of energy transfer per unit path per unit interval of *E*. Now a collision probability per unit path is a cross-section times the density *N*. Therefore, we write the integral (1.27) in the form

$$\left\langle \frac{\mathrm{d}E}{\mathrm{d}x} \right\rangle = \int_{0}^{\infty} E N \frac{\mathrm{d}\sigma}{\mathrm{d}E} \hbar \,\mathrm{d}\omega.$$
 (1.28)

This gives us the differential energy transfer cross-section per electron:

$$\frac{\mathrm{d}\sigma}{\mathrm{d}E} = \frac{\alpha}{\beta^2 \pi} \frac{\sigma_{\gamma}(E)}{EZ} \ln \frac{2mc^2 \beta^2}{E[(1-\beta^2 \varepsilon_1)^2 + \beta^4 \varepsilon_2^2]^{1/2}} \\ + \frac{\alpha}{\beta^2 \pi} \left[\frac{Z}{N\hbar c} \left(\beta^2 - \frac{\varepsilon_1}{|\varepsilon|^2} \right) \theta + \frac{1}{ZE^2} \int_0^E \sigma_{\gamma}(E') \mathrm{d}E' \right].$$
(1.29)

The spectrum of energy transfer is determined by expression (1.29). The normalized differential probability per unit energy is

$$F(E) = \frac{N(\mathrm{d}\sigma/\mathrm{d}E)}{\int N(\mathrm{d}\sigma/\mathrm{d}E)\mathrm{d}E},\tag{1.30}$$

where *N* is the number of electrons per unit volume; $\varepsilon = \varepsilon_1 + i\varepsilon_1$ is to be obtained using (1.22) and (1.23); $\theta = \arg(1 - \varepsilon_1\beta^2 + i\varepsilon_2\beta^2)$; and α is the fine-structure constant.

The number of primary encounters per unit length is given by

$$1/\lambda = \int N \frac{\mathrm{d}\sigma}{\mathrm{d}E} \mathrm{d}E. \tag{1.31}$$

In the gas of a drift chamber the largest possible energy transfers cause secondary electron tracks which do not belong to the primary track. Depending on the exact method of observation, there is always an effective cut-off E_{max} for the observable energy transfer, which is independent of β . For simplicity, we keep the ' ∞ ' as the upper limit of integration. Figure 1.7 shows the energy spectrum for argon according to a numerical calculation along this line by Lapique and Piuz [LAP 80]; they have evaluated the model of Chechin et al. [CHE 72, ERM 77], which is very similar to the PAI model. The second peak beyond E = 240 eV, which is due to the contribution of the *L* shell, is easily visible.



Fig. 1.7 Distribution of energy transfer calculated by Lapique and Piuz for argon at $\gamma = 1000$, based on the formula by Chechin et al. [CHE 76], similar to our (1.29). Adapted from Table 1.1 of [LAP 80]

1.2.3 Behaviour for Large E

For energies above the highest atomic binding energy $E_{\rm K}$, the fast particle undergoes elastic scattering on the atomic electrons as if they were free, and (1.29) becomes the differential cross-section for Rutherford scattering on one electron. Using (1.26) and (1.27) we find

$$\frac{\mathrm{d}\sigma}{\mathrm{d}E} \to \frac{2\pi r_{\mathrm{e}}^2}{\beta^2} \frac{mc^2}{E^2} (E \gg E_{\mathrm{K}}), \qquad (1.32)$$

where r_e is the classical electron radius, equal to $e^2/mc^2 = 2.82 \times 10^{-13}$ cm. This happens because the third term in (1.29) is the only one surviving at large *E*, where $\sigma_{\gamma}(E)$ vanishes quickly so that the sum rule (1.26) applies, together with (1.22).

This behaviour at large *E* means that the energy spectrum F(E) has an extremely long tail. Although $\int F(E) dE$ converges, the mean transferred energy per collision, $\langle E \rangle$, has a logarithmic divergence,

$$\langle E \rangle = \int EF(E) dE = \int dE/E \propto \log E.$$
 (1.33)

This requires a careful interpretation of the mean energy transfer, as shown in the following sections. There is no danger that the mean transferred energy $\langle E \rangle$ diverges in the practical application because there is always an upper cut-off for *E* at work in the integral (1.33), which depends on the situation. This is discussed in Sec. 1.2.8.

1.2.4 Cluster-Size Distribution

An effective description of the ionization left by the particle along its trajectory is provided by a probability distribution of the number of electrons liberated directly or indirectly with each primary encounter. It is known under the name cluster-size distribution, because the secondary electrons are usually created in the immediate vicinity of the primary encounter and, together with the primary electrons, form clusters of one or several – sometimes many – electrons. Although the secondary electrons are not always so well localized, we will use this name.

In order to calculate the cluster-size distribution P(k) we need to know the spectrum of energy loss, F(E)dE, and, for each E, the probability p(E, k) of producing exactly k ionization electrons. The cluster-size distribution is obtained by integration over the energy:

$$P(k) = \int F(E)p(E,k)dE.$$
(1.34)

We may also form the integrated probability Q(j) that a cluster has more than j electrons:

$$Q(j) = 1 - \sum_{k=1}^{j} P(k).$$
(1.35)



Fig. 1.8 Integral cluster-size distribution for fast particles ($\gamma = 1000$) in argon; Q(n) is the probability that the cluster has more than *n* electrons. Calculated from [LAP 80] and [ERM 77]. For large *n*, $Q(n) \approx 0.2/n$

The quantity p(E, k) contains the details of the various ionization mechanisms described in Sect. 1.1 and is generally not known. Lapique and Piuz [LAP 80] have made a computer model of the atomic processes involved in pure argon and have thus been able to calculate a cluster-size distribution. It is presented in the integrated form in Fig. 1.8.

Apart from early cloud chamber studies, there is now one careful experimental determination of cluster-size distributions from the Heidelberg group [FIS 91]. It covers the range up to approximately 15 electrons in argon, helium, methane and several hydrocarbons. We reproduce their measurements in Fig. 1.9. For numerical applications Table 1.4 contains best estimates for the probabilities P(k), based on the hand-drawn lines of Fig. 1.9 and their extrapolations according to the $1/n^2$ behaviour expected for unbound electrons.

If one compares these measurements with the calculation of Lapique and Piuz, then one observes that there is somewhat less structure than they expected in the function P(k). The Heidelberg group suggest that the absorption of free photons with its strong energy variation, which is the basis for the model of Chechin et al. and the PAI model, may not be directly applicable to the calculation of $d\sigma/dE$.

The number *n* in these graphs is called *k* in the text and in Table 1.4.

1.2.5 Ionization Distribution on a Given Track Length

The importance of the cluster-size distribution lies in the fact that, once it is known, the ionization distribution G(x, n) on the track length x is calculated simply by summing the cluster size as many times as there are primary encounters in the track length; G(x, n) depends only on the cluster-size distribution and the number of



Fig. 1.9 Experimental cluster-size distributions from [FIS 91]. The *continuous lines* are hand-drawn interpolations whereas the *broken lines* are extrapolations corresponding to the $1/n^2$ -law expected for large n

	CH_4	Ar	He	CO_2
k				
1	78.6	65.6	76.60	72.50
2	12.0	15.0	12.50	14.00
3	3.4	6.4	4.60	4.20
4	1.6	3.5	2.0	2.20
5	0.95	2.25	1.2	1.40
6	0.60	1.55	0.75	1.00
7	0.44	1.05	0.50	0.75
8	0.34	0.81	0.36	0.55
9	0.27	0.61	0.25	0.46
10	0.21	0.49	0.19	0.38
11	0.17	0.39	0.14	0.34
12	0.13	0.30	0.10	0.28
13	0.10	0.25	0.08	0.24
14	0.08	0.20	0.06	0.20
15	0.06	0.16	0.048	0.16
16	(0.050)	0.12	(0.043)	0.12
17	(0.042)	0.095	(0.038)	0.09
18	(0.037)	0.075	(0.034)	(0.064)
19	(0.033)	(0.063)	(0.030)	(0.048)
≥ 20	$(11.9/k^2)$	$(21.6/k^2)$	$(10.9/k^2)$	$(14.9/k^2)$

Table 1.4 Experimental cluster-size distributions P(k) in per cent by Fischle et al. [FIS 91]. Whereas the measured data and their errors are shown in Fig. 1.9, this table contains interpolated values for numerical applications. Values in brackets are extrapolations according to the expectation of free electrons

clusters. The most practical way to achieve the summation is by the Monte Carlo method on a computer, especially when the cluster-size distribution exists only in the form of a table.

In this case, we proceed in two steps. First, we make a random choice from the Poisson distribution (1.2) of a number *m* of encounters in the track length $x : \langle m \rangle = x/\lambda$. Second, we make *m* random choices from the cluster-size distribution P(k) of *m* cluster sizes k_1, k_2, \ldots, k_m . The number

$$n = \sum_{i=1}^{m} k_i \tag{1.36}$$

is one entry in a frequency distribution G(x, n) of the number of ionization electrons in *x*.

Figure 1.10 contains ionization distributions for several track lengths (mean numbers $\langle m \rangle$ of clusters) in argon that were computed in this way using the integrated probability Q depicted in Fig. 1.8. The ionization distributions develop a peak that defines *the most probable ionization* I_{mp} . They also have a *full width at half maximum* W, although the mean and the root-mean-square deviation exist only if an upper cut-off is introduced. The value of I_{mp} is not proportional to the mean number of clusters but rises from $\langle m \rangle$ to $\sim 3 \langle m \rangle$ as $\langle m \rangle$ increases from 5 to 1000. Figure 1.11

Fig. 1.10 Ionization distribution obtained by summing *m* times the cluster-size distribution of Fig. 1.8, using the method described in Sect. 1.2.3. On 1 cm of Ar in normal conditions there are, on the average, $\langle m \rangle = 35$ clusters ($\gamma = 1000$); the eight distributions then correspond to track lengths of 0.14, 0.29, 0.57, 1.4, 2.9, 5.7, 14, and 29 cm







shows this increase. It does not obey a simple law because it is influenced by the atomic structure of argon. Neglecting the atomic structure, it approaches a straight line; compare the remarks made on $\Delta_{\rm mp}$ after (1.49). The distributions of Fig. 1.10 also become more peaked, so that the ratio $W/I_{\rm mp}$ decreases from ~ 1.3 to ~ 0.3 in this range of $\langle m \rangle$.

Relative widths W/I_{mp} of measured pulse-height distributions quoted by Walenta [WAL 81] are shown in Fig. 1.11 as a function of the gas sample thickness *pL*. The ratio decreases with increasing *pL*. If we parametrize the decrease in the form of a power law,

$$\left(\frac{W}{I_{\rm mp}}\right)_1 : \left(\frac{W}{I_{\rm mp}}\right)_2 = [(pL)_1 : (pL)_2]^k,$$
 (1.37)

then from Fig. 1.12 we get k between -0.2 and -0.4. Since the ionization distribution depends only on the cluster-size distribution and the number of clusters, it depends on the sample length L and the gas pressure p through the product pL.



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Fig. 1.13 Average ionization after cutting the upper 5% of the probability distribution, calculated as a function of the average number $\langle m \rangle$ of clusters



For practical purposes, we introduce an upper cut-off E_{95} in the transferred energy at the level of 95% of the integrated probability distribution F(E):

$$\int_{0}^{E_{95}} F(E) \mathrm{d}E = 0.95.$$

This allows us to compute the *average ionization* $\langle I \rangle_{95}$ from the distributions of Fig. 1.10. It is plotted in Fig. 1.13 as a function of $\langle m \rangle$.

The role of the rare cases of large cluster sizes can be appreciated by looking at Fig. 1.8. Since 1% of the clusters are larger than 30 electrons, it takes of the order of 100 primary interactions (3 cm of argon NTP, $\gamma = 1000$) to have one such cluster among them. It will contribute about 10% to the total ionization. The larger the number *m* of clusters one needs to sum, the smaller will be the probabilities Q(n) that have to be taken into account. Let us compute the probability *P* that the very rare event of a large cluster above n_0 occurs at least once in a number of *m* clusters:

$$P = 1 - [1 - Q(n_0)]^m \approx 1 - e^{-mQ(n_0)}.$$
(1.38)

It can be shown that (1.38) is correct within 10% as long as $Q(n_0) < 1/\sqrt{(5m)}$.

If the cluster-size distribution is not known, we first calculate the energy loss Δ on a given track length *x* and its probability distribution $F(x, \Delta)$. This is then converted into the ionization distribution by dividing Δ by the appropriate value of *W*. The energy transfer spectrum is independent of any other collision, and we have to sum the contributions from as many collisions $\langle m \rangle = x/\lambda$ as there are on the length *x*, using expression (1.31).

These days this is best achieved by the Monte Carlo method using a computer. Working with analytical methods, one may also perform a stepwise convolution. For example,

$$F(2\lambda, \Delta) = \int_{0}^{\infty} F(\Delta - E)F(E)dE,$$

$$F(4\lambda, \Delta) = \int_{0}^{\infty} F(2\lambda, \Delta - E)F(2\lambda, E) dE, \text{ etc.}$$
(1.39)

The review of Bichsel and Saxon [BIC 75] contains more details about how to build up $F(x, \Delta)$.

Another way of constructing $F(x, \Delta)$ from F(E) was invented by Landau in 1944 [LAN 44]. He expressed the change of $F(x, \Delta)$ along a length dx by the difference in the number of particles which, because of ionization losses along dx, acquire a given energy E and the number of particles which leave the given energy interval near Δ :

$$\frac{\partial}{\partial x}F(x,\Delta) = \int_{0}^{\infty} F(E)[F(x,\Delta-E) - F(x,\Delta)] \, \mathrm{d}E. \tag{1.40}$$

(For the upper limit of integration, one may write ∞ because $F(x, \Delta) = 0$ for $\Delta < 0$.) The solution of (1.40) is found with the help of the Laplace transform $\bar{F}(x, p)$, which is related to the energy loss distribution by

$$\bar{F}(x,p) = \int_{0}^{\infty} F(x,\Delta) e^{-p\Delta} \, \mathrm{d}\Delta, \qquad (1.41)$$

$$F(x,\Delta) = \frac{1}{2\pi i} \int_{-i\infty+\sigma}^{+i\infty+\sigma} e^{p\Delta} \bar{F}(x,p) \, \mathrm{d}p.$$
(1.42)

Here the integration is to the right $(\sigma > 0)$ of the imaginary axis of *p*. Multiplying both sides of (1.40) by a $e^{-p\Delta}$ and integrating over Δ , we get

$$\frac{\partial}{\partial x}\bar{F}(x,p) = -\bar{F}(x,p)\int_{0}^{\infty}F(E)(1-\mathrm{e}^{-pE})\,\mathrm{d}E,\qquad(1.43)$$

which integrates to

$$\bar{F}(x,p) = \exp\left[-x \int_{0}^{\infty} \bar{F}(E)(1-\mathrm{e}^{-pE}) \,\mathrm{d}E\right],\tag{1.44}$$

because the boundary condition is $F(0,\Delta) = \delta(\Delta)$ or F(0, p) = 1. Inserting (1.41) into (1.44), Landau obtained the general expression for the energy loss distribution, valid for any F(E):

$$F(x,\Delta) = \frac{1}{2\pi i} \int_{-i\infty+\sigma}^{+i\infty+\sigma} \exp\left[p\Delta - x \int_{0}^{\infty} F(E)(1 - e^{-pE}) dE\right] dp.$$
(1.45)

This relation was evaluated by Landau for a simplified form of F(E) that is applicable at energies far above the atomic binding energies where the scattering cross-section is determined by Rutherford scattering and where the atomic structure can be ignored (see (1.32)). Inserting

$$F(E) = \frac{2\pi r_{\rm e}^2}{\beta^2} \frac{mc^2}{E^2} N$$
(1.46)

into (1.45), Landau was able to show that the probability distribution was given by a universal function $\phi(\lambda)$:

$$F(x,\Delta) d\Delta = \phi\left(\frac{\Delta - \Delta_{\rm mp}}{\xi}\right) d\left(\frac{\Delta - \Delta_{\rm mp}}{\xi}\right).$$
(1.47)

Here Δ_{mp} is the most probable energy loss, and ξ is a scaling factor for the energy loss, proportional to *x*:

$$\xi = x 2\pi r_{\rm e}^2 \frac{mc^2}{\beta^2} N. \tag{1.48}$$

The function $\phi(\lambda)$ and its integral $\psi(\lambda)$ are given as a graph in Fig. 1.14. Computer programs exist for the calculation of ϕ and for the random generation of Landaudistributed numbers: see Kölbig and Schorr [KÖL 84]. The integral probability for an energy loss exceeding Δ is

$$\int_{\Delta}^{\infty} F(x,\Delta') \, \mathrm{d}\Delta' = \psi\left(\frac{\Delta - \Delta_{\mathrm{mp}}}{\xi}\right). \tag{1.49}$$

We notice that 10% of the cases lie above the value of Δ that is three times the FWHM above the most probable value. For large positive values of the argument, $\phi(\lambda)$ tends to $1/\lambda^2$, $\psi(\lambda)$ tends to $1/\lambda$. The assumption (1.47) makes the Landau



Fig. 1.14 Landau's function $\phi(\lambda)$ and its integral $\psi(\lambda)$. The scale on the left refers to ϕ , the one on the right to ψ

curve a valid description of the energy loss fluctuations only in a regime of large Δ (corresponding to $x \approx 170 \,\mathrm{cm}$ in normal argon gas, according to an analysis of [CHE 76] [see also Fig. 1.21]). We skip a discussion of Landau's expression for $\Delta_{\rm mp}$ and of the normalization of his F(E). Let us remark, however, that, as a function of the length x, $\Delta_{\rm mp}$ is proportional to $x \log x$. In practice, the Landau curve is often used to parametrize energy loss distributions with a two-parameter fit of ξ and $\Delta_{\rm mp}$, without reference to the theoretical expressions for them.

Generalizations of the Landau theory have been given by Blunck and Leisegang [BLU 50], Vavilov [VAV 57], and others. The interested reader is referred to the monograph by Bugadov, Merson, Sitar and Chechin [BUG 88] for a comparison of these theories of energy loss.

When the summation of the energy lost over the length *x* has been achieved with any of the methods mentioned above, the energy loss distribution must be converted into an ionization distribution. We have to make the assumption that to every energy loss Δ there corresponds, on the average, a number *n* of ion pairs according to the relation

$$\Delta = nW, \tag{1.50}$$

where W is the average energy for producing an ion pair (Sect. 1.1.3). Expression (1.50) is to hold independently of the size or the composition of Δ (whether there are one large or many small transfers), and W is to be the constant measured with fully stopped electrons. It is hard to ascertain the error that we introduce with this assumption. The W measured with fully stopped electrons is known to increase for energy transfers below ~ 1 keV (Fig. 1.2).

Using (1.50), we obtain the probability distribution G(x, n) of the number *n* of ionization electrons produced on the track length *x*:

$$G(x,n) = F(x,nW)W.$$
(1.51)

In Fig. 1.15 we show two examples of ionization distributions calculated in this way by Allison and Cobb [ALL 80], compared with measured pulse heights from Harris et al. [HAR 73] on argon samples of 1.5 cm thickness. Although there is a small systematic shift and an excess of data at small *n* it is a remarkable fact that the pulse-height distribution can be predicted so well using the theory described above. For a comparison with the predictions of other models for calculating $F(x, \Delta)$, see Allison and Cobb [ALL 80], and Ermilova, Kotenko and Merzon [ERM 77].

1.2.6 Velocity Dependence of the Energy Loss

Let us go back to (1.29). The term proportional to θ is connected with Cerenkov radiation of frequency ω . It makes only a small contribution to the cross-section but has a very characteristic velocity dependence. As soon as ε_2 vanishes, this radiation will be emitted into the medium above a threshold given by

$$\beta_0^2 = \frac{1}{\varepsilon_1},\tag{1.52}$$

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Fig. 1.15 Measured pulseheight distributions from [HAR 73], compared with the predictions of the photo-absorption model of [ALL 80]. The experimental overflow is collected in the last bin. The horizontal scale is normalized to the peak of the 55 Fe spectrum (5.9keV = 223 electrons)



where θ jumps approximately from 0 to π as β increases. The emitted intensity in photons per unit path length per unit of photon energy interval is then

$$N\left(\frac{\mathrm{d}\sigma}{\mathrm{d}E}\right)_{\mathrm{Ce}} = \frac{\alpha}{c}\left(1 - \frac{1}{\beta^2\varepsilon_1}\right) = \frac{\alpha}{c\gamma_0^2}\frac{\gamma^2 - \gamma_0^2}{\gamma^2 - 1}.$$
(1.53)

The behaviour of this intensity as a function of $\gamma = 1/(1 - \beta^2)^{1/2}$ is plotted in Fig. 1.16. The threshold can be expressed by

$$\gamma_0^2 = \varepsilon_1 / (\varepsilon_1 - 1). \tag{1.54}$$

We now discuss the velocity dependence of the remaining terms in (1.29). They give the main contribution to the cross-section. The equation may be written in the form

$$\frac{d\sigma}{dE} = \frac{a}{\beta^2} \left[b + \ln \frac{\beta^2}{\left[(1 - \beta^2 \varepsilon_1)^2 + \beta^4 \varepsilon_2^2 \right]^{1/2}} \right],$$
(1.55)

where *a* and *b* depend on *E* and $\sigma_{\gamma}(E)$ but are independent of β .

Fig. 1.16 Intensity of Cerenkov radiation as a function of γ , according to (1.53)



There is an overall factor of l/β^2 which dominates at small β . For β near 1, the behaviour is determined by the logarithmic term which first rises and then remains constant as the relativistic velocity increases:

$$\ln \frac{\beta^2}{[(1-\beta^2\varepsilon_1)^2+\beta^4\varepsilon_2^2]^{1/2}} = \ln \frac{\gamma^2-1}{\{[\gamma^2(1-\varepsilon_1)+\varepsilon_1]^2+(\gamma^2-1)^2\varepsilon_2^2\}^{1/2}}$$
(1.56)

$$\to \ln \frac{\gamma^2 - 1}{\varepsilon_1} \quad \text{for } \gamma^2 \ll 1/|1 - \varepsilon|, \qquad (1.57)$$

$$\to \ln \frac{1}{|1-\varepsilon|} \quad \text{for } \gamma^2 \gg 1/|1-\varepsilon|. \tag{1.58}$$

The region (1.57) is called the relativistic rise and the region (1.58) the plateau of the energy loss (see Fig. 1.17).

$$Z = \ln \frac{\gamma^2 - 1}{\{ [\gamma^2(1 - \varepsilon_1) + \varepsilon_1]^2 + (\gamma^2 - 1)\varepsilon_2^2 \}^{1/2}};$$

 ε was put equal to $1 - 10^{-4} + 10^{-4}$ i



Fig. 1.17 Behaviour as a function of γ of the logarithmic term (1.56):

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1.2 Calculation of Energy Loss

The beginning of the plateau is characterized by a relativistic velocity factor γ^* , such that

$$\frac{\gamma^{*2} - 1}{\varepsilon_1} = \frac{1}{|1 - \varepsilon|}; \quad \gamma^* \approx 1\sqrt{|1 - \varepsilon|}. \tag{1.59}$$

As long as ε_1 is larger than 1 – as is usually the case for visible light – there is always some γ_0 to fulfill the Cerenkov condition (1.54), and Cerenkov radiation is emitted into the medium if it is transparent ($\varepsilon_2 = 0$). Under these conditions, the beginning of the plateau region is at the same velocity: $\gamma^* \approx \gamma^0$. But if ε_1 is smaller than 1, as happens for energies *E* above the highest resonances of the atoms of the medium, then there is no Cerenkov light to correspond to the onset of the plateau.

In the theory of optical dispersion, the behaviour of $\varepsilon(\omega)$ for $\omega = E/\hbar$ far above the resonances is described using the concept of plasma frequency ω_p , which is given by the charge *e*, the mass *m* and the density *N* of the electrons in the gas (e.g. [JAC 75]):

$$\omega_{\rm p}^2 = 4\pi N e^2/m. \tag{1.60}$$

It is shown that there

$$\varepsilon_1(\omega) \approx 1 - \omega_p^2/\omega^2,$$
 (1.61)

$$\varepsilon_2(\omega) \ll 1 - \varepsilon_1(\omega).$$
 (1.62)

In connection with (1.59), the beginning of the plateau is given by the plasma frequency for every value *E* of the energy loss:

$$\gamma^* \approx \omega/\omega_{\rm p} = \left(\frac{m}{4\pi Nc^2}\right)^{1/2} \frac{E}{\hbar}.$$
 (1.63)

It turns out that this relation (which was derived for a free-electron gas) already holds very well for all *E* above the M-shell resonances in argon.

The existence of a plateau is caused by the density of the medium. Both $(1 - \varepsilon_1)$ and ε_2 are proportional to the electron density *N* and go to zero when *N* does. We can see from (1.59) and also from (1.29) that the relativistic rise of the energy loss will continue for all γ in the limit of vanishing *N*, and there will be no plateau. The medium with vanishing density behaves like a single atom, which has no plateau for the collision cross-section.

Figure 1.18 shows the energy loss cross-section in argon as a function of $\beta\gamma$ for three representative values of *E*, calculated by Allison and Cobb from (1.29) without the small Cerenkov term. The variable $\beta\gamma$ instead of γ is chosen because it is more appropriate at small β , and also it is the variable in which energy loss had been discussed before using the Bethe–Bloch formula (Sect. 1.2.7). The three curves are normalized at their minimum approximately at $\gamma = 4$. The onset of the plateau is at values γ^* proportional to *E*, as described by (1.63). From the point of view of particle identification, the large *E* are the best, but they are also very rare (see Figs. 1.7 and 1.8).

After integration over E, the calculated most probable energy loss had the form depicted in Fig. 1.19, where it is compared with measurements (see Lehraus et al.

1 Gas Ionization by Charged Particles and by Laser Rays

Fig. 1.18 Energy dependence of dE/dx: variation with $\beta\gamma$ of the energy loss crosssection for Ar at normal density, normalized to $\beta\gamma = 4$, according to a calculation by Allison and Cobb [ALL 80]. The curves are for three values of the energy loss *E*, corresponding to M-, L-, and K-shell ionization



[LEH 82] and references quoted therein). Both the measured and the calculated values are normalized at $\gamma = 4$. The agreement is remarkable and indicates that the theory gives an adequate explanation of the velocity dependence of gas ionization.

The effect of the gas density on the relativistic rise is visible in the data of Fig. 1.20. There is also a small dependence on the gas sample thickness, for which we refer the reader to an article by Walenta [WAL 79] and to Fig. 10.5.



Fig. 1.19 Measured values of the most probable energy loss in an Ar + methane mixture as a function of $\beta\gamma$, compared with the photo-absorption model of Allison and Cobb for Ar. For details, see [ALL 80] and [LEH 82] and references quoted therein

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Fig. 1.20 Density dependence of dE/dx: variation with $\beta\gamma$ of the most probable value of the pulse-height distribution, normalized to the value at the minimum, according to measurements by Walenta et al. [WAL 79] in Ar (90%) + CH₄ (10%) over a length of 2.3 cm. The measurements are at four values of the gas pressure. The interpolating curves were calculated according to the theory of Sternheimer

There is a velocity dependence not only of the most probable value but also of the whole shape of the ionization distribution. This dependence is particularly pronounced in very small gas samples, i.e. with small numbers of primary encounters, where the change in statistics – a consequence of the velocity dependence of the primary ionization – is relatively large. We see in Fig. 1.21 the energy-loss distributions calculated with the PAI model for thin (x = 1.5 cm) and very thin (x = 0.3 cm) argon samples, at five different velocities. The curious disappearance of the sharp peak in the very thin sample is caused by the shell structure of the argon atom.

1.2.7 The Bethe–Bloch Formula

Historically, Bethe was the first to calculate, in 1930, the average energy loss with a quantum theory of collision between the travelling particle and a single atom. After adding the energy lost to all the atoms in the vicinity of the particle, the energy loss per unit of pathlength is given by

$$\frac{\mathrm{d}E}{\mathrm{d}x} = \frac{4\pi N e^4}{mc^2 \beta^2} z^2 \left(\ln \frac{2mc^2 \beta^2 \gamma^2}{I} - \beta^2 \right) \tag{1.64}$$

([BET 33], Eq. 7.15). In this equation mc^2 is the rest energy of the electron, z the charge of the travelling particle, N the number density of electrons in the matter traversed, e the elementary charge, β the velocity of the travelling particle in terms of the velocity c of light, and $\gamma^2 = 1/(1 - \beta^2)$. The symbol I denotes the mean excitation energy of the atom. Bloch calculated values of I using the Thomas–Fermi theory of the atom. Equation (1.64) is also called the Bethe–Bloch formula. It describes the integral over all the energies lost to the individual atoms of the medium. This integral extends up to the maximum of the transferrable energy, and it is for



Fig. 1.21a,b d*E*/dx-distributions calculated with the PAI model in argon [ALL 81] for different values of γ (a) sample length 0.3 cm; (b) 1.5 cm, both at normal density

this reason that (1.64) is only valid for travelling particles heavier than electrons. These have different kinematic limits because of their small mass and because they are identical with their collision partner; also their spectrum of transferred energy is different. A modification of (1.64) will make it valid for electrons and heavier particles alike above some value of γ ; see Sect. 1.2.8.

The factor at the front of (1.64) can be brought into a different form by expressing N through Avogadro's number N_0 , the gas density ρ and the ratio of atomic number Z and atomic weight A of the medium: $N = N_0(Z/A)\rho$. Also, e^2/mc^2 is equal to the classical electron radius $r_e = 2.82$ fm. Therefore, (1.64) can be written as

$$\frac{\mathrm{d}E}{\mathrm{d}x} = 4\pi N_0 r_{\rm e}^2 mc^2 \frac{Z}{A} \rho \frac{1}{\beta^2} z^2 \left(\ln \frac{2mc^2}{I} \beta^2 \gamma^2 - \beta^2 \right)$$
$$= 0.3071 \left(\frac{\mathrm{MeV}}{\mathrm{g/cm^2}} \right) \frac{Z}{A} \rho \frac{1}{\beta^2} z^2 \left(\ln \frac{2mc^2}{I} \beta^2 \gamma^2 - \beta^2 \right)$$
(1.65)

As $\beta \gamma$ is increased dE/dx falls at first with $1/\beta^2$, then goes through a minimum and rises again for larger values of $\beta \gamma$. The logarithmic term describes the relativistic rise. Its strength is given by the mean excitation energy *I*. There are two physical origins of this effect. One is in the time behaviour of the electromagnetic field carried by the travelling particle. As seen from the atom, the field components of short duration become stronger as γ goes up, increasing the cross-section for the excitation and ionization. The other reason is kinematic. As $\beta\gamma$ is increased the maximal possible energy that can be conveyed from the particle to the atom goes up too and makes the average energy increase with $\beta\gamma$. For example, a pion of 1 GeV can transfer 50 MeV, and a pion of 10 GeV can transfer 3.3 GeV to an electron at rest. Such large energy transfers are not applicable to tracks in drift chambers; this is another reason for a necessary modification of (1.64); see Sect. 1.2.8.

The mean excitation energy I is calculable for simple atoms, but it has most often been considered a parameter to be fitted from the measurements of the ionization energy loss near the minimum. A critical collection of such determinations of Iis contained in an article by Seltzer and Berger [SEL 82], a selection for relevant drift chamber gases is presented in our Table 1.5. The mean excitation energy for the chemical elements is found to increase with the atomic number Z and follows approximately

I = AZ

with A decreasing from 20 eV (H) to 13 eV (C) and roughly 10 eV (Ar and higher). Values of *I* for compounds and mixtures can be calculated in a first approximation according to Bragg's additivity rule, which states that

$$\ln I_{\rm compound} = \sum n_i \ln I_i / \sum n_i,$$

where the n_i and I_i are the electron densities and the mean excitation energies belonging to element *i*.

Table 1.5	Mean	excitation	energies	and	specific	ionization	in	the	minimum	for	various	gases.
Values of J	I from	[SEL 82], v	values of	(dE)	$(dx)_{\min}/f$	o calculate	d fr	om	(1.64')			

Gas		Ζ	А	Density ρ (N.T.P.) (g/I)	Mean excitation energy <i>I</i> (<i>eV</i>)	$(dE/dx)_{min}/\rho$ (MeV/g cm ⁻²)
Uudnogon	ц	1	2.016	0.000	10.2	4.11
Helium	п ₂ Не	2	4.003	0.090	41.8	4.11
Neon	Ne	10	20.18	0.90	137	1.73
Argon	Ar	18	39.95	1.78	188	1.52
Krypton	Kr	36	83.8	3.74	352	1.36
Xenon	Xe	54	131.3	5.89	482	1.26
Oxygen	O_2	16	32.00	1.43	95	1.81
Nitrogen	N_2	14	28.01	1.25	82	1.83
Methane	CH_4	10	16.04	0.72	41.7	2.43
Ethane	C_2H_6	18	30.07	1.25	45.4	2.31
Propane	C_3H_8	26	44.11	1.88	47.1	2.27
Isobutane	$C_{4}H_{10}$	34	58.12	2.67	48.3	2.25
Ethylene	C_2H_4	20	28.05	1.18	51	2.73
Carbon dioxide	CO_2	22	44.00	1.98	85	1.83

It was discovered later that the relativistic rise would not continue to indefinitely large values of γ . In 1939, Fermi calculated the 'density effect' as the coherent effect of the surrounding polarizable atoms, which shield the field of the travelling particle [FER 40]. A corresponding correction term $\delta(\beta)$ is introduced into (1.64), which reads in its conventional form

$$\frac{\mathrm{d}E}{\mathrm{d}x} = \frac{4\pi N e^4}{mc^2} \frac{1}{\beta^2} z^2 \left(\ln \frac{2mc^2}{I} \beta^2 \gamma^2 - \beta^2 - \frac{\delta(\beta)}{2} \right). \tag{1.66}$$

The exact behaviour of $\delta(\beta)$ obviously has to depend on the substance and its state of aggregation. Sternheimer and others have made parameter descriptions of $\delta(\beta)$ which consist of piecewise power-law fits with coefficients derived from the known oscillator strengths of the relevant substances. Such parameters are tabulated in [STE 84], and the literature can be traced back from there. Near the minimum, $\delta = 0$, and in the limit of $\beta \to 1$, the density correction approaches

$$\delta \to \ln \frac{\hbar^2 \omega_p^2}{I^2} \gamma^2 - 1 \tag{1.67}$$

([FAN 63], Eq. 1.49), where $\hbar \omega_p$ is the quantum energy of the plasma oscillation of the medium (see (1.60)). The correction term $\delta(\beta)/2$ in (1.66), being a linear function of ln γ cancels some but not all of the relativistic rise – the dynamic part has disappeared, and the kinematic part still makes the total energy loss increase, albeit with a smaller rate than before.

1.2.8 Energy Deposited on a Track – Restricted Energy Loss

The track ionization for drift chambers cannot be calculated on the basis of the total energy loss described in (1.64). This formula includes all the high-energy transfers that do not contribute to a track, although they are kinematically possible. Above a certain energy, an electron knocked out of a gas atom will form a second track, a δ electron, and will not contribute to the first one any more. Above what energy the new track is recognized and its ionization no longer attributed to the first track depends on the circumstances. Among these circumstances there is the *range* (i.e. the length of δ ray until it is stopped) in the particular gas. If the range is below the typical size of the pick-up electrodes, there is no separation yet. If the range is large compared to this size, then the second track may be separated by the electronics and the pattern recognition program. If there is a *magnetic field* and the track of the δ electron is curved, a similar idea applies to the radius of curvature.

There are also statistical circumstances that produce an effective cut-off: in any finite number of measurements there is always one largest energy transfer. A value of energy transfer so improbable that no track of a given series of measurements, or only an insignificant part of them, contains one is also an effective cut-off. We have calculated some examples of cut-off energies in Table 1.6 which result from the different effects mentioned above.

1.2 Calculation of Energy Loss

Table 1.6 Some energy transfers E relevant for the introduction of an upper cut-off in the definition of a track of ionization in argon gas

Range of δ electron (bar cm)	E (keV)
1	30
3	60
10	120
30	250
Radius of curvature of δ -electron track in different magnetic fields (cm)	E (MeV)
0.5 in 0.4 T	0.3
0.5 in 1.5 T	1.8
5 in 0.4 T	5.5
5 in 1.5 T	22
Probability of finding one interac- tion with minimum deposit of <i>E</i> on 1 bar m of tracklength	E (MeV)
0.1%	12
1%	1.2
10%	0.12

Kinematic limits of maximum transferrable energy (MeV)

βγ	e	π	р
0.1	0.001	0.010	0.010
1	0.106	1.01	1.02
4	0.80	15.9	16.3
10	2.31	95	101
100	25.3	$5.8 imes 10^3$	9.2×10^3
1000	255	121×10^3	490×10^3

It appears from Table 1.6 that in a typical argon chamber without magnetic field a cut-off E_{max} somewhere between 30 and 250 keV is at work on account of the range. Inside a magnetic field the situation is more complicated because some δ rays will curl up and stay with the primary track, even up to 1 or several MeV; but this happens only at the 1% probability level per bar *m* of tracklength. In summary: there is a cut-off with a value somewhere between 30 keV and 1 MeV (for a typical argon chamber), depending on the apparatus. It has to replace the kinematic limit if it is smaller.

The modified Bethe–Bloch formula for the energy loss restricted in this way reads as follows ([FAN 63], 1.88):

1 Gas Ionization by Charged Particles and by Laser Rays

$$\left(\frac{\mathrm{d}E}{\mathrm{d}x}\right)_{\mathrm{restricted}} = \frac{4\pi N e^4}{mc^2} \frac{1}{\beta^2} z^2 \left[\ln \frac{\sqrt{2mc^2 E_{\mathrm{max}}} \beta \gamma}{I} - \frac{\beta^2}{2} - \frac{\delta(\beta)}{2} \right].$$
(1.68)

Equation (1.68) holds for the range of $\beta \gamma$ where E_{max} is smaller than the kinematic limit, and for $\gamma^2 \gg E_{\text{max}}/mc^2$. In comparison to (1.66) the value at the minimum as well as the relativistic rise have become smaller. Formulae (1.64) and (1.66) were valid for particles heavier than electrons, because electrons have different kinematic limits and a different spectrum. The restricted energy loss (1.68) is also applicable for electrons because the different kinematic limits have been replaced by the common cut-off E_{max} . It can be shown ([BET 33], Eq. 55.8) that electrons travelling with $\gamma^2 \gg E_{\text{max}}/mc^2$ produce essentially the same spectrum as heavier particles with the same γ . The universal validity of (1.68), which implies that the restricted energy loss is a function only of the particle velocity and not of the mass or the energy separately, is a consequence of the introduction of the cut-off energy E_{max} .

In the limit $\beta \to 1$ we now have complete cancellation of the γ dependence, and the restricted energy loss reaches the 'Fermi plateau'; insertion of (1.67) into (1.68) yields

$$\left(\frac{\mathrm{d}E}{\mathrm{d}x}\right)_{\mathrm{restr}\beta=1} = \frac{4\pi N e^4}{mc^2} z^2 \ln \frac{\sqrt{2mc^2 E_{\mathrm{max}}}}{\hbar\omega_{\mathrm{p}}}.$$
 (1.69)

The ratio between the values of the restricted energy loss on the plateau and in the minimum is given by

$$R(E_{\max}) = \frac{\left(\frac{dE}{dx}\right)_{\substack{\text{restricted}}}^{\text{plateau}}}{\left(\frac{dE}{dx}\right)_{\substack{\text{restricted}}}^{\text{minimum}}} = \frac{\ln \frac{\sqrt{2mc^2 E_{\max}}}{\hbar \omega_p}}{\ln \frac{\sqrt{2mc^2 E_{\max}}}{I}(\beta \gamma)_{\min} - \frac{\beta_{\min}^2}{2}}.$$
(1.70)

If we insert the values of ω_p and *I* for argon gas at N.T.P., using (1.60) and Table 1.5, we obtain R = 1.60, 1.54 and 1.48 for $E_{max} = 30 \text{ keV}$, 150 keV and 1 MeV, respectively. A precise evaluation of *R* requires better knowledge of E_{max} . When varying the gas and its density, E_{max} will also change in most applications.

The interest in particle identification by ionization measurement brings into focus the *accuracy* and hence the statistical aspect. The *average* energy loss has large fluctuations due to rare events with large energy transfer. Therefore the *most probable* energy loss is a better estimator.

The analytic method of Landau for the determination of the most probable energy loss cannot be a basis for the calculation of the energy dependence of ionization in drift chambers – their gas layers are too thin, and the cut-off required by the definition of a track is not part of Landau's method.

A statistical formulation of the problem, treated with Monte-Carlo methods along the lines of Ermilova, Kotenko and Merzon [ERM 77] or of Allison and

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Cobb [ALL 80], is better suited to describing the velocity dependence of the most probable energy loss. The properties of the medium enter into these models through the frequency dependence of the dielectric constant, which in turn is derivable from experimental photoabsorption coefficients. We have presented the photoabsorption ionization model [PAI] of Allison and Cobb in Sect. 1.2.2. Some more information including numerical values of the energy loss from the PAI model on the Fermi plateau is contained in Chap. 10. A step-by-step comparison of the method of Bethe–Bloch–Sternheimer with the PAI model does not exist, to our knowledge.

The reader who is interested in more historical details may find useful the famous old book by Rossi [ROS 52]. An in-depth discussion of ionization is contained in the monograph by Bugadov, Merson, Sitar and Chechin [BUG 88] as well as in the article by Fano [FAN 63].

1.2.9 Localization of Charge Along the Track

As we have seen in Sects. 1.1.1 and 1.2.2, the charge along a track is created in discrete clusters that vary greatly in size. This has some consequence for the coordinate measurement of the track. The precise way in which the discrete nature of ionization determines fundamental limits of accuracy depends on the measurement method in question and will be dealt with in Chap. 7. In preparation, we discuss here the following question: Given a certain track length L – for example, the part of the track collected onto one wire – with what precision is the centre of gravity of the discretely deposited ionization located along the track? If the coordinate along the track is x, and in the *i*th cluster we have n_i electrons, then the centre of gravity is at

$$\bar{x} = \sum_{i=1}^{m} (x_i n_i) \Big/ \sum_{i=1}^{m} n_i.$$
(1.71)

Let the track extend around 0 from -L/2 to +L/2. The probability distribution for every x_i is

$$f(x_i) dx_i = (1/L) dx_i.$$
 (1.72)

Averaging over all x_i , we have for every fixed set of n_i

$$\langle \bar{x} \rangle = 0$$

and

$$\langle \bar{x}^2 \rangle = \left\langle \sum_{i=1}^m x_i^2 n_i^2 \right\rangle / \left(\sum_{i=1}^m n_i \right)^2$$

$$= \frac{L^2}{12} \sum_{i=1}^m n_i^2 / \left(\sum_{i=1}^m n_i \right)^2 = \frac{L^2}{12} \frac{1}{N_{\text{eff}}}.$$
(1.73)

Average number $\langle m \rangle$	1	5	10	20	50	100	200	500	1000
N _{eff}	1	2.4	3.7	5.2	8.0	12	15	26	41

Table 1.7 Values of $N_{\rm eff}$ calculated for various average numbers $\langle m \rangle$ of clusters, using the clustersize distribution of Fig. 1.7

This is because the x_i are created independently of each other so that the mixed terms $x_i x_j$ in the square drop out. The statistical factor that multiplies $L^2/12$ has been denoted $1/N_{\text{eff}}$ in (1.73); its value depends on the partitioning of the charge over the *m* clusters. If all clusters were equally large, then N_{eff} would take on the value *m*. It is equal to the equivalent number of independently fluctuating entities of equal sizes that create a fluctuation that is the same as the one created by the clustered charges. As these are different in size, N_{eff} has to be smaller than *m*.

For a calculation of N_{eff} , which governs the localizability of any cluster ionization charge, we have to integrate over the cluster-size distribution. Starting from the one plotted in Fig. 1.7 we calculate, with the Monte Carlo method, the values listed in Table 1.7.

There are two properties of $N_{\rm eff}$ that are remarkable: (i) it is quite small compared with the average number $\langle m \rangle$ of clusters (let alone the total ionization); (ii) it does not grow as fast as $\langle m \rangle$ (see the graph in Fig. 1.22). The reason for the latter is that the relative contribution of the rare large clusters grows with the increase of the number of clusters as the tail of the cluster-size distribution is sampled more often.

The variation of $N_{\rm eff}$ with $\langle m \rangle$ seen in Fig. 1.22 may be described roughly as

$$N_{\rm eff} = \langle m \rangle^{0.54}.\tag{1.74}$$

There is a statistical correlation between N_{eff} and the total charge deposited in *L*. It can be used to increase N_{eff} by cutting on the pulse height, but the gain is not overwhelmingly large.

If diffusion is taken into account, N_{eff} may become considerably larger in time, owing to the declustering effect. This is treated in Sect. 1.2.





1.2.10 A Measurement of N_{eff}

The effective number of independently fluctuating charges along the length L of a track can be measured. The r.m.s. fluctuation of the centre of gravity of the charge deposited along L is, by definition of N_{eff} , equal to

$$\delta y_{\rm c} = \frac{L}{\sqrt{12N_{\rm eff}}}$$

A particle track whose ionization is sampled over a length *L* by *n* wires with pulse heights $P_i(i = 1, ..., n)$ has the centre of its charge at

$$y_{\rm c} = \sum P_i y_i / \sum P_i,$$

where the y_i are the wire positions along the track. A measurement of y_c of many tracks allows a determination of δy_c , and hence of N_{eff} , to be made.

In an experiment using a model of the ALEPH TPC, cosmic-ray tracks were collected in a small interval of momentum and angle of incidence. The chamber contained an Ar $(90\%) + CH_4(10\%)$ gas mixture at atmospheric pressure and had a sense-wire spacing of 0.4 cm. Track lengths *L* between 0.8 and 20 cm were specified and $N_{\rm eff}$ was calculated for every *L*. The result is shown in Fig. 1.23. The choice of *L* is limited on the low side by the wire spacing and on the high side by the dynamic range of the pulse-height recording. In the case under consideration, the overflow bin contained 1.5% of the pulses. For higher values of *L* this bin is sampled more often, and the calculated number $N_{\rm eff}$ begins to depend on the details of an extrapolation of the overflow bin. A power-law fit to Fig. 1.23 shows that $N_{\rm eff}$ varied with *L* according to

$$N_{\rm eff} \propto (L/1\,{\rm cm})^{0.45\pm0.1}$$

Comparing Figs. 1.22 and 1.23, we notice that the exponent is identical, within errors, to that obtained from the theoretical cluster-size distribution. Using the power law, which is only an empirical relation, we may obtain an estimate of the primary ionization density, because it can be expected that the function $N_{\text{eff}}(L)$ becomes equal to 1 at $L = \lambda$, the average distance between clusters.

Fig. 1.23 N_{eff} measured with cosmic rays as a function of the track length *L*. The last data point has the largest dependence on the treatment of the overflow bin (see text). The three values correspond to extrapolation according to (*a*) a $1/PH^2$ law, (*b*) the Landau distribution or (*c*) no extrapolation, respectively



1.3 Gas Ionization by Laser Rays

The light of a narrow pulsed laser beam that traverses a volume of gas, under favourable conditions, is capable of ionizing the gas in the beam so that it imitates a straight particle track. For this to occur, there must be some ionizable molecules in the gas, and the energy density must be sufficiently high, depending on the wavelength. In practice, a small nitrogen laser, emitting pulses of 10^4 W on a few square millimetres at $\lambda = 337$ nm, may be sufficient in an ordinary chamber gas that has not been especially cleansed and therefore contains suitable molecules in some low concentration. This technique has the obvious advantage of producing identical tracks in the same place. Therefore, by taking repeated measurements of the same coordinate, one may form the average, which can be made almost free from statistical variations, if only the number of repeated measurements is made large enough. In practice 100 shots are usually sufficient. The technique has been widely used ever since its first application in 1979 [AND 79].

Chemical compounds used for laser ionization are discussed in Sect. 12.4.

1.3.1 The nth Order Cross-Section Equivalent

The quantum energy of laser light in the visible and the near ultraviolet is much lower than the ionization energies of molecules. It takes two or more such laser photons to ionize the organic molecules present in the chamber gas. Multiphoton ionization processes involving 11 photons have been observed in xenon (see the review by Lambropoulos [LAM 76]). For the ionization of a molecule to occur, the *n* photons have to be incident on the molecule during the lifetime of the intermediate states. Then the ionization rate varies the *n*th power of the photon flux because the photons act incoherently in the gas. The probability of *n* photons arriving in a given time interval is equal to the *n*th power of the photon flux ϕ . Just as the concept of 'cross-section' σ describes one-particle collision rates in units of cm², we have an '*n*th-order cross-section equivalent' $\sigma^{(n)}$ for *n*-particle collisions in units of cm²ⁿsⁿ⁻¹. In a volume *V* containing a density *N* of molecules, the ionization rate *R* is therefore given by the expression

$$R = \phi^n NV \ \sigma^{(n)}. \tag{1.75}$$

In fact, *n*-photon ionization is most easily identified by a measurement of *R* as a function of ϕ .

A light pulse with cross-sectional area A and duration T contains m photons if the flux ϕ and the energy E are given by

$$\phi = m/(AT),$$

$$E = mhv = mhc/\lambda$$

Considering a traversed volume V = AL, the specific ionization per unit track length for the *n*-photon process is

$$\frac{RT}{L} = \frac{m^n}{(AT)^{n-1}} N \sigma^{(n)}$$
$$= \left(\frac{E}{AT}\right)^n ATN\left(\frac{\lambda}{hc}\right)^n \sigma^{(n)}.$$
(1.76)

In (1.76), (E/AT) is the power density of the beam.

So far, we have implicitly assumed the duration of the light pulse to be short compared with the inverse transition frequencies between the states involved. The more general situation develops towards a dynamic equilibrium between excitation and de-excitation. The case of two-photon ionization is treated in more detail in Sect. 1.3.2.

The molecular ions created in the ionization do not as a rule resemble the parent molecules very much, because they are cracked in the process. Fragmentation patterns are complicated and usually not understood [REI 85].

1.3.2 Rate Equations for Two-Photon Ionization

For the electrons in the molecules, we distinguish the ground level (0), the intermediate level (1), and the continuum ionization level (2). We denote the population densities in the gas by P_0 , P_1 , and P_2 . The incident radiation stimulates transitions $0 \rightarrow 1$, $1 \rightarrow 2$, and $1 \rightarrow 0$, but there are also spontaneous transitions $1 \rightarrow 0$. Depending on the circumstances, there may be losses from level 1 into other channels. The transition rates, denoted by k_1 to k_4 , are determined by the incident flux and by the internal transition mechanism.

The rate equations are written in the following form (the primes denote the time derivatives):

$$P_0'(t) = -k_1 P_0(t) + (k_1 + k_2) P_1(t),$$

$$P_1'(t) = +k_1 P_0(t) - (k_1 + k_2 + k_3 + k_4) P_1(t),$$

$$P_2'(t) = k_4 P_1.$$
(1.77)

They are symbolized in Fig. 1.24.

The rate per molecule k_1 is taken to be proportional to the incoming flux ϕ of photons; the constant of proportionality is the cross-section σ_{01} for the process $0 \rightarrow 1$:

$$k_1 = \sigma_{01}\phi. \tag{1.78}$$

We want to calculate the transition rate $P'_2(t)$ with which electrons appear in the continuum state. It is proportional to the density $P_1(t)$ of the intermediate state, and the corresponding rate per molecule is

$$k_4 = \sigma_{12}\phi. \tag{1.79}$$

Fig. 1.24 Scheme of the five transition rates used in (1.77a–c)



The first two of the rate equations are a system of homogeneous linear differential equations. Before we derive the general mathematical solution, we shall consider some limiting cases in order to better understand the physical content of (1.77).

Before the pulse arrives, $P_0(0)$ is of the order of 10^{13} per cubic centimetre in a gas having a typical concentration of the ionizing molecules of one part per million, and $P_1(0) = 0$. While $P_1(t)$ is slowly built up at the rate $P'_1(t)$, we may consider P_0 as a constant as long as $P_1(t)$ has not developed into a similar order of magnitude. The situation of making only a few ionization electrons with the laser shot is well described by this approximation, which treats the ground state as an infinite reservoir.

(*a*) *Case of P*₀ *as an Infinite Reservoir*. We may write the first two of (1.77) in the following form:

$$P_0'(t) = -k_1 P_0 + (k_1 + k_2) P_1(t), \qquad (1.80a)$$

$$P_1'(t) = +k_1 P_0 - (k_1 + k_2 + k_3 + k_4) P_1(t).$$
(1.80b)

The solution of (1.80b) is

$$P_1(t) = \frac{k_1 P_0}{\sum k} (1 - e^{-t \sum k}), \qquad (1.81)$$

where $\sum k = k_1 + k_2 + k_3 + k_4$. Obviously, our approximation is always fulfilled if $k_1 \ll \sum k$ or $\sigma_{01}\phi \ll \sum k$ (using (1.78)). Let us assume that this is the case. Equation (1.81) leads to a production rate of ionization equal to

$$P_2'(t) = k_4 P_1(t) = \frac{k_1 k_4 P_0}{\sum k} (1 - e^{-t \sum k}).$$
(1.82)

Integrated over the duration T of a constant light pulse, the total density reached at the end of the pulse is given by

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1.3 Gas Ionization by Laser Rays

$$P_2(T) = \frac{k_1 k_4 P_0}{\sum k} \left[T - (1 - e^{-T \sum k}) / \sum k \right].$$
(1.83)

In the limit of short pulses, i.e. $T \ll 1/\sum k$, the exponential may be expanded to second order and gives us

$$P_2(T) \to \frac{1}{2} k_1 k_4 P_0 T^2.$$
 (1.84)

In the limit of long pulses, i.e. $T \gg 1/\sum k$, the exponential vanishes, so that

$$P_2(T) \to \frac{k_1 k_4 P_0}{\Sigma k} T. \tag{1.85}$$

Expression (1.84) is proportional to ϕ^2 , the square of the photon flux, because of (1.78) and (1.79). This is also the case for expression (1.85) unless k_1 or k_2 dominates $\sum k$. In our approximation that treats P_0 as an infinite reservoir, we assume that $k_1 \ll \sum k$; then a similar condition holds for k_2 (except for special circumstances in which σ_{12} is orders of magnitude larger than σ_{10}):

$$P_2(T) \rightarrow \frac{1}{2}\sigma_{01}\sigma_{12}P_0\phi^2 T^2 \quad (\text{small } T, \text{ small } \phi), \tag{1.86}$$

$$P_2(T) \to \frac{\sigma_{01}\sigma_{12}}{k_2 + k_3} P_0 \phi^2 T \quad (\text{large } T, \text{ small } \phi).$$

$$(1.87)$$

(b) General Case. If we want to know what happens when the photon flux is strong, (1.77) have to be solved in a rigorous way. This is achieved by a variable transformation that separates the equations (see any textbook on differential equations, for example [KAM 59].) One finds the eigenvalues s_1, s_2 of the matrix of coefficients from the determinant

$$\begin{vmatrix} -k_1 - s & k_1 + k_2 \\ k_1 & -\sum k - s \end{vmatrix} = 0,$$
(1.88)

$$s_{1,2} = -\frac{\sum k + k_1}{2} \pm \left[\left(\frac{\sum k + k_1}{2} \right)^2 - k_1(k_3 + k_4) \right]^{1/2}.$$
 (1.89)

These two eigenvalues are real and negative; we take $s_2 < s_1 < 0$.

The solutions to the differential equations (1.77) satisfying the initial conditions $P_1(0) = 0, P_2(0)$, are given by

$$P_0(t) = \frac{P_0(0)}{s_1 - s_2} [-(k_1 + s_2)e^{s_1t} + (k_1 + s_1)e^{s_2t}], \qquad (1.90a)$$

$$P_1(t) = \frac{P_0(0)k_1}{s_1 - s_2} [e^{s_1 t} - e^{s_2 t}],$$
(1.90b)

$$P_2(t) = \frac{P_0(0)k_1k_4}{s_1s_2} \left[1 + \frac{s_2}{s_1 - s_2} e^{s_1t} - \frac{s_1}{s_1 - s_2} e^{s_2t} \right].$$
 (1.90c)

Equation (1.90c) represents the general solution to the problem. It describes the concentration of ionization electrons as a function of time and of the rate coefficients k_1 to k_4 . For small *t* we recover our expressions (1.84) and (1.86) by developing the exponentials to the second order in s_1t and s_2t :

$$P_2(t) \to \frac{1}{2}k_1k_4P_0(0)t^2.$$
 (1.91)

For large t, using (1.89), we obtain

$$P_2(t) \to \frac{k_4}{k_3 + k_4} P_0(0).$$
 (1.92)

This enormous concentration of electrons (saturation) would imply that the ground state has been emptied, a situation that should not concern us when we study ionization tracks that are similar to particle tracks.

Equation (1.91), identical to (1.84) and (1.86), gives rise to the definition of the second-order cross-section equivalent described in Sect. 1.3.1. For a laser shot of duration *T*, identifying R/V with P_2/T , we have

$$\sigma^{(2)} = \frac{1}{2}\sigma_{01}\sigma_{12}T.$$
(1.93)

Under the conditions that lead to (1.87), we have instead

$$\sigma^{(2)} = \sigma_{01}\sigma_{12}/(k_2 + k_3), \tag{1.94}$$

whereas under the most general conditions, including saturation, $\sigma^{(2)}$ depends not only on *T* but also on ϕ .

1.3.3 Dependence of Laser Ionization on Wavelength

The ionization yield depends very much on the wavelength. Using tunable dye lasers, Ledingham and co-workers have found an increase of four orders of magnitude, when going from $\lambda = 330 \text{ nm}$ to $\lambda = 260 \text{ nm}$. In Fig. 1.25 'clean' counter gas is compared with a gas seeded with a small amount of phenol. The fine structure visible around 270 nm was resolved using high-resolution techniques and was compared with the known single-photon UV absorption of phenol (see Fig. 1.26).

The identical wavelength dependence is apparent. We understand this behaviour from (1.93) and (1.94): the wavelength dependence resides almost entirely in the factor σ_{01} , implying that the cross-section for ionization from the intermediate level does not vary so much. The amount of characteristic structure in the spectrum of laser-induced resonant two-photon ionization ('R2PI') makes it a sensitive tool for the identification of molecules [HUR 79].



Fig. 1.25 Ionization induced in untreated counter gas [Ar (90%) + CH₄(10%)] by a $1 \times 1 \text{ mm}^2$ pulsed laser beam of $1 \mu J(\times)$, compared with the same gas seeded with a small amount of phenol (+) [TOW 86]



Fig. 1.26 A comparison of the laser-induced R2PI spectrum of counter gas doped with a trace of phenol (B) and the single-photon UV absorption spectrum of phenol [TOW 86]

1.3.4 Laser-Beam Optics

A beam of laser light that is to create ionization as if from a particle must have an approximately constant cross-sectional area along the beam. Relations (1.75) and (1.76) imply that, for example, in two-photon ionization a light pulse with a given energy produces half as many ions per unit track length when it has twice the cross-sectional area. In the interest of a constant high yield and of a narrow deposit of ionization, one would like to have the beam width as small as possible over the largest possible track length.

The photons in a beam occupy a volume in the four-dimensional phase space at each point along the beam. For illustration, we consider the horizontal plane in Fig. 1.27, where an almost parallel beam is shown to be focused into a narrow waist by a lens. After the focus, the beam opens up again. Each photon trajectory is represented by a point in the phase-space diagrams below where the distance from the axis is plotted against the small angle of the trajectory with the axis. Here we deal with geometrical optics only; the wave optical aspects are treated later. In this sense we may regard the optical elements of the beam (lenses, mirrors, light guides, free space, apertures) as determining a trajectory for each photon in a timeindependent fashion. Now, Liouville's theorem in statistical mechanics states that in such a passive system the density of photons in phase space is a constant of motion, meaning that it does not change along the beam. As long as there are no photons lost, the occupied volume of cross-sectional area times solid angle is the same everywhere along the beam and the same as just behind the laser. In the phasespace diagrams of Fig. 1.27 the envelopes containing the beam do not change their area. A concentration of the beam in space by a focusing lens is accompanied by a corresponding extension of the solid angle.



Fig. 1.27 Phase-space diagrams at three points along a light-beam, which is almost parallel at the left and is focussed into B by a lens at A

There is a principal limit of the size, in phase space, of a photon beam. Heisenberg's uncertainty principle of quantum mechanics states that, in each of the two transverse dimensions separately, the limits are given by

$$\Delta x \Delta p_x > h/4\pi, \tag{1.95}$$

where Δx and Δp_x are the root mean square widths in space and in momentum [MES 59] and *h* is Planck's constant. Since the r.m.s. opening angle is

$$\Delta \alpha = \Delta p_x / p = \Delta p_x \lambda / h \ll 1,$$

we have

$$\Delta x \Delta \alpha > \lambda / 4\pi. \tag{1.96}$$

An example not very far from the principal limit is provided by the situation where a plane light-wave is delimited by an aperture, say a slit of width $\pm A$. The diffraction caused by the slit will open the range of the angles β of propagation behind the slit so that approximately

$$|\pm\beta| \approx \frac{1}{A} \frac{\lambda}{2\pi}.$$
(1.97)

Many lasers can be tuned to emit beams near the fundamental limit. If their wavelength is subsequently halved by a frequency doubler, the limit refers to the old wavelength unless the phase space and, inevitably, the power of the beam are reduced afterwards.

For practical purposes we work with approximate full widths W_x and W_α , ignoring the exact distribution of intensity across the beam, and use the order-of-magnitude relation

$$W_x W_\alpha > \lambda. \tag{1.98}$$

The highest spatial concentration of light is reached in a beam focus; let it have a width W_x . Ideally, the arrival angles of the photons do not depend on the point across the focus; let the angular width be W_{α} . At a distance *D* behind the focus, every such point has reached a width αD . The statistical ensemble of all the photons has a combined width of W_{tot} given by

$$W_{\rm tot}^2 = W_x^2 + (W_\alpha D)^2.$$
(1.99)

The quadratic addition of these two widths is correct in the approximation that the light intensity in the focus is a Gaussian function of both the space and the angular coordinates. For most applications this is not far from reality.

Applying (1.98) and (1.99), the total width of a focused beam, at a distance D away from the focus, is not smaller than

$$W_{\text{tot}}^{\min} = \left[W_x^2 + \left(\frac{\lambda D}{W_x}\right)^2 \right]^{1/2}.$$
 (1.100)

This is plotted in Fig. 1.28 as a function of D for various values of W_x .



The technique of *light-tracks* simulating particle tracks is particularly well suited for the calibration of coordinate measurements based on the pulse heights of cathode strips, because they find the centre of the track. The one to several mm wide profile of the light-beam is usually not well known, whereas the position of the centre is much better defined. The calibration of coordinates based on drift time measurements requires the profile to be known. First studies of the profile of light-tracks with the aim of improving the drift-coordinate calibration were performed by Fabretti et al. [FAB 90].

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Chapter 2 The Drift of Electrons and Ions in Gases

The behaviour of the drift chamber is crucially dependent on the drift of the electrons and ions that are created by the particles measured or in the avalanches at the electrodes. In addition to the electric drift field, there is often a magnetic field, which is necessary for measuring particle momentum. Obviously we have to understand how the drift velocity vector in electric and magnetic fields depends on the properties of the gas molecules, including their density and temperature. We might start by writing down the most general expression and then specialize to simple practical cases. However, it is more '*anschaulich*' to proceed in the opposite way. We derive the simple cases first and then generalize to the more rigorous formulation in Sect. 2.3.

2.1 An Equation of Motion with Friction

The motion of charged particles under the influence of electric and magnetic fields, E and B may be understood in terms of an equation of motion:

$$m\frac{\mathrm{d}\boldsymbol{u}}{\mathrm{d}t} = e\boldsymbol{E} + e[\boldsymbol{u} \times \boldsymbol{B}] - K\boldsymbol{u}, \qquad (2.1)$$

where *m* and *e* are the mass and electric charge of the particle, *u* is its velocity vector, and *K* describes a frictional force proportional to *u* that is caused by the interaction of the particle with the gas. In Sect. 2.2 we will see that in terms of the more detailed theory involving atomic collisions, (2.1) describes the drift at large *t* to a very good approximation. Historically, (2.1) was introduced by P. Langevin, who imagined the force *Ku* as a stochastic average over the random collisions of the drifting particle.

The ratio m/K has the dimension of a characteristic time, and we define

$$\tau = \frac{m}{K}.$$
 (2.2)

Equation (2.1) is an inhomogeneous system of linear differential equations for the three components of velocity.

The solution for $t \gg \tau$ of (2.1) is a steady state for which du/dt = 0. The drift velocity vector is determined by the linear equation

$$\frac{1}{\tau}\boldsymbol{u} - \frac{e}{m}[\boldsymbol{u} \times \boldsymbol{B}] = -\frac{e}{m}\boldsymbol{E}.$$
(2.3)

In order to solve for \boldsymbol{u} , we write $(e/m)B_x = \omega_x$ etc., $(e/m)E_x = \varepsilon_x$, etc., and express (2.3) in the form of the matrix equation

$$M\boldsymbol{u} = \boldsymbol{\varepsilon}, \\ M = \begin{bmatrix} 1/\tau & -\omega_z & \omega_y \\ \omega_z & 1/\tau & -\omega_x \\ -\omega_y & \omega_x & 1/\tau \end{bmatrix}.$$
(2.4)

The solution is obtained by inverting *M*:

$$\boldsymbol{u} = M^{-1}\boldsymbol{\varepsilon},$$

$$M^{-1} = \begin{bmatrix} 1 + \omega_x^2 \tau^2 & \omega_z \tau + \omega_x \omega_y \tau^2 & -\omega_y \tau + \omega_x \omega_z \tau^2 \\ -\omega_z \tau + \omega_x \omega_y \tau^2 & 1 + \omega_y^2 \tau^2 & \omega_x \tau + \omega_y \omega_z \tau^2 \\ \omega_y \tau + \omega_x \omega_z \tau^2 & -\omega_x \tau + \omega_y \omega_z \tau^2 & 1 + \omega_z^2 \tau^2 \end{bmatrix}$$

$$\times \frac{\tau}{1 + \omega^2 \tau^2},$$
(2.5)

where $\omega^2 = \omega_x^2 + \omega_y^2 + \omega_z^2 = (e/m)^2 B^2$ is the square of the cyclotron frequency of the electron. As we explain in Sect. 2.3, our solution (2.5) is equal to that obtained in the full microscopic theory in the approximation that τ is independent of the collision energy [see the discussion following (2.84)].

A different way of writing (2.5) is the following:

$$\boldsymbol{u} = \frac{e}{m}\tau|\boldsymbol{E}|\frac{1}{1+\omega^2\tau^2}(\hat{\boldsymbol{E}}+\omega\tau[\hat{\boldsymbol{E}}\times\hat{\boldsymbol{B}}]+\omega^2\tau^2(\hat{\boldsymbol{E}}\cdot\hat{\boldsymbol{B}})\hat{\boldsymbol{B}}).$$
(2.6)

Here \hat{E} and \hat{B} denote the unit vectors in the directions of the fields. The drift direction is governed by the dimensionless parameter $\omega \tau$, where ω is defined as (e/m)|B| and carries the sign of the charge of the moving particle.

For $\omega \tau = 0$, *u* is along *E*; in this case the relation has the simple form

$$u = \frac{e}{m} \tau E = \mu E,$$

$$\mu = \frac{e}{m} \tau.$$
(2.7)

These equations define the scalar mobility μ as the ratio of drift velocity to electric field in the absence of magnetic field; μ is proportional to the characteristic time τ defined in (2.2) and carries the charge sign of the particle.

In the presence of the magnetic field, the mobility is the tensor $(e/m)M^{-1}$ given in (2.5). For large positive values of $\omega \tau$ and e > 0, u generally tends to be along B; but if $\hat{E} \cdot \hat{B} = 0$, then large $\omega \tau$ turn u in the direction of $\hat{E} \times \hat{B}$, independently of

2.1 An Equation of Motion with Friction

the sign of *e*. Reversing the magnetic field direction causes the $\hat{E} \times \hat{B}$ component in (2.6) to change sign. Reversing the charge of the particle causes the \hat{E} and the $(\hat{E} \cdot \hat{B})\hat{B}$ components in (2.6) to change sign.

An illustration of the directional behaviour of u is presented in Fig. 2.1a, where the coordinate system is oriented so that the z axis is along \hat{B} , and \hat{E} is in the x-zplane. A positively charged particle starting at the origin will arrive on the plane z_0 at a point which belongs to a half circle over the diameter connecting the end-points of the \hat{B} and \hat{E} vectors in the z_0 plane. This is so because the components of u in these coordinates satisfy the relation

$$\left(\frac{u_x}{u_z} - \frac{1}{2}\frac{E_x}{E_z}\right)^2 + \left(\frac{u_y}{u_z}\right)^2 = \left(\frac{1}{2}\frac{E_x}{E_z}\right)^2$$

for any $\omega\tau$. The component in the direction of $\hat{E} \times \hat{B}$ is largest for $\omega\tau = 1$. In practice one studies primarily the drift of electrons; their negative electric charge causes a drift behaviour with respect to the *E* and *B* fields, which is illustrated in Fig. 2.1b [DYD 04].

Both the direction and the magnitude of u are influenced by the magnetic field. If we distinguish $u(\omega)$, the drift velocity in the presence of B, and u(0), the drift velocity at B = 0 under otherwise identical circumstances, using (2.6) we derive

$$\frac{u^2(\omega)}{u^2(0)} = \frac{1 + \omega^2 \tau^2 \cos^2 \phi}{1 + \omega^2 \tau^2},$$
(2.8)

where ϕ is the angle between E and B. This ratio happens to be the same as the one by which the component of u along E, u_E , changes with B:



Fig. 2.1 Directional behaviour of the drift velocity of a particle in the presence of an electric and a magnetic field. Values of the parameter $\omega \tau$ are indicated along the half-circle on the z_0 plane: (a) case of positive electric charge of the particle; (b) case of negative charge

(2.9)

2.1.1 Case of E Nearly Parallel to B

Two cases are of special interest. The first applies to the situation where a magnetic field is almost parallel to the electric field. Using (2.6) with $E = (0, 0, E_z), B = (B_x, B_y, B_z)$, and $|B_x|, |B_y| \ll |B_z|$, we express the drift directions in first order by

$$\frac{u_x}{u_z} = \frac{-\omega\tau B_y + \omega^2\tau^2 B_x}{(1+\omega^2\tau^2)B_z},$$

$$\frac{u_y}{u_z} = \frac{\omega\tau B_x + \omega^2\tau^2 B_y}{(1+\omega^2\tau^2)B_z}.$$
(2.10)

Here the terms proportional to $\omega \tau / (1 + \omega^2 \tau^2)$ change sign under a reversal of **B** [go back to (2.6) in order to see this]. Equations (2.10) will be used in Sect. 2.4.4 for the analysis of track distortions.

2.1.2 Case of E Orthogonal to B

The second case of interest applies to the situation where \boldsymbol{E} is at right angles to \boldsymbol{B} . Using (2.6) with $(\hat{\boldsymbol{E}} \cdot \hat{\boldsymbol{B}}) = 0$, $\boldsymbol{E} = (E_x, 0, 0)$, and $\boldsymbol{B} = (0, 0, B_z)$, we have

$$u_{x} = \frac{(e/m)\tau}{1+\omega^{2}\tau^{2}}|\boldsymbol{E}|,$$

$$u_{y} = -\frac{(e/m)\tau}{1+\omega^{2}\tau^{2}}\omega\tau|\boldsymbol{E}|,$$

$$u_{z} = 0,$$

$$\tan \Psi \equiv \frac{u_{y}}{u_{x}} = -\omega\tau.$$

(2.11)

From (2.11) we deduce the following for the magnitude of u:

$$|\boldsymbol{u}| = \frac{(e/m)\tau}{\sqrt{1+\omega^2\tau^2}}|\boldsymbol{E}| = \frac{e}{m}\tau|\boldsymbol{E}|\cos\psi.$$
(2.12)

The product $|\mathbf{E}| \cos \psi$ represents the component of the electric field in the drift direction. Compared with the magnetic-field-free case (2.7), we may write the functional dependence on $|\mathbf{E}|$ and $|\mathbf{B}|$ in the following form:

$$|u| = F(E,B) = F(E\cos\psi, 0),$$
 (2.13)

which is also known as Tonks' theorem [TON 55].

The expression has a simple meaning: regardless of the drift direction of the electron, the component of the electric field along this direction determines the drift velocity for every magnetic field. The derivation of (2.13) is based on a constant value of τ and is experimentally verified to good precision (see Fig. 2.26). This is discussed in more detail in Sects. 2.2.3 and 2.4.6.

2.2 The Microscopic Picture

On the microscopic scale, the electrons or ions that drift through the gas are scattered on the gas molecules so that their direction of motion is randomized in each collision. On average, they assume a constant drift velocity u in the direction of the electric field E (or, if a magnetic field is also present, in the direction which is given by both fields). The drift velocity u is much smaller than the instantaneous velocity c between collisions.

The gases we deal with are sufficiently rarefied that the distances travelled by electrons between collisions are large in comparison with their Compton wavelengths. So our picture is classical and atomistic. For gas pressures above, say, 100 atm, slow-drifting electrons interact with several atoms simultaneously and require a quantum mechanical treatment [BRA 81, ATR 77].

In order to understand the drift mechanism, we derive some basic relations between the macroscopic quantities of drift velocity u and isotropic diffusion coefficient D on the one hand and the microscopic quantities of electron velocity c, mean time τ between collisions, and fractional energy loss λ on the other. The microscopic quantities are randomly distributed according to distribution functions treated in Sect. 2.3; in this section we deal with suitable averages. The relevant relations can be expected to be correct within factors of the order of unity.

2.2.1 Drift of Electrons

Let us consider an electron between two collisions. Because of its light mass, the electron scatters isotropically and, immediately after the collision, it has forgotten any preferential direction. Some short time later, in addition to its instantaneous and randomly oriented velocity c, the electron has picked up the extra velocity u equal to its acceleration along the field, multiplied by the average time that has elapsed since the last collision:

$$u = \frac{eE}{m}\tau.$$
 (2.14)

This extra velocity appears macroscopically as the drift velocity. In the next encounter, the extra energy, on the average, is lost in the collision through recoil or excitation. Therefore there is a balance between the energy picked up and the collision losses. On a drift distance *x*, the number of encounters is $n = (x/u)(1/\tau)$, the time of the drift divided by the average time τ between collisions. If λ denotes the average fractional energy loss per collision, the energy balance is the following:

$$\frac{x}{u\tau}\lambda\varepsilon_E = eEx. \tag{2.15}$$

Here the equilibrium energy ε_E carries an index *E* because it does not contain the part due to the thermal motion of the gas molecules, but only the part taken out of the electric field.

One may wonder about the fact that the average time between collisions is the same as the average time that has elapsed since the last collision. This is because in a completely random series of encounters, characterized only by the average rate $1/\tau$, the differential probability f(t)dt that the next encounter is a time between t and t + dt away from any given point t = 0 in time is

$$f(t)\mathrm{d}t = \frac{1}{\tau}\mathrm{e}^{-t/\tau}\mathrm{d}t,\qquad(2.16)$$

independent of the point where the time measurement begins.

Equation (2.14), as compared with (2.7), provides an interpretation and a justification of the constant τ introduced in Sect. 2.1. In the frictional-motion picture, τ was the ratio of the mass of the drifting particle over the coefficient of friction. In the microscopic picture, τ is the mean time between the collisions of the drifting particle with the atoms of the gas. For drifting particles with instantaneous velocity c, the mean time τ between collisions may be expressed in terms of the cross-section σ and the number density N:

$$\frac{1}{\tau} = N\sigma c. \tag{2.17}$$

Here c is related to the total energy of the drifting electron by

$$\frac{1}{2}mc^2 = \varepsilon = \varepsilon_E + \frac{3}{2}kT,$$
(2.18)

because the total energy is made up of two parts: the energy received from the electric field and the thermal energy that is appropriate for 3 degrees of freedom (k = Boltzmann's constant, T = gas temperature).

For electron drift in particle detectors, we usually have $\varepsilon_E \gg (3/2)kT$; we can neglect the thermal motion, and (2.14), (2.15), and (2.18) combine to give the two equilibrium velocities as follows:

$$u^2 = \frac{eE}{mN\sigma}\sqrt{\frac{\lambda}{2}},\tag{2.19}$$

$$c^2 = \frac{eE}{mN\sigma}\sqrt{\frac{2}{\lambda}},\tag{2.20}$$

where $\varepsilon = (1/2)mc^2 \simeq \varepsilon_E \gg (3/2)kT$.

Both σ and λ are functions of ε . (We are confident that the fractional energy loss per collision, λ , Eq. 2.15, will not be confused with a mean free path or a wavelength which are traditionally also called λ). One notices the important role played by the energy loss in the collisions: with vanishing λ , the drift velocity would become zero. If ε is below the excitation levels of the gas molecules, the scattering is elastic and λ is approximately equal to twice the mass ratio of the collision partners (see Sect. 2.2.2); hence it is of the order of 10^{-4} for electrons.

As an illustration, we show in Fig. 2.2a the behaviour of the effective crosssections for argon and methane, two typical counter gases used in drift chambers.

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Fig. 2.2 (a) Effective ('momentum transfer') crosssection $\sigma(\varepsilon)$ for argon and methane. (b) Fraction $\lambda(\varepsilon)$ of energy loss per collision for argon and methane. Results of B. Schmidt [SCH 86]; see Sect. 2.4.1



The method of determining them will be discussed in Sect. 2.4. In both cases we observe a clear dip near $\varepsilon \simeq 0.25 \,\text{eV}$ or $\varepsilon \simeq 0.30 \,\text{eV}$. This is the famous Ramsauer minimum [RAM 21] which is due to quantum mechanical processes in the scattering of the electron with the gas molecule [ALL 31]. The noble gases krypton and xenon show the same behaviour but helium and neon do not. For a more detailed discussion on the scattering of electrons on molecules the reader is referred to [BRO 66].

The behaviour of $\lambda(\varepsilon)$ for argon and methane is seen in Fig. 2.2b. The threshold for excitation of the argon atom is at 11.5 eV, that for the methane molecule is at 0.03 eV. Under these circumstances it is not surprising that the drift velocity for electrons depends critically on the exact gas composition. Owing to the very different behaviour of the energy loss in molecular gases with respect to noble gases, even small additions (10^{-2}) of molecular gases to a noble gas dramatically change the fractional energy loss λ (cf. Fig. 2.2b), by absorbing collision energy in the rotational states. This change of λ results in an increase of the electron drift velocity by large factors, since the fraction of drifting electrons with energy close to that of the Ramsauer minimum increases and the average σ decreases. Also the functional dependence u(E) is changed. We note that the dependence of the drift velocity and the electron energy on E and N is always through the ratio E/N. This implies that in two gases operated with different gas pressures and identical temperature, the E fields must be adjusted in proportion to the gas pressures in order to obtain identical u and ε in both gases. Reduced fields are given in units of V cm⁻¹ Torr⁻¹. A special unit has also been coined: one Townsend (1 Td) is 10^{-17} V cm².

In a gas mixture composed of two or more components *i* with number densities n_i , the effective cross-section $\sigma(\varepsilon)$ and the effective fractional energy loss per collision $\lambda(\varepsilon)$ have to be calculated from the properties of the individual components:

$$\sigma(\varepsilon) = \sum n_i \sigma_i(\varepsilon) / N,$$

$$\lambda(\varepsilon)\sigma(\varepsilon) = \sum n_i \lambda_i(\varepsilon) \sigma_i(\varepsilon) / N,$$

$$N = \sum n_i.$$
(2.21)

The general behaviour of electron drift velocities is that they rise with increasing electric field, then level off or decrease as a result of the combined effects of $\sigma(\varepsilon)$ and $\lambda(\varepsilon)$ as ε increases with increasing *E*. Examples will be presented in Sect. 2.4 and in Chap. 12.

2.2.2 Drift of Ions

The behaviour of ions differs from that of electrons because of their much larger mass and their chemical reactions. The monograph by McDaniel and Mason [MCD 73] deals with the mobility and diffusion of ions in gases in a comprehensive way. Electrons in an electric field are accelerated more rapidly than ions, and they lose very little energy when colliding elastically with the gas atoms. The electron momentum is randomized in the collisions and is therefore lost, on the average. In electric field strengths that are typical for drift chambers, the electrons reach random energies far in excess of the energy of the thermal motion, and quite often they surpass the threshold of inelastic excitation of molecules in the gas. In this case their mobility becomes a function of the energy loss that is associated with such excitation.

Ions in similar fields acquire, on one mean-free path, an amount of energy that is similar to that acquired by electrons. But a good fraction of this energy is lost in the next collision, and the ion momentum is not randomized as much. Therefore, far less field energy is stored in random motion. As a consequence, the random energy of ions is mostly thermal, and only a small fraction is due to the field. The effect on the diffusion of ions results in this diffusion being orders of magnitude smaller than that of electrons in similar fields. The effect on the mobility is also quite interesting: since the energy scale, over which collision cross-sections vary significantly, is easily covered by the electron random energies reached under various operating conditions, we find rapid and sometimes complicated dependences of electron mobility on such operating conditions – electric and magnetic field strengths and gas composition being examples. In contrast, the mobility of ions does not vary as much.
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In order to understand the randomization in more quantitative terms, we consider the elastic scattering of an ion (or electron) with a molecule of the gas, neglecting the thermal motion.

Elastic Scattering and the Average Losses of Energy and Momentum. We consider the scattering of two particles with masses *m* and *M* in their centre-of-mass (c.m.) system in which the incoming momenta are equal and opposite and are denoted by *p*. In the laboratory frame, *M* was initially at rest, and the incoming particle had momentum *P* (see Fig. 2.3). The two frames are transformed into each other by the velocity v = P/(M+m).

For elastic scattering, we have $|\mathbf{p}'| = |\mathbf{p}| = M|\mathbf{v}| = p$. The loss of momentum of particle *M* along its direction of motion is, in the c.m. system, equal to

$$p(1-\cos\theta),$$

and invariant under the Galilean transformation. At our low momenta the scattering is isotropic, and after averaging over the angles we find the average fractional momentum loss κ :

$$\kappa = \frac{p}{P} = \frac{M}{M+m}.$$
(2.22)

Similarly, the square of the momentum transfer – equally invariant – is

$$(\boldsymbol{p}-\boldsymbol{p}')^2 = 2p^2(1-\cos\theta).$$

It is equal to the square of the laboratory momentum of the particle initially at rest; therefore its kinetic energy is $E'_{kin} = p^2(1 - \cos\theta)/M$. After averaging over the angles, the fractional energy loss λ is the ratio of this kinetic energy to that of the other (incoming) particle in the laboratory system:

$$\lambda = \frac{p^2}{M} \frac{2m}{P^2} = \frac{2mM}{(M+m)^2}.$$
(2.23)

We are now in a position to go through the arguments of Sect. 2.2.1 again, applying them to ions.

Expressions for the Mobility of Ions. Let us consider an ion between two collisions. Because of its heavy mass it does not scatter isotropically. Immediately after the collision, superimposed over the random velocity c_r there is a component c_d in the drift direction. Some short time later, it has, in addition, picked up the extra velocity



Fig. 2.3 Momentum diagrams for the collision of the drifting particle (mass m) with a gas molecule (mass M) in the centre of mass and in the rest frame of the molecule

v equal to the acceleration of the ion along the field, multiplied by the average time that has elapsed since the last collision. The drift velocity is the sum of v and c_d :

$$\boldsymbol{u} = \boldsymbol{v} + \boldsymbol{c}_{\mathrm{d}} = \frac{e\boldsymbol{E}}{m}\boldsymbol{\tau} + \boldsymbol{c}_{\mathrm{d}}.$$
(2.24)

The value of c_d is given by the average momentum loss in the direction of the drift that takes place in the next encounter; it must be equal to the momentum mv picked up between the encounters:

$$\kappa m \langle \boldsymbol{c}_{\mathrm{r}} + \boldsymbol{c}_{\mathrm{d}} + \boldsymbol{v} \rangle = \kappa m (\boldsymbol{c}_{\mathrm{d}} + \boldsymbol{v}) = m \boldsymbol{v}, \qquad (2.25)$$

where the brackets $\langle \rangle$ denote the average over the angles. For the magnitude of c_d we calculate $c_d = v(1 - \kappa)/\kappa$, and for the drift velocity (using (2.22)),

$$u = v + c_{\rm d} = \frac{v}{\kappa} = \frac{e}{m} E \tau \frac{1}{\kappa} = \frac{e}{m} E \tau \left(1 + \frac{m}{M}\right). \tag{2.26}$$

Here τ is given by the relative velocity c_{rel} between the ion and the gas molecule, the cross-section σ , and the number density N as

$$\frac{1}{\tau} = N\sigma c_{\rm rel}.\tag{2.27}$$

We now distinguish two limiting cases of field strength *E*. If it is low so that the ion random velocity is thermal, we must take for the relative velocity the average magnitude of the difference between the two randomly distributed velocities of the ion (c_{ion}) and the gas atoms (c_{gas}) :

$$c_{\rm rel} = \langle |\boldsymbol{c}_{\rm ion} - \boldsymbol{c}_{\rm gas}| \rangle = (c_{\rm ions}^2 + c_{\rm gas}^2)^{1/2}.$$
 (2.28)

With equipartition of energy, we can express c_{rel} through the temperature T and Boltzmann's constant k:

$$c_{\rm rel}^2 = c_{\rm ion}^2 + c_{\rm gas}^2 = 3kT\left(\frac{1}{m} + \frac{1}{M}\right).$$
 (2.29)

Using (2.26, 2.27), and (2.29), we obtain

$$u = \left(\frac{1}{m} + \frac{1}{M}\right)^{1/2} \left(\frac{1}{3kT}\right)^{1/2} \frac{eE}{N\sigma} (\text{low } E).$$
(2.30)

It is characteristic of the drift velocity at low fields that it is proportional to E, or that the mobility is independent of E.

For the case of large *E*, where we can neglect the thermal motion, we proceed as in the case of electrons (where the temperature was always neglected). By combining (2.15, 2.17, 2.24), and (2.26), we solve for u^2 and c^2 and obtain the symmetric forms

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$$u^{2} = \frac{eE}{m^{*}N\sigma} \left(\frac{\lambda}{2}\frac{m}{m^{*}}\right)^{1/2}$$
(2.31)

and

$$c^{2} = \frac{eE}{m^{*}N\sigma} \left(\frac{2}{\lambda}\frac{m}{m^{*}}\right)^{1/2},$$
(2.32)

where the 'reduced mass' m^* between the ion (m) and the gas molecule (M) is defined as

$$\frac{1}{m^*} = \frac{1}{m} + \frac{1}{M}.$$
(2.33)

Using (2.23), we may express λ for elastic scattering through the ratio of the masses, with the result that

$$u = \left[\frac{eE}{mN\sigma}\right]^{1/2} \left[\frac{m}{M}\left(1+\frac{m}{M}\right)\right]^{1/2} (\text{high } E).$$
(2.34)

It is characteristic of the drift velocity at high fields and constant cross-section σ that it is proportional to the square root of *E*, or the mobility decreases as $1/\sqrt{E}$.

The distinction between 'high' and 'low' E in (2.30) and (2.34) is obviously with respect to the field in which the ion, over one mean free path, picks up an amount of energy equal to the thermal energy. The measured ion drift velocities for noble gases shown in Fig. 2.4 exhibit very well the limit in behaviour of (2.30) and (2.34) with the electric field.

Table 2.1 contains ion mobilities for low fields that were measured in the noble gases. Various approximation methods for the calculation of cross-sections in the scattering of ions on molecules have been treated elsewhere [MCD 73]. When ions travel in their parent gas, the original collision cross-section is increased by about a factor of two by the mechanism of resonant charge transfer.

Ion Drift in Gas Mixtures. The gas of a drift chamber is often a composition of two or more constituents. Ion drift in gas mixtures can be understood along the lines of the last subsection. We want to modify (2.26) for the case where one type of ion (mass *m*) moves between the atoms or molecules with masses $M_k(k = 1, 2, ...)$ each present in the gas with its own number density N_k . The gas number density *N* is equal to the sum over all the N_k . The resulting drift velocity in the field *E* is called \bar{u} ; it is equal to

$$\bar{u} = -\frac{e}{m} E \bar{\tau} \frac{1}{\bar{\kappa}}.$$
(2.35)

Here $\bar{\tau}$ is the mean time between collisions, and $\bar{\kappa}$ is the mean fractional momentum loss in the mixture; they are both quickly calculated from the τ_k and κ_k that belong to each constituent. The overall collision rate is the sum of the individual collision rates, or

$$1/\bar{\tau} = \sum (1/\tau_k). \tag{2.36}$$

The overall momentum loss is the average over all the κ_k , weighted with the relative rates with which each type of molecule is bombarded:



Fig. 2.4 Drift velocity *u* of positive noble gas ions in their own gas as functions of the reduced electric field. The limiting behaviour at low fields $(u \propto E)$ and at high fields $(u \propto \sqrt{E})$ is visible [LAN 57]

$$\bar{\kappa} = \frac{\sum(\kappa_k/\tau_k)}{\sum(1/\tau_k)}.$$
(2.37)

Combining (2.35) to (2.37), we obtain

$$\bar{u} = \frac{e}{m} E \frac{1}{\sum (\kappa_k / \tau_k)}.$$
(2.38)

Table 2.1 Experimental low-field mobilities of various noble gas ions in their parent gas [MCD 73]

Gas	Ion	$\begin{array}{c} \text{Mobility} \\ (\text{cm}^2 \text{V}^{-1} \text{s}^{-1}) \end{array}$
He	He ⁺	10.40 ± 0.10
Ne	Ne ⁺	4.14 ± 0.2^{a}
Ar	Ar^+	1.535 ± 0.007
Kr	Kr^+	0.96 ± 0.09
Xe	Xe^+	0.57 ± 0.05

^a Average over several measurements

This equation can be cast into a form that is known as *Blanc's law* if we denote by u_k the drift velocity of the ion in the pure component k at the full density N:

$$u_k = \frac{e}{m} E \frac{\tau_k}{\kappa_k} \frac{N_k}{N},\tag{2.39}$$

where we have used (2.17). Expressions (2.38) and (2.39) give us Blanc's law:

$$\frac{1}{\bar{u}} = \sum \frac{N_k}{N} \frac{1}{u_k};\tag{2.40}$$

it states that the inverse drift velocities in the individual gas components add in proportion to the relative component densities to yield the inverse drift velocity of the mixture.

Blanc's law holds for the case of low electric fields. The case of high fields is slightly more complicated because the energy partition of the drifting ion into random and directed motion must be taken into account. The reader is referred to the monograph of McDaniel and Mason [MCD 73].

In practice, (2.40) is quite well fulfilled. In Fig. 2.5 we show mobilities, measured by the Charpak group [SCH 77], as functions of the relative gas concentration for several binary mixtures of argon with the common quench gases: isobutane, methane, and carbon dioxide.





The production of positive ions in molecular gases is a fairly complex phenomenon, and without a clear identification – perhaps using a mass spectrometer – one is usually ignorant of the identity of the migrating charged bodies. For the purposes of drift chambers it often suffices to know their drift velocities. However, the chemical deposits on the wire electrodes, as a result of chamber operation, can be evaluated with more complete knowledge about which ions really migrate toward the cathodes.

One must read Table 2.2, which contains measured ion mobilities, with these remarks in mind. For example, the notation $([OCH_3)_2CH_2]^+$, means the ion(s) travelling towards the cathode in a mixture of argon + methylal. It is assumed here that the argon ions that are created simultaneously transfer their charge to the methylal molecules, thus creating more $([OCH_3)_2CH_2]^+$, ions. This is elaborated below.

Charge Transfer. When the migrating ions in a drift chamber collide with molecules that have an ionization potential smaller than the energy available in the ion, there is the possibility that a charge-exchange process takes place, which neutralizes the ion and creates a new ion. This process happens with cross-sections that are of a similar order of magnitude to the other ion–molecule scattering cross-sections. Therefore the rate of ion transformation through charge transfer is correspondingly high and proportional to the concentration of the molecules to be ionized.

The Charpak group have found that 1% of methylal added to binary argon + isobutane mixtures made a significant change in the ion mobility over 2 cm of drift in their field (a few hundred to a thousand V/cm). This has to be interpreted as a charge transfer process from the ions in the original mixture to the methylal molecules, thus creating ' $[(OCH_3)_2CH_2]$ +' ions with lesser mobility. Their result [SCH 77] is presented in Fig. 2.6, where the inverse measured mobility is plotted against the density of the various binary and ternary mixtures. Straight lines correspond to Blanc's law; they connect mixtures in which the migrating ion(s) is (are) supposedly the same. We must therefore imagine the motion of ions in drift chambers as a dynamic process in which the various ionic species, which were originally produced in the avalanches or any other collision process, disappear quickly and leave only the one type that has the lowest ionization potential.

Ion notation	Gas	$\begin{array}{c} \text{Mobility} \\ (\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}) \end{array}$
[CH ₄] ⁺	Ar	1.87
$[CO_2]^+$	Ar	1.72
$[IsoC_4H_{10}]^+$	Ar	1.56
$[(OCH_3)_2CH_2]^+$	Ar	1.51
[CH ₄] ⁺	CH_4	2.26
$[CO_2]^+$	CO_2	1.09
$[IsoC_4H_{10}]^+$	IsoC ₄ H ₁₀	0.61
$[(OCH_3)_2CH_2]^+$	$IsoC_4H_{10}$	0.55
$[(OCH_3)_2CH_2]^+$	$(OCH_3)_2CH_2$	0.26

Table 2.2 Measured mobilities of various ions in some gases used in drift chambers [SCH 77]



Fig. 2.6 Inverse mobility of ions in binary and ternary gas mixture composed of argon–isobutane–methylal, measured by [SCH 77] and plotted as a function of the gas density. A: argon–methylal; B to E: argon–isobutane–methylal, with argon in different proportions (B: 80%, C: 70%, D: 60%, and E: 50%) F: argon–isobutane. The numbers close to the experimental points represent the percentage concentration of methylal (A to E) or isobutane (F), respectively

Practical drift chamber gases – apart from the principal components that were intentionally mixed together by the experimenter – always contain some impurities; they are difficult to control below the level of 10^{-4} . The mere fact that pulsed lasers of modest energy are capable of producing ionization in 'clean' gas (see Sect. 1.3 for details) is proof of the presence of impurities with low ionization potentials. It would obviously be interesting to know the identity of migrating ions at the end of the 2-m-long drift space of a large time projection chamber (TPC).

2.2.3 Inclusion of Magnetic Field

When we consider the influence of a magnetic field on drifting electrons and ions, the first indication may be provided by the value of the mobility μ of these charges. In particle chamber conditions, this is of the order of magnitude of $\mu \simeq 10^4 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ for electrons (see Fig. 2.17 and use (2.7)), whereas for ions the order of magnitude is $\mu = 1 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ (see Tables 2.1 and 2.2). Typical magnetic fields *B* available to particle experimenters are limited, so far, by the magnetic susceptibility of iron, and the order of magnitude is 1 T or $10^{-4} \text{ V} \text{ s cm}^{-2}$. We know from Sect. 2.1 that it is the numerical value of $\omega \tau = (e/m)B\tau$ that governs the effects of the magnetic field on the drift velocity vector. Using (2.7), which stated that $\mu = (e/m)\tau$, we find

$$\omega \tau = B\mu \simeq \begin{cases} 10^{-4} & \text{for ions} \\ 1 & \text{for electrons} \end{cases}$$

in order of magnitude. Therefore, the effect of such magnetic fields on ion drift is negligible, and we concentrate on electrons. This has the advantage that we may assume that the colliding body scatters isotropically in all directions, owing to its small mass.

When the magnetic field is added to the considerations of Sect. 2.2.1, we can describe the most general case in a coordinate system in which *B* is along *z*, and *E* has components E_z and E_x . An electron between collisions moves according to the equation of motion,

$$m\frac{\mathrm{d}\boldsymbol{v}}{\mathrm{d}t} = e\boldsymbol{E} + e[\boldsymbol{v} \times \boldsymbol{B}], \qquad (2.41)$$

which in our case is written as

$$\dot{v}_x = \varepsilon_x + \omega v_y,
\dot{v}_y = -\omega v_x,
\dot{v}_z = \varepsilon_z,$$
(2.42)

where $\omega \equiv (e/m)B$ and $\varepsilon \equiv (e/m)E$. Electrons have their direction of motion randomized in each collision, and we are interested in the extra velocity picked up by the electron since the last collision. Hence we look for the solution of (2.42) with $\boldsymbol{v} = 0$ at t = 0. It is given by

$$v_x(t) = (\varepsilon_x/\omega)\sin \omega t,$$

$$v_y(t) = (\varepsilon_x/\omega)(\cos \omega t - 1),$$

$$v_x(t) = \varepsilon_z t.$$

(2.43)

Before we can identify v with the drift velocity, we must average over t, using (2.16), the probability distribution of t. This was also done when deriving (2.14), which, being a linear function of time, required t to be replaced by τ , the mean time since the last collision. The drift velocity for the present case is given by

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$$u_{x} = \langle v_{x}(t) \rangle = \frac{\varepsilon_{x}}{\omega} \int_{0}^{\infty} \frac{1}{\tau} e^{-t/\tau} \sin \omega t \, dt = \frac{\varepsilon_{x}\tau}{1+\omega^{2}\tau^{2}},$$

$$u_{y} = \langle v_{y}(t) \rangle = \frac{\varepsilon_{x}}{\omega} \int_{0}^{\infty} \frac{1}{\tau} e^{-t/\tau} (\cos \omega t - 1) dt = \frac{-\varepsilon_{x}\omega\tau^{2}}{1+\omega^{2}\tau^{2}},$$

$$u_{z} = \langle v_{z}(t) \rangle = \varepsilon_{z} \int_{0}^{\infty} \frac{1}{\tau} e^{-t/\tau} dt = \varepsilon_{z}\tau.$$

(2.44)

We immediately recognize that the result is the same as for (2.5) and (2.6), derived from the macroscopic equation of motion using the concept of friction. The mobility tensor (2.5) is therefore the same in the macroscopic and the microscopic picture. It will only have to be modified in Sect. 2.3, where the electron velocity has a probability distribution over a range of values, rather than a single value.

We can now state the condition of energy balance in the presence of a magnetic field. If the angle between the two fields is ϕ , the energy transferred to the electron per unit distance along E, equal to the corresponding collision loss, is

$$eE = \frac{1}{2} \frac{\lambda mc^2}{u_E(\omega)\tau} = \frac{1}{2} \frac{\lambda m^2 c^2 (1 + \omega^2 \tau^2)}{eE \tau^2 (1 + \omega^2 \tau^2 \cos^2 \phi)}.$$
 (2.45)

Here we have used (2.9). On the other hand, the square of the drift velocity was given by (2.7) and (2.8),

$$u^{2} = \left(\frac{e}{m}E\tau\right)^{2}\frac{1+\omega^{2}\tau^{2}\cos^{2}\phi}{1+\omega^{2}\tau^{2}}.$$
(2.46)

The two expressions (2.45) and (2.46) determine the two equilibrium velocities u and c. First we notice that the ratio

$$\frac{u^2}{c^2} = \frac{\lambda}{2} \tag{2.47}$$

is given by the fractional energy loss per collision alone; in particular, it is independent of both fields. In the situation without magnetic field, the two electron velocities were determined by the cross-section and the energy loss in (2.19) and (2.20). With magnetic field, the corresponding relations are more complicated owing to the presence of the terms proportional to $\omega^2 \tau^2 = \omega^2 / (N^2 \sigma^2 c^2)$. Whereas in the most general case (2.45) and (2.46) could be solved for c^2 by a graphical or numerical method, we present the closed solution for two important practical cases.

Case of E Parallel to B. The first case concerns the drift volume of the TPC; here we have $\cos^2 \phi = 1$ and therefore

$$c^2 \frac{eE}{mN\sigma} \sqrt{\frac{2}{\lambda}},\tag{2.48}$$

exactly as in the absence of magnetic field.

Case of E Orthogonal to B. The second case concerns the drift volume of the axial wire drift chamber, where $\cos^2 \phi = 0$; here

$$c^{2} = \left[\left(\frac{eE}{mN\sigma} \right)^{2} \frac{2}{\lambda} + \left(\frac{\omega^{2}}{2N^{2}\sigma^{2}} \right)^{2} \right]^{1/2} - \left[\frac{\omega^{2}}{2N^{2}\sigma^{2}} \right].$$
(2.49)

We note that the random velocity c is reduced in the presence of a magnetic field orthogonal to E. The same is true for the drift velocity because of (2.47). Any two values of E and B that produce the same solution for c in (2.49) lead to the same drift velocity. In particular, if E_1 is the electric field that produces certain values of c and u in the absence of magnetic field ($B_1 = 0$), then there is a corresponding E_2 for the same values of c and u at some non-zero B_2 . In order to find an expression for E_2 in terms of E_1 and B_2 , we rewrite (2.49) for the two pairs of fields in the following form:

$$-\left(\frac{eE_1}{mN\sigma}\right)^2 \frac{2}{\lambda} + c^4 = 0,$$

$$\left(\frac{ecB_2}{mN\sigma}\right)^2 - \left(\frac{eE_2}{mN\sigma}\right)^2 \frac{2}{\lambda} + c^4 = 0.$$
(2.50)

Note that λ and σ are the same in both cases because they are functions of *c* alone. From (2.50) we deduce that

$$E_2^2 = E_1^2 \left[1 + \left(\frac{eB_2}{cmN\sigma} \right)^2 \right] = E_1^2 (1 + \omega_2^2 \tau^2), \qquad (2.51)$$

which is the microscopic justification for (2.12) and (2.13). One cannot understand (2.12) from a derivation using a constant friction term τ because τ does not remain constant when *E* is varied (see (2.7) and Fig. 2.17). Rather, as we have seen, τ also depends on *B* in such a way that it comes back to its old value for the appropriate combination of *B* and *E*.

Next, we wish to evaluate (2.49) for large values of the *B* field. In the limit $\omega \tau \gg 1$ the second term in the square root of (2.49) becomes much larger compared to the first term (using (2.46) and (2.47) it can be shown that the two terms are equal when $\omega \tau \simeq 2.2$), and we have to first order in $1/\omega \tau$

$$c^2 = \left(\frac{eE}{m\omega}\right)^2 \frac{2}{\lambda},\tag{2.52}$$

$$u^2 = \left(\frac{eE}{m\omega}\right)^2, \quad u = \frac{E}{B},$$
 (2.53)

which is remarkable because c no longer depends on σ .

Equation (2.53) has the following significance. In the presence of a magnetic field *B*, orthogonal to *E* and strong enough for $\omega \tau$ to be large, the drift velocity *u* approaches a universal value E/B, which is the same for all gases.

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In order to study the deviations from the universal expression (2.53), we may carry the expansion of the square root in (2.49) to the second order. Using (2.47) and (2.53) we find

$$u = \frac{E}{B} \left(1 - \frac{1}{\omega^2 \tau^2} \right) (\omega \tau \gg 1).$$
(2.54)

This means that the universal limit (2.53) is approached rapidly from below as *B* is increased.

This physical content of (2.53) can best be understood by comparison with the motion of an electron *in vacuo*: under the influence of crossed electric and magnetic fields, the electron is accelerated by the *E* field and bent by the *B* field; it performs a cycloidal motion in the plane orthogonal to *B* (see (2.43) and Fig. 2.7). When averaging over the periodic part, one finds that the electron drifts with the constant speed E/B in the direction of $-\hat{E} \times \hat{B}$. This motion *in vacuo* is the limit of the gas drift for large values of $\omega \tau$, the mean number of turns (expressed in radians) between collisions. Experimentally it can be reached either by increasing the *B* field or by reducing the gas density, which is roughly proportional to $1/\tau$.

2.2.4 Diffusion

As the drifting electrons or ions are scattered on the gas molecules, their drift velocity deviates from the average owing to the random nature of the collisions. In the simplest case the deviation is the same in all directions, and a point-like cloud of



Fig. 2.7 Motion of an electron *in vacuo* under the influence of orthogonal *E* and *B* fields: *B* goes out of the paper, the electron stays in the plane of the paper

electrons which then begins to drift at time t = 0 from the origin in the *z* direction will, after some time *t*, assume the following Gaussian density distribution:

$$n = \left(\frac{1}{\sqrt{4\pi Dt}}\right)^3 \exp\left(\frac{-r^2}{4Dt}\right),\tag{2.55}$$

where $r^2 = x^2 + y^2 + (z - ut)^2$; *D* is the diffusion constant because *n* satisfies the continuity equation for the conserved electron current Γ :

$$\boldsymbol{\Gamma} = n\boldsymbol{u} - D\boldsymbol{\nabla}n,\tag{2.56}$$

$$\frac{\partial n}{\partial t} + \boldsymbol{\nabla} \cdot \boldsymbol{\Gamma} = 0, \qquad (2.57)$$

$$\frac{\partial n}{\partial t} + n\boldsymbol{\nabla} \cdot \boldsymbol{u} - D\boldsymbol{\nabla}^2 n = 0.$$
(2.58)

The diffusion constant D, defined by (2.56), makes the mean squared deviation of the electrons equal to 2Dt in any one direction from their centre. (This is a special case of (2.75), which deals with the case of anisotropic diffusion.)

In order to express the diffusion constant in terms of the microscopic picture, we suppose that one electron or ion starts at time t = 0 and has a velocity c; hence, according to (2.16), there is probability distribution of free path l equal to

$$g(l)dl = \frac{1}{l_0} e^{-l/l_0} dl, \qquad (2.59)$$

where $l_0 = c\tau$ is the mean free path. The simplest case is the one where scattering is isotropic with respect to the drift direction. We consider this case first. It applies to ions at low electric fields $E(E/(N\sigma) \ll kT)$ and, to a good first approximation, to electrons.

Consider a time t at which a large number, n, of encounters have already occurred; then $n = t/\tau$. The mean square displacement in one direction, say x, is

$$\int \left(\sum_{1}^{n} l_{i} \cos \theta_{i}\right)^{2} \prod_{1}^{n} g(l_{k}) dl_{k} \frac{d \cos \theta_{k}}{2} = n \frac{2}{3} l_{0}^{2} = \frac{2}{3} \frac{l_{0}^{2}}{\tau} t.$$
(2.60)

Hence $l_i \cos \theta_i$ is the displacement along *x* between the (i-1)th and the *i*th collision (Fig. 2.8); the $\cos \theta_i$ are uniformly distributed between -1 and +1 according to our assumption. The l_i are distributed with the probability density (2.59). Note that the mixed terms in the sum vanish. The part proportional to 2t is the diffusion coefficient *D*,

$$D = \frac{l_0^2}{3\tau} = \frac{cl_0}{3} = \frac{c^2\tau}{3} = \frac{2}{3}\frac{\varepsilon}{m}\tau.$$
 (2.61)

Recalling the expression for the electron mobility μ ,

$$\mu = \frac{e}{m}\tau,$$

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Fig. 2.8 Electron paths for the derivation of (2.60)



we notice that the electron energy can be determined by a measurement of the ratio D/μ :

$$\varepsilon = \frac{3}{2} \frac{De}{\mu}.$$
(2.62)

When the diffusing body has thermal energy, $\varepsilon = (3/2)kT$, (2.62) takes the form

$$\frac{D}{\mu} = \frac{kT}{e}$$

which is known as the *Nernst–Townsend formula*, or the *Einstein formula*. (For historical references, see [HUX 74].)

The energy determines the diffusion width σ_x of an electron cloud which, after starting point-like, has travelled over a distance *L*:

$$\sigma_x^2 = 2Dt = \frac{2DL}{\mu E} = \frac{4\varepsilon L}{3eE}.$$
(2.63)

In drift chambers we therefore require small electron energies at high drift fields in order to have σ_x^2 as small as possible. In the literature one finds the concept of characteristic energy, ε_k , which is related to our ε by the relation $\varepsilon_k = (2/3)\varepsilon$.

In Fig. 2.9 we show the variation of ε_k with the electric field strength, measured with electrons drifting in the two gases, argon and carbon dioxide, which represent somewhat extreme cases concerning the change-over from thermal behaviour to field-dominated behaviour. In argon a field strength as low as 1 V/cm produces electron energies distinctly larger than thermal ('hot gas'). In carbon dioxide the same behaviour occurs only at field strengths above 2 kV/cm ('cold gas'). The reason is a large value of the relative energy loss λ in CO₂, due to the internal degrees of freedom of the CO₂ molecule, which are accessible at low collision energies.

Fig. 2.9 Characteristic energy of electrons in Ar and CO_2 as a function of the reduced electric field. The electric field under normal conditions is also indicated. The parameters refer to the different temperatures at which the measurements were made [SCH 76]



The fractional energy loss λ was introduced in Eq. 2.15 and played a decisive role throughout Sect. 2.2.

For ions and electrons with thermal energy $\varepsilon = (3/2)kT$, (2.63) shows that the diffusion width of a cloud is independent of the nature of the gas and is proportional to the square root of the absolute temperature: the 'thermal limit' is given by

$$\sigma_x = \left(\frac{2kTL}{eE}\right)^{1/2}.$$
(2.64)

2.2.5 Electric Anisotropy

Until 1967 it had always been assumed that the diffusion of drifting electrons in gases has the isotropic form implied by (2.55). But then Wagner et al. [WAG 67] discovered experimentally that the value of electron diffusion along the electric field can be quite different from that in the perpendicular direction. The diffusion of drifting ions is also often found to be non-isotropic.

When ions collide with the gas molecules, they retain their direction of motion to some extent because the masses of the two collision partners are similar, and therefore the instantaneous velocity has a preferential direction along the electric field (see Sect. 2.2.2). This causes the diffusion to be larger in the drift direction; the mechanism is at work for ions travelling in high electric fields $E(eE/(N\sigma) \ge kT)$, and we do not treat it here because it plays no role in the detection of particles.

In the case of electrons, there is almost no preferential direction for the instantaneous velocity. We will describe the electron diffusion anisotropy following the

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semiquantitative treatment of Partker and Lowke [PAR 69], which is restricted to energy loss by elastic collisions. The essential point of the argument is that the mobility of the electrons assumes different values in the leading edge and in the centre of the travelling cloud if the collision rate is a function of electron energy. This change of mobility inside the cloud is equivalent to a change of diffusion in the longitudinal direction.

We express the energy balance (2.15) in the drifting cloud more precisely by making use of the electron current introduced in (2.51); it now contains the diffusion term $D\nabla n$. Let the drift be in the *z* direction ($E = E\hat{z}$). Using the collision frequency $v \equiv 1/\tau$ instead of τ and dropping the index from ε , the energy balance takes the form

$$n\nu\lambda\varepsilon = e\mathbf{E}\cdot\boldsymbol{\Gamma} = e\mu E^2 n - eED\frac{\partial n}{\partial z},$$
(2.65)

where v, μ , λ and D are functions of ε . In principle, we can solve this equation for ε in terms of $(1/n)(\partial n/\partial z)$. Here we will put λ constant, as it is in the case of elastic scattering, and develop $v(\varepsilon)$ around the equilibrium point, which is given when $\partial n/\partial z = 0$:

$$\varepsilon_0 = \frac{1}{m\lambda} \left(\frac{eE}{v_0}\right)^2$$

The functions *D* and *m* are approximated by their expressions (2.61) and (2.62). Putting $\varepsilon = \varepsilon_0 + \Delta \varepsilon$ and $v = v_0 + (\partial v / \partial \varepsilon) \Delta \varepsilon$ in (2.65), the variation of energy inside the cloud can be expressed to first order as

$$\Delta \varepsilon = -\frac{2\varepsilon_0^2}{3eE[1+2(\partial \nu/\partial \varepsilon)_0(\varepsilon_0/\nu_0)]} \frac{1}{n} \frac{\partial n}{\partial z},$$
(2.66)

 $(\partial v/\partial \varepsilon)_0$ being the derivative of the collision frequency with respect to the energy, evaluated at ε_0 . Equation (2.66) shows that ε is larger in the leading edge of the cloud and smaller in the trailing edge, and from (2.62) it follows that – unless $(\partial v/\partial \varepsilon) = 0$ – the mobility μ also is a function of position in the cloud (see Fig. 2.10):

$$\mu = \mu_0 \left(rac{1}{v_0} rac{\partial v}{\partial arepsilon} \Delta arepsilon
ight).$$

We now rearrange the terms in the expression for the electron current and find

$$\boldsymbol{\Gamma} = \mu_0 E n \hat{\boldsymbol{z}} - D\left(\frac{\partial n}{\partial x} \hat{\boldsymbol{x}} + \frac{\partial n}{\partial y} \hat{\boldsymbol{y}}\right) - D\left(1 - \frac{\gamma}{1 + 2\gamma}\right) \frac{\partial n}{\partial z} \hat{\boldsymbol{z}},$$

where $\gamma \equiv (\varepsilon_0/v_0)(\partial v/\partial \varepsilon)$. Obviously the diffusion in the drift direction has changed and is no longer equal to the diffusion in the perpendicular direction. We distinguish the two diffusion coefficients by the indices L and T. The ratio is

$$\frac{D_{\rm L}}{D_{\rm T}} = \frac{1+\gamma}{1+2\gamma}.$$
 (2.67)

Fig. 2.10 Mobility variation inside an electron cloud travelling in the *z* direction



Instead of the density distribution (2.55) of the diffusing cloud of electrons, we have in the anisotropic case

$$n = \frac{1}{\sqrt{4\pi D_{\rm L}t}} \left(\frac{1}{\sqrt{4\pi D_{\rm T}t}}\right)^2 \exp\left[-\frac{x^2 + y^2}{4D_{\rm T}t} - \frac{(z - ut)^2}{4D_{\rm L}t}\right].$$
 (2.68)

2.2.6 Magnetic Anisotropy

Let us now consider the effect of a magnetic field *B* along *z*. The electric field is in the x - z plane and we assume there is no *electric anisotropy*. The magnetic field causes the electrons to move in helices rather than in straight lines between collisions. Projection onto the x - y plane yields circles with radii

$$\rho = \frac{c}{\omega}\sin\theta,\tag{2.69}$$

where $\omega = (e/m)B$ is the cyclotron frequency of the electron, *c* its velocity and θ the angle with respect to the *z* axis. Projection onto the x - z plane yields sinusoidal curves. Figure 2.11a, in contrast to Fig. 2.8, shows how the random propagation of the electron is diminished by the magnetic field. We must repeat our calculation (2.60) with the new orbits.



Fig. 2.11 (a) Electron paths causing the magnetic anisotropy of diffusion. (b) First part of the trajectory showing the direction projected into the x - y plane

Looking at Fig. 2.11b we describe the motion of the electron which has suffered a collision at the origin by the orbit

$$x(l) = \rho \left[\sin \left(\frac{\omega l}{c} - \phi \right) + \sin \phi \right],$$

$$y(l) = \rho \left[\cos \left(\frac{\omega l}{c} - \phi \right) - \cos \phi \right],$$

$$z(l) = l \cos \theta,$$

(2.70)

where *l* is the length of the trajectory and ϕ is the starting direction in the *x* – *y* plane. More precisely, the derivatives with respect to *l* at the origin, giving the initial direction of the electron, are the following:

$$x'(0) = \sin \theta \cos \phi,$$

$$y'(0) = \sin \theta \sin \phi,$$

$$z'(0) = \cos \theta.$$

The mean square displacement of the electron after the first collision is given by an integration over the solid angle and over the distribution (2.59) of path lengths:

$$\langle x^2 \rangle = \frac{1}{4\pi l_0} \int e^{-l/l_0} x^2(l) d\phi d\cos\theta \, dl \tag{2.71}$$

and similarly for $\langle y^2 \rangle$ and $\langle z^2 \rangle$. It is not difficult to integrate (2.71), using (2.70) and (2.69). The result is

2 The Drift of Electrons and Ions in Gases

$$\begin{split} \langle x^2 \rangle &= \langle y^2 \rangle = \frac{2}{3} \frac{l_0^2}{1 + \omega^2 l_0^2/c} = \frac{2}{3} \frac{l_0^2}{1 + \omega^2 \tau^2}, \\ \langle z^2 \rangle &= \frac{2}{3} l_0^2. \end{split}$$

In comparison to (2.60), the magnetic field has caused the diffusion along x and y (then perpendicular to the magnetic field) to be reduced by the factor

$$\frac{D_{\rm T}(\omega)}{D_{\rm T}(0)} = \frac{1}{1 + \omega^2 \tau^2},$$
(2.72)

whereas the longitudinal diffusion is the same as before:

$$D_{\mathrm{L}}(\boldsymbol{\omega}) = D_{\mathrm{L}}(0). \tag{2.73}$$

If there is an *E* field as well as a *B* field in the gas, the electric and magnetic anisotropies combine. In the most general case of arbitrary field directions, the diffusion is described by a 3×3 tensor: let the *B* field be along the *z* axis of a right-handed coordinate system *S*, and let the drift direction \hat{u} , which is at an angle β with respect to *B*, have components along \hat{z} and \hat{x} . The electric anisotropy is along \hat{u} , and the diffusion tensor is diagonal in the system *S'* which is rotated around \hat{y} by the angle β .

In order to describe the two anisotropies in *S*, we must transform the diagonal tensor *S'* to *S* before we multiply by the diagonal tensor that represents the magnetic anisotropy. If the electric anisotropy is equal to D_L/D_T and the magnetic one is equal to $D(0)/D(\omega) = 1/\eta$, we get for the combined tensor *S*

$$D_{ik} = \begin{pmatrix} \cos\beta & 0 & \sin\beta \\ 0 & 1 & 0 \\ -\sin\beta & 0 & \cos\beta \end{pmatrix} \begin{pmatrix} D_{\rm T} & 0 & 0 \\ 0 & D_{\rm T} & 0 \\ 0 & 0 & D_{\rm L} \end{pmatrix} \begin{pmatrix} \cos\beta & 0 & -\sin\beta \\ 0 & 1 & 0 \\ \sin\beta & 0 & \cos\beta \end{pmatrix} \times \begin{pmatrix} \eta & 0 & 0 \\ 0 & \eta & 0 \\ 0 & 0 & 1 \end{pmatrix},$$
$$D_{ik} = \begin{pmatrix} \eta (D_{\rm T} \cos^2\beta + D_{\rm L} \sin^2\beta) & 0 & (D_{\rm L} - D_{\rm T})\sin\beta\cos\beta \\ 0 & D_{\rm T} & 0 \\ \eta (D_{\rm T} - D_{\rm T})\sin\beta\cos\beta & 0 & D_{\rm T} \sin^2\beta + D_{\rm L} \cos^2\beta \end{pmatrix}. \quad (2.74)$$

The importance of diffusion for drift chambers is in the limitation for the coordinate measurement. Hence, we are interested in the deviation along a given direction of an electron that has been diffusing for a time *t*. We treat the general case of a diffusion tensor D_{ij} and a direction $\hat{\alpha}$ given by the three cosine $\alpha_k(\alpha_1^2 + \alpha_2^2 + \alpha_3^2 = 1)$, both expressed in the same coordinate system. We make use of the continuity equation (2.58) for the density $n(x_1, x_2, x_3)$, normalized so that $\int n \, dx = 1$. For a time-independent and homogeneous field the drift velocity is constant, and we have

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$$\frac{\mathrm{d}n}{\mathrm{d}t} = D_{ik} \frac{\partial^2 n}{\partial x_i \partial x_k}$$

(summation over identical indices is always understood). The rate of the mean square deviation along $x' = \alpha_i x_j$ is given by

$$\frac{\mathrm{d}\langle x'^2\rangle}{\mathrm{d}t} = \int_{-\infty}^{+\infty} (\alpha_i x_i)^2 \frac{\mathrm{d}n}{\mathrm{d}t} \mathrm{d}x = \int_{-\infty}^{+\infty} \alpha_i \alpha_j x_i x_j D_{nm} \frac{\partial^2 n}{\partial x_n \partial x_m} \mathrm{d}x = 2\alpha_i \alpha_j D_{ij}.$$

In the last integral all the 81 terms vanish except when the powers of the x_i match the powers of the derivatives: one shows by two partial integrations that

$$\int_{-\infty}^{+\infty} x_i x_j \frac{\partial^2 n}{\partial x_n \partial x_m} \mathrm{d} \boldsymbol{x} = 2 \delta_{im} \delta_{jn},$$

where $\delta_{ik} = 1$ if i = k, and zero otherwise. We have used the fact that electron density and its derivatives vanish at infinity

If a point-like ensemble of electrons begins to diffuse at time zero, then after a time *t* it has grown so that the mean square width of the cloud in the direction α has the value

$$\langle x^{\prime 2} \rangle = 2\alpha_i \alpha_j D_{ij} t. \tag{2.75}$$

The isotropic case in which x'^2 is independent of $\hat{\alpha}$ is obviously given by a D_{ij} which is the unit matrix multiplied with the isotropic diffusion constant. The factor 2 in (2.75) is also present in (2.55) and in the comparison between (2.60) and (2.61). Equation (2.75) implies that the width of the cloud is calculated only from the symmetric part of D_{ij} ; furthermore, the diffusion tensor must be positive definite, otherwise our cloud would shrink in some direction–a thermo-dynamic impossibility.

2.2.7 Electron Attachment

During their drift, electrons may be absorbed in the gas by the formation of negative ions. Whereas the noble gases and most organic molecules can form only stable negative ions at collision energies of several electronvolts (which is higher than the energies reached during the drift in gas chambers), there are some molecules that are capable of attaching electrons at much lower collision energies. Such molecules are sometimes present in the chamber gas as impurities. Among all the elements, the largest electron affinities, i.e. binding energies of an electron to the atom in question, are found with the halogenides (3.1-3.7 eV) and with oxygen ($\sim 0.5 \text{ eV}$). Therefore we have in mind contaminations due to air, water, and halogen-containing chemicals.

Our account must necessarily be brief; for a thorough discussion of the atomic physics of electron attachment, the reader is referred to Massey et al. [MAS 69].

Modern developments may be followed in the Proceedings of the International Conference on the Physics of Electronic and Atomic Collisions, see especially [CHR 81]. One distinguishes two-body and three-body processes.

The two-body process involves a molecule M that may or may not disintegrate into various constituents A, B, ..., one of which forms a negative ion:

$$e^- + M \rightarrow M^-$$

or

$$e^- + M \rightarrow A^- + B + \dots$$

The break-up of the molecule owing to the attaching electron is quite common and is called *dissociative attachment*. The probability of the molecule staying intact is generally higher at lower electron energies. The rate *R* of attachment is given by the cross-section σ , the electron velocity *c*, and the density *N* of the attaching molecule:

$$R = c\sigma N = kN. \tag{2.76}$$

The rate is proportional to the density. The constant of proportionality is called the two-body attachment rate-constant k.

As examples of strong attachment of slow electrons, we depict in Fig. 2.12ad the measured cross-sections of some freons. The rate constants of many other halogen-containing compounds are known [MCC 81]; some of them reach several 10^{-8} s⁻¹ cm³ at low (thermal) electron energies.

Among the three-body processes, the *Bloch–Bradbury* process is the best known [BLO 35, HER 69]. It plays an important role in the absorption of electrons by oxygen molecules. At energies below 1 eV, the electron is attached to the oxygen molecule that forms the excited and unstable state O_2^{*-} . Unless the energy of excitation is carried away by a third body X during the lifetime of the excitation, the O_2^{*-} ion will lose its electron, which is then no longer attached. The lifetime τ is of the order of 10^{-10} s; experimental determinations span the range between 0.02×10^{-10} and 1.0×10^{-10} s, and theoretical calculations come out between 0.88×10^{-10} and 3×10^{-10} s [HAT 81]. The rate *R* of effective attachment depends on τ , as well as on the two collision rates and the cross-sections for the two processes,

$$\sigma_1: \mathbf{e}^- + \mathbf{O}_2 \to \mathbf{O}_2^{*-},$$

$$\sigma_2: \mathbf{O}_2^{*-} + \mathbf{X} \to \mathbf{O}_2^{*-} + \mathbf{X}$$

Let us look at a swarm of electrons in a gas that contains O_2 molecules with density $N(O_2)$ and third bodies X with density N(X). Per electron, let the rate dn/dt of formation of the O_2^{*-} state be $1/T_1$; if the rate of spontaneous decay is n/τ and the rate of de-excitation through collision with third bodies n/T_2 , then the equilibrium number *n* per electron of O_2^{*-} states is given by

$$\frac{1}{T_1} = \frac{n}{\tau} + \frac{n}{T_2},$$



Fig. 2.12a-d Cross-sections for the production of negative ions by slow electrons in (a) CCl_4 , (b) CCl_2F_2 , (c) CF_3I and (d) BCl_3 , observed by Buchel'nikova [BUC 58]

$$n = \frac{1}{T_1} \frac{\tau T_2}{\tau + T_2}$$

Therefore, the rate R of effective attachment of one electron is

$$R=\frac{n}{T_2}=\frac{1}{T_1}\frac{\tau}{\tau+T_2}.$$

The rates $1/T_1$ and $1/T_2$ may be expressed by the cross-sections *a* and relative velocities *c*:

$$\frac{1}{T_1} = c_1 \sigma_1 N(\mathbf{O}_2),$$
$$\frac{1}{T_2} = c_2 \sigma_2 N(\mathbf{X}).$$

In our application, c_1 is the instantaneous electron velocity and c_2 the velocity of the thermal motion between the molecules O_2 and X.

For ordinary pressure and temperature we have $T_2 \gg \tau$, and therefore the rate is given by

$$R = \tau c_1 c_2 \sigma_1 \sigma_2 N(O_2) N(X) = k_1 N(O_2) N(X).$$
(2.77)

It is proportional to the product of the two densities. The three-body attachment coefficient *k* depends on the electron energy through c_1 and σ_1 , on the temperature through c_2 , and on the nature of the third body through σ_2 . The rate varies linearly with each concentration and quadratically with the total gas density.

In the 1980's another three-body process has been identified as making an important contribution to the absorption of electrons on O_2 molecules. The O_2 molecules and some other molecules X form *unstable van der Waals molecules*:

$$O_2 + X \leftrightarrow (O_2 X).$$

These disintegrate if hit by an electron, which finally remains attached to the O₂ molecule:

$$e^- + (O_2X) \rightarrow O_2^- + X$$

Since the concentration of van der Waals molecules in the gas is proportional to the product $N(O_2)N(X)$, the dependence on pressure and concentration ratios in a first approximation is the same as in the Bloch–Bradbury process.

The relative importance of these two three-body attachment processes has been measured with the help of an oxygen-isotope effect [SHI 84]. The authors find



Fig. 2.13 Some three-body attachment coefficients for O_2 quoted from Massey et al. [MAS 69]. The two crosses are measurements by Huk et al. [HUK 88]; for the hydrocarbons at thermal energy, see [SHI 84]

examples where the van der Waal mechanism dominates, whilst the Bloch–Bradbury process is weak; also at higher gas pressures, the van der Waals mechanism makes a strong contribution.

For the operation of drift chambers, the absorption of electrons is a disturbing side effect that can be avoided by using clean gases. Therefore we leave out further refinements that are discussed in the literature.

Some measured three-body attachment coefficients for O_2 are shown in Fig. 2.13 as functions of the electron energy. It can be seen that the H_2O molecule is much more effective as the third body than the more inert atoms or the nitrogen molecule.

The three-body O₂ attachment coefficient involving the methane molecule is large enough to cause electron losses in chambers where methane is a quenching gas. For example (compare Table 11.4), with 20% CH₄ at 8.5 bar, an oxygen contamination of 1 ppm will cause an absorption rate of 2000/s, or roughly 3%/m of drift at a velocity of $6 \text{ cm}/\mu s$. More information on electron attachment is collected in Chap. 12.

2.3 Results from the Complete Microscopic Theory

In this section we quote without proof results for mobility and diffusion in the framework of the complete microscopic theory. The reader is referred to Huxley and Crompton [HUX 74] and to Allis [ALL 56] for a more detailed discussion.

2.3.1 Distribution Function of Velocities

The principal approximation of Sect. 2.2 was to take a single velocity c to represent the motion between collisions of the drifting electrons. In reality, these velocities are distributed around a mean value according to a distribution function

$$f_0(c)\mathrm{d}c,$$

which represents the isotropic probability density of finding the electron in the threedimensional velocity interval $dc_x dc_y dc_z$ at *c*. Therefore the distribution function is normalized so that

$$4\pi \int\limits_0^\infty c^2 f_0(c) \mathrm{d}c = 1.$$

The term 'isotropic' actually refers to the first, isotropic, term of an expansion in Legendre functions of the probability distribution for the vector c.

The shape of the distribution depends on the way in which the energy loss and the cross-section vary with the collision velocity. The regime of elastic scattering as well as a good part of the regime of inelastic scattering can be described by two functions: an effective cross-section $\sigma(c)$, and the fractional energy loss $\lambda(c)(\sigma(c))$ is sometimes called the momentum transfer cross-section). Electron drift velocities that are appropriate for drift chambers are achieved by electric fields that are high enough to make the random energy of the electron much higher than the thermal energy of the gas molecules. Therefore we may neglect thermal motion. Absorption or production of electrons (ionization) is equally excluded.

With these assumptions the distribution of the random velocities can be derived in the framework of the Maxwell–Boltzmann transport equations [HUX 74, SCH 86, ALL 56]:

$$f_0(c) = \text{const} \exp\left[-3\int_0^\varepsilon \lambda \frac{\varepsilon d\varepsilon}{\varepsilon_l^2}\right] = \text{const} \exp\left[\frac{-3m}{2e^2E^2}\int_0^\varepsilon \lambda v^2 d\varepsilon\right], \quad (2.78)$$

where $\varepsilon = mc^2/2$, and $\varepsilon_l = eEl_0 = eE/(N\sigma)$ is the energy gained through a mean free path l_0 in the direction of the field. The distribution function can also be written as an integral over the collision frequency $v = cN\sigma$. The second form of (2.78) lends itself to the generalization owing to the presence of a magnetic field. For a discussion of the range of validity of our assumptions, the reader is also referred to the quoted literature.

In order to make a picture of such velocity distributions, we consider two limiting cases.

 If both the collision time τ and the fractional energy loss are independent of c, then f₀(c) is the Maxwell distribution. Using (2.77) and (2.78),

$$f_0(c) \to \frac{1}{(\alpha \sqrt{\pi})^3} \exp\left[-\left(\frac{c}{\alpha}\right)^2\right],$$
 (2.79)

with

$$\alpha^2 = \frac{4}{3\lambda} \left(\frac{eE}{m}\tau\right)^2$$

• If both the mean free path $l_0 = c\tau$ and the fractional energy loss are independent of c – an approximation that is sometimes useful in a limited range of energies – then $f_0(c)$ assumes the form of a *Druyvesteyn distribution* (Fig. 2.14):

$$f_0(c) \to \frac{1}{\alpha^3 \pi \Gamma(3/4)} \exp\left[-\left(\frac{c}{\alpha}\right)^4\right],$$
 (2.80)

with

$$\alpha^4 = \frac{8}{3\lambda} \left(\frac{eE}{m} l_0\right)^2$$

Once $f_0(c)$ is known, the mobility and diffusion are calculated from appropriate averages over all velocities c.



2.3.2 Drift

The drift velocity is given by

$$u = \frac{4\pi}{3} \frac{e}{m} \frac{E}{N} \int_{0}^{\infty} f_{0}(c) \frac{d}{dc} \left[\frac{c^{2}}{\sigma(c)} \right] dc = -\frac{4\pi}{3} \frac{e}{m} E \int_{0}^{\infty} \frac{c^{3}}{\nu(c)} \frac{d}{dc} f_{0}(c) dc.$$
(2.81)

The two expressions are related to each other by a partial integration and by the fact that the mean collision frequency v(c) is $N\sigma(c)c$. The drift velocity depends on *E* and *N* only through the ratio E/N.

Another way of writing (2.81) is to use brackets for denoting the average over the velocity distribution. With a little algebra, we obtain

$$u = \frac{e}{m} \left(\langle \tau \rangle + \left\langle \frac{c}{3} \frac{\mathrm{d}\tau}{\mathrm{d}c} \right\rangle \right) E.$$
(2.82)

This shows that expression (2.14) is recovered not only in the obvious case that τ is independent of *c*, but already when only the average $\langle c d\tau/dc \rangle$ vanishes.

In the case of a constant σ and λ , using the Druyvesteyn distribution (2.80), we may derive the mean square random velocity $\langle c^2 \rangle$ and the square of the drift velocity from (2.81). We find that

$$\langle c^2 \rangle = \frac{eE}{mN\sigma} \sqrt{\frac{2}{\lambda}} 0.854,$$

 $u^2 = \frac{eE}{mN\sigma} \sqrt{\frac{\lambda}{2}} 0.855.$

A comparison with (2.19) and (2.20) shows that there are extra factors of 0.854 and 0.855 resulting from the finite width of the velocity distribution.

2.3.3 Inclusion of Magnetic Field

In Sect. 2.2.3 we have seen that the addition of a magnetic field to electrons drifting in an electric field will change their effective random velocity c unless the two fields are parallel, so there has to be a change in the distribution function. Following Allis and Allen [ALL 37] (but see also [MAS 69, HUX 74]), we quote the result for the case where the two fields are orthogonal to each other. The distribution takes the form

$$f_0(c) = \text{const} \exp\left[-\frac{3m}{2e^2E^2} \int_0^\varepsilon \lambda(\varepsilon) [v^2(\varepsilon) + \omega^2] \mathrm{d}\varepsilon\right], \qquad (2.83)$$

where the cyclotron frequency $\omega = (e/m)B$ is, of course, independent of ε .

This function depends on two constants of nature *e* and *m*, on two functions of the electron energy $\sigma(\varepsilon)$ and $\lambda(\varepsilon)$, and on three numbers (*E*, *B*, *N*) in the hands of the experimenter, of which two (say E/N and B/N) are independent. For arbitrary orientation of the fields, f_0 would depend on the angle between the two fields.

In the presence of a magnetic field, the drift-velocity vector depends on both the electric and magnetic fields. The corresponding mobility tensor is μ_{ik} , so that $u_i = \mu_{ik}E_k$ (summation over common indices is understood). The three diagonal components and the six off-diagonal terms are given by the following expressions:

$$\mu_{ii} = -\frac{4\pi}{3} \frac{e}{m} \int_{0}^{\infty} \frac{c^{3}(v^{2} + \omega_{i}^{2})}{v(v^{2} + \omega^{2})} \frac{d}{dc} f_{0}(c) dc,$$

$$\mu_{ik} = -\frac{4\pi}{3} \frac{e}{m} \int_{0}^{\infty} \frac{c^{3}(\omega_{i}\omega_{k} + v\varepsilon_{ikj}\omega_{j})}{v(v^{2} + \omega^{2})} \frac{d}{dc} f_{0}(c) dc.$$
(2.84)

where the fully antisymmetric symbol ε_{ikj} represents a sign-factor that is equal to +1 for all even permutations of 123, to -1 for all odd ones, and to zero if any two elements are equal; $\omega_1, \omega_2, \omega_3$, are the components of the magnetic field, multiplied by e/m, $\omega^2 = \omega_1^2 + \omega_2^2 + \omega_3^2$; $f_0(c)$ is the velocity distribution function appropriate for the two fields. As in the case of the scalar mobility, if *v* is independent of *c* then one recovers the expression (2.5) derived from the equation of motion with friction. Deviations from this relation can therefore be expected to the extent that *v* varies with *c*. See also the discussion in Sect. 2.4.5.

We notice that the number density *N* of gas molecules is a scaling factor, not only for the electric field but also for the magnetic field. If in (2.84) we divide numerator and denominator by $\omega^2 = (e/m)^2 B^2$, then all terms containing ω 's appear either as ω_i/ω or as $\nu/\omega = N\sigma c/\omega$.

2.4 Applications

The dependence of the drift-velocity vector on the three scalar quantities E, B, and N may therefore be written in the form

$$u_i = \mu_{ik} \left(\frac{E}{N}, \frac{B}{N}, \phi\right) \frac{E_k}{N}, \qquad (2.85)$$

where ϕ is the angle between the fields.

This relation is important when it comes to a discussion of the gas pressure in drift chambers (Chap. 12).

2.3.4 Diffusion

As given in the quoted literature, the isotropic diffusion coefficient is derived from the velocity distribution function through the integral

$$D = 4\pi \int_{0}^{\infty} \frac{c^2}{3\nu(c)} f_0(c)c^2 \,\mathrm{d}c.$$
 (2.86)

We note that expression (2.61) represented the case of one unique velocity,

$$4\pi c^2 f_0(c) = \delta(c - \langle c \rangle).$$

The magnetic anisotropy caused by a *B* field may be described by the 3×3 tensor D_{ik} . Its elements are given by

$$D_{ii} = \frac{4\pi}{3} \int_{0}^{\infty} \frac{c^{2}(v^{2} + \omega_{i}^{2})}{v(v^{2} + \omega^{2})} f_{0}(c)c^{2} dc,$$

$$D_{ik} = \frac{4\pi}{3} \int_{0}^{\infty} \frac{c^{2}(\omega_{i}\omega_{k} + v\varepsilon_{ikj}\omega_{j})}{v(v^{2} + \omega^{2})} f_{0}(c)c^{2} dc.$$
(2.87)

For the electric anisotropy of diffusion, we must retain in the velocity distribution its dependence on position; the reader is referred to the literature [PAR 69].

2.4 Applications

In this section we discuss few practical applications of the formulae derived in the previous sections.

2.4.1 Determination of $\sigma(\varepsilon)$ and $\lambda(\varepsilon)$ from Drift Measurement

In the drift of ions and electrons in gases, the quantities that are important for track localization are the drift velocity and the diffusion tensor. In this chapter we have

described how they are derived as functions of *E* and *B* from the two functions of the collision velocity, $\sigma(c)$ and $\lambda(c)$, the effective scattering cross-section, and the fraction of energy loss per collision. However, these two functions are generally not known from independent measurements, and one goes in the opposite direction: starting from measurements of u(E) and $D(E)/\mu(E)$, one tries to find, with some intuition, $\sigma(c)$ and $\lambda(c)$, in such a way that they reproduce the measurements using the formulae described in Sect. 2.3. If the measured values coincide with the ones "recalculated" from the guessed $\sigma(c)$ and $\lambda(c)$, then this consistency indicates that $\sigma(c)$ and $\lambda(c)$ were guessed correctly. The first example using this procedure was applied to electrons in argon by Frost and Phelps in 1964 [FRO 64].

In the work of B. Schmidt [SCH 86], considerable progress is visible not only in the accuracy of his measurements – which is near 1% in the drift velocity and 5% in D/μ – but also in the inclusion of the electric anisotropy of diffusion. He studied the noble gases and some molecular gases–chiefly methane–which are useful in drift chambers. In Fig. 2.15 we see the CH₄ drift-velocity measurements, and in Fig. 2.16 the measurements of the transverse and longitudinal diffusion. Superimposed we find curves that represent the recalculated values. The effective (momentum transfer) cross-section of methane and the energy loss factor of methane used in their calculation have already been shown in Figs. 2.2a and 2.2b as functions of the electron energy. The consistency of these results leaves no doubt that the method is correct, although the assessment of the errors to $\sigma(\varepsilon)$ and $\lambda(\varepsilon)$ remains difficult. It is possible to give $\lambda(\varepsilon)$ a form that is consistent with plausible assumptions about the quadrupole moments of the methane molecule. Similar computations were done by Biagi [BIA 89]. A special case concerning water contamination is treated in Sect. 12.3.3.



Fig. 2.15 Measured and recalculated electron drift velocity in CH₄ as a function of the reduced electric field. One Townsend (Td) equals 10^{-17} V cm².[SCH 86]



Fig. 2.16 Measured and recalculated transverse and longitudinal electron diffusion in CH_4 [SCH 86]. The ratio of the diffusion coefficients over the mobility is shown as a function of the reduced electric field

There are microwave relaxation measurements that allow an alternative derivation of the cross-sections of some gases; also, there are quantum-mechanical calculations for the noble gases. Where a comparison of cross-sections can be made, they are identical within factors of 2 to 5, and often much better. According to the calculations, the minimum is sharper than that derived from the drift measurement because the wide energy distribution smears it out. For more details, the reader is referred to the literature.

There is a very large number of measurements of electron drift velocities and diffusion coefficients. Many of them are collected in two compilations [FEH 83] and [PEI 84], which also contain other material that is of interest with respect to drift chambers.

Measurements in magnetic fields are rare; we present some examples in Sect. 2.4.7. Precision reproductions of magnetic data, and determinations of $\sigma(\varepsilon)$ and $\lambda(\varepsilon)$ from them, have not yet been done.

2.4.2 Example: Argon–Methane Mixture

In this subsection we want to collect and interpret some drift and diffusion measurements for argon + methane mixtures without magnetic field. This gas has been investigated more systematically than most others, and is being used in several large TPCs.

The measurements, done by Jean-Marie et al. [JEA 77], of the drift velocity as a function of the electric field *E* at atmospheric pressure are presented in Fig. 2.17. For all mixing ratios *R* there is a rising part at low *E* and a falling part at high *E*. The maxima occur at values E_p , which depend almost linearly on the CH₄ concentration,

Fig. 2.17 Drift velocity u in an argon-methane mixture as a function of the electric field E, measured by Jean-Marie et al. [JEA 77]. The lowest curve is for 90% Ar + 10% CH₄ etc.



up to $E_p = 900 \text{ V/cm}$ for pure CH₄. For every concentration, the maximum occurs at the electric-field value where the average electron energy is at the Ramsauer minimum of the momentum transfer cross-section (e = 0.3 eV for CH₄ and 0.25 eV for Ar). According to (2.19), the peak behaviour of u^2 is determined mostly by the $\sigma(\varepsilon)$ in the denominator because the factor $\sqrt{\lambda(\varepsilon)}$ varies much less.

We can actually measure the values of ε for every *E* and *R*, and check that the Ramsauer minimum coincides with the velocity peak. For this we make use of the systematic measurements of the width σ_x of the single-electron diffusion conducted by the Berkeley group [PEP 76]. Their results have been rescaled to 1 cm drift length at 760 Torr, and are plotted in Fig. 2.18. They exhibit a fairly constant behaviour of the diffusion when *E* is changed, and an increase for smaller CH₄ concentrations.

Referring to our equation (2.63), we may calculate the electron energy for every E and every mixing ratio R:

$$\varepsilon(E,R) = \frac{3}{4} \frac{\sigma_x^2(E,R)}{1 \,\mathrm{cm}} eE, \qquad (2.88)$$

This has been graphed in Fig. 2.19, where we have also marked on the horizontal scale the velocity peaks for the various values of R. We observe that the measured electron energies are in the Ramsauer minimum at the velocity peaks (see Fig. 2.2a).

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Fig. 2.18 Width of the diffusion cloud after a drift of 1 cm for various mixtures of CH₄ and Ar at 760 Torr. The upper group of points refer to 10% CH₄ + 90% Ar, etc. Measurements by the Berkeley TPC group [PEP 76] were done at 600 Torr over a drift length of 15 cm



Fig. 2.19 Electron energy defined in (2.63) as a function of the electric field for various mixtures of $CH_4 + Ar$ at 760 Torr. The data of Fig. 2.18 were used. The arrows on the horizontal scale indicate the position of the maxima of the drift velocities according to Fig. 2.17



2.4.3 Experimental Check of the Universal Drift Velocity for Large $\omega \tau$

In a drift experiment with crossed electric and magnetic fields, Merck [MER 89] measured drift angles and drift velocities at atmospheric pressure in Ar + CH₄ mixtures that are known to have large values of τ under typical drift-chamber conditions. Using the tangent of the drift angle as measure for $\omega\tau$ (2.11), he found the drift velocities that are plotted as a function of $\omega\tau$ in Fig. 2.20a,b. We observe that they do approach the limit

$$u \rightarrow \frac{E}{B}$$

quickly from below. However, the approximation (2.54) is not very good, as different combinations of E and B that lead to the same $\omega \tau$ do not yield the same





u, especially at low concentrations of CH₄. We would expect that the more detailed theory involving the electron energy distribution is required in order to explain these variations.

2.4.4 A Measurement of Track Displacement as a Function of Magnetic Field

In a TPC with almost perfect parallelism between *B* and *E*, the small angle a of misalignment causes a displacement of every track element that is proportional to the drift length *L*. If we imagine the coordinate system aligned with the *E* field along *z* and with small extra *B* components along *x* and *y*, there will be displacements at the wire plane, equal to $\delta_x = Lu_x/u_z$ and $\delta_y = Lu_y/u_z$; according to (2.6), these are

$$\delta_{x} = L\left(\alpha_{x}\frac{\omega^{2}\tau^{2}}{1+\omega^{2}\tau^{2}} - \alpha_{y}\frac{\omega\tau}{1+\omega^{2}\tau^{2}}\right),$$

$$\delta_{y} = L\left(\alpha_{x}\frac{\omega\tau}{1+\omega^{2}\tau^{2}} + \alpha_{y}\frac{\omega^{2}\tau^{2}}{1+\omega^{2}\tau^{2}}\right),$$
(2.89)

with $\alpha_x = B_x/B_z$ and $\alpha_y = B_y/B_z$. It is by reversing the magnetic field that the different contributions can be separated. The symmetric part of δ_x is

$$\Delta_{x}^{S} = \frac{1}{2} [\delta_{x}(B) + \delta_{x}(-B)] = L\alpha_{x} \frac{\omega^{2}\tau^{2}}{1 + \omega^{2}\tau^{2}}, \qquad (2.90)$$

and its antisymmetric part is

$$\Delta_x^{\mathbf{A}} = \frac{1}{2} [\delta_x(B) - \delta_x(-B)] = L \alpha_y \frac{-\omega \tau}{1 + \omega^2 \tau^2}.$$
(2.91)

In Fig. 2.21 we see measured displacements [AME 85] for two different values of *L* and a range of values of *B*. Fitting the symmetric part in Fig. 2.21 with the functional form of (2.90) yielded $\tau = 0.29 \times 10^{-10}$ s, and the antisymmetric part fitted with (2.91) yielded $\tau = 0.35 \times 10^{-10}$ s, for the particular conditions of the experiment (argon (91%) + methane (9%), 1 bar, E = 110 V/cm, u = 5.05 cm/µs). These values of τ are not the same because they represent averages over the distribution functions, which are written explicitly in (2.84).

2.4.5 A Measurement of the Magnetic Anisotropy of Diffusion

In a TPC with parallel *E* and *B* fields, the transverse width σ_{diff} of the electron cloud originating from a laser track was measured for various drift distances *L* and magnetic fields *B* [AME 86]. Since this width is related to the diffusion constant *D* and the known drift velocity *u* by



Fig. 2.21 Measured track displacements due to a small angle between the electric and magnetic fields; (a) symmetric part, (b) antisymmetric part. The curves are fits to (2.90) and (2.91). Curves A: L = 126 cm; curves B: L = 65 cm [AME 85]

$$\sigma_{\rm diff}^2(L,B) = 2D(B)L/u,$$

we determined D(B). The quantity actually observed, σ_1^2 , was the quadratic sum of σ_{diff} and of a constant, σ_0 , given by the width of the laser beam and the electrode configuration. Figure 2.22 depicts the observations.

If we express the factor D(0)/D(B) by which the magnetic field reduces the diffusion constant as a function of B^2 , we see a linear behaviour for small B^2 as well



Fig. 2.22 Measured dependence of σ_1^2 on the magnetic field and the drift length. The slope decreases with increasing *B* as the diffusion is reduced [AME 86]

2.4 Applications



as for large B^2 . The transition region between the two straight lines is around $6kG^2$ (see Fig. 2.23). The interpretation is the following.

Referring to (2.84) and (2.87) we note that the off-diagonal elements of the diffusion tensor do not contribute to σ_{diff} . We write

$$D_{11}(\omega) = \frac{4\pi}{3} \int_{0}^{\infty} \frac{c^2 v}{v^2 + \omega^2} f_0(c) c^2 dc = \left\langle \frac{c^2 v}{3(v^2 + \omega^2)} \right\rangle.$$

This expression can be evaluated in the two limiting cases of ω^2 small and ω^2 large compared with v_0^2 , the square of a typical collision frequency v_0 . For this typical frequency we may take the value derived from the electron mobility μ in the limit in which v is independent of $c: v_0 = (e/m)/\mu$. We find in lowest order

$$\frac{D_{11}(0)}{D_{11}(B)} = 1 + \omega^2 \tau_1^2, \quad \omega^2 \ll v_0^2,
\frac{D_{11}(0)}{D_{11}(B)} = C + \omega^2 \tau_2^2, \quad \omega^2 \ll v_0^2.$$
(2.92)

The values of

$$\tau_{1}^{2} = \frac{\langle c^{2}/v^{3} \rangle}{\langle c^{2}/v \rangle},$$

$$\tau_{2}^{2} = \frac{\langle c^{2}/v \rangle}{\langle c^{2}/v \rangle},$$

$$C = \frac{\langle c^{2}/v \rangle \langle c^{2}v^{3} \rangle}{\langle c^{2}v \rangle^{2}}$$
(2.93)

are independent of ω , because the two fields are parallel to each other.

Since v is a function of c and is therefore distributed over a wide range of values, the averages in (2.93) are all different. In fact the straight lines in Fig. 2.23

are described by $\tau_1 = (0.4 \pm 0.02) \times 10^{-10}$ s, $\tau_2 = (0.266 \pm 0.006) \times 10^{-10}$ s, and $C = 2.8 \pm 0.2$ for the particular conditions investigated, which were argon (91%) + methane (9%) at 1 bar, E = 110 V/cm, and u = 5.05 cm/µs, implying $v_0 = 4.2 \times 10^{10}$ s⁻¹.

The two straight lines cross each other at $\omega = (3.6 \pm 0.3) \times 10^{10} \text{ s}^{-1}$, where ω/v_0 is nearly 1. If v were independent of c, or if the distribution of c were extremely narrow, we would have had $\tau_1 = \tau_2$ and C = 1.

2.4.6 Calculated and Measured Electron Drift Velocities in Crossed Electric and Magnetic Fields

Drift chambers that have to operate in a magnetic field B often have their proportional wires parallel to B, hence their electrons drifting in crossed electric and magnetic fields.

Daum et al. [DAU 78] have measured the drift-velocity vector for a variety of suitable gas mixtures as functions of both fields. Typical velocities |u| are shown in Fig. 2.24, and typical drift angles ψ , measured against the direction of E towards $E \times B$, are shown in Fig. 2.25. We have selected two examples of gas mixtures,



Fig. 2.24 Magnitude of the drift velocity in crossed electric and magnetic fields for two different gas mixtures, plotted as a function of the electric field (at atmospheric pressure) for four different values of *B*. The curves represent calculations by Ramanantsizhena [RAM 79], the points measurements by Daum et al. [DAU 78]






Fig. 2.26 The magnitude of the drift velocity in two different mixtures of argon–methane, measured at various magnetic fields by Merck [MER 89], and plotted as a function of the electric field component along the drift direction. The measured points fall essentially on universal curves that are independent of the magnetic field

argon + ethane, and xenon + ethane, which exhibit different mobilities and, therefore, different values of $\omega \tau$ at a given magnetic field.

These measurements have been compared with calculations based on the formalism explained in Sect. 2.3, by Ramanantsizhena [RAM 79]. He used elastic cross-sections for the $e-C_2H_6$ collision, which are based on the work of Duncan and Walker [DUN 74], and inelastic cross-sections derived from Palladino and Sadoulet [PAL 75]. Comparing the measurements with the calculations, we notice that agreement exists, mostly at the level of 5 to 10%, occasionally worse. In addition we observe the small variation of the calculated maximum of the drift velocity as the magnetic field is changed: according to Tonks' theorem it should stay the same, but with a realistic distribution function it decreases by 1 or 2% for the gas mixtures of Fig. 2.24 as *B* goes up from 0 to 1.5 T.

In Fig. 2.26 we see drift velocities measured by Merck [MER 89] in crossed electric and magnetic fields as functions of the electric field component along the drift direction. We note that the points belonging to different *B* fall on the same line characteristic of the gas, within the measurement error, which is 2 or 3% (only for the small CH₄ concentration is there a 12% deviation near the peak). Obviously Tonks' theorem, (2.13) and (2.51), is quite well confirmed.

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Chapter 3 Electrostatics of Tubes, Wire Grids and Field Cages

The electric field in a drift chamber must provide two functions: drift and amplification. Whereas in the immediate vicinity of the thin proportional or 'sense' wire the cylindrical electric field provides directly the large field strengths required for charge amplification, the drift field must be created by a suitable arrangement of electrodes that are set at potentials supplied by external voltage sources. It is true that drift fields have also been created by depositing electric charges on insulators – such chambers are described in Sect. 11.4 – but we do not treat them here. Charge amplification is not necessarily confined to proportional wires. It has also been measured between parallel plates and between a wire mesh and a metal plate as well as in the tiny holes in a plate coated on both sides with the metal layers of a condenser. In fact these MICROMEGA and GEM counters seem to have a promising future [FAB 04].

There is a large variety of drift chambers, and they have all different electrode arrangements. An overview of existing chambers is given in Chap. 11, where we distinguish three basic types. In the volume-sensitive chambers (types 2 and 3) the functions of drift and amplification are often more or less well separated, either by special wire grids that separate the drift space from the sense wire or at least by the introduction of 'field' or 'potential' wires between the sense wires. The drift field, which fills a space large compared to the amplification space, then has to be defined at its boundaries; these make up the 'field cage'. For a uniform field, the electrodes at the boundaries are at graded potentials in the field direction and at constant potentials orthogonal to it.

Also the area-sensitive chambers (type 1) have often been built with 'potential' or 'field-shaping' wires to provide a better definition and a separate adjustment of the drift field. In this chapter we want to discuss some elements that are typical for the volume-sensitive chambers with separated drift and amplification spaces: one or several grids with regularly spaced wires in conjunction with a field cage. Although directly applicable to a time projection chamber (TPC), the following considerations will also apply to many type 2 chambers.

Electrostatic problems of the most general electrode configuration are usually solved by numerical methods, for example using relaxation techniques [WEN 58].

Computer codes exist for wire chamber applications [VEN 08]. In this chapter we develop analytical methods taking advantage of simple geometry, in order to establish the main concepts. A classic treatment is found in Morse and Feshbach [MOR 53].

The simplest device for the measurement of drift time is the drift or proportional tube. This name refers to the original, proportional mode of amplification, but the device can also be used beyond the proportional mode, see Sect. 4.2. In its ideal form it is a circular cylindrical tube with a wire in the centre. As we have in mind to also describe deviations from the ideal form which arise in practice we will approach the electrostatics of a tube in a slightly generalized way.

3.1 Perfect and Imperfect Drift Tubes

Deviations from the ideal geometry of two concentric circular cylinders are caused by displaced wires or deformed walls. In this section we discuss the electric field arising in a circular right cylinder with the wire off-centre. Since we are dealing with relatively small deviations our method is a first-order perturbation calculation of the linear deviation.

The solution of Laplace's equation

$$\nabla^2 \Phi = 0 \tag{3.1}$$

for the potential Φ in the charge-free space between two conductors is found by separation of variables. In cylindrical coordinates we write

$$\Phi(r, \varphi, z) = R(r)\phi(\varphi)Z(z)$$

$$\frac{1}{rR}\frac{\partial}{\partial r}\left(r\frac{\partial R}{\partial r}\right) + \frac{1}{r^2\phi}\frac{\partial^2\phi}{\partial\varphi^2} + \frac{1}{Z}\frac{\partial^2 Z}{\partial z^2} = 0.$$
(3.2)

Assuming Z(z) = const = 1, we equate the second term to the constant $-v^2$ so that

$$\frac{d^2\phi}{d\phi^2} = -v^2\phi,$$

whose solutions are

$$\begin{split} \phi(\varphi) &= C'_{\varphi} \cos v \varphi + C''_{\varphi} \sin v \varphi & \text{if } v \neq 0 \\ \phi(\varphi) &= C'_{\varphi} \varphi + C''_{\varphi} & \text{if } v = 0. \end{split}$$
(3.3)

The *C*'s are constants to be determined by the boundary conditions. The radial part becomes the Euler-Cauchy equation

$$r\frac{d}{dr}\left(r\frac{dR}{dr}\right) - v^2 R = 0. \tag{3.4}$$

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3.1 Perfect and Imperfect Drift Tubes

If v = 0, the solution is given by

$$R(r) = C'_r \ln r + C''_r.$$
(3.5)

3.1.1 Perfect Drift Tube

The potential between two coaxial cylinders is a straight application of Eq. (3.5). When the outer cylinder (radius *b*) is on ground, and the wire (radius *a*) on positive potential *U*, one determines the coefficients to be given by $C'_{\varphi} = 0$, $C''_{\pi} = -C'_{r} \ln b$ and $C'_{r}C''_{\varphi} \ln(a/b) = U$, so that

$$\Phi = \frac{U}{\ln(a/b)} \ln(\frac{r}{b}). \tag{3.6}$$

The electric field is directed radially outwards, and

$$E_r = -\frac{\partial \Phi}{\partial r} = \frac{U}{\ln(b/a)} \frac{1}{r}.$$
(3.7)

Another way to calculate E_r is using Gauss' theorem according to which

$$E_r = \frac{\lambda}{2\pi\varepsilon_0} \frac{1}{r} \tag{3.8}$$

where λ is the linear charge density on the wire; the value of ε_0 is $8.854 \cdot 10^{-12}$ As/Vm. Therefore the capacitance per unit length of tube is given by

$$C = \frac{\lambda}{U} = \frac{2\pi\varepsilon_0}{\ln(b/a)}.$$

3.1.2 Displaced Wire

Solution of the Electrostatic Problem

Let the wire be displaced from the tube centre by the distance d in the negative ydirection (Fig. 3.1). The wire defines the centre of the coordinate system so that the first boundary condition is

$$\Phi(a) = U,$$
 independent of φ . (3.9)

We must express the second boundary by the radius vector as a function of φ . The exact expression is

$$\rho = d\sin\varphi + b\sqrt{(1 - (d^2/b^2)(1 - \sin^2\varphi))},$$

Fig. 3.1 Geometry of displaced wire



but we are only interested in small wire displacements. To first order in d/b we have the boundary at

$$\rho = b + d\sin\varphi, \tag{3.10}$$

and the second boundary condition is

$$\Phi(\rho) = 0. \tag{3.11}$$

Now we must determine the various coefficients using (3.9) and (3.11). To the first order in d/b we have solutions for v = 0 and v = 1, and the most general solution is

$$\Phi = (C_r^{0'} \ln r + C_r^{0''}) C_{\varphi}^{0''} + (C_r^{1'} r + C_r^{1''} / r) (C_{\varphi}^{1'} \cos \varphi + C_{\varphi}^{1''} \sin \varphi).$$
(3.12)

Inserting (3.9), we have to require

$$C_r^{1'}a + C_r^{1''}/a = 0, (3.13)$$

which implies that $C_r^{1''}$ can be neglected against $C_r^{1'}$ for the entire space except in the immediate vicinity of the wire surface.

When inserting (3.11) and (3.10) into (3.12) we make use of the relation

$$\ln(b+d\sin\varphi) = \ln b + (d/b)\sin\varphi,$$

which holds to first order in d/b. This determines the constants $C_r^{0'}$, $C_r^{0''}$ and $C_{\varphi}^{0''}$ as in the case (3.6) of the perfect tube. Comparing factors that multiply the sin φ -terms, we find

$$C_{\varphi}^{0''}C_{r}^{0'}(d/b) + C_{r}^{1'}bC_{\varphi}^{1''} = 0$$

or

$$C_r^{1'} C_{\varphi}^{1''} = -\frac{d}{b^2} \frac{U}{\ln(a/b)}$$
(3.14)

whereas $C_{\varphi}^{1'} = 0$. This produces the solution, in first order of (*d/b*), equal to

$$\Phi(r,\varphi) = \frac{U}{\ln(a/b)} \ln \frac{r}{b} - \frac{U}{\ln(a/b)} \frac{d}{b} \frac{r}{b} \sin \varphi.$$
(3.15)

3.1 Perfect and Imperfect Drift Tubes

The perturbing potential Φ_1 caused by the wire displacement is given by the second term. Using $y = r \sin \varphi$, the field perturbation is calculated to be

$$(E_1)_y = -\frac{\partial \Phi_1}{\partial y} = -\frac{U}{\ln(b/a)}\frac{d}{b^2}$$
(3.16)

$$(E_1)_x = (E_1)_z = 0. (3.17)$$

It describes a constant field directed towards negative y, whose magnitude is d/b times the value of the unperturbed field (3.7) at the wall.

For the purpose of calculating the electrostatic force on the wire (see further down) we also record the value of $(E_1)_y$ on the wire surface (r = a). Starting from (3.13) without the previous simplification $C_r^{1''} = 0$, the correct perturbation potential is

$$\Phi_1(r,\varphi) = \frac{-U}{\ln(a/b)} \frac{d}{b^2} (r - \frac{a^2}{r}) \sin \varphi.$$
(3.18)

The field in y-direction equals

$$(E_1(a))_y = -\frac{\partial \Phi_1}{\partial y}$$
 evaluated at $r = a$
= $-\frac{U}{\ln(b/a)} \frac{2d}{b^2} \sin^2 \varphi$

Averaging over φ we have an extra field on the wire surface equal to

$$\overline{(E_1(a))_y} = -\frac{U}{\ln(b/a)}\frac{d}{b^2}$$
(3.19)

The average extra field on the wire surface is as large as the field perturbation (3.16), (3.17) throughout the volume.

Gravitational Sag

The main reason for wire displacement is the weight of the wire. Even when strung with a pulling force T close to the breaking limit, wires in several metre long tubes will experience a gravitational sag that is large in comparison with the achievable accuracy of drift tubes.

In order to derive a formula for the amount of bowing we introduce the coordinates y (downwards) and x (horizontal). We note that on every length element dx the weight of the wire is

$$\rho g \sigma dx$$
 (3.20)

(ρ = density, σ = cross sectional area of the wire, $g = 981 \text{ cm/s}^2$). It must be compensated by the vertical component of the tension at this point, which is equal to the difference of the slopes at the two ends of the interval dx, multiplied by the pulling force T:

$$-T[y'(x+dx) - y'(x)]$$
(3.21)

where the primes denote the first derivative. In this approximation we have assumed that the pulling force is the same for all *x*, the variation due to the weight of the wire being negligible for practical tubes.

Combining (3.20) and (3.21), one has the differential equation

$$-y'' = C = \rho g \sigma / T \tag{3.22}$$

with the solution

$$y = (C/2)x^2 + C_1 x + C_2.$$
(3.23)

Specifying that y = 0 at $x = \pm L/2$ determines the coefficients C_1 , C_2 , and the solution becomes

$$y = \frac{C}{2} \left(\frac{L^2}{4} - x^2\right).$$
 (3.24)

The point of the maximum excursion is the sagitta, equal to

$$s = y(0) = \frac{CL^2}{8} = \frac{\rho g \sigma L^2}{8T}.$$
 (3.25)

It is proportional to the inverse of the mechanical tension. If the tension is increased the sagitta is reduced, but the tension cannot be arbitrarily increased since non-elastic deformations take place. The maximum pulling force T_c that can be applied to a wire is proportional to its cross section, and the ratio T_c/σ is constant (except for very thin wires). The minimum achievable sagitta of a wire of given length is independent of the wire cross section. The values of the critical tension and typical sagittas for 100-cm-long wires of different materials are shown in Table 3.1. Usually the wires are strung to a tension close to the critical one in order to reduce the sagging. Inspecting Table 3.1 we notice that among the various materials, tungsten is the one that allows the smallest sagittas but at the expense of quite a large tension, for a given diameter of the wire. Since the tension of the wires is held by the endplates of the chamber, a large tension requires stiff endplates. In the design of a chamber one usually compromises between these two parameters.

If the sagitta of long wires cannot be constructed to be small one may be obliged to control its size within small tolerances. A practical way of doing this is by measuring the oscillation frequency of the wire. The frequency f_1 of the lowest mode of the elastic string is

 Table 3.1 Maximum stresses before deformation of typical wire materials and corresponding sagittas for 1-m-long wires

Material	$T_{\rm c}/\sigma~({\rm kg/mm}^2)$	Sagitta (μ m) of a 100 cm long wire strung at $T_{\rm c}$
Al	416	2184
Cu	2137	3053
Fe	1825	3954
W	180410	613

3.1 Perfect and Imperfect Drift Tubes

$$f_1 = \frac{1}{2L} \sqrt{\frac{T}{\rho\sigma}}.$$
(3.26)

Inserting (3.25) into (3.26) produces the simple relation

$$f_1^2 = \frac{g}{32s}.$$
 (3.27)

Electrostatic Force on the Sagged Wire

The displacement of the wire creates an average field (3.19) which acts on the electric charge of the wire and produces a force which tends to increase the displacement. The differential equation (3.22) needs to be complemented by a term which represents the electrostatic force per unit wire length. This is given by the product

$$\lambda \cdot (E_1(a))_{\nu}$$

where λ is given by (3.8) in terms of the unperturbed field, and $(E_1(a))_y$ is given by (3.19) and is proportional to the displacement *y*. The electrostatic force, like gravity, points downwards and leads to a positive term on the right-hand side of (3.22), whereas y'' < 0. Therefore, the differential equation is

$$y'' + k^2 y + C = 0 (3.28)$$

with $C = \rho g \sigma / T$ and $k^2 = 2\pi \epsilon_0 E_0^2(b) / T$. The value of k is plotted against $E_0(b)$ and T in Fig. 3.2.

The general solution of (3.28) is

$$y = C_1 \cos kx + C_2 \sin kx - C/k^2.$$
(3.29)

When specifying $y(\pm L/2) = 0$, the coefficients C_1 , C_2 are determined, and the solution becomes

$$y = \frac{C}{k^2} \left(\frac{1}{\cos(kL/2)} \cos kx - 1 \right).$$
(3.30)

The electrostatic force has changed the form of the wire from the parabola (3.24) to the cosine function (3.30).

The new sagitta is

$$s_k = y(0) = \frac{C}{k^2} \left(\frac{1}{\cos(kL/2)} - 1 \right) \xrightarrow{kL \ll 1} \frac{CL^2}{8}$$
 (3.31)

This means the electrostatic force has increased the sagitta (3.25) by the factor

$$\frac{s_k}{s} = \frac{8}{k^2 L^2} \left(\frac{1}{\cos(kL/2)} - 1 \right) = \frac{2}{q^2} \left(\frac{1}{\cos q} - 1 \right).$$
(3.32)

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Fig. 3.2 Value of the constant *k* in (3.28) relevant for the electrostatic amplification of the gravitational sag, as a function of the electric field $E_0(b)$ at the tube wall, for various wire pulling forces *T*

As the product kL approaches the value π , the excursion tends to infinity, and the wire is no longer in a stable position. For example, the gravitational sag of a wire strung with one N inside a 5 m long tube will be amplified by a factor of s_k/s of 1.56 if the field at the wall is $E_0(b) = 500$ V/cm. The point of instability is reached at $E_0(b) = 840$ V/cm. In Fig. 3.3 we plot s_k/s as a function of q^2 or $k^2L^2/4$.



Fig. 3.3 Amplification factor of the gravitational sag owing to electrostatic forces, according to (3.32)

3.2 Wire Grids

3.2.1 The Electric Field of an Ideal Grid of Wires Parallel to a Conducting Plane

We assume a reference system with the x - y plane coincident with the conducting plane (pad plane) and the y axis along the direction of the wires of the grid. The z axis is perpendicular to the plane (see Fig. 3.4).

The potential is a function of the coordinates x and z only, because the problem has a translational symmetry along the y direction. We assume the zero of the potential on the conducting plane (z = 0). The complex potential of a single line of charge λ per unit length placed at U' = x' + iz' is

$$\phi(U) = -\frac{\lambda}{2\pi\varepsilon_0} \ln \frac{(U - U')}{(U - \bar{U}')},\tag{3.33}$$

where U = x + iz is the coordinate of a general point and $\overline{U}' = x' - iz'$ is the complex conjugate of U'. MKS units are used throughout.

The potential of the whole grid is obtained by adding up the contributions of each wire:

$$\phi(U) = -\frac{\lambda}{2\pi\varepsilon_0} \sum_{k=-\infty}^{k=+\infty} \ln \frac{(U-U'_k)}{(U-\bar{U}'_k)},$$

where U'_k is the coordinate of the *k*th wire.

All the wires of the grid are equispaced with a pitch s: therefore

$$U'_k = x_0 + ks + iz_0 (k = \dots - 2, -1, 0, 1, 2, \dots),$$

where x_0 and z_0 are the coordinates of the 0th wire of the grid. The potential of the grid can be written as

$$\phi(U) = -\frac{\lambda}{2\pi\varepsilon_0} \sum_{k=-\infty}^{k=+\infty} \ln \frac{(U-U_0'-ks)}{(U-\bar{U}_0'-ks)}.$$

This summation can be computed [ABR 65]:



Fig. 3.4 An ideal grid of wires parallel to a conducting plane

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$$\phi(U) = -\frac{\lambda}{2\pi\varepsilon_0} \ln \frac{\sin[(\pi/s)(U-U_0')]}{\sin[(\pi/s)(U-\bar{U}_0')]}$$

and the corresponding real potential is

$$V(x,z) = \operatorname{Re} \phi(U)$$

= $-\frac{\lambda}{4\pi\epsilon_0} \ln \frac{\sin^2[(\pi/s)(x-x_0)] + \sin h^2[(\pi/s)(z-z_0)]}{\sin^2[(\pi/s)(x-x_0)] + \sin h^2[(\pi/s)(z+z_0)]}.$ (3.34)

Figure 3.5a shows V(x, z) as function of z at two different values of x. In the chosen example the grid was placed at $z_0 = s$. We notice that such a grid behaves almost everywhere like a simple layer of charge with surface density λ/s . Only in the immediate vicinity of the wires (distances much smaller than the pitch) can the structure of the grid be seen (compare with Fig. 3.5b, which shows the potential of a simple layer of charge). Therefore it is possible to superimpose different grids or plane electrodes at distances larger than the pitch without changing the boundary conditions of the electrostatic problem. We have an example of the general two-dimensional problem where a potential ϕ that varies periodically in one direction x has every Fourier component $\approx \cos(2\pi nx/s)$ damped along the transverse direction z according to the factor $e^{-2\pi nz/s}$. This holds because every Fourier component must satisfy Laplace's equation

$$\frac{\partial^2 \phi}{\partial x^2} + \frac{\partial^2 \phi}{\partial z^2} = 0$$



Fig. 3.5 (a) The potential V(x,z) of a grid of wires situated a distance z_0 from a conducting plane at $x_0, x_0 + s, ...$ with pitch $s = z_0$ and a linear charge density λ per wire. (b) The potential V(z) of a plane of charge situated a distance z_0 from a conducting plane, with a surface charge density σ

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outside the wires. The solution is

$$\phi = \sum_{n} C_n \mathrm{e}^{-2\pi nz/s} \cos(2\pi nx/s),$$

the C_n being constants.

At a distance from the grid comparable or larger than the pitch the potential assumes the value

$$V(x,z) = \frac{z\lambda}{\varepsilon_0 s} \quad \text{for } z < z_0, z_0 - z \gg \frac{s}{2\pi},$$

$$V(x,z) = \frac{z_0\lambda}{\varepsilon_0 s} \quad \text{for } z_0 < z, z - z_0 \gg \frac{s}{2\pi}.$$
(3.35)

On the surface of the wires the potential assumes the value evaluated at $(x - x_0)^2 + (z - z_0)^2 = r^2$. We replace in first order of r/s the hyperbolic functions by their arguments and take for $\sinh(2\pi z_0/s)$ the positive exponential. The potential of the wire is then

$$V(\text{wire}) = \frac{\lambda z_0}{\varepsilon_0 s} \left(1 - \frac{s}{2\pi z_0} \ln \frac{2\pi r}{s} \right).$$
(3.36)

This means that the wire grid, although it behaves like a simple sheet with area charge density λ/s has some 'transparency'. We could have given the grid a zero potential and the conducting plane a potential *V*. Then, beyond the grid the potential would have been

$$\frac{\lambda}{2\pi\varepsilon_0}\ln\frac{2\pi r}{s}$$

and not zero as on the grid – some of the potential of the plane behind can be 'seen through the grid'. In other words, the potential beyond the grid is different from the potential on the grid by the difference between the electric field on the two sides of the grid, multiplied by the length $(s/2\pi) \ln(2\pi r/s)$.

The electric field that can be computed from (3.34) is given here for convenience:

$$E_x(x,z) = \frac{\lambda}{2s\varepsilon_0} \sin\left[\frac{2\pi}{s}(x-x_0)\right] \left[\frac{1}{A_1} - \frac{1}{A_2}\right],$$
$$E_z(x,z) = \frac{\lambda}{2s\varepsilon_0} \left\{\frac{\sinh[(2\pi/s)(z-z_0)]}{A_1} - \frac{\sinh[(2\pi/s)(z+z_0)]}{A_2}\right\},$$

where

$$A_1 = \cosh\left[\frac{2\pi}{s}(z-z_0)\right] - \cos\left[\frac{2\pi}{s}(x-x_0)\right],$$
$$A_2 = \cosh\left[\frac{2\pi}{s}(z+z_0)\right] - \cos\left[\frac{2\pi}{s}(x-x_0)\right].$$

3.2.2 Superposition of the Electric Fields of Several Grids and of a High-Voltage Plane

Knowing the potential created by one plane grid (3.34) and its very simple form (3.35) valid at a distance $d(d \gg s/2\pi)$ out of this plane, we want to be able to superimpose several such grids, in order to accommodate not only the sense wires but also all the other electrodes: the near-by field and shielding wires and the distant high-voltage electrode.

In order to be as explicit as possible we will present the specific case of a TPC. These chambers have more grids than most other volume-sensitive drift chambers, and the simpler cases may be derived by removing individual grids from the following computations.

We want to calculate the electric field in a TPC with the geometry sketched in Fig. 3.6. The pad plane is grounded, and we have four independent potentials: the high-voltage plane (V_p) , the zero-grid wire (V_z) , the field wires (V_f) and the sense wires (V_s) . We have to find the relations between those potentials and the charge induced on the different electrodes.

Since the distance *d* between the grid planes satisfies the condition $d \gg s/2\pi$, the total electric field is generally obtained by superimposing the solution of each grid. This assumes that all the wires inside a single grid are at the same potential, but it is not the case for the sense-wire and field-wire grids where the sense wires and the field wires are at different potentials and the two grids are at the same *z*. In this case the superposition is still possible owing to the symmetry of the geometry: the potential induced by the sense-wire grid on the field wires is the same for all the field wires and vice-versa.

The potential induced by the sense-wire grid on the field wires can easily be computed because the field-wire grid and the sense-wire grid have the same pitch. Evaluating formula (3.34) at the position of any field wire we find that

$$V\left(x_0 + \frac{s_1}{2} + ks_1, z_1\right) = \frac{\lambda_s}{2\pi\varepsilon_0} \ln\left[\cosh\frac{2\pi z_1}{s_1}\right] \approx \frac{\lambda_s z_1}{\varepsilon_0 s_1} - \frac{\lambda_s}{2\pi\varepsilon_0} \ln 2.$$
(3.37)

Fig. 3.6 Basic grid geometry of a TPC: The sense-wire/field-wire plane is sandwiched between two grounded planes – the zero-grid-wire plane and the pad plane. The high-voltage plane is a large distance away from them



3.2 Wire Grids

We can now use (3.35), (3.36) and (3.37) to calculate the potential of each electrode as the sum of the contributions of the charges induced on each grid and on the high-voltage plane:

$$\begin{split} V_{\rm s} &= \frac{\lambda_{\rm s} z_1}{\epsilon_0 s_1} \left(1 - \frac{s_1}{2\pi z_1} \ln \frac{2\pi r_{\rm s}}{s_1} \right) + \frac{\lambda_{\rm f} z_1}{\epsilon_0 s_1} \left(1 - \frac{s_1}{2\pi z_1} \ln 2 \right) + \frac{\lambda_{\rm z} z_1}{s_2 \epsilon_0} + \frac{\sigma_{\rm p} z_1}{\epsilon_0}, \\ V_{\rm f} &= \frac{\lambda_{\rm s} z_1}{\epsilon_0 s_1} \left(1 - \frac{s_1}{2\pi z_1} \ln 2 \right) + \frac{\lambda_{\rm f} z_1}{\epsilon_0 s_1} \left(1 - \frac{s_1}{2\pi z_1} \ln \frac{2\pi r_{\rm f}}{s_1} \right) + \frac{\lambda_{\rm z} z_1}{s_2 \epsilon_0} + \frac{\sigma_{\rm p} z_1}{\epsilon_0}, \\ V_{\rm z} &= \frac{\lambda_{\rm s} z_1}{s_1 \epsilon_1} + \frac{\lambda_{\rm f} z_1}{s_1 \epsilon_0} + \frac{\lambda_{\rm z} z_2}{\epsilon_0 s_2} \left(1 - \frac{s_2}{2\pi z_2} \ln \frac{2\pi r_z}{s_2} \right) + \frac{\sigma_{\rm p} z_2}{\epsilon_0}, \end{split}$$
(3.38)

$$V_{\rm p} &= \frac{\lambda_{\rm s} z_1}{s_1 \epsilon_0} + \frac{\lambda_{\rm f} z_1}{s_1 \epsilon_0} + \frac{\lambda_{\rm z} z_2}{s_2 \epsilon_0} + \frac{\sigma_{\rm p} z_{\rm p}}{\epsilon_0}, \end{split}$$

where σ_p is the surface charge density on the high-voltage plane, λ_s , λ_f , λ_z are the charges per unit length on the wires, and r_s , r_f , r_z are the radii of the wires.

We can define a surface charge density σ , for each grid, as the charge per unit length, divided by the pitch (λ_i/s_i) , and (3.38) can be written as

$$\begin{pmatrix} V_{\rm s} \\ V_{\rm f} \\ V_{\rm z} \\ V_{\rm p} \end{pmatrix} = A \begin{pmatrix} \sigma_{\rm s} \\ \sigma_{\rm f} \\ \sigma_{\rm z} \\ \sigma_{\rm p} \end{pmatrix}, \qquad (3.39)$$

where *A* is the matrix of the potential coefficients. The matrix *A* can be inverted to give the capacitance matrix (this is the solution of the electrostatic problem):

$$\begin{pmatrix} \sigma_{\rm s} \\ \sigma_{\rm f} \\ \sigma_{\rm z} \\ \sigma_{\rm p} \end{pmatrix} = A^{-1} \begin{pmatrix} V_{\rm s} \\ V_{\rm f} \\ V_{\rm z} \\ V_{\rm p} \end{pmatrix}.$$
(3.40)

Once the capacitance matrix A^{-1} is known we can calculate the charges induced on each electrode for any configuration of the potentials. The electric field is given by the superposition of the drift field with the fields of all the grids, given by (3.38).

In normal operating conditions the electric field in the amplification region is much higher than the drift field. In this case $\lambda_s/s_1 \gg |\sigma_p|$ and the charge induced on the high-voltage plane can be approximated by

$$\sigma_{\rm p} = \varepsilon_0 \frac{V_{\rm p} - V_{\rm z}}{z_{\rm p} - z_2}.$$

Then the matrix A of (3.39) can be reduced to a 3×3 matrix, neglecting the last row and the last column,

Table 3.2 Matrix of the potential coefficients (m^2 /farad) referring to the grids s, f and z in the standard case

	(6.64	3.56	4.00
$A = 1.13 \times 10^{8}$	3.56	5.62	4.00
	4.00	4.00	8.28)

$$A = \frac{1}{\varepsilon_0} \begin{pmatrix} z_1 - \frac{s_1}{2\pi} \ln \frac{2\pi r_s}{s_1} & z_1 - \frac{s_1}{2\pi} \ln 2 & z_1 \\ z_1 - \frac{s_1}{2\pi} \ln 2 & z_1 - \frac{s_1}{2\pi} \ln \frac{2\pi r_f}{s_1} & z_1 \\ z_1 & z_1 & z_2 - \frac{s_2}{2\pi} \ln \frac{2\pi r_z}{s_2} \end{pmatrix}.$$
 (3.41)

Tables 3.2 and 3.3 give the coefficients of the matrix A of (3.41) and of its inverse in a standard case:

$$z_1 = 4 \text{ mm}, z_2 = 8 \text{ mm}, s_1 = 4 \text{ mm}, s_2 = 1 \text{ mm},$$

 $r_s = 0.01 \text{ mm}, r_f = r_z = 0.05 \text{ mm}.$

Using (3.38) we can now compute the potential of the high-voltage plane when it is uncharged ($\sigma_p = 0$):

$$V_{\rm p} = V(\infty) = \sigma_{\rm s} \frac{z_1}{\varepsilon_0} + \sigma_{\rm f} \frac{z_1}{\varepsilon_0} + \sigma_{\rm z} \frac{z_2}{\varepsilon_0}.$$
 (3.42)

The electric field in the drift region is zero.

In order to produce a drift field E we have to set the high-voltage plane at a potential

$$V_{\rm p} = -E(z_{\rm p} - z_2) + V(\infty). \tag{3.43}$$

(*E* is defined positive and is the modulus of the drift field.)

3.2.3 Matching the Potential of the Zero Grid and of the Electrodes of the Field Cage

When we set the potential of the high-voltage plane V_p to the value defined by (3.43), the potential in the drift region $(z - z_2 \gg s_2/2\pi)$ is given by

Table 3.3 Capacitance Matrix (farad/m²) referring to the grids s, f and z in the standard case

	(0.25	-0.11	-0.07
$A^{-1} = 8.85 \times 10^{-9}$	-0.11	0.32	-0.10
	0.07	-0.10	0.21)

3.2 Wire Grids

$$V(z) = -E(z - z_2) + V(\infty).$$
(3.44)

Using equations (3.41) and (3.42) one can show that

$$V_{\rm z} = V(\infty) - \frac{s_2}{2\pi\varepsilon_0}\sigma_{\rm z}\ln\frac{\pi r_{\rm z}}{s_2}$$

and (3.44) can be written as

$$V(z) = -E(z - z_2) + V_z + \frac{s_2}{2\pi\varepsilon_0}\sigma_z \ln\frac{2\pi r_z}{s_2}.$$
 (3.45)

Figure 3.7 shows $V(z) - V_z$ as function of $z - z_2$ in the geometry discussed in the previous section with $V_s = 1300 V$, $V_g = V_z = 0$ and with a superimposed drift field of 100 V/cm. We notice that in this configuration the equipotential surface of potential V_z is shifted into the drift region by about 2 mm. This effect has to be taken into account when the potential of the electrodes of the field cage has to be matched with the potential of the zero grid and when one has to set the potential of the gating grid (see Sect. 3.3.2).

After the adjustment of all the potentials on the grids and the high-voltage plane the field configuration is established. We show in Fig. 3.8 the field lines for the typical case of a TPC corresponding to Fig. 3.6 with $z_1 = 4 \text{ mm}$, $z_2 = 8 \text{ mm}$, $s_1 = 4 \text{ mm}$, $s_2 = 1 \text{ mm}$, $r_s = 0.01 \text{ mm}$, $r_f = r_z = 0.05 \text{ mm}$, $V_s = 1300 \text{ V}$, $V_f = V_z = 0$, $E_p = 100 \text{ V/cm}$. One observes that the drift region is filled with a very uniform







Fig. 3.8 Field lines for the typical case of a TPC with electrodes as in Fig. 3.6 $(z_1 = 4 \text{ mm}, z_2 = 8 \text{ mm}, s_1 = 4 \text{ mm}, s_2 = 1 \text{ mm}, r_s = 0.01 \text{ mm}, r_f = r_z = 0.05 \text{ mm}, V_s = 1300 \text{ V}, V_f = V_z = 0, E_p = 100 \text{ V/cm})$

field, but also in the amplification region we find homogeneous domains as expected from (3.35). The electric field lines reach the sense wires from the drift region along narrow paths.

3.3 An Ion Gate in the Drift Space

It is possible to control the passage of the electrons from the drift region into the amplification region with a gate, which is an additional grid ('gating grid'), located inside the drift volume in front of the zero grid and close to it. This is important when the drift chamber has to run under conditions of heavy background.

In this section we deal with the principal (electrostatic) function of the ion gate and how it is integrated into the system of all the other electrodes. Chapter 9 is devoted to a discussion of the behaviour of ion gates and their transparency under various operating conditions, including alternating wire potentials, and magnetic fields.

The potential of the wires of the gating grid can be regulated to make the grid opaque or transparent to the drifting electrons. In this section we neglect the effect of the magnetic field and assume that the electrons follow the electric field lines.

In the approximation that the electric field in the amplification region is much higher than the drift field, the variation of the potentials of the gating grid will not change appreciably the charge distribution on the electrodes in the amplification region, and we can schematize the gating grid as a grid of wires placed in between two infinite plane conductors: the high-voltage plane and the zero grid. The geometry is sketched in Fig. 3.9.

3.3.1 Calculation of Transparency

If the electrons follow the electric field lines we can compute the transparency T, i.e. the fraction of field lines that cross the gating grid, from the surface charge on the high-voltage plane and on the gating grid:

$$T = 1 - \frac{\sigma_{\rm g}^+}{|\sigma_{\rm p}|},\tag{3.46}$$

where σ_p is the surface charge density on the high-voltage plane (negative) and σ_g^+ is the surface charge density of positive charges on the gating grid.

If we approximate the wires of the grid by lines of charge λ per unit length, the surface charge density on the grid is simply λ/s , and the condition of full transparency is

 $\lambda \leq 0.$

This approximation is no longer correct when the absolute value of λ is so small that we have to consider the variation of charge density over the surface of the wire. A wire 'floating' in an external electric field *E* is polarized by the field, which

Z_p HV plane

 Z_3 Q_3 gating grid Z_2 Q_2 Q_2

Fig. 3.9 Scheme for the inclusion of the gating grid



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Fig. 3.10 Electric field lines near an uncharged wire floating in a homogenous field

produces a surface charge density σ_D on the wire. It depends on the azimuth (see Fig. 3.10):

$$\sigma_{\rm D} = 2E\varepsilon_0\cos\theta, \qquad (3.47)$$

where θ is the angle between *E* and the radius vector from the centre to the surface of the wire [PUR 63].

In the general case the wire has, in addition to this polarization charge, a linear charge λ . The total surface charge density on the wire is

$$\sigma_{\rm w} = \frac{\lambda}{2\pi r} + 2E\varepsilon_0 \cos\theta, \qquad (3.48)$$

r being the radius of the wire. An illustration is Fig. 3.11. When

$$\frac{|\lambda|}{4\pi\varepsilon_0}\gg Er$$



Fig. 3.11 Dependence on azimuth of the surface charge density σ_w located on the gating grid wire

the polarization effect can be neglected. This is the case of the zero-grid, sense and field wires, as discussed in the previous section.

There may be both positive and negative charges on the wires of the gating grid. In order to calculate T we must now count the positive charges only. This can be done using (3.48):

$$\lambda^{+} = 0 \qquad \text{when} \quad \frac{\lambda}{2\pi r} < -2E\varepsilon_{0},$$

$$\lambda^{+} = \lambda \qquad \text{when} \quad \frac{\lambda}{2\pi r} > 2E\varepsilon_{0},$$

$$\lambda^{+} = \frac{\lambda\theta_{0}}{\pi} + 4E\varepsilon_{0}r\sin\theta_{0} \qquad (3.49)$$

$$\text{when} - 2E\varepsilon_{0} < \frac{\lambda}{2\pi r} < 2E\varepsilon_{0},$$

$$\theta_{0} = \arccos\frac{-\lambda}{4\pi\varepsilon_{0}Er}$$

and the surface charge density of positive charge on the gating grid is

$$\sigma_{\rm g}^+ = \frac{\lambda^+}{s_3}.\tag{3.50}$$

Using (3.46) and (3.50) we obtain the condition for full transparency in the general case:

$$\frac{\lambda_{\rm g}}{2\pi r_{\rm g}} \le -2E\varepsilon_0 \quad \text{or} \quad \frac{\sigma_{\rm g}}{2\pi r_{\rm g}} s_3 \le -2E\varepsilon_0. \tag{3.51}$$

In the limiting condition of full transparency, the electric field between the gating grid and the zero-grid increases by a factor

$$1+4\pi \frac{r_g}{s_3}$$

with respect to the drift field.

Using (3.50) and (3.50) we can calculate the transparency in the special case of $\sigma_g = 0$:

$$T=1-\frac{4r_{\rm g}}{s_3}.$$

The opacity of the gating grid in this configuration is twice the geometrical opacity. To illustrate the situation of limiting transparency the field lines above and below the fully open gate are displayed in Fig. 3.12a,b.

The drift field lines for our standard case are shown in Fig. 3.13a,b. We observe that the drifting electrons arrive on a sense wire on one of four roads through the zero grid – a consequence of the ratio of $s_1/s_3 = 4$.

In order to compute the transparency as a function of the gating-grid potential we have to calculate the capacity matrix. Following the scheme of Sect. 3.2 we obtain



Fig. 3.12a,b Field lines in the limiting case of full transparency. (a) Neighbourhood above and below the gate (the electrons drift from above), (b) Enlargement around the region around



Fig. 3.13a,b Drift field lines in a standard case

 $(z_1 = 4 \text{ mm}, z_2 = 8 \text{ mm}, z_3 = 12 \text{ mm}, s_1 = 4 \text{ mm}, s_2 = 1 \text{ mm}, s_3 = 2 \text{ mm})$. The field lines between the sense wires and the other electrodes have been omitted for clariy. *Squares*: gating grid; *black circles*: zero-grid; *open circles*: sense wires; *crosses*: field wires, (**a**) gating grid open (maximal transparency), (**b**) gating grid closed

3.3 An Ion Gate in the Drift Space

$$\begin{pmatrix} V_{\rm p} - V_{\rm z} \\ V_{\rm g} - V_{\rm z} \end{pmatrix} = \frac{1}{\varepsilon_0} \begin{pmatrix} z_{\rm p} - z_2 & z_3 - z_2 \\ z_3 - z_2 & (z_3 - z_2) - \frac{s_3}{2\pi} \ln \frac{2\pi r_{\rm g}}{s_3} \end{pmatrix} \begin{pmatrix} \sigma_{\rm p} \\ \sigma_{\rm g} \end{pmatrix}$$
(3.52)

and

$$\begin{pmatrix} \sigma_{\rm p} \\ \sigma_{\rm g} \end{pmatrix} = K \begin{pmatrix} z_3 - z_2 - \frac{s_3}{2\pi} \ln \frac{2\pi r_{\rm g}}{s_3} & -(z_3 - z_2) \\ -(z_3 - z_2) & z_{\rm p} - z_2 \end{pmatrix} \begin{pmatrix} V_{\rm p} - V_{\rm z} \\ V_{\rm g} - V_{\rm z} \end{pmatrix}, \quad (3.53)$$

where

$$K = \frac{\varepsilon_0}{(z_p - z_2) \left(z_3 - z_2 - \frac{s_3}{2\pi} \ln \frac{2\pi r_g}{s_3} \right) - (z_3 - z_2)^2}$$

and V_g is the potential of the gating grid. In the following we neglect the second term in the denominator of the factor K, since $z_p - z_2 \gg z_3 - z_2$ in the standard case.

Using (3.51) and (3.53) we can calculate the minimum value of V_g needed for the full transparency of the gating grid:

$$V_{\rm g} - V_{\rm z} \le \frac{4\pi r_{\rm g}}{s_3} \frac{V_{\rm p} - V_{\rm z}}{z_{\rm p} - z_2} \left(z_3 - z_2 - \frac{s_3}{2\pi} \ln \frac{2\pi r_{\rm g}}{s_3} \right) + \frac{z_3 - z_2}{z_{\rm p} - z_2} (V_{\rm p} - V_{\rm z}).$$
(3.54)

The second term of (3.54) is the potential difference that makes $\sigma_g = 0$. The first term is the additional difference needed to eliminate the positive charges from the gating grid. In a standard configuration the two terms are comparable.

In Fig. 3.14 we compare the transparency calculated according to (3.46–3.53) for our standard case with measurements performed on a model of the ALEPH TPC [AME 85-1]. There is good agreement between theory and experiment.



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3.3.2 Setting of the Gating Grid Potential with Respect to the Zero-Grid Potential

In Sect. 3.4 it was shown that because of the high field in the amplification region the average potential at the position of the zero-grid does not coincide with V_z . The potential in the drift region, where the gating grid has to be placed, is given by (3.45).

This formula can be extrapolated at $z = z_2$:

$$V(z_2) = V_z + \frac{s_2}{2\pi\varepsilon_0} \sigma_z \ln \frac{2\pi r_z}{s_2}, \qquad (3.55)$$

giving the effective potential of the zero-grid seen from the region where the gating grid has to be placed.

In Sect. 3.3.1 we calculated the condition of full transparency, approximating the zero-grid as a solid plane at a potential V_z and referring to it the potential of the gating grid. In the real case V_g has to be referred to the effective potential $V(z_2)$ given by (3.55).

From what has been shown so far one can deduce that by making V_g sufficiently positive all drift field lines terminate on the gating grid and the transparency *T* is 0. Figure 3.13a,bb shows how the drift field lines terminate on the gating grid.

3.4 Field Cages

The electric field in the drift region has to be as uniform as possible and ideally similar to that of an infinitely large parallel-plate capacitor. The ideal boundary condition on the field cage is then a linear potential varying from the potential of the high-voltage membrane to the effective potential of the zero-grid.

This boundary condition can be constructed, in principle, by covering the field cage with a high-resistivity uniform material. A very good approximation can be obtained covering the inner surface of the field cage with a regular set of conducting strips perpendicular to the electric field, with a constant potential difference ΔV between two adjacent strips:

$$\Delta V = E\Delta,$$

where Δ is the pitch of the electrode system.

The exact form of the electric field produced by this system of electrodes can be calculated with conformal mapping taking advantage of the symmetry of the boundary conditions [DUR 64]. Figure 3.15 shows the electric field lines and the equipotentials near the strips in a particular case when the distance between two strips is 1/10 of the strip width. The electric field very near to the strips is not uniform and there are also field lines that go from one strip to the adjacent one. The transverse component essentially decays as $\exp(-2\pi t/\Delta)$ where t is the distance from the field cage (see Sect. 3.2), and when $t = \Delta$ the ratio between the transverse and the main component of the electric field is about 10^{-3} . At larger distances it



Fig. 3.15 Electric field configuration near the strips of a field cage. Equipotential lines (*broken*) and electric field lines (*full*) are shown. D: drift space; Δ : electrode pitch; *t*: coordinate in the drift space

becomes completely negligible, showing that this geometry of the electrodes is indeed a good approximation of the ideal case. However, the insulators present some problems.

3.4.1 The Difficulty of Free Dielectric Surfaces

The Dirichlet boundary conditions of the electrostatic problem to be solved in some volume require the specification of a potential at every point of a closed boundary surface. When conducting strips are involved that are at increasing potentials, insulators between them are unavoidable, and the potential on these cannot be specified. If the amount of free charge deposited on these surfaces were known everywhere, one would have mixed boundary conditions, partly Dirichlet, partly Neumann, and a solution could be found. In high-voltage field cages there is always some gas ionization, and the amount of free charges ready to deposit on some insulator is infinitely large. How can this uncertainty in the definition of the drift field be limited? There are several solutions to this difficulty:

Controlled (small, surface or volume) conductivity of the insulator: For every rate of deposit of ions there is some value of conductivity allowing the transport of these ions sufficiently fast to the next electrode, so that their disturbing effect is limited.

Retracted insulator surfaces: If the electrodes have the form indicated in Fig. 3.16a,ba or b, any field *E* that may develop at the bottom of the ditch between conductors owing to charge deposit will be damped by a factor of the order of $\exp(-\pi d/s)$ at the edge of the drift space. (For details of this electrostatic problem, see e.g. [JAC 75, p. 72.]) A maximum field *E* is given by the breakdown strength of the particular gas.



Thin insulator with shielding electrodes covering the gap from behind: Apart from the system of main electrodes, there is another set separated by a thin layer of insulator, and staggered by a half-step according to Fig. 3.17. The purpose of these shielding electrodes at intermediate potentials is to regularize the field in the drift region, but also to produce virtual mirror charges of any free charges that may have deposited in the gap, thus reducing their effect in the drift space.

If we assume that by one of the measures described above the adverse effects of any charge deposit are sufficiently reduced, we may imagine a smooth (linear) transition of potential between neighbouring electrodes, and the exact form of the electric field produced by the system of electrodes at increasing potentials can be calculated as discussed at the beginning of this section.

Electrostatic distortions were studied by Iwasaki et al. [IWA 83].



Fig. 3.17 Field-cage electrode configuration with secondary electrode strips (SE) covering the gaps between the main electrode strips (ME) behind a thin insulator foil (It). D: drift space; I: insulator

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3.4.2 Irregularities in the Field Cage

In this subsection we present some studies that have arisen in practice when estimating the tolerances that had to be respected in the ALEPH TPC for the conductivity of the insulator, for the match of the gating grid and for the resistors in the potential divider. We quote the three relevant electrostatic solutions as examples of similar problems in chambers with different geometry.

If all the electrodes of the field cage are set at the correct potential, the drift field is uniform and parallel to the axis of the TPC in the whole drift volume. A wrong setting of the potentials produces a transverse component of the electric field and causes a distortion of the trajectories of the drifting electrons. In order to study this effect in detail the drift volume of the TPC is schematized as a cylinder of length *L* and radius *A* (see Fig. 3.18). The potentials defined on the surface of the cylinder define the boundary conditions of the electrostatic problem and the drift field inside the volume. If the potentials on the boundary do not vary with ϕ , the electric field can only have a transverse component in the radial direction.

In the absence of magnetic field the electrons drift along the electric field line; an electron placed at the position (r_0, z_0) reaches the end of the drift volume at a radial position

$$r = r_0 + \int_{z_0}^0 \frac{E_{\mathrm{r}}(r,z)}{E_z} \mathrm{d}z.$$

The radial component of the field can be calculated solving the Poisson equation in cylindrical coordinates [JAC 75, p. 108]. Since the ideal setting of the potential does not produce radial electric field components it is convenient to use as a boundary condition the difference between the actual and the ideal potentials. This is possible because the Poisson equation is linear in the potential. Although we discuss the examples in a cylindrical geometry, they apply to other geometries in a similar way.

Non-Linearity in the Resistor Chain. The potential of the strips of the field cage are defined connecting them to a linear resistor chain. The strips are insulated from the external ground by an insulator that has a finite resistivity and that is in parallel with the resistors of the chain. It can be shown that the resistance to ground of a strip placed at a position z is



Fig. 3.18 Scheme of a cylindrical TPC drift region

3 Electrostatics of Tubes, Wire Grids and Field Cages

$$R(z) = R_{\text{tot}} \left[\frac{z}{L} - \frac{1}{6} \left(\frac{z}{L} \right)^3 \frac{R_{\text{tot}}}{R_{\text{man}}} \right]$$

where R_{tot} is the resistance of the whole resistor chain and R_{man} is the resistance of the insulator mantel across the wall of the insulator. This non-linear resistance produces a potential distribution that differs from the linear one by

$$\Delta V(z) = \left[\frac{Z}{L} - \left(\frac{Z}{L}\right)^3\right] V_{\rm p} \frac{R_{\rm tot}}{R_{\rm man}} \frac{R_{\rm tot}}{R_{\rm man}} \ll 1,$$

where V_p is the potential of the central electrode. This error potential can be approximated by

$$\Delta V(z) \approx \frac{0.38}{6} V_{\rm p} \frac{R_{\rm tot}}{R_{\rm man}} \sin\left(\pi \frac{z}{L}\right).$$

Following Jackson's formalism [JAC 75] it can be shown that the radial displacement of an electron drifting from the point (r, z) is

$$\Delta r \approx \frac{0.38}{6} \frac{R_{\text{tot}}}{R_{\text{man}}} L \frac{\mathrm{i}J_1\left(\frac{\mathrm{i}\pi r}{L}\right)}{J_0\left(\frac{\mathrm{i}\pi A}{L}\right)} \cos\left(\frac{\pi z}{L}-1\right),$$

where J_0 are the Bessel functions of order 0 and 1. Figure 3.19 shows a plot of Δr as function of *z* for different values of *r* assuming L = A = 2 m and $R_{\text{tot}}/R_{\text{man}} = 10^{-3}$.

Mismatch of the Gating Grid. The potentials of the field cage have to match that of the last wire plane as discussed in Sect. 3.2. An error ΔV in the potential of the last electrode of the field cage produces a radial displacement

$$\Delta r = 2L \frac{\Delta V}{V_{\rm p}} \sum_{n} \frac{J_1(x_n r/A)}{J_1(x_n) x_n} \left(\frac{\cosh[\pi(L-z)(x_n/A) - \cosh(Lx_n/A)]}{\sinh(Lx_{n/A})} \right),$$



Fig. 3.19 Radial displacement *r* of the arrival point of an electron, caused by a resistance R_{man} of the insulator mantle a thousand times the value of the resistor chain, Δr is shown as a function of the starting point *z*, *R* in the example A = L = 2 m



Fig. 3.20 Radial displacement Δr of the arrival point of an electron, caused by a voltage mismatch ΔV between the last electrode of the field cage and the last wire plane, amounting to $\Delta V/V_p = 10^{-4}$ of the drift voltage. Δr is shown as a function of the starting point (z, R) in the example A = L = 2 m

where $x_n = k_n A$ and $J_0(k_n) = 0$.

Figure 3.20 shows a plot of Δr as a function of z for different values of r assuming L = A = 2 m and $\Delta V/V_p = 10^{-4}$.

Resistor Chain Containing One Wrong Resistor. If in the voltage-divider chain one of the resistors (placed at $z = \overline{z}$) has a wrong value, it induces an error in the potential of the field cage:

$$\begin{split} \Delta V(z) &= \frac{-\Delta V}{L} z, \ z < \bar{z}, \\ \Delta V \left(1 - \frac{z}{L} \right), \quad z > \bar{z}, \\ \Delta V &= V_{\mathrm{p}} \frac{\Delta R}{R_{\mathrm{tot}}}, \end{split}$$

where ΔR is the error in the resistance of that particular resistor and R_{tot} is the total resistance of the chain. The induced radial displacement is



Fig. 3.21 Radial displacement Δr of the arrival point of an electron, caused by one wrong resistor value $R^* = R + \Delta R$, where $\Delta R/R_{\text{tot}} = 1/400$ of the value of the total resistor chain. Δr is shown as a function of the starting point (z, R) in the example A = L = 2 m

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$$\Delta r = L \frac{\Delta R}{r_{\text{tot}}} \left[\frac{1}{\pi} \sum \frac{i J_1(i n \pi r) / L}{J_0(i n \pi A) / L} \frac{1}{n} \cos\left(\frac{n \pi \bar{z}}{L}\right) \left(\cos\frac{n \pi z}{L} - 1\right) \right].$$

Figure 3.21 shows a plot of Δr as a function of z for different values of r for a particular case L = A = 2 m, z = 1.4 m, $\Delta R/R_{\text{tot}} = 1/400$.

We have computed in this subsection three specific cases of field-cage problems in the spirit of showing the order of magnitude of the relevant electron displacements. The design of the drift chamber must be such that the displacement Δr induced by such irregularities remains small in comparison to the required accuracy.

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Chapter 4 Amplification of Ionization

4.1 The Proportional Wire

Among all the amplifiers of the feeble energy deposited by a particle on its passage through matter, the proportional wire is a particularly simple and well-known example. When it is coupled with a sensitive electronic amplifier, a few – even single – electrons from the ionization of a particle can be observed, which create ionization avalanches in the high electric field near the surface of the thin wire. The development of the proportional counter started as long ago as 1948; for an early review, see [CUR 58]. The proportional counter is also treated in text books on counters in general, for example those of Korff [KOR 55] and Knoll [KNO 79]. The latter contains a basic list of reference texts. The classical monograph by Raether [RAE 64] deals with electron avalanches in a broader context.

As an electron drifts towards the wire it travels in an increasing electric field E, which, in the vicinity of the wire at radius r, is given by the linear charge density λ on the wire:

$$E = \frac{\lambda}{2\pi\varepsilon_0} \frac{1}{r}$$

In the absence of a magnetic field, the path of the electron will be radial. The presence of a magnetic field modifies the path (as discussed in Chaps. 2 and 7) but, if the electric field is strong enough, the trajectory terminates in any case on the wire.

Once the electric field near the electron is strong enough so that between collisions with the gas molecules the electron can pick up sufficient energy for ionization, another electron is created and the avalanche starts. At normal gas density the mean free path between two collisions is of the order of microns; hence the field that starts the avalanche is of the order of several 10^4 V/cm , and the wire has to be thin, say a few 10^{-3} cm , for 1 or 2 kV.

As the number of electrons multiplies in successive generations (Fig. 4.1), the avalanche continues to grow until all the electrons are collected on the wire. The avalanche does not, in general, surround the wire but develops preferentially on the approach side of the initiating electrons (cf. Sect. 4.3). The whole process

4 Amplification of Ionization

Fig. 4.1 Schematic development of the proportional wire avalanche



develops in the longitudinal direction over as many free paths as there are generations, say typically over 50 to $100\,\mu$ m. This part ends after a fraction of a nanosecond, under normal gas conditions. The physical processes inside the avalanche are quite complicated, as they involve single and multiple ionization, optical and metastable excitations, perhaps recombinations, and energy transfer by collisions between atoms, much the same as discussed in Sect. 1.1. The de-excitation of metastable states may in principle increase the duration of the avalanche up to the collision time between the molecules, but not much is known about this.

The proportional wire owes its name to the fact that the signal is proportional to the number of electrons collected. This proportionality is possible to the extent that the avalanche-induced changes of the electric field remain negligible compared to the field of the wire. Referring to Sect. 4.5.1, we may characterize the regime of proportionality as that in which the charge density in the avalanche is negligible compared with the linear charge density of the wire. The charge density of the avalanche is given by the product of the gain factor and the number of electrons that start the avalanche, divided by its width.

A very interesting role is played by the photons, which are as abundant as electrons because the relevant cross-sections are of the same order of magnitude. A small fraction of them will be energetic enough to ionize the gas, in all probability ionizing a gas component with a low ionization potential. If it now happens that these ionizing photons travel further, on the average, than the longitudinal size of

Fig. 4.2 Mechanism of breakdown by photoionization of the gas outside the cylinder that contains the full avalanche



the avalanche, then the electrons they produce will each give rise to another full avalanche and the counter may break down. In order to formulate a stability criterion, we refer to the avalanche of Fig. 4.2, created by one electron e_1 . Let us call n_e the number of electrons in the avalanche and n_{ph} the number of energetic photons, and use q to denote the average probability that one of them ionizes the gas outside the radius r_{min} . Breakdown occurs if

$$n_{\rm ph}q > 1$$
, $xn_{\rm e}q > 1$

where x is the ratio $n_{\rm ph}/n_{\rm e}$. This ratio may be expected to stay roughly constant as $n_{\rm e}$ is changed by a variation of the wire voltage.



Fig. 4.3a,b Optical properties of chamber gases: (a) Outstanding spectral emission lines of the neutral Ar atom [HAN 81]. The intensities are approximate and are plotted on a logarithmic scale. (b) Absorption cross-sections for UV photons of the normal alkanes [SCH 62]

Methane	CH ₄
Ethane	C_2H_6
Propane	C_3H_8
Butane	$C_{4}H_{10}$
Pentane	C5H12
Isobutane	$(CH_3)_2CHCH_3$
Carbon dioxide	CO_2
Ethylene	$(C_2H_2)_2$
Methylal	$CH_2(CH_2OH)_2$

 Table 4.1 Common quench gases

A similar consideration applies also to photons from the avalanche that reach the conducting surfaces of the cathodes, where they may create free electrons by the photoelectric effect.

It is because of these far-travelling photons that an organic 'quench gas' needs to be present. Its effect is to reduce q allowing larger values of n_e , and hence larger gain. Organic molecules, with their many degrees of freedom, have large photoabsorption coefficients over a range of wavelengths that is wider than that for noble gas atoms. Some examples are given in Fig. 4.3a,b, which also contains a picture of the most prominent emission lines of the argon. The photoabsorption spectrum of argon was shown as a graph in Fig. 1.4 in the context of a calculation of particle ionization. Table 4.1 contains a list of common quench gases. Inorganic quench gases have been studied by Dwurazny, Jelen, and Rulikowska–Zabrebska [DWU 83].

4.2 Beyond the Proportional Mode

If the avalanche amplification is increased beyond the region of proportionality, the space charge of the positive ions *reduces* appreciably the field near the head of the avalanche, that is the field experienced by the electrons between the wire and the positive cloud. The amplification is smaller for any subsequent increment and we are in the regime of 'limited proportionality'.

Near the tail of the avalanche, however, we have an *increase* of the electric field owing to the positive ions, especially once the fast-moving electrons have disappeared into the wire. This situation leads to two different kinds of multiplicative processes, depending on the behaviour of the photons:

• If the UV absorption of the quench gas is very strong, the photons in the avalanche produce ionization near their creation point, including the region near the tail of the avalanche where the electric field is particularly large. This starts the phenomenon of the 'limited streamer', which is a backward-moving multiplication process in the sense of a series of avalanches whose starting points move further and further away from the wire. In a paper by Atac, Tollestrup, and Potter [ATA 82], it is suggested that energetic photons are created by the recombination process with cool electrons when the field at the avalanche head is sufficiently
reduced. Under the influence of the growing charge, the starting points of successive new avalanches move further outwards. Once the streamer has reached a certain length that depends on the wire voltage, typically 1 to 3 mm, it comes to an end. The total charge is almost independent of the amount of charge that originally started the process. Figure 4.4a,b shows a typical pulse height distribution of the limited streamer for individual electrons (b) and for ~100 electrons (a) [BAT 85]: they give approximately the same total charge. The self-quench occurs because the electric field becomes weaker as the avalanches are produced further away from the wire. But the exact mechanism is not well understood. More details can be found in the articles by Alekseev et al. [ALE 80], Iarocci [IAR 83] and Atac et al. [ATA 82] and in the references quoted therein. A summary and overview has been given by Alexeev, Kruglov, and Khazins [ALE 82].

As the high voltage of a wire tube with the correct quenching gas is increased (Fig. 4.5), the collected charge at first follows a nearly exponential mode (proportional mode), then flattens off as the avalanche charge density approaches the wire charge density (limited proportional mode), and then suddenly jumps to the limited streamer mode where the charge multiplication is one and a half orders of magnitude larger. This behaviour is reported in Fig. 4.5. The collected charge continues to rise more slowly up to the general breakdown of the counter. F.E.









Taylor argues that the size of the limited streamer is essentially given by electrostatic considerations [TAY 90].

• If the UV absorption of the gas is so low that ionizing photons can travel distances that are comparable to the counter dimension, then multiplicative processes may develop along the full length of the wire. The wire is said to be in Geiger mode if the external electric circuit terminates the discharge with the help of a large HV feed resistor. The size of the signal is therefore also independent of the original charge. The Geiger counter is described, for example, in [KNO 79] and [KOR 55].

4.3 Lateral Extent of the Avalanche

The electrons from an ionization track, which are collected on a wire and start an avalanche there, do not usually arrive at the same point in space, but there is some spread between them. This happens not only because the track was originally extended in space, and every electron is guided on its drift path to a different place near the wire, but also because of the diffusion in the gas during the drift. The proportional avalanche has a lateral extent that is at least as large as this spread.

In the avalanche process itself there is a lateral development associated with the multiplication of charges, and this is mainly due to diffusion of electrons, the electrostatic repulsion of charges, and the propagation of ionizing photons. The intrinsic lateral size of an avalanche therefore depends on the gas (collision cross-section and

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UV absorption), on the number of charges in the avalanche and their density and on the electron energy that is obtained in the various parts of the multiplication process. If one wants to know whether the charges go fully around the wire or stay on one side, then the wire diameter also plays an important role.

The spread of avalanches on a wire has been studied experimentally by Okuno et al. [OKU 79], by observing the signals from the positive ions in a segmented cathode tube surrounding the wire. In a mixture of $Ar(90\%) + CH_4(10\%)$, the avalanches, created by a ⁵⁵Fe source on a wire of $25\,\mu$ m diameter, occupied only 100° in azimuth (FWHM) in the proportional region (total charge below 10^{6} electrons). When the voltage was raised, the avalanche started to surround the anode wire. Figure 4.6 shows how the azimuthal width increased with the total charge of the avalanche. The increase came at smaller total charges when the concentration of the quenching gas was smaller. The influence of the UV photons was more pronounced at higher charge multiplication. The X-ray photon of the ⁵⁵Fe source has an energy of 5.9 keV and creates approximately 227 electrons. The finite size of the electron cloud produced by the X-ray photon can be neglected.

In a detailed Monte Carlo simulation of the scattering processes involved in the multiplication, Matoba et al. have shown how a small avalanche develops in three dimensions [MAT 85]. In Fig. 4.7 we reproduce a picture of their electron density. In recent years the computational techniques for the simulation of such processes have been considerably advanced; see for example [GRO 89]. We may expect more detailed insight into the dynamics of the avalanche as computer codes are developed that describe not only the various collision phenomena between the electrons, ions and gas molecules but also the important effect of the photons.



Fig. 4.6 Angular spread (FWHM) of the avalanche from ^{55}Fe X-rays in various Ar+CH₄ mixtures as a function of the total charge in the avalanche. The anode wire had a diameter of $25\,\mu\text{m}$ [OKU 79]

Fig. 4.7 Two-dimensional displays of the electron density in a small avalanche created by a Monte Carlo simulation from a single electron. Photon ionization was neglected [MAT 85]



4.4 Amplification Factor (Gain) of the Proportional Wire

The multiplication of ionization is described by the first Townsend coefficient α . If multiplication occurs, the increase of the number of electrons per path ds is given by

$$\mathrm{d}N = N\alpha\,\mathrm{d}s.\tag{4.1}$$

The coefficient α is determined by the excitation and ionization cross sections of the electrons that have acquired sufficient energy in the field. It also depends on the various transfer mechanism discussed in Chap. 1. Therefore, no fundamental expression exists for α and it must be measured for every gas mixture. It also depends on the electric field *E* and increases with the field because the ionization cross-section goes up from threshold as the collision energy ε increases. If the gas density ρ is changed while keeping the distribution of ε fixed (that is, at fixed E/ρ), then α changes proportionally with the density because all the linear dimensions in the gas scale with the mean free collision length (cf. Chap. 2). Therefore we may write the functional dependence of α as

$$\alpha\left(\frac{E}{\rho},\rho\right) = \frac{\alpha_0}{\rho_0}\rho = f\left(\frac{E}{\rho}\right)\rho.$$
(4.2)

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In Fig. 4.8 we show measurements with pure noble gases in the form of α over the gas pressure as a function of the electric field over the gas pressure, at normal temperature, as obtained by von Engel [ENG 56].

The amplification factor on a wire is given by integrating (4.1) between the point S_{\min} where the field is just sufficient to start the avalanche and the wire radius *a*:

$$N/N_0 = \exp \int_{s_{\min}}^{a} \alpha(s) ds = \exp \int_{E_{\min}}^{E(a)} \frac{\alpha(E)}{dE/ds} dE.$$
(4.3)

Here N and N_0 are the final and initial number of electrons in the avalanche; dE/ds is the electric field gradient. The minimal field E_{min} needed for ionization to multiply is given by the energy required to ionize the molecules in question, divided by the mean free path between collisions; therefore E_{min} must be proportional to the gas density.

The electric field near a wire whose radius is small compared with the distance to other electrodes is given by the charge per unit length, λ , as a function of the radius:

$$E(r) = \frac{\lambda}{2\pi\varepsilon_0 r},\tag{4.4}$$

where $\varepsilon_0 = 8.85 \times 10^{-12}$ A s/(V m), and λ can be derived from the wire voltages and the capacitance matrix (cf. Chap. 3). Inserting (4.4) into (4.3) we have

$$N/N_0 = \exp \int_{E_{\rm min}}^{E(a)} \frac{\lambda \alpha(E)}{2\pi \varepsilon_0 E^2} dE.$$
(4.5)

The ratio N/N_0 is usually called *gain*. In the following paragraphs we use $G = N/N_0$ to indicate it.

4.4.1 The Diethorn Formula

Diethorn [DIE 56] derived a useful formula for *G* by assuming α to be proportional to *E*. Looking at Fig. 4.8, this is not unreasonable for heavy noble gases between 10^2 and 10^3 [V/cm Torr], a typical range of fields near thin wires. Inserting $\alpha = \beta E$ into (4.5) gives

$$\ln G = \frac{\beta \lambda}{2\pi\varepsilon_0} \ln \frac{\lambda}{2\pi\varepsilon_0 a E_{\min}}.$$
(4.6)

The value of β can be related in the following way to the average energy $e\Delta V$ required to produce one more electron. The potential difference between r = a and $r = s_{\min}$ that corresponds to relation (4.3) is

$$\Phi(a) - \Phi(S_{\min}) = \int_{a}^{S_{\min}} E(r) dr = \frac{\lambda}{2\pi\varepsilon_0} \ln \frac{S_{\min}}{a} = \frac{\lambda}{2\pi\varepsilon_0} \ln \frac{\lambda}{2\pi\varepsilon_0 aE_{\min}}.$$
 (4.7)

It gives rise to a number Z of generations of doubling the electrons in the avalanche:

$$Z = [\Phi(a) - \Phi(S_{\min})] / \Delta V, \qquad (4.8)$$

$$G = 2^Z, \tag{4.9}$$

$$\ln G = \frac{\ln 2}{\Delta V} \frac{\lambda}{2\pi\varepsilon_0} \ln \frac{\lambda}{2\pi\varepsilon_0 a E_{\min}}.$$
(4.10)

We recognize that in this model the constant β of (4.6) has the meaning of the inverse of the average potential required to produce one electron in the avalanche multiplied by ln 2.

We write E_{\min} , which is proportional to the gas density ρ , in the form

$$E_{\min}(\rho) = E_{\min}(\rho_0) \frac{\rho}{\rho_0},$$
 (4.11)

where ρ_0 is the normal gas density. We finally obtain

$$\ln G = \frac{\ln 2}{\Delta V} \frac{\lambda}{2\pi\varepsilon_0} \ln \frac{\lambda}{2\pi\varepsilon_0 a E_{\min}(\rho_0)(\rho/\rho_0)}.$$
(4.12)

Relation (4.12) was compared with measurements using proportional counter tubes, and was shown to be better than the older models of Rose–Korff and Curran–Craggs; see [HEN 72, WOL 74, KIS 60] and the literature quoted therein. In a proportional counter tube with inner radius *b* and wire radius *a*, the charge density λ is related to the voltage *V* by

4.4 Amplification Factor (Gain) of the Proportional Wire

$$\frac{\lambda}{2\pi\varepsilon_0} = \frac{V}{\ln(b/a)}.$$
(4.13)

Therefore, (4.12) can also be expressed in the following form (Diethorn's formula):

$$\ln G = \frac{\ln 2}{\ln(b/a)} \frac{V}{\Delta V} \ln \frac{V}{\ln(b/a) a E_{\min}(\rho_0)(\rho/\rho_0)}.$$
(4.14)

Experimentally, we vary ρ/ρ_0 , a and $V/\ln(b/a)$, and measure G. A plot of

$$\frac{\ln G \ln(b/a)}{V} \text{ versus } \ln \frac{V}{\ln(b/a)a(\rho/\rho_0)}$$

must be linear and yields the two constants $E_{\min}(\rho_0)$ and ΔV . Figure 4.9 shows such a plot made by Hendricks [HEN 72] for two xenon gas mixtures, and Table 4.2 contains a collection of Diethorn parameters measured in this way, typically for amplification factors between 10^2 and 10^5 . They are only in moderate agreement with each other.

We recognize the value of formulae (4.12) and (4.14), discussed above, more from a practical than from a fundamental point of view. Obviously, for a given gas mixture, the Townsend coefficient $\alpha(E)$ must first be known accurately as a function of the electric field. Then the multiplication factor can be calculated using (4.5). See also Charles [CHA 72] and Shalev and Hopstone [SHA 78], who compared and criticized various formulae for the gas gain.





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Gas mixture	$E_{\min}(\rho_0)$ (k V/cm)	ΔV (V)	Refs.
$Ar(90\%) + CH_4(10\%)$	48± 3	23.6 ± 5.4	HEN 72
$Ar(95\%) + CH_4(5\%)$	45 ± 4	21.8 ± 4.4	HEN 72
CH ₄	69 ± 5	36.5 ± 5.0	HEN 72
C ₃ H ₈	100 ± 4	29.5 ± 2.0	HEN 72
$He(96\%) + (CH_3)_2 CHCH_3(4\%)$	148 ± 2	27.6 ± 3.0	HEN 72
$Ar(75\%) + Xe(15\%) + CO_2(10\%)$	51 ± 4	20.2 ± 0.3	HEN 72
$Ar(69.4\%) + Xe(19.9\%) + CO_2(10.7\%)$	54.5 ± 4.0	20.3 ± 2.5	HEN 72
$Ar(64.6\%) + Xe(24.7\%) + CO_2(10.7\%)$	60 ± 5	18.3 ± 5.0	HEN 72
$Xe(90\%) + CH_4 (10\%)$	36.2	33.9	WOL 74
$Xe(95\%) + CO_2(5\%)$	36.6	31.4	WOL 74
$CH_4(99.8\%) + Ar(0.2\%)$	171	38.3	KIS 60
$Ar(92.1\%) + CH_4(7.9\%)$	77.5	30.2	DIE 56
$CH_4(76.5\%) + Ar(23.5\%)$	196	36.2	DIE 56
$CH_4(90.3\%) + Ar(9.7\%)$	21.8	28.3	DIE 56
$Ar(90\%) + CH_3CH_2OH(10\%)$	62	27.0	DIE 56
CH ₄	144	40.3	DIE 56

Table 4.2 Measured Diethorn parameters for various gases

4.4.2 Dependence of the Gain on the Gas Density

The variation of the gain with the gas density is of particular interest since very often the chambers are operated at atmospheric pressure and the gas density changes proportionally to it. From (4.10) and (4.11), a small relative change $d\rho/\rho$ of the density can be seen to result in a change of amplification of

$$\frac{\mathrm{d}G}{G} = -\frac{\lambda \ln 2}{\Delta V 2\pi\varepsilon_0} \frac{\mathrm{d}\rho}{\rho} \,. \tag{4.15}$$

In practical cases the factor that multiplies $d\rho/\rho$ ranges between 5 and 8: variation of the gas pressure causes global variations of the gain that are typically 5 to 8 times larger. Since the gas pressure can be easily monitored these variations can be corrected for.

4.4.3 Measurement of the Gain Variation with Sense-Wire Voltage and Gas Pressure

In this section we give some measurements of the variation of the gain with the sense wire voltage and with the atmospheric pressure. These measurements have been obtained using prototypes of the ALEPH TPC that had a cell geometry as described in Sect. 3.2.

Figure 4.10 shows a plot of the gain as a function of the voltage (cf. (4.14)) using the Diethorn parameters for an Argon (90%)–CH₄(10%) mixture (cf. Table 4.2) and





assuming atmospheric pressure. The two side-lines show the large uncertainty in the prediction of the gain owing to the large error (20%) in ΔV . The superimposed experimental points have been measured with a chamber under the same operating conditions. The agreement is very good.

Figure 4.11 shows the variation of the atmospheric pressure p over a period of 2 days (a) and the corresponding average pulse height measured by the chamber when detecting the electrons produced in the gas by the absorption of X-rays from a 55 Fe source (b). One notices how the measured pulse height follows the variations of the pressure (note the zero-suppressed scales of the two plots). The chamber was operated in an Argon (90%)–CH₄(10%) mixture. The sense-wire voltage was 1.4 kV and the field wires were grounded. Using Table 3.5 we can compute the linear charge density λ of the sense wires and from the measured value of ΔV



Fig. 4.11 (a) Atmospheric pressure p as a function of the time in a time interval of two days. (b) Average pulse-height measured by the chamber in the same period. Measurements done with the ALEPH TPC

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(cf. Table 4.2) using (4.15) we predict that

$$\frac{\mathrm{d}G}{G} = -(6.7 \pm 1.5)\frac{\mathrm{d}p}{p}\,.$$

Inspecting Fig. 4.11 a we read an overall change of pressure of 0.8% and predict a change of gain of $-(5.5 \pm 1.2)$ %, in agreement with the variation (-4%) shown in Fig. 4.11b.

4.5 Local Variations of the Gain

Equation (4.12) shows that the gain depends on the local charge density of the wire λ . A relative change $d\lambda/\lambda$, as may result from geometrical imperfections of a wire chamber, from fluctuations of the supply voltage, or from space charge near the wire will change the amplification by the factor [cf. (4.12)]

$$\frac{\mathrm{d}G}{G} = \left(\ln G + \frac{\lambda \ln 2}{\Delta V 2\pi\varepsilon_0}\right) \frac{\mathrm{d}\lambda}{\lambda}.$$
(4.16)

In practical cases the two factors in the parentheses of the previous equation are of the same order of magnitude and their sum lies in the range 10–20: the local relative variations of the charge density cause local relative variations of the gain that are typically 10–20 times greater.

In Sect. 3.2 we saw how the linear charge density λ depends on the potentials and on the geometry of the wire chamber, assuming that there is an ideal geometry. Real chambers deviate from the ideal geometry: the wires are not infinite and we can expect changes in the charge density in the region close to the wire supports. Moreover, the mechanical components of the chamber have small construction imperfections, which can induce local changes in the charge density along the wire. The mathematical solution of the electrostatic problem is not simple because as soon as we introduce variations in the ideal geometry we lose the symmetry of the boundary conditions.

In drift chambers that are operated in high-density particle fluxes there is another problem: the local charge density on the wire seen by ionization electrons when they reach the wire can be modified by the presence of the ions which were produced in a previous avalanche and still are drifting inside the drift cell.

4.5.1 Variation of the Gain Near the Edge of the Chamber

In wire chambers the gain usually drops to zero near the support frame. This behaviour depends on the details of the geometry and extends over a region of the wire comparable to the distance between the sense-wire grid and the cathode plane.

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Fig. 4.12 Measured pulse heights of wire signals created by a laser beam near the wire support frame as a function of the distance between the frame and the laser beam. Guard strips can extend the sensitive length of the wire. The distance between neighbouring grids was 4 mm [BRA 85]

Figure 4.12 from [BRA 85] shows the relative variation of the gain near the edge of a wire chamber.

The dependence of the wire gain on the distance from the chamber edge can be modified by the addition of field correction strips [BRA 85], [AME 86c], which can be trimmed to an appropriate voltage to modify the electric field in the region of the frame and to obtain a more uniform charge density (see Fig. 4.12).

4.5.2 Local Variation of the Gain Owing to Mechanical Imperfections

Here we want to evaluate the extent to which small deviations from the ideal geometry can affect the charge density on the sense wires, and we refer again to the example discussed in Sect. 3.2. The problem has been extensively studied by Erskine [ERS 72], and we refer to his paper for a general discussion.

The order of magnitude of the charge variation induced by some imperfections of the chamber can be obtained using the general formulae of Sect. 3.2: this is possible for imperfections that can be approximated to a large extent as a global variation of the geometry of the chamber. For example, the effect of a bump in the cathode plane can be evaluated from the global effect of a reduction of the distance between the sense-field grid and the cathode plane.

In the following we refer to the notation of Sect. 3.2 and to the geometry sketched in Fig. 3.4. Equation (3.39) gives the potentials of the electrodes as a function of

their charges and of the matrix of the potential coefficients A:

$$V = A\sigma, \qquad (4.17)$$

where the $\sigma_i = \lambda_i / S_i$ are the linear charge densities on the wires of each grid divided by the pitch of the grid. A change in the geometry of the wire chamber induces a change in the matrix. Differentiating (4.17) with the fixed values of the potential *V*, we obtain

$$A d\sigma = -dA\sigma$$

where $d\sigma$ is the vector of the charge-density variations and dA is the matrix of the variations in the potential coefficients induced by a particular change in the geometry of the chamber. Using the previous equation, we obtain

$$\mathrm{d}\sigma = -A^{-1}\mathrm{d}A\sigma\,.\tag{4.18}$$

As a first example we calculate the charge-density variation induced by a displacement of the cathode plane. The matrix dA can be calculated by differentiating (3.41) with respect to z, noting that the effect of a displacement dz of the cathode plane changes z_1 and z_2 by the same amount (cf. Fig. 3.4):

$$dA = -\frac{dz}{\varepsilon_0} \begin{pmatrix} 1 & 1 & 1\\ 1 & 1 & 1\\ 1 & 1 & 1 \end{pmatrix}.$$
 (4.19)

From (4.18),

$$d\sigma = \frac{dz}{\varepsilon_0} A^{-1} \begin{pmatrix} \sigma_s + \sigma_F + \sigma_z \\ \sigma_s + \sigma_F + \sigma_z \\ \sigma_s + \sigma_F + \sigma_z \end{pmatrix}.$$
 (4.20)

In the approximations of Sect. 3.2 the quantity $\sigma_s + \sigma_F + \sigma_z$ is the charge density on the cathode plane. The charge-density variation $d\sigma$ induced by a displacement of the cathode plane vanishes if there are no charges on the plane. In the particular geometry of the example considered in Sect. 3.2, we obtain:

$$\mathrm{d}\sigma_{\mathrm{s}} = (70\,\mathrm{m})^{-1}\mathrm{d}z(\sigma_{\mathrm{s}} + \sigma_{\mathrm{F}} + \sigma_{\mathrm{z}})$$

As another example we now compute the charge variation induced by a change in the sense-wire diameter. Differentiating (3.41) with respect to the sense-wire radius r_s yields

$$dA = -\frac{s_1}{2\pi\varepsilon_0} \frac{dr_s}{r_s} \begin{pmatrix} 1 & 0 & 0\\ 0 & 0 & 0\\ 0 & 0 & 0 \end{pmatrix}, \qquad (4.21)$$

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and

$$\mathrm{d}\,\boldsymbol{\sigma} = -\frac{s_1}{2\pi\varepsilon_0} \frac{\mathrm{d}r_{\mathrm{s}}}{r_{\mathrm{s}}} A^{-1} \begin{pmatrix} \boldsymbol{\sigma}_{\mathrm{s}} \\ \boldsymbol{0} \\ \boldsymbol{0} \end{pmatrix}. \tag{4.22}$$

For the particular example considered in Sect. 3.2 we get

$$\frac{\mathrm{d}\sigma_{\mathrm{s}}}{\sigma_{\mathrm{s}}} = 0.16 \frac{\mathrm{d}r_{\mathrm{s}}}{r_{\mathrm{s}}}$$

The effect of the displacement of a single wire is more difficult. In this case we cannot use (3.41) because it was calculated for a set of symmetric grids, and this symmetry is lost when a single wire is displaced. We note that in first order the displacement of a wire does not affect the charge density of the wire itself (again because of the symmetry), but only that of other wires close to it. The displacement of a field wire change the charge density of the two closest sense wires proportionally to its own charge density. If there is no charge density on the field wires, their displacement does not affect the gain of the chamber.

Table 4.3 shows the gain variations induced by mechanical imperfections in the geometry of the example discussed here. We have assumed that the setting of the voltages produces a gain of 10^4 , and using (4.16) we compute the relation between the relative variation of the gain and the local relative charge-density variation:

$$\frac{\mathrm{d}G}{G} = (15.9 \pm 1.5) \frac{\mathrm{d}\sigma_{\mathrm{s}}}{\sigma_{\mathrm{s}}}$$

The same gain can be obtained for different settings of the sense-wire voltage (V_s) and the field-wire voltage (V_F) that leave the charge density on the sense wire σ_s unchanged. Using Table 3.3 we compute the condition of constant gain:

$$0.25V_{\rm s} - 0.11V_{\rm F} = \text{constant}$$
.

The different settings correspond to different values of the ratio σ_F/σ_s . Again using Table 3.3 we deduce that if $V_F/V_s = 0$, then $\sigma_F/\sigma_s = -0.44$, while $\sigma_F/\sigma_s = 0$ when $V_F/V_s = 0.34$. As shown in Table 4.3 the ratio σ_F/σ_s influences the local variations of the gain that are due to mechanical imperfections.

Table 4.3 Gain variation dG/G induced by mechanical imperfections in the geometry discussed in Sect. 3.2. A gain of 10^4 is assumed and all displacements (Δ) are in mm. σ_F/σ_s is the ratio between the charge densities on the field wires and the sense wires

Imperfection	$\mathrm{d}G/G$
Bump on the pad plane	$0.69\Delta z(1+\sigma_{\rm F}/\sigma_{\rm s})$
Displacement of a field wire	$1.1\Delta x \sigma_{\rm F}/\sigma_{\rm s}$
Displacement of a sense wire	$0.2\Delta x$
Variation of the sense wire diameter	$2.5\Delta r/r$

4.5.3 Gain Drop due to Space Charge

When the avalanche has come to an end, all electrons are collected on the anode and the space near the wire is filled with the remaining positive ions. We may assume that in the regime of proportional wire amplification, the amount of charge in the avalanche is small compared to the charge on the wire (integrated along the wire over the lateral extent of the avalanche). The positive ions are moving away from the wire at relatively low speed. With a mobility of a few cm/s per V/cm, a typical speed near the thin wire ($E \sim 2 \times 10^5 \text{ V/cm}$) would be several 10^5 cm/s , and a hundred times less at a hundred times the radius. The avalanche charge obviously takes hundreds of microseconds to settle on a cathode several millimetres away.

When there is a continuous particle flow with a much higher frequency than that corresponding to the ion travel time, we have a stationary situation, and the travelling ions build up a stationary space charge density $\rho(x)$ in the chamber volume. This reduces the electric field close to the wire and therefore the gas gain, which poses a fundamental limitation on the rate capability of any wire chamber.

In order to calculate ρ we consider in Figure 4.13 a small area A_1 of the wire surface which shows an electric field E_1 and which releases positive ions of charge q at a constant rate v. The ions are moving with a velocity of $v = \mu E_1$ where μ is the ion mobility. Within a time Δt , the charge $Q_1 = qv\Delta t$ is entering the volume $V_1 = A_1v\Delta t$, which results in a charge density of $\rho_1 = Q_1/V_1 = qv/\mu E_1A_1$ close to the wire surface. As the ions are moving away from the wire along the electric field lines they are passing an equipotential area A_2 in a field E_2 , and the charge density at this position is $\rho_2 = qv/\mu E_2A_2$. From Gauss' Law we know that $E_2A_2 - E_1A_1 = Q/\epsilon_0$, where Q is the total charge contained in the 'flux tube' between A_1 and A_2 . If the electric field due to the space charge is small compared to the electric field



Fig. 4.13 Anode wire with some field lines (continuous) and some equipotential lines (broken). The A's symbolize the areas of the equipotential surfaces between the same field lines that come from the border of the original area A_1 on the wire surface. The E's represent the fields on the equipotential surfaces. As the ions travel along the field lines they become slower by the same factor as the field lines go apart, resulting in a constant charge density in the volume ('flux tube') filled with ions originating from A_1

from the wire, which is usually the case, we may neglect Q and obtain in first order that

$$E_1A_1 = E_2A_2$$
 and therefore $\rho_1 = \rho_2$.

We have found the remarkable result that the charge density is constant along the entire 'flux tube' at any distance from the wire. In case the electric field E_1 and the ion flux v are uniform around the wire surface, which is a common case, we find a constant charge density in the *entire* volume that is filled by the field lines originating from the wire.

For a wire of radius a with a surface field of E_1 , a charge deposit q at a rate of R per unit length of the wire we therefore find a uniform space charge density of

$$\rho = \frac{qR}{\mu E_1 2a\pi}.\tag{4.23}$$

Next we investigate the gas gain drop due to the presence of ρ . Setting a wire to potential V_0 amounts to placing a certain charge λ on the wire. The charge density ρ creates an electric field $E_s(\mathbf{x})$ which is superimposed on the electric field of the wire charge λ . The resulting potential difference due to ρ is $\Delta V = \int E_s(\mathbf{x}) ds$, where the path of integration is taken from the wire surface to the cathode. Consequently the wire charge λ is reduced such that its contribution to the potential is $V_0 - \Delta V$. The gain reduction due to the space charge ρ is therefore equal to a voltage reduction of ΔV in the absence of space charge. This effective voltage drop of the wires in a chamber is therefore calculated in first order by removing all wires and calculating the potential difference between wire positions and cathode due to the charge density ρ . We will now discuss two examples.

First we examine a drift tube (cf. Section 3.1) exposed to a particle flux of Φ per unit detector area and a total avalanche charge of q per particle. With $R = 2b\Phi$ and the wire surface field of $E_1 = V_0/(a \ln \frac{b}{a})$ we find the uniform space charge density

$$\rho = \frac{bq\Phi \ln \frac{b}{a}}{\pi\mu V_0}.$$
(4.24)

In the absence of the wire, ρ produces an electric field of $E_s(r) = \rho r/2\varepsilon_0$, so the potential difference between wire position and tube wall is

$$\Delta V = \int_0^b E_s(r) dr = \rho b^2 / 4\varepsilon_0 = \frac{b^3 q \Phi \ln \frac{b}{a}}{4\pi\varepsilon_0 \mu V_0}.$$
(4.25)

The voltage drop is proportional to the third power of the tube radius, so a reduction of the tube radius is the most effective way to increase the rate capability. As an example, Fig. 4.14 shows the gain reduction in the drift tubes of the ATLAS muon spectrometer [ATL 00]. The measurements are well explained by the theory outlined above.

As a second example we investigate a wire chamber schematically shown in Fig. 4.15, where a row of wires with a pitch of *s* is positioned symmetrically between two grounded cathode planes at a distance *h*. Setting all wires to potential V_0 ,



Fig. 4.14 Calculated and measured gain drop in drift tubes due to photon background in the ATLAS muon spectrometer. The parameters are b = 15mm, $a = 25\mu$ m, $V_0 = 3170$ V, $\mu = 0.55cm^2/Vs$. The gain of 2×10^4 and primary charge deposit of 1400 electrons/photon yields q = 4.5 pC. A rate of R = 1000 Hz/cm results in a voltage drop $\Delta V = -17V$ and therefore a gas gain reduction of 10%

the electric field on the wire surface is given by $E_1 = V_0/a \log \frac{r_c}{a}$ where r_c is a length with an average value of the same order of magnitude as *s* and *h*. A particle flux of Φ results in $R = s\Phi$ and we therefore have a uniform charge density of

$$\rho = \frac{sq\Phi \ln \frac{r_c}{a}}{2\pi\mu V_0}.\tag{4.26}$$

The electric field due to the charge density ρ in the absence of the wires is given by $E(z) = \rho z / \varepsilon_0$, and the resulting potential difference is

$$\Delta V = \int_0^h E(z) dz = \frac{h^2}{2\varepsilon_0} \rho = \frac{sh^2 q \Phi \ln \frac{r_c}{a}}{4\pi\varepsilon_0 \mu V_0}.$$
(4.27)

As before, the voltage drop mainly depends on the chamber dimensions s and h which must be small for a high rate capability of the wire chamber.

One should be aware of the fact that the ion mobility μ is often not known very well due to the presence of charge transfer in the migration of ions. This was elaborated on the last pages of Sect. 2.2.2.

Fig. 4.15 Multiwire proportional chamber

z = h							
Z = 0	Ð	S•	۰	0	۰	۰	

4.6 Statistical Fluctuation of the Gain

The gain of an avalanche is equal to the number of ion pairs within it divided by the number of electrons that started the avalanche. In the regime of proportionality, the average number of electrons produced in the avalanche is proportional to the number of initial electrons. We are interested in the fluctuation in the number of electrons that is caused by the random nature of the multiplication process.

We may assume that each initiating electron develops its own small avalanche, independent of the presence of the others nearby. If we want to know the probability distribution of the number N of the ions in the total avalanche we simply sum over the probability distribution P(n) of the number n of electrons in the individual small avalanches. The first step is to find an expression P(n), which is done in the following sections.

If the number k of initiating electrons is large, the central-limit theorem of statistics, which makes a statement about the distribution function F(N) of the sum N, applies:

$$N = n_1 + n_2 + n_3 + \ldots + n_k, \tag{4.28}$$

where each of the independent variables n_i has the distribution function P(n). If the mean of P(n) is called \overline{n} and the variance is σ^2 , then the central-limit theorem states that in the limit of $k \to \infty$, F(N) is a Gaussian:

$$F(N) = \frac{1}{S\sqrt{2\pi}} \exp\left[(N - \overline{N})^2 / 2S^2\right]$$
(4.29)

with

$$\overline{N} = k\overline{n}$$
 and $S^2 = k\sigma^2$. (4.30)

This means that the exact shape of P(n) is not needed for the distribution of avalanches started by a large number of electrons. On the other hand, P(n) is particularly interesting for drift chambers where individual ionization electrons have to be detected, as in ring-imaging (RICH) counters.

Single-electron spectra and avalanche fluctuations in proportional counters have been measured by Hurst et al., using laser resonant ionization spectroscopy (RIS) [HUR 78] and by Schlumbohm [SCH 58], whose data are discussed later. A review of single-electron spectra is given by Genz [GEN 73].

Statistical fluctuations of the gain may be influenced by chemical reactions associated with the formation of avalanches. Such deterioration of performance occurs either through deposits on old wires or through the presence of small contaminations of the gas. A discussion of these effects is given in Sect. 12.6; we refer especially to Fig. 12.7. Here we assume that the proportional wire is in an unperturbed working condition.

4.6.1 Distributions of Avalanches in Weak Fields

In this section we investigate the fluctuation of avalanches started by single electrons in weak electric fields, where the assumption holds that the average distance between ionizing collisions $1/\alpha$ is large compared to the distance $x_0 = U_i/E$ which an electron of zero energy has to travel before reaching the ionization potential U_i of the gas [SNY 47] [WIJ 49] [LEG 55]. In this case the probability for an ionizing collision in a spatial interval ds is $p = \alpha ds$, independent of the electron's 'history' (see Sect. 4.6.3 for details). We assume a single electron starting at position s = 0and moving along a coordinate s, where it experiences an electric field E(s) and a Townsend coefficient $\alpha(s)$. Equation 4.3 tells us that at position s we will find on average $\overline{n}(s) = \exp(\int_0^s \alpha(s')ds')$ electrons. Since the multiplication is a statistical process, the true number will fluctuate around this average, and we are looking for P(n,s), the probability of finding n electrons at a position s. With the above assumptions ($p = \alpha ds$), we have the following probability of finding n electrons at position s + ds:

$$P(n,s+ds) = P(n-1,s)(n-1)p(1-p)^{n-2} + P(n,s)(1-p)^n$$
(4.31)

The first term on the right-hand side represents the probability that we find n-1 electrons at *s* and exactly one of them duplicates; the second term represents the probability that there are already *n* electrons and no duplication takes place. All other possibilities are of order ds^2 and higher. Expanding the above expression for small values of *ds* yields the equation

$$\frac{dP(n,s)}{ds} = P(n-1,s)(n-1)\alpha(s) - P(n,s)n\alpha(s), \qquad (4.32)$$

with the conditions P(1,0) = 1 and P(n,0) = 0 for n > 1. If we write the equation in terms of a transformed variable $u = \int_0^s \alpha(s') ds'$, it assumes the simpler form

$$\frac{dP(n,u)}{du} = P(n-1,u)(n-1) - P(n,u)n.$$
(4.33)

For the beginning of the process, we have the equation

$$\frac{dP(1,u)}{du} = -P(1,u) \qquad \text{and therefore} \qquad P(1,u) = e^{-u}. \tag{4.34}$$

The probabilities for n > 0 are calculated by inserting P(1, u) into Eq. (4.32) and iterating the procedure, which yields

$$P(n,u) = e^{-u} (1 - e^{-u})^{n-1}.$$
(4.35)

Returning to the variable *s*, we finally get

$$P(n,s) = \frac{1}{\overline{n}(s)} \left(1 - \frac{1}{\overline{n}(s)} \right)^{n-1} \qquad \overline{n}(s) = \exp(\int_0^s \alpha(s') ds'). \tag{4.36}$$

We see that the probability distribution depends only on \overline{n} and not explicitly on s, which means that the avalanche distribution has the same shape at every stage of the avalanche and for any coordinate dependence of α . The variance of the

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distribution is

$$\sigma(s)^{2} = \sum_{n=1}^{\infty} n^{2} P(n,s) - \overline{n}(s)^{2} = \overline{n}(s) \left(\overline{n}(s) - 1\right).$$
(4.37)

In the limit of $\overline{n} \to \infty$, which is quite appropriate for avalanches, the expressions become

$$P(n,s) = \frac{1}{\overline{n}(s)} e^{-\frac{n}{\overline{n}(s)}} \qquad \sigma(s) = \overline{n}(s).$$
(4.38)

The equations tell us that the avalanche process has an exponential signal distribution, small signals being most probable, and that the r.m.s. width is equal to the mean (Yule-Furry law). The pulse-height distribution is purely monotonic and shows no peak. This is actually confirmed by experiment; see the measurements described in Sect. 4.6.3 (Fig. 4.16a).

4.6.2 Distributions of Avalanches in Electronegative Gases

Gases containing electronegative components will attach electrons during the development of the avalanche and this will affect the gain fluctuations. We therefore introduce an attachment coefficient η [LEG 61]. Just as the expression αds represents the probability that an electron experiences an ionizing collision in a spatial interval ds, forming an electron and a positive ion, the value ηds represents the probability that an electron attaches in a spatial interval ds, forming a negative ion. The average number of electrons $\overline{n}(s)$ and positive ions $\overline{m}(s)$ is therefore defined by the relation $d\overline{n} = (\alpha - \eta)\overline{n}ds$ and $d\overline{m} = \alpha \overline{n}ds$, which, for the average number of electrons, yields

$$\overline{n}(s) = \exp \int_0^s (\alpha(s') - \eta(s')) ds'$$
(4.39)

The average number of negative ions is then $\overline{m} - \overline{n}$. The value $\alpha - \eta$ is called the 'effective' Townsend coefficient. In order to arrive at the avalanche distribution we proceed as before. There are four possibilities for *n* electrons to arrive at position s + ds: (1) From *n* electrons, one multiplies and one attaches; (2) from *n* electrons, none multiplies and none attaches; (3) from n - 1 electrons one multiplies and none attaches. In first order of *ds* this reads as

$$\frac{dP(n,s)}{ds} = P(n-1,s)(n-1)\alpha - P(n,s)n(\alpha+\eta) + P(n+1,s)(n+1)\eta. \quad (4.40)$$

Since $\alpha(s)$ and $\eta(s)$ generally have a different functional dependence on the electric field and thus on *s*, we cannot transform the equation into a simple form as before. We therefore assume α and η to be constant, meaning that the following solutions are only valid for a constant electric field. According to Legler [LEG 61] the solution of Eq. (4.40) is

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$$P(n,s) = k \frac{\overline{n}(s) - 1}{\overline{n}(s) - k} \qquad n = 0$$

$$= \overline{n}(s) \left(\frac{1 - k}{\overline{n}(s) - k}\right)^2 \left(\frac{\overline{n}(s) - 1}{\overline{n}(s) - k}\right)^{n-1} n > 0 \qquad (4.41)$$

where we have defined $k = \eta/\alpha$. The variance of this distribution is $\sigma^2 = \overline{n}(\overline{n} - 1)(1+k)/(1-k)$. For large values of \overline{n} we find P(0,s) = k, and for n > 0 we find

$$P(n,s) = \frac{(1-k)^2}{\overline{n}(s)} \exp\left[-(1-k)\frac{n}{\overline{n}(s)}\right] \qquad \sigma^2(s) = \frac{1+k}{1-k}\overline{n}(s)^2. \tag{4.42}$$

The attachment therefore results in the probability $k = \eta/\alpha$ that one ends up with zero electrons. Compared to the situation without attachment, the distribution is still exponential and the r.m.s. is increased by the factor $\sqrt{(1+k)/(1-k)}$. Averaging only over avalanches with n > 0, we find the average number of electrons $\overline{n}^*(x) = \overline{n}(x)/(1-k)$ and a variance of $\sigma(x)^2 = \overline{n}^*(x)^2$. We conclude that the effect of attachment increases the avalanche fluctuations and results again in an exponential signal distribution.

4.6.3 Distributions of Avalanches in Strong Homogeneous Fields

Figure 4.16a-e shows measurements taken in parallel-plate geometry in methylal vapour for five different fields of increasing strength. For a weak field there is the purely exponential distribution. As the field is increased a depletion at small numbers of ions is visible, becomes more and more pronounced, and produces a clear peak at high electric fields. All of these curves display an approximate exponential decrease at the upper end which becomes steeper for higher E.

A quantitative explanation of these measurements was given by Legler [LEG 61] in terms of the parameter

$$\chi = \frac{\alpha(E)U_i}{E},\tag{4.43}$$

where *E* is the electric field, α the first Townsend coefficient, and U_i the ionization potential of the gas. Owing to the dependence of α on *E* (Fig. 4.8), χ usually increases with increasing *E*.

The electron that causes an ionizing collision loses at least the energy e_0U_i in the collision, and a new electron with nearly zero energy joins the avalanche. The new electron has to travel a distance greater than $x_0 = U_i/E$ in order to have a non-zero probability for ionization. In case this distance x_0 is small compared to the average

Fig. 4.16a-e Distribution of numbers of ions in avalanches started by single electrons as measured by Schlumbohm [SCH 58] in methylal, in parallel-plate geometry, for various values of χ : (a) $\chi = 0.038$, (b) $\chi = 0.044$, (c) $\chi = 0.095$, (d) $\chi = 0.19$, superimposed on the theoretical curve by Legler, dotted (see text), (e) $\chi = 0.24$

distance $1/\alpha$ between ionizing collisions, which means that $\chi = \alpha x_0 \ll 1$, the assumption used in the previous sections, is valid and the avalanche distribution has an exponential form. In case x_0 is comparable to $1/\alpha$, meaning that χ approaches 1, the avalanche fluctuations will be altered.

Denoting the distance of an electron from the last ionizing collision as ξ and assuming that the probability of ionization per unit path length depends on ξ as

$$a(\xi) = 0 \qquad \xi < U_i/E$$

$$= a_0 \qquad \xi \ge U_i/E,$$
(4.44)

one can calculate avalanche distributions for different values of χ , and these are plotted in Fig. 4.17. Legler has shown that they are in good agreement with experimental spectra taken in homogeneous fields, as long as χ (4.43) increases with increasing *E*. As an example, he superimposed the calculated distribution curve for $\chi = 0.18$ on Schlumbohm's data measured at $\chi = \alpha U_i/E = 0.19$ (see Fig. 4.16d).

In this model, the avalanche grows exponentially according to $\exp(\alpha s)$, and it can be shown that α and a_0 are connected by

$$a_0=\frac{\alpha}{2e^{-\alpha x_0}-1}.$$

For the parameter $\chi = \alpha x_0$ this defines the condition $0 \le \chi \le \log 2$. Although an explicit expression for Legler's probability distribution does not exist, Alkhazov [ALK 70] was able to calculate all the moments of the distribution for large values of \overline{n} and gave a value for the variance of $\sigma^2 = \overline{n}^2 f_0$ with

$$f_0(\chi) = \frac{(2e^{-\chi} - 1)^2}{4e^{-\chi} - 2e^{-2\chi} - 1} \approx (2e^{-\chi} - 1)^2.$$
(4.45)



Fig. 4.17 Distribution functions according to Legler's model for different values of $\chi \equiv \alpha x_0$. The number v of electrons is plotted in terms of the average

For small values of χ we have $f_0 = 1$, reproducing the Yule-Furry law. For increasing values of χ , the value f_0 and thus the variance decrease monotonically.

4.6.4 Distributions of Avalanches in Strong Non-uniform Fields

For non-uniform fields, which is the relevant case for wire chambers, the full range of electric fields must be taken into account and χ and α are functions of the coordinate *s*. Alkhazov [ALK 70] showed that for large values of \overline{n} the variance of the avalanche distribution is given by $\sigma^2 = \overline{n}^2 f$, where

$$f = \int_0^s f_0[\chi(s')] \,\alpha(s') \exp\left(-\int_0^{s'} \alpha(s'') ds''\right) ds'.$$
(4.46)

By also calculating the higher moments of the distribution function Alkhazov showed that the 1/r dependence of the electric field in the vicinity of a sense wire together with the 'typical' dependence of the Townsend coefficient on the electric field results in a distribution that closely resembles a Polya distribution, defined for large *n* by

$$P(n) = \frac{1}{\overline{n}} \frac{(\theta+1)^{\theta+1}}{\Gamma(\theta+1)} \left(\frac{n}{\overline{n}}\right)^{\theta} e^{-(\theta+1)n/\overline{n}} \qquad \sigma^2 = \overline{n}^2/(\theta+1).$$
(4.47)

This was also verified by measurements from Curran [CUR 49]. For $\theta = 0$ the Polya distribution represents the exponential distribution. For argon and methane, Alkhazov calculates values of f = 0.6-0.8 for gas gains in the range 10^2-10^5 . With $f = 1/(\theta + 1)$ for the Polya distribution we thus have values of θ in the range of 0.25–0.67. Polya functions are depicted in Fig. 4.18.

We conclude this section by noting that the Polya distribution is frequently also used to describe the avalanche fluctuations in homogeneous fields. Although a physical justification for this approach was attempted [BYR 62], it was strongly criticized on theoretical grounds [LEG 67] [ALK 70]. It was also shown that the Polya distribution deviates from the measured spectra for homogeneous fields [LEG 67]. For many practical applications the difference in shape between the curves of Figs. 4.17 and 4.18 is not relevant.

4.6.5 The Effect of Avalanche Fluctuations on the Wire Pulse Heights

Let each electron create an avalanche of average size *h* (a large number), distributed according to a density function $e_h(k)$ which has some variance σ_e^2 . As an example, we may imagine e_h to be the exponential distribution $e_h(k) = (1/h) \exp(-k/h)$ that has $\sigma_e = h$ or one of the Polya distributions discussed in Sect. 4.6.4. In any case,



 σ_e will vary together with *h*, as larger avalanches can be expected to have larger fluctuations. If there is a fixed number *n* of electrons to create an avalanche, the resulting average avalanche size on a proportional wire is *nh*, the variance being $n\sigma_e^2$.

If the number *n* is not fixed but is itself subject to fluctuations around a mean *m* with variance σ_m^2 , then the mean and the variance of the resulting number of electrons at the wire are

$$N_e = mh, \qquad (4.48)$$

$$\sigma^2 = m\sigma_e^2 + h^2 \sigma_m^2. \tag{4.49}$$

4.6.6 A Measurement of Avalanche Fluctuations Using Laser Tracks

A simple method that is close to the practice of recording particle tracks is to compare the pulse heights of many wires that record a laser track. The ionization of the gas by a beam of pulsed laser light is described in more detail in Chap. 1. The electrons along the beam are created independently; hence the numbers that arrive on each wire are randomly distributed according to Poisson's law, with a mean common to all the wires (provided the light beam is sufficiently uniform). The basic idea is to observe how much more the pulse heights fluctuate owing to the presence of the term containing σ_e^2 in (4.49).

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For the case at hand, in which the number of ionization electrons that start the avalanche is Poisson-distributed, we have $\sigma_m^2 = m$. The measured pulse height *P* is proportional to the avalanche size; let the constant of proportionality be called *a* – it could have the dimension volts per electron. Then the mean and the variance of the pulses created by these electrons are

$$\langle P \rangle = aN_e = amh, \qquad (4.50)$$

$$\sigma_P^2 = a^2 \sigma^2 = a^2 m \sigma_e^2 + a^2 m h^2.$$
(4.51)

In order to determine σ_e^2 experimentally, we measure the ratio $R = \sigma_P^2 / \langle P \rangle^2$ for various *m*:

$$R = \frac{1 + \sigma_e^2 / h^2}{m} \,. \tag{4.52}$$

This can be achieved by varying the laser intensity using grey filters. The track from one or several shots of the same intensity that lead to the same *m* are measured on a number of wires *K* (measured pulse heights P_i (i = 1, 2, ..., K)). The average pulse height is given by

$$\langle P \rangle = \sum_{i} \frac{P_i}{K} \tag{4.53}$$

and the ratio R by

$$R = \sum_{i} \frac{(P_i - \langle P \rangle)^2}{K \langle P \rangle}.$$
(4.54)

The value of *m* can be obtained from the pulse height by calibration with a ⁵⁵Fe radioactive source. Since the peak of the spectrum is at m = 227 in Ar, a pulse height *P* corresponds to

$$m = 227 \frac{P}{P_{\text{peak}}}$$

In an experiment using the TPC 90 model of the ALEPH TPC with approximately 100 wires, the ratio *R* was measured as a function of 1/m (Fig. 4.19), and a straight-line fit gave



Fig. 4.19 Square of the measured relative pulse-height variation as a function of the inverse number of primary electrons

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$$R = 2.2 \times \frac{1}{m} + 0.003$$

The constant term represents an intrinsic pulse-height variation from wire to wire owing to the apparatus, whereas the measured slope implies a value of

$$\sigma_e^2 = 1.2 h^2$$
 or $\sigma_e = 1.1 h$,

using (4.52). This determination of σ_e is roughly 10% accurate.

Within the limits of this simple experiment, we may conclude that the variance of the single-electron avalanche was equal to that of the Yule–Furry process.

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Chapter 5 Creation of the Signal

The moving charges in a chamber give rise to electrical signals on the electrodes that can be read out by amplifiers. The electrons created in the avalanche close to the wire move to the wire surface within a time typically much less than a nanosecond, resulting in a short signal pulse. The ions created in the avalanche move away from the wire with a velocity about a factor 1000 smaller, which results in a signal with a long tail of typically several hundred microseconds duration. The movement of these charges induces a signal not only on the wire but also on the other electrodes in the chamber, so for the purpose of coordinate measurements the cathode can be subdivided into several parts. In this chapter we derive very general theorems that allow the calculation of signals in wire chambers and present some practical examples.

5.1 The Principle of Signal Induction by Moving Charges

In order to understand how moving charges give rise to signals on electrodes we first consider the simple example shown in Fig. 5.1a [JAC 75]. A point charge q in the presence of a grounded metal plate induces a charge on the metal surface. This surface charge can be calculated by solving the Poisson equation for the potential ϕ with a point charge q at $z = z_0$ and the boundary condition that $\phi = 0$ at z = 0. Gauss' law tells us that the resulting electric field $\mathbf{E} = -\nabla\phi$ on the metal surface is related to the surface charge density σ by $\sigma(x,y) = \varepsilon_0 E(x, y, z = 0)$. The solution for this particular geometry can be found by assuming a mirror charge -q at $z = -z_0$. The electric field on the metal surface is thus given by

$$E_z(x,y) = -\frac{qz_0}{2\pi\varepsilon_0(x^2 + y^2 + z_0^2)^{\frac{3}{2}}} \qquad E_x = E_y = 0,$$
(5.1)

and the surface charge density is $\sigma(x, y) = \varepsilon_0 E_z(x, y)$. The total charge induced on the metal plate is therefore



Fig. 5.1 (a) A point charge q induces a charge density $\sigma(x, y)$ on the surface of a grounded metal plate. (b) Segmenting the metal plate results in induced charges Q_n on the strips. In case q is moving, the induced charges on the strips are changing and currents are flowing between the strips and ground

$$Q = \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \sigma(x, y) dx dy = -q, \qquad (5.2)$$

and it is independent of the distance of the charge q from the metal plate. Let us now imagine the metal plate to be segmented into strips of width w, each of the strips being grounded (Fig. 5.1b). In order to find the charge induced, e.g., on the central strip, we have to integrate the surface charge density from Eq. (5.1) over the area of the strip:

$$Q_1(z_0) = \int_{-\infty}^{\infty} \int_{-w/2}^{w/2} \sigma(x, y) dx dy = -\frac{2q}{\pi} \arctan\left(\frac{w}{2z_0}\right).$$
 (5.3)

This induced charge now depends on the distance z_0 of the point charge q from the metal surface. If the charge is moving towards the metal strip with a velocity v according to $z_0(t) = z_0 - vt$, we find a time-dependent-induced charge $Q_1[z_0(t)]$ and thus an induced current of

$$I_1^{ind}(t) = -\frac{d}{dt} \mathcal{Q}_1[z_0(t)] = -\frac{\partial \mathcal{Q}_1[z_0(t)]}{\partial z_0} \frac{dz_0(t)}{dt} = \frac{4qw}{\pi [4z_0(t)^2 + w^2]} v.$$
(5.4)

We see that the *movement* of a charge *induces a current* which flows between the electrode and ground. This is the principle of signal induction by moving charges. For more realistic geometries, this method of calculating the signals is the same but can become quite complex. In the following we derive theorems that allow a simpler and more intuitive way of calculating signals induced on grounded electrodes. After that we investigate the signals for the scenario where the electrodes are not grounded but are connected to amplifiers or interconnected by a general reactive network.

5.2 Capacitance Matrix, Reciprocity Theorem

The capacitance matrix and the reciprocity theorem are the bases for the discussion of signals induced on metal electrodes. The expression 'metal' electrode refers to the condition that the charges on the electrode can move and that the electrode surface

5.2 Capacitance Matrix, Reciprocity Theorem

is therefore an equipotential one. Setting a set of *N* metal electrodes to voltages V_n defines the potential $\phi(x)$ and the resulting electric field $E(x) = -\nabla \phi(x)$ in the chamber volume. The potential is uniquely defined by the conditions that $\phi(x)$ satisfies the Laplace equation and that $\phi(x) = V_n$ on the electrode surfaces.

Figure 5.2a shows a set of three metal electrodes. The voltages V_n and charges Q_n on the electrodes are related by the capacitance matrix of the electrode system [JAC 75]:

$$Q_n = \sum_{m=1}^{N} c_{nm} V_m.$$
(5.5)

The capacitance matrix is defined by the electrode geometry, and for the capacitance matrix elements c_{nm} , the following relations hold:

$$c_{nm} = c_{mn}, \quad c_{nm} \le 0 \quad \text{for} \quad n \ne m, \quad c_{nn} \ge 0, \quad \sum_{m=1}^{N} c_{nm} \ge 0.$$
 (5.6)

These relations are a direct consequence of Green's second theorem and the fact that the potential has to satisfy the Laplace equation. A set of different voltages \overline{V}_n is related to a set of different charges \overline{Q}_n by the same capacitance matrix $\overline{Q}_n = \sum c_{nm} \overline{V}_m$, so by inverting this relation and multiplying it by Eq. (5.5) we find

$$\sum_{n=1}^{N} Q_n \overline{V}_n = \sum_{n=1}^{N} \overline{Q}_n V_n.$$
(5.7)

This relation is called is called the *reciprocity theorem* and we use it frequently in the following discussions. Another important relation concerns the sum of all the charges of an electrode system. Figure 5.2b shows an electrode surrounding three electrodes. We apply Gauss' law to the volume between the electrodes, which tells us that the sum of all charges within this volume is equal to ε_0 times the integral of E(x) over the surface surrounding it. Because $\varepsilon_0 \int E(x) dA$ over a metal electrode is equal to the charge on this electrode, we find that the sum of all charges on the



Fig. 5.2 (a) The voltages and charges in a system of electrodes are related by the capacitance matrix c_{nm} . (b) A set of metal electrodes where one electrode encloses the others. The sum of all charges Q_n on the electrodes is equal to the sum of all charges q_n in the volume between the electrodes

metal electrodes is equal to the sum of all charges in the volume between the electrodes! In the case where there are no charges in the volume between the electrodes, the sum of the charges Q_n on the electrodes must be zero for any set of voltages V_n applied to them. Thus for the capacitance matrix we find the relation

$$\sum_{n} Q_{n} = 0 \quad \rightarrow \quad \sum_{n} \sum_{m} c_{nm} V_{m} = 0 \quad \rightarrow \quad \sum_{n} c_{nm} = 0, \tag{5.8}$$

which means that for a set of electrodes that is enclosed by one of them, the sum of all columns (rows) of the capacitance matrix is equal to zero.

To conclude this section we note that the capacitance matrix elements c_{nm} are different from the more familiar *capacitances* C_{nm} that we know from electric circuit diagrams. The C_{nm} are related to the voltage difference between circuit nodes, and we show later that the c_{nm} and C_{nm} are related by

$$C_{nn} = \sum_{m=1}^{N} c_{nm}, \qquad C_{nm} = -c_{nm} \text{ if } n \neq m.$$
 (5.9)

5.3 Signals Induced on Grounded Electrodes, Ramo's Theorem

We consider a set of three grounded electrodes in the presence of a point charge $Q_0 = q$ at position x as shown in Fig. 5.3a. We assume the point charge Q_0 to be sitting on an (infinitely small) metal electrode, so we have a system of four metal electrodes. For this setup we have $V_1 = V_2 = V_3 = 0$ and we want to know the charges Q_1, Q_2, Q_3 induced by the presence of charge $Q_0 = q$. Equation (5.7) reads

$$q\overline{V}_0 + Q_1\overline{V}_1 + Q_2\overline{V}_2 + Q_3\overline{V}_3 = \overline{Q}_0V_0.$$
(5.10)

Choosing another electrostatic state (Fig. 5.3b), where we remove the charge q from the small electrode ($\overline{Q}_0 = 0$), we set electrode 1 to voltage V_w ($\overline{V}_1 = V_w$) while keeping the other electrodes grounded ($\overline{V}_2 = \overline{V}_3 = 0$), the above relation becomes



Fig. 5.3 (a) The point charge q induces charges Q_n on the grounded electrodes. (b) Another set of voltages and charges which defines the 'weighting potential' of the first electrode

5.4 Total Induced Charge and Sum of Induced Signals

Fig. 5.4 In the case where the charge q is moving there are currents flowing between the electrodes and ground. The definition of I = -dQ/dtindicates that the positive current points away from the electrode



$$q\overline{V}_0 + Q_1 V_w = 0 \qquad \rightarrow \qquad Q_1 = -q \frac{\overline{V}_0}{V_w}.$$
(5.11)

 \overline{V}_0 is the potential of the uncharged small electrode for the second electrostatic state, and since an infinitely small uncharged electrode is equal to having no electrode, \overline{V}_0 is the potential at point \boldsymbol{x} when the point charge q is removed, electrode 1 is put to potential V_w , and electrodes 2 and 3 are grounded. We call $\overline{V}_0 = \psi_1(\boldsymbol{x})$ the *weighting potential* of electrode 1, and the induced charge Q_1 is given by

$$Q_1 = -\frac{q}{V_w} \psi_1(\boldsymbol{x}) \,. \tag{5.12}$$

In the case where the point charge q is moving along a trajectory x(t), as shown in Fig. 5.4, we find a time-dependent-induced charge on electrode n and therefore a current of

$$I_n^{ind}(t) = -\frac{dQ_n(t)}{dt} = \frac{q}{V_w} \nabla \psi_n[\boldsymbol{x}(t)] \frac{d\boldsymbol{x}(t)}{dt} = -\frac{q}{V_w} \boldsymbol{E}_n[\boldsymbol{x}(t)] \, \boldsymbol{v}(t).$$
(5.13)

We call $E_n(x) = -\nabla \psi_n(x)$ the weighting field of electrode *n*, which is Ramo's theorem [RAM 39]:

The current induced on a grounded electrode by a point charge q moving along a trajectory $\mathbf{x}(t)$ is $I_n^{ind}(t) = -q/V_w \mathbf{E}_n[\mathbf{x}(t)] v(t)$, where $\mathbf{E}_n(\mathbf{x})$ is the electric field in the case where the charge q is removed, electrode n is set to voltage V_w , and all other electrodes are grounded.

It must be noted that the sign of the induced current is given not only by the sign of the charge but also by the orientation of the particle velocity vector with respect to the direction of the weighting field. The trajectory x(t) is determined by the 'real' electric and magnetic fields in the detector together with the drift properties of the electrons and ions in the detector gas.

5.4 Total Induced Charge and Sum of Induced Signals

If the charge q is moving along a trajectory x(t) from position $x_0 = x(t_0)$ to position $x_1 = x(t_1)$, the total amount of charge Q_n^{ind} that flows between electrode n and ground is given by

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$$Q_n^{ind} = \int_{t_0}^{t_1} I_n^{ind}(t) dt = -\frac{q}{V_w} \int_{t_0}^{t_1} \boldsymbol{E}_n[\boldsymbol{x}(t)] \, \dot{\boldsymbol{x}}(t) dt = \frac{q}{V_w} [\boldsymbol{\psi}_n(\boldsymbol{x}_1) - \boldsymbol{\psi}_n(\boldsymbol{x}_0)] \,.$$
(5.14)

We find that this induced charge depends only on the end points of the trajectory and is independent of the specific path. If a pair of charges q, -q is produced at point x_0 at $t = t_0$ and q arrives at position x_1 while -q arrives at position x_2 after a time t_1 , the charge induced on electrode n is given by

$$Q_n^{ind} = \int_{t_0}^{t_1} I_n^{ind}(t) dt = \frac{q}{V_w} [\psi_n(\boldsymbol{x}_1) - \psi_n(\boldsymbol{x}_2)].$$
(5.15)

If the charge q moves to the surface of electrode n while the charge -q moves to the surface of some other electrode, the total induced charge on electrode n is equal to q, since $\psi_n = V_w$ on electrode n and $\psi_n = 0$ on the other electrodes. When both charges move to other electrodes, the total induced charge on electrode n is zero. We can therefore conclude:

After all the charges have arrived at the different electrodes, the total charge induced on electrode n is equal to the charge that has arrived at electrode n.

From this we also conclude that the current signals on electrodes that do not receive any charge are strictly bipolar.

If we want to know the sum of the signals induced on several electrodes we can either calculate the weighting fields and induced currents for the individual electrodes and add the currents or we can calculate the weighting field for the entire set of electrodes by setting all of them to voltage V_w and grounding the remaining ones. Let us assume the set of electrodes shown in Fig. 5.5, where one electrode encloses the others. The weighting potential ψ_{tot} for the sum of *all* induced currents is defined by setting *all* electrodes to potential V_w . This, however, results in $\psi_{tot}(x) = V_w$ in the entire volume and consequently a weighting field of $E_{tot}(x) = 0$. We can therefore conclude:

The sum of all induced currents on grounded electrodes is zero at any time, provided there is one electrode enclosing all the others.



Fig. 5.5 A set of grounded electrodes enclosed by one electrode. The sum of all induced currents is zero at any given time

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5.5 Induced Signals in a Drift Tube

As an example we calculate the induced signal in a drift tube with (cathode) radius *b* and wire radius *a* (Fig. 5.6). The tube is set to potential -U and the wire is grounded. This results in an electric field of $E(r) = U/(r \ln(b/a))$, as calculated in Sect. 3.1.1. We assume a single primary electron-ion pair in the gas volume. The electron moves to the wire and the ion moves to the tube wall. Close to the wire the electron starts an avalanche creating N_{tot} electrons and ions. The N_{tot} electrons of charge $-e_0$ move to the wire surface within a time much less than a nanosecond. The N_{tot} ions of charge $+e_0$ move away from the wire, but much more slowly, arriving at the tube wall after a time typically several hundreds of microseconds. As a first step we simply assume that the N_{tot} electrons are created at the wire surface and so do not move, while the N_{tot} ions move from the wire surface to the tube wall. The velocity of the ions is given by the mobility μ as $v = \mu E$, so with the condition that r(t = 0) = a we find the ion trajectory to be

$$\frac{dr(t)}{dt} = \mu \frac{U}{r(t)\ln(b/a)} \quad \to \quad r(t) = a\sqrt{1 + \frac{t}{t_0}} \qquad t_0 = \frac{a^2\ln(b/a)}{2\mu U}$$
(5.16)

The characteristic time t_0 is typically one or a few nanoseconds. It takes very much longer for the ions to arrive at the tube wall r = b; this maximum travel time is $t_{max} = t_0[(b/a)^2 - 1]$, typically four to six orders of magnitude larger than t_0 , in the hundred microsecond range.

The weighting potential ψ_1 and weighting field E_1 of the wire are defined by setting the wire to potential V_w and grounding the tube, which results in

$$\psi_1(r) = -\frac{V_w \ln(r/b)}{\ln(b/a)} \qquad E_1(r) = \frac{V_w}{r \ln(b/a)}$$
(5.17)

According to Eq. (5.13), the current induced on the wire by the movement of the N_{tot} ions is given by

$$I_1^{ind}(t) = -\frac{N_{tot}e_0}{V_w} E_1[r(t)]\dot{r}(t) = -\frac{N_{tot}e_0}{2\ln(b/a)}\frac{1}{t+t_0}.$$
(5.18)

The wire signal is negative and has a hyperbolic form with a characteristic time constant t_0 , which in practical cases will be a few nanoseconds. The induced charge at time *t* is given by





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$$Q_1^{ind}(t) = \int_0^t I_1^{ind}(t')dt' = -\frac{N_{tot}e_0}{2\ln(b/a)}\ln\left(1+\frac{t}{t_0}\right).$$
(5.19)

Once the ions have arrived at the tube wall the induced charge on the wire is $Q_1^{ind}(t_{max}) = -N_{tot}e_0$, which agrees with the statement about the total induced charge from the previous section. The current induced on the tube ('the cathode') is $I_2^{ind}(t) = -I_1^{ind}(t)$ since the tube completely encloses the wire and thus the sum of the two signals must be zero at any time.

As an illustration, in Fig. 5.7 we plot the time development of a current pulse described by Eqs. (5.18) and (5.19) using typical parameters for a, b, and t_0 . One observes the extremely sharp onset and the extremely long tail characteristic of such pulses.

In a second step we refine the picture by involving the radial extent of the avalanche, the electron movement, and the field dependence of the ion mobility. We use the model from Sect. 4.4.1, where the Townsend coefficient was taken to be proportional to the electric field ($\alpha = (\ln 2/\Delta V)E$) and the first multiplication starts at a minimum field E_{min} . With $E_{min} = U/(r_{min} \ln(b/a))$, the number of electrons present at distance *r* is given by

$$N(r) = \exp\left(\int_{r}^{r_{min}} \alpha(r) dr\right) = \left(\frac{r_{min}}{r}\right)^{\frac{U \ln 2}{\Delta V \ln(b/a)}}$$
(5.20)

The total number of avalanche electrons (the gain) is $N_{tot} = N(a)$. The number of electrons created between *r* and r + dr is n(r)dr = (dN/dr)dr, so the centre of gravity r_{cog} of the electron avalanche is given by

$$r_{cog} = \frac{1}{N_{tot}} \int_{a}^{r_{min}} r n(r) dr = a(1+\varepsilon) \qquad \varepsilon = \frac{\Delta V \ln(b/a)}{U \ln 2}$$
(5.21)

Typical operating voltages U of $\approx 2 \text{ kV}$, ΔV values of $\approx 20V$, and $\ln(b/a)$ values of ≈ 10 result in a value for ε of the order of 0.1. With traditional wire radii of $a = 10 - 30 \,\mu\text{m}$ we find that the centre of gravity of the electron avalanche is only a few micrometers above the wire surface.

With such a small distance to travel to their destination, the wire surface, the electrons can only make a small contribution to the total signal charge. The latter



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one is given by $Q_{tot}^{ind} = -e_0 N_{tot}$ once all the electrons and ions have arrived on their respective electrodes (see the previous section). The signal from the electrons may be calculated using Eq. (5.14), which tells us that a single electron moving from distance *r* to the wire surface induces a charge of $-(e_0/v_w)(\psi_1(a) - \psi_1(r)) = -e_0 \ln(r/a)/\ln(b/a)$. Thus, assuming that all the electrons are moving from r_{cog} to the wire surface, the fraction of charge induced by the avalanche electrons is given by

$$\frac{Q_e^{ind}}{Q_{tot}^{ind}} = \frac{\ln(r_{cog}/a)}{\ln(b/a)} \approx \frac{\Delta V}{U\ln 2}.$$
(5.22)

For typical values of U and ΔV discussed above, the fraction of charge induced by the movement of the electrons amounts to 1 or 2% of the total induced charge. Since the electrons arrive at the wire within a time much shorter than 1 ns, for all practical purposes we can assume the electron component of the signal to be a delta current $I_e^{ind}(t) = Q_e^{ind} \delta(t)$. The ions move from their point of creation to the tube wall, and we assume here that they all start from r_{cog} . In the high electric fields of 10^3-10^4 V/(cm Torr) in the vicinity of the wire, the ion velocity is not proportional to E but rather is related to the field by $v = \kappa \sqrt{E}$ (Sect. 2.2.2). Thus, for the early part of the ion trajectory we have

$$\frac{dr(t)}{dt} = \kappa \sqrt{\frac{U}{r(t)\ln(b/a)}} \rightarrow r(t) = a(1+\varepsilon)\sqrt{1+\frac{t}{t_1}}$$

$$t_1 = \frac{2}{3\kappa} \sqrt{\frac{\ln(b/a)}{U}a^3(1+\varepsilon)^3}.$$
(5.23)

In practice, t_1 is a small factor (say two or three times) larger than t_0 . It is remarkable that the functional dependence on t is the same as the one of the simplified case of Eq. (5.16). The refinements have only changed the numerical values of t_0 and a, so the signal again assumes a hyperbolic form with a characteristic time constant t_1 . The sharp onset and the long tail remain as shown in Fig. 5.7.

Since the electric field in the vicinity of the wire of any wire chamber has the form 1/r, the universal shape of the induced current signal $I_1^{ind}(t)$ Eq. (5.18) is valid for wire signals of all wire chamber geometries.

5.6 Signals Induced on Electrodes Connected with Impedance Elements

In this section we calculate the signals induced by moving charges on electrodes connected with arbitrary impedance elements. Before doing this, however, we first investigate the circuit shown in Fig. 5.8, where external current sources I_n are impressed on nodes which are connected to impedances Z_{nm} . These impedances represent linear 'physical' objects such as resistors, capacitors, and amplifiers. In the Laplace domain (see Chap. 6), the current I_{nm} flowing from node *n* to node *m*

Fig. 5.8 Circuit diagram representing three nodes connected to each other and ground through impedances Z_{nm} . The $I_n(t)$ represent external currents impressed on the nodes, and the $V_n(t)$ represent the resulting voltages

through Z_{nm} and the current I_{nn} flowing between node *n* and ground through Z_{nn} are defined by

$$I_{nm}(s) = [V_n(s) - V_m(s)]/Z_{nm}(s)$$
 and $I_{nn}(s) = V_n(s)/Z_{nn}(s)$. (5.24)

On every node, the sum of all currents must be zero, which gives

$$I_n - I_{nn} - \sum_{m \neq n} I_{nm} = 0 \quad \rightarrow \quad I_n = \sum_m y_{nm} V_m, \tag{5.25}$$

where we have defined the *admittance matrix* y_{nm} of the circuit as

$$y_{nn} = \sum_{m} \frac{1}{Z_{nm}}$$
 $y_{nm} = -\frac{1}{Z_{nm}}$ $n \neq m.$ (5.26)

The voltages on the nodes, resulting from the impressed currents, are therefore given by

$$V_n(s) = \sum_m z_{nm}(s) I_m(s) \qquad z_{nm}(s) = y_{nm}^{-1}(s).$$
(5.27)

The matrix z_{nm} is the inverse of the admittance matrix and is called the *impedance matrix* of the circuit.

Up to this point we have understood that there is a linear relationship [Eq. (5.25) or Eq. (5.27)] between the currents $I_n(t)$ impressed on the nodes of the network (Fig. 5.8) and the resulting potentials $V_n(t)$ on the nodes. What we finally want to determine are the potentials $V_n^{ind}(t)$ induced by a moving charge q between the electrodes that are part of a network as shown in Fig. 5.9a. In the following we will find that these voltages are calculated by adding the mutual electrode capacitances to the network from Fig. 5.8 and placing the currents that would be induced on grounded electrodes as impressed currents to this circuit (Fig. 5.9b). The drift of charges in gases is slow enough to allow the use of the quasi-electrostatic calculation, meaning that Eq. (5.5) and the reciprocity theorem (5.7) are also valid for time-dependent charges $Q_n(t)$ and voltages $V_n(t)$ at every time t. Following the procedure of Sect. 5.3, we use a second electrostatic state, where $\overline{Q}_0(t) = 0$, $\overline{V}_1(t) = V_w$ and $\overline{V}_2(t) = \overline{V}_3(t) = 0$, which gives



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Fig. 5.9 (a) The point charge q induces voltages on the electrodes that are connected with impedance elements. (b) These induced voltages are calculated by adding the mutual electrode-electrode capacitances C_{nm} to the equivalent circuit and placing the currents, induced on the grounded electrodes, as impressed current sources on the nodes

$$q \psi_1(\boldsymbol{x}) + Q_1 V_w = \overline{Q}_1 V_1^{ind} + \overline{Q}_2 V_2^{ind} + \overline{Q}_3 V_3^{ind}.$$
 (5.28)

The charges \overline{Q}_n and voltages \overline{V}_n are related by the capacitance matrix of the three-electrode system giving $\overline{Q}_n = c_{1n}V_w$. Writing the same relations for the other electrodes results in

$$Q_n = -\frac{q}{V_w} \psi_n(\boldsymbol{x}) + \sum_m c_{nm} V_m^{ind}, s$$
(5.29)

where Q_n , V_n^{ind} , and ψ_n are the charge, voltage, and weighting potential of electrode n. If the point charge q moves along the trajectory x(t) we find time-dependent charges Q_n on the electrodes, and their rate of change is

$$\frac{dQ_n}{dt} = -I_n^{ind}(t) + \sum_m c_{nm} \frac{dV_m^{ind}}{dt}.$$
(5.30)

The $I_n^{ind}(t)$ are the currents from Eq. (5.13) induced on the electrodes in the case where they are grounded. The charges Q_n can only change due to currents flowing between the electrodes, i.e., $dQ_n/dt = \sum_m I_{nm} + I_{nn}$. These currents in turn are given by the potential differences and connecting impedances, as defined in Eq. (5.24). In the Laplace domain we therefore have

$$\sum_{m} \frac{(V_m^{ind} - V_n^{ind})}{Z_{nm}} + \frac{V_n^{ind}}{Z_{nn}} = -I_n^{ind} + \sum_{m} sc_{nm}V_m^{ind} \longrightarrow$$
(5.31)

$$I_n^{ind} = \sum_m (sc_{nm} + y_{nm})V_m^{ind} \quad \text{or} \quad V_n^{ind} = \sum_m (sc + y)_{nm}^{-1}I_m^{ind}, \quad (5.32)$$

where the admittance matrix y_{nm} is defined in Eq. (5.26). The following is our final result:

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The voltages $V_n^{ind}(t)$ induced by a moving charge on electrodes connected to impedances $Z_{nm}(s)$ are determined by first using Ramo's theorem to calculate the currents induced on the grounded electrodes and placing them as ideal current sources on an equivalent circuit diagram with admittance matrix $sc_{nm} + y_{nm}(s)$ (Fig. 5.9b).

The additional admittance matrix elements sc_{nm} are due to the mutual capacitance between the electrodes. Inverting the relation (5.26) for $y_{nm}^c = sc_{nm}$, we see that the impedances corresponding to c_{nm} are given by

$$Z_{nm}^{c} = \frac{1}{sC_{nm}} \qquad \text{with} \qquad C_{nn} = \sum_{m} c_{nm} \qquad C_{nm} = -c_{nm} \quad n \neq m \qquad (5.33)$$

The C_{nm} are the electrode capacitances, which must be distinguished from the capacitance matrix c_{nm} in the same way that the impedances Z_{nm} must be distinguished from the impedance matrix z_{nm} . The equivalent circuit for Eq. (5.32) is shown in Fig. 5.9b. To calculate the induced voltages we compute the currents induced on grounded electrodes with Ramo's theorem and perform the next step of the calculation analytically or, e.g., with an analog circuit simulation program.

For the completion of our task we still have to specify the actual trajectory of the moving charge, and we must find the numerical values of the capacitance matrix elements. For this, the weighting fields known from Eq. (5.13) turn out to be useful because they have a simple relation to the capacitance matrix as well as to the trajectory-defining field E(x). If metal electrodes are set to voltages V_n , the potential $\psi(x)$ is uniquely defined by the requirements that it fulfils the Laplace equation in the volume between the electrodes and that $\psi(x) = V_n$ on the electrode surfaces. The potential

$$\Psi(\boldsymbol{x}) = \sum_{n} \frac{V_n}{V_w} \Psi_n(\boldsymbol{x})$$
(5.34)

satisfies these conditions because the weighting potentials ψ_n are equal to V_w on electrode *n* and zero on the other electrodes, and since such a solution is unique it is the general solution of this problem. From this we immediately obtain the field E(x) as a linear superposition of the weighting fields:

$$\boldsymbol{E}(\boldsymbol{x}) = \sum_{n} \frac{V_n}{V_w} \boldsymbol{E}_n(\boldsymbol{x}).$$
 (5.35)

The surface charge density on a metal electrode is related to the electric field on the surface by $\sigma = \varepsilon_0 |\mathbf{E}|$. The total charge on electrode *n* is therefore defined by the integral over the electrode surface A_n

$$Q_n = \varepsilon_0 \oint_{\boldsymbol{A}_n} \boldsymbol{E}(\boldsymbol{x}) d\boldsymbol{A} = \sum_m \frac{V_m}{V_w} \oint_{\boldsymbol{A}_n} \boldsymbol{E}_m(\boldsymbol{x}) d\boldsymbol{A} = \sum_m c_{nm} V_m.$$
(5.36)

As a result, the capacitance matrix elements are calculated to be

$$c_{nm} = \frac{\varepsilon_0}{V_w} \oint_{\boldsymbol{A}_n} \boldsymbol{E}_m(\boldsymbol{x}) d\boldsymbol{A}.$$
 (5.37)

Knowing the weighting fields $E_n(x)$ is therefore sufficient to calculate the chamber signals in four steps:

- 1. Using Eq. (5.35) we find the 'real' electric field in the chamber which determines the particle trajectories.
- 2. The induced currents on grounded electrodes follow from Ramo's theorem [Eq. (5.13)].
- 3. The capacitance matrix c_{nm} and capacitances C_{nm} are calculated from Eqs. (5.37) and (5.33).
- 4. These capacitance elements are added to the equivalent circuit and the induced currents are impressed on the nodes as ideal current sources.

The calculation of the weighting fields and capacitance matrix is performed analytically or with dedicated computer programs. The final step of placing the currents on the equivalent circuit diagram is usually done by analog circuit simulation programs.

5.6.1 Application to a Drift Tube and its Circuitry

We now illustrate the above procedure by applying it to the drift tube shown in Fig. 5.10a. For our example we use values of l = 100 cm, tube radius b = 1.5 cm, and wire radius $a = 25 \,\mu$ m.

We first have to calculate the electric field in the detector and determine the ion trajectories, as done in Eq. (5.16). Next we calculate the weighting fields and the induced current signals using Ramo's theorem, which was done in Eq. (5.18). In a third step we calculate the capacitance matrix of the tube using Eq. (5.37). Electrode 1 (the wire) has an area of $A_1 = 2a\pi l\hat{r}$ and electrode 2 (tube) has an area of $A_2 = -2b\pi l\hat{r}$. With the weighting fields $E_1 = V_w/r\ln(b/a)\hat{r}$ (wire) and $E_2 = -V_w/r\ln(b/a)\hat{r}$ (tube) we find

$$c_{11} = c_{22} = -c_{12} = -c_{21} = \frac{2\pi\varepsilon_0 l}{\ln(b/a)}.$$
(5.38)



Fig. 5.10 (a) Typical setup for a drift tube. The wire is set to voltage U and is decoupled from the amplifier input by a capacitor C. (b) The signals in the presence of the reactive elements are calculated by placing the currents $I_n^{ind}(t)$, induced on the grounded electrodes, as ideal current sources on the equivalent circuit

The capacitances, calculated by Eq. (5.33), are therefore

$$C_{11} = C_{22} = 0$$
 $C_{12} = C_{21} = \frac{2\pi\varepsilon_0 l}{\ln(b/a)}$. (5.39)

For the chosen parameters we find $C_{12} = 20$ pF. In the final step we impress the induced currents as ideal current sources on the equivalent circuit of the tube as shown in Fig. 5.10b. The wire is read out by an amplifier with input resistance R_{in} , which we choose to be 50Ω . In the equivalent circuit, the wire and the tube have become pointlike nodes. This is only admissible if the tube is 'electrically short', i.e., if the shortest wavelength $\lambda = c/f_0$ processed by the readout electronics with bandwidth limit f_0 is large compared to the tube length l. For the assumed parameters this translates into $f_0 \ll 300$ MHz. We use a value of 1.6 MHz in the following. In a case where l is not much smaller than c/f_0 we would have to consider the tube to be a transmission line. In practical applications it is not convenient to set the tube and set the wire to positive voltage U. The signal $-I_1^{ind}$ induced on the tube can be neglected because the current is 'leaving' to the ground node and is not entering the amplifier.

Choice of the circuit parameters. The capacitor *C* decoupling the amplifier from the potential *U* must be large compared to C_{12} so that the current signal goes into the amplifier instead of flowing into C_{12} . But it must not be so large that the energy $E = CU^2/2$ it stores would destroy the amplifier in the case of a spark. Let us take the typical value of 1 nF for *C*.

The resistor R_L connects the wire to the voltage supply. It must be large in comparison to the impedance of *C* and R_{in} in series so that only a small fraction of the signal is lost into the power supply. If we want 99% of the bandwidth to find this impedance sufficiently small, we may evaluate it at 1% of the bandwidth limit leaving a value of

$$R_L > \frac{1}{2\pi f_0 \times 0.01} + R_{in} \approx 10^4 \Omega$$
 (5.40)

in our example. In addition, this resistor is a source of thermal current noise which is proportional to $1/\sqrt{R_L}$, so in this respect as well one chooses the resistor as large as possible. The upper limit for R_L is defined by the maximum voltage drop that one allows for a given chamber current. With a primary ionization of, e.g., 125 electrons and a gas gain of 5×10^5 at a rate of 100 kHz, we find a chamber current of $1 \,\mu$ A, which leads to a tolerable voltage drop of 1 V for an R_L value of $1 M\Omega$. Values for R_L of 100 k Ω to several $M\Omega$ are typical; let us make $R_L = 1 \,\mathrm{M}\Omega$ for definiteness.

The relation between the induced current I_1^{ind} and amplifier input current I_A can be determined by evaluating the equivalent circuit diagram in Fig. 5.10b. Using the methods of Chap. 6 we change to the Laplace domain and find

$$I_A(s) = \frac{sR_LC}{1 + s(R_LC + R_{in}C + R_LC_{12}) + s^2R_{in}C_{12}R_LC} I_1^{ind}(s).$$
(5.41)

With the relative magnitudes of R_L , R_{in} , C, and C_{12} that we assumed before, the expression approximates to

$$I_A(s) \approx \left(\frac{1}{\tau_2} \frac{1}{s+1/\tau_2}\right) \left(\frac{s}{s+1/\tau_1}\right) I_1^{ind}(s) \quad \begin{array}{l} \tau_1 = R_L C = 1 \,\mathrm{ms} \\ \tau_2 = R_{in} C_{12} = 1 \,\mathrm{ns} \end{array}.$$
(5.42)

We can visualize the transfer function by an equivalent block diagram as outlined in Chap. 6. Converting the current I_1^{ind} to a voltage pulse, we see that this transfer function corresponds to an RC integration element with time constant τ_2 and a CR differentiation element with time constant τ_1 . This is illustrated in Fig. 5.11. The RC integration with a time constant of $\tau_1 = 1$ ns will change the 'infinite' rise time of the induced signal to a signal with a rise time of ~ 1 ns, which has very little influence in the case in which the amplifier rise time is longer than ≈ 10 ns. The differentiation with a time constant of $\tau_2 = 1$ ms will also have very little influence on the signal shape within the first several microseconds; it has, however, a profound influence in the case of high-rate applications. Any voltage signal passing a capacitor will integrate to zero, i.e., $\int_0^\infty I_A(t)dt = 0$. This means that the signal will slowly approach zero and then have a very shallow and long undershoot with a timescale of several times τ_1 . If the counting rate is $< 1/\tau_1 = 100$ Hz there is no mutual influence of the pulses, but as the rate increases, more and more of these undershoots will pile up and lead to baseline fluctuations. This point will be elaborated in Chap. 6, where we discuss the amplifier transfer functions which shape the input signal I_A so as to obtain the optimum information from the detector signal.

5.6.2 Alternative Methods for the Calculation of the Signal

To conclude the discussion of signal theorems we point out that there is an alternative way of calculating the induced voltages for the setup of Fig. 5.9a, which does not involve the four separate steps outlined earlier. Placing a delta current $I_w \delta(t)$ on electrode *n* defines a time-dependent weighting field $E_n^{dyn}(x,t)$ in the space between the electrodes, from which the voltage $V_n^{ind}(t)$ can be calculated by convolution with the velocity vector of the moving charge [GAT 82]:



Fig. 5.11 Equivalent transfer function from the wire signal to the amplifier input

This theorem can be useful when one studies a detector geometry with a simulation program that allows the transient analysis of time-dependent electric fields.

There are detectors with electrodes that have only a finite conductivity, such as resistive plate chambers (RPCs) [SAN 80] or undepleted silicon detectors. In such cases, which do not normally occur in wire chambers, the theorems discussed in this chapter are not directly applicable, but have to be generalized. An extension of the theorems of signal generation including resistive electrodes as well as dissipative dielectrics has been published elsewhere [RIE 04].

5.7 Signals Induced in Multiwire Chambers

A classical multiwire chamber consists of a plane of anode wires situated between two parallel cathode planes. Often one of the cathode planes is subdivided into strips orthogonal to the wires; then the avalanches can be localized in two dimensions by reading out the electrical signals from the wires and the strips [GAT 79]. Such a geometry is depicted further on in Fig. 5.14. In the following we discuss the main characteristics of the wire and cathode signals using the method outlined in Sect. 5.1-5.4.

5.7.1 Signals Induced on Wires

The wire radii, typically $10-30\,\mu$ m, are small compared to the distance between the wires and the distance between the wire and the cathode of typically a few millimetres. This fact gives rise to a coaxial electric field close to the wires, as we show in the following. Setting the wires to potentials U_n results in charges q_n on the wires, which are determined by the capacitance matrix through $q_n = \sum_{m=1}^N c_{nm} U_m$. We combine the two cathode planes into electrode 1 and label the individual wires as electrodes 2, 3, 4, etc. (cf. Fig. 5.12). We assume the wires to be infinitely long, so c_{nm} and q_n are the capacitance matrix and charge per unit of wire length. The electric field at a distance *r* from a line charge *q* is given by

$$\boldsymbol{E}(r) = \frac{q}{2\pi\varepsilon_0 r} \hat{\boldsymbol{r}},\tag{5.44}$$

electrode '1' _____ cathode plane \circ \circ $\overset{*}{2'}$ $\overset{\circ}{3'}$ $\overset{\circ}{4'}$ \circ anode wires '1' _____ cathode plane

Fig. 5.12 Electrode arrangement for which the induced currents are calculated in (5.48) to (5.51). Wire '2' carries the avalanche

5.7 Signals Induced in Multiwire Chambers

so at a point with distance r_1 and r_2 to two wires carrying charge q_1 and q_2 , the electric field is $E = 1/(2\pi\varepsilon_0)([q_1/r_1]\hat{r}_1 + [q_2/r_2]\hat{r}_2)$. In the vicinity of a wire, meaning that $r_1 \ll r_2$, the field is dominated by the charge on this wire as long as the charges q_1 and q_2 are of similar magnitude. We can conclude that the electric field at distance r from wire n is approximately coaxial, and its magnitude given by

$$E(r) = \frac{q_n}{2\pi\varepsilon_0 r} = \frac{1}{2\pi\varepsilon_0 r} \left(\sum_{m=1}^N c_{nm} U_m\right)$$
(5.45)

as long as r is small compared to the distance between the chamber electrodes. Under these circumstances, the trajectory of the avalanche ions is just the same as the one in the drift tube [Eq. (5.16)], and we have

$$r(t) = a\sqrt{1+t/t_0}$$
 $\frac{1}{t_0} = \frac{\mu}{a^2\pi\epsilon_0} \left(\sum_{m=1}^N c_{nm}U_m\right).$ (5.46)

It is interesting to note that it is the bandwidth of the electronics which decides whether the coaxial approximation (5.45) is adequate. Imagine a fast amplifier (large bandwidth) for signals only 50 ns long: with typical values of 1 ns for t_0 and 15 μ m for the wire radius *a*, the ions have travelled only a few percent of a typical wire pitch of 1.5 or 2 mm, namely 0.1 mm in 50 ns – the coaxial approximation is probably good enough in most circumstances. On the other hand, imagine a slower amplifier (smaller bandwidth) for signals 1 μ s long: with the same typical values the ions have already travelled a significant fraction of the typical wire pitch, namely 0.5 mm in 1 μ s – the coaxial approximation is probably not good in many circumstances, and the signal shape begins to depend on the angular distribution of avalanche ions around the wire.

For the time being we wish to stay in the coaxial approximation (5.45) in order to compute the signals on the various wires. We consider the situation with a plane of anode wires, all on the same potential, between two cathode plates, as depicted in Fig. 5.12.

Knowing the ion trajectory r(t) we need to calculate the weighting fields of the wires in order to find the induced current signals. The weighting field of the avalanche wire (electrode '2'), where the avalanche takes place, is found by setting the wire to voltage V_w and grounding all other wires and electrodes. This results in the charge $q_2 = c_{22}V_w$ on this wire, and the magnitude of the weighting field in the coaxial approximation is

$$E_2(r) = \frac{c_{22}V_w}{2\pi\epsilon_0 r}.$$
 (5.47)

The current induced by N_{tot} ions of charge e_0 , moving away from the wire surface, is therefore

$$I_2(t) = -\frac{N_{tot}e_0}{V_w} E_2[r(t)] \frac{dr}{dt} = -\frac{N_{tot}e_0}{4\pi\epsilon_0} \frac{c_{22}}{t+t_0}.$$
 (5.48)

The signal on the avalanche wire is negative because $c_{22} > 0$ [cf. Eq. (5.6)].

The weighting field of the closest neighbour (electrode '3') is given by setting wire '3' to potential V_w and grounding all other wires. This results in a charge of $q_3 = c_{23}V_w$ on the avalanche wire and the signal on wire '3' is therefore

$$I_3(t) = -\frac{N_{tot}e_0}{4\pi\epsilon_0} \frac{c_{23}}{t+t_0}.$$
 (5.49)

The 'cross-induced' signal has the same shape as the signal on the avalanche wire and because $c_{2n} < 0, n \neq 2$, it is positive. The other wires have the same signal polarity and shape, with relative amplitudes c_{24}, c_{25} , etc. We can express the relative signal amplitudes by the more familiar capacitances C_{nm} and find

$$\frac{I_n(t)}{I_1(t)} = \frac{c_{2n}}{c_{22}} = -\frac{C_{1n}}{\sum_{m=1}^N C_{2m}}.$$
(5.50)

The amplitude of the 'cross-induced' signal from the avalanche wire to wire n is therefore given by the mutual capacitance between the avalanche wire and wire n divided by the sum of all mutual capacitances of the avalanche wire to the other electrodes.

We have to note that the capacitive coupling between wires causes a signal of the *same* polarity on the neighbouring wires, which can be seen, e.g., by injecting a wire signal with a pulse generator. During the early days of wire chamber development one feared that the resolution of multiwire chambers was limited owing to this capacitive coupling, which increases as the wire spacing is reduced. The *opposite* polarity of the signal induced by the avalanche is, however, hiding this capacitive crosstalk, which makes it 'a simple matter to localize the wire which is the seed of the avalanche, whatever the distance between the wires' [CHA 92].

The sum of all wire signals is given by

$$I_w(t) = \sum_{n=2}^{N} I_n(t) = -\frac{N_{tot}e_0}{4\pi\varepsilon_0} \frac{1}{t+t_0} \sum_{n=2}^{N} c_{1n} = -\frac{N_{tot}e_0}{4\pi\varepsilon_0} \frac{C_{12}}{t+t_0}.$$
 (5.51)

Here we have used the relation $C_{12} = -c_{12}$ and the fact that the two cathode planes completely enclose the wires and the sum of all capacitance matrix elements $\sum_{m=1}^{N} c_{nm}$ is zero. The sum of all wire signals thus has negative polarity. If all the wires are set to the same voltage U, the characteristic time constant t_0 from Eq. (5.46) assumes the form

$$\frac{1}{t_0} = \frac{\mu}{a^2 \pi \varepsilon_0} \left(U \sum_{m=2}^N c_{nm} \right) = \frac{\mu U C_{12}}{a^2 \pi \varepsilon_0}.$$
(5.52)

For a comparison with the simple drift tube with wire radius *a* and tube radius *b*, we remember that the wire signal and wire capacitance per unit length C'_{12} were calculated [Eqs. (5.16), (5.18), (5.39)] to be

$$I(t) = -\frac{N_{tot}e_0}{2\ln(b/a)} \frac{1}{t+t_0} \qquad \frac{1}{t_0} = \frac{2\mu U}{a^2\ln(b/a)} \qquad C_{12}' = \frac{2\pi\varepsilon_0}{\ln(b/a)}.$$
 (5.53)

5.7 Signals Induced in Multiwire Chambers

If we express $\ln(b/a)$ by the capacitance per unit length C'_{12} the expression for the wire signal in the drift tube is equivalent to the expression for the summed wire signal in the MWPC. Therefore one can define the so called 'equivalent cathode radius' for an MWPC as

$$b_{eq} = a \exp\left(\frac{2\pi\epsilon_0}{C_{12}}\right) = a \exp\left(\frac{55.6 \text{ pF/m}}{C'_{12}}\right).$$
 (5.54)

We can therefore conclude that while the avalanche ions are moving in the coaxial region of the wire, all signals in the wire chamber have the same shape, namely hyperbolic proportional to $1/(t+t_0)$ with the characteristic time constant t_0 . The relative amplitudes of the signals are determined by the capacitance matrix elements, and the signal on the avalanche wire has negative polarity while all other signals have positive polarity. For wire chambers where all wires are set to the same voltage U, the summed wire signal is equivalent to the wire signal in a drift tube, and we can define an equivalent cathode radius b_{eq} for the wire chamber.

Finally, let us picture what we can expect beyond the coaxial approximation. Once the avalanche ions are at a distance from the wire which is comparable to the other chamber dimensions, the capacitance matrix elements are not sufficient to determine the signals, the signal shapes differ, and the weighting fields for each wire must be considered. The curves in Fig. 5.13 are the results of a numerical calculation for a model chamber like the one in Fig. 5.12 with anode wires spaced 2.5 mm and an anode-cathode distance of 5 mm. The weighting fields of the different electrodes at the point of the travelling ions are represented as a function of the distance of the ions from the wire that carries the avalanche. The ratios between the weighting fields of different electrodes may be taken for the respective signal ratios. One observes that the signal on the neighbouring wire '3' (crosstalk) depends very much more on the angular distribution of avalanches around their wire than is the case for the main signal on electrode '2'.





5.7.2 Signals Induced on Cathode Strips and Pads

When the wires are enclosed by the two cathode planes, the sum of all chamber signals is zero at any time and the cathode signal $I_c(t)$ is equal to the negative summed wire signal $-I_w(t)$. In our example, the cathodes are symmetrically placed with respect to the wire plane, so the signal on a single cathode plane in the coaxial approximation is

$$I_{c1}(t) = \frac{1}{2}I_c(t) = -\frac{1}{2}I_w(t) = \frac{1}{2}\frac{N_{tot}e_0}{4\pi\epsilon_0}\frac{C_{12}}{t+t_0}.$$
(5.55)

The avalanche can be localized in the direction perpendicular to the sense wire when subdividing the cathode into separate strips or pads, as indicated in Fig. 5.14. The weighting field of a cathode strip is calculated by setting the strip to potential V_w while grounding all other strips and wires. This method is used in [MAT 84a] to arrive at the exact expression for the weighting field and induced signal. For practical purposes a few simplifications can be introduced [GAT 79][MAT 84b]. The signal on a cathode strip is determined by first calculating the signal on a strip of infinitesimal width, which is then integrated over the strip width *w*. This procedure defines a so-called cathode charge distribution $\Gamma(\lambda)$ through

$$dI_{c1}(t,\lambda) = I_c(t)\Gamma(\lambda)d\lambda \qquad \int_{-\infty}^{\infty}\Gamma(\lambda)d\lambda = \frac{1}{2},$$
(5.56)

where $\lambda = x/h$ is the distance of the infinitesimal strip from the avalanche position. The distribution $\Gamma(\lambda)$ can be calculated by investigating the weighting field of an infinitesimal cathode strip. A single-parameter semi-empirical expression for $\Gamma(\lambda)$ was given by Gatti et al. [GAT 79] and discussed by Mathieson and Gordon [MAT 84b]:

$$\Gamma(\lambda) = K_1 \frac{1 - \tanh^2 K_2 \lambda}{1 + K_3 \tanh^2 K_2 \lambda}.$$
(5.57)

Here the parameters K_1 and K_2 are uniquely defined by K_3 , which depends on the chamber geometry as shown in Fig. 5.15:

Fig. 5.14 A row of wires centred between two cathode planes. By segmenting the cathode into strips, the position of the avalanche along the wire direction can be determined. The wire pitch *s*, the strip width w = 2a, and the distance *h* between anode and cathode planes are indicated





Fig. 5.15 (a) Values of the parameter K_3 as a function of chamber geometrical parameters h/s and a/s [MAT 84b]. (b) Cathode charge distribution $\Gamma(\lambda)$ according to Gatti for h/s = 2 and $a/s = 5.25 \times 10^{-3}$ together with a Gaussian that has the same area and the same FWHM

$$K_1 = \frac{K_2\sqrt{K_3}}{4\operatorname{atan}\sqrt{K_3}}$$
 $K_2 = \frac{\pi}{2}\left(1 - \frac{\sqrt{K_3}}{2}\right).$ (5.58)

 $\Gamma(\lambda)$ represents the charge distribution on one of the cathode planes originating from a single avalanche. We take it to be independent of direction in that plane, the variable $\lambda = x/h$ representing one coordinate in that plane, normalized to the anode-cathode distance *h*. The other coordinate, at right angles to *x*, has already been integrated over, following the idea of a cathode segmented into strips. One of the two curves in Fig. 5.15b is Eq. (5.57) with a choice of K_3 indicated in the caption. The other is a Gaussian for comparison, with the same area and the same width. Gatti's curve has a longer tail at large $|\lambda|$. The FWHM of the distribution can be expressed as

$$\frac{\text{FWHM}}{h} = \frac{4\arctan(1/\sqrt{2+K_3})}{\pi(1-0.5\sqrt{K_3})}.$$
(5.59)

Expression (5.57) is approximate in the sense that it neglects any influence of the avalanche position around the wire if the avalanche develops on one side. But this is not relevant unless electric signals are recorded that are so long that the ions have moved beyond a few wire radii. In practical measurements of particle tracks there are many avalanches that contribute to an electric signal. These are spread out along the track, by diffusion and other effects (cf. Chap. 2). The average formula (5.57) is then quite adequate to generate, perhaps in a simulation program, the true charge by superposition of many $\Gamma(\lambda^i)$ at the avalanche positions λ^i .

Precision measurements of charge distributions for different avalanche positions around the wire were reported by Gordon and Mathieson [MAT 84a].

Varying the ratio of cathode separation to wire pitch h/s from 0.1 to ∞ , the parameter K_3 assumes values between 0.1 and 1, which means that the FWHM assumes values between 2.8*h* and 2.4*h*. For a strip of finite width *w* centred at position λ , we get the signal $I(t, \lambda, w)$ by integrating Eq. (5.56), and we find

5 Creation of the Signal

$$I(t,\lambda,w) = \int_{\lambda-w/2}^{\lambda+w/2} dI_{c1}(t,\lambda')d\lambda' = I_c(t) \int_{\lambda-w/2}^{\lambda+w/2} \Gamma(\lambda')d\lambda' = I_c(t)P_0(\lambda), \quad (5.60)$$

where

$$P_0(\lambda) = \frac{K_1}{K_2\sqrt{K_3}} \left(\arctan\left[\sqrt{K_3} \tanh K_2(\lambda + \frac{w}{2})\right] - \arctan\left[\sqrt{K_3} \tanh K_2(\lambda - \frac{w}{2})\right] \right).$$
(5.61)

We call $P_0(\lambda)$ the *pad response function*. The fact that the signal on the entire cathode plane is equal to half the total cathode signal is verified by evaluating

$$\lim_{w \to \infty} P_0(\lambda) = \frac{1}{2}.$$
(5.62)

The pad response function depends on the strip width w. Figure 5.16 shows some examples calculated for various w's using the charge distribution displayed in Fig. 5.15. The pad response function determines what fraction of the total cathode signal is induced in the strip as a function of the distance between the centre of the strip and the avalanche position (measured in the cathode plane). Equation (5.62) implies that this fraction would reach 50% for an infinitely wide strip. For narrower strips it is still quite large, the example of Fig. 5.16 shows that 22% is collected when the avalanche is at the centre of a strip with width 0.75h and 11% if it is over the centre of the neighbouring strip. For the measurement of tracks an effective pad response function $P_{eff}(\lambda)$ is applicable, which results from folding in the distribution of the positions of avalanches that contribute to the cathode strip signal. This $P_{eff}(\lambda)$ can either be constructed using the methods described above





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or be measured by fitting tracks. Often a simple superposition of Gauss curves is sufficient.

The measurement of the coordinate of the avalanche is made by interpolating the signals recorded on adjacent cathode strips with the help of the effective pad response function $P_{eff}(\lambda)$. The strip width w and the cathode distance h have to be chosen such that the typical pulse height induced on two or three adjacent strips falls into the dynamic range of the readout electronics. If the resolution limit for position determination along the wire is given by the electronics pulse-height measurement, a strip width near the cathode-anode distance ($w \approx h$) gives the best position resolution [GAT 79]. When the coordinate of the avalanche is exactly in between two strips, it induces two equal signals on them. If the avalanche is produced in correspondence with the centre of one strip, it induces a large signal on it and two smaller signals on the two adjacent strips. Typically one records two signals in the first case and three in the second.

Measuring the signal $I_1(t)$ and $I_2(t)$ on two adjacent cathode strips of pitch *w* we have the relations $I_1(t)/I_2(t) = P_0(\lambda)/P_0(\lambda - w)$, which can be inverted to yield the avalanche position λ . Measuring the signals on three adjacent strips over-constrains the equation and leads to a further improvement of the position resolution. With

$$\frac{I_2(t)}{I_1(t)} = p_1 = \frac{P_0(\lambda_1)}{P_0(\lambda_1 - w)} \qquad \frac{I_2(t)}{I_3(t)} = p_2 = \frac{P_0(\lambda_2)}{P_0(\lambda_2 + w)}$$
(5.63)

we find λ_1 and λ_2 which determines the same avalanche position. Since the measurement error is roughly inversely proportional to the recorded pulse height on the outer strips, one may use the relative weights of p_1^2 and p_2^2 to estimate λ from the two independent measurements

$$\lambda = \frac{1}{p_1^2 + p_2^2} \left(p_1^2 \lambda_1 + p_2^2 \lambda_2 \right)$$
(5.64)

In order to achieve a precise signal measurement, the readout electronics will use a signal processing filter that optimizes the signal-to-noise ratio. Such a processing chain leaves the ratio of signals on neighbouring strips unchanged as long as it is the same for the strips involved.

Another common way of determining the avalanche position is to simply determine the centre of gravity of the strip charges or to apply a Gaussian type fit to the measured charges [END 81]. All of these methods introduce systematic errors as a function of the distance of the track from the strip centre ('differential nonlinearity'), but these can be corrected with suitable models.

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Chapter 6 Electronics for Drift Chambers

The signals induced on the drift chamber electrodes must be processed by appropriate readout electronics. The design and specification of the electronic circuits depend strongly on the detector application. For timing purposes one typically wants fast amplifiers to reduce time walk effects. For applications where charge measurement is required one prefers long integration times (slower amplifiers) in order to integrate a large fraction of the detector signal. For high-rate applications, signal tail cancellation and baseline restoration are important issues in order to avoid signal pileup and baseline fluctuations. The electronics noise level must be considered as well as it determines the required chamber gas gain for the desired signal-to-noise ratio.

The art and science of electronics is a universe of its own, and we cannot develop the contents of this chapter from the basic principles as we have undertaken to do in the other chapters of this book. Here it is our task to collect the concepts that allow us to arrive at the electronics specifications for particular detector applications. The numerous ways of realizing the actual circuits are also not part of this book. The reader interested in a more detailed treatment of electronic signal processing may want to consult the textbooks of Oppenheim and Willsky [OPP 97] (mathematical tools), Nahvi and Edminster [NAH 03], Horowitz and Hill [HOR 89] (basic introduction to electronic circuits), Nicholson [NIC 73] (nuclear electronics), Radeka [RAD 88] (low noise techniques), and Rehak [REH 83] and Gatti [GAT 85] (signal processing for particle detectors).

The front-end electronics of wire chambers, or at least their first stages, are typically *linear* signal processing devices. A linear signal processing device has the property that a given input pulse shape $I_{in}(t)$ results in an output pulse shape $V_{out}(t)$ which is independent of the signal amplitude, i.e., $V_{out}[c \times I_{in}(t)] = c \times V_{out}[I_{in}(t)]$ for any value of the constant *c*.

There are important advantages of linearity: in position-sensitive wire chambers with cathode segmentation for cathode charge interpolation (Sect. 5.7.2), the track position is determined by the ratio of the charges induced on neighbouring strips or pads. If the readout electronics were nonlinear, one would have to apply a pulse-height-dependent correction of the position, which is undesirable. Another compelling reason for linearity is related to signal shaping. The long $1/(t + t_0)$ tail of the wire chamber signal leads to signal pileup and hence to rate limitations. For this reason one introduces filters (shapers) which reduce the pulse width. If the amplifier stages preceding the shaper are nonlinear, the signal shapes arriving at the shaper vary according to their amplitude, which makes the shaper circuit with fixed parameters inefficient. For linear electronics the shaper just has to be matched to the input pulse shape, i.e., to the parameter t_0 for the given wire chamber geometry.

An amplifier is traditionally considered a device that produces an amplified copy of the input signal. For example, the output of an ideal voltage amplifier for an input voltage signal $v_{in}(t)$ is $v_{out}(t) = G \times v_{in}(t)$, where G is the (dimensionless) voltage gain of the amplifier. Figure 6.1a shows how a voltage signal induced on a detector electrode is read out by a voltage amplifier. In order to create an exact copy of the induced voltage signal the input impedance of the voltage amplifier must be infinite, because for finite input impedance we would find a current flowing into the amplifier, which would change the voltage $V_3(t)$.

Figure 6.1b shows a set of grounded electrodes where the moving charge induces currents. Such a current can be read out by an ideal current-sensitive amplifier, which produces an output voltage signal $v(t) = ki_3(t)$. The 'gain' k has the dimension of Ω and it would be more precise to call this device a current-to-voltage converter. The input impedance of the device must be zero so that the electrodes stay at ground potential.

Figure 6.2 shows the realization of voltage and current amplifiers using an operational amplifier, which is a device with very high voltage gain, very high input impedance, and very high bandwidth, ideally all being infinite. The voltage amplifier shown in Fig. 6.2a has a gain of $G = V_2/V_1 = 1 + R_2/R_1$ and infinite input impedance. The output voltage V_2 is independent of the load R_L . The current amplifier shown in Fig. 6.2b has a gain of $k = V_2/I_1 = -R$ and zero input impedance. Also for this device the output voltage V_2 is independent of the load R_L . If we were just interested in a copy of the induced signal, the electronics chapter of this book would end at this point. In practice the induced signal must be processed and transformed by several filters in order to arrive at a useful signal-to-noise ratio, pulse width, and frequency spectrum of the output signal, because these quantities determine the



Fig. 6.1 (a) An ideal voltage amplifier with gain G and infinite input impedance reading the voltage signal induced on the detector electrode. (b) An ideal current amplifier with conversion factor k and input impedance zero reading the current signal induced on the detector electrode

6.1 Linear Signal Processing



Fig. 6.2 Realization of a voltage amplifier (a) and a current amplifier (b) by using an operational amplifier

charge measurement accuracy, the rate capability, and the crosstalk behaviour of the detector.

The signal filtering is also called signal shaping, and the readout electronics are sometimes separated into an 'amplifier' and a 'shaper'. In the following chapters we only use the word 'amplifier' for the entire linear signal processing chain of the readout electronics.

We conclude this introduction by noting that the vocabulary and tradition in the field of detector electronics is somewhat different from the sometimes more familiar field of radio and telecommunication electronics. Whereas the latter is formulated almost exclusively in the frequency domain, detector signals are mostly discussed in the time domain. For detector signals we are interested in pulse height, signal-to-noise ratio, pulse width, signal pileup, and rate capability. All these numbers are associated with the amplitude and time dependence of detector signals. In the frequency domain the effect of a filter applied to a signal is simply the product of the signal and the filter transfer function. The equivalent operation in the time domain is the convolution of the input signal with the amplifier delta response. As we discuss mostly time domain signals we make frequent use of the convolution integral.

Before describing the readout electronics we review the necessary vocabulary and mathematical tools required for analysis of linear signal processing devices.

6.1 Linear Signal Processing

The *Laplace* and *Fourier* transformations of time domain signals are essential tools for electrical circuit analysis. The following section summarizes the principal relationships and examples that are used for later discussion of the actual front-end electronics. Details of these techniques can be found in numerous textbooks; we follow the nomenclature and definitions given in [OPP 97].

6.1.1 Laplace and Fourier Transforms

The Laplace transform of a time-dependent function f(t) is defined by

$$\mathscr{L}[f(t)] = F(s) = \int_{-\infty}^{\infty} f(t) e^{-st} dt, \qquad (6.1)$$

where *s* is a complex number with real part σ and an imaginary part ω : $s = \sigma + i\omega$. This definition is called the 'bilateral' Laplace transform because the integration extends from $-\infty$ to ∞ . In the case where f(t) = 0 for t < 0 the transform is equal to the unilateral Laplace transform, which has a lower integration limit of 0. While F(s) has no direct physical interpretation, the Fourier transform of the signal, defined by

$$\mathscr{F}[f(t)] = \int_{-\infty}^{\infty} f(t) e^{-i\omega t} dt = F(i\omega) \qquad \omega = 2\pi f, \tag{6.2}$$

expresses the signal as a superposition of sinusoidal waves of frequency f with amplitudes $|F(i\omega)|$ and relative phases $\arg[F(i\omega)]$. The Fourier transform is a special case of the bilateral Laplace transform with $\sigma = 0$. The inverse transforms are

$$f(t) = \frac{1}{2\pi i} \int_{\sigma - i\infty}^{\sigma + i\infty} F(s) e^{st} ds \qquad f(t) = \frac{1}{2\pi} \int_{-\infty}^{\infty} F(i\omega) e^{i\omega t} d\omega.$$
(6.3)

The transformations of the most common functions are tabulated in standard textbooks. For the Laplace and Fourier transforms, the following relations hold (proofs can be found in [OPP 97]):

(a) Addition

$$\mathscr{L}[af(t) + bg(t)] = aF(s) + bG(s) \qquad \mathscr{L}\left[\int_{-\infty}^{\infty} f(t - t')g(t')dt'\right] = F(s)G(s)$$
(c) Time differentiation

$$\mathscr{L}\left[f^{(n)}(t)\right] = s^{n}F(s) \qquad (d) \text{ Time integration}$$

$$\mathscr{L}\left[f^{(n)}(t)\right] = s^{n}F(s) \qquad \mathscr{L}\left[\int_{-\infty}^{t} f(t')dt'\right] = \frac{1}{s}F(s)$$
(e) Time shift
(f) Time scaling

$$\mathscr{L}[f(t - t_{0})] = F(s)e^{-st_{0}} \qquad \mathscr{L}[f(at)] = \frac{1}{a}F(\frac{s}{a})$$
(g) Damping

$$\mathscr{L}[e^{-s_{0}t}f(t)] = F(s + s_{0}) \qquad \mathscr{L}[t^{n}f(t)] = (-1)^{n}F^{(n)}(s)$$
(i) Initial value if $f(t) = 0$ for $t < 0$ (j) Final value

$$f(0^{+}) = \lim_{s \to \infty} sF(s) \qquad f(\infty) = \lim_{s \to 0} sF(s)$$
(k) Parseval's theorem

$$\int_{-\infty}^{\infty} f(t)^{2}dt = \int_{-\infty}^{\infty} |F(i2\pi f)|^{2}df \qquad = 2\int_{0}^{\infty} |F(i2\pi f)|^{2}df$$
(6.4)

The usefulness of these transformations for electrical circuit analysis is illustrated by the following example. The voltage $v_R(t)$ across a resistor R for an impressed current i(t) is given by Ohm's law as $v_R(t) = Ri(t)$. The voltage across a capacitor C for an impressed current i(t) is $v_C(t) = 1/C \int i(t)dt$. The voltage across an inductance L for an impressed current i(t) is given by $v_L(t) = Ldi(t)/dt$. Voltages and currents in a circuit containing R, L, and C elements are determined by applying Kirchhoff's laws, which state that the sum of voltages in every loop must be zero and the sum of the currents on every node must be zero. This analysis therefore leads to a set of linear differential equations for the currents and voltages in the circuit.

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Writing the above relations in the Laplace domain, we find $V_R(s) = RI(s)$, $V_C(s) = I(s)/sC$, and $V_L(s) = sLI(s)$, and the circuit relations become algebraic equations. Instead of having to solve a set of coupled differential equations in the time domain we just have to solve a set of linear algebraic equations in the Laplace domain! In addition, owing to the theorems stated above, many signal manipulations are strongly simplified when working in the Laplace domain.

Finally we define the impedance Z(s) of a circuit element as Z(s) = V(s)/I(s). We find the impedance of $Z_C(s) = 1/sC$ for a capacitor and $Z_L(s) = sL$ for an inductor. In analogy to the resistance $R_1 + R_2$ of two resistors switched in series, the total impedance of two impedances Z_1 and Z_2 switched in series is $Z_1 + Z_2$. Likewise, the parallel application of the impedances gives a total impedance of $Z_1Z_2/(Z_1+Z_2)$.

6.1.2 Transfer Functions, Poles and Zeros, Delta Response

We now want to read out the chamber output signal i(t) with a general linear signal processing device. Such a signal is, e.g., the current signal i(t) of the drift tube indicated in Fig. 5.10. A linear device is defined by the following property: if the input signals $i_1(t)$ and $i_2(t)$ result in output signals $v_1(t)$ and $v_2(t)$, the input signal $i(t) = c_1i_1(t) + c_2i_2(t)$ will result in the output signal $v(t) = c_1v_1(t) + c_2v_2(t)$.

The input and output signals of a linear, time-invariant, and causal device are related by a differential equation of the following form:

$$a_0 v(t) + a_1 \frac{dv(t)}{dt} + \dots + a_m \frac{d^m v(t)}{dt^m} = b_0 i(t) + b_1 \frac{di(t)}{dt} + \dots + b_n \frac{d^n i(t)}{dt^n}, \quad (6.5)$$

where the coefficients a and b are independent of time. The term 'time-invariant' describes the fact that the relation between input and output signals is independent of time. For a 'causal' system the output signal v(t) is zero as long as the input signal i(t) is zero.

Performing the Laplace transform and using Eq. (6.4c) transforms this equation into an algebraic equation with the solution

$$V(s) = \frac{b_0 + b_1 s + \dots + b_n s^n}{a_0 + a_1 s + \dots + a_m s^m} I(s) = W(s)I(s),$$
(6.6)

where we have defined $\mathcal{L}[i(t)] = I(s)$ and $\mathcal{L}[v(t)] = V(s)$. The function W(s) is called the *transfer function* of the system and we see that the transfer function of a linear time-invariant system can be expressed by the ratio of two polynomials in the Laplace domain.

Setting $s = i\omega$ yields the transfer function in the Fourier domain and the relationship between input and output signals is

$$V(i\omega) = W(i\omega)I(i\omega). \tag{6.7}$$

Separating the signal I and the transfer function W into the absolute value and the phase indicates how the frequencies contained in the input signal are separately transformed in order to yield the output signal:

$$V(i\omega) = |I(i\omega)||W(i\omega)|\exp[i\arg[I(i\omega)] + i\arg[W(i\omega)]].$$
(6.8)

The sinusoidal components of the input signal *I* are scaled by |W| and phase shifted by $\arg[W]$. For very high frequencies the transfer function from Eq. (6.6) behaves as

$$|W(i\omega)| = \propto \omega^{n-m}.$$
(6.9)

A system where n > m is non-physical because it would result in infinite amplification at infinite frequency. We can therefore state that for the transfer function of a realistic linear device we have $n \le m$. An *n*th-order polynomial has *n* (real and complex) roots, so the transfer function W(s) can be expressed as

$$W(s) = A \frac{(s-z_1)(s-z_2)\dots(s-z_n)}{(s-p_1)(s-p_2)\dots(s-p_m)}.$$
(6.10)

The roots $s = z_1, z_2...$ are the zeros of W(s) and $s = p_1, p_2...$ are the poles of W(s). In general, z_i and p_i are complex numbers, and some of the roots may be repeated. In the Laplace domain, the transfer function of a linear signal processing device can therefore be fully described by its poles, its zeros, and a constant gain factor *A*.

A unit input signal I(s) = 1 will result in the output signal V(s) = W(s). Returning to the time domain we have $\mathcal{L}^{-1}[1] = \delta(t)$ and $\mathcal{L}^{-1}[W(s)] = w(t)$. The inverse Laplace transform of the transfer function is thus the output signal for a unit delta input signal, which we call the *delta response* of the system. Since, according to Eq. (6.4b), a multiplication in the Laplace domain corresponds to a convolution in the time domain, in the latter Eq. (6.6) reads as

$$v(t) = \int_{-\infty}^{\infty} w(t - t') i(t') dt'.$$
 (6.11)

If w(t) and i(t) are causal, meaning that w(t) = i(t) = 0 for t < 0, the convolution integral reads as

$$v(t) = \int_0^t w(t - t')i(t') dt'.$$
(6.12)

The transfer function W(s) and the delta response w(t) are two equivalent ways of describing a linear system, and this is symbolized in Fig. 6.3. Using partial fraction expansion, we can write the transfer function W(s) in Eq. (6.10) with $m \ge n$ as a sum of terms with the form $1/(s - p_i)^{k_i}$, where $k_i \ge 0$ are integers and the poles are complex numbers $(p_i = a_i + ib_i)$. The delta response w(t) of a linear system therefore becomes a sum of terms with the form

$$\mathscr{L}^{-1}\left[\frac{1}{(s-p_i)^{k_i}}\right] = \frac{t^{k_i-1}}{(k_i-1)!} e^{a_i t} \left[\cos(b_i t) + i\sin(b_i t)\right] \Theta(t) \qquad k_i \ge 1.$$
(6.13)

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Fig. 6.3 A linear device is characterized by the transfer function W(s) in the Laplace domain or the delta response $w(t) = \mathcal{L}^{-1}[W(s)]$ in the time domain

The step function $\Theta(t)$ is defined in Eq. (6.16). For k = 0 we have $\mathscr{L}^{-1}[1] = \delta(t)$. If $a_i > 0$, the delta response tends to infinity for $t \to \infty$, so the criterion for stability of a linear system is given by the requirement that the real parts of *all* poles of W(s) must be negative. In the case where $a_i + ib_i$ is a root of a polynomial, the complex conjugate $a_i - ib_i$ is also a root of the polynomial. Thus the terms in Eq. (6.13) always appear in complex conjugate pairs, the imaginary part is cancelled, and the delta response is always real.

Figure 6.4 shows an example of the terms from Eq. (6.13) for k = 2, 4, 6 and $b_i = 0$. In this book we mainly discuss transfer functions with real poles. The imaginary parts of poles arise from inductances. (As these cannot be implemented physically as coils in integrated devices, one would make them feedback loops using operational amplifiers).

6.1.3 CR, RC, Pole-zero and Zero-pole Filters

In this section we discuss four elementary filters that illustrate the formalism outlined in the previous section. They are also elementary in the sense that by cascading these four filter types we can construct any desired transfer function W(s) with real poles. If we wanted to construct the most general transfer function W(s) also including complex poles we would have to add a few elementary circuits containing an inductance *L*. The CR and RC filters are shown in Fig. 6.5. The output voltages of the two filters for an input voltage signal $V(s) = \mathcal{L}[v(t)]$ are

Fig. 6.4 The delta response w(t) of a linear network with real poles consists of the sum of shapes indicated in this figure. In the case where W(s) has complex poles we find terms with an oscillatory behaviour of frequency $b_i/2\pi$ and a damping factor of $\exp(-a_i t)$



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Fig. 6.5 A CR (left) and RC (right) filter consisting of a resistor R and a capacitor C. A voltage signal v(t) is transformed into the output voltage signals $v_1(t)$ and $v_2(t)$

$$V_1(s) = \frac{sRC}{1 + sRC} V(s) = \frac{s\tau}{1 + s\tau} V(s) = W_{CR}(s) V(s)$$
(6.14)

$$V_2(s) = \frac{1}{1 + sRC} V(s) = \frac{1}{1 + s\tau} V(s) = W_{RC}(s) V(s).$$
(6.15)

The value $\tau = RC$ is the characteristic time constant of the filters. In the following we frequently use the step function $\Theta(t)$, which is defined by

$$v(t) = \Theta(t) = \begin{cases} 0 & t \le 0\\ 1 & t > 0 \end{cases} \qquad V(s) = \mathscr{L}[v(t)] = \frac{1}{s}.$$
(6.16)

Applying this voltage step of amplitude V_0 at the inputs of the two filters yields the output signals

$$V_1(s) = \frac{V_0 \tau}{1 + s\tau}$$
 $V_2(s) = \frac{V_0}{s(1 + s\tau)}$. (6.17)

Returning to the time domain, we find

$$v_1(t) = V_0 e^{-\frac{t}{\tau}} \Theta(t)$$
 $v_2(t) = V_0 (1 - e^{-\frac{t}{\tau}}) \Theta(t)$ (6.18)

The two responses are shown in Fig. 6.6. The output of the CR filter decays exponentially from the value V_0 to 0, while the output of the RC filter increases exponentially from 0 to V_0 . We can also calculate the output signal in the time domain by finding the delta response of the circuit $w(t) = \mathcal{L}^{-1}[W(s)]$ and convoluting it with the input signal:

$$w_{CR}(t) = \delta(t) + \frac{1}{\tau} e^{-\frac{t}{\tau}} \Theta(t) \qquad \qquad w_{RC}(t) = \frac{1}{\tau} e^{-\frac{t}{\tau}} \Theta(t) \tag{6.19}$$



Fig. 6.6 Output of the CR and RC filter for a voltage step function input

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$$v_{1}(t) = \int_{0}^{t} \left(\delta(t - t') - \frac{1}{\tau} e^{-\frac{t - t'}{\tau}} \Theta(t - t') \right) V_{0} \Theta(t') dt' = V_{0} e^{-\frac{t}{\tau}} \Theta(t)$$
$$v_{2}(t) = \int_{0}^{t} \left(\frac{1}{\tau} e^{-\frac{t - t'}{\tau}} \Theta(t - t') \right) V_{0} \Theta(t') dt' = V_{0} \left(1 - e^{-\frac{t}{\tau}} \right) \Theta(t) .$$
(6.20)

We find the same result as before. If we replace *s* by $i\omega$ we have the transfer function in the Fourier (frequency) domain:

$$W_{CR}(i\omega) = \frac{i\omega\tau}{1+i\omega\tau} = \frac{\omega\tau}{\sqrt{1+\omega^2\tau^2}} \exp\left[i\arctan 1/\omega\tau\right],$$

$$W_{RC}(i\omega) = \frac{1}{1+i\omega\tau} = \frac{1}{\sqrt{1+\omega^2\tau^2}} \exp\left[i\arctan\omega\tau\right].$$
(6.21)

The absolute values and the phases of the transfer functions are shown in Fig. 6.7. At the frequency $\omega_0 = 1/\tau$, the input voltage is attenuated by $1/\sqrt{2} \approx 0.707$ by both filters. The CR filter attenuates frequencies $\omega < \omega_0$ while high frequencies are passing the circuit, so the CR circuit is called a high-pass filter. The RC circuit passes low frequencies and attenuates high frequencies and is called a low-pass filter. At the frequency ω_0 , the phase shift between the input and the output voltage is $\arctan(1) = \pi/4 = 45^\circ$.

From Eq. (6.4c,d) we know that the differentiation in the time domain corresponds to a multiplication with s in the Laplace domain and that the integration in the time domain corresponds to division by s in the Laplace domain. The transfer function of a 'differentiator' or 'integrator' is therefore s or 1/s. The RC filter therefore becomes an integrator for large values of τ , or more precisely if the frequency $1/\tau$ is much lower than all the frequencies contained in the signal. The CR circuit approaches a differentiator if τ is small, i.e., if the frequency $1/\tau$ is much higher than the frequencies contained in the input signal.

To conclude this section we investigate the pole-zero and zero-pole filters shown in Fig. 6.8, which are used extensively for signal shaping. The transfer functions of the two filters are given by



Fig. 6.7 Absolute value and phase of the transfer function for an RC (low-pass) and a CR (highpass) filter. At the frequency $\omega_0 = 1/\tau$ the input voltage is attenuated by $1/\sqrt{2} \approx 0.707$ and the phase shift between the input and the output signal is $\pi/4 = 45^{\circ}$



Fig. 6.8 Pole-zero (a) and zero-pole (b) filters used for unipolar shaping of exponential signals

$$W_{PZ}(s) = \frac{s+1/\tau_1}{s+1/\tau_2} \qquad \tau_1 = R_1 C \quad \tau_2 = \frac{R_1 R_2}{R_1 + R_2} C \qquad \tau_1 > \tau_2 \qquad (6.22)$$

and

$$W_{ZP}(s) = \frac{\tau_1}{\tau_2} \frac{s + 1/\tau_1}{s + 1/\tau_2} \qquad \tau_1 = R_2 C \quad \tau_2 = (R_1 + R_2) C \qquad \tau_1 < \tau_2.$$
(6.23)

Equations (6.22) and (6.23) are direct applications of the concepts presented in the last paragraph of Sect. 6.1.1. The first filter is called pole-zero because the transfer function has a single pole and a single zero, and the pole $s = -1/\tau_2$ is smaller than the zero $s = -1/\tau_1$ of the transfer function. For the zero-pole filter the zero is smaller than the pole. The transfer functions of both filters are shown in Fig. 6.9a. The pole-zero filter passes low frequencies and attenuates high frequencies by $k = R_2/(R_1 + R_2)$. The zero-pole filter attenuates low frequencies by a factor *k* and passes high frequencies. At a frequency $\omega = 1/\sqrt{\tau_1 \tau_2}$ the input voltage is attenuated by \sqrt{k} for both filters, which is the geometric mean of the transfer functions at zero frequency and infinite frequency.

Applying an exponential signal with time constant τ_1 to the input of both filters with time constants τ_1 and τ_2 results in an exponential output signal with time constant τ_2 (Fig. 6.9b) [NIC 73]:





Fig. 6.9 (a) Transfer functions of the pole-zero and zero-pole filter. (b) Output of both filters for an input signal with the form $\exp(-t/\tau_1)$. The output signal is an exponential with time constant τ_2 , so the pole-zero filter shortens the exponential tail while the zero-pole filter lengthens the tail

Therefore the pole-zero filter is used for shortening exponential signal tails in electronic circuits, and we also use it later to shorten the tail of wire chamber signals.

For later use we give the delta response of the pole-zero filter, which evaluates to

$$w_{PZ}(t) = \mathscr{L}^{-1}[W_{PZ}(s)] = \delta(t) - \frac{\tau_1 - \tau_2}{\tau_1 \tau_2} e^{-\frac{t}{\tau_2}} \Theta(t).$$
(6.25)

As mentioned above, we only discuss transfer functions with real poles in this book. A transfer function of this kind can be represented by a sequence of CR, RC, pole-zero and zero-pole filters because the form given in Eq. (6.10) can be interpreted as a product of suitably chosen transfer functions W_{CR} , W_{RC} , W_{PZ} , and W_{ZP} .

6.1.4 Cascading of Circuit Elements

Let us assume two RC filters which are connected as shown in Fig. 6.10. An application of the combination rules of the four impedances (Sect. 6.1.1) yields the transfer function

$$V_2(s) = \frac{V(s)}{(k+sRC)(1/k+sRC)} \quad \neq \quad \frac{V(s)}{(1+sRC)^2}$$
(6.26)

with $k = (3 - \sqrt{5})/2$. The transfer function of two cascaded circuit elements is therefore not simply equal to the product of the two individual transfer functions. The reason is that the second RC filter takes current out of the first filter so that the voltage at its output is no longer $V_1 = 1/(1 + sRC)V(s)$.

In order to decouple the two circuits we must introduce a so-called voltage buffer between them, which is an active device of infinite input impedance, infinite bandwidth, and voltage gain G. Such a buffer produces an output signal which is an exact copy of the input signal scaled by G. Owing to the infinite input impedance, no current is taken out of the first RC circuit and the transfer function becomes the product of the individual transfer functions. A realization of such a buffer was shown earlier in Fig. 6.2a.



Fig. 6.10 (a) Series connection of two RC filters. As the second filter is 'loading' the first, the transfer function is different from the product of the individual transfer functions. (b) Two RC filters separated by a voltage buffer of infinite input impedance. For this setup the transfer function is given by $W(s) = W_{RC}(s)W_{RC}(s)$

We conclude that a cascade of circuit elements with individual transfer functions $W_1(s), W_2(s) \dots W_n(s)$, which are decoupled by ideal voltage buffers, has a transfer function equal to the product

$$W(s) = W_1(s) \times W_2(s) \times \ldots \times W_n(s).$$
(6.27)

6.1.5 Amplifier Types, Bandwidth, Sensitivity, and Ballistic Deficit

The practical realizations of linear signal processing systems discussed above are amplifiers and filter circuits connected to the detector electrodes. Parameters that characterize these devices, such as gain and bandwidth, have a range of differing definitions in the literature on microelectronics. We therefore review and define the vocabulary for the discussion of detector electronics.

Bandwidth Limit: In the frequency domain, an amplifier is characterized by the gain $|W(i\omega)|$ and the phase shift $\arg[W(i\omega)]$ for each frequency. The bandwidth limit of an amplifier is defined as the frequency at which the signal transmission has been reduced by 3 dB from the central or midrange reference value. Since the power level is defined as $10\log(P/P_{ref})$ dB and the voltage level as $20\log(V/V_{ref})$ dB, a 3 dB reduction corresponds to a power level of ≈ 0.5 and a voltage level equal to $\approx 0.708 \approx 1/\sqrt{2}$ of the value at the centre frequency reference [MOT 93]. The bandwidth limit of the RC low-pass filter is thus given by $f_{bw} = 1/2\pi\tau = 1/2\pi RC$.

Rise Time, Peaking Time: The rise time t_r of a pulse is defined as the time taken for its leading edge to rise from 10 to 90% of the peak height. The peaking time t_p of a pulse is defined as the time taken for its leading edge to rise from zero to peak height. When we talk about the peaking time of an amplifier we mean the peaking time of its delta response.

Voltage, Current, and Charge Amplifiers: A voltage amplifier processes a voltage signal presented at its input and is characterized by high input impedance. A current amplifier processes the current signal flowing into the amplifier and is characterized by low input impedance. The signals in wire chambers are induced current signals, as discussed in the previous chapter. The example of the drift tube in Sect. 5.6.1 shows that the detector capacitance C_{det} together with the input resistance R_{in} forms an integration stage with bandwidth limit of $f_{bw} = 1/2\pi R_{in}C_{det}$, which is undesirable if one wants to preserve the fast signal. In order to preserve the chamber signal shape, the input impedance of the amplifier must be small compared to all other impedances in the detector or in the ideal case, equal to zero, which means that we use current amplifiers for readout of wire chambers. If the bandwidth of the current amplifier is such that it integrates a significant fraction of the chamber signal, or the entire chamber signal, it is usually called a charge amplifier.

Sensitivity of Current and Charge Amplifiers: The filters discussed in the previous sections transform an input voltage signal to an output voltage signal, and therefore the dimension of the transfer function is [W(s)] = 1. The transfer function of a current amplifier that transforms a current input signal into a voltage output signal can be written as V(s) = kW(s)I(s), where *k* has dimensions of V/A= Ω and

6.1 Linear Signal Processing

W(s) keeps the dimension 1. In the time domain the relationship between the input and output signals is

$$v(t) = k \int w(t-t')i(t')dt' = kw(t_p) \int \frac{w(t-t')}{w(t_p)}i(t')dt' = g \int h(t-t')i(t')dt'.$$
(6.28)

The value $w(t_p)$ is the peak of the delta response w(t), and the dimensionless function h(t) is the normalized delta response. An input current pulse of $i(t) = Q\delta(t)$ results in an amplifier output peak voltage of $v(t_p) = gQ$. We call g which has the dimension V/C, the sensitivity of the amplifier, Typical wire chamber amplifiers have sensitivities in the range of 1–50 mV/fC.

Ballistic Deficit: If a current amplifier has a peaking time t_p which is much longer than the duration of the input current signal i(t), the convolution integral can be approximated and the output pulse is given by

$$v(t) = g \int h(t - t')i(t')dt' \approx gh(t) \int i(t')dt' = gh(t)Q_{tot}.$$
 (6.29)

The peak of the output signal is gQ_{tot} . The output pulse height is therefore proportional to the total signal charge and such an amplifier is called a *charge amplifier*. For timing purposes or due to high signal rates, one typically wants to preserve the signal speed and keep the pulse width to a minimum. Although the amplifiers used for wire chambers will always have peaking times shorter than the maximum drift time of the ions, an amplifier that integrates a significant fraction of the induced charge is traditionally still called a charge amplifier.

As long peaking times limit the rate capability of a detector one usually has to live with a compromise between pulse-width and charge measurement accuracy. The incomplete measurement of the signal charge is characterized by the so-called *ballistic deficit*, which is defined as the difference between the amplifier output pulse height for the input signal i(t) and the output pulse height if the entire input signal charge $Q_{tot} = \int i(t)dt$ is contained in a delta current pulse $Q_{tot} \delta(t)$.

Equivalent Block Diagram: In Sect. 6.1.1 we saw that the transfer function W(s) of a linear electronic circuit is specified by an expression of the form

$$W(s) = A \frac{(s-z_1)(s-z_2)\dots(s-z_n)}{(s-p_1)(s-p_2)\dots(s-p_m)}.$$
(6.30)

Let us now assume that we have defined such a transfer function and we want to find an electronic circuit realization of it. As an example we assume that we want to transform a voltage signal $V_1(s)$ by the transfer function

$$V_2(s) = W(s)V_1(s) = G \frac{s+\alpha}{(s+\beta)(s+\gamma)} V_1(s),$$
(6.31)

where α, β , and γ are positive and real. We can interpret W(s) as the product of a pole-zero filter and an RC filter, so a possible realization of this transfer function can be seen in Fig. 6.11, where a pole-zero and an RC filter are coupled by an





ideal voltage buffer of gain G. Such a representation is of course not unique and there are several ways to realize a transfer function. The important point is that any transfer function can be represented by a cascade of simple, elementary circuits, which facilitates the circuit analysis and serves as a basis for the actual design.

Up to now we have investigated filters that convert voltage input signals into voltage output signals. However, the signals induced on chamber electrodes are current signals, so for our block diagram representation we need an idealized device which converts a current input signal into a voltage signal. We assume an idealized device with infinite bandwidth such that for a current input signal i(t) we get a voltage output signal v(t) = ki(t). With this device we can complete our block diagram representation of the detector readout electronics (Fig. 6.12). In principle this kind of block diagram can also be used for a practical realization, where the voltage buffer and current to voltage converter are devices with a bandwidth that must be broader than the bandwidth of the other circuit elements. Although most designs of chamber electronics consist of cascaded blocks with intermediate buffers, there are numerous different ways of realizing the individual transfer functions. As outlined earlier, the goal of this chapter is not the design a practical realization of the readout electronics but its precise specification. The block diagram defined above serves as a basis for the circuit realization.

6.2 Signal Shaping

The transfer function W(s) of the readout electronics must be chosen in order to optimize the measurement of the quantity of interest, such as signal charge or signal time. For this discussion the electronics noise plays a key role, and we have to characterize noise sources and apply the theory of optimum filtering. Parameters



Fig. 6.12 An ideal current to voltage converter followed by a CR and pole-zero filter

to be considered for this optimization process are rate capability (pulse width) and crosstalk as well as the practical aspects for the realization of the electronics.

In this section we first discuss two common examples of amplifier transfer functions, a unipolar and bipolar shaper, and we discuss their characteristics as outlined in the last section. After that we describe various techniques to remove the long $1/(t+t_0)$ tail of wire chamber signals in order to avoid pileup of signals at high rates.

6.2.1 Unipolar and Bipolar Signal Shaping

Two commonly used transfer functions for signal shaping, a so-called unipolar shaper and bipolar shaper, are defined by

$$W_{uni}(s) = kA \frac{1}{(1+s\tau)^{n+1}}$$
 $W_{bip}(s) = kA \frac{s\tau}{(1+s\tau)^{n+1}}.$ (6.32)

The equivalent block diagram of the unipolar shaper (Fig. 6.13a) consists of an ideal current-to-voltage converter with equivalent resistance k followed by n + 1 RC filters. The filters are separated by n ideal voltage buffers with voltage gains $G_1, G_2...G_n$, which results in a gain factor of $A = G_1G_2...G_n$. The bipolar shaper uses n RC filters followed by a single CR filter, as shown in Fig. 6.13b. The delta responses w(t) of the two shapers are calculated by performing the inverse Laplace transforms of Eqs. (6.32), which are tabulated in standard textbooks [OPP 97]. Writing w(t) = gh(t), with the peak of h(t) normalized to unity, we find

$$h_{uni}(t) = e^n \left(\frac{t}{n\tau}\right)^n e^{-\frac{t}{\tau}} \Theta(t) \quad h_{bip}(t) = \frac{e^r}{\sqrt{n}} \left(n - \frac{t}{\tau}\right) \left(\frac{t}{r\tau}\right)^{n-1} e^{-\frac{t}{\tau}} \Theta(t) \quad (6.33)$$



Fig. 6.13 (a) Unipolar shaping circuit consisting of n + 1 identical RC filters which are separated by ideal voltage buffers. (b) Bipolar shaping circuit consisting of n identical RC filters and a single CR filter with the same time constant



Fig. 6.14 Delta response for an unipolar shaper consisting of five RC filters and a bipolar shaper consisting of four RC filters and a single CR filter. (a) The plot gives the delta responses for the same value of τ and shows that the bipolar response is the derivative of the unipolar response. (b) The plot shows the two delta responses with the same peaking time

with the sensitivity

$$g_{uni} = \frac{kA}{\tau n!} \frac{n^n}{e^n} \qquad g_{bip} = \frac{kA}{\tau n!} \frac{r^n}{e^r} \frac{\sqrt{n}}{r} \qquad r = n - \sqrt{n}.$$
(6.34)

Figure 6.14a shows the two delta responses for n = 4. The unipolar shaper has a peaking time of $t_p = n\tau$. Mathematically the bipolar delta response is the derivative of the unipolar response, because $W_{bip}(s) = \tau s W_{uni}(s)$ and a multiplication with *s* in the Laplace domain corresponds to a derivative in the time domain [Eq. (6.4c)]. Thus the bipolar delta response crosses the zero line at $t = n\tau$. The peak and the minimum of the bipolar delta response are situated symmetrically around the zero crossing time at $t_p = \tau(n - \sqrt{n})$ and $t_m = \tau(n + \sqrt{n})$. If we want the peaking time t_p of the two shapers to be equal we have to use the RC time constant $\tau = t_p/n$ for the unipolar shaper and $\tau = t_p/r$ for the bipolar shaper.

$$h_{uni}(t) = \left(\frac{t}{t_p}\right)^n e^{n(1-t/t_p)} \Theta(t), \qquad (6.35)$$

$$h_{bip}(t) = \frac{1}{\sqrt{n}} \left(n - \frac{rt}{t_p} \right) \left(\frac{t}{t_p} \right)^{n-1} e^{r(1 - t/t_p)} \Theta(t), \tag{6.36}$$

$$H_{uni}(s) = \frac{t_p \ e^n n!}{(n+st_p)^{n+1}} \qquad H_{bip}(s) = \frac{1}{\sqrt{n}} \frac{st_p^2 \ e^r n!}{(r+st_p)^{n+1}}.$$
 (6.37)

Here we have used the symbols H(s) to represent the Laplace transforms of the delta responses h(t) normalized to unity at the peak. Figure 6.14b shows the two delta responses with identical peaking times and n = 4.

The absolute value of the transfer function for the two shapers with a peaking time t_p is given by

$$|W_{uni}(i\omega)| = \frac{kA}{\sqrt{\left(1 + \omega^2 t_p^2/n^2\right)^{n+1}}} \qquad |W_{bip}(i\omega)| = \frac{kA\,\omega t_p/r}{\sqrt{\left(1 + \omega^2 t_p^2/r^2\right)^{n+1}}}.$$
 (6.38)



Fig. 6.15 Absolute value of the transfer functions for the unipolar and the bipolar shaper as a function of the dimensionless number ωt_p , assuming n = 4. The plot in (**a**) has a linear coordinate, and the plot in (**b**) shows the two transfer functions in units of dB. The horizontal line indicates the -3 dB level. Both shapers attenuate frequencies higher than $\omega \approx 1/t_p$. The transfer function of the bipolar shaper shows a maximum at $\omega = (\sqrt{n} - 1)/t_p$ and monotonically decreases for lower frequencies. At zero frequency the transfer function of the bipolar shaper is zero

The two transfer functions are depicted in Fig. 6.15. The unipolar shaper passes all frequencies up to the 3-dB bandwidth limit of $\omega_{bw} = n\sqrt{2^{1/(n+1)} - 1/t_p}$, which evaluates to $\omega_{bw} \approx 1.54/t_p$ for n = 4. The transfer function of the bipolar shaper has a peak at $\omega = (\sqrt{n} - 1)/t_p$ and lower and higher frequencies are attenuated. For n = 4 the peak of the transfer function is located at $\omega = 1/t_p$ and the 3-dB bandwidth limit is $\omega_{bw} \approx 1.81/t_p$, similar to the one from the unipolar shaper. For our purposes it is sufficient to assume that the bandwidth limits of a unipolar and a bipolar shaper of the same peaking time t_p are identical. For DC signals, which means $\omega = 0$, the transfer function of the bipolar shaper is zero. The name 'bipolar shaper' comes from the fact that the positive part of the signal is followed by a negative part ('undershoot') of equal area, such that the time integral over the entire signal is zero. This follows from the fact that $H_{bip}(0) = 0$, which can be seen by using Eqs. (6.4d) and (6.4j):

$$\lim_{t \to \infty} g \int_{-\infty}^{t} h_{bip}(t') dt' = \lim_{s \to 0} s \frac{1}{s} H_{bip}(s) = H_{bip}(0) = 0.$$
(6.39)

In fact, for any device with a transfer function having the property W(0) = 0, the integral of the delta response w(t) is zero, which means that the positive signal part has an area equal to the negative signal part. The same is true for any output signal $V_1(s) = W(s)V(s)$ of the device:

$$\lim_{t \to \infty} \int_{-\infty}^{t} v_1(t') dt' = \lim_{s \to 0} s \frac{1}{s} W(s) V(s) = W(0) V(0) = 0.$$
(6.40)

In physical terms, the zero in the transfer function at $s = i\omega = 0$ implies that DC signals are fully attenuated. Only sinusoidal components with frequencies $\omega > 0$ pass the circuit, and because all individual sinusoidal components are bipolar the entire signal is bipolar.

A device with a transfer function W(s) having the property W(0) = 0 is called an AC coupled device. If W(0) is non-zero it is called DC coupled. The drift tube circuit discussed in Sect. 5.6.1 is an AC coupled system because the capacitor blocking the high voltage U from the amplifier also blocks the low-frequency components of the signal.

In the following we discuss the processing of a wire chamber signal by the two shapers discussed above. The currents flowing into the input of the readout electronics are typically not exactly equal to the current signals induced on the electrodes, but they are already 'shaped' by the effects of the passive detector elements preceding the amplifier together with the input impedance of the amplifier. In order to avoid the complications of this input circuit, which we discuss later, we consider for the moment only the drift tube from Sect. 5.5, where the tube wall is set to potential -U and the wire is grounded. We assume that the connection of the wire to ground is performed through a current amplifier of zero input impedance with transfer function W_{uni} or W_{bip} . The induced current signal is therefore equal to the current flowing into the amplifier and is given by the form

$$i(t) = \frac{q}{2t_0 \ln(b/a)} \frac{1}{1 + t/t_0} \qquad 0 < t/t_0 < t_{max} = \frac{b^2}{a^2} - 1.$$
(6.41)

As the Laplace transform of this signal cannot be written in closed form we calculate the output signal by numerical evaluation of the convolution of i(t) with the amplifier delta response. We assume the same sensitivity g and peaking time t_p for the unipolar and bipolar shaper. We must therefore perform the convolution of i(t) with $gh_{uni}(t)$ or $gh_{bip}(t)$, where we insert $\tau = t_p/n$ for the unipolar and $\tau = t_p/(n - \sqrt{n})$ for the bipolar shaper. We just present the integral for the unipolar shaper, which reads as

$$v(t) = g \int_0^t h_{uni}(t-t')i(t') dt' \longrightarrow$$

$$(6.42)$$

$$\frac{t}{q} = \frac{1}{2\ln(b/a)} \int_0^t \left[e \frac{t_0}{t_p} \left(\frac{t}{t_0} - \frac{t'}{t_0} \right) e^{-\frac{t_0}{t_p} \left(\frac{t}{t_0} - \frac{t'}{t_0} \right)} \right]^n \frac{1}{1 + (t'/t_0)} \frac{dt'}{t_0}.$$

As an example we use a drift tube with a parameter b/a = 100, giving a value of $t_{max} = 10^4 t_0$ for the signal duration. For a t_0 value of 1 ns this evaluates to $t_{max} = 10 \mu$ s. Figure 6.16a shows the amplifier output signals for n = 4 and a value for $t_p/t_0 = 10$. For a t_0 value of 1 ns this corresponds to an amplifier peaking time of 10 ns. The bipolar signal returns to zero after a time of $t/t_0 \approx 100$, while the output signal of the unipolar shaper shows a very long tail that will lead to signal pileup at high counting rates.

For our assumed parameters the signal has a peak of $v_p/gq = 0.22$, which means that the ballistic deficit is 78%. Figure 6.16b shows the amplifier output signal for increasing values of t_p/t_0 . The longer the peaking time the larger the signal and the smaller the ballistic deficit. For $t_p > t_{max}$ the signal peak approaches v = gq and the ballistic deficit approaches zero. The pulse height is related to the signal charge



Fig. 6.16 (a) Output of a unipolar and bipolar amplifier for a drift tube signal of form $1/(t + t_0)$. The amplifier parameters are n = 4 and $t_p/t_0 = 10$. The ballistic deficit for this set of parameters is 78%. (b) Amplifier output for the unipolar shaper with n = 4 and various values of $t_p/t_0 = 1$, 10, 30, 150. The longer the peaking time the larger is the signal. For $t_p > t_{max} = 10^4 t_0$, the peak approaches a value of $v_p = gq$

'integrated' by the amplifier. Let us assume that we approximate the delta response by a 'box' with a duration T_I equal to the period that the delta response exceeds 90% of its peak value. We can state that the width of the box is equal to the 'flat part' of the delta response, and for the unipolar and bipolar shaper discussed in this chapter we have $T_I \simeq t_p/2$, as can be seen in Fig. 6.17a. We therefore assume a device with a delta response $h_{box}(t) = 1$ for $0 < t < T_I$ and $h_{box}(t) = 0$ outside this interval. The output signal of such a device is

$$v(t) = g \int_0^t h_{box}(t - t')i(t') dt' = g \int_{t - T_I}^t i(t') dt'$$
(6.43)

and the peak of the signal is

$$v_p = v(T_I) = g \int_0^{T_I} i(t') dt' = g Q(T_I) = \frac{gq}{2\ln\frac{b}{a}} \ln\left(1 + \frac{T_I}{t_0}\right).$$
(6.44)

The signal peak is thus equal to the sensitivity *g* times the total charge induced within the duration T_I of the flat top of the delta response. We call the time T_I the integration time of the amplifier. Figure 6.17b shows the charge integrated during a time $T_I = t_p/2$, together with the signal peak of the exact expression from Eq. (6.42). We see that they are almost identical, which justifies the above assumptions. In order to have no ballistic deficit, the flat top of the delta response has to be longer than the duration of the entire signal, being $10^4 t_0$ in our case. Because a signal duration of several microseconds is usually not compatible with rate requirements we always use only a fraction of the induced charge. However, since the induced charge increases just with the logarithm of the integration time, it takes only a time of $200t_0$ to integrate half the charge, corresponding to a ballistic deficit of 50%. It takes another 9800 t_0 to induce the remaining 50% of the charge.

We can conclude that the peak of the amplifier output signal is proportional to the charge integrated during the duration of the 'flat top' (>90% of the peak value)



Fig. 6.17 (a) Approximation of the unipolar delta response by a box with a width corresponding to the duration of the flat top of the signal. (b) Output signal peak for the unipolar delta response $h_{uni}(t)$ and the box delta response $h_{box}(t)$ with a width T_I equal to the flat top of $h_{uni}(t)$. We see that interpreting T_I as the amplifier integration time is a very good approximation

of the amplifier delta response. For wire chamber signals, where the induced charge increases only with the logarithm of the elapsed time, this means that the ballistic deficit is 80% for integration times of $\approx 10-20t_0$ and 50% for integration times of $\approx 100-200t_0$ ns. In order to have a ballistic deficit below 10% one has to integrate for $10^3-10^4t_0$, corresponding to several tens of microseconds.

6.2.2 Signal Tail Cancellation

The long tails of the wire chamber signals result in undesired signal pileup even at modestly high counting rates. There are several possibilities for removing this signal tail. The simplest and most preferable is the use of the bipolar shaper shown in the last section. For the example of $t_0 = 1$ ns and $t_p = 10$ ns we saw that the width of the positive signal part is ≈ 30 ns followed by an undershoot of about 70 ns duration. The baseline is 'restored' after a total duration of 100 ns.

There are, however, applications where such a bipolar pulse is undesirable and we want to remove the signal tail without producing an undershoot. One reason is the worsening of the signal-to-noise ratio for this shaping method, as pointed out in Sect. 6.3. Another reason concerns the pulse width. We show in this section that the 'dead-time' of 100 ns, mentioned in the example above, can be reduced to about 40 ns with a unipolar shaping scheme. A third reason concerns crosstalk. We have seen that the signal induced on the wire where the avalanche is taking place has negative polarity and the signal induced on the neighbouring wire has positive polarity. Applying a negative discriminator threshold to the wire signal registers only the avalanche wire. If we read the wire signals with a bipolar shaping amplifier there is a negative undershoot of the cross-induced signals, which can also trigger the discriminator, resulting in crosstalk.

The standard technique for realization of unipolar tail cancellation is the use of one or several pole-zero filters [BOI 82]. As we saw in Sect. 6.1.3, a pole-zero
6.2 Signal Shaping

filter with time constants τ_1 and τ_2 transforms an exponential signal of the form $\exp(-t/\tau_1)$ into an exponential signal with time constant τ_2 (Fig. 6.8). In order to apply such a procedure to our wire chamber signal we first approximate the signal

$$i(t) = \frac{q}{2t_0 \ln \frac{b}{a}} \frac{1}{1 + t/t_0} = I_0 \frac{1}{1 + t/t_0}$$
(6.45)

by a sum of exponentials with increasing time constants $\tau_n = t_0 / \alpha_n$:

$$i(t) \simeq I_0 \sum_{n=1}^N A_n e^{-\alpha_n t/t_0} = I_0 \sum_{n=1}^N A_n e^{-t/\tau_n} \qquad \tau_n < \tau_{n+1}.$$
(6.46)

By choosing the number of exponential terms N sufficiently large, the signal can be approximated to any desired accuracy. The Laplace transform of the above expression is

$$I(s) = \mathscr{L}[i(t)] = I_0 \sum_{n=1}^{N} \frac{A_n}{s + 1/\tau_n}.$$
(6.47)

For illustration we use two exponentials:

$$i(t) = I_0 \left(A_1 e^{-t/\tau_1} + A_2 e^{-t/\tau_2} \right) \qquad I(s) = I_0 \left(\frac{A_1}{s+1/\tau_1} + \frac{A_2}{s+1/\tau_2} \right) \tag{6.48}$$

and rewrite the expression as

$$I(s) = I_0 \frac{(A_1 + A_2)}{(s + 1/\tau_1)} \frac{(s + 1/\tau)}{(s + 1/\tau_2)} \qquad \tau = \tau_1 \tau_2 \frac{A_1 + A_2}{A_1 \tau_1 + A_2 \tau_2} < \tau_2.$$
(6.49)

Applying a pole-zero filter with the time constants τ_2 and τ to the signal, i.e., $W_{PZ}(s) = (s+1/\tau_2)/(s+1/\tau)$, results in the output signal

$$I_2(s) = I(s) \frac{s+1/\tau_2}{s+1/\tau} = I_0 \frac{A_1 + A_2}{s+1/\tau_1} \qquad i_2(t) = I_0(A_1 + A_2) e^{-t/\tau_1}, \tag{6.50}$$

which is a single exponential. This means that applying a pole-zero filter with these specially chosen time constants to the sum of two exponential signals is equivalent to 'removing' one of the exponential terms. The procedure is easily extended to the sum of several exponentials. Representing i(t) by the sum of three exponentials we need two pole-zero filters to arrive at a single exponential, and for N exponentials we need N - 1 filters to remove all but the first exponential term.

In order to find the constants A_n and $\alpha_n = \tau_n/t_0$ that approximate i(t), we minimize the area (charge) between i(t) and the sum of exponentials

$$\int_{0}^{kt_{0}} \left(\frac{1}{1 + t/t_{0}} - \sum_{n=1}^{N} A_{n} e^{-\alpha_{n} t/t_{0}} \right)^{2} dt \to \min.$$
 (6.51)



For a given time interval $T = kt_0$ the number of exponentials N must be chosen such that the signal is represented with the desired accuracy. Figure 6.18 shows the chamber signal approximated by up to five terms. Using 1/2/3/4/5 exponential terms, we can represent the signal with 10% accuracy in a time interval of $3/20/100/350/1200t_0$.

As a numerical example we use three exponentials and two pole-zero filters:

$$I_0 \frac{1}{1 + t/t_0} \simeq I_0 \left(A_1 e^{-\alpha_1 t/t_0} + A_2 e^{-\alpha_2 t/t_0} + A_3 e^{-\alpha_3 t/t_0} \right).$$
(6.52)

The minimization procedure in Eq. (6.51) results in the parameters

$$A_1 = 0.62$$
 $A_2 = 0.29$ $A_3 = 0.052$ $\frac{\tau_1}{t_0} = 0.92$ $\frac{\tau_2}{t_0} = 5.6$ $\frac{\tau_3}{t_0} = 57.$

As before, we rewrite the expression with a common denominator

$$\sum_{n=1}^{3} \frac{A_n}{s+1/\tau_n} = \frac{as^2 + bs + c}{(s+1/\tau_1)(s+1/\tau_2)(s+1/\tau_3)}$$
(6.53)

$$a = A_1 + A_2 + A_3 \quad b = \frac{A_1}{\tau_2} + \frac{A_1}{\tau_3} + \frac{A_2}{\tau_1} + \frac{A_2}{\tau_3} + \frac{A_3}{\tau_1} + \frac{A_3}{\tau_2} \quad c = \frac{A_1}{\tau_2 \tau_3} + \frac{A_2}{\tau_1 \tau_3} + \frac{A_3}{\tau_1 \tau_2}$$

Writing the polynomial in the numerator in the form $as^2 + bs + c = a(s + 1/\tau_a)$ (s+1/ τ_b), we get

$$I(s) \simeq I_0 \frac{a}{(s+1/\tau_1)} \frac{(s+1/\tau_a)}{(s+1/\tau_2)} \frac{(s+1/\tau_b)}{(s+1/\tau_3)}.$$
(6.54)

Inserting the fit parameters we have $\tau_a = 2.04t_0$ and $\tau_b = 26.9t_0$. By applying two pole-zero filters with time constants τ_2 , τ_a and τ_3 , τ_b we transform the signal into a single exponential

$$I_2(s) = I(s) \frac{(s+1/\tau_2)}{(s+1/\tau_a)} \frac{(s+1/\tau_3)}{(s+1/\tau_b)} = I_0 \frac{a}{s+1/\tau_3}$$
(6.55)

$$i(t) = I_0 (A_1 + A_2 + A_3) e^{-t/\tau_1} = I_0 0.96 e^{-t/0.92t_0}.$$
(6.56)

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Fig. 6.19 (a) Wire chamber signal processed by a unipolar shaper of n = 4 and $t_p/t_0 = 10$ together with the same signal filtered by of two pole-zero filters. The pulse width is reduced to a length of $T \simeq 40t_0$. (b) The same signal on a smaller vertical scale, showing a tail with a height corresponding to about 1% of the chamber signal

Figure 6.19 shows the result of applying these two pole-zero filters to the wire chamber signal of Eq. (6.45), which was processed by a unipolar shaper with n = 4 and $t_p/t_0 = 10$. For this purpose we convoluted the signal v(t) from Eq. (6.42) with the delta response of the pole-zero filter from Eq. (6.25):

$$v_2(t) = \int_0^t w_{PZ}(t-t')v(t')dt' = v(t) - \int_0^t \frac{\tau_2 - \tau_a}{\tau_2 \tau_a} e^{-(t-t')/\tau_a} v(t')dt'.$$
(6.57)

We see that the result is very satisfactory: the two pole-zero filters have considerably reduced the signal length to about $40t_0$ and only a small tail below 1% of the peak value remains.

Improvement for Long Peaking Times: In the previous example, two of the fitted exponential time constants were rather small $(0.92t_0 \text{ and } 5.6t_0)$ because they had to represent the steep part of the original wire signal at very short times. But for amplifiers with long peaking times $t_p \gg t_0$, the output pulse shape does not depend on the exact form of the input at times $< t_p$, but only on the signal charge during this time. We can then achieve a closer approximation by *first* convoluting the exponential terms with the amplifier response and *then* fitting this signal to the chamber signal processed by the amplifier. The fit can extend over times as long as several hundred t_0 .

$$v_1(t) = g \int_0^t h_{uni}(t-t') \frac{I_0}{1+t'/t_0} dt' \quad v_2(t) = \mathscr{L}^{-1} \left[g H_{uni}(s) I_0 \sum_{m=1}^N \frac{A_m}{s+1/\tau_m} \right].$$
(6.58)

The parameters A_n , α_n in the analytic expression of $v_2(t)$ are then determined such that the 'amplified' signal $v_1(t)$ is represented as closely as possible. The analytic representation of $v_2(t)$ can be expressed by making use of the relations

$$\mathscr{L}^{-1}\left[H_{uni}(s)\frac{A}{s+1/\tau}\right] = \mathscr{L}^{-1}\left[\frac{t_p e^n n!}{(n+st_p)^{n+1}}\frac{A}{(s+1/\tau)}\right] = Af(t,\tau)$$

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$$f(t,\tau) = t_p n! e^n \left(n - \frac{t_p}{\tau} \right)^{-(n+1)} \left(e^{-t/\tau} - e^{-nt/t_p} \sum_{m=0}^n \frac{1}{m!} \left[\left(n - \frac{t_p}{\tau} \right) \frac{t}{t_p} \right]^m \right).$$
(6.59)

Thus for three exponentials the signal is expressed as

$$v_2(t) = gI_0 \left(A_1 f(t, \tau_1) + A_2 f(t, \tau_2) + A_3 f(t, \tau_3) \right).$$
(6.60)

For a value of $t_p/t_0 = 10$, the signal $v_1(t)$ is approximated to within $\pm 10\%$ accuracy up to $350t_0$ by the parameters

$$A_1 = 0.60$$
 $A_2 = 0.10$ $A_3 = 0.016$ $\frac{\tau_1}{\tau_0} = 2.48$ $\frac{\tau_2}{\tau_0} = 18.8$ $\frac{\tau_3}{\tau_0} = 191.48$

Using two pole-zero filters with these time constants, giving $\tau_a = 9.37$, $\tau_b = 107.35$ results in the output signal presented in Fig. 6.20. A small bump with a height of 0.5% of the peak value is followed by a remaining tail of only 0.25% relative height. This is an improvement of a factor 2 compared to the previous scheme.

Although the unipolar-shaped pulse is shorter and avoids the undershoot, there are several issues that have to be considered carefully when choosing this shaping scheme. First, one has to evaluate the effects of the remaining signal tail, which lasts up to $10^5 t_0$ in our example. Although the tail is small, the statistical superposition of many of them may result in significant baseline fluctuations. In addition, the precise cancellation of the signal tail requires a very good knowledge of the chamber signal shape. Because the time constant t_0 depends on the ion mobility and applied high voltage, the signal shape depends on the working point and the gas mixture that is used. The optimized pole-zero filter constants are therefore in principle only valid for a single well-defined working point. Another word of caution concerns the realization of the pole-zero filters. Resistors and capacitors have certain production variations. In integrated circuits, the absolute values of *R* and *C* elements have typical errors of up to 10%, so the precise realization of the time constants is rather difficult. The tail cancellation effect is mostly defined by the so-called pole/zero ratio τ_1/τ_2 , which itself is determined by the ratio of resistors. Although ratios of



Fig. 6.20 (a) Application of the two pole-zero filters to the wire chamber signal, where the polezero time constants were determined *after* processing with the unipolar shaper. (b) The same signal on a smaller vertical scale showing a tail of only 0.25% height

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resistors on ICs are typically correct to about 1% it is still very tedious to fine-tune the time constants.

It is therefore advisable to use the bipolar scheme whenever possible owing to its simplicity and insensitivity to working point variations and imprecisions of electronic elements. In the case where unipolar shaping is required for reasons outlined in the introduction, it is usually essential to make the pole-zero time constants programmable in order to be able to compensate for process variations and adapt to changing working points.

6.2.3 Signal Pileup, Baseline Shift, and Baseline Fluctuations

At high counting rates, when the time between signals is not long compared to the signal pulse width, the individual signals pile up and cause a deterioration of the signal quality. This can be calculated if one uses the fact that the individual pulses come at random and therefore have an exponential distribution of the time interval between any two consecutive signals. The probability P(t)dt for finding a time interval t, t + dt is

$$P(t) dt = \frac{1}{\tau} e^{-t/\tau} dt = v e^{-vt} dt, \qquad (6.61)$$

where v is the average pulse rate and $\tau = 1/v$ is the average time between two consecutive pulses. The effect of different pulse shapes at high counting rates is demonstrated in the four parts of Fig. 6.21, where we see a rapid random sequence of identical pulses treated by four different shapers. We use the remainder of this section to quantify what we see. The rate v is taken to be $v = 5 \times 10^{-3}/t_0$, which corresponds to 5 MHz when $t_0 = 1$ ns.

For the following discussion it is useful to separate the signal into a 'signal' part of duration T and a 'tail' part (Fig. 6.22). The first high-rate effect to discuss is signal pileup, where the 'signal' part of two signals arrives within a time interval that is smaller than the signal pulse width T. This pileup results in incorrect charge or time measurement. In a particle tracking system, the particle trajectory is typically measured by several readout channels, and the track reconstruction can detect the channel with incorrect charge or time measurement. Consequently the measurement from this channel is not used in the reconstruction, which results in an inefficiency of this channel. The signal pileup probability, or inefficiency ε , for a pulse width T and a rate v is given by

$$\varepsilon = \int_0^T v e^{-vt} dt = 1 - e^{-vT} \approx \frac{T}{\tau} \quad \text{for} \quad T \ll \tau.$$
(6.62)

The rate requirement is therefore one key element for specification of the maximum pulse width T, which in turn specifies the shaping strategy. The signal part of the bipolar pulse in Fig. 6.16a has a duration of $T \approx 80t_0$ while the signal part of the



Fig. 6.21 A fast random sequence of chamber signals processed by four different shapers: (a) unipolar shaper, (b) bipolar shaper, (c) unipolar shaper with two pole-zero filters, and (d) unipolar shaper with two pole-zero filters and AC coupling. The rate dependence of the baseline for these four shapers is treated in this subsection

unipolar pulse with two pole-zero filters in Fig. 6.20 has a length of $T \approx 40t_0$. This causes an inefficiency of 40% for the bipolar shaper and 20% for the unipolar shaper at the average pulse separation of $200t_0$.

The second high-rate effect is 'tail' pileup, where a signal is 'sitting' on the superimposed tails of one or several preceding signals, causing a displacement of the baseline. We would like to know the average value of the displacement ('baseline shift') as well as its variance ('baseline fluctuation'). The baseline fluctuations cause a deterioration in the measurement accuracy rather than an inefficiency.



Fig. 6.22 (a) Separation of the chamber pulse into a 'signal' part and a 'tail' part. (b) Signal pileup leading to incorrect charge or time measurements. Removing these incorrect measurements leads to inefficiency

6.2 Signal Shaping

In the following we would like to compute the effect of the random superposition of a number of tails from preceding signals. Looking at the wire chamber signal processed by a unipolar shaper in Fig. 6.16, we see that the output signal shows a long tail that approaches the baseline only slowly. The distinction between the signal and the tail parts is of course somewhat arbitrary and we take the beginning of the tail at a time t_{min} when the signal level falls below 10% of the peak value, which corresponds to $t/t_0 = 70$ for the assumed parameters. For $t \gg t_0$, the convolution integral in Eq. (6.42) is approximated by

$$v(t) \approx g i(t) \int_0^\infty h_{uni}(t') dt' \approx \frac{gq c_n t_p}{2\ln(b/a)} \frac{1}{t} \qquad t_{min} < t < t_{max}, \tag{6.63}$$

where

$$c_n = \frac{1}{n} \left(\frac{e}{n}\right)^n \int_0^\infty y^n e^{-y} dy = \frac{e^n n!}{n^{n+1}}.$$
 (6.64)

In order to calculate the average baseline and the baseline fluctuation we use Campbell's theorem, which states the following: If signals of equal shape v(t) are randomly superimposed at an average rate v, the average and the variance of the resulting signal are given by

$$\overline{v} = v \int_{-\infty}^{\infty} v(t) dt \qquad \sigma_v^2 = v \int_{-\infty}^{\infty} v(t)^2 dt.$$
(6.65)

Inserting the expressions from Eq. (6.63) for the signal tail we find an average baseline \overline{v} and an r.m.s. baseline fluctuation σ_v of

$$\overline{v} = v t_0 \frac{gq c_n}{2\ln(b/a)} \frac{t_p}{t_0} \ln \frac{t_{max}}{t_{min}} \quad \text{and} \quad \sigma_v \approx \sqrt{v t_0} \frac{gq c_n}{2\ln(b/a)} \frac{t_p}{t_0} \sqrt{\frac{t_0}{t_{min}}}.$$
 (6.66)

Normalizing these values to the peak v_p of the signal v(t) given in Eq. (6.44), we find the values

$$\frac{\overline{v}}{v_p} = \frac{vt_0}{\ln(1+t_p/2t_0)} \frac{c_n t_p}{t_0} \ln \frac{t_{max}}{t_{min}} \qquad \frac{\sigma_v}{v_p} \approx \frac{\sqrt{vt_0}}{\ln(1+t_p/2t_0)} \frac{c_n t_p}{t_0} \sqrt{\frac{t_0}{t_{min}}}.$$

For the parameters of b/a = 100, n = 4, $t_p/t_0 = 10$, and $t_{max}/t_0 = (b/a)^2 = 10^4$, assuming that the beginning of the tail is at $t_{min}/t_0 = 70$, Fig. 6.23 shows the average baseline shift and r.m.s. With a value of $t_0 = 1$ ns and a rate v = 5 MHz we find a baseline shift and r.m.s. corresponding to $\simeq 15\%$ and $\simeq 5\%$ of the average signal. The baseline shift of 15% can be clearly made out in Fig. 6.21a. If the signal charge q is not constant but is fluctuating around an average value of \overline{q} with a variance of σ_q , an extension of Campbell's theorem tells us that the value of q in the expression for \overline{v} must be replaced by \overline{q} and the value of q in the expression for σ_v must be replaced by $\overline{q}\sqrt{1+\sigma_q^2/\overline{q}^2}$.

This example illustrates the undesirable effects of the long tail associated with the simple unipolar shaper. We now set out to remove the signal tail as explained



Fig. 6.23 Average baseline shift (a) and baseline fluctuation (b) for various shapers, as a function of the signal rate v

in the previous section. Let us apply two pole-zero filters with time constants τ_2 , τ_a and τ_3 , τ_b , which remove the signal tail up to $\approx 3\tau_3$. For times longer than $3\tau_3$ the pole-zero filters are just scaling the signal without changing the shape, because the transfer is then approximately constant,

$$\frac{i\omega+1/\tau_2}{i\omega+1/\tau_a}\frac{i\omega+1/\tau_3}{i\omega+1/\tau_b} \approx \frac{\tau_a}{\tau_2}\frac{\tau_b}{\tau_3} \quad \text{for} \quad \omega \ll \frac{1}{\tau_3}.$$
(6.67)

The signal tail is therefore given by the expression from Eq. (6.63) scaled by this factor:

$$v(t) \approx \frac{gq c_n t_p}{2\ln(b/a)} \frac{\tau_a}{\tau_2} \frac{\tau_b}{\tau_3} \frac{1}{t} \qquad 3\tau_3 < t < t_{max}.$$
 (6.68)

The expressions for the average and r.m.s of the baseline are equal those from Eq. (6.66), scaled by $\tau_a \tau_b / \tau_2 \tau_3$ with t_{min} replaced by $3\tau_3$.

In order to express the baseline shift and fluctuation as a fraction of the pulse height we must first find the peak of the unipolar-shaped signal processed by two pole-zero filters. We use the fact that the pole-zero filters remove all but the first exponential, so the remaining signal is given by $i(t) = A \exp(-t\tau_1)$ [Eq. (6.56)], where we have defined $A = A_1 + A_2 + A_3$. The procedure for determining the pole-zero parameters results in a time constant τ_1 which is much smaller than the amplifier peaking time t_p , so we can assume that the entire signal charge is contained in a delta signal and find the amplifier output peak v_p :

$$v_p = gQ = g \int_0^\infty i(t)dt = \frac{gq}{2t_0 \ln \frac{b}{q}} A \tau_1.$$
(6.69)

Thus, the average baseline shift and the r.m.s. fluctuation are

$$\frac{\overline{v}}{v_p} = v t_0 \frac{c_n}{A} \frac{t_p \tau_a \tau_b}{\tau_1 \tau_2 \tau_3} \ln \frac{t_{max}}{3 \tau_3} \qquad \frac{\sigma_v}{v_p} \approx \sqrt{v t_0} \frac{c_n}{A} \frac{t_p \tau_a \tau_b}{\tau_1 \tau_2 \tau_3} \sqrt{\frac{t_0}{3 \tau_3}}.$$

Figure 6.23 shows the results using the time constants that we determined in the previous section. With $t_0 = 1$ ns at a rate of 5 MHz we find a baseline shift of 3% and a baseline fluctuation of 0.8% of the average pulse height. In Fig. 6.21c we see

6.2 Signal Shaping

the sequence of input pulses for this shaping scenario, and the reduction of baseline shift and fluctuation is evident. These numbers can be still improved by using more pole-zero filters with time constants $\tau_c, \tau_4 \dots$ The above formula can be directly extended for this case. With this technique we can in principle reduce the baseline shift and fluctuation to any desired level, but it requires a very precise choice of filter constants matched to the chamber input signal and the working point.

At this stage one might be tempted to AC couple the signal by adding a CR filter with time constant $\tau > \tau_3$ in order to remove the remaining signal tail. But that introduces a new tail because any signal processed by a CR filter is strictly bipolar. Let us nonetheless consider this possibility for a moment. We approximate the unipolar signal by a box signal of duration T and amplitude v_p , as shown in Fig. 6.20. Sending this signal through a CR filter of time constant τ we find the following output signal, sketched in Fig. 6.24:

$$\frac{v(t)}{v_p} = e^{-\frac{t}{\tau}} \quad t < T \qquad \frac{v(t)}{v_p} = -(1 - e^{-\frac{T}{\tau}})e^{-\frac{t}{\tau}} \quad t > T.$$
(6.70)

The CR filter has created a new tail, an undershoot with an area equal to the area of the positive signal part. The baseline shift and fluctuation due to this tail are again calculated with Campbell's theorem, and assuming that $\tau \gg T$ we find

$$\frac{\overline{v}}{v_p} = -v\tau(1 - e^{-\frac{T}{\tau}}) \approx -vT \qquad \frac{\sigma_v}{v_p} = \sqrt{\frac{v\tau}{2}}(1 - e^{-\frac{T}{\tau}}) \approx T\sqrt{\frac{v}{2\tau}}.$$
 (6.71)

The baseline shift is independent of the filter time constant and simply reflects the area balance of the positive and negative signal parts. In case the average distance between two pulses τ is twice the pulse width $\tau = 1/v = 2T$ we have $\overline{v}/v_0 = 0.5$, which means that the baseline has shifted by half of the amplitude. The baseline fluctuation decreases for a longer RC time constant τ and can be reduced to any desired level. The fact that the baseline shift cannot be removed and that we therefore have a rate-dependent baseline makes this shaping scheme with a long RC time constant undesirable for high-rate applications. An example of such an RC filter applied to a sequence of chamber pulses is shown in Fig. 6.21d.

The simplest way of avoiding baseline fluctuations is the bipolar shaper described in the last section. The results of the previous paragraph also apply to this shaper



Fig. 6.24 Square signal processed by a CR filter. The CR filter introduces a signal tail with an area equal to the positive signal part

because the bipolar shaper is equal to a unipolar shaper with an additional CR filter. But now the CR time constant is short—of the same order as the signal length T—so this shaper creates a large, but short undershoot. The area balance is done 'quickly', and after a duration of two to three times t_p the signal is back to the baseline.

The tail of the output of the bipolar shaper is found by writing the output signal in the Laplace domain and interpreting the *s* in the numerator as the derivative of the unipolar output signal:

$$v(t) = \mathscr{L}^{-1}\left[gH_{bip}(s)I(s)\right] = g\frac{d}{dt}\mathscr{L}^{-1}\left[\frac{1}{s}H_{bip}(s)I(s)\right] \approx gi'(t)\lim_{s\to 0}\frac{1}{s}H_{bip}(s)$$
(6.72)

$$v(t) \approx -gq \frac{e^r n!}{\sqrt{n}r^{n+1}} \frac{1}{2\ln(b/a)} \frac{t_p^2}{t^2}.$$
(6.73)

We see that the negative signal tail tends to zero as $1/t^2$, which guarantees a quick return to the baseline, and the influence on the following pulses is eliminated. The effect of this shaping scheme is shown in Fig. 6.21b. It can be seen that the pulse width and therefore the inefficiency is increased, but the baseline is equal to zero and the fluctuations are eliminated.

Conclusion of this Section

There are two linear signal processing strategies by which we can avoid baseline shift and baseline fluctuations at high counting rates owing to the long tail of wire chamber signals:

Unipolar Shaping: A unipolar shaper and several pole-zero filters matched to the individual exponentials that represent the chamber signal are used. The advantage is a 'short' unipolar response. There are, however, several disadvantages to this approach. First of all, the entire electronics readout chain must be DC coupled. This causes problems for the electronics design because the DC offset variations within the electronics chain, which are due to component imperfections or temperature variations, must be very carefully controlled. The DC coupling also makes the electronics sensitive to low-frequency noise, which is very undesirable. In addition, the wire signals are intrinsically AC coupled owing to the capacitor that decouples the wire high voltage from the amplifier input, so a unipolar shaping strategy is simply not realizable with a linear electronics circuit. In addition, the pole-zero parameters must be carefully tuned to the signal tail constant t_0 , which depends on the chamber geometry, the gas used, and even the operating voltage. Since the absolute values of resistors and capacitors in most electronics technologies can vary by 10-20% with respect to the nominal values, the needed precision of the achieved time constants must be very carefully evaluated. A solution to this problem is the introduction of programmable pole-zero time constants, but this, of course, adds another level of complication.

Bipolar Shaping: A bipolar shaper, realized by a fast CR 'differentiation' with a timescale of the same order as the peaking time, produces a large, but short, signal undershoot. The signal dead time is approximately doubled with respect to the unipolar + pole-zero shaping scheme and, as we will see later, the signal-to-noise ratio is slightly reduced. The simplicity of the realization and the reduced sensitivity of the signal shape to the input signal parameters makes this scheme a very desirable one.

Nonlinear Shaping: Another possibility for avoiding the signal tail, which was not discussed here, is a nonlinear circuit for elimination of the signal tail. These circuits are usually called 'baseline restorers' and are realized by different kinds of nonlinear components such as, e.g., diodes. These nonlinear baseline restorers allow one to avoid the area balance present in linear AC coupled systems, so it is possible to realize unipolar shaping without undershoot even if the signal is AC coupled. A widely used circuit for this purpose is the Robinson restorer, which is described in detail in [NIC 73]. The important advantages of linear signal processing that were praised in the fourth paragraph of the introduction to this chapter are then lost.

6.2.4 Input Circuit

Up to now we have considered a setup where the induced current signal is equal to the current flowing into the amplifier. The detector capacitance, together with the finite amplifier input impedance, that shape the signal and the current flowing into the amplifier is different from the induced one. In general, the amplifier input current is calculated from the induced currents by applying them to the network representing the wire chamber and the other impedance elements connected to the electrodes (Fig. 6.25). If we want to study effects of coupling among different electrodes and readout channels, such as, e.g., crosstalk, we have to use the entire equivalent circuit representing the chamber. For studying the readout signal on a single electrode we



Fig. 6.25 Equivalent input circuit relating the currents induced on the electrodes to the amplifier input current



Fig. 6.26 Input circuit and equivalent block diagram for a typical cathode and a wire readout channel

can neglect the impedances between the electrodes, which are typically large, and just consider the electrode capacitance and amplifier input impedance. Figure 6.26 shows the circuit for a typical cathode and wire readout channel. A cathode strip or cathode pad is typically directly connected to the amplifier input and the induced current is divided between the input impedance R_{in} and the detector capacitance C_{det} . As a result, the amplifier input current is equal to

$$I_{in}(s) = \frac{1}{1 + s\tau_1} I_{ind}(s) \quad \tau_1 = R_{in}C_{det}.$$
 (6.74)

This is equivalent to the transfer function of an *RC* integration stage, as indicated in the equivalent block diagram in Fig. 6.27. The wire is also connected to the high voltage through a load resistor R_L and decoupled from the amplifier with a capacitor *C*. The amplifier input current is therefore related to the induced current as follows:

$$I_{in}(s) \approx \frac{1}{(1+s\tau_1)} \frac{s\tau_2}{(1+s\tau_2)} I_{ind}(s) \qquad \tau_1 = R_{in}C_{det} \quad \tau_2 = R_L C.$$
(6.75)

This transfer function is equivalent to an RC filter with time constant τ_1 followed by an CR filter with time constant τ_2 . This means that the wire chamber signal is AC



Fig. 6.27 Equivalent block diagrams for a cathode channel processed by a unipolar shaper with n = 2 and a double pole-zero filter (top), and a wire channel processed by a bipolar shaper with n = 2 (bottom)

coupled and the output signal of any linear signal processing chain connected to the wire is strictly bipolar.

The current signal $I_{in}(s)$ is then processed by the readout electronics chain. Figure 6.27 shows how the input circuit is represented in an equivalent block diagram. The examples show a cathode signal processed by a unipolar shaper with two pole-zero filters and a wire signal processed by a bipolar shaper. The amplifier output signals for the two scenarios are given by

$$V(s) = \frac{1}{1 + sR_{in}C_{det}} \frac{G}{(1 + s\tau)^{n+1}} \frac{s + 1/\tau_1}{s + 1/\tau_a} \frac{s + 1/\tau_2}{s + 1/\tau_b} I^{ind}(s),$$
(6.76)

$$V(s) = \frac{1}{1 + sR_{in}C_{det}} \frac{sR_LC}{(1 + sR_LC)} \frac{Gs\tau}{(1 + s\tau)^{n+1}} I^{ind}(s).$$
(6.77)

6.3 Noise and Optimum Filters

By this point we are familiar with various possible transfer functions and pulse shapes for analyzing wire chamber signals so that for a given application we have a choice for achieving the best performance. There is one more element which often plays an essential role when designing optimal chamber electronics—the inevitable noise present in all electronics elements as well as in the wire chamber itself, which represents a background against which the signals have to be distinguished. In the following sections we characterize noise as a general phenomenon, discuss some relevant noise sources, and develop a method for studying the influence of the noise source on the signal pulse shapes. In the end we want to find the optimum transfer function for a given application.

For optimum charge measurement in cathode pad and cathode strip chambers, the noise may limit the measurement accuracy and we want to choose $H(i\omega)$ such that the signal-to-noise ratio is maximized. The choice of $H(i\omega)$ for time measurement is more complicated. The time resolution of a wire chamber is determined by the chamber internal effects of primary ionization and electron dynamics together with the electronics noise. In order to minimize the noise effect one has to maximize the so-called 'slope-to-noise' ratio, which may sometimes pose conditions unfavourable for exploiting the measurement accuracy of the chamber itself.

In principle the signal-to-noise ratio and slope to noise ratio can always be improved by increasing the chamber gas gain. On the other hand, for reasons of chamber ageing and rate limitations, one wants to work at the lowest possible gas gain.

The 'optimum filters' that minimize the effect of noise are related in a unique way to the input signal shape and the noise spectrum, but they are not always realizable or practical. They serve as a guideline for choosing the parameters for a realistic design and show how far it deviates from the theoretically optimal performance. The optimum filter might result in a very long pulse which is not compatible with rate requirements or it might increase the impact of the chamber internal effects. After reviewing some basic definitions we consider the two main noise sources: passive detector elements, which are 'irreducible' noise sources, and amplifier noise, which is subject to specification. Finally we discuss how to optimize the amplifier transfer function in order to achieve the best possible signal-to-noise ratio.

6.3.1 Noise Characterization

Noise Alone

The random statistical movement of the atomic constituents of matter is the source of electrical noise on any signal line. It occurs as random fluctuations of currents and voltages. For a description of noise, statistical concepts are appropriate.

Any observation of noise happens during an observation time *T*. Let us assume a random voltage signal n(t) in the example depicted in Fig. 6.28a, where *T* was chosen to be 100 ns. The variance σ_n^2 of n(t) is a measure of the fluctuation. If the average of the noise signal \overline{n} is zero, the variance is given by

$$\sigma_n^2 = \overline{n^2} - \overline{n}^2 = \frac{1}{T} \int_{-T/2}^{T/2} n(t)^2 dt.$$
 (6.78)

The frequency content can be described by a discrete set of frequencies $f_k = k/2\pi T$ with k = 1, 2, ... If we let T go to infinity, the frequency content of the noise becomes continuous, and a noise power spectrum w(f) may be defined over the continuous frequency variable f, so that the variance of the fluctuation is given by

$$\sigma_n^2 = \int_0^\infty w(f) df = \frac{1}{2\pi} \int_0^\infty w(\omega) d\omega.$$
(6.79)

The noise power spectrum is the essential tool for the characterization of electronics noise. It specifies the contribution in the frequency interval df to the square of the fluctuating quantity. If n(t) is a voltage or a current on unit resistance, then $n^2(t)$ is a power and w(f) a frequency power density; hence the name.



Fig. 6.28 (a) Random noise signal n(t). (b) Power spectral noise density w(f) of the noise signal, which characterizes the noise signal in the frequency domain

6.3 Noise and Optimum Filters

The noise power spectrum must obviously be related to the Fourier components of n(t). The relationship is as follows: If the Fourier transformation is

$$n(t) = \frac{1}{2\pi} \int_{-\infty}^{\infty} N(i\omega) e^{i\omega t} d\omega, \qquad (6.80)$$

then, using (6.78) and $N^*(-i\omega) = N(\omega)$ and going to the limit, σ_n^2 becomes

$$\lim_{T \to \infty} \frac{2}{T} \int_0^T |N(i\omega)|^2 d\omega, \tag{6.81}$$

which implies

$$w(f) = \lim_{T \to \infty} \frac{2}{T} |N(i\omega)|^2.$$
(6.82)

As an illustration, a typical power spectrum w(f) has been defined to be flat up to a cutoff frequency at 150 MHz, together with an example of a fluctuating voltage n(t) containing frequencies according to w(f). Both quantities are depicted in Fig. 6.28. The higher this cutoff the more 'spiky' the noise.

In the case where the noise power spectrum is constant for all frequencies we call the noise 'white' because the noise signal contains all frequencies in equal amounts. The power spectrum w(f) is not only useful for calculation of the r.m.s. fluctuation of the noise signal, but it is also related to some other key parameters which characterize a noise signal. As was shown by Rice [RIC 44] the average frequency of zero crossings of n(t) is given by

$$f_{zero} = 2\sqrt{\frac{\int_0^{\infty} f^2 w(f) df}{\int_0^{\infty} w(f) df}}.$$
 (6.83)

The evaluation of Eq. (6.83) using the noise power spectrum in Fig. 6.28b gives $f_{zero} = 0.31 \text{ GHz}$ and the noise signal in Fig. 6.28a counts 27 zero crossings in 100 ns, giving a rate of 0.27 GHz. For a noise spectrum that is constant up to a sharp cutoff frequency f_0 this expression evaluates to $f_{zero} = 2/\sqrt{3}f_0 = 1.155f_0$. The frequency of zero crossings of the noise signal is therefore approximately given by the cutoff frequency of the power spectrum.

Noise in a Linear Network

Now we want to find out how the spectral density of a noise signal is transformed if it is sent through a linear network with transfer function $H(i\omega)$. The noise signal $N(i\omega)$ is transformed into $N(i\omega)H(i\omega)$. Using Eq. (6.82), we see that the noise power spectrum is transformed into

$$w(f) \to w(f) |H(i2\pi f)|^2.$$
 (6.84)

If we assume a noise signal with a constant power spectrum up to a given frequency, i.e., $w(f) = w_0$ for $f < f_0$, we find a noise r.m.s. of $\sigma_n = \sqrt{w_0 f_0}$. If we send this noise signal through a low-pass filter of unity gain with a sharp cutoff frequency $f_1 < f_0$, the noise r.m.s. becomes $\sigma_n = \sqrt{w_0 f_1}$, meaning that the r.m.s. is reduced by a factor $\sqrt{f_1/f_0}$. As shown later one can improve the signal-to-noise ratio by filters that are passing only the frequencies contained in the signal and removing the others.

Next we want to find the noise power spectrum at a given circuit node of a linear network in the case where there are several independent (uncorrelated) current and voltage noise sources distributed throughout the network. Elementary circuit theory tells us that for a set of voltage and current sources distributed in a linear network, the voltage on a given circuit node can be calculated in the following way: The contribution of each individual source is computed separately by 'switching all other sources off'. A source is 'switched off' by shorting it out if it is a voltage source and by opening it if it is a current source. The final voltage is then the sum of these individual contributions. For the network in Fig. 6.29a, e.g., the voltage at node $V_1(s)$ due to the voltage source V(s) and current source I(s) is

$$V_1(s) = \frac{Z_2(s)}{Z_1(s) + Z_2(s)} V(s) + \frac{Z_1(s)Z_2(s)}{Z_1(s) + Z_2(s)} I(s).$$
(6.85)

If these are noise sources with voltage noise power spectrum $w_v(f)$ and current noise power spectrum $w_i(f)$, Eq. (6.84) tells us that the noise power spectrum $w_{v_1}(f)$ is given by

$$w_{v_1}(f) = \left| \frac{Z_2(i\omega)}{Z_1(i\omega) + Z_2(i\omega)} \right|^2 w_v(f) + \left| \frac{Z_1(i\omega)Z_2(i\omega)}{Z_1(i\omega) + Z_2(i\omega)} \right|^2 w_i(f).$$
(6.86)

In order to characterize the signal, noise, and impedance of a wire chamber electrode connected to the input of an amplifier, it is very useful to further simplify the picture by using Thevenin's and Norton's theorems (Fig. 6.30):

A linear, active network which contains one or more voltage or current sources can be replaced by a single impedance Z(s) with a series voltage source $V_T(s)$ (Thevenin's theorem), or by the same impedance with a parallel current source $I_N(s)$ (Norton's theorem).

The impedance Z(s) can be obtained by shorting out the voltage sources, opening up all current sources, and finding the equivalent impedance of the network. The Theveninn equivalent voltage $V_T(s)$ or Norton equivalent current $I_N(s)$ can be



Fig. 6.29 A voltage source and a current source embedded in a linear network



Fig. 6.30 Illustration of Thevenin's and Norton's theorems

calculated by the well known network rules. The voltage $V_T(s)$ and current $I_N(s)$ are related by $V_T(s) = Z(s)I_N(s)$. As an example we use the circuit of Fig. 6.29. By shorting the voltage source and opening the current source, the impedance of the entire network becomes $Z(s) = Z_1(s)Z_2(s)/(Z_1(s) + Z_2(s))$. The Thevenin equivalent voltage is given by $V_1(s)$ from Eq. (6.85) and the current is therefore $I_1(s) = V(s)/Z(s) = I(s) + V(s)/Z(s)$. The same is true for noise sources: the entire network can again be represented by a single impedance Z(s) with a series voltage noise power spectrum $w_v(f)$ or a parallel current noise power spectrum $w_i(f)$ (Fig. 6.31), and the two are related by

$$w_v(f) = |Z(i2\pi f)|^2 w_i(f).$$
(6.87)

Thus we can represent the wire chamber electrode connected to an amplifier input by a single impedance element Z(s) with a parallel current source representing the chamber signal and a parallel current noise power spectrum representing all electrode noise sources (Fig. 6.32).

In this way we can evaluate the relative magnitudes of signal and noise at the amplifier input, which allows us to choose the amplifier transfer function in order to optimize the signal-to-noise ratio at the amplifier output.

6.3.2 Noise Sources

Having the vocabulary and the tools for noise analysis at hand we can now discuss the different noise sources in a wire chamber setup. We consider only the noise inherent in the detector and the amplifier and not external 'man-made' noise that may originate in various electrical devices outside of the detector. Of course, any such interference noise has to be eliminated before approaching the inherent 'irreducible' detector and amplifier noise.



Fig. 6.31 Thevenin's and Norton's theorems applied to the noise power spectra



Fig. 6.32 Representation of the wire chamber elements, noise sources, and the chamber signal by a single impedance Z(s) with a single current source and a single noise power spectrum

There are many physical processes that create noise in electric circuits. The three most important ones for particle detection are shot noise, thermal (Johnson) noise, and flicker (1/f) noise.

Shot Noise

This electrical noise is based on the random arrival of the smallest quantized units of electric charge. The name derives from an analogy with the pellets of a shotgun. If the random sequence is governed by the arrival probability p per unit of time alone (no correlations) one easily calculates the mean number \overline{m} of particles in an observation time T as well as the variance, $\overline{m^2} - \overline{m^2}$:

$$\overline{m} = pT \tag{6.88}$$

The actual integer number m is distributed around this mean according to the Poisson probability distribution

$$P(\overline{m},m) = \frac{\overline{m}^m}{m!} e^{-\overline{m}}.$$
(6.89)

The expectation value of m^2 is therefore

$$\sum_{m=0}^{\infty} m^2 \, \overline{\frac{m^m}{m!}} \, e^{-\overline{m}} = \overline{m} + \overline{m}^2. \tag{6.90}$$

It follows that the variance is equal to the mean, a famous property of the Poisson distribution. A power spectrum for this kind of noise exists once an electrical pulse $e_0 f(t)$ is associated with each noise particle carrying the elementary charge e_0 . We have a random sequence of identical current pulses coming at a mean frequency v. Campbell's theorem applies [RIC 44]. It states that under these circumstances the average current \overline{I} and its variance σ_I^2 are given by

$$\overline{I} = \mathbf{v} \, e_0 \int_{-\infty}^{\infty} f(t) dt \qquad \sigma_I^2 = \mathbf{v} \, e_0^2 \int_{-\infty}^{\infty} f(t)^2 dt. \tag{6.91}$$

Applying Parseval's theorem we can transform the expression for σ_I into

$$\sigma_I^2 = 2v e_0^2 \int_0^\infty |F(i\omega)|^2 df.$$
 (6.92)

This can be identified with the noise power spectrum, which has the following form:

$$w(f) = 2ve_0^2 |F(i\omega)|^2.$$
(6.93)

We note that the power spectrum of shot noise depends on the size of the elementary charge. For a given current ve_0 the fluctuation increases with the size of e_0 .

If we imagine f(t) to be a δ -function $\delta(t)$ we have $F(i\omega) = 1$ and the noise power spectrum becomes white:

$$w(f) = 2ve_0^2 = 2e_0\bar{I}.$$
(6.94)

This means that we can imagine white noise to be a random sequence of delta current pulses.

Thermal or Johnson Noise

In 1906 Einstein predicted that Brownian motion of the charge carriers would lead to a fluctuating potential between the ends of any resistance in thermal equilibrium. The effect was first observed by Johnson [JOH 28] and its power spectrum was calculated by Nyquist [NYQ 28].

One way to establish the voltage and current fluctuations at the ends of the conductor is to sum up the contributions of the electrons that move about in thermal equilibrium with the constituents of the conductor. Every electron moving with a velocity u_i down the conductor contributes a small current e_0u_i ; this is related to the mean energy per degree of freedom, proportional to the absolute temperature and the resistance of the conductor. Such a microscopic derivation can be found in [KIT 58].

A more general derivation of the noise power spectrum follows. It is based on the insight that the electric and magnetic fields created by the movements of the electrons themselves possess degrees of freedom of the system which are in thermal equilibrium with their surroundings and therefore must carry the average energy of kT/2 per degree of freedom or kT per mode of the electromagnetic field (k = Boltzmann constant, T = absolute temperature).

In order to find the noise power spectrum, all that remains to be done is to properly count the modes of the electric and magnetic fields. This was achieved by Nyquist [NYQ 28] in a paper immediately following the paper in which Johnson [JOH 28] first described thermal noise. One considers two equal resistors $R_1 = R_2 = R$ connected by an ideal lossless transmission line as indicated in Fig. 6.33. The transmission line is given an impedance equal to R, the resistors are in thermal equilibrium at the absolute temperature T. The voltage fluctuations at R_1 are accompanied by current fluctuations so that some electrical power P_1 is flowing into the line at R_1 and is being absorbed in R_2 . There are no reflections because the line is properly terminated. An equal amount of power flows from R_2 through the transmission line into R_1 . The amount of P_1 can be connected to the vibrational modes of the transmission line in the following way: Let L be its length and c the



Fig. 6.33 Nyquist's idealized arrangement of two resistors in thermal equilibrium, connected by a lossless transmission line that has no thermal properties

velocity of propagation of the electrical signals on the line. Let the line suddenly be isolated from the resistors by short-circuiting both ends so that the electromagnetic waves are trapped and their modes can be counted. The *n*th mode has a wavelength $\lambda_n = 2L/n$ and a frequency $f_n = nc/2\lambda$, so in the frequency interval df there are 2L/cdf modes $(n \gg 1)$, each of which carries an average energy kT.

One half of this energy is the power emitted from R_1 during the time interval L/c, so this power is equal to

$$kT df$$
 (6.95)

in the frequency interval df. It is remarkable that the power density is independent of f, R_1 , and the nature of the resistance.

If one wants to express the emitted power P_1 of one resistor in terms of the fluctuation of the voltage $V_1(t)$, one may calculate the total power dissipated in the two resistors as

$$2P = \frac{1}{2}\overline{(V_1 + V_2)I} = \frac{1}{2R}\left(\frac{V_1^2}{4} + \frac{V_2^2}{4}\right)$$
(6.96)

using $I(t) = 1/2(V_1(t) + V_2(t)/2R)$ plus the fact that V_1 and V_2 fluctuate incoherently. Therefore, using Eq. (6.96), we find that the voltage fluctuations per frequency unit across a resistor is

$$\overline{V_1^2} = 4kTR. \tag{6.97}$$

One says that the voltage noise power spectrum is

$$w(f)df = 4kTRdf, (6.98)$$

where w(f) is expressed in V²/Hz [cf. Eq. (6.79)]. As it is independent of f it is 'white' noise.

Next we have to consider the temperature noise originating from a passive network described by a complex impedance. Let the resistance *R* be connected to such a network with impedance Z(f) = R(f) + iX(f), according to Fig. 6.34 By reasoning according to Nyquist, as above, we know that the power transferred from the



Fig. 6.34 Resistance *R* and network with impedance R(f) + iX(f) on the same temperature, connected to each other. The noise at *R* is $\overline{V^2}$; the noise from the network is $\overline{V(f)^2}$

resistance to the network is equal to that transferred in the opposite direction. The former is seen by simple circuit theory to be equal to

$$\frac{\overline{V^2}R(f)}{(R+R(f))^2 + X(f)^2} df$$
(6.99)

and the latter is simply equal to

$$\frac{V(f)^2 R}{(R+R(f))^2 + X(f)^2} df.$$
(6.100)

We therefore have to conclude that the voltage power spectrum of any passive network is

$$v_v(f)df = 4R(f)kTdf = 4kT\operatorname{Re}[Z(i\omega)]df.$$
(6.101)

The equivalent parallel current noise spectrum is

ı

$$w_i(f)df = \frac{w_v(f)}{|Z(i\omega)|^2} = 4kT \operatorname{Re}[1/Z(i\omega)]df.$$
(6.102)

Following upon Planck's work, we see that Eq. (6.95 ff) are only valid as long as the average energy of one mode of the electromagnetic field is much higher than the quantum energy hf at frequency f (where h is Planck's constant). This is actually the case for all our electronics applications. Under quantum conditions, i.e., for temperatures and frequencies where kT becomes comparable to hf, instead of (6.95) the average energy becomes

$$\frac{hf}{\exp(hf/kT) - 1}$$
 per mode of the electromagnetic field (6.103)

which approaches kT when $kT \gg hf$.

Flicker or 1/f Noise

There is a third category characterized by increasing noise with decreasing frequency. It is not one single well-defined process that causes it but rather a whole collection, sometimes not completely understood. This 'flicker noise' typically occurs in non-equilibrium situations in devices subjected to applied bias voltage to which it is often proportional. Examples are the contact resistance fluctuations in carbon microphones and carbon resistors or leakage currents in the dielectric of capacitors. It occurs in field effect transistors and in many other places discussed in the literature [ROB 74].

The frequency dependence of the power spectrum is often near 1/f and may extend to very low f (on the order of 10^{-2} Hz or less). It is well known that a single relaxation process (one governed by an exponential decrease in the time response) cannot account for the observations, but perhaps a superposition of several would serve. One way to parametrize the power spectrum w(f) is to specify the frequency f_0 at which the flicker noise is equal to the white temperature noise power $w_T(f) = 4kRT df$. The total power spectrum is then

$$w_{tot}(f) = w_T(f) \left(1 + f_0/f\right).$$
 (6.104)

The value of f_0 has been seen to differ from as low as 10^{-2} Hz to as high as 100 MHz, but it is usually in the region of a few kHz [ROB 74]. For practical purposes active electronic circuit components often carry a specification from the manufacturer.

Amplifier Noise

When dealing with signals it is sufficient to represent the amplifier only by its transfer function W(s) and input impedance $Z_{in}(s)$, without referring to the specific realization. However, the noise output signal of an amplifier depends on the specific components of the amplifier circuit and the noise analysis is generally quite a complex task.

It is possible to represent the effect of all the noise sources inside an amplifier by two noise generators at the input of the device, which is treated as a noise-free black box [MOT 93]. If the noise generators are correlated there is in addition a complex correlation coefficient; this we may neglect here because the noise sources are typically quite independent.

Figure 6.35 shows this model, where a voltage noise generator $w_v(f)$ and a current noise generator $w_i(f)$ are placed at the input of the noiseless amplifier. Traditionally the voltage and current noise power spectra of the amplifier are called $w_v(f) = e_n^2(f)$ and $w_i(f) = i_n^2(f)$. We call $e_n^2(f)$ the series noise power spectrum and $i_n^2(f)$ the parallel noise power spectrum of the amplifier. This provides a complete representation of all the internal amplifier noise sources. The voltage and the current noise generators must be dealt with separately because their relative importance depends on the impedance of the signal source. Once this in known they may be contracted in a single noise generator. This is our procedure in what follows.



Fig. 6.35 Amplifier noise model, where the noise is formulated by a pair of noise sources at the input of a noiseless device. The voltage noise generator $w_v(f) = e_n^2(f)$ and current noise generator $w_i(f) = i_n^2(f)$ provide a complete representation of the numerous noise sources inside the real amplifier

In order to calculate the noise power spectra $e_n^2(f)$ and $i_n^2(f)$ one must of course analyze the entire amplifier circuit. Although the numerous elements of the amplifier all contribute to the noise, it is typically only the first element of the circuit (first transistor or feedback resistor) that dominates the noise. The thermal noise, shot noise, and 1/f noise of this first element defines the noise performance of the amplifier. Bipolar transistors or field effect transistors are the classical basic building blocks for detector readout electronics. In semiconductor devices incorporating a p-n junction, the charge carriers interact with fields due to applied external voltages only in the depletion layer at the junction, which is a region that is distinct from the region where their statistical properties are established. Bipolar transistors are then given combinations of $2e_0I_c$, $2e_0I_b$, and $2e_0I_e$ where I_c , I_b , I_e are the collector, base, and emitter currents.

If the interaction region with the external fields coincides with the region where the carrier fluctuations are generated and the carriers remain approximately in thermal equilibrium during their interaction, the thermal (Johnson) noise will dominate. Field effect transistors, where the fluctuations are established in the channel, are typical thermal-noise-limited devices [ROB 74]. The 1/f noises of bipolar and field effect transistors show characteristic differences which have to be considered in the choice of electronics technology.

However, the purpose of our discussion is not the design of the amplifier but rather it is the other way around. By comparing the wire chamber signal and the noise due to the passive components of the wire chamber with the amplifier noise at the input of the amplifier we can define the acceptable magnitudes of the amplifier noise. This procedure results in a *specification* for acceptable amplifier noise.

Because the shot noise and thermal noise are white noise sources we can define an equivalent noise resistance R, where $w_0 = 4kTR$ at T = 295 K gives a power spectrum equal to the one from the input transistor. Although the parallel noise i_n^2 and series noise i_n^2 can both show 1/f noise, we limit ourselves to the following amplifier noise spectra:

$$e_n(f)^2 = 4kTR_s + B/(2\pi f)$$
 $i_n^2(f) = 4kT/R_p.$ (6.105)

The series noise resistance R_s , the parallel noise resistance R_p , and flicker noise coefficient *B* specify the noise behaviour of the amplifier at a given working point.

Noise in a Readout Channel, Electrode+Amplifier

We now have all the ingredients necessary to calculate the noise levels for a readout channel of a wire chamber. We connect the detector model from Fig. 6.32 to the amplifier model from Fig. 6.35 and perform one final simplification: The voltage noise source e_n^2 can be transformed into a current noise source by using Eq. (6.87), and the resulting current noise sources can be contracted into one; the resulting power spectrum assumes the form



Fig. 6.36 All noise sources collected into a single current noise source at the amplifier input. This is our universal model for the ensemble of chamber signal source plus amplifier

$$w(f) = w_i(f) + i_n^2(f) + \frac{e_n^2(f)}{|Z(i\omega)|^2}.$$
(6.106)

The current noise spectrum w(f) is called *equivalent input noise*. We thus have represented the entire readout channel by the chamber impedance Z(s), the parallel current noise density w(f), the amplifier input impedance $Z_{in}(s)$, and the chamber signal I(s) (cf. Fig. 6.36). Note that w(f) is independent of the amplifier's gain and its input impedance. It is this property that makes the equivalent input noise the most useful index upon which to compare the noise characteristics of various amplifiers and devices. Summarizing the previous section, we note that the noise components of Eq. (6.106) are as follows: The thermal chamber noise $w_i(f)$ is caused by the dissipative elements in the wire chamber through $w_i(\omega) = 4kT \operatorname{Re}[1/Z(i\omega)]$. The amplifier noise is represented by the parallel noise resistance R_p , the series noise resistance R_s , and the coefficient for the 1/fnoise:

$$w(\omega) = 4kT \operatorname{Re}\left[\frac{1}{Z(i\omega)}\right] + \frac{4kT}{R_p} + \frac{4kTR_s + B/\omega}{|Z(i\omega)|^2}.$$
(6.107)

The amplifier input impedance $Z_{in}(s)$ enters when we calculate the signal and noise at the output of the amplifier. The fraction of current flowing into the amplifier is $Z/(Z + Z_{in})$, so the chamber current signal and the noise current flowing into the amplifier are

$$I^{in}(s) = \frac{Z(s)}{Z(s) + Z_{in}(s)} I(s) \qquad w_{in}(f) = \frac{|Z(i\omega)|^2}{|Z(i\omega) + Z_{in}(i\omega)|^2} w(f).$$
(6.108)

Finally, the amplifier output signal V(s) and the variance of the amplifier output noise σ_v^2 are

$$V(s) = gH(s)I_{in}(s) \qquad \sigma_v^2 = \frac{1}{2\pi} \int_0^\infty w_{in}(\omega)g^2 |H(i\omega)|^2 d\omega.$$
(6.109)

In the following we use these results to discuss the three most important electrode configurations: cathode readout, wire readout, and a terminated transmission line channel. We want to see their behaviour for both a bipolar and a unipolar shaper.

6.3.3 Noise in Wire Chambers

Cathode Channel

This case is relatively simple because Z(s) is given only by the chamber capacitance C_D , and the parameters of the universal model are

$$Z(s) = \frac{1}{sC_D} \qquad I(s) = I^{ind}(s) \qquad w_i(\omega) = 4kT \text{Re}[1/Z(i\omega)] = 0.$$
(6.110)

The capacitor C_D is not a source of noise because it contains no dissipative elements. The equivalent input noise defined in Eq. (6.107) is therefore given by

$$w(f) = \frac{4kT}{R_p} + 4kTR_s\omega^2 C_D^2 + B\omega C_D^2.$$
 (6.111)

For the readout electronics we take the unipolar and bipolar shapers $H_{uni}(s)$ and $H_{bip}(s)$ from Sect. 6.2 and an amplifier input impedance $Z_{in} = R_{in}$ that is negligible compared to the detector impedance Z. We thus assume that $|Z(i\omega)| = 1/\omega C_D \gg R_{in}$. This is a good approximation for $f \ll 1/2\pi R_{in}C_D$, which for a typical amplifier input resistance of 50 Ω and a detector capacitance of 20 pF evaluates to $f \ll 200$ MHz. We set $Z_{in} = 0$ for Eq. (6.108) and have $I^{in}(s) = I(s)$ and $w_{in}(\omega) = w(\omega)$.

Now we can calculate the amplifier output noise according to Eq. (6.109). We first need the expression $|H(i\omega)|^2$ for the unipolar and the bipolar shapers. $H(i\omega)$ is the Fourier transform of the normalized delta response; it was specified in Eq. (6.37) and depends on the number of stages that make up the shaping circuit (cf. Fig. 6.13); t_p is the peaking time of both the unipolar and the bipolar shaper. We obtain

$$|H_{uni}(i\omega)|^2 = \frac{(e^n t_p n!)^2}{[n^2 + (\omega t_p)^2]^{n+1}} \qquad |H_{bip}(i\omega)|^2 = \frac{1}{n} \frac{(e^r t_p^2 n!)^2 \omega^2}{[r^2 + (\omega t_p)^2]^{n+1}}, \quad (6.112)$$

where $r = n - \sqrt{n}$ as the peaking times are the same. The integration over all frequencies for σ_v leads to integrals of the form $\int x^m / (a^2 + b^2 x^2)^{n+1}$, which can be written in closed form as

$$\int_{0}^{\infty} \frac{x^{2k}}{(a^{2}+b^{2}x^{2})^{n+1}} dx = \frac{1}{a^{2n-2k+1}b^{2k+1}} \frac{\pi}{2} \frac{1}{n!4^{n}} \frac{(2k)!}{k!} \frac{(2n-2k)!}{(n-k)!},$$

$$\int_{0}^{\infty} \frac{x^{2k+1}}{(a^{2}+b^{2}x^{2})^{n+1}} dx = \frac{1}{a^{2n-2k}b^{2k+2}} \frac{1}{2} \frac{k!(n-k-1)!}{n!}.$$
(6.113)

The variance of the amplifier output noise is then

$$\sigma_v^2 = \frac{1}{2\pi} \int_0^\infty \left(\frac{4kT}{R_p} + 4kTR_s \,\omega^2 C_D^2 + B \,\omega C_D^2 \right) |gH(i\omega)|^2 d\omega, \tag{6.114}$$



Fig. 6.37 Cathode pad connected to to an amplifier and the universal model of the readout channel

which finally evaluates to

$$\frac{\sigma_v^2}{g^2} = \left(\frac{4kT}{R_p}\right) K_p t_p + \left(4kTR_sC_D^2\right) \frac{K_s}{t_p} + \left(BC_D^2\right) K_f = \text{ENC}^2.$$
(6.115)

 K_p, K_s and K_f are dimensionless parameters given by

Unipolar Bipolar

$$K_{p} = \frac{1}{2} \left(\frac{e}{2n}\right)^{2n} (2n-1)! \qquad \frac{1}{2} \frac{e^{2r}}{(2r)^{2n}} r(2n-2)!$$

$$K_{s} = \frac{1}{2} \left(\frac{e}{2n}\right)^{2n} n^{2} (2n-2)! \qquad \frac{3e^{2r}}{(2r)^{2n}} r^{3} (n-1)(2n-4)!$$

$$K_{f} = \frac{1}{4\pi} \left(\frac{e}{n}\right)^{2n} n! (n-1)! \qquad \frac{1}{4\pi} \frac{e^{2r}}{r^{2n}} r^{2} (n-1)! (n-2)!$$
(6.116)

These parameters are of the order of unity and they are shown in Fig. 6.38. The noise r.m.s. is written as $\sigma_v = g \text{ENC}$, where ENC is the so-called *equivalent noise charge*.

We saw earlier that injecting a delta current $Q\delta(t)$ into an amplifier of sensitivity g results in an amplifier output pulse height of V = gQ. Therefore, injecting a delta signal with charge Q = ENC into the amplifier results in an output pulse height equal to the r.m.s of the amplifier output noise. The ENC characterizes the noise level independently of the amplifier sensitivity g and is the most useful quantity for comparing the noise behaviour of different amplifiers.









Fig. 6.39 Equivalent noise charge (ENC) as a function of the peaking time, calculated from Eq. (6.115). The three noise components are plotted separately, using typical values for the different noise sources: parallel noise $(R_p = 10k\Omega)$ curves 1, series noise $(R_s = 150\Omega)$ curves 2, 1/f noise curves 3. The resulting total noise curves *S* exhibit a shallow minimum. (**a**) unipolar shaping, (**b**) bipolar shaping, both with n = 4

The three components of the ENC for the cathode channel are due to the parallel white noise, series white noise, and the 1/f noise of the amplifier. The noise r.m.s. for the bipolar and the unipolar shaper as a function of amplifier peaking time is shown in Fig. 6.39. The three components of the noise exhibit a very distinct dependence on the amplifier peaking time. The parallel noise is proportional to $\sqrt{t_p}$, whereas the series noise is proportional to $1/\sqrt{t_p}$. The contribution from the 1/f noise is independent of the amplifier peaking time. The noise σ_v shows a minimum at the peaking time t_{opt} given by

$$t_{opt} = C_D \sqrt{R_s R_p} \sqrt{\frac{K_s}{K_p}} \qquad \text{ENC}_{opt}^2 = 8kT C_D \sqrt{\frac{R_s}{R_p}} \sqrt{K_s K_p} + B C_D^2 K_f. \quad (6.117)$$

The time constant $\tau_c = C_D \sqrt{R_s R_p}$ is the so-called *noise corner time constant*, so the optimum peaking time is of the same order as τ_c . In the following we neglect the small 1/f component of the noise. For estimation of the order of magnitude for t_{opt} and ENC_{opt} we take an example where $R_p = 10 k\Omega$ and $R_s = 100 \Omega$ at room temperature T = 295 K, which results in

$$t_{opt}[\text{ns}] = C_D[\text{pF}] \sqrt{\frac{K_s}{K_p}} \qquad \text{ENC}_{opt} = 350\sqrt{C_D[\text{pF}]} (K_s K_p)^{1/4} \text{ electrons.} \quad (6.118)$$

Assuming a detector capacitance of $C_d = 20-50 \text{ pF}$ and that K_p and K_s are of the order of unity, we find optimum peaking times in the range from 20–50 ns and ENC values between 1500 and 1800 electrons. We will see later that the minimum possible ENC for any kind of shaping function is given by $\text{ENC}_{min}^2 = 4kTC_s\sqrt{R_s/R_p}$, so we can rewrite the expression for the ENC as

$$\operatorname{ENC}^{2}(t_{p}) = \operatorname{ENC}^{2}_{min} \sqrt{4K_{p}K_{s}} \frac{1}{2} \left(\frac{t_{p}}{t_{opt}} + \frac{t_{opt}}{t_{p}} \right).$$
(6.119)



The factor $(4K_pK_s)^{1/4}$ tells us the amount by which the ENC for a given amplifier transfer function differs from the theoretical minimum. Figure 6.40 shows this value for the unipolar and the bipolar shaper.

It is interesting to investigate how the parameters K_p and K_s are related to the actual shape of the electronics delta response. With the help of Parseval's theorem we can perform the calculation of K_s and K_p in the time domain

$$K_p t_p = \frac{1}{2\pi} \int_0^\infty |H(i\omega)|^2 d\omega = \frac{1}{2} \int_0^\infty h(t)^2 dt, \qquad (6.120)$$

$$\frac{K_s}{t_p} = \frac{1}{2\pi} \int_0^\infty |\omega H(i\omega)|^2 d\omega = \frac{1}{2} \int_0^\infty h'(t)^2 dt.$$
(6.121)

The parallel noise is given by the time integral over h(t), which means that it increases as the length of the electronic delta response, and so the peaking time increases. The series noise is given by the integral over the derivative of h(t), and because a shorter delta response has steeper rising and falling edges, the series noise decreases for increasing peaking time.

Up to now we have examined how to minimize the variance σ_v^2 of the amplifier output noise, which is equivalent to maximizing the signal-to-noise ratio when the chamber signal is a delta pulse $I(t) = Q\delta(t)$.

However, our wire signal is different from a delta signal and shows the $1/(t+t_0)$ time dependence. As discussed in Sect. 6.2.1 the peak of the amplifier output signal is approximately given by the charge integrated during the duration $T_I \approx t_p/2$ of the 'flat top' of the delta response, i.e.,

$$v_p(t_p) \approx gQ(t_p) \approx \frac{gq}{2\ln(b/a)} \ln\left(1 + \frac{t_p}{2t_0}\right). \tag{6.122}$$

If we want to optimize the signal-to-noise ratio we must find the best peaking time t_p by maximizing the expression

$$\left(\frac{S}{N}\right)^2 = \frac{Q_p(t_p)^2}{\text{ENC}^2(t_p)} = \left(\frac{q}{2\ln(b/a)}\right)^2 \frac{2}{\text{ENC}_{min}\sqrt{4K_sK_p}} \frac{\ln^2(1+t_p/2t_0)}{t_p/t_{opt}+t_{opt}/t_p}$$

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Fig. 6.41 Optimum peaking time t_{opt}^{Wire} for a wire chamber signal as a function of the time constant t_0 , normalized to t_{opt}^{δ} which is the optimum peaking time for a delta input signal



where t_{opt} gives the optimum signal-to-noise ratio for a delta input signal. The maximum of the expression can only be found numerically, and Fig. 6.41 shows the optimum peaking time as a function of the signal tail t_0 .

For t_0 values that are much shorter than t_{opt}^{δ} the wire chamber signal closely resembles a delta pulse and the optimum peaking time for the wire readout is equal t_{opt}^{δ} . In the case where t_0 is similar to or longer than t_{opt}^{δ} , the optimum peaking time t_{opt}^{Wire} is longer because integrating more of the induced charge is still improving the signal-to-noise ratio.

Terminated Transmission Line

If the signal propagation time along an electrode is of the same order as the signal pulse width as illustrated in Fig. 6.42, the electrode must be terminated in order to avoid multiple signal reflections. A transmission line with characteristic impedance Z_0 can be terminated with a resistor $R_T = Z_0$. In this case, Z(s) consists of a simple resistor R_T , which represents all the electrical characteristics of a terminated transmission line. The chamber model parameters are given by

$$Z(s) = R_T$$
 $I(s) = I^{ind}(s)$ $w_i(f) = \frac{4kT}{R_T}$. (6.123)

While the load resistor R_L for the wire channel is usually dimensioned such that it is a negligible source of noise compared to the amplifier noise, the termination



Fig. 6.42 Transmission line channel connected to to an amplifier and the universal model of the readout channel

resistor R_T of a transmission line is uniquely defined by the chamber geometry and has typical values of 50–500 Ω . Therefore it is usually the termination resistor noise that dominates over the amplifier noise for a transmission line readout.

The equivalent input noise is

$$w(f) = \frac{4kT}{R_T} + i_n^2 + \frac{e_n^2}{R_T^2} = \frac{4kT}{R_T} \left(1 + \frac{R_T}{R_p} + \frac{R_s}{R_T} \right) + \frac{B}{\omega R_T^2}.$$
 (6.124)

For this discussion we neglect the 1/f noise by setting B = 0, but because the order of magnitude of the input impedance is similar to the chamber impedance we cannot neglect Z_{in} as was done for the cathode channel. We therefore have

$$I^{in}(s) = \frac{R_T}{R_T + R_{in}} I(s) = \gamma I(s) \qquad w_{in}(f) = \gamma^2 w(f).$$
(6.125)

The output noise for the unipolar and the bipolar shaper is therefore

$$\sigma_v^2 = \gamma^2 g^2 \frac{1}{2\pi} \int_0^\infty w_{in}(f) = g^2 \gamma^2 \frac{4kT}{R_T} \left(1 + \frac{R_T}{R_p} + \frac{R_s}{R_T} \right) K_p t_p.$$
(6.126)

First we see that the noise r.m.s. is monotonically increasing with the peaking time t_p , so the smallest noise r.m.s. is achieved for the shortest peaking time. To find the ENC we send, as before, a delta signal $Q\delta(t)$ into the amplifier, which gives the output pulse height $v_p = g\gamma Q$, so the equivalent noise charge is

$$\text{ENC}^{2} = \frac{4kT}{R_{T}} \left(1 + \frac{R_{T}}{R_{p}} + \frac{R_{s}}{R_{T}} \right) K_{p} t_{p} = c_{1} t_{p}.$$
(6.127)

For the cathode channel discussed in the previous section, the noise is entirely defined by the amplifier noise i_n^2 and e_n^2 and therefore depends only on the amplifier design. For the terminated transmission line channel, the noise of the termination resistor represents an irreducible noise floor and the amplifier noise is negligible when $R_p \gg R_T$ and $R_s \ll R_T$.

As before, we are interested in optimizing the signal-to-noise ratio for the wire chamber signal:

$$\left(\frac{S}{N}\right)^2 = \frac{Q_p(t_p)^2}{\text{ENC}^2(t_p)} = \left(\frac{Q}{2\ln\frac{b}{a}}\right)^2 \frac{\ln^2(1+t_p/2t_0)}{c_1 t_p} \quad \to \quad \max.$$

The numerical evaluation shows that the expression has a maximum at $t_p \approx 8t_0$. If the input signal were a delta current pulse the signal-to-noise ratio would continuously improve by reducing the amplifier peaking time. Since the wire chamber signal has a tail and the induced charge only increases with the logarithm of time, there is an optimum amplifier peaking time, that maximizes the signal-to-noise ratio.



Fig. 6.43 Wire connected to to an amplifier and the universal model of the readout channel

Wire Channel

The case shown in Fig. 6.43 contains more elements than there were for the cathode and the transmission line channels. For the wire channel we have the following electrical parameters:

$$Z(s) = \frac{1}{sC} + \frac{R_L}{1 + sR_LC_D} \qquad I(s) = \frac{sR_LC}{1 + sR_L(C + C_D)}I^{ind}(s)$$
$$w_i(f) = \frac{4kT}{R_L} \frac{(\omega R_LC)^2}{1 + (\omega R_L(C + C_D))^2} \approx \frac{4kT}{R_L} \quad \text{for} \quad C \gg C_D \quad f \gg \frac{1}{2\pi R_LC}.$$

The loading resistor R_L is a source of thermal noise which is 'filtered' by the detector capacitance C_D and the decoupling capacitor C. The expression for $w_i(f)$ represents the white noise of the resistor filtered by a high-pass filter with time constant $\tau = R_L C$. With the typical numbers of $R_L = 1 \text{ M}\Omega$ and C = 1 nF we have $\tau = 1 \text{ ms}$. Therefore, only frequencies of f < 160 Hz are attenuated, which is negligible for the typical amplifier bandwidth of a few MHz, and we can neglect the effect of C and C_D . We assume again that the amplifier input resistance is negligible with respect to the chamber impedance and we also neglect the 1/f noise term. The equivalent input noise is then

$$w(f) = \frac{4kT}{R_L} + i_n^2 + \omega^2 C_D^2 e_n^2 + \frac{e_n^2}{R_L^2} = \frac{4kT}{R_L} \left(1 + \frac{R_s}{R_L} + \frac{R_L}{R_p} \right) + 4kTR_s \omega^2 C_D^2.$$
(6.128)

This expression has the same form as the one for the cathode channel and the results from there apply to this case as well.

We have seen that the unipolar shaper gives a better signal-to-noise ratio than the bipolar shaper, but the question arises as to whether one can improve the situation still more by yet another kind of electronics transfer function. This problem can be solved in a remarkably general and elegant way, and it is possible find the maximum obtainable signal-to-noise ratio from the amplifier input signal and the spectral noise density at the amplifier input.

6.3.4 A Universal Limit on the Signal-to-Noise Ratio

In the last sections we found that we get different ENC values for different amplifier transfer functions, and that for a specific shape of a delta response there is an optimum peaking time. We found that the unipolar shaper results in a smaller ENC than the bipolar shaper, and the question arises as to whether we can decrease the noise level by yet another transfer function. Or going even further we can ask, what is the maximum obtainable signal-to-noise ratio?

The reason the signal-to-noise ratio can be improved by specific filters is the fact the signal and the noise have different frequency spectra. So it is possible to improve the signal-to-noise ratio by specific filters. The mathematical problem that we have to solve can be formulated as shown in what follows.

A signal $F(i\omega)$ with a superimposed noise having a power spectrum $w(\omega)$ is processed by an amplifier with transfer function $H(i\omega)$. Which transfer function $H(i\omega)$ maximizes the signal-to-noise ratio?

Using Eq. 6.3 and 6.84 we can write the amplifier output signal g(t) and the variance of the noise at the amplifier output as

$$g(t) = \frac{1}{2\pi} \int_{-\infty}^{\infty} F(i\omega) H(i\omega) e^{i\omega t} d\omega \qquad \sigma^2 = \frac{1}{2\pi} \int_{0}^{\infty} w(\omega) |H(i\omega)|^2 d\omega.$$
(6.129)

The output signal g(t) has a maximum at some time t_m when the signal-to-noise ratio S/N at the amplifier output is

$$\left(\frac{S}{N}\right)^2 = \left(\frac{g(t_m)}{\sigma}\right)^2 = \frac{1}{\pi} \frac{\left|\int_{-\infty}^{\infty} F(i\omega) H(i\omega) e^{i\omega t_m} d\omega\right|^2}{\int_{-\infty}^{\infty} w(\omega) |H(i\omega)|^2 d\omega}.$$
(6.130)

This expression has an upper limit given by the Schwarz inequality, which gives the following relation for two complex-valued functions $\psi(x)$ and $\phi(x)$:

$$\left| \int_{a}^{b} \psi^{*}(x)\phi(x)dx \right|^{2} \leq \int_{a}^{b} |\psi(x)|^{2}dx \int_{a}^{b} |\phi(x)|^{2}dx,$$
(6.131)

where the equal sign applies if $\psi(x) = c_1 \phi(x)$ ($c_1 = \text{const}$). If we insert

$$\psi(\omega) = \frac{F^*(i\omega)}{\sqrt{w(\omega)}} e^{-i\omega t_m} \qquad \phi(\omega) = \sqrt{w(\omega)} H(i\omega) \tag{6.132}$$

and extend the integration limits to infinity, the inequality reads as

$$\left|\int_{-\infty}^{\infty} F(i\omega)H(i\omega)e^{i\omega t_m}d\omega\right|^2 \leq \int_{-\infty}^{\infty}\frac{|F(i\omega)|^2}{w(\omega)}d\omega\int_{-\infty}^{\infty}w(\omega)|H(i\omega)|^2d\omega, \quad (6.133)$$

and therefore

$$\left(\frac{S}{N}\right)^2 \le \frac{1}{\pi} \int_{-\infty}^{\infty} \frac{|F(i\omega)|^2}{w(\omega)} d\omega = \frac{2}{\pi} \int_0^{\infty} \frac{|F(i\omega)|^2}{w(\omega)} d\omega.$$
(6.134)

This result is remarkable in two respects. On the one hand, the solution to the problem is surprisingly simple, while, on the other hand, the result has far-reaching consequences: Whichever transfer function $H(i\omega)$ we choose, the (S/N) will always be lower than the value indicated above, which can be calculated in a straightforward fashion from the signal and the noise spectrum at the amplifier input.

Now we would like to know the optimum transfer function $H(i\omega)$ and the output signal $G(i\omega)$. From the above relations we find that the equal sign applies if

$$\frac{F^*(i\omega)}{\sqrt{w(\omega)}}e^{-i\omega t_m} = c_1\sqrt{w(\omega)}H(i\omega) \quad \to \quad H(i\omega) = \frac{1}{c_1}\frac{F^*(i\omega)}{w(\omega)}e^{-i\omega t_m}.$$
 (6.135)

We can omit the factor $\exp(-i\omega t_m)$ because it corresponds simply to a time delay t_m according to Eq. (6.4e). This transfer function is unique up to a constant, and it provides the maximum signal-to-noise ratio. The amplifier output signal is then proportional to

$$G(i\omega) = F(i\omega)H(i\omega) = \frac{|F(i\omega)|^2}{w(\omega)} \qquad g(t) = \mathscr{F}^{-1}[G(i\omega)]. \tag{6.136}$$

We note that this signal g(t) is symmetric around t = 0 because $G(i\omega)$ is real.

As an example we consider a wire chamber cathode pad channel, where we found a noise power spectrum of $w(\omega) = 4kT/R_p + 4kTR_sC_D^2\omega^2 = a^2 + b^2\omega^2$. Assuming that the detector signal is a delta current pulse, we find the following optimum signal-to-noise ratio

$$f(t) = Q\delta(t) \qquad F(i\omega) = Q \qquad \left(\frac{S}{N}\right)^2 \le \frac{2}{\pi} \int_0^\infty \frac{Q^2}{a^2 + b^2 \omega^2} d\omega = \frac{Q^2}{ab} \quad (6.137)$$

The optimum transfer function is

$$H(i\omega) = \frac{1}{c_1} \frac{Q}{a^2 + b^2 \omega^2} \qquad h(t) = \mathscr{F}^{-1}[H(i\omega)] = c_2 e^{-|t|/\tau_c} \qquad \tau_c = \frac{b}{a}.$$
 (6.138)

The time constant τ_c is called the *noise corner time constant*. The delta response of the optimum filter h(t) has a peak at t = 0 and is symmetric around t = 0 from where it decays exponentially. This delta response is called the 'infinite cusp' function. As we saw earlier, a unipolar shaper with n = 6 results in a signal-to-noise ratio that is just 15% worse than the optimum one that would be achieved by using the infinite cusp delta response.

The current signals in a wire chamber are not delta currents but have the hyperbolic $1/(t + t_0)$ form. If we use several pole-zero filters to remove the signal tail such that only a single exponential is left, the chamber signal is given by $f(t) = A_1 \exp(-t/\tau_1)$ and the maximum achievable signal-to-noise ratio is smaller than the one described above. By writing the signal amplitude in terms of the signal charge $Q = \int f(t) dt = A_1 \tau_1$, we have

$$f(t) = \frac{Q}{\tau_1} e^{-t/\tau_1} \qquad F(i\omega) = \frac{Q}{\tau_1} \frac{1}{i\omega + 1/\tau_1} \qquad \left(\frac{S}{N}\right)^2 \le \frac{Q^2}{ab(1 + \tau_1/\tau_c)}.$$
(6.139)

In a previous section we found that it is very useful to approximate the chamber signal by a sum of exponentials, which can be done for every possible signal shape to any desired accuracy. By evaluating the above expressions for an input signal of the form $f(t) = \sum_{n=1}^{N} A_n \exp(-t/\tau_n)$ we can find the maximum achievable signal-to-noise ratio for an arbitrary signal shape. We again write the amplitudes in terms of the charge 'contained' in each exponential $Q_n = A_n \tau_n$. The result is

$$\left(\frac{S}{N}\right)^{2} \leq \frac{1}{ab} \sum_{n=1}^{N} \sum_{m=1}^{N} \frac{Q_{m}}{1 + \tau_{m}/\tau_{c}} \frac{Q_{n}}{1 + \tau_{n}/\tau_{c}} \left[1 + \frac{2\tau_{m}\tau_{n}}{\tau_{c}(\tau_{n} + \tau_{m})}\right].$$
(6.140)

The expression can be used to investigate by what factor the noise for a realistic amplifier transfer function deviates from the theoretical minimum.

6.4 Electronics for Charge Measurement

In the previous sections we discussed the processing of a wire chamber signal for several typical electrode configurations, including the effects of electronic noise. Up to now the signal induced on the electrode was assumed to have the form $1/(t + t_0)$, which is characteristic for any electrode configuration as long as the avalanche electrons are moving in the coaxial region of the wire.

However, the signal shape applies only for a single electron that arrives at the wire and creates a single avalanche. It would also apply for a localized cloud of electrons arriving within a time shorter than t_0 . But the time spread of the incoming electrons is generally much larger than t_0 , so the total signal is a superposition of single-electron signals $i_0(t) = I_0/(1 + t/t_0)$,

$$i_{ind}(t) = \sum_{n=1}^{N} G_n i_0(t - t_n), \qquad (6.141)$$

with arrival times t_n and avalanche sizes G_n . The output of the front-end electronics is then also a linear superposition of the responses to the single electron pulses. The question arises as to how we choose the transfer function $H(i\omega)$ in order to arrive at the best signal-to-noise ratio for this situation. Clearly, the electron arrival times vary from event to event and the electronics can only be adjusted for an average situation.

We first investigate the case of a TPC, where the arrival of the electrons at the sense wires assumes a Gaussian form owing to the diffusion along the drift path. If we define an arrival time distribution n(t) such that n(t)dt is the average number of electrons that arrive between t and t + dt, we have

$$n(t)dt = \frac{N}{\sqrt{2\pi}\sigma_t} e^{-(t-T)^2/2\sigma_t^2} dt,$$
 (6.142)

where σ_t characterizes the electron diffusion along the drift path. Each arriving electron will induce a signal of the form $Gi_0(t)$, where G is the gas gain, and the discrete sum of time-delayed signals of Eq. (6.141) becomes a convolution of n(t) with $i_0(t)$:

$$i(t) = G \int_{-\infty}^{\infty} i_0(t - t') n(t') dt'.$$
 (6.143)

We realize that from a formal point of view, the arrival time distribution n(t) enters like a linear signal processing device in an electronics chain. Using the Fourier transform of n(t) we see that this becomes even more evident because we have

$$I(i\omega) = GI_0(i\omega)N(i\omega). \tag{6.144}$$

We can therefore apply all the results from the previous sections for optimizing the electronic transfer function in order to achieve the best signal-to-noise ratio.

The optimum achievable signal-to-noise ratio for the average signal is given by

$$\left(\frac{S}{N}\right)^2 = \frac{G^2}{\pi} \int_{-\infty}^{\infty} \frac{|I_0(i\omega)N(i\omega)|^2}{w(\omega)} d\omega.$$
(6.145)

If we assume that for reasons of high rate we remove the signal tail with a series of pole-zero filters such that the single electron signal assumes an exponential form with a time constant τ which is negligible with respect to the arrival time distribution, we can assume $I_0(t) = Q\delta(t)$. If we assume in addition that the superimposed noise is white, the optimum transfer function according to Eq. (6.135) is

$$H(i\omega) = \frac{N^*(i\omega)}{w_0},\tag{6.146}$$

a Gaussian with the same width as the arrival time distribution.

With a wire chamber geometry shown in Chap. 7 the arrival time distribution will be different from track to track, depending on the incident angle, the path length variation, and diffusion. The distribution n(t) is given by the function $f_z(t,y)$ in Eq. (7.7) and results in a width given by Eqs. (7.8) and (7.9). The optimizing process can then be conducted as before. In general the optimum amplifier peaking time is such that the width of the delta response is approximately equal to the electron arrival time distribution.

The actual measurement of the charge can be done in different ways. One either records the peak of the signal by a so-called 'peak sensing ADC', or one samples the signal at regular intervals and reconstructs the signal peak by fitting the known response to the sample points.

6.5 Electronics for Time Measurement

In this section we investigate which front-end electronics should be used in order to extract the best time information from the chamber signal. In drift chambers, the time information is used to determine the track position by measuring the arrival time of the ionization electrons at the sense wires. In so-called trigger chambers, the time information is used to determine the time when a charged particle is passing the detector. For the choice of the transfer function $H(i\omega)$ which optimizes the time measurement accuracy we have to consider several effects: the electronic noise, pulse-height fluctuations, and the arrival time distribution of the electrons.

The fluctuations of the electron arrival times are discussed in detail in Sect. 7.4. For long electron drift distances the diffusion effect dominates and the average electron arrival time gives the best time measurement. For short drift distances, the primary ionization fluctuations together with effects such as track inclination and path length variations dominate and the first arriving electrons show the smallest arrival time fluctuations. Mathematically, the optimum time measurement would be achieved by recording the arrival time of each individual electron and performing statistical analyses of the electron arrival time spectrum for each event. Clearly this is not practical. With realistic front-end electronics we can approximately realize some effective weighting of the arrival times and we can choose whether the time information should be given by the first electrons or some effective average of several arriving electrons.

There are several ways of extracting the time information from the signal. We can record the signal shape by sampling the signal at regular intervals and find the time, e.g., by fitting the known average pulse shape to the signal as shown in Fig. 6.44a. This requires of course the recording of multiple data points per signal, and it is only useful in detectors where the signal shape does not vary significantly from event to event. In the following we discuss how to directly extract a single time value from the signal by applying a discriminator, as shown in Fig. 6.44b. A discriminator is a device that creates a square 'logic' output pulse when the input signal crosses a certain applied threshold. The edge of the logic pulse can then be measured by a suitable device, typically called a time to digital converter (TDC). For the discussion of the individual contributions to the time resolution we need the following expressions: the current signal $i_0(t)$ induced by a single ion moving from the wire



Fig. 6.44 (a) Sampling of the signal in regular time intervals for extraction of time time information. (b) Application of a discriminator to the signal where the time information is determined by the threshold crossing time
surface towards the cathode and the amplifier output signal $v_0(t)$ for such an input pulse:

$$i_0(t) = \frac{I_0}{1 + t/t_0} \qquad v_0(t) = g \int_0^t h(t - t') i_0(t') dt'.$$
(6.147)

From Fig. 6.16 and Eq. (6.44) we know that the peak v_{0p} and the peak time T_p of $v_0(t)$ are approximately given by

$$v_{0p} \approx g I_0 t_0 \ln(1 + t_p/2t_0) \qquad T_p \approx t_p$$
 (6.148)

for both the unipolar and the bipolar shaper.

6.5.1 Influence of Electronics Noise on Time Resolution

In order to isolate the effect of electronic noise from chamber intrinsic fluctuations we first assume that m electrons arrive at the wire at exactly the same time and that all electrons experience the same avalanche multiplication G. The induced current, the output signal and the peak of the output signal are then

$$i(t) = mGi_0(t)$$
 $v(t) = mGv_0(t)$ $v_p \approx g mGI_0t_0 \ln(1 + t_p/2t_0)$ (6.149)

Applying a discriminator with a threshold v_T to the amplifier output signal results in a measured time t_T which, in the absence of electronic noise, is strictly related to the arrival time of the electrons (Fig. 6.45). If electronic noise with an r.m.s of σ_v is superimposed on the output signal v(t), the edge time of the discriminator output will vary, as illustrated in Fig. 6.46a. From the figure it is evident that the r.m.s. of the discriminator output time jitter is

$$\sigma_t = \frac{\sigma_v}{k} = \frac{g \,\text{ENC}}{k} \qquad k = v'(t_T), \tag{6.150}$$

where k is the slope of v(t) at the threshold level. The slope k is proportional to v_p/T_p , so we have



Fig. 6.45 Definition of the slope *k* at the threshold crossing, the signal peak time T_p , and the signal peak v_p



Fig. 6.46 (a) Electronic noise resulting in time jitter. (b) Dependence of σ_t on the amplifier peaking time for a cathode readout channel and the parameters $C_d = 20 \text{ pF}$, $R_p = 10 \text{ k}\Omega$, $R_s = 150\Omega$, $I_0 t_0 = e_0/2 \ln(100)$, m = 10, $G = 10^4$, $t_0 = 1 \text{ ns}$, $c_1 = 2$, unipolar shaper with n = 4

$$k \propto \frac{v_p}{T_p} = c_1 \frac{g \, mG \, I_0 t_0 \, \ln(1 + t_p/2t_0)}{t_p} \qquad \sigma_t = \frac{t_p \, \text{ENC}}{c_1 mG \, I_0 t_0 \, \ln(1 + t_p/2t_0)}, \quad (6.151)$$

where c_1 is a constant with a value of $c_1 \approx 1.5 - 2.5$. For faster signal rise times, i.e., for smaller values of t_p , the time jitter σ_t is reduced. We must, however, keep in mind that the ENC also depends on the amplifier peaking time t_p as given by Eq. (6.115). Neglecting 1/f noise we found $\text{ENC}(t_p) = \sqrt{A/t_p + Bt_p}$ for a typical cathode pad readout channel. Thus, for the time jitter we get

$$\sigma_t(t_p) = \frac{t_p \sqrt{A/t_p + Bt_p}}{c_1 m G I_0 t_0 \ln(1 + t_p/2t_0)} \quad A = 4kT R_s C_d^2 K_s \quad B = 4kT K_p/R_p. \quad (6.152)$$

For small values of t_p we find $\sigma_t \propto 1/\sqrt{t_p}$; for large values of t_p the expression increases as $t_p^{3/2}/\ln t_p$. We therefore have an amplifier peaking time t_p for which the slope-to-noise ratio σ_v/k and, therefore, the time jitter σ_t become minimal. It can be shown that the above expression has a minimum at $t_p \leq 8t_0$ for any choice of parameters. Figure 6.46b shows an example of the time jitter versus peaking time for some typical parameters of a cathode channel.

Formally, the problem of minimizing the noise-to-slope ratio, or maximizing the slope-to-noise ratio, can be studied in the same way as the question of the maximum achievable signal-to-noise ratio treated earlier. The formulation of the problem is the following: A signal $F(i\omega)$ with a superimposed noise of power spectrum $w(\omega)$ is processed by an amplifier with transfer function $H(i\omega)$. Which transfer function $H(i\omega)$ maximizes the slope to noise ratio?

The slope of the amplifier output signal g(t) is dg(t)/dt = g'(t), which in the frequency domain corresponds to a multiplication of $G(i\omega)$ with $i\omega$. The slope-to-noise ratio is

$$\left(\frac{k}{\sigma}\right)^2 = \left(\frac{g'(t_m)}{\sigma}\right)^2 = \frac{1}{\pi} \frac{\left(\int_{-\infty}^{\infty} i\omega F(i\omega) H(i\omega) e^{i\omega t_m} d\omega\right)^2}{\int_{-\infty}^{\infty} w(\omega) |H(i\omega)|^2 d\omega}.$$
(6.153)

Proceeding as before we find the maximum achievable slope-to-noise ratio

$$\left(\frac{k}{\sigma}\right)^2 \le \frac{2}{\pi} \int_0^\infty \frac{|\omega F(i\omega)|^2}{w(\omega)} d\omega \tag{6.154}$$

with the optimum transfer function $H(i\omega)$ and the output signal $G(i\omega)$ being

$$H(i\omega) = i\omega \frac{F^*(i\omega)}{w(\omega)} e^{-i\omega t_m} \qquad G(i\omega) = i\omega \frac{|F(i\omega)|^2}{w(\omega)} e^{-it_m\omega}.$$
 (6.155)

We realize that $H(i\omega)$ and $G(i\omega)$ differ only by the factor $i\omega$ from the filters optimizing the signal-to-noise ratio that we found earlier. Since a multiplication with $i\omega$ in the frequency domain corresponds to the derivative in the time domain we can conclude:

For a given signal f(t) and noise power spectrum $w(\omega)$, the amplifier delta response that maximizes the slope-to-noise ratio is equal to the derivative of the amplifier delta response that maximizes the signal-to-noise ratio.

Since the amplifier output signal for maximizing the signal-to-noise ratio is symmetric around t = 0, the amplifier output signal optimizing the slope-to-noise ratio is antisymmetric around zero and the maximum slope-to-noise ratio is found at the zero crossing timer of the signal (Fig. 6.47).

6.5.2 Influence of Pulse-Height Fluctuations on Time Resolution

We now consider the same situation as before, where *m* electrons arrive at the same time at the sense wire, but we let the number *m* fluctuate from event to event according to a distribution p(m) with an average of \overline{m} and an r.m.s. of σ_m (Fig. 6.48a). Although all the electrons arrive at the same time, we find different threshold



Fig. 6.47 Example for the output signal of two optimum filters. The symmetric curve is the output signal for a filter that maximizes the signal-to-noise ratio. The antisymmetric curve is the output of a filter that maximizes the slope-to-noise ratio. The maximum slope-to-noise ratio is found at the zero crossing. The delta response of the filter that maximizes the slope-to-noise ratio is equal to the time derivative of the delta response for the filter that maximizes the signal-to-noise ratio. The same is true for the output signals of the two filters



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Fig. 6.48 (a) Variations of the pulse height result in different threshold crossing times. The effect is called 'time walk'. (b) The zero crossing time of a bipolar pulse is independent of the pulse height

crossing times owing to the pulse-height variations of the signal, an effect that is called 'time walk'. The threshold crossing time and its variance are

$$t_T(m) = \frac{v_T}{k(m)} \qquad \sigma_t \approx \sigma_m \frac{dt_T(m)}{dm}|_{m=\overline{m}} = \frac{t_p v_T}{c_1 m G I_0 t_0 \ln(1 + t_p/2t_0)} \left(\frac{\sigma_m}{\overline{m}}\right).$$
(6.156)

We see that the time walk decreases linearly with the threshold and the peaking time and we therefore want fast electronics and the lowest possible threshold for achieving the best time resolution. However, the lowest possible threshold is again determined by the noise. The frequency f_T of the noise threshold crossings for a threshold v_T is given by

$$f_T = f_{zero} e^{-v_T^2/2\sigma_v^2},$$
 (6.157)

where f_{zero} is the number of zero crossings from Eq. (6.83) [RIC 44]. Setting the threshold v_T to 1,2,3,4,5 times the noise r.m.s. results in a threshold crossing frequency of 0.6,0.14,0.01, 3.3×10^{-4} , 3.7×10^{-6} times f_{zero} . With f_{zero} being in the range of 10–100 MHz we have to set the threshold v_T to at least five times the noise r.m.s. in order to arrive at a noise count rate of less than 100 Hz. We use $v_T = 5 \sigma_v$ in the following. The discriminator threshold v_T is typically expressed as a charge according to $v_T = gQ_T$ in order to arrive at expressions independent of the amplifier sensitivity. The amplifier output noise is $\sigma_v = gENC$, and we therefore have a threshold of $Q_T = 5ENC$:

$$\sigma_t = \frac{t_p 5 \sqrt{A/t_p + Bt_p}}{c_1 \overline{m} G I_0 t_0 \ln(1 + t_p/2t_0)} \left(\frac{\sigma_m}{\overline{m}}\right).$$
(6.158)

This expression is equal to the expression for the time jitter up to a factor $5\sigma_m/\overline{m}$. Therefore the peaking time that minimizes the jitter due to electronic noise also minimizes the jitter due to pulse-height variations. The combined effect of electronic noise and pulse-height fluctuations becomes

$$\sigma_t = \sqrt{\sigma_{jitter}^2 + \sigma_{walk}^2} = \sqrt{1 + \left(\frac{5\sigma_m}{\overline{m}}\right)^2 \frac{t_p \sqrt{A/t_p + Bt_p}}{c_1 \overline{m} G I_0 t_0 \ln(1 + t_p/2t_0)}}.$$
(6.159)

If the relative pulse-height variations σ_m/\overline{m} are greater than one, which is usually the case in wire chambers, the time resolution is dominated by the pulse-height variations and not by the jitter from electronic noise. On the other hand, it is the noise that sets the lower limit on the threshold level, so it is the noise alone that determines the time resolution owing to jitter and walk.

There are numerous ways of eliminating this pulse-height dependence of the threshold crossing time. One can, for instance, exploit the fact the zero crossing time of a bipolar-shaped pulse is independent of the signal amplitude, which follows directly from the linearity of the system, as shown in Fig. 6.48b. Another possibility is the use of a so-called constant fraction discriminator that uses a threshold which is always set to a certain fraction of the signal peak. These techniques are applicable when the arrival time spread of the electrons is negligible compared to noise and pulse-height variation effects. In the next section we investigate how variation in the electron arrival time influences the time resolution.

6.5.3 Influence of Electron Arrival Time Fluctuations on Time Resolution

In the previous section we assumed that the number of electrons arriving at the wire varies from event to event, but that all the electrons arrive at the same time. Now we include the effect that the *m* individual electrons arrive at different times $t_1, t_2 \dots t_m$. The arrival times of the electrons as well as the number of electrons *m* fluctuate from event to event. In Sect. 7.4 it is shown that the average electron arrival time gives the best timing only when the diffusion dominates the arrival spread, as for distant tracks in a TPC.

For short drift distances, the primary ionization fluctuations together with effects such as track inclination and path length variations dominate, and the first arriving electrons show the smallest arrival time fluctuations. For geometries like the drift tube, the average electron arrival time shows a very large r.m.s. even for long drift distances because the last arriving electrons always originate close to the tube wall and therefore have no correlation with the drift distance (Fig. 6.49). To study the effect of the arrival time spread we first investigate the bipolar shaping scheme,



Fig. 6.49 Electron drift lines in a drift tube. The distance of the track from the wire is determined by the first arriving electrons. The last arriving electrons originate from the tube wall and have no correlation with the track distance





Fig. 6.50 Pulses from three electrons arriving at the wire at different times. The solid lines show the pulses of the individual electrons; the dotted lines correspond to the sum of the pulses giving the measured chamber signal. Parts (a) and (b) show the bipolar-shaped signals where the time measurement is given by the zero crossing of the chamber signal. Parts (c) and (d) show the unipolar-shaped signals where the time measurement is given by the threshold crossing of the chamber signal. The two schemes have distinctly different timing properties

where the zero crossing of the signal determines the measurement time. Figure 6.50a shows the signals from three individual electrons arriving at different times and the resulting chamber signal which is the sum of the individual electron signals. Around the zero crossing the electron signals can be approximated by a straight line with a slope -k (Fig. 6.50b), and the individual electron signals $v_i(t)$ and the resulting signal v(t) can be approximated by

$$v_i(t) = -k(t - t_i)$$
 $v(t) = \sum_{i=1}^m v_i(t) = -kmt - k\sum_{i=1}^m t_i.$ (6.160)

The zero crossing time t_T of the signal v(t) is

$$v(t) = 0 \quad \rightarrow \quad t_T = \frac{1}{m} \sum_{i=1}^m t_i = \overline{t}$$
(6.161)

and equal to the average arrival time of the m electrons. This scheme is therefore applicable for the 'diffusion dominated' cases mentioned above.

If we want the *n*th electron to give the timing information we can imagine an amplifier that produces a step function output signal of amplitude v_0 for a single

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electron. The step functions of the individual arriving electrons would therefore pile up and by setting the threshold to $v_T = nv_0$ we would measure the arrival time of the *n*th electron. However, true step function requires an amplifier of infinite bandwidth, and a realistic step function will take a certain time to rise from zero to v_0 . This time must be shorter than the time between arriving electrons such that the pulses are really piling up. Since the time between the first arriving electrons is typically much less than a nanosecond, the bandwidth of such an amplifier must be extremely broad, and the corresponding large noise might not allow a threshold that is low enough to record the early electrons. In some rare cases this might still be a viable option. Typically the amplifier peaking time is much longer than the time intervals between arriving electrons and it is not the pulse heights but the *slopes* of the individual electrons that pile up as shown next.

Figure 6.50c shows the signals from three individual electrons and the resulting chamber signal. The time information is given by the threshold crossing time of the leading edge of the chamber signal. The signals $v_i(t)$ from the individual electrons can again be approximated by 'straight lines', as indicated in Fig. 6.50d, but in contrast to the bipolar shape from before, these straight lines do not cross the zero line, but start from zero at $t = t_i$. This is illustrated in Fig. 6.51. A single electron arriving at time t_i produces the signal

$$v_i(t) = k(t - t_i)\Theta(t - t_i)$$
 $v(t) = \sum_{i=1}^m k(t - t_i)\Theta(t - t_i).$ (6.162)

The chamber signal is therefore

$$v(t) = 0 t < t_1$$

$$v(t) = k(t - t_1) t_1 < t < t_2$$

$$v(t) = k(t - t_1) + k(t - t_2) t_2 < t < t_3$$
(6.163)







6 Electronics for Drift Chambers

and in general we get

$$v(t) = \sum_{i=1}^{n} k(t - t_i) = knt - k \sum_{i=1}^{n} t_i \qquad t_n < t < t_{n+1}.$$
 (6.164)

Whenever a new electron arrives the slope changes by k, and after the arrival of the nth electron the signal slope is $k_s = nk$. The threshold crossing time t_T is

$$v(t) = v_T \quad \to \quad t_T = \frac{1}{n} \sum_{i=1}^n t_i + \frac{v_T}{kn} = \bar{t}_{< n} + \frac{v_T}{kn} \quad \text{if} \quad t_n < t_T < t_{n+1}.$$
 (6.165)

We see that the threshold crossing time is equal to the average arrival time of the *n* electrons that arrived before the threshold crossing plus another term that is inversely proportional to *n*. Figure 6.51 shows an example in which four electrons arrive at times t_1, t_2, t_3 , and t_4 . The chamber signal crosses the threshold before the arrival of the fourth electron, so we have n = 3 and the threshold crossing time is

$$t_T = \frac{1}{3}(t_1 + t_2 + t_3) + \frac{v_T}{3k}.$$
(6.166)

If all the electrons arrive at the same time t = 0 we are left with only the second term, which is equal to the expression for the time walk discussed in the previous section. We can therefore state that the first term is due to the electron arrival time spread and the second term to the varying number of electrons that contribute to the signal at the threshold crossing time. However, the two expressions correlate in a complex way.

If we want to explicitly calculate the threshold crossing time distribution and its r.m.s., it is not sufficient to know the average and r.m.s of the arrival distribution for the *n*th electron. The threshold crossing time depends on the arrival times of all n electrons, so we need the probability density

$$P(t_1, t_2, t_3...)dt_1dt_2dt_3..., (6.167)$$

which gives the probability that the first electron arrives in the time interval $t_1, t_1 + dt_1$, the second arrives in the time interval $t_2, t_2 + dt_2$, etc. The distribution $P(t_1, t_2 ...)$ is typically generated with a Monte Carlo simulation program. Instead of finding an analytic parametrization of the Monte Carlo generated distributions and evaluating the integrals of the probability distribution it is much easier to record the arrival time pattern $t_1, ..., t_m$ for each Monte Carlo event and to find the chamber signal by superimposing the single-electron pulse $v_0(t)$ according to

$$v(t) = \sum_{i=1}^{m} v_0(t - t_i).$$
(6.168)

By adding the expected noise signal to v(t) we find a set of pulses from which we can calculate the threshold crossing times and therefore the time r.m.s. This procedure is very fast and by varying the threshold and electronic parameters it is a straightforward task to find the optimum electronic parameters.

We can, on the other hand, get a good qualitative idea about the optimum electronic parameters. If we assume that the first electron arrives at t = 0 and the following electrons arrive at regular time intervals Δt , the chamber signal v(t) becomes

$$v(t) = \sum_{i} k(t - i\Delta t) \Theta(t - i\Delta t) \approx \frac{kt^2}{2\Delta t}.$$
(6.169)

The threshold crossing time t_T and the number of electrons *n* having arrived at the wire before t_T are

$$t_T \approx \sqrt{\frac{2v_T \Delta t}{k}} \qquad n \approx \frac{t_T}{\Delta t} = \sqrt{\frac{2v_T}{k\Delta t}}.$$
 (6.170)

If the electrons are separated by $2\Delta t$ instead of Δt the threshold crossing time is a factor $\sqrt{2}$ later. The two 'events' with an electron separation Δt and $2\Delta t$ are shown in Fig. 6.52. The time difference Δt_T between the two threshold crossings for the two signals is

$$\Delta t_T = (\sqrt{2} - 1)\sqrt{\frac{2v_T \Delta t}{k}}.$$
(6.171)

The variation of the threshold crossing time therefore decreases for lower threshold and large slope (faster electronics) as was the case for pulse height fluctuations and time walk. The lower threshold limit is again determined by the noise level. The effects of pulse-height variation, discussed in the previous section, and the arrival time fluctuations cannot be separated because they are highly correlated. A larger primary ionization will also result in shorter time intervals between arriving electrons. The only effect that can be added in square is the jitter from electronic noise that is independent of the electron statistics.

On the one hand, lowering the threshold v_T and increasing the signal slope k (broader bandwidth, i.e., smaller peaking time) will reduce the effect of arrival time



Fig. 6.52 Two signals where the electrons arrive at the wire at regular time intervals Δt and $2\Delta t$, respectively

fluctuations and related pulse-height fluctuations. On the other hand, a broader bandwidth will increase the noise and a lower threshold will increase the noise jitter because of the parabolic shape of the signal. The compromise between these two tendencies will define the optimum amplifier peaking time, which will again be of the order of a few times t_0 .

Finally we note that the slope of the signal at the threshold crossing time $k_s = nk$ measures the number of electrons that have contributed to the signal, and by using this information we can improve the time resolution. The slope can, for example, be measured by a second threshold (Fig. 6.52) or by a device that measures the signal charge in a short time interval following the threshold crossing time. This technique is known as *amplitude and rise time compensation* and allows extraction of the optimum time information from the signal.

6.6 Three Examples of Modern Drift Chamber Electronics

In this last section we present some front-end electronics examples that are being used in large detector systems. We discuss an amplifier for time measurement used at rates up to 15 MHz, an amplifier for charge measurement in a cathode strip chamber, and a front-end system for a TPC.

6.6.1 The ASDBLR Front-end Electronics

The ASDBLR (amplifier shaper discriminator baseline restorer) chip [BEN 96] is an eight-channel front-end chip developed for readout of the ATLAS [ATL 94] transition radiation tracker [AKE 04]. The chip is implemented in a radiation hard bipolar process. The tracker consists of almost half a million drift tubes of 4 mm diameter with a 30- μ m-diameter anode wire. A xenon-based gas mixture at a gas gain of $\approx 2 \times 10^4$ is used. The goal is a spatial resolution of better than 150 μ m at extreme rates of up to 15 MHz. To cope with this high rate, unipolar signal shaping was chosen. The ASDBLR circuit is based on a front-end described in [FIS 85], and the equivalent block diagram is equal to the one shown in Fig. 6.27 top. It consists of a large bandwidth preamplifier with 1 ns rise time followed by a unipolar shaper (n = 3) that provides a peaking time of $t_p = 8$ ns. The preamp input impedance of $R_{in} = 295 \Omega$ is matched to the characteristic impedance of the drift tube, which represents a capacitance of $C_D \approx 12 \,\mathrm{pF}$. A double pole-zero network cancels the signal tail. In order to provide the baseline stability at the very high rates, the shaper is followed by a fast (nonlinear) baseline restoration circuit using diodes. For very small signals, the BLR acts like a CR differentiation circuit and produces a bipolar output. As the shaper signals grow in magnitude, the exponential behaviour of the diodes causes the undershoot to rise logarithmically with the pulse height, which results in a unipolar signal shape. With this signal processing chain, the return to baseline is 30 ns for a $v_p/g = 2$ -fC pulse and 60 ns for a $v_p/g = 200$ -fC pulse. The achieved ENC with attached drift tube is approximately 2300 electrons. The sensitivity of g = 20 mV/fC provides a full-scale linear range for pulse heights from 0 to $v_p/g = 200$ fC. The last circuit element is a discriminator with two thresholds providing the leading edge time (low threshold) and the identification of an X-ray photon hit (high threshold). A single-wire resolution of $100 \,\mu$ m and efficiency of 80% at low rate is achieved. At a rate of 17 MHz, the resolution is $120 \,\mu$ m and the efficiency is 50% [AKE 04].

6.6.2 The ATLAS CSC Front-end Electronics

The ATLAS CSC fronted chip [OCO 99][JUN 05] is designed for readout of the ATLAS cathode strip chambers [BEN 95]. These chambers measure muon tracks with an accuracy of $\approx 50\,\mu$ m by using charge interpolation of cathode strips with a pitch of 5.08 mm. The chambers are multiwire proportional chambers with a wire pitch and wire-to-cathode distance of 2.54 mm. The gas used is an Ar/CO₂ mixture operated at a gas gain of 2×10^4 . For a pitch of 5 mm and the specified position resolution of 50 μ m, a signal-to-noise ratio of about 150 is required. This leads to a specification for an ENC of less than 2500 electrons for the chosen operating point. The cathode strip capacitance ranges from 50 to 100 pF.

The front-end electronics developed for this detector consists of a bipolar shaper with a peaking time of 75 ns, resulting in a total pulse length of about 300 ns. This number is a compromise between noise performance and the inefficiency at the highest expected rates of about 600 kHz. This bipolar shaper is not the one described in the previous sections, but a shaper with one real pole and six complex poles, called a seventh- order complex Gaussian filter [OHK 76]. It has the advantage of a more symmetric response compared to the bipolar shaper realized by an equivalent number of real coincident poles and having the same pulse-width. The achieved noise performance is $1140+17.6 \text{ e}^-/\text{pF}$. The sensitivity is 3.8 mV/fC, which allows a linear range of 450 fC. A single chip of $3.29 \times 5.79 \text{ mm}$ size contains 25 channels and the power dissipation amounts to 32.5 mW/channel. The output signals are then sampled at a 20 MHz rate and readout on a level 1 trigger to a 12 bit analog to digital converter (ADC).

6.6.3 The PASA and ALTRO Electronics for the ALICE TPC

The PASA (preamplifier shaper) chip together with ALTRO (alice TPC readout) chip [MUS 03] form the front-end of the time projection chamber for the ALICE [ALI 95] [APP 99] experiment. This ALICE TPC consists of a cylindrical gas volume of about 90 m³ under a uniform electrostatic field and a drift distance of up to 2.5 m. At the endplates, multiwire proportional chambers provide a readout by

means of a cathode plane segmented into about 6×10^5 pads. These pads are connected to the PASA chip, a 16-channel amplifier chip providing a delta response with a peaking time of $t_p \approx 150$ ns and a full width at half maximum of about 200 ns. The peaking time is realized by two so-called T-bridge second-order shapers resulting in two pairs of real poles. The transfer function is, however, very similar to an n = 4 unipolar shaper. The diffusion of the gas used is quoted as $220 \,\mu\text{m}/\sqrt{\text{cm}}$, so a diffusion of $\sigma = 2.2 \,\text{mm}$ at a drift distance of 100 cm and $\sigma = 3.5 \,\text{mm}$ at a drift distance at 250 cm is expected. With a drift velocity of 28.3 μ m/ns this corresponds to a FWHM of the arriving electron cloud of 180 and 290 ns. The choice of 200 ns for the FWHM of the shaper is therefore a compromise in terms of optimum signal-to-noise ratio and pulse width. The ENC of the PASA chip is < 1000 electrons in order to allow a signal-to-noise ratio of 30 at the specified working point. The sensitivity is $g = 12 \,\text{mV/fC}$ with a linear range of 2 V.

The signal from the PASA is then fed into the ALTRO chip [BOS 03], which integrates 16 channels, each consisting of a 10-bit, 10 MS/s ADC, followed by a programmable digital baseline subtraction and tail cancellation filter, a zero suppression unit, and a multi-event buffer. All this functionality is contained in an 8×8 mm CMOS chip. The tail cancellation filter can be programmed to represent any fourth-order filter, i.e., any transfer function consisting of a fourth-order polynomial in the numerator and the denominator. The advantage of such an approach is evident: The signal tail cancellation time constants do not have to be hardwired into the front-end electronic chip but are fully programmable, which provides maximum flexibility. Clearly, the integration of the front-end chip in the ALTRO is a desirable next step.

We conclude this section by noting that the extreme miniaturization of microelectronic components, together with the reduced power consumption, has allowed the placement of a large number of electronic channels very close to the detector, which makes the systems very compact and economic.

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Chapter 7 Coordinate Measurement and Fundamental Limits of Accuracy

7.1 Methods of Coordinate Measurement

After the passage of a charged particle through the sensitive gas volume, the electrons produced in the ionization process along a trajectory segment drift toward the sense wire, where they are collected and amplified in avalanches. There are essentially four different methods to determine particle coordinates in drift chambers:

- 1. *Measurement of the drift time*. Using the known drift velocity of the ionization electrons along their drift trajectory, this determines the distance along the drift trajectory between wire and track.
- 2. *Measurement of the pulse-height ratios on pick-up electrodes* (strips, "pads", wires) near the sense-wire avalanche. With electrode response known this determines the coordinate of the avalanche between the pick-up electrodes. If the drift trajectory is known, the corresponding coordinate is determined. In this way the coordinate along the sense wire is measurable.
- 3. *Measurement of the pulse-height ratios at the two ends of a sense wire* (charge division). The position of the avalanche along the wire is determined using the known damping of the pulse as it propagates along the wire.
- 4. *Measurement of the difference of arrival times at the two ends of a sense wire* (time difference). This has been used for the same purpose, applying the known propagation time of the signal on the wire.

Of these, methods 3 and 4 measure the coordinate along the wire direction and method 1 measures the coordinate in the drift direction. The coordinate direction of method 2, finally, is given by the arrangement of the pick-up electrodes. A combination of method 1 with one of the others allows a three-dimensional position measurement of the track segment to be made, provided the drift trajectories are known.

Methods 1 and 2 are the most powerful in terms of the achievable accuracy because it turns out that the electronic measurement of the time and of the pulse-height ratio on neighbouring electrodes can often be made better than the fundamental limits imposed by the properties of the ionization that arrives on the wire. Comparing methods 2 and 3 we notice that in both cases the coordinate is obtained from a known function of a pulse-height ratio times a length: the distance Dbetween the pick-up electrodes in method 2 and the wire length L in the other case. It is clear that the response (i.e. the change in pulse-height ratio per unit length of avalanche displacement) with method 2 is better than the response with method 3 by the order of magnitude of the ratio L/D. The designer of the chamber has to pay for this advantage with a correspondingly larger number of electronic channels.

Comparing methods 1 and 4, both based on a measurement of time, method 4 is less favourable because the response (i.e. the change in measured time per unit length of coordinate displacement) is inversely proportional to the velocity involved, this being the drift velocity u in the gas for method 1 and the signal propagation velocity v (a good fraction of the speed of the light) along the sense wire for method 4. Therefore the response with method 1 is better than the response with method 4 by the order of magnitude of the ratio v/u, which has typical values of 10^3 to 10^4 .

It is not our goal to review here the various technical aspects of these methods, such as pulse propagation, amplifier noise or discriminator behaviour. Our interest is focussed on the fundamental processes that create limitations which cannot be overcome by technical improvements. In methods 1 and 2 we have techniques to measure the coordinate such that the error resulting from imperfections of the electronics can be made much smaller than that deriving from the fundamental processes.

If all the technical problems have been solved, which means that the wire positions are under control, the drift-velocity field is known well enough (implying the absence of unknown field distortions of the electric and magnetic fields) and if the electronics is capable of measuring the drift time or the pulse-height ratio of the induced signals with sufficient accuracy, then we are ultimately faced with the statistical fluctuations of the finite number of electrons involved in the measuring process. These fluctuations are strongly influenced by the clustering of the ionization process itself. They are the fundamental limitation of any coordinate measurement in drift chambers and become effective because of the presence of mechanisms which spread the ionization cloud as it reaches the wire. In this chapter we will study the most important mechanisms of spread: the diffusion in the drift toward the sense wire, the drift path, and time variations due to the inhomogeneous electric field near the wire and those due to an angle the track might have with the wire. In the presence of a magnetic field, the cylindrical electric field near the wire can combine with the magnetic field and create a spread of ionization as if the track had an angle with the wire.

The problem of accuracy can be described in the following terms. The ionization electrons from the track element in question arrive at the wires; they are spread both in arrival time and along the wires. What are the best estimates for the two coordinates and what is their statistical variation?

In order to understand this better, we will first analyse the spreading on a single wire and how it depends on the track angles, the wire geometry, the magnetic and electric fields and the diffusion. Then we have to discuss how much we gain from the fact that there is not one electron but many electrons arriving. Here the nature of the ionization, which is clustered, plays a role. Anticipating the result of this chapter, we summarize the benefit of having many electrons as follows. When diffusion is the main source of spreading, the increase in accuracy is a function of the total number N of electrons, in the sense that the r.m.s. measurement error decreases as $1/\sqrt{N}$. When any of the other mechanisms is the main source of spreading, the accuracy is a function only of N_{eff} , a number which is usually much smaller than N and depends on the length of the track segment as well as on diffusion.

Recently another basic problem has been discovered which, in principle, is capable of limiting the measuring accuracy of drift chambers. Long wires may be excited to vibrations by the unavoidable momentum transfer from the avalanches to the wire. Coordinate measurements become less accurate to the extent that the wire position is unknown. Although it is only in special circumstances large enough to bother, the phenomenon is a fundamental limitation of coordinate measurements. It will be treated in Sect. 7.5.

7.2 Basic Formulae for a Single Wire

For the coordinate measurements along the wire direction and along the drift direction there are some common aspects that we want to underline. In both cases the accuracy is limited by a track angle which spreads the ionization at the wire and by diffusion which amplifies this spread.

The most general orientation a track might have with the wire plane is given by two angles θ and α . For the measurement along the wire, only the angle θ between the track projected onto the wire plane and the wire is relevant, and for the measurement along the drift direction it is the angle α between the track projected onto the plane orthogonal to the wire and the wire plane.

We consider the simplified scheme of a drift chamber given in Figs. 7.1 and 7.2. The sense wire is parallel to the *x* axis and contains the point of origin y = z = 0. We show two regions: the "drift region", where the ionization electrons drift and



Fig. 7.1 Scheme of a drift cell. For a study of the ionization spread on the wire, we consider a track parallel to the x-y plane



Fig. 7.2 Scheme of a drift cell. For a study of the spread of arrival times we consider a track parallel to the z-y plane

diffuse, and a "wire region" where they are collected on the wire. The drift-velocity vector is assumed constant in the drift region and the diffusion in the wire region is neglected.

In Fig. 7.1 we have drawn the case relevant for the coordinate along the wire, where the track may be assumed to be parallel to the x-y plane. In Fig. 7.2 we have drawn a different track, parallel to the x-z plane, relevant for the coordinate along the drift direction. In the following we discuss those aspects of the problem that are common to the determination of both coordinates.

The ionization clusters are randomly distributed along the particle trajectory with uniform distribution. An electron is collected by the wire if it arrives at -b/2 < y < b/2 at the entrance of the wire region after its drift and its random diffusion. Because of diffusion, electrons produced at y < -b/2 or at y > b/2 may also be collected by the wire and contribute to the measurement.

Since we neglect the diffusion in the wire region, the arrival position and time of one electron on the wire are completely determined by its arrival coordinates and time at the entrance to the wire region. We discuss first the distribution of these variables in the case of a single electron, and later we treat the statistical problems connected with the ensemble of collected electrons.

7.2.1 Frequency Distribution of the Coordinates of a Single Electron at the Entrance to the Wire Region

This distribution is determined by the trajectory of the particle and by the random diffusion of the drifting electron in the drift region.

We begin with the particular case shown in Fig. 7.1: a charged particle parallel to the *x*-*y* plane produces ionization clusters at coordinates $x = x_0 + s \sin \theta$, $y = s \cos \theta$ and $z = z_0$, where *s* is the coordinate along the track and θ is the angle between the perpendicular to the wire and the projection of the trajectory on the wire plane.

7.2 Basic Formulae for a Single Wire

The arrival position of an electron produced at coordinate *s* along the track is distributed according to a Gaussian diffusion around the production coordinate, while *s* is uniformly distributed along the trajectory. Introducing the symbol *G*,

$$G(x|\langle x \rangle, \sigma) = \frac{1}{\sqrt{2\pi\sigma}} \exp\left(-\frac{(x-\langle x \rangle)^2}{2\sigma^2}\right)$$

to denote the generic Gaussian function of average $\langle x \rangle$ and r.m.s. σ we can write down the frequency distribution of the arrival positions and time of the electron at the entrance of the wire region ($z = z_w$) as

$$F(x, y, t) dx dy dt = \frac{dx dy dt}{R} \int_{-R/2}^{+R/2} ds \ G(x|x_0 + s \sin \theta, \sigma_x) \\ \times G(y|s \cos \theta, \sigma_y) G(t|(z_0 - z_w)/u, \sigma_t) .$$
(7.1)

Here $\sigma_x, \sigma_y, \sigma_t = \sigma_z/u$ denote the diffusion r.m.s. in the three directions (in the most general case we should introduce the diffusion tensor) and *u* is the drift velocity assumed along *z*. *R* is the length of a track arbitrarily chosen so large that $R \cos \theta \gg b$ and $R \cos \theta \gg \sigma_i (i = x, y, z)$. In the following we will always take the limit $R \to \infty$.

This frequency distribution has been written assuming that just one ionization electron is produced along the track segment *R*. This electron is collected by the wire and contributes to the coordinate measurement only if its arrival position at the entrance to the wire region satisfies the condition -b/2 < y < b/2. The probability that this electron is collected by the wire is

$$\int_{-\infty}^{+\infty} dx \int_{-\infty}^{+\infty} dt \int_{-b/2}^{+b/2} dy F(x, y, t) = \frac{b}{R\cos\theta}$$
(7.2)

and is equal to the ratio between the length of the portion of the track between the planes y = -b/2 and y = b/2 and R.

If we are interested in the measurement of the coordinate along the wire direction (x) alone, the readout electronics will integrate electrons arriving at different times: the probability distribution of the arrival positions at the entrance of the wire region for the electrons that are collected by the wire is obtained integrating the distribution F(x, y, t) given by (7.1) in the variable *t* and normalizing it using (7.2):

$$f_x(x,y)dxdy = dx dy \frac{\cos\theta}{b} \int_{-R/2}^{+R/2} ds G(x|x_0 + s\sin\theta, \sigma_x)G(y|s\cos\theta, \sigma_y).$$
(7.3)

Assuming that the *x* coordinate on the wire is the same as at the entrance to the wire region we can compute the average and the variance of the arrival position at the wire as

7 Coordinate Measurement and Fundamental Limits of Accuracy

$$\langle x \rangle = \int_{-b/2}^{b/2} \mathrm{d}y \int_{-\infty}^{+\infty} x f_x(x, y) \mathrm{d}x = x_0 , \qquad (7.4)$$

$$\langle x^2 \rangle - \langle x \rangle^2 = \sigma_x^2 + \sigma_y^2 \tan^2 \theta + \frac{b^2}{12} \tan^2 \theta .$$
 (7.5)

The variance of x is the sum of three terms: the first two depend on diffusion, the third is the projection of the track segment on the wire; this latter we call the *angular wire effect*. The factor 1/12 that divides the square of the width b of the drift cell comes from the variance of the uniform distribution of the electrons along the track.

7.2.2 Frequency Distribution of the Arrival Time of a Single Electron at the Entrance to the Wire Region

We now turn to the particular case shown in Fig. 7.2: a charged particle parallel to the *y*-*z* plane produces ionization clusters at coordinates $x = x_0$, $y = s \cos \alpha$ and $z = z_0 + s \sin \alpha$, where *s* is the coordinate along the track and α is the angle between the perpendicular to the drift-velocity direction (*z*) and the projection of the trajectory on the wire *z*-*y* plane.

The frequency distribution of the arrival positions and time of the electron at the entrance of the wire region $(z = z_w)$ is

$$F(x, y, t) dx dy dt = \frac{dx dy dt}{R} \int_{-R/2}^{+R/2} ds G(x|x_0 + \sigma_x) \\ \times G(y|s \cos \alpha, \sigma_y) G(t|(z_0 + s \sin \alpha - z_w)/u, \sigma_t) .$$
(7.6)

If we are interested in the measurement of the coordinate along the drift direction z alone, the readout electronics will not distinguish among electrons arriving at different wire positions: the probability distribution of the arrival time at the entrance to the wire region for the electrons that are collected by the wire is obtained by integrating the distribution given by (7.6) in the variable x and normalizing it using (7.2):

$$F_{z}(t,y)dtdy = dtdy \frac{\cos\alpha}{b} \int_{-R/2}^{+R/2} ds G(t|(z_{0}+s\sin\alpha-z_{w})/u,\sigma_{t})$$
$$\times G(y|s\cos\alpha,\sigma_{y}).$$
(7.7)

Assuming for the moment that the arrival time on the wire is equal to the time at the entrance to the wire region, plus the constant shift z_w/u , we can compute the average and the variance of the arrival time at the wire;

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7.2 Basic Formulae for a Single Wire

$$\langle t \rangle = \int_{-b/2}^{b/2} dy \int_{-\infty}^{+\infty} t f_z(t, y) dt = z_0/u , \qquad (7.8)$$

$$\langle t^2 \rangle - \langle t \rangle^2 = \sigma_t^2 + \frac{\sigma_y^2}{u^2} \tan^2 \alpha + \frac{b^2}{12u^2} \tan^2 \alpha .$$
 (7.9)

,

Comparing (7.3) and (7.7) we observe that one can obtain one distribution from the other with the substitutions

$$f_x \leftrightarrow f_z ,$$

$$x \leftrightarrow z = tu ,$$

$$x_0 \leftrightarrow z_0 - z_w ,$$

$$\sigma_x \leftrightarrow \alpha_z = \sigma_t u$$

$$\theta \leftrightarrow \alpha .$$

In the following, we discuss how the cluster fluctuations influence the resolution in the coordinate measurement along the wire direction (x). This will be done using the probability distribution (7.3) and assuming that the *x* coordinate at the wire is the same as at the entrance of the wire region. Analogously, the same conclusions can be drawn with regard to the coordinate measurement in the drift direction, using the formal substitutions (7.10). Drift-path variations are introduced in Sect. 7.4.

7.2.3 Influence of the Cluster Fluctuations on the Resolution – the Effective Number of Electrons

Up to this point we have calculated the average and the variance of the position x of a single electron (see (7.4) and (7.5)). For the measurement of the coordinate we average over all electrons that are collected by the wire in a given time interval, defined by the readout electronics, and the variance of the coordinate measurement will be reduced. As it turns out, this reduction is not given by a single factor. This is because of the ionization clustering.

We measure the x coordinate averaging the arrival positions of N electrons:

$$X_{\rm AV} = \frac{x_1 + x_2 + \ldots + x_N}{N} \,. \tag{7.10}$$

The variance of X_{AV} depends on the characteristics of the ionization process because the electrons are produced in clusters and therefore the *x* are, in general, not independent.

Assume that the N electrons are grouped in M sets of n electrons, each set containing the electrons that were produced in the same cluster and after drift and

diffusion are collected by the wire:

$$\sum_{j=1}^{M} n_j = N \,. \tag{7.11}$$

In general not all the electrons produced in the same cluster are collected by the wire because of the random diffusion along the drift path.

The variance of X_{AV} is by definition

$$\sigma_{X_{\rm AV}}^2 = \left\langle X_{\rm AV}^2 \right\rangle - \left\langle X_{\rm AV} \right\rangle^2 \,, \tag{7.12}$$

where the average $\langle \rangle$ is taken over the probability distribution f_x :

$$\langle X_{\rm AV} \rangle = \frac{\sum \langle x_i \rangle}{N} = \int_{-b/2}^{b/2} dy \int_{-\infty}^{+\infty} x f_x(x, y) dx = x_0$$
(7.13)

and

$$\left\langle X_{\rm AV}^2 \right\rangle = \frac{1}{N^2} \sum_{ij} \langle x_i x_j \rangle . \tag{7.14}$$

The sum in the last equation contains three different kinds of terms; refer to Table 7.1 for a graphical representation. When i = j then $\langle x_i x_j \rangle = \langle x^2 \rangle$. There are *N* terms of this kind; they are marked by crosses in the table. When $i \neq j$ and the electrons do not belong to the same cluster, then $\langle x_i x_j \rangle = \langle x \rangle^2$, because two different ionization processes are not correlated. There are $N^2 - \sum n_j^2$ terms of this kind, they are represented by the dots in the rectangular boxes of the table. When $i \neq j$ and the electrons do belong to the same cluster (the dots in the square boxes), then x_i and x_j are correlated. We define the average $\langle x_i x_j \rangle = \langle xx \rangle$. There are $\sum n_j^2 - N$ terms of this kind.

Using (7.12-7.14) one finds that the variance is equal to

$$\sigma_{X_{\rm AV}}^2 = \frac{1}{N} (\langle x^2 \rangle - \langle xx \rangle) + \frac{\sum n_j^2}{N^2} (\langle xx \rangle - \langle x^2 \rangle) .$$
 (7.15)

C uster Electron	I	~ 1 ~ 1	2	3	4	2 5	6	3 7	M N
1	1	×	•	•	•	•	•	•	•
	2	•	×	٠	٠	•	•	•	•
	3	•	•	×	٠	•	٠	•	•
	4	•	•	•	x	•	•	•	•
2	5	·	•	•	٠	×	•	٠	•
	6	•	•	٠	•	•	×	•	•
3	7	•	•	٠	•	•	٠	x	•
:	:	•	•	٠	٠	•	•	•	×
м	N								

Table 7.1 Classification of the pairs of all electrons from a track that were collected on one wire

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In the absence of diffusion, $\langle xx \rangle$ is equal to $\langle x^2 \rangle$ and the first term of (7.15) is zero, so we obtain the result derived in Sect. 1.2, where the quantity $\sum n_j^2/N^2$ was defined as $1/N_{\text{eff}}$. If all the clusters consisted of one electron, the term $\sum n_j^2/N^2$ there became equal to 1/N and we obtained the standard formula of the variance of the mean. We may therefore distinguish the following limiting cases of (7.15):

we may therefore distinguish the following miniting cases of (

• Limit of no diffusion, using (7.5):

$$\sigma_{X_{\rm AV}}^2 \to \frac{1}{N_{\rm eff}} (\langle x^2 \rangle - \langle x \rangle^2) = \frac{1}{N_{\rm eff}} \frac{b^2}{12} \tan^2 \theta .$$
 (7.16)

• Limit of no clustering, using (7.5) and $\sigma_x = \sigma_y = \sigma$:

$$\sigma_{X_{\rm AV}}^2 \to \frac{1}{N} (\langle x^2 \rangle - \langle x \rangle^2) = \frac{1}{N} \left(\frac{\sigma^2}{\cos^2 \theta} + \frac{b^2}{12} \tan^2 \theta \right) .$$
(7.17)

• Limit $\theta = 0$, in the presence of clustering:

$$\sigma_{X_{\rm AV}}^2 \to \frac{\sigma}{N} \,. \tag{7.18}$$

In (7.16–7.18), N_{eff} is the effective number and N is the total number of electrons on the track segment delimited by the cell width; their values are θ -dependent through the length of the track segment.

An analytical expression of the covariance $\langle xx \rangle$ in (7.15) is derived under certain assumptions in the appendix to this chapter, resulting in formula (7.81) for $\sigma_{X_{AV}}^2$. This can be rewritten in the form

$$\sigma_{X_{\rm AV}}^2 \to \frac{1}{N'} \frac{\sigma^2}{\cos^2 \theta} + \frac{1}{N'_{\rm eff}} \frac{b^2}{12} \tan^2 \theta . \qquad (7.19)$$

where the quantities N' and N'_{eff} depend on θ as well as on σ and b.

Let us first deal with the term proportional to $(b^2/12) \tan^2 \theta$. We may regard N'_{eff} as the effective number of electrons that would cause the same fluctuation as the combined action of ionization plus diffusion, thus extending the original meaning of N_{eff} defined in Sect. 1.2 and used in (7.16).

The quantity N'_{eff} , for which an analytic expression is given in the appendix to this chapter, can also be calculated with a numerical simulation of the ionization and diffusion process. In order to compute it as a function of the diffusion parameter σ we evaluate the variance V_{AV} of the average of the coordinates along the track direction of those electrons that, after diffusion σ along the track direction, are contained in a track segment of length *l*. We write

$$\frac{1}{N'_{\rm eff}} \frac{1}{N_{\rm eff}(\sigma)} = \frac{l^2}{12} \frac{1}{V_{\rm AV}(\sigma)} \,. \tag{7.20}$$

Figure 7.3 shows how $N_{\rm eff}(\sigma)$ varies with diffusion. We have plotted on the vertical axis the quantity





where the ratio λ/l is equal to the average number of clusters on the track segment l (λ was defined in Sect. 1.1.1 as the mean distance between two clusters). Therefore $N_{\text{eff}}(\sigma)\lambda/l$ is the ratio of the effective number of electrons over the number of clusters in the track length l.

On the horizontal scale we have the diffusion expressed in units of the length of the track segment σ/l . This is suggested by (7.81) and is a very natural choice because the change of $N_{\text{eff}}(\sigma)$ is caused by electrons that have diffused so much that they cross over from one track segment to the neighbouring one, thus breaking the cluster correlation. It can therefore be expected that $N_{\text{eff}}(\sigma)$ goes up when σ exceeds some distance comparable to the length of the track segment, i.e. the distance between the wires. And this is in fact what we see.

The curves in Fig. 7.3 where computed using the argon cluster-size distribution of Fig. 1.7. At zero diffusion $N_{\rm eff}(0)$ is only $0.3(l = 0.4 \,{\rm cm})$ or 0.2 $(l = 1 \,{\rm cm})$ of the number of clusters. We know from Fig. 1.19 that this number must go down with increasing *l*. Now we switch on the diffusion, and before σ has reached half the length *l* of the segment, $N_{\rm eff}(\sigma)$ is as large as the number of clusters. For very large σ/l all the clustering is destroyed by the diffusion, and $N_{\rm eff}(\sigma)$ approaches the total number *N* of electrons. The increase of $N_{\rm eff}(\sigma)$ with σ/l was first observed in a TPC and termed *declustering through diffusion* [BLU 86].

We notice that the wire angular term in (7.19) can be written in the following way:

$$\frac{1}{N_{\rm eff}(\sigma)} \frac{(b\tan\theta)^2}{12} = \frac{1}{N_{\rm eff}(\sigma)} \frac{1}{12} \left(\frac{b}{\cos\theta}\right)^2 \sin^2\theta .$$
(7.21)

It represents the variance of the average of the position along the track direction of the electrons sampled by the wire, projected onto the wire direction. The first term is the variance of a flat distribution of width $b/\cos\theta$, which is the length of the track segment sampled by the wire. The factor $\sin^2\theta$ projects this variance onto the wire direction.

After this discussion of N'_{eff} as contained in the second term of (7.19), we deal now with the first term. The simple form into which we have cast the terms directly

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proportional to σ^2 (cf. (7.81)) hides the complications in the symbol *N'*. Although it is true that in the limiting cases of (7.17) and (7.18) *N'* is exactly equal to *N*, the total number of electrons on the track segment delimited by the cell width, *N'* changes as a function of θ , σ and *b* so as to make the variance $\sigma_{X_{AV}}^2$ larger. The physical cause of this is the rare larger clusters outside the cell that send some electrons via diffusion to the edge of the cell, and more so when θ is large. We have two reasons not to go into these details here. When we omit the primes in (7.19) the omissions amount to less than 25% in the quantity $\sigma_{X_{AV}}$ (except in extreme cases). The omitted parts, which pull measurements to one side in our cell, have a tendency to pull the corresponding measurement in the neighbouring cell to the opposite side. Therefore it is better to leave them out when combining several cells. The contributions of several wires are discussed in Sects. 7.3 and 7.4.

In conclusion we simplify (7.19) to read

$$\sigma_{X_{\rm AV}}^2 = \frac{1}{N} \frac{\sigma^2}{\cos^2 \theta} + \frac{1}{N_{\rm eff}} \frac{b^2}{12} \tan^2 \theta .$$
 (7.22)

It represents the square of the accuracy with which a track coordinate X_{AV} (7.10) can be measured along a single wire in the absence of a magnetic field.

7.3 Accuracy in the Measurement of the Coordinate in or near the Wire Direction

7.3.1 Inclusion of a Magnetic Field Perpendicular to the Wire Direction: the Wire E × B Effect

Drift chambers with precise measurements of the track coordinates along the wire direction are often operated with a magnetic field perpendicular to the direction of the wires. With this configuration one can obtain a precise determination of the curvature induced on the particle trajectory by the magnetic field, and the momentum of the particle can be determined (see Chap. 8 for details).

The presence of a magnetic field perpendicular to the wire direction modifies the angular wire term of the variance of the arrival position of the electrons (7.5). It becomes asymmetric and, on average, larger because the track segment is projected onto the wire in a more complicated way. The electrons that after their drift are collected in the cylindrical field of the wire have to move transverse to the magnetic field (Fig. 7.4). This produces an $E \times B$ force according to (2.6) and causes the electrons to drift under an effective angle ψ toward the wire. The angle ψ is such that tan $\psi = \omega \tau$, where ω is the cyclotron frequency and τ is the time between two electron collisions suitably averaged. Details have been treated in Sect. 2.1.

The arrival position x_w of an electron entering the region close to the wire with coordinates x and y is $x_w = x - y \tan \psi$; the variance of x_w on the frequency distribution (7.3) is





$$\langle x_{\rm w}^2 \rangle - \langle x_{\rm w} \rangle^2 = \frac{\sigma^2}{\cos^2 \theta} + \frac{b^2}{12} (\tan \theta - \tan \psi)^2 . \tag{7.23}$$

The electrons produced by a track at $\theta = 0$ are spread over a region $b \tan \psi$, and those of a track at an arbitrary angle are smeared over a distance $b(\tan \theta - \tan \psi)$. The width of the charge distribution on the wire has a minimum at $\theta = \psi$ and not at $\theta = 0$.

This effect was discovered with the TRIUMF-TPC [HAR 84] and is typically the most important limitation of the measuring accuracy in all TPC-like detectors using a gas with high values of $\omega\tau$. In the TRIUMF-TPC the angle ψ was 29°, and 32° in the ALEPH TPC in standard running conditions. The broadening of the avalanche width has been systematically studied in [BLU 86].

Using (7.23) we can rewrite (7.22) to include this effect:

$$\sigma_{X_{\rm AV}}^2 = \frac{1}{N} \frac{\sigma^2}{\cos^2 \theta} + \frac{1}{N_{\rm eff}} \frac{b^2}{12} (\tan \theta - \tan \psi)^2 . \qquad (7.24)$$

Equation (7.24) is the general expression for the accuracy $\sigma_{X_{AV}}$ with which a track segment can be measured on one wire along the wire direction. Summarizing our findings up to here, we see that this accuracy depends on the projected angle θ the track has with respect to the normal to the wire direction as well as on the angle ψ of the wire $E \times B$ effect. N_{eff} is roughly 6 for 1 cm of argon NTP and is more accurately obtained in Figs. 7.3 and 1.19. The diffusion term is characterized by the width σ of the single-electron diffusion transverse to the drift and the total number N of electrons, typically 100/cm in argon NTP.

The size and relative importance of the two terms in (7.24) depend on the electron drift length *L*, because σ^2 is proportional to *L* and N_{eff} depends on *L* through the declustering effect (Fig. 7.3). Also the angle θ has some influence on *N* and N_{eff} as the length of the track segment varies with θ . If one wants to be more specific, one has to take into account the details of a particular chamber.

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7.3.2 Case Study of the Explicit Dependence of the Resolution on L and θ

Writing (7.24) in the form

$$\sigma_{X_{\rm AV}}^2 = \frac{1}{n_0} \left(\frac{C^2 L}{b \cos \theta} + \frac{b}{12} \frac{(\tan \theta \tan \psi)^2 \cos \theta}{g(L)} \right)$$
(7.25)

we have introduced the L dependence of the diffusion and of $N_{\rm eff}$:

$$\sigma^2 = C^2 L \,, \tag{7.26}$$

$$N_{\rm eff} = Ng(L) , \qquad (7.27)$$

as well as the θ dependence of N:

$$N = n_0 b / \cos \theta \,. \tag{7.28}$$

Here n_0 is the number of collected electrons per unit track length. (We recall that g(L) is not a universal function but depends to some extent on N, b and θ .)

Figure 7.5a-c shows $\sigma_{X_{AV}}^2$ calculated as a function of *L* at $\theta = 0$ for $C^2 = 3.4 \times 10^{-3}$ mm, $\psi = 32^\circ$ (corresponding to a gas mixture of 80% argon and 20% methane in a field of 0.85 T), b = 4 mm, $n_0 = 8.1$ electrons/mm. We notice that the resolution goes through a shallow minimum at small *L* and is dominated by diffusion at large *L*.

Figure 7.6 shows $\sigma_{X_{AV}}^2$ as a function of the angle θ for two different values of *L* and for the same choice of the other parameters.





7.3.3 The General Situation – Contributions of Several Wires, and the Angular Pad Effect

The most general situation is the one where the coordinate direction along the pad row is inclined with respect to the wire direction, and several wires are located opposite the same cathode strips, as seen in Fig. 7.7. Apart from θ , the angle between the track and the wire normal, and ψ , the effective angle of approach caused by the wire $\mathbf{E} \times \mathbf{B}$ effect, we also have α , the angle between the normal to the direction of the pad row and the track; all angles are measured in the wire plane. The angles θ and α are the same when the pad row follows the wire direction.



Fig. 7.7 Scheme of a chamber with cathode-strip readout. The *bold lines* indicate the arrival positions of the electrons on the wire; the *dotted lines* indicate the direction of the drift velocity in the region close to the sense wires

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7.3 Accuracy in the Measurement of the Coordinate

The signals induced in a cathode strip are from k wires, where

k = pad length h/wire pitch b.

These signals are added in the measuring process. We want to compute the achievable accuracy. As the situation is quite complicated we wish to start with a simple case. The basic statistical relation will be derived for the special geometry given by $\alpha = 0$, $\theta = 0$; also we will assume $\sigma = 0$. Later on we will generalize our findings step by step.

The simplified geometry is sketched in Fig. 7.8. The ionization clusters along the track are redistributed onto the sense wires, where they occupy sections of length $b \tan \psi$. The situation is quite similar to the one in Sect. 1.2.6, where we treated the problem of charge localization along a track. The coordinate to be determined by the pads in one measurement is

$$X_{\text{AVP}} = \frac{\sum_{i=1}^{m_1} x_i n_i + \sum_{i=m_1+1}^{m_2} x_i n_i + \dots + \sum_{i=m_{k-1}+1}^{m_k} x_i n_i}{\left(\sum_{i=1}^{m_k} n_i\right)^2} , \qquad (7.29)$$

where each x_i is the position of a cluster with n_i electrons; there are m_1 clusters on the first, and $m_j - m_{j-1}$ on the *j*th sense wire (j = 1, ..., k). Averaging over the positions x_i – which are distributed between $-(b/2) \tan \psi$ and $+(b/2) \tan \psi$ – we find for the average and the variance

$$\langle X_{\rm AVP} \rangle = 0$$

and

$$\sigma_{\text{AVP}}^2 = \langle X_{\text{AVP}}^2 \rangle - \langle X_{\text{AVP}} \rangle^2$$
$$= \frac{b^2 \tan^2 \psi}{12} \frac{\sum_{i=1}^{m_k} n_i^2}{\left(\sum_{i=1}^{m_k} n_i\right)^2}$$
(7.30)

$$\sigma_{\rm AVP}^2 = \frac{b^2 \tan^2 \psi}{12} \frac{1}{N_{\rm eff}(h)} (\alpha = \theta = \sigma = 0) .$$



Fig. 7.8 Track and sense wires for (7.30)

Here we have denoted by $1/N_{\text{eff}}(h)$ the statistical factor which is equal to the sum of the squared cluster size divided by the square of the summed cluster sizes, taken over all the clusters on the piece of track that is delimited by the pad length *h*. Let us repeat (cf. Sect. 1.2.9 that the effective number N_{eff} is a measure of fluctuation which is smaller than the number of clusters because of the fluctuations of the cluster size. It is not proportional to *h*; for argon it scales according to Fig. 1.22. Comparing $N_{\text{eff}}(b)$, the corresponding number that belongs to a wire cell, we have for that case

$$N_{\rm eff}(h) \sim N_{\rm eff}(b)(h/b)^{0.54}$$

For this reason the achievable accuracy of pads does not improve with the square root but (for argon) more with the fourth root of the pad length.

In the next step we let θ and σ be different from zero, but keep $\sigma \ll b$ and $\alpha = 0$. The geometry is sketched in Fig. 7.9. The angle θ the track makes with the wire normal has two consequences: it changes the length on the wire occupied by charges, from *b* tan ψ to $b(\tan \psi - \tan \theta)$, and it introduces the projection factor $\cos \theta$ between this length and the coordinate direction. The diffusion, finally, contributes to the variance the same term as in (7.22) but with two changes. Firstly, the projection factor onto the coordinate direction is 1 in the present case. Secondly, *N* now represents the total number of electrons from the track segment delimited by *h*; we write N(h), which is of course proportional to *h*. The variance of X_{AVP} therefore assumes the form

$$\sigma_{X_{\text{AVP}}}^2 = \frac{\sigma^2}{N(h)} + \frac{1}{N_{\text{eff}}(h)} \frac{b^2}{12} (\tan \psi - \tan \theta)^2 \cos^2 \theta \,(\alpha = 0, \sigma \ll b). \tag{7.31}$$

Next we let α assume a non-zero value. This has the consequence that the two projection factors must be referred to the new coordinate direction, that is the diffusion term receives in its denominator the factor $\cos^2 \alpha$, and the projection factor of the angular term changes into $\cos^2(\theta - \alpha)$. The variance (7.31) of X_{AVP} receives another contribution, which describes the fluctuation of the position of the centre of



Fig. 7.9 Track and sense wires for (7.31)

charge along the track segment, because a non-zero angle α projects this fluctuation onto the coordinate direction. The size of this term is proportional to the squared length of the pad,

$$\frac{1}{N_{\rm eff}} \frac{(h \tan \alpha)^2}{12} \,. \tag{7.32}$$

This is the *angular pad effect*. We recognize the similarity with the corresponding angular wire term in (7.22); in (7.32) the fluctuation is controlled by the effective number of electrons on the track segment defined by the pad.

This contribution to the variance can be suppressed if the pulse height on the relevant wires is recorded, because one way of looking at this fluctuation is that it is caused by the differences in the charge deposited on the wires (see Fig. 7.10). It has been demonstrated in practice [AME 83, BAR 82], that the measured track position can be corrected using the wire pulse heights, leaving only a small residual error.

Finally we have to lift the restriction that σ^2 should be small compared to b^2 . In order for declustering to occur, the diffusion must reach the value of a length parameter which reorganizes the charges in such a way that the cluster correlation is broken, thus making N_{eff} larger. For the angular terms in (7.22) and (7.24) it was *b* that set the scale whereas in the angular pad term (7.32) it is *h* that sets the scale. (It is irrelevant on which wire the charge is collected – only new charges from outside the pad region improve the cluster statistics.)

Although the declustering effect often does not play a decisive role in practical drift chambers – because the diffusion is not large enough – we want to be specific in distinguishing the respective scales of the declustering.

For this purpose we denote by

$$N_{\rm eff}\left(h, \frac{\sigma}{b}\right)$$

the effective number of electrons on the track segment delimited by h and declustered by diffusion on the scale b. In this sense the variance of X_{AVP} takes the form

$$\sigma_{\rm AVP}^2 = \frac{1}{N(h)} \frac{\sigma^2}{\cos^2 \alpha} + \frac{b^2 (\tan \theta - \tan \psi)^2 \cos^2(\theta - \alpha)}{12N_{\rm eff} \left(h, \frac{\sigma}{b}\right)} + \frac{(h^2 - b^2) \tan^2 \alpha}{12N_{\rm eff} \left(h, \frac{\sigma}{h}\right)} .$$
(7.33)





This is the principal limit of the coordinate measuring accuracy using pads; θ, ψ , and α were defined in Fig. 7.7. In the usual case of no declustering, the values of N_{eff} for argon can be taken from Fig. 1.22.

7.3.4 Consequences of (7.33) for the Construction of TPCs

The relative size of the three terms in (7.33) depends, firstly, on the diffusion of the electrons during their drift. In the presence of a typical longitudinal magnetic field, the magnetic anisotropy of diffusion will make the first term the smallest one on average, for any practical choice of b and h.

In the usual case, a pad extends over several wires, and *h* is much larger than *b*; therefore the third term will dominate even for a small α . The most critical coordinate measurements are those for a determination of large track momenta on tracks with a small curvature. The pad rows should therefore be oriented at right angles to these critical tracks, so that, for them, $\alpha \approx 0$. For this reason, the ALEPH and the DELPHI TPCs have circular pad rows.

With the choice of *h* the designer of the TPC wants to take advantage of the fact that N(h) increases in proportion to *h* and $N_{\text{eff}}(h)$ approximately in proportion to \sqrt{h} . Also, the larger the collected amount of charge on a pad the less critical is the noise of the electronic amplifier. On the other hand the third term in (7.33) can be kept small only within a range of α which becomes smaller and smaller as *h* is increased. Even the modest magnetic bending of a high-momentum track may exceed this range if *h* is made too large. It can be shown that the consequence is a *constant* limiting relative-momentum-measuring accuracy $\delta p/p$ rather than one which decreases as *p* is reduced.

Problems of double-track resolution are discussed in Sect. 11.7.1

7.3.5 A Measurement of the Angular Variation of the Accuracy

The second term in (7.33) can be studied in detail by measuring σ_{AVP}^2 as a function of θ , keeping α fixed at 0. This has been done by Blum et al. [BLU 86] using a small TPC with rotatable wires in a beam of 50 GeV muons. Each track had its transverse position measured at four points using the pulse heights on the pads (see Fig. 7.11). The pad length *h* was 3 cm and the wire pitch *b* was 4 mm. The variance was determined for every track as one half the sum of the squared residuals of the straight-line fit. The result is σ_m^2 , the measured variance averaged over many tracks, as a function of the angle θ between the tracks and the normal to the wires. According to (7.33) σ_m^2 should vary as

$$\sigma_{\rm m}^2 = \sigma_0^2 + \frac{b^2}{12N_{\rm eff}\left(h,\frac{\sigma}{b}\right)} (\tan\theta - \tan\psi)^2 \cos^2\theta$$
$$= \sigma_0^2 + \frac{b^2}{12N_{\rm eff}\left(h,\frac{\sigma}{b}\right)} \frac{\sin^2(\theta - \psi)}{\cos^2\psi}, \tag{7.34}$$



Fig. 7.11 Layout of TPC with rotatable wires [BLU 86]

where σ_0^2 contains the effects of diffusion and, perhaps, of the electronics and any remaining contribution of the angular pad effect.

The results are depicted in Fig. 7.12a,b. The curves represent fits to (7.34) on adjusting the three free parameters ψ , σ_0 and $N_{\text{eff}}(h, \sigma/b)$. A reversal of the magnetic field changes the sign of ψ so that two curves are seen in Fig. 7.12a,ba. The values of the fitted parameters are shown in Table 7.2.

Keeping in mind that a magnetic field of 1.5 T reduces the transverse diffusion coefficient by a factor 50 (cf. Sect. 2.4.5) we expect for the mean square width of the diffusion cloud after 4 cm of drift a value of $1.6 \text{ mm}^2(B = 0)$ or $3.2 \times 10^{-2} \text{ mm}^2(B = 1.5 \text{ T})$. Since on a pad length of 3 cm the number of ionization



Fig. 7.12a,b The square of the measuring accuracy σ determined by [BLU 86] as a function of the track angle θ , (a) in a magnetic field of ± 1.5 T, (b) without magnetic field. The continuous lines were calculated using (7.34) with the fitted parameters of Table 7.2

$\overline{B(\mathrm{T})}$	$\sigma_0^2(\mathrm{mm}^2)$	$N_{\rm eff}\left(h, \frac{\sigma}{b}\right)$	$\psi(\text{deg})$
1.5 0	$\begin{array}{c} (1.08\pm0.03)10^{-2} \\ (1.58\pm0.06)10^{-2} \end{array}$	$\begin{array}{c} 27.8\pm0.6\\ 83\pm8 \end{array}$	$32.3 \pm 1.5 \\ -1 \pm 2$

Table 7.2 Parameters fitted to the measured accuracy σ_m^2 according to (7.34) for two values of the magnetic field (gas: Ar (90%) + CH₄ (10%))

electrons is approximately 300, the expected change in the uncertainty of the centre is 0.5×10^{-2} mm², equal to the measured difference in σ_0^2 appearing in Table 7.2.

The increase by a factor of three in the parameter N_{eff} , connected with the removal of the *B* field, is attributed to the declustering effect: as the width of the diffusion cloud increases it becomes comparable to *b*, more electrons from the same cluster arrive on different wires, and N_{eff} goes up. The increase does not occur when the tracks are produced by a laser ray rather than a particle.

The angle ψ of electron drift near the wire was 32° at 1.5 T in gas composed of argon (90%) and methane (10%). This value depends strongly on the gas and on the electric field near the sense wires. The wire and field configuration employed here is characteristic of TPCs and is described in the case studies in Sect 3.1.2. The tangent of ψ is found to be roughly proportional to *B*.

7.4 Accuracy in the Measurement of the Coordinate in the Drift Direction

In Sect. 7.2 we pointed out that there is a symmetry between the two situations symbolized in Figs. 7.1 and 7.2, the coordinate measurement along the wire and along the drift direction. The variances (7.5) and (7.9) of the single-electron coordinate are basically the same if one employs the substitution rule (7.10); this holds under the assumption that the time of arrival of the drifting electron at the entrance of the wire region is the same, up to a constant, as that recorded by the electronics.

We must now complement this argument by the observation that for most drift chambers this last approximation is too crude. Figure 7.2 shows that, owing to the shape of the velocity field lines in the wire region, even electrons produced by a track at $\alpha = 0$ have different paths before reaching the wire: electrons collected at the edge of the cell have to drift more than those collected in the middle.

The isochronous lines in the wire region have almost a parabolic shape and can be approximated by

$$z = z_0 - a \frac{y^2}{b},$$

where *a* is a dimensionless constant of the order of unity, which depends on the shape of the field lines in this region. In the example of Fig. 7.2, a = 0.8.

The arrival time t on the wire of a single electron entering the wire region at y at the time t is then

7.4 Accuracy in the Measurement of the Coordinate in the Drift Direction

$$t = t' + \frac{1}{u} \left(z_{\rm w} + a \frac{y^2}{b} \right) \,. \tag{7.35}$$

The average and variance of this last expression on the distribution (7.7) are

$$\langle t \rangle = \frac{1}{u} \left(z_0 + a \frac{b}{12} \right) \,, \tag{7.36}$$

$$\langle t^2 \rangle - \langle t \rangle^2 = \frac{1}{u^2} \left(\sigma_z^2 + \sigma_y^2 \tan^2 \alpha + \frac{b^2}{12} \tan^2 \alpha + \frac{a^2 b^2}{180} \right) ,$$
 (7.37)

where the last and new term is the contribution of the drift-path variations in the wire region.

7.4.1 Inclusion of a Magnetic Field Parallel to the Wire Direction: the Drift E × B Effect

Drift chambers with precise measurements of the track coordinates along the drift direction are often operated with a magnetic field perpendicular to the drift direction and parallel to the wires. With this configuration one can obtain a precise determination of the curvature induced on the particle trajectory by the magnetic field, and the momentum of the particle can be determined (see Chap. 8 for details).

If a magnetic field perpendicular to the drift electric field is present, the drifting electrons have to move transverse to it. This produces an $E \times B$ force according to (2.6) and causes the electrons to drift under an effective angle ψ with respect to the direction of the electric field. The angle ψ is such that $\tan \psi = \omega \tau$, where ω is the cyclotron frequency and τ is the time between two collision suitably averaged.

Electrons produced by a track at $\alpha = 0$ do not arrive simultaneously at the entrance to the wire region, but their arrival positions depend linearly on y with a slope tan ψ .

The variance of the arrival time of a single electron depends now on the angle ψ :

$$\langle t^2 \rangle - \langle t \rangle^2 = \frac{1}{u^2} \left(\sigma_z^2 + \sigma_y^2 \tan^2 \alpha + \frac{b^2}{12} (\tan \alpha - \tan \psi)^2 + \frac{a^2 b^2}{180} \right) ,$$
 (7.38)

where the diffusion parameter σ_z refers to the new drift direction, and σ_y to the direction perpendicular to it and to the magnetic field. The two parameters are not necessary equal, owing to the electric anisotropy of diffusion (cf. Sect. 2.2.5), but for simplicity we will replace them below by a common value.

Up to now we have dealt with the drift-time variations of a single electron. When a measurement is performed, the whole swarm arrives. There are various ways to extract the time information. In terms of electronics, one may either employ discriminators of various types in order to trigger on the first electrons, or on the centroid of the pulse or on some other value based on a threshold-crossing time. Or one may apply a very fast sampling technique in order to obtain a numerical representation of

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the pulse shape, which may be used to derive a suitable estimator. We discuss here two estimators of the arrival time of the swarm: the average and the *M*th electron, assuming for simplicity $\psi = 0$.

7.4.2 Average Arrival Time of Many Electrons

When we average over the arrival times of all the electrons, the statistical reduction of the different terms of (7.38) is not the same because of the correlation between electrons produced in the same cluster. Following the lines of Sect. 7.2 we can write the variance of the average arrival time as

$$\sigma_{\text{TAV}}^2 = \frac{1}{u^2} \left[\frac{1}{N} \frac{\sigma^2}{\cos^2 \alpha} + \frac{1}{N_{\text{eff}}} \left(\frac{b^2}{12} \tan^2 \alpha + \frac{a^2 b^2}{180} \right) \right], \quad (7.39)$$

where N represents the total ionization collected by the wire, and N_{eff} is the effective number of independent electrons.

The contribution of the drift-path variation of the variance of the average is always present, even for tracks in good geometry ($\alpha = 0$) and close to the wire ($\sigma \approx 0$). It is quite large and increases with *b* more than linearly, since N_{eff} increases with the track length more slowly than in proportion.

Obviously the average over all arrival times fluctuates so badly because of the late-arriving electrons, those that have to take the longest path when they approach the wire. If one derives the time signal from the few electrons that arrive first, the latecomers do not contribute. In fact, a discriminator with a low threshold will do this automatically.

7.4.3 Arrival Time of the Mth Electron

Let the time signal be defined by the moment that the Mth electron arrives. Here M can either be a fixed number (this is the case when a fixed-threshold discriminator is used) or a given fraction of the total number of electrons contributing (this is the case of a constant-fraction discriminator).

The probability p(t) of one electron arriving before the time *t* is calculable using (7.7) and (7.35):

$$p(t) = \frac{\int_{-\infty}^{t} f(\tau) \mathrm{d}\tau}{\int_{-\infty}^{+\infty} f(\tau) \mathrm{d}\tau},$$
(7.40)

where

$$f(\tau)d\tau = \int_{-b/2}^{+b/2} dy f_z(\tau - (z_w + ay^2/b)/u, y)d\tau .$$
 (7.41)

Next we have to write out the probability R(t) that the *M*th electron out of a group of *N* arrives in the interval dt. It is equal to the probability that any one of
7.4 Accuracy in the Measurement of the Coordinate in the Drift Direction

the *N* electrons arrives precisely in dt (equal to *N* (dp/dt) or *N* dp) multiplied by the probability that any of (M - 1) out of the (N - 1) remaining ones arrives before *t* and the rest after t + dt:

$$R(t)dt = N {\binom{N-1}{M-1}} p^{M-1} (1-p)^{N-M} \frac{dp}{dt} dt$$

= $M {\binom{N}{M}} p^{M-1} (1-p)^{N-M} dp = P(p) dp.$ (7.42)

In the last expression we have defined a probability density P(p) for the variable p. It is easy to show that

$$\int_{-\infty}^{+\infty} R(t) \mathrm{d}t = \int_{0}^{1} P(p) \mathrm{d}p = 1 \; .$$

Here and in the following steps we make use of the well-known expression for the definite integral

$$\int_{0}^{1} x^{k} (1-x)^{j} \mathrm{d}x = \frac{j!k!}{(j+k+1)!} \, .$$

The variance of the arrival time of the *M*th electron is given by

$$\sigma_{\mathrm TM}^2 = \langle t^2 \rangle - \langle t \rangle^2 \; ,$$

with

$$\langle t^2 \rangle = \int_{-\infty}^{+\infty} t^2 R(t) dt = \int_{0}^{1} t^2(p) P(p) dp$$

and

$$\langle t \rangle = \int_{-\infty}^{+\infty} t R(t) dt = \int_{0}^{1} t(p) P(p) dp .$$
 (7.43)

The function t(p) is obtained by inverting (7.40).

We consider now separately the two contributions of the difference of the drift paths and of the diffusion and study the particular case of a track perpendicular to the drift velocity direction ($\alpha = 0$).

7.4.4 Variance of the Arrival Time of the Mth Electron: Contribution of the Drift-Path Variations

In order to study the effect of the drift-path variation alone we go to the limit $\sigma_y \rightarrow 0, \sigma_t \rightarrow 0$ of (7.41) at $\alpha = 0$, and obtain

7 Coordinate Measurement and Fundamental Limits of Accuracy

$$f(t)dt = \frac{u}{R} \frac{1}{\sqrt{\frac{a}{b}(tu - z_0)}} dt, \quad 0 \le (tu - z_0) \le \frac{ab}{4}$$
(7.44)

and f(t) = 0 outside of this time interval. Using this expression we can evaluate p(t) from (7.40) and invert it:

$$t(p) = \frac{1}{u} \left(\frac{ab}{4}p^2 + z_0\right) .$$
 (7.45)

Now we compute the integrals (7.43) and use this expression for t(p):

$$\sigma_{\rm TPM}^2 = \left(\frac{ab}{4u}\right)^2 \frac{M(M+1)}{(N+1)(N+2)} \left(\frac{(M+2)(M+3)}{(N+3)(N+4)} - \frac{M(M+1)}{(N+1)(N+2)}\right) .$$
(7.46)

This is the variance in the arrival time of the Mth electron among N independent ones when only the drift-path variation is taken into account.

If we want to apply this formula to a practical case we have to use for N the number of clusters, and we realize that because of the cluster-size fluctuations it describes correctly only the case M = 1, since the threshold can only be set at a certain number of electrons and not of clusters.

In order to take into account the cluster-size fluctuations we have to use a Monte Carlo program. Figure 7.13a,b shows the result of a simulation of the distribution of the arrival times, assuming the conditions valid for 1 cm of argon gas at NTP (and 27 clusters/cm). In both parts of the figure the r.m.s. of the arrival time is normalized to the width of the collection time interval:

$$\Delta T = ab/4u$$



Fig. 7.13a,b R.m.s. variation of the arrival time of the *M*th electron in 1 cm of argon, caused by differences in drift-path length, (**a**) as a function of M, (**b**) when M is a fixed fraction of the total number of electrons *N*. The r.m.s. of the average time is also shown. (See text for explanations.)

Also visible is the r.m.s. of the average (7.39), evaluated for $\alpha = 0$, $\sigma = 0$, $N_{\text{eff}} = 6$ and normalized to the same quantity. We observe that the limit of the accuracy due to the drift-path variation can be made very small by lowering the threshold. For example, σ_{TM} comes down to 30% of σ_{TAV} when triggering on a value of *M* equal to 5% of *N*. But by gaining on the drift-path variations, one loses on the diffusion term.

7.4.5 Variance of the Arrival Time of the Mth Electron: Contribution of the Diffusion

Next we study the contribution of diffusion. The probability density f(t) of (7.41) with a = 0 and $\alpha = 0$ takes the form

$$f(t)dt = \frac{b}{R} \frac{\exp\left(-\frac{\left(t - \frac{z_0}{u}\right)^2}{2\sigma_t^2}\right)}{\sqrt{2\pi}\sigma_t} dt , \qquad (7.47)$$

and the function p(t) of (7.40) is the function E:

$$p(t) = E\left(\frac{t - z_0/u}{\sigma_t}\right) = \int_{-\infty}^{\frac{t - z_0/u}{\sigma_t}} \mathrm{d}q \frac{\exp(-q^2/2)}{\sqrt{2\pi}} \,. \tag{7.48}$$

To compute the variance of the arrival time of the *M*th electron we should solve the integrals (7.43) using the function t(p) defined by the inverse of (7.40).

Since we cannot invert the expression (7.48) analytically, we linearize it in the vicinity of the average value of the function P(p) of (7.42). This procedure is justified by the fact that the variance of the function P(p) is small when M is small and N large. It is illustrated in Fig. 7.14. The variance of the arrival time is the variance of p on the probability distribution P(p) projected onto the t axis using the derivative

$$\frac{\mathrm{d}t}{\mathrm{d}p} = \sigma_t \frac{\mathrm{d}q}{\mathrm{d}E(q)} = \sigma_t \sqrt{2\pi} \exp\left(+\frac{\langle q \rangle^2}{2}\right) \,,$$

evaluated at $\langle q \rangle$ defined by $\langle p \rangle = E(\langle q \rangle)$.

The variance of *p* is given by

$$\langle p^2 \rangle = \int_0^1 p^2 P(p) \mathrm{d}p = \frac{M}{N+1}$$

and

$$\langle p^2 \rangle = \int_0^1 p^2 P(p) \mathrm{d}p = \frac{M(M+1)}{(N+1)(N+2)}$$



from which we obtain

$$\langle p^2 \rangle - \langle p \rangle^2 = \frac{M}{(N+1)(N+2)} \left(1 - \frac{M}{N+1} \right) \approx \frac{M}{N^2} \left(1 - \frac{M}{N} \right) . \tag{7.49}$$

Projecting now this variance onto the time axis (see Fig. 7.14) we obtain

$$\sigma_{\text{TD}M}^2 \approx \frac{\sigma_t^2}{N} 2\pi \exp(\langle q \rangle^2) \frac{M}{N} \left(1 - \frac{M}{N} \right) \,, \tag{7.50}$$

where $\langle q \rangle$ is the normalized average arrival time, given by the condition that the corresponding integral probability *p* takes on the value M/(N+1), or in good approximation, M/N. In other words, $\langle q \rangle$ is given by the inverse of the function *E* at its argument M/N:

$$\langle q \rangle = E^{-1}(M/N) .$$
 (7.51)

Expression (7.50) with (7.51) represents the answer to the question how much the arrival time of the *M*th electron fluctuates when each single electron has a Gaussian distribution with a width σ_t ; σ_{TDM} goes down with the total number *N* of electrons and is equal to σ_t/\sqrt{N} times a factor which depends only on M/N. The factor describes the loss of accuracy when the arrival-time measurement is based on the *M*th electron rather than on the average of all *N*. (The variance σ_{TAV}^2 of the average arrival time caused by diffusion alone was σ_t^2/N as implied by (7.39).) The loss factor is plotted in Fig. 7.15 and is seen to be always larger than 1. For example the loss is a factor 2 if one triggers on the first 5% of the swarm.

An often-quoted formula according to which

$$\sigma_{\text{TDM}} = \frac{\sigma_t}{\sqrt{2\log N}} \sum_{r=M}^{\infty} \frac{1}{r^2}$$
(7.52)



instead of (7.50) has been discussed by Cramer [CRA 51]. The right-hand side of (7.52) is the first term of a power series in $1/\log N$. It turns out that for M = 1 (7.52) is more accurate than (7.50), but it cannot reproduce the variation of σ_{TDM} with M.

We conclude this section with a comment on the various ways to estimate the time of arrival of the electron swarm. It is clear from the previous pages that this is a question of the relative importance of the two main contributions to the measurement accuracy. Where the drift-path variations are relatively large, one gains a lot by triggering on a low threshold. Where the diffusion is relatively large, one gains, but not so much, by using the average. The contribution from the angular effect and from the effect of the drift-path variations quickly increase as the angle α increases. Since the diffusion increases with the drift length, the relative importance of the two contributions changes through their dependence on σ_t and N_{eff} , and the best estimator is a function of the drift length. Depending on how far one wants to go in the optimization, the fast sampling technique offers the greatest freedom.

7.5 Accuracy Limitation Owing to Wire Vibrations

Up to this point we have had two phenomena which, in functioning together, produce fundamental limitations on the accuracy of coordinate measurement: diffusion and ionization fluctuation. As we have seen in this chapter, these limitations are fundamental in the sense that they are inherent in the measuring process and cannot be overcome by removing technical imperfections.

After the appearance of the first edition of this book, a new phenomenon was described which also limits the accuracy of coordinate measurement in a fundamental way: wire vibrations caused by the avalanches on the sense wire [BOY 95]. Every avalanche exerts a repulsive force onto the wire as long as the positive ions are on their way to the cathode. Upon their arrival at the cathode they have conveyed a tiny bit of momentum to the wire. In an environment of heavy background radiation



Fig. 7.16 Schematic view of the experimental setup of [BOY 95]

thousands of these tiny bits of momentum can displace the wire and make it vibrate. The measurement accuracy is limited to the extent that the wire position is unknown.

Boyko et al. [BOY 95] used a long drift tube and observed wire vibrations through a window with a microscope (see Fig. 7.16). A radioactive source could be brought close to the tube to produce counts of the frequency and pulseheight that were registered. Wire vibration amplitudes up to $30 \,\mu$ m were observed at count rates up to $4.5 \,\text{kHz}$.

7.5.1 Linear Harmonic Oscillator Driven by Random Pulses

Before we treat the motion of the wire we look at the simpler case of the linear harmonic oscillator under the influence of a driving force consisting of an irregular (random) sequence of short impact pulses (see Fig. 7.17).

The equation of motion for the one-dimensional damped harmonic oscillator that is excited by a force of very short duration at time t_1 is

$$m\frac{d^2x(t)}{dt^2} + \Gamma\frac{dx(t)}{dt} + kx(t) = f(t) \qquad f(t) = f_1\delta(t - t_1), \tag{7.53}$$

where f_1 characterizes the size of the short impact and has the dimension of momentum. The solution of this equation is

$$x(t) = \frac{f_1}{\omega m} e^{-\frac{\Gamma}{2m}(t-t_1)} \sin \omega(t-t_1) \qquad \omega = \sqrt{\frac{k}{m} \left(1 - \frac{\Gamma^2}{4km}\right)}.$$
 (7.54)

In the case of several consecutive forces at times t_n and with amplitudes f_n , $f(t) = \sum f_n \delta(t - t_n)$, the solution takes the form

Fig. 7.17 Harmonic oscillator, characterized by spring constant *k*, damping constant Γ , and mass *m*, driven by a random sequence of short impact pulses



7.5 Accuracy Limitation Owing to Wire Vibrations

$$x(t) = \sum_{n} \frac{f_n}{\omega m} e^{-\frac{\Gamma}{2m}(t-t_n)} \sin \omega (t-t_n).$$
(7.55)

For such a superposition of pulses of equal shape with amplitudes f_n from a probability distribution P(f), separated by random time intervals with an average frequency v, Campbell's theorem [CAM 09][RIC 44] applies. This theorem tells us that the average \bar{x} and the variance σ_x^2 of x(t) are given by

$$\bar{x} = v\bar{f} \int_0^\infty \left(\frac{1}{\omega m} e^{-\frac{\Gamma}{2m}t} \sin \omega t\right) dt = \frac{v\bar{f}}{k}$$
(7.56)

$$\sigma_x^2 = v \overline{f^2} \int_0^\infty \left(\frac{1}{\omega m} e^{-\frac{\Gamma}{2m}t} \sin \omega t \right)^2 dt = \frac{v f^2}{2\Gamma k},$$
(7.57)

where $\overline{f} = \int fP(f)df$ and $\overline{f^2} = \int f^2 P(f)df$. In a case in which all pulses have the same amplitude f_0 , we have $P(f) = \delta(f - f_0)$ and thus $\overline{f} = f_0$ and $\overline{f^2} = f_0^2$. The r.m.s. of the amplitude then becomes

$$\sigma_x = f_0 \sqrt{\frac{\nu}{2\Gamma k}}.$$
(7.58)

We see that the fluctuation of the position increases with the rate v but decreases for increased damping Γ and spring constant k. The fact that σ_x is independent of mis due to a balance of primary excitation and damping. For larger m, a single pulse f_n produces a smaller amplitude, a smaller damping factor $\Gamma/2m$, and a decreased frequency ω , but increases the duration of the influence of f_n .

7.5.2 Wire Excited by Avalanche Ions

The avalanche ions moving from the wire surface to the tube wall exert a force on the wire. Since the electric field in the tube at radius *R* is given by $E(r) = V/(r \ln R/a)$, the resulting force on the wire by a charge *q* at position *r* is given by F(r) = qE(r). The movement of the ions from the wire surface to the tube wall with the velocity $v(r) = \mu E(r)$ transfers the total momentum of

$$p = \int F(t)dt = \int_0^R F(r)\frac{dt}{dr}dr = \int_0^R \frac{F(r)}{v(r)}dr = \frac{qR}{\mu}$$
(7.59)

to the wire. Since the maximum drift time of the ions is typically much shorter than any time associated with the mechanical movement of the wire (i.e., the period of the first harmonic), one can assume the action of the repulsive force to be $f = qR/\mu \,\delta(t)$.

The equation determining the wire displacement y(x,t) in a cylindrical drift tube of radius *R* and wire radius *a* in the presence of an external force density f(x,t) is given by

7 Coordinate Measurement and Fundamental Limits of Accuracy

$$\rho \frac{\partial^2 y}{\partial t^2} + \gamma_0 \frac{\partial y}{\partial t} - T \frac{\partial^2 y}{\partial x^2} - \kappa y = -g\rho + f(x,t), \qquad (7.60)$$

where ρ is the linear wire density, γ_0 the friction coefficient and *T* the wire tension. The term $\kappa = 2\pi\varepsilon_0 V^2/(R\ln R/a)^2$ represents the electrostatic force, *V* is the wire voltage and $g\rho$ the gravitational force. The expression f(x,t) due to the avalanches of charge q_n at time t_n , position x_n and angular position ϕ_n is

$$f(x,t) = \frac{R}{\mu} \sum_{n} q_n \cos \phi_n \,\delta(t-t_n) \delta(x-x_n). \tag{7.61}$$

The solution of Eq. (7.60) and the statistical analysis can be performed in analogy to the simple example from the previous section. The solution obviously depends on the way the excitations are distributed in the azimuthal direction and along the wire, and whether the avalanches are created from a point source or from tracks. Boyko et al. have shown that these different conditions can be collected into *one* dimensionless constant. They find the resulting variance of the position of the wire, averaged over the wire length, to be given by

$$\sigma_y = \frac{\overline{q}R}{\mu} \sqrt{\frac{\nu}{12T\gamma_0}} \sqrt{KK_1K_2}, \qquad (7.62)$$

where \overline{q} is the average total charge per event, v is the total particle rate on the tube, and K, K_1, K_2 are dimensionless geometry factors which together make up one constant. This solution assumes that the avalanche ions return to the tube wall along the trajectories of the primary ionization electrons. For point ionization we have K = 1 and $K_1 = 0.5$. For particle tracks through the tube we have K = 0.416 and $K_1 = 0.5-1$ depending on the angular distribution of the tracks. K_2 is another geometry factor being ≈ 1 for uniform illumination along the tube.

Figure 7.18 shows results of a calculation assuming a drift tube of R = 1 cm, mobility $\mu = 1.7 \text{ cm}^2/\text{Vs}$ and a damping factor $\gamma_0 = 7 \times 10^{-5} \text{ kg/sm}$. The wire

Fig. 7.18 Wire vibration amplitudes calculated by [BOY 95] for a practical case (see text). The uncertainty of the wire position is shown as a function of the count rate. The three bands belong to the three different avalanche sizes indicated; in each band the upper edge is valid for a wire tension of 50 g and the lower for one of 500 g



tension is varied from 50 to 500 g. The diagram makes it clear that wire vibrations can be a decisive factor for detectors operating in limited streamer mode (charges of 10-100 pC) at fluxes >10⁵ particles/s. In proportional mode (charges around 1 pC) the vibration makes a significant contribution (>10µm) only in the case of lower ion mobility (larger pressure), lower wire tension, smaller wire damping, and rates beyond 1 MHz.

7.6 Accuracy Limitation Owing to Space Charge Fluctuations

There are situations in which the drift time measurement becomes inaccurate owing to fluctuations in the drift field. As an example we discuss the ATLAS MDT drift tubes [ATL 97]. It is expected that their momentum measuring accuracy will be reduced when the photon background rate goes beyond the design level. In the tubes, the background γ -radiation will produce a space charge whose density depends on the counting rate, the ion charge per count, the ion drift velocity, and the tube diameter. The space charge density is homogeneous – which produces a field (increasing linearly from the wire to the tube wall) in addition to the main field (proportional to 1/r). This was explained in Sect. 4.5.3 in the context of the reduction of amplification. Using the method outlined there, we can estimate that at a background count rate of 1.4 kHz per cm of wire length (roughly five times the design value), the drift field is distorted to an extent that an apparent shift of track positions of the order of a millimetre takes place in part of the drift space.

This effect can in principle be corrected by carefully monitoring the history of the previous few milliseconds (the ion travel time to the tube wall). If the tube works perfectly, and if the charge associated with each previous pulse is known, it might be possible to assess the total ion charge present in the tube at the moment of recording the track in question. Then the drift field distortion may be calculated and the track position corrected.

However, this procedure is limited by the inhomogeneity of the charge density along the tube. Even if there is some knowledge about the average density of counts along the tube, there is the statistical fluctuation in the immediate vicinity of the recorded track. Before we report a measurement quantifying this effect, let us estimate what we can expect. At the flux rate of 1400 Hz/cm the charge that will contribute to the disturbing field is the one produced in roughly 3 cm of tube length (approximately the tube diameter) in 5 ms (the ion travel time to the wall); this corresponds to $1400 \text{ Hz/cm} \times 5 \text{ ms} \times 3 \text{ cm} = 21$ avalanches on average. As these are occurring at random we expect a fluctuation of $1/\sqrt{21}$ or 0.22 of the total shift. Thus if the total shift goes up to the order of 1 mm it will fluctuate on the order of 0.2 mm.

In an experiment using a strong radioactive γ -source the ATLAS muon team [ATL 00] irradiated the tubes in the drift chambers, creating background conditions five times as severe as expected for the most heavily irradiated parts of the



spectrometer. The coordinates of high-energy muon tracks were measured at right angles to the wires, and the resolution was determined. The result of the experiment is shown in Fig. 7.19. The resolution deteriorates enormously in the outer region of the tube owing to the presence of the background, and assumes values up to $140 \,\mu$ m. A detailed simulation along the ideas outlined above was carried out and compared to the measurements. The curves in Fig. 7.19 match the data and show that the effect is understood.

Finally, let us be aware that it is the problem of ageing to which one owes this critical dependence of measuring accuracy on background. Had not the hydrocarbons been outlawed one could find gas mixtures with a much reduced dependence of the drift velocity on the electric field (cf. the remarks at the end of Sect. 12.6.4).

Appendix to Chapter 7. Influence of Cluster Fluctuations on the Measurement Accuracy of a Single Wire

An analytical form of Eq. (7.15) can be derived under certain assumptions as follows. The symbols used here were defined in Sect. 7.2.

We consider the N_c clusters produced along the track segment *R*. N_c^i represents the clusters of cluster size *i*, where $N_c^i = N_c P(i)$ and P(i) is the cluster-size distribution defined in Sect. 1.2.2 [Eq. (1.34)].

The N_c^i clusters produce a total of iN_c^i electrons and on average m_i of them,

$$m_i = iN_c P(i) \frac{b}{R\cos\theta} = iN_c^i \frac{b}{R\cos\theta} , \qquad (7.63)$$

are collected by the wire. The total number N of electrons collected by the wire is

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$$N=\sum_i m_i,$$

where the sum on *i* is performed on the cluster size *i*.

As we showed in Sect. 7.2.3, N does not depend on diffusion, and we assume in the following that neither does each m_i .

Defining \bar{x}_i to be the average position of the m_i electrons collected by the wire and produced in clusters of original cluster size *i*, the quantity X_{AV} defined by (7.10) can be rewritten as

$$X_{\rm AV} = \frac{\sum m_i \bar{x}_i}{\sum m_i} = \frac{\sum m_i \bar{x}_i}{N} . \tag{7.64}$$

Its variance is given simply by

$$\sigma_{X_{\text{AV}}}^2 = \text{Var}(X_{\text{AV}}) = \frac{\sum m_i^2 \text{Var}(\bar{x}_i)}{N^2} , \qquad (7.65)$$

since the various \bar{x}_i are not correlated because they are by definition averages of arrival positions of electrons produced in different clusters.

The variance of \bar{x}_i , Var (\bar{x}_i) , depends on the distribution of the number k(k = 0, ..., i) of collected electrons when *i* are produced in the same cluster. Referring to Eqs. (7.1) and (7.3) and assuming for simplicity $x_0 = 0$, we find that the probability that *k* electrons among *i* are collected is given by

$$\frac{1}{R} \int_{-R/2}^{+R/2} ds \left[\int_{-\infty}^{+\infty} dx G(x|s\sin\theta,\sigma_x) \right]^i \left[\int_{-b/2}^{+b/2} dy G(y|s\cos\theta,\sigma_y) \right]^k \\ \times \left[1 - \int_{-b/2}^{+b/2} dy G(y|s\cos\theta,\sigma_y) \right]^{i-k} \binom{i}{k}, \qquad (7.66)$$

where the term $\binom{i}{k}$ takes into account the different combinations of *k* electrons among *i*.

Since we have assumed that $x_0 = 0$, we also have that

$$\langle x \rangle = \langle \bar{x}_i \rangle = \langle X_{\rm AV} \rangle = 0.$$
 (7.67)

The integrals in dx of (7.66) are equal to 1. Defining

$$\Delta(s\cos\theta) = \int_{-b/2}^{+b/2} dy G(y|s\cos\theta, \sigma_y)$$
(7.68)

as the probability that one electron is collected by the wire $(0 < \Delta < 1)$, we rewrite the probability that *k* among *i* electrons produced in the same cluster are collected by the wire as

$$\Pi_{k}^{i} = \frac{1}{R} \int_{-R/2}^{+R/2} \Delta^{k} (1-\Delta)^{i-k} \binom{i}{k} \, \mathrm{d}s \,. \tag{7.69}$$

We note that

$$\sum_{k=0} i\Pi_k^i = 1 \; .$$

If along the track segment *R* we produce N_c^i clusters of *i* electrons, on the wire we collect on average

- $N_{\rm c}^i \Pi_1^i$ single electrons
- $N_{\rm c}^i \Pi_2^i$ pairs of electrons
- $N_{\rm c}^i \Pi_3^{\overline{i}}$ triplets of electrons
- ..
- $N_{\rm c}^{i}\Pi_{\rm i}^{i}$ *i*th of electrons

and in total we have

$$N_{\rm c}^i \sum_{k=0}^l k \Pi_K^i = m_i$$

electrons. This last equality can be proved using (7.69) and (7.68) and the properties of the binomial distribution.

The number N_{pairs}^i of different *pairs* of electrons produced in the same cluster of cluster size *i* and collected by the wire is given by

$$N_{\text{pairs}}^{i} = N_{c}^{i} \sum_{k=2}^{i} {\binom{k}{2}} \Pi_{k}^{i} = \frac{N_{c}^{i}}{2} \left(\sum_{k=0}^{i} k^{2} \Pi_{k}^{i} - \sum_{k=0}^{i} k \Pi_{k}^{i} \right)$$
$$= \frac{N_{c}^{i}}{2} \sum_{k=0}^{i} k^{2} \Pi_{k}^{i} - \frac{m_{i}}{2} .$$
(7.70)

We are now in a position to compute the variance Var (\bar{x}_i) of the average position \bar{x}_i of the m_i electrons produced by clusters of cluster size *i* and collected by the wire: we have m_i variance terms $\langle x^2 \rangle$ and $2 \times N_{\text{pairs}}^i$ covariance terms $\langle xx \rangle$. The average $\langle \bar{x}_i \rangle$ is zero because we have assumed that $x_0 = 0$ in (7.66) [see also (7.67)]. We obtain

$$\operatorname{Var}(\bar{x}_{i}) = \frac{m_{i} \langle x^{2} \rangle + N_{\text{pairs}}^{i} \langle xx \rangle}{m_{i}^{2}}$$
$$= \frac{m_{i} \langle x^{2} \rangle + \left(N_{c}^{i} \sum_{k=0}^{i} k^{2} \Pi_{k}^{i} - m_{i}\right) \langle xx \rangle}{m_{i}^{2}}$$
$$= \frac{1}{m_{i}} \left[\left(\langle x^{2} \rangle - \langle xx \rangle\right) + \frac{\sum_{k=0}^{i} k^{2} \Pi_{k}^{i}}{\sum_{k=0}^{i} k \Pi_{k}^{i}} \langle xx \rangle \right].$$
(7.71)

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Using (7.69) and the properties of the binomial distribution, one can show that

$$\sum_{k=0}^{i} k^{2} \Pi_{k}^{i} = \frac{i^{2} - i}{R} \int_{-R/2}^{+R/2} \Delta^{2} ds + \frac{i}{R} \int_{-R/2}^{+R/2} \Delta ds + \frac{i}{R} \int_{-R/2}^{$$

From these equations we obtain

$$\frac{\sum_{k=0}^{i} k^2 \Pi_k^i}{\sum_{k=0}^{i} k \Pi_k^i} = 1 + (i-1)I_2 \,,$$

where

$$I_{2} = \frac{\int \Delta^{2} ds}{\int \Delta^{2} ds}, \qquad (7.72)$$
$$\int \Delta ds$$
$$-R/2$$

and we can rewrite (7.71) as

$$\operatorname{Var}(\bar{x}_i) = \frac{1}{m_i} (\langle x^2 \rangle - I_2 \langle xx \rangle + iI_2 \langle xx \rangle) .$$
(7.73)

Finally we substitute the variance $Var(\bar{x}_i)$ from this last equation into (7.65) and set

$$\operatorname{Var}(X_{\mathrm{AV}}) = \frac{\sum m_i(\langle x^2 \rangle - I_2 \langle xx \rangle + iI_2 \langle xx \rangle)}{N^2}$$
$$= \frac{\langle x^2 \rangle - I_2 \langle xx \rangle}{N} + \frac{\sum im_i}{N^2} I_2 \langle xx \rangle .$$
(7.74)

Using (7.63) we can show that

$$\frac{\sum_{i} im_{i}}{N^{2}} = \frac{\sum_{i} i^{2} N_{c} P(i) [b/(R \cos \theta)]}{N^{2}} = \frac{\sum_{i} i^{2} N_{c} P(i) [b/(R \cos \theta)]}{(\sum_{i} i N_{c} P(i) [b/(R \cos \theta)])^{2}}$$
$$= \frac{\sum_{j} n_{j}^{2}}{(\sum_{j} n_{j})^{2}} \frac{1}{b/(R \cos \theta)}$$
$$= \frac{1}{N_{\text{eff}}}, \qquad (7.75)$$

where the sum over *i* is performed on the cluster size *i*, while the sum over *j* is performed on the N_c clusters produced by the particle in the track segment *R* and n_j is the number of electrons in the cluster *j*.

 N_{eff} was defined in Sect. 1.2.5 as the effective number of electrons computed along the track segment *R*; here it is scaled by the normalization factor $b/R\cos\theta$ derived in (7.2). In Sect. 1.2.5 we showed that N_{eff} does not scale linearly with the length of track sampled, while (7.75) implies a linear dependence of N_{eff} on *R*. This is an implicit consequence of the assumption that the m_i are constant, since we do not take into account the effect of the rare and large clusters present in the tails of the cluster-size distribution, and this effect is a limitation of our derivation. We comment on this point at the end of this appendix.

The quantity I_2 defined in (7.72) can be computed using (7.68):

$$I_2 = \operatorname{Erf}\left(\frac{b}{2\sigma_y}\right) - \frac{1}{\sqrt{\pi}} \frac{2\sigma_y}{b} \left[1 - \exp\left(-\frac{b^2}{4\sigma_y^2}\right)\right], \qquad (7.76)$$

where Erf is the error function [ABR 64],

$$\operatorname{Erf}(z) = \frac{2}{\sqrt{\pi}} \int_{0}^{z} \exp(-t^{2}) \mathrm{d}t$$

In the limit $\sigma_y \ll b, I_2 \to 1$, since $\operatorname{Erf}(\infty) = 1$. When $\sigma_y \gg b$, then $I_2 \to b/(2\sqrt{\pi}\sigma_y) \to 0$.

In order to compute explicitly the variance $Var(X_{AV})$ of (7.74) we have to evaluate the correlation term $\langle xx \rangle$.

The covariance of the arrival position of two electrons produced in the same cluster is evaluated from the distribution function of their arrival positions. Starting from (7.1) and (7.3) we write it as

$$F_{xx}(x_1, y_1, x_2, y_2) = \frac{1}{R} \int_{-R/2}^{+R/2} ds G(x_1 | s \sin \theta, \sigma_x) G(y_1 | s \cos \theta, \sigma_y)$$
$$\times G(x_2 | s \sin \theta, \sigma_x) G(y_2 | s \cos \theta, \sigma_y), \tag{7.77}$$

where the two indices 1 and 2 refer to the two electrons.

This distribution is not normalized. Its normalization is the probability that two electrons produced in the same cluster are both collected by the wire. It can be shown that

$$\int_{-\infty}^{+\infty} dx_1 \int_{-b/2}^{b/2} dy_1 \int_{-\infty}^{\infty} dx_2 \int_{-b/2}^{b/2} dy_2 F_{xx}(x_1, y_1, x_2, y_2) = I_2 \frac{b}{\cos \theta} , \qquad (7.78)$$

where I_2 is defined by (7.72). Since in (7.74) we have the product $I_2\langle xx \rangle$, we can compute directly

$$I_{2}\langle xx \rangle = \frac{\cos \theta}{b} \int_{-\infty}^{+\infty} dx_{1} \int_{-b/2}^{b/2} dy_{1}$$
$$\times \int_{-\infty}^{+\infty} dx_{2} \int_{-b/2}^{+b/2} dy_{2}x_{1}x_{2}F_{xx}(x_{1}, y_{1}, x_{2}, y_{2}), \qquad (7.79)$$

and after some tedious integration we obtain

$$I_{2}\langle xx \rangle = \tan^{2}\theta \left[\left(\sigma_{y}^{2} + \frac{b^{2}}{12} \right) \left(\operatorname{Erf} \left(\frac{b}{2\sigma_{y}} \right) - \frac{2}{\sqrt{\pi}} \frac{\sigma_{y}}{b} \left(1 - \exp \left[-\frac{b^{2}}{4\sigma_{y}^{2}} \right] \right) \right) + b^{2} \frac{1}{3\sqrt{\pi}} \left(4 \frac{\sigma_{y}^{3}}{b^{3}} \left(1 - \exp \left[-\frac{b^{2}}{4\sigma_{y}^{2}} \right] \right) - \frac{\sigma_{y}}{b} \right) - \sigma_{y}^{2} \frac{1}{\sqrt{\pi}} \left(\frac{\sigma_{y}}{b} \left(1 - \exp \left[-\frac{b^{2}}{4\sigma_{y}^{2}} \right] \right) \right) \right].$$
(7.80)

Now we have all the information we require and can write down the final formula for the variance $Var(X_{AV})$. Using (7.74), (7.75), (7.5) and (7.80) yields

$$\sigma_{X_{AV}}^{2} = \operatorname{Var}(X_{AV}) = \sigma_{x}^{2} \frac{1}{N} + \tan^{2} \theta \sigma_{y}^{2} \left[\frac{1}{N} + \left(\frac{1}{N_{\text{eff}}} - \frac{1}{N} \right) F_{\sigma} \left(\frac{\sigma_{y}}{b} \right) \right] + \tan^{2} \theta \frac{b^{2}}{12} \left[\frac{1}{N} + \left(\frac{1}{N_{\text{eff}}} - \frac{1}{N} \right) F_{b} \left(\frac{\sigma_{y}}{b} \right) \right],$$
(7.81)

where the two functions F_{σ} and F_{b} are given by

$$F_{\sigma} = \operatorname{Erf}\left(\frac{b}{2\sigma_{y}}\right) - \frac{3}{\sqrt{\pi}}\frac{\sigma_{y}}{b}\left(1 - \exp\left[-\frac{b^{2}}{4\sigma_{y}^{2}}\right]\right)$$
(7.82)

$$F_b = \operatorname{Erf}\left(\frac{b}{2\sigma_y}\right) - \frac{2}{\sqrt{\pi}} \frac{\sigma_y}{b} \left(1 - \exp\left[-\frac{b^2}{4\sigma_y^2}\right]\right) \left(1 - 8\frac{\sigma_y^2}{b^2}\right) - \frac{4}{\sqrt{\pi}} \frac{\sigma_y}{b} . \quad (7.83)$$

These are equal to 1 when σ_y/b is zero and go to zero when $\sigma_y/b \to \infty$. Inspecting (7.81) we note that this behaviour corresponds to a smooth transition between the coefficients $1/N_{\text{eff}}$ and 1/N in the angular terms. In the absence of diffusion there is complete correlation and the reduction factor of the angular term in the variance of





the average (7.10) is only N_{eff} ; when the diffusion is large compared to the width *b* of the drift cell, there is no correlation and the reduction factor of the angular term is *N*, the total number of collected electrons. The functions F_{σ} and F_b are shown in Fig. 7.20.

If we had calculated the plot of Fig. 7.3 with (7.81) (instead of using the numerical simulation (see Sect. 7.2.3)), we would have found a similar behaviour but a somewhat steeper increase of $N_{\text{eff}}(\sigma)$ with σ/l . This is a consequence of the assumption introduced: we have assumed that the average number m_i of electrons originated by clusters of size *i* and collected by the wire is constant. If we do not make this assumption, then (7.65) contains an additional term,

$$\operatorname{Var}(X_{\rm AV}) = \frac{\sum m_i^2 \operatorname{Var}(\bar{x}_i)}{N^2} + \frac{\sum (\bar{x}_i - X_{\rm AV})^2 \operatorname{Var}(m_i)}{N^2} .$$
(7.84)

The second term plays a role when the rare large clusters are present, since they dominate the average. The numerical simulation introduced in Sect. 7.2.3 and used to produce Fig. 7.3 takes into account all the various effects due to the peculiar shape of the cluster-size distribution and then correctly produces a variance larger than that evaluated in (7.81) and consequently a smaller $N_{\text{eff}}(\sigma)$.

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Chapter 8 Geometrical Track Parameters and Their Errors

Now we come to the point to which all the efforts of drift-chamber design lead up - the determination of the track parameters. The point of origin of a track, its angles of orientation, and its curvature in a magnetic field are the main geometric properties that one aims to measure. The proof of the pudding is in the eating, and the proof of the drift chamber is in the track parameters.

In a particle experiment a track is often measured by several detectors, and the accuracy of its parameters depends on the integrity of the whole ensemble, and in particular on the knowledge of the relative detector positions. Likewise, the track parameters determined with a drift chamber depend on its overall geometry, the electrode positions, fields and electron drift paths. If one wants to calculate the achievable accuracy of a drift chamber in all parts of its volume, one needs to have quantitative knowledge of these factors in addition to the point-measuring accuracy. Such knowledge is often difficult to get, and then one may want to work the other way around: starting from a measurement of the achieved accuracy of track parameters, one can compare it to that expected from the point-measuring accuracy alone. If they agree, then the other factors make only a small contribution, if they do not, the contribution of the other factors is larger, or perhaps dominant.

The achieved accuracy can be measured in a number of ways. The common methods include the following: vertex localization by comparing tracks from the same vertex, momentum resolution by measuring tracks with known momentum, a combination of momentum and angular precision with a measurement of the invariant mass of a decaying particle.

It is obviously our first task to ascertain the accuracy that can be achieved in a given geometry when considering the resolution of each measuring point alone, ignoring all the other factors by assuming they are negligible or have been corrected for. We will do this in two sections, one for the situation without magnetic field, using straight-line fits, the other for the situation inside a magnetic field, where a quadratic fit is appropriate. One section is devoted to accuracy limitations due to multiple Coulomb scattering in parts of the apparatus. Finally, the results on spectrometer resolution are summarized.

A general treatment of the methods of track fitting using different statistical approaches is presented in the book of Böck, Grote, Notz and Regler [BOC 90]. Here our aim is more modest and more specific: on the basis of the least-squares method we would like to understand how the point-measuring errors of a drift chamber propagate into the track parameters.

8.1 Linear Fit

Referring to Fig. 8.1, there are N + 1 points at positions $x_i (i = 0, 1, ..., N)$ where the coordinates y_i of a given track were measured. We ask for the accuracy with which the coordinate and the direction of the track are determined at x = 0. If there is a magnetic field, the track is curved. As a first step we imagine the curvature to be well measured outside the vertex detector so that we are allowed to consider a straight-line extrapolation; the influence of an error of curvature will be estimated in Sect. 8.2.

A least-squares fit to the straight line

$$y = a + bx \tag{8.1}$$

is obtained by minimizing

$$\chi^2 = \sum (y_i - a - bx_i)^2 / \sigma_i^2 , \qquad (8.2)$$

where the σ_i are the uncorrelated point-measuring errors whose reciprocal squares are used as weights. The two conditions $\partial \chi^2 / \partial a = 0$ and $\partial \chi^2 / \partial b = 0$ lead to the following linear equations:

$$aS_1 + bS_x = \sum y_i / \sigma_i^2 ,$$

$$bS_x + bS_{xx} = \sum x_i y_i / \sigma_i^2$$

where $S_1 = \sum 1/\sigma_i^2$, $S_x = \sum x_i/\sigma_i^2$, $S_y = \sum y_i/\sigma_i^2$, $S_{xy} = \sum x_iy_i/\sigma_1^2$, $S_{xx} = \sum x_ix_i/\sigma_i^2$ (all sums from 0 to *N*); also $D = S_1S_{xx} - S_x^2$. The two linear equations are solved for the best estimates of the coefficients *a* and *b* by

$$a = (S_y S_{xx} - S_x S_{xy})/D,$$

$$b = (S_1 S_{xy} - S_x S_y)/D.$$



Fig. 8.1 Straight-line fit to the origin

8.1 Linear Fit

Let us now consider the fluctuations of *a* and *b*. They are caused by the fluctuations of the y_i , which can be characterized by the $(N+1)^2$ covariances $[y_iy_k]$ defined as the average over the product minus the product of the averages:

$$[y_i y_k] = \langle y_i y_k \rangle - \langle y_i \rangle \langle y_k \rangle ; \qquad (8.3)$$

they vanish when $i \neq k$ because the y_i fluctuate independently of one another, and $[y_i^2]$ is what was called σ_i^2 before.

The fluctuations of a and b are described by their covariance matrix,

$$\begin{pmatrix} \begin{bmatrix} a^2 \end{bmatrix} & \begin{bmatrix} ab \end{bmatrix} \\ \begin{bmatrix} ab \end{bmatrix} & \begin{bmatrix} b^2 \end{bmatrix} \end{pmatrix},$$

and we have to determine how it depends on the quantities $[y_i^2]$.

To compute $[a^2] = \langle a^2 \rangle - \langle a \rangle^2$ we use (8.3):

$$\begin{aligned} [a^2] &= \left(S_{xx}^2 \sum \left(\langle y_i^2 \rangle - \langle y_i \rangle^2 \right) \middle/ \sigma_i^4 + S_x^2 \left(\sum x_i^2 \langle y_i^2 \rangle - x_i^2 \langle y_i \rangle^2 \right) \middle/ \sigma_i^4 \right) \\ &- 2S_x S_{xx} \sum x_i \left(\langle y_i^2 \rangle - \langle y_i \rangle^2 \right) \middle/ \sigma_i^4 \right) \middle/ D^2 \\ &= \left(S_{xx} \sum [y_i^2] \middle/ \sigma_i^4 + S_x^2 \sum x_i^2 [y_i^2] \middle/ \sigma_i^4 - 2S_x S_{xx} \sum x_i [y_i^2] \middle/ \sigma_i^4 \right) \Big/ D^2 \\ &= S_{xx} \middle/ D . \end{aligned}$$

$$(8.4)$$

The other two elements are calculated in a similar way, and the covariance matrix of the fitted parameters is

$$\begin{pmatrix} \begin{bmatrix} a^2 \end{bmatrix} & \begin{bmatrix} ab \end{bmatrix} \\ \begin{bmatrix} ab \end{bmatrix} & \begin{bmatrix} b^2 \end{bmatrix} \end{pmatrix} = \begin{pmatrix} S_{xx} & -S_x \\ -S_x & S_1 \end{pmatrix} \frac{1}{D} .$$
 (8.5)

Since the fit is linear, the result (8.4) and (8.5) depends only on the covariances of the y_i and not on their averages.

8.1.1 Case of Equal Spacing Between x_0 and x_N

We evaluate (8.3) for N + 1 equally spaced points with equal point errors ε^2 . In this case $S_1 = (N+1)/\varepsilon^2$, $S_x = (N+1)(x_0 + x_N)/(2\varepsilon^2)$ and $S_{xx} = (N+1)[x_0x_N + (x_N - x_0)^2(2 + 1/N)/6]/\varepsilon^2$. We see that the result will depend on the number of points and on the ratio of the two extreme distances x_N and x_0 . Let us introduce the ratio *r*, which expresses how far – in units of the chamber length – the centre of the chamber is away from the origin:

$$r = \frac{x_N + x_0}{2(x_N - x_0)} \,. \tag{8.6}$$

Table 8.1 Values of the factor Z(r,N) in (8.7) for various distances r of the vertex from the centre of the chamber, in units of the chamber length, and for various numbers of N + 1 equally spaced sense wires

N	<i>r</i> :	5.0	3.0	2.0	1.5	1.0	0.75	0.60	0.50
1		10.1	6.08	4.12	3.16	2.24	1.80	1.56	1.41
2		12.3	7.42	5.00	3.81	2.65	2.09	1.78	1.58
5		14.7	8.84	5.94	4.50	3.09	2.41	2.02	1.77
9		15.7	9.45	6.35	4.81	3.29	2.55	2.13	1.86
19		16.5	9.94	6.67	5.04	3.44	2.67	2.22	1.93
infin.		17.3	10.4	7.00	5.29	3.61	2.78	2.31	2.00

Inserting the sums into (8.4) and taking the square root we obtain the vertex localization accuracy

 $\sigma_a = \frac{\varepsilon}{\sqrt{(N+1)}} Z(r, N) , \qquad (8.7)$

with

$$Z(r,N) = \left(\frac{12r^2 + 1 + \frac{2}{N}}{1 + \frac{2}{N}}\right)^{1/2}$$

Values of *Z* have been computed for some *r* and *N*; results are listed in Table 8.1. We observe that the strongest functional variation is with the ratio *r*; this is understandable since it has the meaning of a lever–arm ratio. For any given *r*, the factor *Z* is more favourable for small *N*; this means that the dependence on *N* is weaker than the $1/\sqrt{(N+1)}$ rule. The error in the direction is given by

$$\sigma_b = \frac{\varepsilon}{x_N - x_0} \frac{1}{\sqrt{N+1}} \sqrt{\frac{12N}{N+2}} \,. \tag{8.8}$$

8.2 Quadratic Fit

In a magnetic spectrometer the particle momenta are determined from a measurement of the track curvature. We recall that in a homogeneous magnetic field B the trajectory is a helix with radius of curvature

$$R = p_{\rm T}/eB \,, \tag{8.9}$$

where *e* is the electric charge of the particle and p_T its momentum transverse to the magnetic field. A remark concerning units: relation (8.9) is in m, if *e* is in As, *B* in T (i.e. Vs/m²) and p_T in N s (i.e. V A s²/m). If one wants to express the momentum in units of GeV/*c*, then one must multiply p_T by the factor *f* that says how many GeV/*c* there are to one N s. This factor is

$$f = \frac{1 \text{GeV}/c}{1 \text{Ns}} = \frac{10^9 e(\text{As})(\text{V})}{(\text{VAs}^2/\text{m})2.9979 \times 10^8 (\text{m/s})},$$
(8.10)

8.2 Quadratic Fit

so that (8.9), to better than one tenth of a percent, takes on the simple form

$$R = \frac{10}{3} \left(\frac{\mathrm{Tm}}{\mathrm{GeV}/c} \right) \frac{p_{\mathrm{T}}}{B} \,. \tag{8.11}$$

This radius has to be measured in a plane perpendicular to *B*. Our interest is in the large momenta because they are the most difficult to measure precisely. Therefore we approximate the helix trajectory, which is actually a circle in a plane perpendicular to its axis, by a parabola in such a plane,

$$y = a + bx + (c/2)x^2$$
, (8.12)

up to terms of the order of x^3/R^2 , where c = 1/R. The measured y_i at positions x_i are fitted to (8.12) with the aim of determining *a*, *b* and *c*.

8.2.1 Error Calculation

One is interested in the errors of a, b and c. Our procedure is similar to that of Gluckstern [GLU 63], but is more general in that it includes the extrapolation to a vertex point at an arbitrary distance.

The linear equations for *a*, *b* and *c* are derived from the conditions of a minimal χ^2 and read as follows (the weighting factor at each point is denoted by f_n):

$$aF_0 + bF_1 + (c/2)F_2 = \sum f_n y_n ,$$

$$aF_1 + bF_2 + (c/2)F_3 = \sum f_n x_n y_n$$

$$aF_2 + bF_3 + (c/2)F_4 = \sum f_n x_n^2 y_n ,$$

(8.13)

where

$$F_j = \sum f_n(x_n)^j$$
 (8.14)

All sums run from n = 0 to n = N. The solution of (8.13) for our three quantities is

$$a = \frac{\sum y_n G_n}{\sum G_n} ,$$

$$b = \frac{\sum y_n P_n}{\sum x_n P_n} ,$$

$$\frac{c}{2} = \frac{\sum y_n Q_n}{\sum x_n^2 Q_n} ,$$

(8.15)

where the G_n , P_n and Q_n are expressed using determinants of the F_j :

$$G_n = f_n \begin{vmatrix} F_2 & F_3 \\ F_3 & F_4 \end{vmatrix} - f_n x_n \begin{vmatrix} F_1 & F_2 \\ F_3 & F_4 \end{vmatrix} + f_n x_n^2 \begin{vmatrix} F_1 & F_2 \\ F_2 & F_3 \end{vmatrix},$$

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$$P_{n} = -f_{n} \begin{vmatrix} F_{1} & F_{3} \\ F_{2} & F_{4} \end{vmatrix} + f_{n}x_{n} \begin{vmatrix} F_{0} & F_{2} \\ F_{2} & F_{4} \end{vmatrix} - f_{n}x_{n}^{2} \begin{vmatrix} F_{0} & F_{1} \\ F_{2} & F_{3} \end{vmatrix} ,$$

$$Q_{n} = f_{n} \begin{vmatrix} F_{1} & F_{2} \\ F_{2} & F_{3} \end{vmatrix} - f_{n}x_{n} \begin{vmatrix} F_{0} & F_{1} \\ F_{2} & F_{3} \end{vmatrix} + f_{n}x_{n}^{2} \begin{vmatrix} F_{0} & F_{1} \\ F_{1} & F_{2} \end{vmatrix} .$$

They have the property that

$$\sum Q_n = \sum x_n Q_n = \sum P_n$$

= $\sum x_n^2 P_n = \sum x_n G_n = \sum x_n^2 G_n = 0$ (8.16)

and

$$\sum x_n^2 Q_n = \sum x_n P_n = \sum G_n . \tag{8.17}$$

Using (8.16), the variance of the first coefficient is given by

$$[a^{2}] = \sum \sum G_{m} G_{n}[y_{m}y_{n}] / \left(\sum G_{n}\right)^{2} , \qquad (8.18)$$

where $[y_m y_n]$ denotes the covariance of the measurements at two points x_m and x_n . The other elements are formed in the same manner.

The point-measurement errors are equal and uncorrelated. We write

$$[y_n \quad y_m] = \varepsilon^2 \delta_{mm} \tag{8.19}$$

and obtain

$$[a^{2}] = \varepsilon^{2} \sum G_{n}^{2} / (\sum G_{n})^{2} ,$$

$$[ab] = \varepsilon^{2} \sum G_{n}P_{n} / (\sum G_{n}) (\sum x_{n}P_{n}) ,$$

$$[b^{2}] = \varepsilon^{2} \sum P_{n}^{2} / (\sum x_{n}P_{n})^{2} ,$$

$$[ac] = 2\varepsilon^{2} \sum G_{n}Q_{n} / (\sum G_{n}) (\sum x_{n}^{2}Q_{n}) ,$$

$$[bc] = \varepsilon^{2} 2 \sum Q_{n}P_{n} / (\sum x_{n}^{2}Q_{n}) (\sum x_{n}P_{n}) ,$$

$$[c^{2}] = \varepsilon^{2} 4 \sum Q_{n}^{2} / (\sum x_{n}^{2}Q_{n})^{2} .$$

(8.20)

8.2.2 Origin at the Centre of the Track – Uniform Spacing of Wires

In order to facilitate the evaluation of (8.20) we begin by setting the origin of the *x* coordinates at the centre of the track. Let

8.2 Quadratic Fit

$$q_n = x_n - x_c$$
, with $x_c = \sum x_n / (N+1)$, (8.21)

and

$$L = x_N - x_0$$

For uniform spacing and uniform weights $f_n = 1$, the subdeterminants are easily calculated to be

$$G_n = F_2 F_4 - q_n^2 F_2^2 ,$$

 $P_n = q_n (F_0 F_4 - F_2^2) ,$
 $Q_n = -F_2^2 + q_n^2 F_0 F_2 ,$

with $F_j = \sum q^j$. Note that $F_1 = F_3 = 0$ for symmetry. The other F_j are

$$F_{0} = N + 1 ,$$

$$F_{2} = L^{2} \frac{(N+1)(N+2)}{12N} ,$$

$$F_{4} = L^{4} \frac{(N+1)(N+2)(3N^{2}+6N-4)}{240N^{3}} ,$$

$$S = F_{0}F_{4} - F_{2}^{2} = L^{4} \frac{(N-1)(N+1)^{2}(N+2)(N+3)}{180N^{3}} ,$$
(8.22)

A combination S, needed later, has been included here. Inserting the subdeterminants into (8.20) we find the six elements of the covariance matrix, valid at the origin, that is the centre of the track:

$$[a^{2}] = \varepsilon^{2} F_{4} / (F_{0}F_{4} - F_{2}^{2}) ,$$

$$[ab] = 0 ,$$

$$[b^{2}] = \varepsilon^{2} / F_{2} ,$$

$$[ac] = -2\varepsilon^{2} F_{2} / (F_{0}F_{4} - F_{2}^{2}) ,$$

$$[bc] = 0 ,$$

$$[c^{2}] = 4F_{0} / (F_{0}F_{4} - F_{2}^{2}) .$$
(8.23)

Note that there is no correlation between the direction b and the offset a or the curvature c in the middle of the track. The elements of the covariance matrix (8.23) will assume different values outside the centre, and this will be treated in Sect. 8.2.4. The variance of the curvature, however, is the same all along the track, and we can evaluate it by inserting (8.22) into the last of the equations (8.23). The variance of

N	A_N	$\sqrt{(A_N)/8}$
2	96	1.22
3	81	1.12
4	73.1	1.07
5	67.0	1.02
6	61.7	0.982
8	53.2	0.912
10	46.6	0.853
infin.	$\frac{720}{N+5}$	$\frac{3.35}{\sqrt{N+5}}$

Table 8.2 Values of the factors A_N in (8.24) and $\sqrt{(A_N)/8}$ in (8.26) for various values of N. (The number of measuring points is N + 1.)

the curvature is equal to

$$[c^{2}] = \frac{\varepsilon^{2}}{L^{4}} \frac{720N^{3}}{(N-1)(N+1)(N+2)(N+3)} = \frac{\varepsilon^{2}}{L^{4}} A_{N} , \qquad (8.24)$$

where we have defined a factor A_N , some values of which are enumerated in Table 8.2.

8.2.3 Sagitta

The maximum excursion of a piece of a circle over the corresponding chord is called its sagitta. The sagitta s of a track with length L and radius of curvature $R \gg L$ is proportional to the square of the track length, as can be seen from the sketch of Fig. 8.2 when developing the cosine of the small angle (L/2R) into powers of (L/2R):

$$s = L^2 / 8R$$
, (8.25)

so its r.m.s. error becomes

$$\delta s = \varepsilon \frac{\sqrt{A_N}}{8} \,. \tag{8.26}$$

This ratio between the errors of the sagitta and the individual point coordinates is also contained in Table 8.2.



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Fig. 8.2 Sagitta s

8.2.4 Covariance Matrix at an Arbitrary Point Along the Track

Now we know the full covariance matrix of a, b and c at the centre of the chamber, and we are curious to know the accuracy with which the measured track can be extrapolated to some point x outside the centre. For this we must express the position and the slope of the track as a function of the independent variable which defines the distance from the track centre to the point in question:

$$a(x) = a_0 + b_0 x + (c_0/2)x^2 ,$$

$$b(x) = b_0 + c_0 x ,$$

$$c(x) = c_0 .$$

(8.27)

 a_0, b_0 and c_0 represent the values of the coefficients at the centre, for which the covariance matrix was given in (8.23). The distance of the point *x* from the centre x_c of the chamber will be described by the ratio

$$r=\frac{x-x_c}{L},$$

which has the same physical meaning as the r of (8.6) used in the linear fit.

For example, to compute the covariance $[a(x) \ c(x)]$, we form

$$\left[(a_0 + b_0 x + (c_0/2)x^2) \quad c_0 \right],$$

which is equal to $[a_0c_0] + x[b_0c_0] + (x^2/2)[c_0^2]$. In this way the full covariance matrix is constructed, and the result is

$$\begin{split} & [a^{2}(r)] = \varepsilon^{2} \left[\frac{F_{4}}{S} + r^{2} \left(\frac{L^{2}}{F_{2}} - \frac{2L^{2}F_{2}}{S} \right) + r^{4} \frac{L^{4}F_{0}}{S} \right] = \varepsilon^{2} \frac{1}{N+1} B_{aa}^{2}(r,N) , \\ & [a(r)b(r)] = \frac{\varepsilon^{2}}{L} \left[r \left(\frac{L^{2}}{F_{2}} - \frac{2L^{2}F_{2}}{S} \right) + 2r^{3} \frac{L^{4}F_{0}}{S} \right] = \frac{\varepsilon^{2}}{L} \frac{1}{N+1} B_{ab}^{2}(r,N) , \\ & [b^{2}(r)] = \frac{\varepsilon^{2}}{L^{2}} \left[\frac{L^{2}}{F_{2}} + 4r^{2} \frac{L^{4}F_{0}}{S} \right] = \frac{\varepsilon^{2}}{L^{2}} \frac{1}{N+1} B_{bb}^{2}(r,N) , \\ & [a(r)c_{0}] = \frac{\varepsilon^{2}}{L^{2}} \left[-\frac{2L^{2}F_{2}}{S} + 2r^{2} \frac{L^{4}F_{0}}{S} \right] = \frac{\varepsilon^{2}}{L^{2}} \frac{1}{N+1} B_{ac}^{2}(r,N) , \\ & [b(r)c_{0}] = \frac{\varepsilon^{2}}{L^{3}} \left[4r \frac{L^{4}F_{0}}{S} \right] = \frac{\varepsilon^{2}}{L^{3}} \frac{1}{N+1} B_{bc}^{2}(r,N) , \\ & [c_{0}^{2}] = \frac{\varepsilon^{2}}{L^{4}} \left[4 \frac{L^{4}F_{0}}{S} \right] = \frac{\varepsilon^{2}}{L^{4}} \frac{1}{N+1} B_{cc}^{2}(N) . \end{split}$$

Apart from the dimensional factors in front of the square brackets, these covariances depend only on *r* and *N*; they contain a common denominator N + 1, the number of measurements. The remaining factors have been called B(r,N); they tend to a constant as $N \to \infty$, and they rapidly increase with *r*. The factors B_{aa} and B_{bb} belonging to the diagonal elements $[a^2(r)]$ and $[b^2(r)]$ were calculated for some values of *N* and *r* using (8.28) and (8.22). They are listed in Tables 8.3 and 8.4. The factor B_{cc} belonging to $[c^2]$ does not vary with *r* and was already contained in Table 8.2 in the form of $A_N = B_{cc}^2(N)/(N+1)$.

8.2.5 Comparison Between the Linear and Quadratic Fits in Special Cases

Let us consider the extrapolation of a measured track to a vertex. The accuracy of vertex determination is very different whether it happens inside a magnetic field with unknown track momentum or outside (or momentum known). We have a direct comparison in Tables 8.1 and 8.3. It appears that a chamber whose front end is only a quarter of its length away from the vertex (r = 0.75) extrapolates half as well when inside a field. This gets quickly worse when the vertex is further away – if the factor of comparison is around 2.3 at r = 0.75, it is near 5 at r = 1.5. This depends only weakly on the number of wires. It is obviously essential for a vertex chamber that it be supported by a momentum measuring device with precision much better than that of the vertex chamber alone.

The loss of accuracy owing to the presence of a magnetic field is also important for the measurement of direction. We want to compute the precision with which a chamber can measure the direction of a track at the first of N + 1 regularly spaced wires. In the quadratic fit we may use the third of equations (8.28) in conjunction with Table 8.4 (last column), or we may evaluate the equation directly for r = 1/2, which yields

$$\left[b^2\left(\frac{1}{2}\right)\right] = \frac{\varepsilon^2}{L^2} \frac{12(2_N+1)(8N-3)N}{(N-1)(N+1)(N+2)(N+3)}$$
(quadratic fit). (8.29)

Table 8.3 Values of the factor $B_{aa}(r,N)$ in (8.28) at various points along the track at distances r from the centre of the chamber (in units of its length), for various numbers of N + 1 equally spaced sense wires

N	<i>r</i> :	5	3	2	1.5	1	0.75	0.60	0.50
2		211	75.3	32.9	18.1	7.63	4.10	2.65	2.05
3		224	80.2	35.2	19.5	8.29	4.48	2.84	2.07
5		250	89.5	39.4	21.9	9.39	5.10	3.20	2.26
10		282	101	44.6	24.8	10.7	5.84	3.65	2.54
19		304	109	48.1	26.8	11.6	6.32	3.95	2.72
infin.		335	120	53.0	29.5	12.8	7.00	4.37	3.00

Table 8.4 Values of the factor $B_{bb}(r,N)$ in (8.28) at various points along the track at distances r from the centre of the chamber (in units of its length), for various numbers of N + 1 equally spaced sense wires

Ν	<i>r</i> :	5	3	2	1.5	1	0.75	0.60	0.50
2		84.9	51.0	34.0	25.6	17.1	13.0	10.5	8.83
3		90.0	54.0	36.1	27.1	18.2	13.8	11.1	9.39
5		100	60.2	40.2	30.2	20.3	15.3	12.4	10.4
10		113	68.0	45.4	34.1	22.9	17.3	14.0	11.8
19		122	73.2	48.8	36.7	24.6	18.6	15.0	12.6
infin.		134	80.6	53.8	40.4	27.1	20.4	16.5	13.9

In the linear fit we use (8.8), where *L* was called $x_N - x_0$:

$$\sigma_b^2 = \frac{\varepsilon^2}{L^2} \frac{12N}{(N+1)(N+2)} \text{ linear fit }.$$
 (8.30)

The ratio of the errors is

$$\frac{\text{with bending}}{\text{without bending}} = \left(\frac{(2N+1)(8N-3)}{(N-1)(N+3)}\right)^{1/2},$$
(8.31)

which tends to 4 for infinite N and is 3.60 for N = 2. This ratio is independent of the magnetic field and of the particle momentum as long as the curvature can be as large as the uncertainty with which it is measured. If there is a priori knowledge that the sagitta of the track is much smaller than the measurement error, the curvature can be neglected, and (8.30) applies.

The fact that the directional error is dominated by the error in curvature is also visible in their correlation coefficient: with some algebra, we form the ratio

$$\frac{[b(\frac{1}{2})c]}{\sqrt{[c^2][b^2(\frac{1}{2})]}} = \frac{0.968}{\sqrt{\left(1+\frac{1}{2N}\right)\left(1-\frac{3}{8N}\right)}}$$
(8.32)

and find it almost equal to 1. This means the error in curvature produces almost the entire error in direction. Figure 8.3 shows a picture of the case $\langle c \rangle = 0$. Since the sagitta is half as long as the corresponding distance between the chord and the end-point tangent, we may estimate the directional error with



8 Geometrical Track Parameters and Their Errors

$$\delta b = \frac{2\delta s}{L/2} \,. \tag{8.33}$$

Using (8.26), (8.24) and (8.29) one may verify that (8.33) is correct within 4% for all *N*.

8.2.6 Optimal Spacing of Wires

With a given number N + 1 of wires and a given chamber length L the elements of the covariance matrix can be minimized by varying the wire positions. Summarizing Gluckstern [GLU 63] we mention that the optimal spacing is different for different correlation coefficients, and that for a minimal $[c^2]$ the best wire positions are ideally the following:

$$(N+1)/4$$
 wires at $x = 0$, $(N+1)/2$ wires at $x = L/2$,
 $(N+1)/4$ wires at $x = L$.

In practice the clustering of wires will use some of the chamber length. For the ideal case this was set to zero, and he calculates at r = -1/2 that

$$\begin{bmatrix} b^2 \left(\frac{1}{2}\right) \end{bmatrix} = \frac{\varepsilon^2}{L^2} \frac{72}{N+1},$$

$$\begin{bmatrix} b \left(\frac{1}{2}\right) c \end{bmatrix} = -\frac{\varepsilon^2}{L^3} \frac{128}{N+1},$$

$$\begin{bmatrix} c^2 \end{bmatrix} = \frac{\varepsilon^2}{L^4} \frac{256}{N+1},$$
(8.34)

and this, at large *N*, is an important factor of 1.7 better in the momentum resolution than (8.28).

8.3 A Chamber and One Additional Measuring Point Outside

It happens quite often that tracks are measured not only in the main drift chamber but in addition at some extra point which is located some distance away from the main chamber. Typical examples are a miniature vertex detector near the beam pipe, or a single layer of chambers surrounding the central main chamber. In an event with tracks coming from the same vertex, the vertex constraint serves a similar purpose, especially when the vertex position must be the same for many events. We suppose that all the measurements happen inside a magnetic field.

Since we have developed the covariance matrix of the variables a, b and c at an arbitrary point r along the track, we have the tools to add the constraint of the one additional space-coordinate measurement. The scheme to do this is the following.

8.3 A Chamber and One Additional Measuring Point Outside

Let the full covariance matrix at r (8.28) be abbreviated by

$$C_{ik}(r) = \begin{pmatrix} [a^2(r)] & [a(r)b(r)] & [a(r)c] \\ [a(r)b(r)] & [b^2(r)] & [b(r)c] \\ [a(r)c] & [b(r)c] & [c^2] \end{pmatrix}.$$
(8.35)

This matrix has to be inverted to obtain the χ^2 matrix $C_{ik}^{-1}(r)$. The corresponding matrix D_{ik}^{-1} of the additional measuring point has only the one element that belongs to the space-coordinate non-zero; let us call it $1/\varepsilon_v^2(\varepsilon_v)$ is the accuracy of the additional measuring point):

$$D_{ik}^{-1} = \begin{pmatrix} \varepsilon_{\rm v}^{-2} & 0 & 0\\ 0 & 0 & 0\\ 0 & 0 & 0 \end{pmatrix} .$$
 (8.36)

Now the covariance matrix E_{ik} of the total measurement, N + 1 regularly spaced wires plus this one point, a distance rL away from their centre, is given by the inverse of the sum of the inverses of the individual covariances:

$$(E_{ik})^{-1} = (C_{ik}(r))^{-1} + (D_{ik})^{-1}$$
(8.37)

Now there is a theorem (e.g. [SEL 72]) which states that if the inverse of a first matrix is known, then the inverse of a second matrix, which differs from the first in only one element, can be calculated according to a simple formula. In our case the first matrix is C^{-1} , and its known inverse is *C*; the second matrix, E^{-1} , differs from the first only in the (1, 1) element which is larger by $1/\varepsilon_v^2$. The inverse of the second matrix is given by

$$E_{ik} = C_{ik} - \frac{C_{1i}C_{1k}}{\varepsilon_v^2 + C_{11}} .$$
(8.38)

This means that our covariance matrix (8.28) changes by the addition of one point at *r* according to the following scheme (we leave out the argument *r*):

$$\begin{split} \left[a^{2}\right] \to \left[a'^{2}\right] &= \left[a^{2}\right] - \frac{\left[a^{2}\right]^{2}}{\varepsilon_{v}^{2} + \left[a^{2}\right]} ,\\ \left[ab\right] \to \left[a'b'\right] &= \left[ab\right] - \frac{\left[a^{2}\right]\left[ab\right]}{\varepsilon_{v}^{2} + \left[a^{2}\right]} ,\\ \left[b^{2}\right] \to \left[b'^{2}\right] &= \left[b^{2}\right] - \frac{\left[ab^{2}\right]^{2}}{\varepsilon_{v}^{2} + \left[a^{2}\right]} ,\\ \left[ac\right] \to \left[b'c'\right] &= \left[ac\right] - \frac{\left[a^{2}\right]\left[ac\right]}{\varepsilon_{v}^{2} + \left[a^{2}\right]} ,\\ \left[bc\right] \to \left[b'c'\right] &= \left[bc\right] - \frac{\left[ab\right]\left[ac\right]}{\varepsilon_{v}^{2} + \left[a^{2}\right]} ,\\ \left[c^{2}\right] \to \left[c'^{2}\right] &= \left[c^{2}\right] - \frac{\left[ac\right]^{2}}{\varepsilon_{v}^{2} + \left[a^{2}\right]} . \end{split}$$

$$(8.39)$$

8.3.1 Comparison of the Accuracy in the Curvature Measurement

We are particularly interested in the gain that can be obtained for the curvature measurement. Introducing the ratio $f^2 = \varepsilon_v^2 / [a^2(r)]$ (how much better the extra measurement is compared to the extrapolated point measuring accuracy of the chamber), we write the gain factor as

$$\kappa^{2}(f,r) = \frac{[c^{2}] - \frac{[a(r)c]^{2}}{\varepsilon_{v}^{2} + [a^{2}(r)]}}{[c^{2}]} = 1 - \frac{[a(r)c]^{2}}{(1+f^{2})[a^{2}(r)][c^{2}]}.$$
(8.40)

Since the covariance matrix (8.28) is a function of *r* and *N*, κ also depends on *N*. We evaluate (8.40) in the limit of $N \rightarrow \infty$. Table 8.5 contains the result.

It appears that considerable improvement is possible for the curvature, and hence momentum, measurement of a large drift chamber when one extra point outside can be measured with great precision. This is a consequence of the increase of the lever arm. As an example we consider the geometry of the ALEPH TPC. For a well measured track there are 21 measured points, equally spaced over L = 130 cm; each has $\varepsilon = 0.16$ mm, and therefore $\sqrt{[c^2]} = \sqrt{(720/25) \times (0.16 \times 10^{-3})/1.30^2} =$ 5.1×10^{-4} m⁻¹, according to (8.24). A silicon miniature vertex detector with $\varepsilon_v =$ 0.02 mm, 35 cm in front of the first measuring point (r = 0.77), would result in an improvement factor of $\kappa = 0.40$, according to Table 8.5. Here we have determined $\sqrt{[a^2(0.77)]} = 7 \times 0.16$ mm/ $\sqrt{21} = 0.24$ mm, using the first of (8.28) and Table 8.3; therefore f = 0.02/0.24 = 0.08.

Such enormous improvement could only be converted into fact if all the systematic errors were tightly controlled at a level better than these $20 \,\mu$ m. Also, for the moment we have left out any deterioration caused by multiple scattering, to which subject we will turn in Sect. 8.4.

8.3.2 Extrapolation to a Vertex

Since it is the first purpose of a vertex detector to determine track coordinates at a primary or secondary interaction vertex, we must carry our error calculation forward

r	f^{2} :	0	0.1	0.2	0.3	0.5	1.0	2.0
0.5		0.67	0.70	0.73	0.76	0.79	0.85	0.90
0.6		0.53	0.59	0.63	0.67	0.72	0.80	0.87
0.7		0.43	0.51	0.57	0.61	0.68	0.77	0.85
0.8		0.37	0.46	0.53	0.58	0.65	0.75	0.84
1.0		0.28	0.40	0.48	0.54	0.62	0.73	0.83
1.5		0.18	0.35	0.44	0.51	0.60	0.72	0.82
2.0		0.13	0.33	0.43	0.49	0.59	0.71	0.82
infin.		0	0.30	0.41	0.48	0.58	0.71	0.82

Table 8.5 Factors $\kappa(f,r)$ of (8.40) by which the measurement of curvature becomes more accurate when a single measuring point with accuracy $\varepsilon_v = f \sqrt{[a^2(r)]}$ is added to a large number of regularly spaced wires at a distance *rL* from their centre



to the vertex. The situation is sketched in Fig. 8.4. The coordinate x represents the distance of the detector to the vertex, and the extrapolation error Δ of the vertex position is given by the covariance

$$\Delta^{2} = [y^{2}] = [(a'(r) + b'(r)x + c'(r)x^{2}/2)^{2}]$$

= $[a'^{2}] + 2x[a'b'] + x^{2}([b'^{2}] + [a'c'])$ (8.41)
 $+ x^{3}[b'c'] + x^{4}[c'^{2}]/4.$

Here the $[a'^2], [a'b'], \ldots$ represent the elements of the covariance matrix *E* (8.39) at the position *r* of the vertex detector.

The evaluation of (8.41) is too clumsy when done in full generality, and we will consider the special case of a vertex detector that is much more accurate than the drift chamber at *r*, as presented in Table 8.3:

 $f^2 \ll 1$

or

$$\varepsilon_{\rm v}^2 \ll [a^2(r)] \,. \tag{8.42}$$

The covariance matrix at *r* for the ensemble of chamber and vertex detector, in first order of $\varepsilon_v^2/[a^2(r)]$, takes the form

$$E = \begin{pmatrix} \varepsilon_{\rm v}^2 & \varepsilon_{\rm v}^2 [ab]/[a^2] & \varepsilon_{\rm v}^2 [ac]/[a^2] \\ \varepsilon_{\rm v}^2 [ab]/[a^2] & [b^2] - [ab]^2/[a^2] & [bc] - [ab][ac]/[a^2] \\ \varepsilon_{\rm v}^2 [ac]/[a^2] & [bc] - [ab][ac]/[a^2] & [c^2] - [ac]^2/[a^2] \end{pmatrix} .$$
(8.43)

The elements of *E* depend on *N* and *r*. We evaluate (8.43) in the limit of $N \rightarrow \infty$ and for some special values of *r*. For r = 1/2 (i.e. the vertex detector at the same place as the last wire), using (8.41), (8.42), (8.28), (8.22), one finds that

$$\Delta^2 = \frac{\varepsilon^2}{N+1} \left(48\frac{x^2}{L^2} + 120\frac{x^3}{L^3} + 80\frac{x^4}{L^4} \right) + \varepsilon_v^2 \left(1 + 8.0\frac{x}{L} + 6.7\frac{x^2}{L^2} \right) \,.$$





Here we have counted x/L positive if x and x_v point in the same direction. We see that the vertex extrapolation accuracy deteriorates as x/L increases. There is one term proportional to the accuracy squared of the vertex detector alone, and one term proportional to the quantity $\varepsilon^2/(N+1)$, which characterizes the accuracy of the drift chamber.

$$\Delta^2 = R^2 \left(r, \frac{x}{L} \right) \frac{\varepsilon^2}{N+1} + S^2 \left(r, \frac{x}{L} \right) \varepsilon_{\rm v}^2 \,. \tag{8.44}$$

Figure 8.5a,b contains graphs of R(r,x/L) and S(r,x/L) for four values of r in the range of typical applications.

Taking again the geometry of the ALEPH experiment as a numerical example, we read from Fig. 8.5a,b that for r = 0.77 and $x_v = 6.5$ cm the vertex extrapolation accuracy can reach $\Delta = \sqrt{(0.28^2 \varepsilon^2/21 + 1.14^2 \varepsilon_v^2)}$. Using $\varepsilon = 160 \mu m$ and $\varepsilon_v = 20 \mu m$ one obtains $\Delta = 25 \mu m$ in this particular case.

8.4 Limitations Due to Multiple Scattering

The achievable accuracy of a chamber may be reduced by multiple scattering of the measured particle in some piece of the apparatus. There it suffers a displacement and a change in direction, and we want to know the influence on the accuracy of vertex reconstruction and of momentum measurement.

8.4.1 Basic Formulae

The theory of multiple scattering has been developed by Moliere, Snyder, Scott, Bethe and others. Reviews exist from Rossi [ROS 52], Bethe [BET 53] and Scott [SCO 63]. Our interest here must be limited to the basic notions.

8.4 Limitations Due to Multiple Scattering

After a particle has traversed a thickness *x* of some material, it has changed its direction and position, and we want to know the two-dimensional probability distribution $P(x, y, \theta_y)$ of the angular and spatial variables θ_y and *y*. Here we describe in a Cartesian coordinate system the lateral position at a depth *x* by the coordinates *y* and *z*. The corresponding angles are denoted by θ_y (in the *x*-*y* plane) and θ_z (in the *x*-*z* plane). Because of the symmetry of the situation, the two distributions $P(x, y, \theta_y)$ and $P(x, z, \theta_z)$ must be the same. In the simplest approximation they are given [ROS 52] by

$$P(x, y, \theta_y) \,\mathrm{d}y \,\mathrm{d}\theta_y = \frac{2\sqrt{3}}{\pi} \frac{1}{\Theta_s^2 x^2} \exp\left[-\frac{4}{\Theta_s^2} \left(\frac{\theta_y^2}{x} - \frac{3y\theta_y}{x^2} + \frac{3y^2}{x^3}\right)\right], \quad (8.45)$$

where the only parameter Θ_s^2 is called the mean square scattering angle per unit length. The angular distribution, irrespective of the lateral position, is given by the integral

$$Q(x,\theta_y) = \int_{-\infty}^{\infty} P(x,y,\theta_y) dy = \frac{1}{\sqrt{\pi}} \frac{1}{\Theta_s \sqrt{x}} \exp\left[-\frac{\theta_y^2}{\Theta_s^2 x}\right].$$
 (8.46)

We have for this projection a Gaussian distribution with a mean square width of

$$\langle \theta_{\rm y}^2 \rangle = \Theta_{\rm s}^2 x/2 \,. \tag{8.47}$$

Since the basic process is the scattering with a single nucleus, we understand that the variance of θ_y must be proportional to the number of scatterings, and hence *x*.

The corresponding spatial distribution, irrespective of the angle of deflection, is given by the integral over the other variable:

$$S(x,y) = \int_{-\infty}^{\infty} P(x,y,\theta_y) d\theta_y = \sqrt{\frac{3}{\pi}} \frac{1}{\Theta_s \sqrt{x^3}} \exp\left[-\frac{3y^2}{\Theta_s^2 x^3}\right].$$
 (8.48)

This Gaussian distribution has a mean square width of

$$\langle y^2 \rangle = \Theta_{\rm s}^2 x^3 / 6 \,. \tag{8.49}$$

For completeness we mention that the covariance is given by

$$\langle y\theta_y \rangle = \int y\theta_y P(x, y, \theta_y) \,\mathrm{d}y \,\mathrm{d}\theta_y = \Theta_s^2 x^2/4 \,.$$
 (8.50)

The mean square scattering angle per unit length, Θ_s^2 , depends on particle velocity β and momentum *p* as well as on the radiation length X_{rad} of the material:

$$\Theta_{\rm s}^2 = \left(\frac{E_{\rm s}}{\beta cp}\right)^2 \frac{1}{X_{\rm rad}} \,. \tag{8.51}$$

The constant E_s , which has the dimension of energy, is given by the fine-structure constant α and the electron rest energy mc^2 :

$$E_{\rm s} = \left(\frac{4\pi}{\alpha}\right)^{1/2} mc^2 = 21 \,{\rm MeV} \,.$$
 (8.52)

Using (8.52) and (8.51) in (8.50) and (8.49) we may express the projected r.m.s. deflection and displacement as

$$\sqrt{\langle \theta_y^2 \rangle} = \frac{15 \,\mathrm{MeV}}{\beta c p} \sqrt{\frac{x}{X_{\mathrm{rad}}}},\tag{8.53}$$

$$\langle y^2 \rangle = \frac{x}{3} \sqrt{\langle \theta_y^2 \rangle} .$$
 (8.54)

A short list of scattering lengths for some materials of interest in our context is given in Table 8.6. It is extracted from [TSA 74]; see also [PAR 04].

In Moliere's theory [MOL 48], which represents the measurements very well (see BET 53), the Gaussian distribution of the scattering angle is only one term in a series expansion. The effect of the additional terms is that the Gauss curve acquires a tail for angles that are several times as large as the r.m.s. value. Although only at the level of a few per cent compared to the maximum, they are many times larger than the Gauss curve for these arguments. The tail is caused by the few rare events where one or two single scatters reach a deflection several times as large as the r.m.s.

Material	ρ	X _{rad}	$X_{\rm rad}\rho$
Gases (N.T.P.)	(g/l)	(m)	(g/cm^2)
H ²	0.090	6800	61.28
Не	0.178	5300	94.32
Ne	0.90	321.6	28.94
Ar	1.78	109.8	19.55
Xe	5.89	14.4	8.48
Air	1.29	284.2	36.66
CO ₂	1.977	183.1	36.2
CH ₄	0.717	648.5	46.5
$Iso - C_4H_{10}$	2.67	169.3	45.2
Solids	(g/cm^3)	(cm)	(g/cm^2)
Be	1.848	35.3	65.19
С	2.265	18.8	42.70
Al	2.70	8.9	24.01
Si	2.33	9.36	21.82
Fe	7.87	1.76	13.84
Pb	11.35	0.56	6.37
Polyethylene CH ₂	0.92-0.95	~ 47.9	44.8
Mylar C ₅ H ₄ O ₂	1.39	28.7	39.95

Table 8.6 Radiation lengths X_{rad} and densities ρ of some materials relevant for drift chambers
sum of the large majority of events, which are dominated by small-angle scattering alone. This behaviour is typical for Coulomb scattering as described by the Rutherford formula; for hadrons, nuclear elastic scattering also makes a contribution to the tail. All the theories that go beyond the simple approximation discussed above are analytically quite complex.

Highland [HIG 75] has taken a practical standpoint by fitting the width of the scattering-angle distribution of the Moliere theory to a form similar to (8.53), using the radiation lengths as listed in the Particle Data Tables (and partly in our Table 8.6).

He finds that the width of Moliere does not vary appreciably with the nuclear charge number Z; he introduces an x-dependent correction factor $(1 + \varepsilon(x))$ to (8.53), which redefines the energy constant. His result is

$$\theta_{y}^{1/e} = \frac{14.1 \,\mathrm{MeV}}{\beta c p} \sqrt{\frac{x}{X_{\mathrm{rad}}}} \left(1 + \frac{1}{9} \log_{10} \frac{x}{X_{\mathrm{rad}}}\right) \,. \tag{8.55}$$

 $\theta_y^{1/e}$ is the angle in the *x*-*y* plane at which the Moliere probability density is down by a factor of 1/e from the maximum. Formula (8.55) is supposed to be accurate to 5% in the range $10^{-3} < x/X_{\text{rad}} < 10$, except for the very light elements, where the accuracy is 10-20%.

8.4.2 Vertex Determination

At colliders the observation of primary vertices and of secondary vertices from particles with short lifetimes is through a vacuum tube; in addition there is the material of the vertex chamber itself. We would like to compute the vertex localization error due to multiple scattering in these materials. The situation is sketched in Fig. 8.6. We assume for simplicity that the track is infinitely well measured outside the scattering material. Upon extrapolation, it misses the vertex position by the distance d. The average over the square of d is equal to

$$\langle d^2 \rangle = \langle \vartheta_1^2 \rangle r_1^2 + \langle \vartheta_2^2 \rangle r_2^2 + \cdots, \qquad (8.56)$$

where the mean squared projected scattering angle $\langle \vartheta_1^2 \rangle$ is given by the thickness t_i of the layer *i* in units of radiation lengths of the material *i* according to (8.53), where $\langle \vartheta^2 \rangle = \langle \theta_v^2 \rangle$. We express the r.m.s. value of *d* in terms of a 'Coulomb scattering



Fig. 8.6 Coulomb multiple scattering of an infinitely well measured track

limit' S_c of the vertex localization accuracy. By combining (8.56) and (8.53) we have

$$\sqrt{\langle d^2 \rangle} = \frac{S_c}{\beta pc} , \qquad (8.57)$$

with

$$S_{\rm c} = 15 \,{\rm MeV} \left(\sum t_i r_i^2\right)^{1/2}$$
 (8.58)

Practical values of S_c range between 45 and 200 µm GeV for various experiments; compare Table 11.3.

The above calculation gives correct vertex errors in the limit that the Coulomb scattering is much larger than the measurement errors and that all the scattering material is between the sense wires and the vertex. For the general case the estimation of vertex errors is more involved. Although the quadratic addition of measurement errors (8.7) and the multiple-scattering errors (8.57) gives the right order of magnitude for the total, more sophisticated estimation methods give better results. Lutz [LUT 88] has developed an optimal tracking procedure by fitting the individual contributions to multiple scattering between the measuring points.

8.4.3 Resolution of Curvature for Tracks Through a Scattering Medium

We have seen in (8.53) that the mean square scattering angle increases as the momentum of the particle becomes smaller. Let us imagine a drift chamber in a spectrometer where the momentum of a particle is low enough to make the multiple-scattering error the dominating one. We would like to know the accuracy for a measurement of the curvature in this situation; this implies we suppose that the accuracy of the apparatus itself is infinitely better than the multiple-scattering errors.

We resume the arguments of Sect. 8.2 at (8.2.1). In order to evaluate $[y_n y_m]$ in the case of multiple scattering, we observe that

$$[y_n y_m] = [y_n (y_n + (x_m - x_n)\theta_{y_n}] = [y_n^2] + (x_m - x_n)[y_n \theta_{y_n}]$$
(8.59)

for $x_m \ge x_n$. Now we make use of (8.49) and (8.50) and obtain

$$[y_n y_m] = \Theta_s^2 x_n^2 (3x_m - x_n) / 12.$$
(8.60)

Gluckstern [GLU 63] has evaluated the correlation coefficients at the first of N + 1 uniformly spaced wires with the result

$$[c^{2}]_{\rm MS} = \frac{\Theta_{\rm s}^{2}}{2L} C_{N} ,$$

$$\left[cb\left(\frac{1}{2}\right)\right]_{\rm MS} = -\frac{\Theta_{\rm s}^{2}}{2} D_{N} , \qquad (8.61)$$

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8.5 Spectrometer Resolution

N	C_N	D_N	E_N
2	1.33	0.167	0.167
3	1.25	0.125	0.154
4	1.25	0.124	0.160
5	1.26	0.132	0.167
9	1.31	0.156	0.187
infin.	1.43	0.214	0.229

Table 8.7 Values of the factors C_N , D_N and E_N in (8.61) for various values of N

$$\left[b^2\left(\frac{1}{2}\right)\right]_{\rm MS} = \frac{\Theta_{\rm s}^2}{2}LE_N \,.$$

The *N*-dependent coefficients are listed in Table 8.7.

Let us note that the measurement accuracy $\sqrt{[c^2]}$ for the curvature in this multiple-scattering-limited case is inversely proportional to the square-root of the length. Also, the variations of *b* and *c* are much more independent than they were in the measurement-limited case (8.32), because the ratio $D_N/\sqrt{(C_N E_N)}$ is relatively small.

The problem of optimal spacing and optimal weighting has been treated by Gluckstern [GLU 63] as well as by some other authors cited in his paper.

8.5 Spectrometer Resolution

Much of the effort of constructing precise drift chambers was for the goal of highresolution magnetic spectrometers. In this section we want to collect our results concerning the measurement errors of curvature and to express them in terms of momentum resolution. We are concerned with measurements inside a homogeneous magnetic field. There were two limiting cases, the one caused by measurement errors, in the absence of multiple scattering, and the other due to multiple scattering, with zero measurement errors.

8.5.1 Limit of Measurement Errors

We noted before that the variance $[c^2]$ of the curvature is a function of the track length L, the point-measuring accuracy ε , and the number N + 1 of wires, but it does not depend on the curvature itself. For uniform wire spacing we had (8.24)

$$[c^2] = \frac{\varepsilon^2}{L^4} A_N$$
 (A_N in Table 8.2)

and for wires with optimum spacing (8.34)

$$[c^2] = rac{arepsilon^2}{L^4} rac{256}{N+1} \; .$$

The track length is understood to be measured in a plane orthogonal to the magnetic field.

In order to calculate the momentum resolution, we use (8.9) and (8.11) and express the r.m.s. error $\delta(1/R) = \sqrt{[c^2]}$ as

$$\sqrt{[c^2]} = \delta \frac{1}{R} = eB\delta\left(\frac{1}{p_{\rm T}}\right) = -eB\frac{\delta p_{\rm T}}{p_{\rm T}^2} = \frac{-3}{10}\left(\frac{{\rm GeV/c}}{{\rm Tm}}\right)B\frac{\delta p_{\rm T}}{p_{\rm T}^2} \,. \tag{8.65}$$

Introducing θ , the angle between the momentum vector and the magnetic field, the transverse component $p_{\rm T}$ is given by

$$p_{\rm T} = p \sin \theta . \tag{8.66}$$

We drop the minus sign and write (8.65) as

$$\frac{\delta p}{p} = p \sin \theta \frac{10}{3} \left(\frac{\mathrm{Tm}}{\mathrm{GeV/c}} \right) \frac{1}{B} \sqrt{[c^2]} \,. \tag{8.67}$$

This formula shows that the spectrometer resolving power, expressed as a percentage of the measured momentum, deteriorates proportionally to p. This follows from the fact that $[c^2]$ is independent of c; it is also visible directly in the sagitta s(Sect. 8.2.3), whose size can be measured with less relative accuracy $\delta s/s$ as it shrinks with increasing momentum.

8.5.2 Limit of Multiple Scattering

In this case the variance $[c^2]$ depends on the track length *L*, the mean square scattering angle per unit length, Θ_s^2 , and very weakly on the number of measuring points. Θ_s^2 in turn is a function of the scattering material and of the βp of the particle. Using (8.51) and (8.61) we had for uniform wire spacing

$$[c^{2}]_{\rm MS} = \left(\frac{21\,{\rm MeV}}{\beta cp}\right)^{2} \frac{1}{X_{\rm rad}} \frac{C_{N}}{2L} \quad (C_{N}\,{\rm in}\,\,{\rm Table}\,8.7)\,. \tag{8.68}$$

L is the length the track has travelled in the medium and $[c^2]$ the variance of the total curvature. Only a projection on a plane perpendicular to the magnetic field can be confused with a curvature variation caused by a variation in momentum,

$$[c_{\rm proj}^2] = [c^2]_{\rm MS} / \sin^4 \theta , \qquad (8.69)$$

because the projected radius of curvature scales with the square of the projected length. It is $[c_{\text{proj}}^2]_{\text{MS}}$ to which (8.67) applies in the present case, and we find for the momentum resolution

References

$$\frac{\delta p}{p} = \frac{p}{\sin\theta} \frac{10}{3} \left(\frac{\mathrm{Tm}}{\mathrm{GeV}/c}\right) \frac{1}{B} \sqrt{[c^2]_{\mathrm{MS}}} .$$

$$= \frac{21(\mathrm{MeV}/c)}{\beta\sin\theta} \frac{10}{3} \left(\frac{\mathrm{Tm}}{\mathrm{GeV}/c}\right) \frac{1}{B} \sqrt{\frac{C_N}{2LX_{\mathrm{rad}}}} .$$
(8.70)

We see that the multiple-scattering limit of the momentum resolution is independent of momentum because, as p goes up, the decrease in bending power is compensated by the decrease in the scattering angle. According to (8.70), a muon traversing 1 m of magnetized iron (2T) at right angles to the field cannot be measured better than to 22%, even if there were infinitely many measuring points with infinite accuracy inside the iron. Depending on the apparatus, L will often be a function of the angle θ .

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Chapter 9 Ion Gates

Here we wish to take up the subject of ion shutters, which are sometimes placed in the drift space in order to block the passage of electrons or ions. In Chap. 3 we introduced such wire grids in the context of the electrostatics of drift chambers, stressing the relation between the various grids and electrodes that make up a drift chamber. So far we have dealt with the most straightforward type of gating grid, where all the wires are at the same potential.

For applications in large drift chambers there are more sophisticated forms of ion shutters which, in some modes of operation, have different transmission properties for electrons and for heavy ions.

We will begin this chapter by inspecting the conditions that make it necessary to involve gating grids (Sect. 9.1). Then we will survey various forms of gating grids that are in use in particle experiments (Sect. 9.2). Finally we compute values for the transparency under various conditions for which we make use of the results of Chap. 2 concerning ion drift velocities and the magnetic drift properties of electrons in gases.

9.1 Reasons for the Use of Ion Gates

9.1.1 Electric Charge in the Drift Region

Any free charges in the drift volume give rise to electric fields which superimpose themselves on the drift field and distort it. Chambers with long drift lengths L are particularly delicate, especially when they are operated with a low drift field. The displacement σ_x of an electron drift path at its arrival point is of the order of the drift length times the ratio of the disturbing field E_{dist} over the drift field E_{drift} :

$$\sigma_x = L \frac{E_{\text{dist}}}{E_{\text{drift}}} \,. \tag{9.1}$$

This holds if the disturbing field is orthogonal to the drift field, thus causing a displacement of the field lines to the side, but it also holds if the disturbing field acts in the same direction as the drift field, thus causing a change in the velocity and hence of the arrival time, provided the chamber works in the unsaturated mode of the drift velocity (cf. Chap. 12).

Free charges can originate as electrons or gas ions from the ionization in the drift volume, travelling in opposite directions according to their proper drift velocities, or they can be ions from the wire avalanches that have found their way into the drift region, where they move towards the negative high-voltage electrode. This last category contributes the largest part because for every incoming electron which causes *G* avalanche ions to be produced at the proportional wire, there will be *G* ε in the drift space, where ε is the fraction that arrives in the drift space rather than on the cathodes opposite the proportional wire. If there is no gating grid, *G* ε will be of the order of 10³ in typical conditions, but could also be larger (see remarks below).

In order to estimate the size of disturbing fields we consider two examples. The first is a drift chamber in which a gas discharge burns continuously between some sense wires and their cathodes. Such a self-sustained process could be caused by some surface deposit on the cathode, or otherwise. Let the total current be 1µA, and let $\varepsilon = 5\%$ of it penetrate into the drift volume. If the ion drift velocity there is 2 m/s, then the linear charge density in the column of travelling ions is $\lambda = 25 \times 10^{-9}$ A s/m. Using Gauss' theorem in this cylindrical geometry, the resulting radial field a distance *r* away amounts to

$$E_{\text{dist}} = \frac{\lambda}{2\pi r\varepsilon_0} = 450(V)\frac{1}{r} .$$
(9.2)

Here we have neglected the presence of any conductors.

The second example is the ALEPH TPC, irradiated by some ionizing radiation, say cosmic rays or background radiation from the e^+e^- collider. Let the rate density of electrons liberated in the sensitive volume be $R(s^{-1}m^{-3})$. For every electron, $G\varepsilon$ ions will appear in the drift space, where they travel with velocity v_D . Therefore the total charge density in the volume has the value.

$$\rho = \frac{eRLG\varepsilon}{v_{\rm D}} \,, \tag{9.3}$$

where *e* is the charge of the electron and *L* is the length of the drift volume. ρ could depend on the radius *r*, as one would expect from radiation originating along the beam. Let the TPC be approximated by the space between two infinite coaxial conducting cylinders with radii $r_1 = 0.3$ m and $r_2 = 2$ m, with the drift direction parallel to the common axis. The cylinders are grounded. The radial field E_r is calculated from Maxwell's equations,

$$\nabla E_r = \frac{1}{r} \frac{\partial}{\partial r} r E_r = \frac{\rho}{\varepsilon_0} , \qquad (9.4)$$

9.1 Reasons for the Use of Ion Gates

$$\int_{r_1}^{r_2} E_r \mathrm{d}r = 0$$

If $\rho(r) = \rho_0$ does not depend on *r*, as in the case of irradiation by cosmic rays, the resulting radial disturbing field takes the form

$$E_r(r) = \frac{\rho_0}{2\varepsilon_0} \left(r - \frac{1}{2r} \frac{r_2^2 - r_1^2}{\ln(r_2/r_1)} \right) \,. \tag{9.5}$$

If we insert into (9.3) values that are characteristic for the ALEPH TPC irradiated by cosmic rays at sea level ($R = 2 \times 10^6 \text{ s}^{-1} \text{m}^{-3}$, $v_D = 1.5 \text{ m/s}$, $G\varepsilon = 10^3$, L = 2 m), we find that $\rho_0 = 0.43 \times 10^{-9} \text{ A s m}^{-3}$. Figure 9.1 shows the radial field that results from (9.5) in this particular example. We notice that it is negative close to the inner field cage and positive close to the outer one. Compared to the regular axial drift field of 10^4 V/m , it amounts to a fraction of a per cent.

It should be mentioned that the coefficient ε is not very well known. A lower limit can be evaluated assuming that the amplification produced ions uniformly around the proportional wire. In this case ε is equal to the fraction of electric field lines that reach from the sense wire into the drift region. Using the formalism of Sect. 3.2 ε is equal to the ratio of the surface charge densities on the high-voltage plane and on the sense wire grid:

$$\varepsilon = \frac{|\sigma_{\rm p}|}{\sigma_{\rm s}} \,, \tag{9.6}$$

typically between 3 and 5%.

However, it is known that the amplification is not isotropic around the proportional wire. This has been discussed in Sect. 4.3. Large avalanches tend to go around the wire; small avalanches develop on the side where the electrons have arrived. The ions from the small avalanches may go into the drift space more efficiently. Nothing quantitative has been published concerning this question.



Some further uncertainty exists concerning the value of v_D . The effect of charge transfer between the travelling ions and any gas molecules of low ionization potential will substitute these molecules, which are often much slower, for the original ions; see Table 2.2. This effect creates a space charge that is not uniform in the drift direction.

The most important contribution to space charge is usually created by the background radiation at the accelerator. Background conditions can be very different from one experiment to the other. In the ALEPH TPC at LEP (sensitive volume 45 m³) the sense-wire current is ~ 0.5 μ A under standard operating conditions. The UA1 central detector at the CERN SppS (sensitive volume 25 m³) had a current of ~ 120 μ A at the peak luminosity of 3 × 10²⁹ cm⁻² s⁻¹ [BEI 88].

9.1.2 Ageing

There is experimental evidence of a deterioration in performance of drift and proportional chambers after they have been used for some time. Once the total charge collected on the anode wires during their lifetime exceeds some value between 10^{-4} and 1 C per cm of wire length, a loss of gain and excessive dark currents are observed in many chambers. Whereas a short account of this problem is given in Sect. 12.6, we mention it in the context of ion gates in order to underline their effect on the ageing process.

The dose mentioned above is the product of the incoming charge and the gain factor. The limit of observable deteriorations depend very much on the gas composition and on the electric field on the electrode surfaces; under carefully chosen conditions, a limiting dose of the order of 0.1 to 1 C/cm should be achievable. Some modern experiments even expect to achieve 10 C/cm (cf. Sect. 12.6). The ageing process can be stretched in time if only part of the radiation is admitted to the sense wires, using a gate that is triggered only on interesting events.

9.2 Survey of Field Configurations and Trigger Modes

In order to describe the various forms of gating grids employed in particle experiments we use two classifications, one according to drift paths on the basis of different (electric and magnetic) field configurations, the other according to the dynamical behaviour, i.e. how the gates are switched in connection with events in time.

9.2.1 Three Field Configurations

The simplest gate is the one which has all its wires at the same potential (*monopolar* gating grid). We have stated in Sect. 3.3 that it is closed to incoming electrons and outgoing ions if all the field lines terminate on it, provided the common potential is large enough and positive (Fig. 3.10b).

9.2 Survey of Field Configurations and Trigger Modes

There is a technical difficulty connected with this configuration: any transition from the closed to the open state must occur in a time interval ΔT comparable to the electron travel time over a distance small compared to the sensitive drift length, say $\Delta T \approx 1 \,\mu$ s or less. The charge brought onto the grid in this short time causes an enormous disturbance on the nearby sense wires, orders of magnitudes larger than a signal. One solution to this problem is the introduction of a 'shielding grid' between the gating grid and the anode [BRY 85].

Another way to circumvent this difficulty is to close the gating grid by ramping two opposite potentials $+\Delta V_g$ and $-\Delta V_g$ on neighbouring wires [BRE 80, NEM 83]. In this case the net amount of charge on the gating grid does not change, and in a first approximation there is no charge induced in the other electrodes of the drift chamber. This type of grid is called a *bipolar gating grid*. In the closed state it has positive charge on every second wire and negative charge on the wires in between; the drift field lines terminate on the positive charges.

In the presence of a magnetic field *B* the drift paths of electrons are no longer the electric field lines, because their drift-velocity vector has components along *B* and along $[E \times B]$ according to (2.6). The exact behaviour is governed by the parameter $\omega \tau$, or the ion mobility multiplied by the magnitude of the *B* field. This parameter is always very small for ions in drift chambers but can be much larger than one for electrons in suitable gases (cf. Chap. 2). If this is the case and ΔV_g is increased from zero, the ions are stopped first, while many of the electrons are still able to penetrate. The reason is the reduced electron mobility towards the gating grid wires. As ΔV_g is further increased, the gate is finally closed also for the electrons.

This *bipolar gating grid in a magnetic field*, with a suitable value of ΔV_g , can therefore be operated as a diode ([AME 85-1] and later but independently [KEN 84]). The electrons from the drift region make their way through the grid on trajectories which are bent in the wire direction as well as in the direction orthogonal to both the wires and the main drift direction. See Fig. 9.2 for an illustration of the principle.



Fig. 9.2 Scheme of the bipolar grid immersed in a magnetic field, which makes it transparent to electrons while it remains opaque to

ions

9.2.2 Three Trigger Modes

The simplest case is the bipolar gating grid operated in a magnetic field as a diode. It does not have to be triggered, and one avoids all switching circuitry and all pick-up problems. There is a disadvantage to this solution: although the positive ions from the wire avalanches are not admitted back into the drift space, all the electrons from the drift region are allowed to produce avalanches. Under conditions where chamber ageing is a problem, one gives away a factor of the lifetime of the chamber which depends on the background conditions of the experiment.

The tightest trigger is the one where some counters outside the drift chamber select the wanted event and open the gate by applying a (bipolar) voltage pulse to the grid in order to remove the closing potential(s). Depending on the time delay T_d between the moment of the event and the moment the gate has been opened, one loses a length *L* of sensitivity given by the electron drift velocity *u*:

$$L = T_{\rm d} u$$
.

This loss can sometimes be avoided at the expense of some background – if there is a regular time pattern when the events occur, even if they come with low probability. The ALEPH TPC at LEP is triggered 'open' a few μ s before every bunch crossing of the collider. When there is no event, the gate is switched back to 'closed'. In this way it is 'open' for 6μ s out of every 22μ s, but it stays 'open' long enough to read an event. This mode has been termed a *synchronous trigger*, to be contrasted with the *asynchronous trigger* described in the previous paragraph. The synchronous trigger also avoids the disturbance on the signal lines which remains large even with a bipolar gating grid, owing to small accidental asymmetries between neighbouring gating-grid wires.

9.3 Transparency under Various Operating Conditions

The transmission properties of a gate can be defined with respect to the incoming electrons. The electron transparency T_e is the ratio between the number of electrons traversing the grid and the number travelling towards it. In the absence of magnetic field, T_e is given by the corresponding ratio of the numbers of field lines. As a first example, we have calculated T_e in Chap. 3 for the monopolar gate as a function of the grid potential.

Similarly the ion transparency T_i is the fraction of ions traversing the grid, compared to all the ions travelling towards it. For the synchronous trigger mode we must also know $\langle T_i \rangle$, the time-averaged ion transparency.

In this section, computed and measured transparencies are presented for the static and for the synchronously pulsed bipolar gate, and for the bipolar gate in a magnetic field, operated as a diode. For the graphical representation of results and for the comparison with measurement we use a standardized system of electrodes according to Fig. 3.6 with wire positions as in the ALEPH TPC.

9.3.1 Transparency of the Static Bipolar Gate

In order to describe the problem it is convenient to define two surface charge densities, separating the contribution of the wires ramped at positive and negative ΔV_g . The (electron and ion) transparency is zero when the surface charge density of positive charges is equal in absolute value to the surface charge density on the high-voltage plane (or larger). The electric field configurations for full and for zero transparency are shown for our standard case in Fig. 9.3a,b.

To compute the potential difference ΔV_g needed to close the gating grid we first consider the situation in which both the high-voltage plane and the zero-grid plane are grounded. The general solution is then obtained by superimposing the solution calculated in Sect. 3.3 when a common voltage V_g is applied to the wires of the gating grid.

Using the formalism of Sect. 3.3 it can be shown that by applying ΔV_g to the wires of the gating grid we induce a positive charge on the wires at positive potential producing a positive surface charge density

$$\sigma_{\Delta}^{+} = \frac{-\varepsilon_{0}}{\frac{s_{3}}{\pi} \ln \frac{\pi r_{g}}{2s_{3}}} \Delta V_{g} \,. \tag{9.7}$$



Fig. 9.3a,b Electric field configuration in the standard case with the bipolar gating grid. (a) gate open, (b) gate closed

The wires at negative potential contribute to a negative surface charge density

$$\sigma_{\Delta}^{-} = -\sigma_{\Delta}^{+} , \qquad (9.8)$$

and the total charge variation on the gating grid is 0.

This solution can be superimposed on the one calculated in Sect. 3.3.1 since it has the same boundary conditions. The total surface charge density of the wires at potential $V_g + \Delta V_g$ is

$$\sigma_{\Delta}^{+} + \frac{\sigma_{\rm g}}{2} , \qquad (9.9)$$

where σ_g is computed using (3.2.2).

When $\sigma_{\Lambda}^{+} + \hat{\sigma_g}/2$ is positive the transparency of the gating grid is given by

$$T = 1 - \frac{\sigma_{\Delta}^{+} + \sigma_{\rm g}/2}{|\sigma_{\rm p}|} \,. \tag{9.10}$$

Only half of the wires of the gating grid contribute to the positive density. This explains the factor 2 of (9.10). Formula (9.10) has been tested experimentally using a chamber with wires arranged as shown in Fig. 3.6. We depict in Fig. 9.4a,b the calculated and measured electron transparencies as functions of ΔV_g . There is perfect agreement except for the large values of ΔV_g where the gate was found not to be as opaque as calculated, probably because of diffusion, which was omitted in the calculation.

The conditions for a closed grid are

$$\sigma_{\Delta}^{+} + \frac{\sigma_{\rm g}}{2} > |\sigma_{\rm p}| = \varepsilon_0 E , \qquad (9.11)$$

where E is the drift field.



Fig. 9.4a,b Electron transparency *T* (here called T_e) of a gating grid with 2 mm pitch, as a function of the voltage difference ΔV_g applied to adjacent wires. The points are measurements by [AME 85-1]; the line is a calculation according to (9.10)

9.3 Transparency under Various Operating Conditions

When σ_g has the limiting value for the 'full transparency' condition (see 3.51) we obtain

$$\sigma_{\Delta}^{+} > \varepsilon_0 E \left(1 + 2\pi \frac{r_{\rm g}}{s_3} \right) \,. \tag{9.12}$$

In the general case, using (3.53), (9.7) and (9.11) one can calculate the minimum ΔV_g needed to close the grid:

$$\Delta V_{\rm g} > -\frac{s_3}{\pi} \ln\left(\frac{\pi r_{\rm g}}{2s_3}\right) \left(E - \frac{E(z_3 - z_2) + V_{\rm g} - V_z}{2\left(z_3 - z_2 - \frac{s_3}{2\pi} \ln\frac{2\pi r_{\rm g}}{s_3}\right)} \right) \,. \tag{9.13}$$

Figure 9.5a-d shows how the electric field lines are organized around the bipolar gate as the differential voltage ΔV_g is increased. We notice that for small ΔV_g the grid is partly transparent and that for larger ΔV_g the field lines from the drift region end on the wires of the gating grid. The configuration of Fig. 9.5a-db is the case where the gate is just closed. It has field lines from the two regions in close proximity, so that diffusion will allow a small fraction of electrons to traverse the grid. This is not the case in Fig. 9.5a-dc and d, where the gate is more firmly closed.

9.3.2 Average Transparency of the Regularly Pulsed Bipolar Gate

The passage of a drifting electron or ion through a gate requires some time. This time is much longer for ions than for electrons because of their smaller drift velocity u.



Fig. 9.5a-d Electric field lines near the gating grid for different values of $\Delta V_g. E_{drift} = 110 \text{ V/cm}$ and $V_g = -70 \text{ V}$ throughout. (a) $\Delta V_g = 30 \text{ V}$, (b) $\Delta V_g = 45 \text{ V}$, (c) $\Delta V_g = 100 \text{ V}$, (d) $\Delta V_g = 200 \text{ V}$



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Fig. 9.6 Regular switching of the bipolar grid at a frequency $f \Delta T$ is the 'open' time

Since the field region across a bipolar grid extends over some fraction of the pitch *s* (see Fig. 9.5a-d) we may estimate the time to cross the gate to be roughly

$$\tau = s/u , \qquad (9.14)$$

say between 10 and 1000 μ s for ions and three orders of magnitude less for electrons.

A bipolar grid can be operated at a frequency f by switching the closing voltage $\pm \Delta V_g$ during some part of every cycle so that it is 'open' for the remaining time $\Delta t (\Delta t < 1/f)$; the switching is schematized in Fig. 9.6.

If $\tau < \Delta t$, the grid can be traversed in one cycle, and the average transparency is

$$\langle T \rangle \sim f \Delta t$$
 . (9.15)

When $\tau \gg \Delta t$, many cycles are needed to traverse the grid. The electric field changes many times while the ions are near the grid, and they follow a path that alters its direction with the variation of the electric field; see Fig. 9.7 for an illustration. Each cycle, during the 'closed' condition, the ion makes a step towards the gate wire at lower potential, and under favourable conditions it reaches the wire and is absorbed.

For an accurate computation of the transparency we would have to follow the relevant field lines at every step. But we are satisfied with an order-of-magnitude



Fig. 9.7 Sketch of the ion path near the gating grid pulsed at some frequency

calculation, which will exhibit the main variables and their influence on the average ion transparency.

We call the effective depth of the grid S – it will be some fraction of the pitch s – and we assume that the drift field E_d acts all the time whereas the transverse field E_x between the wires of the gating grid acts only during the time the gate is closed.

Assuming that an ion needs n cycles for the traversal of the grid,

$$n = \frac{Sf}{v_x} , \qquad (9.16)$$

it is absorbed if

$$x_0 < n\left(\frac{1}{f} - \Delta t\right) v_x \,. \tag{9.17}$$

Here v_z and v_x are the two components of the drift velocity and x_0 is the initial transverse distance of the ion from the closest gating wire at lower potential (see Fig. 9.7).

The transparency is zero if

$$s < \frac{S}{v_z} f\left(\frac{1}{f} - \Delta t\right) v_x , \qquad (9.18)$$

where *s* is the pitch of the gating grid.

We can calculate the transparency in the general case assuming that the ions are uniformly distributed along x when they reach the region of the gating grid. Using (9.16) and (9.17) we obtain

$$\langle T \rangle = 1 - \frac{S}{s} \frac{v_x}{v_z} (1 - f\Delta t) . \qquad (9.19)$$

Since the drift velocity of the ions is proportional to the electric field, the ratio between its components can be replaced by the ratio between the components of the electric field. The *z* component of the electric field is the drift field E_d and the *x* component can be approximated by $2\Delta V_g/s$. We obtain for the time-averaged ion transparency

$$\langle T \rangle = 1 - \frac{S}{s} \frac{2\Delta V_g}{sE_d} (1 - f\Delta t) . \qquad (9.20)$$

Equation (9.20) shows that within the limits of our very coarse approximations, the average transparency is a linear function of ΔV_g and the frequency *f*. This is also borne out by experiment: in Figs. 9.8 and 9.9 we see the result of measurements [AME 85-2] made with a gating grid operating under conditions similar to those of the ALEPH TPC. Formula (9.20) describes both curves quite well with values of *S*/*s* between 0.4 and 0.5.



 $\Delta V(V)$

9.3.3 Transparency of the Static Bipolar Gate in a Transverse Magnetic Field

A magnetic field along the main drift direction z changes the path of the electrons according to the parameter $\omega \tau$; see (2.6). The components u_x of the drift velocity perpendicular to the magnetic field and perpendicular to the grid wires is reduced by the factor $1 + \omega^2 \tau^2$, whereas the drift velocity u_z in the main direction stays the same:

$$u_x = \frac{1}{1 + \omega^2 \tau^2} \mu E_x ,$$

$$u_z = \mu E_z .$$
(9.21)



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Here μ is the electron mobility. We see that there is a strong influence of the magnetic field on the operation of the bipolar gate – it is closed at much higher values of ΔV_g , since the relevant drift-velocity component u_x , which moves the electrons towards the wires of the grid, is reduced.

We can construct the drift trajectories when we know the behaviour of $\omega \tau$ with the electric field strength *E*. This could be calculated according to the principles discussed in Sect. 2.2.3. But for our example we simply use

$$\begin{aligned} &\omega\tau=6(T^{-1})B \quad \text{for} \quad E<100\,\text{V/cm}\,,\\ &\omega\tau=6(T^{-1})B100(\text{V/cm})/E \quad \text{for} \quad E>100\,\text{V/cm} \end{aligned}$$

Figure 9.10a-d shows the electron drift lines in the x-z plane for a number of conditions. The electron transparency is computed counting the fraction of drift velocity lines that cross the grid. Comparing Figs. 9.10a-da and b, one observes that the magnetic field of 1.5 T changed the transparency from zero to about 80%.

Figure 9.11 displays the measured electron transparency of a gating grid with a pitch of 2 mm in a drift field of 100 V/cm for different values of the magnetic field [AME 85-1]. One observes that the closing voltage goes up roughly linearly with the magnetic field.

Displacement of the Electrons along the Wire Direction. The electrons cross the gating grid in the presence of a component (x) of the electric field perpendicular to the magnetic field. Owing to the $E \times B$ term of the drift-velocity equation (2.6)



Fig. 9.10a-d Electron trajectories approaching the grid from the drift region. E = 110 V/cm. (a) $\Delta V_g = 45$ V, B = 0, (b) $\Delta V_g = 45$ V, B = 1.5 T, (c) $\Delta V_g = 70$ V, B = 1.5 T, (d) $\Delta V_g = 200$ V, B = 1.5 T

Fig. 9.11 Electron transparency vs. ΔV_g (here called ΔV) for various magnetic fields, as measured by [AME 85-1]. The lines are drawn to guide the eye. The two squares show the result of calculations according to Sect. 9.3.3



they are also displaced along the direction (y) parallel to the wires of the grid. The component of the drift velocity along the wire direction is

$$u_y = \frac{\omega \tau}{1 + \omega^2 \tau^2} \mu E_x \, .$$

This effect is similar to the displacement of the electrons along the sensewire direction when they approach the sense wire from the zero-grid region (see Sect. 7.3.1).

Figure 9.5a-db shows the electric field lines in the region of the gating grid when the grid is closed for the ions (but not for the electrons if a strong magnetic field is present). The electric field is roughly constant between two sides of the grid, and its *x* component changes sign on the two sides of the same wire. All the electrons that cross the grid on the same side of a given wire are displaced along *y* in the same direction and roughly by the same amount; all the others that pass on the other side are displaced by the same amount but in the opposite direction. This displacement can be of the order of fractions of a millimetre and depends on ΔV_g , on the magnetic field and on the gas mixture.

The distribution of the arrival point of the electrons on the sense wire is modified. This effect influences the spatial resolution in a similar way as the $E \times B$ effect at the sense wire.

If the pitch of the gating grid and the sense-field grid are the same, it is possible to choose the sign of ΔV_g in such a way that the y displacement at the gating grid has sign opposite to the y displacement at the sense wire [AME 86]. In this case there is a compensation of the overall $E \times B$ effect with a possible benefit to the spatial resolution; nothing quantitative has appeared in the literature.

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Chapter 10 Particle Identification by Measurement of Ionization

Among the track parameters, the ionization plays a special role because it is a function of the particle velocity, which can therefore be indirectly determined through a measurement of the amount of ionization along a track. For relativistic particles this dependence is not very strong, and therefore the amount of ionization must be measured accurately in order to be useful. The ionization has a very broad distribution, and a track has to be measured on many segments (several tens to a few hundred) in order to reach the accuracy required. Fortunately only relative values of the ionization need to be known between tracks of different velocities.

Whereas in Chap. 1 we dealt with the ionization phenomenon in general terms, the present chapter is devoted to a discussion of those aspects of ionization that are important for particle identification. After an explanation of the principle we elaborate on the factors that determine the shape of the ionization curve, and the achievable accuracy. Calculated and measured particle separation powers are discussed next. One section is devoted to cluster counting. Finally, the problems encountered in practical devices are reviewed.

10.1 Principles

In a magnetic spectrometer one measures the particle momentum through the curvature of its track in the magnetic field. If a measurement of ionization is performed on this track, there is the possibility of determining the particle mass, thus identifying the particle. The relation between momentum p and velocity v involves the mass m:

$$v = c^2 p/E = c^2 p/\sqrt{(p^2 c^2 + m^2 c^4)},$$
 (10.1)

where c is the velocity of light.

Any quantification of ionization involves the peculiar statistics of the ionization process. Let us recapitulate from Chap. 1 that the distribution function of the number of electrons produced on a given track length has such a tail towards large numbers that neither a proper mean nor a proper variance exists for the number of electrons.

In order to characterize the distribution one may quote its most probable value and its width at half-maximum. The most probable number of electrons may be taken to represent the 'strength' of the ionization. It is *not* proportional to the length of the track segment. (We have seen in Figs. 1.10 and 1.11 how the most probable value of the ionization per unit length goes up with the gas sample length.) From a number of pulse-height measurements on one track one derives some measure I of the strength of the ionization; details are given in Sect. 10.3. Since I depends on the velocity of the particle and is proportional to the square of the charge Ze of the particle, we write

$$I = Z^2 F_{g,m}(v) \,. \tag{10.2}$$

 $F_{g,m}(v)$ depends, firstly, on the nature of the gas mixture and its density (index g). But it depends also on the length and number of samples and on the exact way in which the ionization of the track is calculated from the ionization of the different samples (index *m*); in addition, there is the small dependence of the relativistic rise on the sample size. If we divide $F_{g,m}(v)$ by its minimal value (at v_{\min}), we obtain a normalized curve

$$F_{g,m}^{(\text{norm})}(v) = F_{g,m}(v) / F_{g,m}(v_{\min}).$$
(10.3)

It turns out that this curve is approximately independent of the exact manner of the ionization measurement:

$$F_{g,m}^{(\text{norm})}(v) \approx F_{g}(v).$$
(10.4)

(Some qualifications are mentioned in the end of Sect. 10.8.1) Most analyses of the ionization loss have been done with this approximation, i.e. one neglects any variation of the relativistic rise on the sample size and works with one universal normalized curve.

Figure 1.19 contained theoretical values for the most probable ionization in argon, as well as experimental values of the truncated mean in argon-methane mixtures. The abscissa is the logarithm of $\beta \gamma(\beta = v/c, \gamma^2 = 1/(1 - \beta^2))$, and the vertical scale is normalized to the value in the minimum.

One cannot resolve (10.1), (10.2) and (10.4) into a form m = m(I, p) because $F_g(v)$ is not monotonic. Therefore we discuss particle identification by plotting $F_g(v)$ for various known charged particles as a function of p. Using the argon curve of Fig. 1.19 we obtain the family of curves shown in Fig. 10.1. We see five curves of identical shape, for electrons, muons, pions, kaons, and protons; they are displaced with respect to each other on the logarithmic scale by the logarithms of the particle mass ratios.

The simultaneous measurement of the momentum and the ionization of a particle results in a point in the diagram of Fig. 10.1. Complete particle identification takes place if, inside the measurement errors, this point can be associated with only one curve. In practice the measurement errors of the ionization are very often so large that several particles could have caused the measured ionization; if this is the case it may be possible to exclude one or more particles.

For good particle identification the measurement accuracy δI is obviously as essential as the vertical distance between the curves in Fig. 10.1. It is therefore our first task to review the gas conditions responsible for the shape of the curve and



Fig. 10.1 Most probable values of the ionization (normalized to the minimum value) in argon at ordinary density as function of the momenta of the known stable charged particles

in particular for the amount of the relativistic rise. Then we have to understand the circumstances that have an influence on δI , and which value of δI can be reached in a given apparatus. The ratio of the accuracy over the relativistic rise characterizes the particle separation power.

But before going into these details let us make an estimate of what we can expect from this method of particle identification. Imagine some drift chamber with a relative accuracy of $\delta I/I = 12\%$ FWHM (5% r.m.s.). If we assume that a respectable degree of identification is already achievable on a curve that is only twice this r.m.s. value away from any other one, if we remove the muon curve (because it is hopelessly close to the pion curve and because muons can be well identified with other methods), and if, finally, we assume that the error of the momentum measurement is negligible, then we can redraw those branches of the curves in Fig. 10.1 that would allow a respectable degree of particle identification in argon. The result is seen in Fig. 10.2.

Under the assumed circumstances, these particles could be identified in the ranges shown in Table 10.1. It is characteristic of the complicated shape of the ionization curve that there are certain bands of overlap in which unique identification is impossible. A useful separation between kaons and protons at high momenta would require the measurement accuracy for the ionization to be $\delta I/I = 8.5\%$ FWHM or better (in argon at normal density). Such values have actually been attained by specialized particle identifiers, see Sect. 10.8.

After having described the principle of particle identification based on the *amount of ionization* along a given length of track we should also mention the possibility based on the *frequency of ionization* along the track. If we were to count the



Table 10.1 Momentum ranges above 0.1 GeV/*c* for a 2 σ identification of particles in argon (normal density), for two measuring accuracies of the ionization (µ's removed)

Particle	Momentum ranges (GeV/c)					
$\delta I/I = 5\%$ r.m.s.						
e	0.17-0.4	0.6-0.8	1.3–19			
π	(0.1)-0.12	0.16-0.8	2.7-19			
K	(0.1)-0.4	0.6-0.8				
р	(0.1)-0.8	1.1-1.5				
$\delta I/I = 3.5\%$ r.m.s.						
e	0.16-0.5	0.6-0.9	1.1-30			
π	(0.1)-0.13	0.16-0.9	2.2-30			
K	(0.1)-0.5	0.6-0.9	6–46			
p	(0.1)-0.9	1.1–1.5	6–46			

number of ionization clusters rather than the amount of ionization on some track length, there would be a profit in the statistical accuracy. A brief description of this interesting method is given in Sect. 10.6.

Much easier than the identification of the known particles would be the recognition of a stable quark with charge e/3 or 2e/3, because it would create only 1/9 or 4/9 of the normal ionization density. Quarks aside, one recognizes that relatively small differences in $\delta I/I$ may be decisive for particle identification. Therefore we must study in some detail how the shape of the ionization curve and the achievable accuracy depend on the parameters of the drift chamber.

10.2 Shape of the Ionization Curve

We recall from Chap. 1 that the curve reaches its minimum near $\beta \gamma = 4$. The shape of a curve that has been normalized to this minimum is characterized by the height of the plateau ('amount of relativistic rise', *R*, above the minimum) and by the value

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Gas	<i>R</i> (% of min. value)		W ₆₆	S at 4 GeV/c			<i>S</i> at 20 GeV/ <i>c</i>			
	Peak	lower	upper	(% FWHM)	e-π	π –K	К–р	e-π	π –K	К–р
Не	58	86	45	15	1.5	0.9	0.3	0.3	0.9	0.5
Ne	57	72	57	13	1.8	1.1	0.4	0.6	1.1	0.6
Ar	57	66	49	12	1.6	1.1	0.4	0.6	0.9	0.6
Kr	63	65	61	11	2.2	1.3	0.5	0.9	1.1	0.7
Xe	67	76	64	13	2.2	1.2	0.4	1.0	1.0	0.6
N_2	56	59	48	11	1.8	1.3	0.4	0.7	1.0	0.7
O ₂	54	54	47	9	2.0	1.5	0.5	0.7	1.1	0.8
CO_2	48	52	41	8	2.0	1.6	0.5	0.6	1.1	0.9
CH_4	43	45	39	9	1.6	1.5	0.5	0.5	1.0	0.8
C_2H_4	42	46	38	8	1.7	1.5	0.5	0.6	1.0	0.8
C_2H_6	38	41	34	8	1.6	1.6	0.5	-	-	-
$C_{4}H_{10}$	23	24	21	6	1.8	1.3	0.3	0.6	1.0	0.8
$80\% \ \mathrm{Ar^+}$	55	62	48	12	1.9	1.2	0.4	_	_	_
20% CO ₂										

Table 10.2 Performance of different gases according to calculations with the PAI model [ALL 82]. A track of 1 m length, sampled in 66 layers of 1.5 cm is assumed. See text for explanation

of the relativistic velocity factor, γ^* , at which the plateau is reached. Both numbers depend on the gas and its density as well as the sample length. In Table 10.2 (Sect. 10.5) we find relativistic rise values calculated by Allison [ALL 82] for various gases at normal density and 1.5-cm-long samples. One observes that *R* is highest for the noble gases and much lower for some hydrocarbons.

The density dependence is contained in the logarithmic term (1.59) and was demonstrated in Fig. 1.20. The curve of Fig. 10.3 shows how the relativistic rise of argon goes down as the density increases. Measured ionization ratios for particles with 15 GeV/*c* momentum are contained in Fig. 10.4. All these data show that the relativistic rise becomes better (higher) as the gas density is decreased and as one passes from smaller to larger atomic numbers of the elements that make up the gas.

The small influence of the sample length on the relativistic rise of argon is displayed in Fig. 10.5. The relativistic rise goes down from 57 to 53% as the sample length increases from 1.5 to 25 cm at one bar.

Fig. 10.3 Calculated variation of the relativistic rise R of the most probable ionization with the gas density (pressure p at constant temperature) [ALL 82]







In a particle experiment, a determination of the ionization as a function of the particle velocity is done with identified particles over a range of momenta. Once the function is established it can be used for the identification of other particles. For this purpose it would be useful to have a mathematical description of the ionization curve. Neither the theory of Bethe, Bloch, and Sternheimer nor the model of Allison and Cobb offer a closed mathematical form. Fits have sometimes been based on (1.66) and a piecewise parametrization of the quantity δ , using five or more parameters for $\delta(\beta)$. Hauschild et al. have found it possible to work with only two free parameters for $\delta(\beta)$ and with a total of four for a description of their data [HAU 91]. – We have sometimes used the following form for a description of measured ionization curves:

$$F_{\rm g}(v) = \frac{p_1}{\beta^{p_4}} \left\{ p_2 - \beta^{p_4} - \ln\left[p_3 + \left(\frac{1}{\beta\gamma}\right)^{p_5}\right] \right\},\tag{10.5}$$

where $\beta = v/c$, $\gamma^2 = 1/(1 - \beta^2)$, and the p_i are five free parameters. Equation (10.5) is a generalization of (1.56), valid in the model of Allison and Cobb for each transferred energy. Figure 10.6 shows four examples of fits to this form.



Fig. 10.5 Calculated variation of the relativistic rise as a function of the gas sample length for argon at normal density [ALL 82]

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Fig. 10.6 Four different measurements of the normalized ionization strength I/I_{min} fitted to the five-parameter form (10.5) [ASS 91]. (a) Data in Ar + CH₄ (various small concentrations up to 10%) at 1 bar, combined from [LEH 78], [LEH 82] and ALEPH data (unpublished). (b) Data in Ar(90%) + CH₄(10%) at 1 bar [WAL 79a]. (c) Data in Ar(80%) + CH₄(20%) at 8.5 bar [COW 88]. (d) Data in Ar(91%) + CH₄(9%) at 1 bar [ALE 91]. A truncated mean was used in all cases to measure *I*

10.3 Statistical Treatment of the *n* Ionization Samples of One Track

The ionization measurements in the various cells, which we imagine to be of equal size, are usually entirely independent – the transport of ionization from one cell to its neighbour caused by the rare forward-going delta rays can be neglected, and we exclude the effect of diffusion or electric cross-talk between neighbouring cells. With each well-measured track we obtain n electronic signals which, up to a

common constant, represent n sample values of the ionization distribution in a cell. The task is to derive from them a suitable estimator for the strength of the ionization in the cell.

The most straightforward, the average of all n values, is a bad estimator which fluctuates a lot from track to track, because the underlying mathematical ionization distribution has no finite average and no finite variance (see (1.33). A good estimator is either derived from a fit to the shape of the measured distribution or from a subsample excluding the very high measured values.

In many cases one knows the shape of the signal distribution, f(S)dS, up to a scale parameter λ that characterizes the ionization strength. The *n* signals S_1, \ldots, S_n are to be used for a determination of λ . Let λ be fixed to 1 for the normalized reference distribution $f_1(S)dS$. Then there is a family of normalized distributions

$$f_{\lambda}(S) dS = (1/\lambda) f_1(S/\lambda) dS, \qquad (10.6)$$

and one must find out which curve fits best the *n* signal values. The most efficient method to achieve this is the maximum-likelihood method. It requires one to maximize with respect to λ the likelihood function

$$\mathscr{L} = \prod_{i} (1/\lambda) f_1(S_i/\lambda), \qquad (10.7)$$

where the product runs over all *n* samples. The result is a λ_0 and its error $\delta\lambda_0$. One may take λ to represent the most probable signal of the distribution; then $\lambda_0 \pm \delta\lambda_0$ is the most probable signal measured for the track at hand.

So far, it has been assumed that the shape of the ionization curve is the same (at a given gas length) for all ionization strengths, i.e. particle velocities. For very small gas lengths this is not really true (see Fig. 1.21). In this case one needs a table of different curves rather than the simple family (10.6). The rest goes as before.

For a general treatment of parameter estimation, the likelihood method, or the concept of efficiency, the reader is referred to a textbook on statistics, e.g. Cramér [CRA 51] or Fisz [FIS 58] or Eadie et al. [EAD 71].

If one does not know the shape of the signal distribution beforehand, one may use a simplified method, the method of "the truncated mean". It is characterized by a cut-off parameter η between 0 and 1. The estimator $\langle S \rangle_{\eta}$ for the signal strength is the average of the ηn lowest values among the *n* signals S_i :

$$\langle S \rangle_{\eta} = \frac{1}{m} \sum_{1}^{m} S_j,$$

where *m* is the integer closest to ηn , and the sum extends over the lowest *m* elements of the ordered full sample $(S_j \leq S_{j+1} \text{ for all } j = 1, ..., n-1)$. The quantity that matters is the fluctuation of $\langle S \rangle_{\eta}$ divided by its value; if for a typical ionization distribution one simulates with the Monte Carlo method the measurement of many tracks in order to determine the best η , one finds a shallow minimum of this quantity as a function of η between 0.35 and 0.75. In this range of η it is an empirical fact that the values of $\langle S \rangle_{\eta}$ are distributed almost like a Gaussian. In many practical experiments the method of the truncated mean was the method of choice, because of its simplicity and because the likelihood method had not given recognizably better results. From a theoretical point of view, the likelihood method should be the best as it makes use of all the available information.

Whatever the exact form of the estimator, we assume that it is a measure of the amount of ionization, which obeys (10.2), and that the approximation (10.4) is sufficiently well fulfilled for a practical analysis.

10.4 Accuracy of the Ionization Measurement

We have to understand how the accuracy of the ionization measurement of one track varies with its length *L* and the number *n* of samples, with the nature of the gas and with its pressure *p*. Since the distribution in a given gap with length x = L/n depends only on the cluster-size distribution and on the number of primary interactions in the gap, the ionization distribution varies with the density (or pressure at constant temperature) in the same way as it does with *x*, and therefore the width *W* of the distribution depends on *x* and *p* through their product *xp*. The relative accuracy will therefore be of the form

$$\frac{\delta I}{I} = f(xp, n, \text{gas}) \text{ or } g(Lp, n, \text{gas})$$

10.4.1 Variation with n and x

If a track of length *L* is sampled on *n* small pieces of length *x*, we may expect that the accuracy δI_{mp} in the determination of the most probable-value improves when we increase *n* and *L*, keeping *x* fixed. Different values of *n* may arise for tracks in one event, depending on the number of samples lost because of overlapping tracks. If the basic distribution of the ionization gathered in one piece *x* were well behaved in the sense of having a mean and a variance – a prerequisite for an application of the central-limit theorem of statistics – then the accuracy would become better with increasing *n* and *L* according to the law $\delta I_{mp} \sim 1/\sqrt{n}$ in the limit of large *n*. It turns out that with the very special cluster-size distribution of Chap. 1 the gain is more like $n^{-0.46}$ for practical values of *n* when dealing with a maximum-likelihood fit for the most probable value [ALL 80]. Walenta and co-workers obtained $n^{-0.43}$ when dealing with the average $\langle I \rangle_{40}$ of the lowest 40% [WAL 79]. The differences in the exponent seem to be small but they count for large *n*! In any event one deals here with empirical relations that have not been justified on mathematical grounds.

If we vary L and x simultaneously, keeping n fixed, we must consider how the width of the ionization distribution changes with the size x of the individual sample. The variation of L and x at constant n could be produced by increasing the gas pressure in a suitable multiwire drift chamber.

As the gap is made larger, W decreases. This has been treated in Chap. 1 (see the discussion around (1.37) and Fig. 1.10). The experiments suggest a power behaviour of the relative width W on a single gap, which varies like

$$(W/I_{\rm mp})_1 : (W/I_{\rm mp})_2 = [(px)_1 : (px)_2]^k = [(pL)_1 : (pL)_2]^k$$
(10.8)

 $(I_{\rm mp} = \text{most probable ionization})$. Based on the PAI model and supported by experimental data one finds that k = -0.32 [ALL 80].

Next we keep the length L = nx fixed and increase *n*, reducing *x*. Now there is a net gain in the accuracy δI proportional to

$$n^{-0.14}$$
 or $n^{-0.11}$

because the better accuracy from the increase of n is partly offset by the worsening from the decrease in x.

Although there is agreement between the different authors about these facts, they disagree about the question down to what subdivision this rule holds. Whereas Allison and Cobb, on the basis of their theory and in accordance with the above, recommend sampling the ionization as finely as possible [ALL 80], Walenta suggests that below 5 cm bar in argon the improvement is negligible [WAL 79]. Lehraus et al., from a more practical point of view, argue similarly [LEH 82a]. It must be said that, at the time, such fine samples had not been systematically explored. More recently the ALEPH and the DELPHI TPCs, working at normal gas density and with 4 mm sense-wire spacing, sample remarkably thin gas layers. Figure 10.7 shows an ALEPH study [ASS 90] in which lepton tracks from e^+e^- interactions were analyzed by adding the signals from neighbouring sense wires, thus varying *n* and *x* at fixed *L*. Though not quite reaching the theoretical prediction (see below), the measured accuracy as a function of *n* lends some support to the idea that fine subdivisions down to half a cm bar may still increase the accuracy.

10.4.2 Variation with the Particle Velocity

We have seen how the single-gap width W is reduced by multiple measurements. The value of W itself results from the summation over the cluster-size distribution

Fig. 10.7 Ionization resolution at constant track length as a function of the sample length. *Crosses*: measured in the ALEPH-TPC (average track length 140 cm, argon (91%) + methane (9%) at 1 bar, diffusion < 1.4 mm r.m.s.). *Line*: prediction of Allison and Cobb, our (10.9)



10.4 Accuracy of the Ionization Measurement



(see Sect. 1.2.4). Does *W* depend on the particle velocity? This must be suspected, because the number of primary interactions does, and so does the cluster-size distribution, although only very weakly. In the PAI model also this detail has been computed. We see in Fig. 10.8 the dependence of the relative width W/I_{mp} on the relativistic velocity factor $\beta\gamma$, which reflects the characteristic shape of the ionization curve. In the example at hand, which is 1.6 cm of argon, W/I_{mp} oscillates inside a narrow band of $(80 \pm 7)\%$ as $\beta\gamma$ increases from 1 to the plateau. One concludes that the velocity dependence of the relative width can usually be neglected in this range.

10.4.3 Variation with the Gas

We finally have to involve the properties of the gas itself; they will determine the absolute scale of the accuracy $\delta I/I$ when px and n are specified. The pulse-height distributions of many gases have been measured in single and multiple gaps. From the work of the Lehraus group [LEH 82b] we present in Fig. 10.9 a compilation of measured single-gap ionization widths of various gases at different densities. It turns out that the noble gases have wider distributions than the organic molecular gases.

With the PAI model, Allison and Cobb calculate for argon ([ALL 80], equation 4.3) a value which represents some average over the particle velocities:

$$\delta I_{\rm mp}/I_{\rm mp} = 0.96 n^{-0.46} (px)^{-0.32}$$
 (FWHM). (10.9)

A systematic comparison between different gases is possible using the dimensionless scaling variable

$$\xi/I = 2\pi N r_{\rm e}^2 m c^2 x / (\beta^2 I) \,. \tag{10.10}$$

We have encountered the variable ξ with the dimension of an energy, as the main factor in the Bethe–Bloch formula (1.65) determining the energy lost in the gas thickness x, to be multiplied only by a β -dependent factor of the order of unity. (N = electron density, $r_{\rm e}$ = classical electron radius = 2.82 fm,



Fig. 10.9 Single-gap resolution measured for various gases and pressures [LEH 82b] as a function of the product of pressure p and sample length x

 mc^2 = rest energy of the electron, β = particle velocity in units of the velocity of light.) We have also met the variable ξ as the scaling factor (1.49) in the Landau distribution.

The mean ionization potential *I* is the only constant in the Bethe–Bloch formula that characterizes the gas; see Table 1.3. The ratio ξ/I will be roughly proportional to the number of electrons liberated over the distance *x*, and therefore it is plausible that it might serve in a comparison of accuracies $\delta I/I$. For $\beta = 1$ and gas layers of 1 cm, ξ/I takes on the values 0.32, 0.50, 0.62, 0.65, and 0.70 for the noble gases He, Ne, Ar, Kr, and Xe at N.T.P., respectively.

From the work of Ermilova, Kotenko and Merzon [ERM 77], Fig. 10.10 contains calculated values of the width of the ionization distribution in a single gap, for various noble gases, plotted as a function of the ratio ξ/I . The full width at half maximum is expressed in units of ξ . We notice that the points of the different gases and sample lengths x fall roughly on one universal curve, which only depends on ξ/I . We also notice that for ξ/I near 1 the theoretical predictions for the width of Landau and Blunck–Leisegang (see Sect. 1.2.5) differ by half an order of magni-

.



Fig. 10.10 The widths of the ionization distributions in units of ξ for the noble gases, calculated for various sample lengths by Ermilova et al., plotted as a function of ξ/I (10.10) [ERM 77]. The points calculated by a Monte Carlo method follow a universal dependence of ξ/I

tude; on the other hand, the Monte Carlo calculation of Ermilova et al., which is very similar to the subsequent PAI model, accurately predicts the measured widths. The three calculations and the experimental points fall generally together only for ratios ξ/I larger than about 50.

Using the universal variable ξ/I Allison and Cobb generalized relation (10.9) for all gases:

$$\delta I_{\rm mp}/I_{\rm mp} = 0.81 n^{-0.46} (\xi/I)^{-0.32}$$
 (FWHM). (10.11)

It should be emphasized that this formula has not yet been tested experimentally in a systematic comparison between different gases. The value of the constant is equal to the value of $0.96(\xi/I)^{0.32}$ for 1 cm of argon.

In (10.11) the length of the device is contained in ξ and *n*, the gas pressure in ξ . If we want to make their influence more visible we may calculate from (10.9) the relative accuracy obtainable with a device 1 m long containing argon gas at N.T.P., and 100 samplings; the result is $\delta I_{\rm mp}/I_{\rm mp} = 0.115$. The value of ξ varies between different gases in the ratio of their atomic charge number Z. Therefore we have for the general case of a gas, characterized by Z and I,

$$\frac{\delta I_{\rm mp}}{I_{\rm mp}} = 0.115 \left(\frac{1\,{\rm m\,bar}}{Lp}\right)^{0.32} \left(\frac{Z_{\rm Ar}I}{ZI_{\rm Ar}}\right)^{0.32} \left(\frac{100}{n}\right)^{0.14} \quad ({\rm FWHM})\,, \qquad (10.12)$$

where L is the length, p the gas pressure and n the number of samplings; I indicates the average ionization potential as used in the Bethe–Bloch formula.

10.5 Particle Separation

In order to judge the power of particle separation for a certain gas and wire arrangement we must combine the results of Sects. 10.2 and 10.4. Generally speaking, the figure of interest is the ratio $\delta I/(IR)$. The noble gases have a wider pulse-height distribution but also a larger relativistic rise, compared to the hydrocarbons investigated. The same compensation is at work with the gas density: as the accuracy $\delta I/I$ becomes better with higher density, the relativistic rise *R* gets worse; in addition the saturation of the plateau starts at a lower γ^* . Finer sampling is an advantage even in the approximation (10.4). In addition, there is the tiny increase, if any, of *R* with finer samples.

The performance of various gases, according to calculations with the PAI model, is compared in Table 10.2 [ALL 82]. These results refer to normal density and to tracks 1 m long, which are sampled in 1.5 cm intervals. The relativistic rise R is indicated for the most probable value of the ionization distribution and for the lower and upper points at half maximum. The full width W_{66} of the ionization determination derivable from a maximum-likelihood fit to all 66 measurements is also shown. The last 6 columns contain particle-pair separation powers S, i.e. for a given pair of particles at some momentum the difference of the peak positions, divided by W_{66} . Remarkably, the separation powers of different gases are very similar.

Measurements of the separation power for various gases and pressures have been performed in a beam of identified particles by Lehraus et al. [LEH 82b]. In their detector with 64 cells, each 4 cm long, they determined simultaneously the difference between the ionization of electrons, pions and protons and the accuracy δI (r.m.s. width of the distribution). The gas and its pressure were varied. Considering the separation of these particles at 15 GeV/*c*, the results are expressed as the ratios D/σ , equal to

$$\frac{\langle I^{\pi} \rangle_{40} - \langle I^{p} \rangle_{40}}{\delta \langle I^{\pi} \rangle_{40}} \quad \text{or} \quad \frac{\langle I^{e} \rangle_{40} - \langle I^{\pi} \rangle_{40}}{\delta \langle I^{\pi} \rangle_{40}}, \tag{10.13}$$

plotted against pressure in Fig. 10.11. This diagram contains a summary of much careful and systematic study. We observe a general decrease below 1 bar and often a decrease above 2 bar, although there are several gas mixtures, where the pion–proton separation increases up to 4 bar. In any event, the values of the ratios stay the same within a few tenths between 1 and 4 bar.

Single-gap measurements in three gases were reported by Walenta et al. [WAL 79] at 3.5 GeV/c. The measured ratio of peak displacement over the full width is plotted against pressure in Fig. 10.12. An increase in separation power can be observed at pressures above 1 bar. The overall picture is that with some gases a profit can be made by going above 1 bar.


Fig. 10.11 Pressure dependence of the resolving power (10.13) for various argon gas mixtures, as measured by [LEH 82a] at 15 GeV/c. The numbers close to the chemical symbols of the quench gases refer to the concentrations; for example, 20CH₄ means 80% Ar + 20%CH₄

10.6 Cluster Counting

The statistical distribution of the number of ionization electrons produced on a given track length has a width W (measured at one half of the maximal probability), which was plotted relative to the most probable ionization I_{mp} in Fig. 1.12 as a function of the track length. This width is determined by the fluctuation in the number of primary clusters that occur over this length and by the fluctuation in the cluster size. It is the latter that dominates; for example, there are 28 primary clusters on 1 cm bar of argon whose Poissonian fluctuation is only 44% FWHM, whereas W/I_{mp} is approximately equal to 1, and for 10 cm bar of argon, the corresponding numbers are



14% compared to $W/I_{mp} \approx 0.5$. The cluster-size distribution P(k) (see Sect. 1.2.4) dominates because of its $1/k^2$ behaviour at large *k*.

Since the number of primary clusters is given with much more relative accuracy than the corresponding amount of ionization, one would like to make use of it for particle identification. The primary ionization cross-section, as a function of velocity, has a similar behaviour to the ionization curve, the slope of the relativistic rise being essentially the same. The plateau, however, is reached at a lower saturation point; this makes the total relativistic rise R_p from the minimum to the plateau somewhat smaller than it is for the amount of ionization. For details see Allison [ALL 80].

Measurements of the relativistic rise of the primary ionization cross-section were reported by Davidenko et al., who used an optical streamer chamber filled with helium at 0.6 bar [DAV 69]; they measured $R_p = 0.38$ (difference between plateau and minimum divided by the value at the minimum). Blum et al. found $R_p = 0.6$ in Ne(70) + He(30) at 1 bar using spark chambers [BLU 74]. Although a systematic evaluation of primary ionization curves is lacking, the effect is obviously strong enough to make the counting of individual ionization clusters a method which is interesting because of its promise of accuracy – if only a way could be found to separate clusters in drift chambers.

One proposal was made by Walenta [WAL 79b]. In his 'Time Expansion Chamber', described in more detail in Chap. 11, the drift region is electrically separated from the amplification region; by using a very low drift velocity, it is possible to separate individual clusters in time and to register individual electrons with some efficiency. The basic problem in argon at atmospheric pressure is that the clusters are so close to each other (28 per cm in the minimum) that even a small amount of diffusion will wash out the primary ionization pattern. For larger distances between clusters one would have to employ lighter gases and/or lower gas pressures. We are not aware of any particle experiment which has successfully used cluster counting for the identification of particles.

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10.7 Ionization Measurement in Practice

The large multiwire drift chambers provide many coordinate measurements on each track, and more often than not this includes recording the wire pulse heights. These are then a measure of the ionization density of each track segment, provided the chamber is operated in the proportional regime. In the universal detectors the particles go in all directions, and their ionization is sampled in different ways, depending on how the track is oriented with respect to the wire array that records it.

There are also more specialized drift chambers, which were built with the express purpose of particle identification behind fixed-target experiments. There, the particles travel generally into one main direction, which makes the ionization sampling much more uniform than it is in the universal detectors.

For good ionization measurements a balance has to be found between two conflicting requirements. On the one hand, the wire gain must be kept small in order to have a signal accurately proportional to the incoming ionization charge. When the gain is too large, the amplification will drop when the incoming charges are concentrated along a short piece of wire, owing to space charge near the wire (see Sect. 4.5), resulting in a gain variation with the amount of diffusion and the trackwire angle. Furthermore, the positive ions created in the wire avalanches penetrate to a certain extent into the drift space, where they cause field and hence track and gain distortions. On the other hand, large signals are required for the coordinate measurement in order to overcome the electronic amplifier noise; this is particularly important for coordinate measurements along the wire, using charge division.

The pulse integration must work in such a way that the result is exactly proportional to the collected charge, and especially that it is independent of the length of the pulse. Otherwise it has to be corrected by a function of the track angle and the drift length, which both have an influence on the pulse length. In order to have a clean pulse integration, overlapping tracks must be eliminated with some safety margin. The number of signals on a track in the middle of a jet of other particles can therefore be considerably reduced. It is not uncommon that in a large drift chamber the average number of signals is only little more than one half of the number of wires that could in principle measure a track.

In order to derive a meaningful ionization of a track, truly independent of all the external circumstances of the measurement, a number of calibrations and corrections are required at the percentage level of accuracy. These may be grouped in two categories, according to whether or not they depend on the track parameters.

10.7.1 Track-Independent Corrections

Without going into the details, we just mention the following effects which change the apparent ionization and therefore have to be kept under control: gas density (pressure and temperature), concentration ratios of the components, electron attachment, base line and pedestal shift of the electronic channels. The response of the individual wires must be the same throughout the drift chamber. At first sight one may argue that the wires measuring the same track are allowed to have inequalities among each other up to a value small compared only to the fluctuations of a wire signal (say small compared to 70%). On a closer look, the requirement of uniformity is more stringent, because the situation changes from one track to the next. A group of wires may not contribute to the next track because the track is displaced or because it overlaps with other tracks. So in practice the wire response must be equalized to a narrower measure. A quantitative evaluation would obviously have to take into account the geometrical details of the situation. Although such equalization can be achieved by determining a correction factor for each wire, matters are simpler when the hardware is already made quite uniform by respecting tight tolerances on the gain and time constants of the charge-sensitive amplifiers.

10.7.2 Track-Dependent Corrections

The amount of track ionization collected on one wire of a grid plane depends on the track orientation. Let α be the angle between the track and the plane, and let β be the angle in the plane that the projected track has with respect to the normal to the wire direction (a track parallel to the wire has $\alpha = 0$ and $\beta = 90^{\circ}$). The length *x* of track contributing to a signal is equal to $x_0/(\cos \alpha \cos \beta)$, where x_0 is the distance between sense wires. We know from Chap. 1 (Fig. 1.10 and the discussion after (1.49)) that the most probable value $I_{\rm mp}$ of the ionization is not a linear function of *x* but can better be approximated by

$$I_{\rm mp}(x)I_{\rm mp}(x_0) = (x/x_0)(1 + C_1\ln(x/x_0)), \qquad (10.14)$$

where the value of C_1 can be obtained from Fig. 1.11 or from a Monte Carlo simulation, or experimentally by grouping wires to make larger x; C_1 is typically between 0.1 and 0.3. The signals from every track segment have to be divided by the factor (10.12) in order to be normalized to the standard length x_0 .

The *effect of saturation* is described by a length λ on the wire over which the incoming electrons are distributed; λ is equal to $x_0 \tan \beta$ and has to be convoluted with the transverse diffusion, which in turn is a function of the drift length *z*. A first-order correction could be the following expression, which depends on a constant *C*₂:

$$I(\beta)/I(90^{\circ}) = 1 - C_2/\lambda(\beta, z).$$
(10.15)

This correction is complicated because it is a function of the drift length z as well as of the angle β ; it is also not quite independent of the amount of ionization itself and of the angle α .

In a geometry where the wires run orthogonal to a magnetic field, the $E \times B$ effect causes the drifting electrons to arrive on the wires at an angle ψ (Fig. 7.5a-c); in this case λ is equal to $x_0 \tan(\beta - \psi)$.

The signal attenuation due to *electron attachment* requires a correction which depends on the drift length z through a constant C_3 :

$$I(z) = I(0)e^{-C_3 z}.$$
 (10.16)

Electronic cross-talk between wires can give rise to an α -dependent correction because the small 'illegal' pulses induced on neighbouring wires are prompt, whereas the normal signal develops according to the arrival time of the electrons. The time differences between the normal and the small induced pulses depend on α and will give rise to a variation in the pulse integration.

The corrections discussed above are all interconnected, and it is difficult to isolate the individual effects. In fact, we do not know a particle experiment in which such a programme has been successfully completed in all details. Nonetheless, with the corrections applied, in practice it has usually been possible for the determination of track ionization to reach a level of accuracy that is not far from that predicted by (10.9). The reader who is interested in more details of the correction procedure is referred to the articles by the groups of ISIS2 [ALL 82, ALL 84], OPAL [BRE 87, HAU 91], CRISIS [TOO 88] and ALEPH [ATW 91].

10.8 Performance Achieved in Existing Detectors

It is appropriate now to describe a small number of wire chambers used in particle experiments and to compare their ionization-measuring capability with the theory. Although a systematic discussion of existing drift chambers begins in Chap. 11, we want to include a few devices here as examples in the context of ionization measurement. We distinguish specialized chambers and universal detectors. The emphasis is on measurements in the region of the relativistic rise.

10.8.1 Wire Chambers Specialized to Measure Track Ionization

As the progress in accelerator technology made fixed-target experiments possible in particle beams with momenta up to one hundred GeV/*c* or more, the relativistic rise of the ionization in gases was put to the service of identifying the secondary particles. The first and largest such undertaking was the External Particle Identifier ('EPI') behind the Big European Bubble Chamber ('BEBC'). It consisted of a stack of 64 rectangular chambers, each 1 m high, 2 m wide and 12 cm deep. Vertical proportional wires – surrounded by field wires – were strung to make sensitive regions in the gas, shaped like rectangular boxes, 1 m high, and with a $6 \times 6 \text{ cm}^2$ ground surface, two layers to a frame, each layer 32 boxes wide; see Fig. 10.13. This arrangement was used as a multiwire proportional chamber hodoscope – the coordinate information came in steps of 6 cm horizontally, but vertically there was no subdivision. The ensemble of the 64 frames was 8.5 m long (deep) and weighed



Fig. 10.13 Layout of the External Particle Identifier and cell structure. The position of the insensitive beam hole is indicated

16 ton. Mounted four metres above the ground, it still looked small compared to the big magnet of BEBC, which was nearly 16 m away (centre to centre), so the solid-angle coverage of secondary particles was only 8 m sr. The whole apparatus had to be movable sideways in order to be able to accept at least a small fraction of the secondary particles that had the same charge sign as the incoming beam. The limiting aperture was a hole in the iron mantle of BEBC through which the secondary particles had to leave the zone of interaction.

If the spatial resolution was modest, the same can be said for the time resolution. The device had to register all the events in one burst, which lasted for only 3μ s. These details are important in the context of pattern recognition and an unambiguous association of track segments.

For the ionization measurement, enough length was available to reach a very fine precision. For beam tracks, Lehraus and collaborators reached a resolution of 6 to 7% FWHM, varying slightly with particle species and momentum. This is almost as good as the theoretical limit of 5.8% derived from (10.9) based on the PAI model.

In Fig. 10.14 we see the ionization of beam tracks consisting of protons and pions with a momentum of 50 GeV/c. The resolution is so good that a clean identification of almost every individual particle is possible.

When analysing tracks that emanate from interactions in the bubble chamber, one loses track segments overlapping with others in the same region (box) of sensitivity. This loss in the number of ionization samples N is an important cause for the observed deterioration of resolution. The resolution in this overlap region seemed to deteriorate more quickly than according to the rule $N^{-0.46}$ or $N^{-0.43}$ discussed in Sect. 10.4.1 for clean measurements. In EPI the average number of samples $\langle N \rangle$ that remained above a minimal requirement N_{\min} , for example, was between 72 and

91 (momentum dependent), resulting in resolutions between 10.6 and 8.7%; see Table 10.3.

Comparable in size was the large drift chamber ISIS2 (which stands for the 'Identification of Secondaries by Ionization Sampling'); it had a length of 5 m and an aperture of 2 m horizontally times 4 m vertically. A description is found in Chap. 11. Here we summarize its capabilities as an ionization-measuring device. With more frequent and finer samplings than EPI, but with reduced length, it should have the same resolving power, according to (10.9). Although the drift-time measurement allowed the vertical track coordinates in ISIS to be known to a few millimetres, the detailed track filtering and subsequent hit association to tracks proved to be critical for achieving a good resolution. For instance, in a typical study of secondary tracks in an experiment 10 m behind the small bubble chamber HOLEBC, the average number of samples retainable per track was $\langle N \rangle = 250$, if the required minimum was set to $N_{\min} = 100$. The achieved accuracy was 8.3% FWHM instead of the theoretical 6.5% expected for this value of $\langle N \rangle$. Whereas such details depend entirely on the track density in the chamber, they are quoted here to illustrate how the ionization resolving power goes down with an increasing overlap of tracks.

With this apparatus the most probable ionization density of each track could be measured with an accuracy of 3.5% r.m.s. and the relativistic rise was 56%. Using the dependence of the ionization on the particle velocity, as well as the momenta determined in the spectrometer, useful particle identification was possible up to 60 GeV. In order to give an impression of the achieved identification reliability, we show in Fig. 10.15a,b the uniqueness f of the electron–pion separation as a function of particle momentum. The parameter f is defined to be the percentage of correctly identified pions (probability > 1%) whose ionization is incompatible with an electron at the 1% level, and this is equal to the percentage of correctly identified electrons incompatible with a pion. (These ratios could be measured because there was independent kinematical particle identification for a sample of events.) Figure 10.15a,bb contains the same for the uniqueness of the pion–kaon separation.





Chamber	EPI		ISIS2 ^a	CRISIS
Experiment	Big Europe	ean	European Hybrid	FNAL Hybrid
	Bubble Ch	amber	Spectrometer with HOLEBC	Spectrometer with 30' BC
Reference	[LEH 78]		[ALL 84]	[TOO 88]
	[BAR 83]			[GOL 85]
Chamber type ^b	MWPC Sta	ack	type 3 drift chamber	type 3 drift chamber
Max. no. of samples per track	128		320	192
Sample length (cm)	6		1.6	1.6
Total length of sensitive	7.7		5.1	3.1
volume (m)				
Size of entrance window	192×90		200×400	98×102
hor. \times vert. (cm)				
Max. drift length (cm)	6		200	25
Gas mixture	Ar(95) + C	$CH_4(5)$	$Ar(80) + CO_2(20)$	$Ar(80) + CO_2(20)$
Pressure (bar)	1		1	1
Gas amplification factor	4000		10000	-
Estimation method employed ^c	$\langle S \rangle_{40}$		M-L	$\langle S \rangle_{75}$
Analysis of beam tracks:				
Observed resolution	6.0 - 7.0		-	7.6-8.0
(FWHM, per cent)				
Theoretical limit	5.8		5.8	7.4
(our equation 9.9)				
Analysis of secondary tracks:				
Min. no. of useful samples required	50	80	100	50
Average no. of useful	$(72 - 91)^d$	$(91 - 109)^d$	250	140 ^e
samples obtained				
Observed resolution	(10.6-8.7)	(8.7 - 7.8)	8.3	10
(FWHM, per cent)				
Theoretical limit	(7.6 - 7.8)	(6.8–6.4)	6.5	8.7
(our (9.9))				
Relativistic rise		58	56	$\simeq 45$
(per cent over the minimum)				

35210Particle Identification by Measurement of Ionization**Table 10.3** Wire chambers specialized in ionization measurement in fixed-target experiments

^a Chamber also described in Sect. 11.7.5.

^b Drift chamber definitions, see Sect. 11.1.

^c Notation, see Sect. 10.3; M-L is maximum likelihood.

^d Depending on momenta of secondaries.

^e Our estimate.

The achieved degree of particle identification is also demonstrated in the scatter plot of momentum vs. ionization of Fig. 10.16. Working with secondary particles of known masses and momenta, Allison and colleagues were able to compare the ionization measurement with expectations based on the PAI model. In the plot we see electrons, pions and protons, but no muons or kaons, because these were not in the sample of kinematically identified tracks; this simplified the situation. One can easily make out the regions in the drawing where the measured tracks are unambiguously associated to one line, i.e. identified. Some confusion between pions and electrons sets in above 10 GeV/c; protons from pions can be separated to higher momenta, in the absence of kaons.

The idea of secondary particle identification in a fixed-target experiment was also the purpose of the construction of CRISIS, which served in the Hybrid Spectrometer at FNAL together with the 30' bubble chamber. It derived its name as well as its design principle from ISIS, of which it was a 'Considerably Reduced' version: the length was 3.1 m, the aperture 1 m by 1 m. The drift length was subdivided into 4 separate shorter regions, thus reducing the problem of track overlap. In the analysis of 100 GeV/*c* beam tracks, a resolution of 7.6 to 7.9% FWHM was reported, compared to 7.4 from (9.9).

The measurement of secondaries from beam–nucleus interactions at 100 GeV/*c* momentum resulted in a width $\delta I/I = 10\%$ (FWHM) after requiring more than 50 charge samples for a track. For a comparison with ISIS2 we form the ratio $(\delta I/I)/R$, which is 0.22 for CRISIS, compared to 0.15 for ISIS2. The group determined the ratio of the numbers of pions to the numbers of protons/antiprotons as a function of momentum on a statistical basis; the presence of kaons could be inferred.

The fact that their plateau was observed near R = 45 per cent above the minimum is very interesting. In columns 1, 2 and 3 of Table 10.3 we find 58, 56 and \approx 45; these numbers should be equal to within a few per cent. This shows that ionization measurements of the kind described here depend very much on the individual experimental procedures (pulse integration, pedestal and other corrections, statistical treatment), therefore, a universal curve for all experiments with the same gas and pressure is not applicable. The resolving powers of measurements in the relativisticrise region achieved in different experiments are reasonably compared using the ratio $(\delta I/I)/R$.





Fig. 10.16 ISIS2 scatter plot of the measured ionization vs. momentum of kinematically identified tracks with more than 100 samplings. *Full circle*: electron; *cross*: pion; *open square*: proton. The lines are the expected curves for electrons, pions, kaons (*dashed*) and protons. The error bars represent one standard deviation for tracks with 250 samplings [ALL 84]

With this experience, some qualifications are in order concerning our statement (10.4). The approximate independence of $F_{g,m}^{(norm)}(v)$ from the index *m* is with respect to small variations in sample size (as they occur in one experiment owing to different track directions) and with respect to the statistical estimator. Between different experiments, $F_g(v)$ can evidently come out different, as a function of the experimental procedures.

10.8.2 Ionization Measurement in Universal Detectors

From the large detectors described in Chap. 11 we have selected three examples for a discussion of their capability to determine the ionization of tracks. They are the ones that show the greatest promise of accuracy using (10.9). All operating essentially with argon gas, they span a range of gas pressures between 1 and 8.5 bar.

The OPAL chamber looks at a radial track with 159 sense wires, spaced 1 cm; with the gas pressure at 4 bar, (10.9) predicts a resolution of 6.0% FWHM. When selecting isolated e- and μ -tracks that can be well measured, the group reaches 7.3%.

In the analysis of hadron jets, losses occurred in the number of useful samples, owing to the overlap of tracks; the hit numbers of the remaining ones followed a



distribution between 0 and 159, peaking at 110 with 89% above 40. On average, well-measured tracks had 94 samples, and a resolution of 8.9% FWHM was obtained. Equation (10.9) predicts 7.6% for these. Again, the deterioration is worse than would be expected from the reduced number of samples alone.

The OPAL group has made a special study of this effect by plotting in Fig. 10.17 the accuracy reached within jets for minimally ionizing pions as a function of the number of useful samples. This is compared with data for isolated particles. These data contain usually the (almost) full number of wires, and these are then artificially reduced by randomly removing good signals; the remaining number N of samples was found to determine the accuracy proportional to $N^{-0.43}$. The curve for particles in jets is worse than (i.e. lies above) the one for isolated particles, for every N. We may suspect that problems of space charge near the wires and in the drift region as well as residual problems of pattern recognition are the cause of this behaviour.

The PEP-4 TPC can measure a good track 183 times. With the wires spaced at x = 0.4 cm and the gas pressure 8.5 bar, the individual sample length px is very similar to that of the OPAL chamber. On the basis of (10.9), one expects a resolution of 5.9% FWHM, and 6.9% is reached for isolated tracks.

The tracks in particle jets are measured with a resolution of 8.3% FWHM. The number of lost samples is our own estimate; as in the case of OPAL, it does not fully account for the reduction in accuracy, compared to the isolated tracks.

The ALEPH TPC is almost twice as large in radius as the PEP-4 TPC and can measure radial tracks on 340 wires. Operating with atmospheric gas pressure, its individual sample length is only px = 0.4 cm bar, smaller than in any other drift chamber. The signals are therefore extremely feeble. In the minimum of ionization, only eleven clusters contribute on average to the signal of a wire (cf. Table 1.1). According to (10.9), a resolution of 8.8% FWHM should be expected, and 10.3% has been reached for isolated tracks.



When studying tracks inside jets and of lower momenta, the large magnetic field (1.5 T; see Table 11.4) poses a special problem: particle tracks below 0.5 GeV/c coil up inside the chamber and require angular corrections (cf. Sect. 10.7.2) over a large range of angles. The resolution for hadron tracks is 13.3% FWHM at the average value of N = 250 samples; this can be compared to the 10.2% expected from (10.9).



Fig. 10.19 R.m.s. particle-separation power *D* as defined in the text, achieved with the OPAL Jet Chamber [HAU 91]

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10.8 Performance Achieved in Existing Detectors

Drift chamber	OPAL Jet Chamber	PEP 4 TPC	ALEPH TPC
Reference	[BRE 87] [HAU 91]	[COW 88]	[ATW 91]
Drift chamber type ^b	2	3	3
Max. no. of samples per track	159	183	340
Sample length (cm bar)	4	3.4	0.4
Max. drift length (cm)	3–25	100	220
Gas mixture	$Ar(88) + CH_4(10)$ + i-C ₄ H ₁₀ (2)	$Ar(80) + CH_4(20)$	$Ar(91) + CH_4(9)$
Pressure (bar)	4	8.5	1
Gas amplification factor	10000	-	5000
Estimation method employed ^c	$\langle S \rangle_{70.}$	$\langle S \rangle_{65}$	$\langle S \rangle_{60}$
Analysis of isolated tracks:			
Min. polar angle required (deg):	45	45	45
Observed resolution (FWHM, per cent)	7.3	6.9	10.3
Theoretical limit ^d (our (10.9))	6.0	5.9	8.8
Analysis of tracks inside jets:			
Min. polar angle required (deg): Min. no. of useful	45	45	45
samples required Average no. of useful	40	80	150
samples obtained Observed resolution ^e	94	140 ^f	250
(FWHM, per cent)	8.9	8.3 ± 0.7	13.3
(our (10.9))	7.6	6.7	10.2
Relativistic rise observed (per cent over the minimum) Measured resolution for isolated	47	37	57
tracks (FWHM), divided by the observed relativistic rise	0.155	0.186	0.181

Table 10.4 Ionization-measuring capability of some universal drift chambers in collider experiments^a

^aMore details on these chambers can be found in Tables 11.2 and 11.4

^bDefinitions Sect. 11.1

^cDefinitions Sect. 10.3

^dUsing lines 4 and 5 above (the effects of slightly larger average sample size and any loss of samples are neglected)

^ePions in the minimum of ionization

^fOur estimate

^gUsing lines 5 and 16 above

In a comparison of these three detectors one must consider the different gas pressures. The relativistic rise *R*, expressed as the percentage difference of the plateau over the minimum, is better for the smaller pressures. On the other hand, the resolution $\delta I/I$ is better for the higher pressures. A useful over-all criterion is the

measured ratio $\delta I/(IR)$, which we have computed in the last line of Table 10.4. The best figure of merit belongs to the OPAL Jet Chamber; for it we show the scatter diagram of ionization strength versus particle momentum in Fig. 10.18. The OPAL r.m.s. particle-separation power D for various pairs of particles is plotted in Fig. 10.19 as a function of momentum. The quantity D_{12} is defined as the ratio of the difference of the ionization strengths of the two particles 1 and 2 to the average resolution

$$D_{12} = \frac{|I_1 - I_2|}{(\delta I_1 / I_1 + \delta I_2 / I_2) / 2}.$$

Experimentally, the two terms in the denominator are equal.

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Chapter 11 Existing Drift Chambers – An Overview

Drift chambers have in common that the drift of the ionization electrons in the gas is used for a coordinate determination by measurement of the drift time. In this chapter we want to take a look at the large variety of forms in which drift chambers have been built for particle physics. As a complete coverage of all existing drift chambers does not correspond to our plan we subdivide the material according to a geometrical criterion into three basic types, and then we discuss typical forms within each type. The selection of chambers is intended to represent the different choices that have been made in this field, but a certain arbitrariness in choosing the examples was unavoidable. Of the chambers we know, we have preferred those that are already working to similar ones that are still in a state of preparation; and those that are well documented we have preferred to similar ones with less detailed descriptions. We have considered drift chambers for the detection of charged particles, but not those for single photons, so the image chambers useful in biology and medicine have been left out as well as those used to detect Cerenkov radiation.

A description of drift chambers in the context of particle-physics experiments is given in the review article by Williams [WIL 86].

Let us begin by defining the three basic types.

11.1 Definition of Three Geometrical Types of Drift Chambers

Type 1: The simplest drift chamber is ideally a *sensitive area* placed across the path of a particle in order to measure one, or perhaps both, coordinates of the point of penetration. It was developed out of the multiwire proportional chamber, or MWPC – a hodoscope of parallel proportional wires – by supplementing the electronics of the sense wires with equipment to measure the time of the avalanche pulse and hence the drift time of the ionization electrons. The electric field in the drift region is shaped, usually with conductors on defined potentials like field wires, but sometimes also by charges deposited on insulators.

In practice, the ionization electrons of a short piece of track are collected on the nearest sense wire. For a complete determination of track parameters, such chambers are often used in stacks of several parallel chambers. The first working drift-chamber system, which was built by Walenta, Heintze and Schürlein [WAL 71], was of type 1.

Types 2 and 3: The particle traverses a *sensitive volume*. The ionization electrons of a number of track pieces are collected on an equal number of sense wires, and several coordinates are measured along the track. Such an arrangement allows the measurement of track directions and, if a magnetic field is present, of track curvature. If the sampling of ionization along the track is done often enough, there is the possibility of determining the ionization density to a degree useful for particle identification.

One type of volume-sensitive drift chamber consists of an arrangement of a large number of parallel or almost parallel sense wires that span the volume, usually interleaved with equally parallel field-shaping wires: this we call type 2.

Chambers of type 2 may be thought of as consisting of many chambers of type 1 in the same volume. Obviously there is no sharp dividing line between types 1 and 2. We will call a drift chamber that presents a sensitive area to the penetrating particle, but measures the particle track with several sense wires, a '*type 1 multisampling chamber*', its depth in the particle direction being considerably smaller than the linear dimensions that span the area.

A quite different type of volume-sensitive drift chamber is characterized by a sensitive volume which is free of wires; the wires are located on one or two surfaces that delimit the drift region. This we call type 3. Well-known examples are the universal track detectors that carry the name 'time projection chambers' (TPCs). In their original form they have segmented cathodes (pads) behind their sensitive wire planes, and the electric field is parallel to the magnetic field; later on, TPCs were also built without magnetic field. Other type 3 chambers include the large drift volumes built for particle identification where all tracks are drifted onto one central wire plane for ionization measurement, or the spiral drift chamber where the electrodes are situated on a cylinder mantle.

For a type 3 drift chamber, the use of the name 'time projection chamber' is as vague as the name is fanciful (time cannot be projected). There seems to be a tendency now for many constructors of new type 3 drift chambers to call their device a 'TPC'.

11.2 Historical Drift Chambers

Throughout this book, we are usually not concerned about the originators of each of the many ideas which together represent our knowledge about drift chambers. In this section we want to make an exception and follow the roots of the drift chamber itself as well as of its two later configurations, the types 2 and 3.

The possibility of using the time of the signal for a coordinate determination was already recognized by the authors of the paper that introduced the multiwire proportional chamber, or 'Charpak chamber', as it was then called [CHA 68].

The first studies exploiting the drift time for a coordinate measurement were done by Bressani, Charpak, Rahm and Zupančič at CERN in 1969 [BRE 69]. It is here that the word 'drift chamber' makes its appearance in the literature. A 3-cm-long drift space was added to a conventional multiwire proportional chamber with dimensions 12×12 cm²; it was separated from the drift region by a wire mesh with 90% transparency. The ionization electrons of a beam particle drifted orthogonally through it onto the sense-wire plane, where they were measured on 15 proportional wires that were spaced at 2 mm. We reproduce in Fig. 11.1 the historic picture of this first drift chamber. Drift-velocity measurements and resolution studies were done with it. The crucial role of diffusion for the accuracy was recognized.

The documentation of this work is not easy to find because it was published in the proceedings of an International Seminar on Filmless Spark and Streamer Chambers in Dubna, with contributions mainly written in Russian. The early investigations were later reported in a wider context by Charpak et al. [CHA 70].

The first operational drift-chamber system including electronic circuitry and digital readout was built by Walenta, Heintze and Schürlein [WAL 71]. The chamber was organized in a novel way, consisting of a multiwire proportional chamber with large wire spacings as shown in Fig. 11.2, where the drift-time measurement gave the coordinate between the wires, thus improving accuracy and using fewer electronic channels compared to the MPWC. The ionization of a measured particle was amplified on one proportional wire. This geometry, which in our classification is of type 1, was later to be developed into a form where the drift field was extended and made more homogeneous by introducing field wires on graded potentials. An example is the type 1 chamber by Breskin et al. schematically shown in Fig. 11.3 [BRE 75]. Further important developments of the drift-chamber technique had been reported by the CERN group [CHA 73].

If the creation of the drift chamber out of an array of proportional wires was an important invention which produced many branches of useful particle detectors, the appearance of one of its principal configurations, the type 2 drift chamber, was part of a rapid development towards larger drift chambers and represents a much smaller 'quantum jump'. When the new $e^+ e^-$ storage rings like DORIS and SPEAR



Fig. 11.1 Disposition of the electrodes of the first drift chamber. Original drawing by Bressani et al. [BRE 69]



Fig. 11.2 Disposition of the electrodes in the chamber built by Walenta et al.

required particle tracking in all directions around the interaction point, the most obvious design was the one where several cylindrical type 1 chambers with increasing diameters were inserted into one another, each one an entity that could be pulled out for maintenance. The MARK I drift chambers and the PLUTO spark chambers were examples of this geometry.

The first genuine type 2 drift chamber was that of the old MARK II detector at SPEAR [DAV 79]. Its designers had taken the essential step of filling the entire sensitive volume with wires strung between two opposite end-plates, having done away with all intermediate ring-shaped structures and gas foils, thus paving the way for a new generation of larger volume-sensitive drift chambers of very high accuracy. A description of the state of the art in 1981 may be found in [WAG 81] and [FLÜ 81].

The origin of the type 3 drift chambers is in Oxford. The ISIS project for the Identification of Secondaries by Ionization Sampling was first described in 1973 [MUL 73, ALL 74], and a prototype with an 85-cm-long drift was tested the same year [see ALL 82]. The basic idea was a large sensitive volume that contained only gas and an electric field, the track ionization being collected and measured on a single wire plane. Multihit electronics recorded the drift times of all the tracks of one event, thus producing a direct image of the event in one projection. The purpose of the apparatus was not primarily a precise determination of coordinates (for this the diffusion was too large as a consequence of the long drift) but the measurement of ionization density for particle identification. A later version of ISIS is described in Sects. 11.7 and 10.7. ISIS can be considered a predecessor of the TPC.



Fig. 11.3 Disposition of the electrodes in the chamber built by Breskin et al. [BRE 75], cathode wires at uniformly decreasing potentials produce a long and homogeneous drift field

The first time the TPC concept appeared on paper was in a laboratory report by D. Nygren [NYG 74]. The chamber was subsequently built at Berkeley and SLAC for the PEP-4 experiment. Again, it is not easy to find access to a documentation of this work. A very detailed description of the PEP-4 TPC is contained in the experiment proposal of the collaborating institutes [CLA 76]. It was presented to the appropriate bodies for approval and later widely circulated among workers in the field. This proposal and its numerous appendices reported on many aspects of the feasibility of a TPC. Some of this important material has never been published.

Conscious [NYG 83] of the latest work at CERN and at Oxford, Nygren invented the TPC by performing a synthesis into one instrument of all the known elements: long drift, diffusion suppression through parallel E and B fields, 3-dimensional coordinate measurement by pick-up electrodes for x and y, and drift-time measurement for z. This was made possible by a novel storage of the pulse train of every electrode over the full length of the drift time. The PEP-4-TPC is described in more detail in Sect. 11.7.

11.3 Drift Chambers for Fixed-Target and Collider Experiments

A typical fixed-target experiment would have an arrangement of type 1 chambers that record (together with other detectors) the reaction products behind a target. If in addition to their directions one also measures the momenta of these particles with the help of a magnet, then we have a magnetic spectrometer, a typical form of which is schematically drawn in Fig. 11.4. Stacks of planar type 1 chambers have been in wide use for such spectrometers.

As for the momentum-measuring accuracy $\delta p/p$ at a given bending power p_B of the magnet, the contribution of each arm is, in a first approximation, proportional to $\delta x/L$, the ratio of the chamber point-measuring accuracy to the length of the lever arm (or thickness of the stack):

$$\frac{\delta p}{p} = \text{const} \frac{p}{p_B} \frac{\delta x}{L}$$

Т

DC's





м

DC's

Often there is freedom to increase L; then the value of δx is less critical, but the dimensions W of the chambers must be increased in proportion.

For the study of very-high-multiplicity events in heavy-ion fixed-target experiments, even type 3 chambers have become popular. The direct three-dimensional measurement of track elements is an advantage for such events (see Sect. 11.7).

An important group of drift chambers has been built around the interaction regions of particle colliders where they are – together with the installed calorimeters – the principal instruments for the investigation of the particles from the collisions. Close to the interaction point we find the *vertex detectors* around the beam pipe whose purpose it is to determine the interaction vertex with high precision. Further out in radius the *main drift chambers* measure the direction and momenta of the charged particles and, in many cases, their ionization. In the design of these tracking devices the choice of the magnetic field and its orientation is a primary concern.

11.3.1 General Considerations Concerning the Directions of Wires and Magnetic Fields

For symmetric electron–positron machines where one studies point-like interaction – these cause essentially isotropic particle distributions – the magnetic field B was most naturally created by a solenoid on axis with the particle beams. A good measurement of particle momenta requires the curvature of tracks to be determined with the greatest accuracy in the *azimuthal* direction. In drift chambers of type 2 it is the drift-time measurement that provides the accuracy; hence the wires are essentially parallel to the magnetic field ('axial wire chambers'). In drift chambers of type 3 the azimuthal accuracy is provided by cathode pick-up electrodes so that the electric drift field can be made parallel to B. Therefore, in $e^+ e^-$ machines we find axial wire chambers and TPC's along the direction of the beams. Along B, particle curvature is not measurable.

For the study of hadron interactions in the $\bar{p}p$ and pp colliders, the magnetic field *B* has sometimes been chosen to be at right angles to the beam direction, on account of the important flux of high-momentum particles in the direction of the beams – the UAI-experiment at the CERN $\bar{p}p$ collider and the Split Field Magnet at the CERN Intersecting Storage Rings being well-known examples. The orientation of the wires of type 1 or type 2 drift chambers again has to be parallel to *B*, which is also the flight direction of the particles with vanishing curvature.

At the e⁻ p collider HERA at DESY there is an inherent asymmetry in the energies of the colliding particles, because 30 GeV electrons collide with 800 GeV protons. The solution adopted for each of the two experiments is a solenoid, coaxial with the beams, instrumented with a coaxial type 2 chamber, and complemented in the forward direction of high momenta with several planar type 1 stacks for particles with polar angles θ approximately between 10 and 30°. In these type 1 chambers we find the sense wires orthogonal to the magnetic field, thus giving an accurate measurement of θ and a good double track resolution in this angular range.

11.3.2 The Dilemma of the Lorentz Angle

In drift chambers of type 2, for an accurate determination of the curvature of an ionization track one compares the times of arrival of the electrons from different track segments on different wires (Fig. 11.5a-ca). The best accuracy is obtained when the electron drift is at right angles to the track; for then the time differences measure the curvature directly, and also the electrons of every track segment that go to the same sense wire are most concentrated in arrival times and hence give the smallest variance in the measurement (cf. Sect. 7.3).

However, the magnetic field **B** orthogonal to the electric drift field **E** forces the electrons towards the direction given by the vector product – $[E \times B]$. The *Lorentz* angle ψ between the drift direction **u** and **E**, in the approximation of Sects. 2.1 and 2.2 (2.1.1) is given by

$$\tan \psi = \omega \tau$$
.

Figure 11.5a-cb shows the resulting disadvantage: not only does one have to measure the sagitta under an angle of projection, but also inside every track segment the arrival times are spread out more than before. This gives rise to the 'angular wire term' in (7.26), with $\alpha = \psi$, even if the track is perfectly radial. Therefore, in this geometry one is obliged to keep $\omega \tau$ small, although – in the interest of a good momentum measurement – one wants the largest possible B field. This is the dilemma of the Lorentz angle.

Since τ is related to the electron mobility μ by the approximate relation $\mu = (e/m)\tau$ (for more details see Chap. 2), one way out of the dilemma is to choose a



Fig. 11.5a-c Drift paths of ionization electrons from the particle track to the sense wires. (a) $\omega \tau = 0$ (no magnetic field); (b) $\omega \tau = 1$, sense wire plane parallel to the tack; (c) $\omega \tau = 1$, sense-wire plane inclined

gas with a low mobility (small drift velocity at high *E* field) and/or a high gas density *N* to which τ is inversely proportional by the relation $\tau = 1/N\sigma c$; cf. Sects. 2.2 and 12.5.

Another way out, but only of part of the dilemma, is a rearrangement of the wires according to Fig. 11.5a-cc: the plane of the sense wires is made *inclined* to the radial direction by the Lorentz angle ψ . This solution has sometimes been adopted for high magnetic fields. Although this solution brings the drift direction back to the normal to the stiff radial tracks, the angular wire effect in (7.26) does not vanish for them. The importance of this effect depends on the radial sense-wire spacing.

11.3.3 Left–Right Ambiguity

The relation between drift time and space coordinate is not always unique. If ionization electrons can reach a proportional wire from two opposite sides, then there are two space coordinates to correspond to a measured signal time, one of them correct, the other a 'ghost'. The situation arises in drift chambers of types 1 and 2, but usually not in the type 3 chambers. (An exception is treated in Sect. 11.7.5). This *left-right ambiguity* can sometimes be resolved with pattern-recognition methods which take into account that a track produces correct coordinates that are continuous and extrapolate to realistic points of origins whereas the ghost coordinates do not make sense – provided the wires are arranged accordingly. Another possibility is the '*staggering*' of the sense wires, i.e. alternate sense wires are slightly displaced from their original positions in opposite directions; the correct coordinates are the ones that combine to form a continuous track. Still another method makes use of the development of avalanches, which do not go around the whole wire when small (Sect. 4.3). Suitable pick-up electrodes can identify the side of approach of the drifting electrons [WAL 78, BRE 78].

11.4 Planar Drift Chambers of Type 1

11.4.1 Coordinate Measurement in the Wire Direction

Whereas the principle coordinate measurement in the wire chambers is through the drift time and therefore orthogonal to the wire direction, for a coordinate measurement along the wire other methods are needed. As we discussed in Sect. 7.1, there are three such methods: 'charge division' and 'time difference', based on a pulse measurement at the two wire ends, and 'cathode strips', based on a measurement of pulses in sections of the cathode.

With these methods it is possible to record the positions of every track segment (the ionization electrons collected on the wire) in all three dimensions, the position of the wire and the drift time giving the additional two. For a true three-dimensional measurement of track segments with cathode strips these must be *short* so that every cathode pulse can be associated from the beginning with its proper wire signal. With *long* cathode strips it is only after track reconstruction that this association can be made. The use of cathode strips in drift chambers has so far been limited to type 1 and type 3 chambers, and short strips ('pads') are so far only found in type 3 chambers.

Many spectrometers were built in which a particle had to successively traverse several parallel drift chambers, which measured only one drift coordinate for the track; but by arranging the sense wires in different directions, the track was measured in different stereo directions, thus allowing the full track reconstruction in three dimensions to be made. For example, a group of 9 parallel chambers could have chambers 1, 4 and 7 with vertical wires (angle of inclination $\alpha = 0$), chambers 2, 5 and 8 with wires inclined by $\alpha = 45^{\circ}$, and chambers 3, 6 and 9 with wires at $\alpha = -45^{\circ}$.

Different from a true coordinate measurement along the wires, this stereo measurement of tracks does not immediately yield three-dimensional coordinate information for every track segment. In the pattern of the drift times one would first find the tracks in the projection of the first group of chambers, then in the second, and so on; later, the various projected tracks would be combined in space.

11.4.2 Five Representative Chambers

In Table 11.1 we have listed five chambers of type 1 that are or were part of important experiments in high-energy physics. In the first two chambers, particle tracks are sampled once, whereas the last three belong to the multisampling kind.

The CDHS chambers were located between iron plates that were at the same time the target and the calorimeter plates of this neutrino experiment, so they had to be large and thin but were not particularly accurate. A relatively simple field-wire configuration was found to produce a sufficiently uniform drift field if the argonisobutane gas mixture was used near saturation. A drift cell and its equipotential lines are shown in Fig. 11.6. Three identical units ('modules') of these hexagonally shaped chambers, with wire orientations at 0, +60 and -60° , were stacked between the iron plates.

The muon identifiers of the DELPHI experiment are the first example of a drift chamber that has the wire amplification in the limited streamer mode. Shielded behind iron as they are, the increased dead time that is caused by the streamer regime was easily tolerable. The large pulses made it possible to use a slow delay line $(0.6 \,\mu\text{s/m})$ for a coordinate determination along the wire. Measuring the time difference the authors obtained an accuracy of better than 10^{-3} of the length. The delay line is incorporated in the cathode, as depicted in Fig. 11.7. The drift field is defined by copper strips in the plastic material of the body.

Of the drift chambers of the HELIOS experiment we discuss the small ones immediately behind the target. Their critical requirements were accuracy and

Table 11.1 Some planar drift cham	bers of type 1				
Name of experiment	CDHS	DELPHI	NA34/HELiOS	L3	HI
Name of chamber	DC	Muon Identifier	DC 1	Middle Muon Chamber	FTD (radial wires)
Amplification mode	Proportional	Limited-streamer	Proportional	Proportional	Proportional
Method of <i>z</i> -measurement	Stereo (successive	Time difference	Stereo (successive	Special chamber	Charge division
	modules)	(delay line)	modules)		(along r)
Reference	[MAR 77]	[DAU 86]	[BET 86]	[ADE 90]	[BEC 89]
			[FAB 90]		[GRA 89]
Geometry					
Width (cm) \times length	400 imes 400	20 imes435	24 (diam)	163 imes 556	30 (inner diam)
(cm) (one chamber)	(hexagonal)				152 (outer diam)
Total area of these chambers in	720	009	0.4	280	5
experiment (m ²)					
No. of sense wires per cell	1	1	8	24	12
No. of cells per chamber	130	1	8	16	48
Sense-wire spacing (mm)	Ι	I	6 (2)	6	10
along the track					
Sense-wire diameter (µm)	40	100	20	30	50
Max. drift length (cm)	3	10	1.5	5	1-5 (proportional
					to r)
Gap (mm)	30	20	48	360	120

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_
(continued)
Table 11.1

Gas (percentage	Ar(70)	$Ar(14)+CO_2(70)$	$CO_2(90)$	Ar(62)	Xe(30)
concentration)	+ i-C ₄ H ₁₀ (30)	+ $i-C_4H_{10}(14)$ + $iso-month-alcohol (2)$	$+ C_2 H_6(10)$	$+ C_2 H_6(38)$	$+ C_2 H_6(40)$ + He(30)
Electric drift field (kV/cm)		\pm 150-propyr-atcurve (2) 0.7	1.2	1.1	+ 1.2
Magnetic field (T)	0	0	0	0.51	1.2
Drift velocity (cm/µs)	5.0	0.75	1.0	4.9	З
Performance (1)					
Point-measuring accuracy per wire In drift direction σ_x (mm)	< 0.7 (c)	1 (b)	0.12 (c) 0.06 (b)	0.17 (c) (3)	0.11–0.15 (b)
In wire direction σ_z (mm)	I	3 (b)	I	I	20 (b)
Double track resolution Δ (mm)	30 (a)	10	0.0 (p)	Not known	Approx. 1.5 (b)

2. Charge collection per sense wire: 2.5–3 mm in track direction. 3. This led to a momentum resolution measured in the experiment equal to $\delta p_t/p_t^2 = 5.3 \times 10^{-4} (\text{GeV}/c)^{-1}$ for high momentum muons.

11.4 Planar Drift Chambers of Type 1



Fig. 11.6a,b A drift cell of the CDHS chambers. (a) sense wires (*small circles*) and field wires (*large circles*) with their potentials in kV; some distances are also indicated in mm; (b) equipotential lines, delineating sensitive areas for one quarter of the drift cell, as indicated in (a)



Fig. 11.7 Cross section of a drift-chamber module of the DELPHI Muon Identifier; the delay line is incorporated in the cathode



Fig. 11.8 A drift cell of the DC1 chambers in the HELIOS experiment; dimensions in mm

double-track separation. The solution adopted involves a slow gas which in turn needed small drift cells in the high-multiplicity, high-rate environment. We see the drift cell in Fig. 11.8. It must provide a very homogeneous field because the gas is not saturated; therefore in each drift cell the eight sense wires are surrounded by a large number of field wires. In an attempt to reduce the influence of the drift-time variations, some of the field wires were given such potentials that only a fraction of the ionization along the track was collected on the sense wires. The whole stack consists of six chambers with three different wire orientations. The performance figures reveal that the outstanding measuring accuracy of 60 μ m per wire, reached with the prototype, worsened and became 120 μ m in the real experiment where the presence of many tracks deteriorated the critical field conditions.

The muon chambers of the L3 experiment are the result of a colossal effort to measure the momenta of fast muons with an accuracy of at least $\delta_{\rm PT}/p_{\rm T}^2 =$ $4 \times 10^{-4} \,{\rm GeV}/c^{-1}$, in cylindrical geometry. In the experiment, the radial space between 2.5 and 5.4 m was allocated to this task, inside a magnetic field of 0.5 T. The principle of the solution is sketched in Fig. 11.9; one observes that for the optimal measurement of momenta in the magnetic field, the chambers are concentrated at the inner and outer edges, and in the middle of the radial space (cf. the discussion in Sect. 8.2.6). Their local measuring accuracy is increased by sampling each track *N* times, thus gaining a factor of $1\sqrt{N}$ over the accuracy of a single wire – provided, the relative wire positions are sufficiently well known. For this purpose, the sense wires have been pulled over optically flat edges and are supported in the middle in a controlled fashion. We show in Fig. 11.10 the drift cell of the chamber type in the middle; it has N = 24 sense wires, 0.9 cm apart and 5.5 m long. Under operating conditions the Lorentz angle is 19°.





In order to make full use of the local accuracy, the three chambers traversed by a fast muon must be in well-known and constant relative positions. This has been achieved to an accuracy of $30\mu m$, or 10^{-5} of the size of the mechanical structure. This combination of size and positioning accuracy was unprecedented at the time in high-energy physics experiments.

The disk-shaped forward tracking chambers for the H1 experiment are in our collection on account of their circular symmetry and their *radial* sense wires. But they are also interesting because, in addition to measuring tracks, they serve for the detection of single photons created by transition radiators immediately upstream. For this double function the gas was chosen to contain a sizeable fraction of xenon with its short absorption length for soft X-rays.

The three-dimensional schematic drawing of Fig. 11.11 makes the 48 wedgeshaped drift cells visible. Each one has at its centre the radial plane of the eight radial sense wires, which are interspersed with field wires, and on both sides the cathode planes. So at the outer radius the drift space is larger than at the inner one in the ratio of these radii; and in order to maintain a uniform drift field in the cell, the cathode is divided into axial strips on such radially increasing potentials that the electric field is everywhere the same and orthogonal to the sense-wire plane. Suitable field degraders close the volume of every cell. The drift-time coordinate



Fig. 11.10 One drift cell of a middle muon chamber of the L3 experiment



Fig. 11.11 Schematic blow-up of the radial-wire drift chamber of the H1 experiment

is in the azimuthal direction, thus appropriate for a measurement of the particle momentum in the axial magnet. (The influence of the magnetic field on the drift directions has been neglected here, cf. Sect. 11.3.2.) The radial track coordinate is obtained by charge division on pairs of wires. Similar chambers had previously been constructed for the CDF experiment at Fermilab.

11.4.3 Type 1 Chambers without Field-Shaping Electrodes

The drift field of a conventional drift chamber is established by conducting surfaces (field wires, metal strips etc.) at suitable potentials. But according to an idea of Allison et al. [ALL 82a], the drift field can also be established by deposition of electrostatic charge on the insulating surfaces that delimit the gas volume. They showed that in a large flat plastic box one can get a very homogeneous field just with one proportional wire in the middle and two small cathode strips along the parallel



Fig. 11.12 A chamber without field-shaping electrodes

edges (Fig. 11.12). The deposition of charge is straightforward if the insulating surfaces are backed (on the outside) by grounded plates parallel to the surface. Looking at Fig. 11.13a, the field lines are as indicated at the moment that HV is applied to the sense wire. Any positive charge from the wire amplification will travel along the field lines and will fall onto the insulator and stay there to subsequently change the field configuration.

This process continues until there are no more field lines pointing at the insulator, i.e. the ideal field configuration is reached (Fig. 11.13b). As long as there is any charge amplification going on at the wire, the ideal field configuration will automatically be reached. It should be noted that for a thin chamber, the charge on the wire must finally be equal to the charge on the insulating surface. This implies that the gas amplification factor, which is determined by the amount of charge on the wire, cannot be altered without changing the drift field in the volume. The problematic side of this method is in the stability of the field. Although the positive charges are easily brought into place, they are not so easily removed following small fluctuations – these may be due to local discharges, bursts of particles, deposits on the wire, etc., and are probably unavoidable. Allison et al. consider insulators with a non-zero conductivity; these would create a dynamic equilibrium, which would become a function of the rate of charge deposition.

On the other hand the new principle makes it easy to construct very simple drift chambers. Franz and Grupen [FRA 82] have described the properties of a flat, round chamber $(1.4 \text{ cm} \times 50 \text{ cm diam})$ with only one short (1.4 cm) wire in the centre.



Fig. 11.13a,b Field

Becker et al. [BEC 82] have reported measurements with long and thin $(20 \text{ cm} \times 1.5 \text{ cm})$ plastic tubes, which could be bent. They have also discussed other applications of the new method. Dörr et al. [DOE 85] analyzed the behaviour of a circular chamber operating in the limited streamer-mode.

11.5 Large Cylindrical Drift Chambers of Type 2

Spanning a large cylindrical volume with wires parallel (or approximately parallel) to the axis requires strong end plates, which hold the wires, carry the combined pulling force, and keep them in accurate positions. Usually the end plates, together with the outer and inner cylinder mantles, also form the envelope for the gas. The wire feedthroughs that transmit the high voltage and the signals are essential elements of the construction.

11.5.1 Coordinate Measurement along the Axis – Stereo Chambers

Where charge division and time-difference methods were found insufficient, the idea of varying the wire directions throughout the volume has been widely used. The equivalent of a stack of type 1 chambers with differing wire orientations is a (type 2) 'axial stereo chamber'. In a cylindrical chamber with many concentric layers of drift cells, a stereo layer can be formed by rotating the end points on one side of the wire that belong to this layer by the small 'stereo angle' α and by keeping the end points fixed on the other side. The cylindrical surface of this wire layer turns from a cylinder mantle into a hyperbolic surface. The azimuthal wire position becomes a linear function and the radial wire position a quadratic function of z to the lowest order of αz counting from the middle of the chamber. This inhomogeneity distorts the electric field to some extent. The achievable precision δz is equal to the measurement accuracy $dr\varphi$ achieved in the azimuthal direction divided by the stereo angle. Hence there is interest in making α as large as the increasing inhomogeneities permit. In practice, stereo angles are built to plus and minus a few degrees, alternating with zero degrees in successive layers.

Obviously a z measurement can also be provided outside the cylindrical wire chamber with a type 1 chamber. In some experiments special 'z chambers' have been built for this purpose.

11.5.2 Five Representative Chambers with (Approximately) Axial Wires

Table 11.2 shows five chambers selected in the spirit described at the beginning of this chapter. In quoting performance figures we have indicated (see footnote 1 of the table) whether they are from early or later stages of the development of the detector.

Table 11.2 Some large cylindrical drift chamber	rs of type 2				
Name of experiment	Mark II	OPAL	ARGUS	SLD	CDF
Name of chamber	New CDC	Jet-chamber	Drift-chamber	CDC	CTC
Method of internal z-measurement	Stereo	Charge division	Stereo	Charge division	Stereo
Reference	[ABR 89]	[FIS 89]	[ALB 89]	[YOU 86]	[BED 88]
		[OPA 91]		[SLD 85]	[BER 91]
Geometry					
Outer/inner radius (cm)	152/19	183/25	172/30	96/24	132/31
Length (cm)	230	320-400	200	180	321
No. of wires	36936		30528	37760	36504
No. of sense wires	5832	3826	5940	5120	6156
No. of sense wires per cell	9	159	1	8	12; 6
Sense wire diameter (µm)	30	50	30	25	40
Max. no. of measured points per track	72	159	36	80	84
Radial distance between sense wires (mm)	8.3	10	18	5	7
Max. drift distance (cm)	3	3-25	1	n	4
Stereo angle $(^{\circ})$	4	0	2-5	3	б
Radial tilt of sense-wire plane (°)	0	0	I	0	45

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11 Existing Drift Chambers - An Overview

lable 11.2 (continued)					
Gas and fields					
Gas (percentage concentration)	$Ar(89) +CO_2(10) +CH_4(1)$	Ar(88) + $CH_4(10)$ +i- $C_4H_{10}(2)$	$C_3H_8(97) + CH_3OH(3) + H_2O(0.2)$	$\begin{array}{c} CO_{2}(92) \\ +i-C_{4}H_{10}(8) \end{array}$	Ar(49.6) + $C_2H_6(49.6)$ + $C_5H_5OH(0.8)$
Gas pressure (bar)	1	4	1	1	1
Electric drift field (kV/cm) Magnetic field (T)	0.7 0.47	0.9 0.4	1-2 (70%) 0.8	1.0 0.6	1.35 1.5
Drift velocity (cm/μs) ωτ (annrox)	5 04	0.3	4–5 < 1	0.9 0.05	_
Performance (1)					
Point-measuring accuracy $\sigma_{r\phi}$ (mm)	0.17 (c)	0.12 (b) 0.135 (c)	0.19 (c)	0.055 (b)	0.2 (c)
Charge division σ_z (mm)	I	30–40 (b) 60 (c)	I	9 (b)	I
Double-track resolution: $\Delta_{r\varphi}$ (mm)	3.8 (c)	2.5(c)	9 (a)	1 (a)	5 (c)
Accuracy of ionization measurement (%)	7.2 (c)	3.5 (b) 3.8 (c)	4.5–5.5 (c)		I
Accuracy of momentum measurement (2) $\delta p_t/p_t^2 (\text{GeV}/c)^{-1}$	0.0046 (c)	0.0012 (b) 0.0022 (c)	0.009 (c)	0.0015 (a)	0.001 (c) (3) 0.002 (c) (2)
1. The performance figures are based on: (a experiment) calculation and lab	oratory tests; (b) protc	otype and test beam me	easurement; (c) measur	ements in the running

experiment. 2. High p_t , full track length, chamber alone. 3. Using the constraint of the primary vertex.

It is not unusual that the prototype performed better than the full chamber eventually did in the experiment.

When the momentum-measurement accuracy actually achieved in an experiment is compared to that expected from the point-measuring accuracy, the number of points, and the magnetic field strength (Sect. 8.5.1), it is often not as good as anticipated. The overall mechanical accuracy, local and global field distortions, and imperfect calibrations all make their contribution to the momentum-measuring accuracy, which sometimes improves only slowly as the apparatus is better and better understood.

11.5.3 Drift Cells

The minimal wire configuration needed to establish the drift and amplification field around the proportional wire (which is at a positive potential) is a group of field wires at a negative potential around it. For a drift chamber of type 2, this elementary 'cell' is repeated to fill the whole volume. Figure 11.14 shows, as an example, drift cells of the ARGUS chamber; the full chamber consists of 5940 cells of this type. Advantages of this arrangement are the high degree of homogeneity over the full volume, the fine granularity, which allows the use of single-hit electronics, and the full track ionization that is employed. On the other hand, the local field around the wire in one cell is not very homogeneous and thus requires a very careful calibration of the critical relation between drift time and wire-track distance. In Fig. 11.15 we see the electron drift paths calculated for such a cell type [HAR 84]. They are in the form of spirals, created by the B field parallel to the wires. The contours of equal arrival times are circles near the sense wire, but they are shaped by the field-wire geometry far from the sense wire. This means in practice that the time-distance relation for tracks is a function of the orientation of the track with respect to the drift cell.

The design of the OPAL drift cell goes in the opposite direction (Fig. 11.16). The basic unit is a wedge-shaped sector that fills 15° of azimuth over the entire radial space so that the chamber consists of 24 of them. Each sector contains one radial plane of sense wires which are interspersed by field wires. The sense wires are actually staggered to resolve the left–right ambiguity. Each sector is limited and



Fig. 11.14 Drift cells of the ARGUS chamber. The sense wire is, typically, at 2.9 kV and the cathode wires are grounded




separated from its two neighbours by two common radial planes of cathode wires at such radially increasing potentials as to create a homogeneous drift field orthogonal to the central sense/field-wire plane. The inner surface of the enclosing cylinder carries suitable field degraders. This geometry has also been called '*jet chamber*' geometry. In this design the homogeneity is constructed into each sector, which is relatively large. Close tracks are resolved electronically by using short pulses and digital pulse-shape analysis. The dilemma of the Lorentz angle is diminished by a high gas pressure and a low magnetic field.

The cell design of the new MARK II chamber follows a similar line: radial sense/field-wire planes with radial cathode planes in between, but organized in 132 layers, 7.5 cm in radius. This is done in order to be able to create stereo angles in consecutive layers. There are 972 cells in the chamber. Figure 11.17 shows a cell with its electron drift trajectories.



Fig. 11.16 A section of the OPAL drift cell with electron drift lines. Upper plane: cathode wires; lower plane: sense/field wires



The small cell of the SLD drift chamber (Fig. 11.18) is designed to create a better separation between the amplification region and the drift region by displacing the field wires from their position between the sense wires to a position surrounding them. This is done to create a uniform drift region for the slow gas employed. Here the good diffusion properties of carbon dioxide have been combined with its low drift velocity at high electric fields. Thus the Lorentz angle is kept near 6° at the field of 0.6 T. On the other hand, this imposes severe requirements on the electric field uniformity, since the drift velocity under these conditions is proportional to the electric field ('unsaturated gas'). There are 640 drift cells in the detector. A very favourable point-measuring accuracy of 55 μ m was obtained with the prototype. This requires that the wire displacements caused by mechanical inaccuracy, gravity, and electrostatic forces as well as by the stereo arrangement are fully controlled to this precision.





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Fig. 11.19 A drift cell of the CDF central tracking chamber, with electron drift lines

The drift cells of the central tracking chamber of the CDF detector (Fig. 11.19) are inclined by 45° with respect to the radial direction in order to take the Lorentz angle at the employed magnetic field of 1.5 T into account. This solution also offers advantages for triggering and for pattern recognition. The arrangement of the drift cells, of which there are 660, in the end plate can be seen in Fig. 11.20. The cells are divided radially into nine superlayers which alternate between wires in the axial direction and wires at a $\pm 3^{\circ}$ stereo angle. Tilted drift cells are also employed for the drift chambers of the H1 and ZEUS experiments at the HERA e-p collider.





11.5.4 The UA1 Central Drift Chamber

The detector fills a cylinder, 6 m long and 2.2 m in diameter, which contains the collider-beam pipe on its axis. Equally horizontal, but at right angles to the beam, is the magnetic field of 0.7 T (see Fig. 11.21). Along its length, the cylinder is divided into three cylindrical sections, each 2 m long: the central section and the two forward ones. The wires are all parallel to the magnetic field and organized in planes according to the following scheme: the anode planes have alternating sense ($35 \,\mu m$ diam) and field (100 μ m diam) wires every 5 mm; the cathode planes with 120 – μ m wires, also every 5 mm, are parallel to the anode planes, leaving drift spaces of 18 cm between them. A peculiarity of the UA1 detector is the orientation of these planes – they are vertical in the central cylinder part and horizontal in the forward parts. This arrangement is a consequence of the horizontal magnetic field; the solution optimizes the momentum-measuring accuracy, the track curvature being measured by the drift time. The charge-division technique is used for the coordinate along the wire direction. Filled with a gas mixture of 40% Ar and 60% C₄H₁₀ at ambient pressure, the drifting electrons reach a velocity of 5.3 cm/µs under a Lorentz angle of 23° in their drift field of 1500 V/cm. The total number of wires is 22 800, of which 6110 are sense wires. A stiff vertical track is measured on 100 points and a stiff track near the forward directions on up to 180 points.



Fig. 11.21 Geometry of the UA1 central detector

11.5 Large Cylindrical Drift Chambers of Type 2

Performance figures were measured in the experiment as follows [NOR 90]: The average point-measuring accuracy in the direction of the drift amounted to 350 µm. The relative accuracy of momentum measurement, which depends very much on the track orientation, was typically $\delta p/p = (0.01 \text{ GeV}/c^{-1})p$ for isolated tracks in a favourable direction (obviously, the curvature of tracks that emanate from the interaction region under a polar angle of 90° and parallel to the magnetic field cannot be measured.) The electronic two-track resolution limit on a wire was about 5 mm. The coordinate measurement accuracy along the wires was 3.5% r.m.s. of the wire length after the gain reduction by a factor of three that was necessary when the detector had to work in the high-luminosity environment; before this change, 2% had been reached. These numbers illustrate the conflicting requirements of having the smallest possible space charge in the drift region (small wire amplification) and the best possible charge-division accuracy (large amplification) at the same time.

Ionization measurements of tracks in this complex detector were limited in accuracy and were not employed for particle identification.

In Fig. 11.22 we reproduce an event as reconstructed by the computer; the high number of measured points along each track make a clear picture even for the complicated events created in high-energy hadron collisions – in fact this picture is famous because it contains the first Z^0 particle ever observed. The two arrows mark the electron and the positron into which it decays.

11.5.5 The ATLAS Muon Drift Chambers (MDT)

The ATLAS experiment at the Large Hadron Collider (LHC) will investigate pp-collisions with a total energy of 14 TeV; muons with transverse momenta up to 1 TeV/c will be detected and measured in the muon spectrometer [ATL 97]. The purpose of the muon drift chambers is to determine the momenta of the muons as accurately as possible.

The ATLAS magnet produces a toroidal field in air (field lines going around the beam) which offers a high bending power at much reduced Coulomb scattering



Fig. 11.22 Computer-reconstructed event in the UA1 central detector – the first Z_0 particle ever observed is seen to decay into an e⁺ and an e⁻. Only one in two wire signals is displayed



Fig. 11.23 ATLAS muon drift chamber, consisting of a pair of threefold tube layers, separated by a spacer frame

because there is no iron yoke. The chambers consist of simple aluminium drift tubes with a diameter of 3 cm, carrying a central wire. (The theoretical work as well as the practical measurements that were done in order to find the best operating conditions for these tubes were published in a series of papers in 2000 [RIE 00]). They are mounted to form chambers as shown in Fig. 11.23; almost all chambers consist of a pair of threefold plane layers of parallel tubes, the triple layers being separated by a spacer. This is the basic unit, mostly 1 to 2 m wide and up to 6 m long in the direction of the tubes. There are 1194 of them, covering a total surface of 5500 m².

As the coordinate measurement of the drift tubes is perpendicular to the wires, the chambers are oriented with the wires essentially following the magnetic field lines. In the 'barrel', the chambers are arranged in three cylindrical concentric layers so that a stiff particle track from the interaction point is measured in all three layers for optimum momentum resolution (see Fig. 11.24). The vertical detectors in the 'end-caps' measure tracks in the more forward or backward directions in a similar way. It should be noted that the muon drift chambers can only determine one coordinate, the one that is useful for the momentum measurement. The azimuthal coordinate of a track is measured in other detectors of the spectrometer. The overall dimensions are characterized by a cylindrical volume into which the muon spectrometer can be fitted; it is 22 m in diameter and 45 m long. The barrel chambers occupy radial space between 4.5 and 11 m, and the longitudinal space for the vertical end plates extends from 7 to 11 m on either side of the interaction point. At the time of writing the second edition of this book, the spectrometer is being assembled to start operation in 2008.

The momentum measuring accuracy in the given magnetic field depends essentially on three factors: (1) the track measuring accuracy of the individual tube, (2) the accuracy with which the relative positions of the tubes are known, and



Fig. 11.24 Cross-sectional view of the barrel part of the ATLAS muon spectrometer. The cross sections of the eight coils of the toroid magnet are visible as white circles; the chambers are located inside and between them. The diameter of the barrel is approx. 22 m

(3) the multiple scattering in the chambers and the structural material traversed by the particle.

1. The accuracy achieved for an individual drift tube in the absence of a magnetic field is depicted in Fig. 11.25 as a function of the distance between the track and the wire. The working gas mixture for these measurements was 91%Ar + 4%N₂ + 5%CH₄ at 3 bar abs., which allows an r.m.s. measuring accuracy of approx. $75 \,\mu$ m to be reached for drift distances above 3 mm. For smaller drift distances the accuracy quickly becomes worse as the primary ionization fluctuation dominates. In view of the problems of ageing in the high flux regime (cf. Sect. 12.6.4), it was later decided to go to 93%Ar + 7%CO₂ at 3 bar abs. The unfavourable dependence of drift velocity on the *E*-field of this gas had to be accepted. The resolution achieved with the new mixture is shown in Fig. 7.19.

2. The geometrical integrity of each chamber is guaranteed by glueing the tubes onto the frames. During the experiment, a laser calibration system will follow the internal elastic deformations caused by changes of temperature or stress. For the measurement of momentum it is important to know the relative positions of the three chambers that together determine the sagitta of the particle track. For



this purpose, the chambers of this 'tower' are interconnected by laser rays seen by position-calibrated detectors on the chambers.

3. The mechanical structures for the support of the magnet, the chambers, and all the other detectors of the ATLAS experiment are almost all made of aluminium. They represent a mass of material which causes a lot of Coulomb scattering in addition to that of the chambers proper. It may be quite different from one track to another; on average it causes relative transverse momentum measurement errors $\delta p_T/p_T$ typically between 2 and 3%. The aluminium of the chambers themselves contributes approx. 1%.

The overall momentum-measuring accuracy of the muon spectrometer is calculated to be roughly $\delta p_T/p_T = 0.1$ at $p_T = 1$ TeV/c, dominated by (1) and (2), and 0.03 at $p_T = 10$ GeV/c, dominated by (3).

11.5.6 A Large TPC System for High Track Densities

The NA49 experiment at the CERN SPS accelerator is dedicated to the study of hadron production on fixed targets in proton-proton, proton-nucleus, and nucleus-nucleus collisions [AFA 99]. A system of 4 large TPCs with a total sensitive volume of 33 m^3 is the main instrument for tracking and dE/dx measurement. The incoming beam passes between them, compare Fig. 11.26. Central lead-lead collisions at the beam momentum of 158 GeV/c per nucleon can produce more than a thousand tracks in one event.

Of the four TPC modules, the two smaller ones are operated inside strong and not very homogeneous vertical magnetic fields, the two larger ones outside. The drift is vertical, the sensitive wire chamber end plates horizontal. The wire grids are

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Fig. 11.26 Top view of the four TPCs; the two 'vertex chambers' inside the magnetic field are on the left, the two 'main chambers' to both sides of the beam outside the magnetic field are on the right. A central Pb + Pb event is depicted in a slice only 7 mm high around the beam plane, in order to be able to distinguish tracks in the projection

designed as in the ALEPH TPC but have a reduced distance between pads and sense wires. Their total area amounts to 30 m². Signals are read out only from the cathode pads of which there are 182 000. A maximum of 234 pad rows is available for the measurement of fully recorded tracks, but the actual number of signal clusters lies approximately between 20 and 160, depending on track overlap and kinematics in the given acceptance region. The authors estimate that an over-all position precision of about ± 0.20 mm has been achieved for isolated tracks, varying with the drift length between ± 0.15 and ± 0.28 mm.

The separation of neighbouring tracks is a major challenge in this experiment. The diffusion properties of the gas and the other detector parameters have been designed with the aim to reach a charge distribution within typically 5 mm FWHM. The authors show that track pairs with average distances above 1.6 cm are fully detected, those with distances of 1.0 cm are detected with 50% efficiency. Further improvements seem to be in reach. It is remarkable that the TPC technique can be extended to record tracks in such high particle densities.

This was made possible by an increased density of cathode pads and the associated electronic channels. The entire front-end electronics up to the digital outputs is mounted on the TPC readout chambers, the pad widths being not more than 3.5 or 5.5 mm.

The high particle density is a challenging environment also for particle identification using dE/dx measurements. It is difficult to control the pulse height variation with drift time which is partly caused by the baseline shift of the electronic signals, partly by the widening of the measured charge clusters at the required threshold, but only to a smaller degree by electron attachment. It is also not easy to correct for electronic cross-talk at these high particle densities. Despite of these severe conditions, the authors are able to report an r.m.s. resolution for the dE/dx measurement of $\sigma_I = 38\%/\sqrt{N_c}$ where the number N_c of signal clusters lies between 20 and 160. The method of charge estimation applied is the one of the truncated mean at the 50% level. The relativistic plateau is IR = 56% above minimum ionization.

Using the ratio σ_I/IR as a measure for the ability of particle identification one can say that the NA49 TPC system reaches a similar level of identification ability as the detectors listed in Tables 10.3 and 10.4, once the losses of signal clusters from track overlap and acceptance limitation are taken into account.

11.6 Small Cylindrical Drift Chambers of Type 2 for Colliders (Vertex Chambers)

Vertex detectors are needed for the measurement of the (primary) interaction vertex or any secondary vertices that may occur in an event from the decay of short-lived particles. The charm, bottom and τ particles have lifetimes of the order of 10^{-13} to 10^{-12} s, so the tracks from the secondary vertices will miss the primary vertex by correspondingly small distances, which are of the order of 30 to 300 µm. Ideally, vertex chambers should have even better measurement accuracies.

This is the field where the fine-grained solid-state particle detectors with their superb spatial resolution are often a better choice than gas drift chambers. These have in their favour the simplicity of a proven technique and a somewhat better resistance against high-radiation background. Also they are more easily extended over large sensitive areas. Being closer to the interaction point they can often be built smaller and with shorter wires than the large axial chambers, so that the wire position can be extremely well defined. This is a prerequisite for the high measurement accuracy achieved in the vertex chambers. When measuring the position of a vertex inside the vacuum tube, multiple scattering in the wall of the tube is often a limiting factor, which depends on the momentum of the extrapolated particle as well as on the tube radius and the thickness of the wall.

In order to reach the best possible point-measuring accuracy and double-track resolution, the sense wires have to be as close as possible to each other (cf. the discussion in Sect. 11.8). The limit imposed by electrostatic stability depends on the wire length and the detailed electrostatic pattern, and it becomes more severe at higher gas pressures because of the corresponding higher voltages.

To find the correct gas, one has to balance the consequences of a slow 'cool' gas (see Sects. 2.2.4, 12.1) – slower electronics, high drift field with low diffusion, sensitivity to field inhomogeneity through unsaturated drift velocity – with the consequences of a fast 'hot' gas – faster electronics, lower sensitivity to field, temperature and pressure variations.

These questions have been studied in detail for the more recent vertex detectors. The chambers listed in Table 11.3 are again intended to represent the different choices in the field. They are all axial drift chambers of type 2. The ones that reach the highest precision are operated with slow cool gas at an elevated pressure. Hayes has compared vertex drift chambers for the LEP and SLC detectors [HAY 88]. The

Table 11.3 Some small drift chambers of type 2 ((vertex chambers)					
Name of experiment	UA2	MARK J	MARK II	OPAL	MAC	ALEPH
Name of chamber	JVD	TEC	DCVD	VCH	straw-VC	ITC
Method of z measurement	Charge division	Ι	I	Time difference	I	Time difference
				+stereo		
Reference	[BOS 89]	[98 GND 86]	[ALE 89]	[CAR 90]	[ASH 87]	[DET 90]
		[AND 88a] [AND 88b]	[DUR 90]	[OPA 91]	[NEL 87]	[BAR 89]
Geometry						
Outer/inner radius (cm)	13/4	12/5	17/5	22/10	9/3.5	28/13
Length (cm)	100	58	55	100	43	200
No. of wires	1232	2750	1800		324	5136
No. of sense wires	208	168	190	648	324	096
No. of sense wires per cell (6)	13	14	19	12(6)	1	1
Sense-wire diameter (µm)	25	20	20	20	30	30
No. of measured points per track	13	14	19	18	6	8
Radial distance between sense wires (mm) (6)	6.4	2.4	2.9	5.0(5.3)	6-10	11-19
Max. drift distance (cm)	2.5	1.3 - 2.6	3	0.8 - 1.9	0.35	0.47 - 0.65
Stereo angle $(^{\circ})$	0	0	0	4	0	0
Radial tilt of sense wire plane (°)	0	土 4	15	0	I	I

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Gas (percentage concentrations)	Ar(60)	$CO_{2}(80)$	$CO_{2}(92)$	Ar(00)	Ar(49.5)	Ar(50)
)	$+C_{2}H_{6}(40)$	$+i-C_4H_{10}(20)$	$+\overline{C}_{2}H_{6}(8)$	$+CH_4(10)$ +i-C4H_10(2)	$+CO_{2}(49.5)$ +CH ₄ (1)	$+C_{2}H_{6}(50)$
Gas pressure (bar)	1	1.9	2	4	4	1
Electric drift field (kV/cm)	1	1.6	1.5	2.7	2-7 (70%)	3-5
Magnetic field (T)	0	0	0.47	0.4	0.6	1.5
Drift velocity (cm/µs)	5.2	0.7	0.6	4.0	1-3 (70%)	5.0
Approx. value of ωau	0	0	0.02	0.1	small	small
Performance (1)						
Point measuring accuracy	150 (b)	35 (b)	30 (b)	50 (b)	70 (c) (4)	100 (b)
$\sigma_{r\phi}$ (μm)	180(c)(3)	40 (c)	50 (c)	55 (c)	45 (c) (3)	150 (c)
	300(c)(5)					
Charge division or time difference	10 (b)	I	I	45 (c)	I	30 (b)
accuracy $\sigma_z(mm)$	25 (c) (3) 35 (c) (5)					
Double-track resolution $\Delta_{r\varphi}$ (mm)	2 (b)	0.3 (b) (7)	0.5 (c) (8)	2.0 (c)	6.9	11 (a)
Impact-parameter accuracy (2)					87 (c) (3)	130 (c)
$\sigma_t \ (\mu m)$	400 (c)	80 (b)	30 (c)	30 (c)	200 (c) (4)	

running experiment.

2. Vertex chamber plus main tracking chamber - high-momentum tracks.

3. Isolated tracks.

Multihadron events, including multiple scattering.
 Multihadron events, average multiplicity 31 to 35.

6. Numbers in brackets refer to the OPAL stereo cell.

7. Track separation at which 50% of the tracks are correctly resolved.

8. Track separation at which approx. 100% of the tracks are resolved.

Table 11.3 (continued)

proceeding of a workshop dedicated mostly to advanced vertex detectors [VIL 86] offers some more material that describes the state of the art in 1986. A short review on straw chambers was given by Toki [TOK 90].

Among the more recent vertex detectors we find the drift chambers with the best measuring accuracy that are integrated into particle experiments. Higher accuracy has only been achieved with more specialized devices. These will be briefly discussed in Sect. 11.8.

11.6.1 Six Representative Chambers

The JDV of the UA2 experiment had to work in severe background conditions at the $\bar{p}p$ collider. The drift cell, shown in Fig. 11.27, has a geometry similar to that of the OPAL chamber; it operates in a fast gas at atmospheric pressure, and at the saturated drift velocity. The point-measuring accuracy achieved in the test beam (150 µm) deteriorated a lot (300 µm) in the large-multiplicity events of the real experiment.

The vertex detector of the MARK-J experiment is built according to the principle of the 'time expansion chamber', or 'TEC'. Introduced by Walenta [WAL 79], it is characterized by a wire amplification region strictly separated from the drift region by a dense wire grid or wire mesh. The drift cell of the MARK-J TEC is shown in Fig. 11.28 and represents one twelfth of the entire chamber. One recognizes the two wedge-shaped drift spaces on either side of the 4 mm wide amplification region; they are not symmetrical because the sense/field wire planes are inclined alternatively by $\pm 4^{\circ}$ in the service of pattern recognition. The gas is a slow and cool mixture of 80% CO₂ and 20% i-C₄H₁₀. The sense wires are read out by 100 MHz analogue-to-digital converters (flash-ADCs). An average point-measuring accuracy of 40 μ m was determined with Bhabha events.



Fig. 11.27 Drift cell of the UA2 JVD chamber



Fig. 11.28 Drift cell of the TEC of the MARK J experiment

The MARK II vertex chamber was designed for the SLAC Linear Collider with its small beam pipe, which has a radius of 2.5 cm. The inner wall of the chamber and the beam pipe represent a total of 0.6% of a radiation length, thus contributing only 45 μ m GeV/*c* to the Coulomb scattering limit *S_c* discussed in Sect. 8.4.2.

The wires run parallel to the axis, and they are organized in cells that each span the full radial range between 5 and 17 cm (see Fig. 11.29). In the middle of each cell is the sense/field-wire plane, inclined by an azimuthal tilt angle of 15°; it contains 41 field wires, spaced out by 2.9 mm, and 40 sense wires between them. Two planes of grid wires, 1.8 mm on either side, separate the amplification region from the drift region and provide a certain amount of focussing for the electron drift paths, similar to what happens in the 'TEC'. The cathode planes with 59 wires, spaced out by 2 mm, bisect the angle between the sense/field-wire planes of two adjacent cells. Each drift cell is thus limited by the two cathode planes at radially increasing potentials and additional potential wires at the cylindrical surfaces. They complete the field cage which provides a uniform field despite the wedge of drift space it encloses.

The OPAL vertex chamber is constructed for LEP whose beam pipe is much larger than the one at the SLC. With its radius of 7.8 cm and its thickness of 0.86% radiation lengths the OPAL pipe contributes a Coulomb scattering limit $S_c = 110$ GeV/*c* to the impact-parameter resolution.

Fig. 11.29 Drift cell of the VCDV of the MARK II experiment



The wire pattern is shown in Fig. 11.30. The chamber is 100 cm long. It has one axial and one stereo layer at 20° . The axial layer between radii of 9.4 and 17.1 cm is of the 'jet chamber' type and has 36 radial planes of sense/field wires, each containing 12 sense wires spaced out by 5 mm, and the field wires between them. The left–right ambiguity, which does not occur when the sense-wire plane is tilted with



Fig. 11.30 Wire pattern of the OPAL vertex chamber



respect to the radial direction, is resolved by staggering alternative sense wires by $\pm 41 \,\mu\text{m}$ which increases to $\pm 80 \,\mu\text{m}$ in the middle of the wires, owing to their electrostatic forces. The 10° in azimuth between two neighbouring sense/field-wire planes are bisected by the radial-wire-cathode planes, so that the maximal drift distance varies with radius from 9 to 15 mm. There is a double layer of potential wires to close the field cage of each cell. This produces a field that is uniform and at right angles to the sense/field-wire plane by grading the cathode voltages appropriately.

The stereo layer occupies the radial space between 18.2 and 22.6 cm; it is organized in the same fashion, but there are only half as many sense wires in this layer. The maximal drift distances are now between 1.6 and 1.9 cm.

Each of the 648 sense wires is read out at both ends and is timed with a constant-fraction discriminator and a time-to-digital converter (TDC). Thus, there is a coordinate measurement along the wire direction from the time difference, in addition to the azimuthal coordinate determined from the average of the two times.

The OPAL vertex detector is operated with the slow mixture CO_2 (92%) + i-C₄H₁₀ (8%) at 2.5 bar. The space resolution achieved with the drift-time measurement is depicted in Fig. 11.31 as as function of the drift distance, both for the OPAL and the MARK II vertex detector prototypes. The resolution has reached the remarkable range between 20 and 40 µm for drift distances up to 3 cm. With fast gas and the same electronics, the resolutions were two or three times worse [HAY 88].

Fig. 11.32 One quarter of the end plate of the MAC straw vertex chamber (for dimensions, consult Table 11.3)



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The drift chambers of the last two examples in our list are again constructed from cells that are built around the individual sense wires. The vertex chamber of the MAC detector consists of many thin tubes of aluminized Mylar foil with the proportional wire in the centre. These '*straws*' provide exact cylindrical symmetry and a high degree of electrical shielding between sense wires. Their inner diameter is 6.9 mm, and the wall thickness $50 \,\mu$ m. In Fig. 11.32 we see the layout of the vertex chamber end plate.

The cylindrical geometry produces a drift field that increases with the inverse distance from the wire. The drift velocity therefore also changes, depending on the gas used. In Table 11.3 we have indicated ranges for the field and the velocity that are valid in the outer 70% of the drift region. In a similar design for the MARK III experiment [ADL 89], the gas mixture was argon–ethane with a more uniform, and higher, velocity; the achieved point-measuring accuracy was comparable. Toki has recently reviewed straw chambers [TOK 90].

The purpose of the ALEPH-ITC is the production of an early trigger signal as well as precise tracking (a solid-state microstrip detector is mounted in addition). The drift cell is a group of six field wires around each proportional wire, in a flat hexagonal arrangement, which is depicted in Fig. 11.33. Each hexagon is characterized by two shape parameters, the diameters in the radial and in the circumferential directions; both vary with the wire layer. A time-difference measurement is the basis for a determination of the axial coordinate. It takes 0.5 µs for a trigger decision in $r - \phi$ and 2.5 µs in $r - \phi - z$.

11.7 Drift Chambers of Type 3

An ionization track created in the sensitive gas volume of a type 3 chamber drifts to one of the end faces that delimit the volume. It is there that the amplification and signal generation take place. Large chambers have drift lengths of one or several metres. If a magnetic field is present in a TPC, it is parallel to the drift field, and in this orientation it can greatly improve the transverse diffusion of the travelling electrons, on account of the magnetic anisotropy of diffusion; see Sect. 2.2.6.

With the length of the drift path we have a correspondingly high drift time – often many tens of microseconds for electrons and several seconds for ions. This makes long type 3 chambers unsuited for measuring events at very high rates because the

space charge from previous events in the drift space will distort the tracks. Ion shutters ('gating grids' – see Chap. 9) are suitable tools for reducing the amount of ion current that flows back into the drift volume from the amplification region.

The length of the drift path also sets severe requirements on the uniformity of the electric and magnetic fields: a non-uniformity of one per cent may cause transverse displacements of the order of one per cent of the drift length.

Finally we mention gas purity. Electrons may be attached to gas components that are present even in extremely low concentrations, the result being a signal loss that increases with the drift path. We have described electron attachment in Sect. 2.2.7.

Still a TPC can be a very powerful universal track detector. If all the abovementioned problems have been overcome, one profits from its advantages: with its wires strung on the inner surface of the end-plates rather than through the volume the construction can be modular and technically very convenient. For every track segment one achieves an intrinsically three-dimensional coordinate determination – two coordinates being given by the position in the end plate of the pick-up electrodes that collect the segment, the third being measured through the drift time.

Furthermore, with a TPC one can totally avoid the dilemma of the Lorentz angle: if one puts B and E parallel in the drift volume, there is no shift of the drift direction, and the magnetic field may be increased as far as technically feasible, the gas pressure can be kept low, and the diffusion may be dramatically reduced; cf. the discussion in Chap. 12.

11.7.1 Double-Track Resolution in TPCs

The measurement of a track produces a dead region around this track where the chamber is insensitive to the measurement of other tracks. In a TPC with cathode pads, this dead region is a tube around the track, whereas in axial wire chambers and in TPCs with wire measurement it is a flat region that extends along the full length of the wire.

Concerning track measurements with pads, overlap occurs on the pad when it is still occupied with the pulse of a first track at a time when the pulse of a second track begins. The pulse length *T* is given by the intrinsic electronic pulse length t_e plus the drift-time difference t_d of the electrons from one track that reach the pad at different times, because of a track inclination θ and the size *h* of the pad. With reference to Fig. 11.34 we have an overlap region Δz in the drift direction, equal to

$$\Delta z = ut_{\rm e} + ut_{\rm d} = ut_{\rm e} + h/\tan\theta , \qquad (11.1)$$

where u is the drift velocity and θ the angle between the track and the normal to the pad (typically the polar angle). In Table 11.4 double-track resolutions are quoted for two polar angles.

In the azimuthal direction, two tracks will have to be 2 or 3 pad widths apart in order to be separable; a practical average may be 2.5 pad widths.



11.7.2 Five Representative TPCs

There are four large cylindrical TPCs that have been built around the interaction points of e^+e^- colliders (PEP-4, TOPAZ, ALEPH, DELPHI); see Table 11.4. They are all very similar because their construction followed closely the principles established by the pioneers in this field, the designers of the PEP-4 TPC. These chambers are cylinders around the colliding beams; the drift direction is parallel to the magnetic field and to the direction of the incoming particles. The drift volume is divided in the middle by the high-voltage membrane which is set at a negative potential so that the circular end plates with their detection electrodes can be kept at earth potential (Fig. 11.35). The disposition of the various layers of electrodes in the end plates is seen in Fig. 11.36a, and Fig. 11.36b shows the arrangement of the pads in the cathode plane in the example of the ALEPH TPC. The inner and outer cylinder mantles that delimit the gas volume also carry the high-voltage electrode rings, which shape the axial, homogeneous electric drift field.

The four large TPCs differ among each other in two respects: the PEP-4 and TOPAZ TPCs are constructed to work at higher gas pressure and with straight pad rows; the ALEPH and DELPHI TPCs have ambient pressure and circular pad rows. The gas pressure is an important choice for any drift chamber (see the discussion in Sect. 12.5), but for TPCs one must consider in addition the magnetic anisotropy of diffusion – the transverse width of the diffusion cloud increases with the pressure. The circular pad rows in the two TPCs at CERN are an improvement over the (earlier) straight rows, since for stiff radial tracks they do not cause the measurement error that was called the 'angular pad effect' in Sect. 7.2.

Whereas the width of the pad determines the number of electronic channels and hence the cost of the project, the length of the pads (extent in the radial direction) is chosen as a balance between the largest possible signal and a loss of accuracy of lower-momentum tracks, owing to the angular pad effect (cf. Sect. 7.3.3). Also, long pads deteriorate the two-track separation for steep tracks (Sect. 11.7.1). The long pads in the ALEPH TPC reflect a choice in favour of a larger signal.

The problem of track overlap may be quantified as a loss of tracks rather than points specifying the minimum opening angle Δ_{α} measured between two tracks at the vertex, below which losses are observed. The minimum opening angle is smaller for pairs with opposite curvature because the magnetic field bends them apart. Such

Table 11.4 Some TPCs built around colliders					
Name of experiment	PEP 4	TOPAZ	ALEPH	DELPHI	CDF(1)
Reference	[LYN 87]	[KAM 86]	[DEC 90]	[BRA 89]	[SNI 88]
	[AVE 89]	[SHI 88]	[ATW 91]	[AAR 90]	
				[SIE 90]	
Geometry					
Outer/inner radius (cm)	100/20	127/30	180/31	116/32	21/7
Drift length (cm)	2 imes 100	2 imes 122	2 imes 220	2 imes 134	2 imes 15
Number of sense wires	2196	2800	6336	1152	384
Sense-wire spacing (mm)	4	4	4	4	6.3
Number of pads	13824	8192	41004	20160	384
Pad dimensions $(r \times r \varphi) (mm^2)$	7×7.5	12 imes10 (4)	30 imes 6	8 imes 7	41 imes 14
Max. no. of measured points per outgoing track					
On pads	15	10	21	16	e,
On wires	183	175	338	192	24
Gas and fields					
Gas (percentage fractions)	Ar(80)	Ar(90)	Ar(90)	Ar (80)	Ar(50)
	$+ CH_4(20)$	$+ CH_4(10)$	$+ CH_4(10)$	$+ CH_4(20)$	$+ C_2 H_6(50)$
Gas pressure (bar)	8.5	3.5	1	1	-
Electric drift field (kV/cm)	0.55	0.35	0.12	0.15	0.25
Magnetic field (T)	1.32	1.0	1.5	1.2	1.5
Drift velocity (cm/µs)	5	5.3	5.0	6.7	4.3
Approx. value of $\omega \tau$	1.5	4.9	7	5.4	3.5

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Performance (2)					
Point-measurement error radial tracks					
On pads: $\sigma_{r\omega}$ (mm)	0.15 (c)	0.20 (c)	0.17 (c)	0.18 (c)	0.4
σ_{7} (mm) at 90°/30°	0.16/(c)	0.3/1.0 (c)	0.74/2 (c)	0.9(c)	I
On wires: σ_z (mm)		0.3/1.0(c)	2 (b)	(0.9)	0.4 - 1
Double-track resolution	2.4 (c)	2.5 (a)	1.5(b)	1.5 (c)	I
On pads: $\Delta_{r\phi}$ (cm)					
Δ_{z} (cm) at 90°/30°		3/3 (a)	2/6 (b)	1.5 (c)	I
$\Delta_{\alpha}(\text{mrad})$	25–40 (c)		35 (c)		
On wires: Δ_z (cm)		3 (a)	2 (b)	1.5 (c)	0.5 - 1.5
Accuracy of momentum measurement (3)	0.009 (c)	0.015 (c)	0.0012 (c)		Ι
$\delta p_t/p_t^2 ({ m GeV}/c)^{-1}$					
Accuracy of momentum measurement (5) $\delta p_t/p_t^2 (\text{GeV}/c)^{-1}$	0.0065 (c)		0.0008 (c)	0.0015 (c)	I
 Numbers are given for each one of the 8 TPC. The performance figures are based on (a) c 	s ('modules'), each havir alculation and laboratory	ig two halves with oppo y tests; (b) prototype ai	site drift directions. nd test-beam measureme	nts; (c) measurements	in the running

Table 11.4 (continued)

(c) 5 2. The performance figures are based on (a) calculation and laboratory tests; (b) pr experiment
 3. High p_i, full track length, TPC alone.
 4. Zig-zag shape along rφ, depth ± 2 mm.
 5. High p_i, full track length, TPC plus other detectors.

11.7 Drift Chambers of Type 3



Fig. 11.36a,b Disposition of the electrodes on the end plate of the ALEPH TPC (distances in mm). (a) Wire grids; (b) pad plane

loss studies have been performed for the PEP-4 and the ALEPH TPCs and the corresponding values of Δ_{α} are also listed in Table 11.4. They represent averages over the full solid angle.

In Table 11.4, besides the four large TPCs mentioned above, we have included one other TPC built around a collider, the CDF vertex TPC system, which consists of eight double chambers near the beam pipe and predominantly serves the purpose of a vertex detector.

11.7.3 A Type 3 Chamber with a Radial Drift Field

The central tracking device for the ASTERIX experiment at CERN [AHM 90] is a cylindrical volume around a gas target. The inner cylinder mantle is a thin aluminized foil with a diameter of 16 cm, the outer mantle has a diameter of 30 cm and carries the detection electrodes: 90 axial sense wires and 270 field wires backed by helical cathode strips. The inner mantle is at a potential of -10 kV; the circular end faces (1 m apart) incorporate field degraders down to the earth potential of the outer cylinder.

With the radial drift field at right angles to the axial magnetic field, which amounts to 0.8 T, the drift paths for the electrons take on the curved forms visible in Fig. 11.37; this gave rise to the name '*spiral projection chamber*' for this device [GAS 81]. Filled with a gas mixture of argon (50%) and ethane (50%), the chamber was primarily used for the detection of X-rays in the keV range, but also for the measurement of particle tracks. A stiff track crosses the drift cells that belong to 5 different sense wires, thus allowing 5 track coordinates to be measured. The number of measured points depends very much on the track curvature.

For the reconstruction of the primary vertex point, an accuracy was achieved which amounted to $\sigma = 0.4$ mm transverse to the beam and $\sigma = 2.1$ mm in the longitudinal direction.



Fig. 11.37 Drift paths of the ASTERIX drift chamber

11.7.4 A TPC for Heavy-Ion Experiments

The interaction of a heavy ion of several hundred GeV per nucleon with a fixed target often produces hundreds of secondary particles. TPCs have been built to study such high-multiplicity events downstream of a fixed target, and we discuss here the Brookhaven chamber as an example [ETK 89]. Like the first TPC, it operates in a magnetic field (0.5 T) parallel to the electric drift field (330 V/cm). However, the electronic signals are derived not from cathode pads but from short (\approx 1 cm) anode wires, which are spaced out by 2.54 mm along several parallel straight rows.

There are three thin-walled TPC modules, one behind the other, which are separate containers of the gas, a mixture of argon (79%), isobutane (16%) and dimethoxymethane (5%) at ambient pressure. In each module the sensitive surface is horizontal, and the vertical y coordinate is measured using the drift time. The x coordinate along each anode row is measured by the wire addresses and a suitable interpolation, but only the fact of a hit above some discriminator threshold is recorded. There are twelve anode rows per module, one every 3.8 cm along the z direction of the incoming beam, and altogether 3072 channels per module.

For the high-multiplicity events a good two-particle separation capability had to be the essential goal of the construction and of the pattern-recognition programme. The measured result was that two tracks could be separated in 50% of the cases if they lay inside the same area that measured $5 \times 5 \text{ mm}^2$ in *x*–*y*. The effective r.m.s. point-measuring accuracy amounted to $\sigma_x = 0.9 \text{ mm}$ and $\sigma_y = 0.75 \text{ mm}$ for secondary tracks from Si interaction, whereas isolated beam tracks could be measured much better. The drift velocity was 2.3 cm/µs.

The beam projectiles are fully ionized, and since the gas ionization that they create is proportional to the square of their electric charge, there is a beam-rate limitation in the TPC owing to the build-up of primary positive charge. The authors observed that an intensity of 2×10^4 oxygen nuclei per AGS spill of 1 s distorted the tracks to the extent that their apparent sagitta was 0.5 mm in y - z.

In Fig. 11.38 we see the x-y projection of an event with 77 tracks pointing to the vertex. Whereas it must be very difficult to measure the track reconstruction efficiency, it is impressive to what extent the drift-chamber technique is capable of reconstructing such complex events.

11.7.5 A Type 3 Chamber as External Particle Identifier

A drift chamber specialized in particle identification, ISIS2, was built by Allison et al. [ALL 84] as part of the European Hybrid Spectrometer. Located behind a fixed target at the SPS machine at CERN, this spectrometer contained two magnets and numerous chambers for the measurement of particle tracks and momenta. The purpose of ISIS2 was to precisely record the ionization of the particle tracks, whereas their coordinates would only have to be measured with moderate accuracy. A schematic diagram of this huge and almost empty box is seen in Fig. 11.39. The



Fig. 11.38 Projection along the beam of a heavy-ion event (silicon beam on gold target) reconstructed in the Brookhaven TPC [ETK 89]



Fig. 11.39 Geometry of the ISIS2 chamber

useful volume is 4 m high, 2 m wide and 5.12 m long; it is divided into two drift spaces by a single horizontal wire plane of alternate anodes and cathodes at half the chamber height. The particles are supposed to enter the chamber through the front window, which is part of the field cage that shapes the vertical electric field of 500 V/cm. There is no magnetic field. The ionization electrons from each track drift in the uniform field and are amplified on 640 proportional wires connected in pairs to 320 channels of multihit electronics. The chamber is filled with a gas mixture of 80% Ar and 20% CO₂ at ambient pressure. The performance of this type 3 chamber was characterized in Chap. 9 in the context of particle identification.

11.7.6 A TPC for Muon-Decay Measurements

In a search for muon–electron conversion, the TRIUMF group employed a TPC which was to measure and identify low-momentum electrons and positrons in the region of 100 MeV/c [BRY 83, HAR 84]. The apparatus surrounded a target foil in which muons were degraded and stopped. The TPC was shaped as a hexagonal cylinder as shown in Fig. 11.40, approximately 70 cm long and equally large in diameter, with a central high-voltage plate; the two end plates carried the readout wires and were at earth potential. The drift field E was 250 V/cm to yield a saturated drift velocity of 7 cm/µs in an argon–methane gas mixture (80/20). A magnetic field of 0.9 T was oriented parallel to E. In order to protect the gas volume as much as possible from positive ions produced at the anode wires, a double layer of a monopolar gating grid (see Sect. 9.2.1) was mounted at the entrance of the amplification region. It was kept 'closed' until a trigger signal arrived.

Fig. 11.40 A perspective view of the TRIUMF TPC [BRY 83]. (1) Magnet iron; (2) coil; (3) outer trigger scintillators; (4) outer trigger proportional counters; (5) end-cap support frame; (6, 8) field cage wires; (7) central high-voltage plane; (9) inner trigger scintillators; (10) inner trigger proportional wire chamber; (11) TPC end-cap proportional wire modules



11.8 Chambers with Extreme Accuracy

The accuracy of coordinate measurement is the crucial point of most drift chambers. As we have discussed throughout this book, the essential parameters are those itemized in Table 11.5. The choices open to the designer that correspond to these parameters are quoted in the right-hand column of the table. We notice that some of them represent conflicting requirements. For example, slow gas is not saturated at practical electric fields, and reduced sense-wire distances cause larger wire bowing owing to electrostatic forces that add to the gravitational sag. There are of course all the other important boundary conditions of the particle experiment - interaction rate, space available, radiation material tolerable, and, last but not least, cost which further restrict the choices to be made in the quest for the very best accuracy. Therefore, it is a much harder goal to achieve good accuracy in a drift chamber that is part of a particle experiment than in a test chamber built for a more specialized investigation. The problems connected with small wire distances and mechanical accuracy are obviously better solved in chambers with small dimensions. For these reasons, the chambers that have reached extreme values of accuracy are small and specialized.

A chamber containing xenon gas under a pressure of 20 atm was presented by Baskakov et al. and is depicted in Fig. 11.41 [BAS 79]. It is the most precise drift chamber known to us. Its two anode wires have no electrical amplifiers attached to them but are viewed by two photomultipliers, which register the light pulse emitted

Diffusion:	Gas with low diffusion
	Elevated gas pressure
	Magnetic field
Drift-path variations:	Reduced sense-wire distance
-	Focussing of drift trajectories
	Drift-path restrictions
Ionization clustering:	Elevated gas pressure
Time measurement:	Fast electronics
	Slow gas
	Optimal estimator
Avalanche localization:	Increased number of channels
	Narrow avalanche
	Accurate pulse-height measurement
	Optimal estimator
Uniformity of drift velocity:	Homogeneous electric field
	No free charges in drift volume
	Small field-wire distances
	Mechanical accuracy
	Saturated drift velocity
Knowledge of wire positions:	Mechanical accuracy
	Short wires
	Controlled wire sag

Table 11.5 Factors relevant for accuracy and corresponding choices of design parameters



Fig. 11.41 Cross section of a drift chamber based on electroluminescence by Baskakov et al. [BAS 79], which had two sense wires

by the avalanche. Drift chambers based on electroluminescence had previously been studied by Charpak, Majewski and Sauli [CHA 75]; these are suitable for high particle rates because the emission of light in the high electric field of the anode wire is so strong (especially at high gas pressure) that only little or no charge amplification is necessary. However, large systems of such drift chambers have not yet been built.

With their chamber, Baskakov et al. were able to achieve an average accuracy of 18 μ m on one wire over a sensitive drift length between 10 and 35 mm (16 μ m at 20 mm). This accuracy comes mainly from the low drift velocity of 0.13 cm/ μ s and the small diffusion at this pressure. The sensitive area was nearly 4×4 cm².



Fig. 11.42a,b Precision drift chamber by Belau et al. [BEL 82]. (a) Wire configuration of three cells; (b) spatial resolution of a single wire as a function of gas pressure

References

A more conventional model is the precision chamber built by Belau et al. for the recording of particles behind a target [BEL 82]. It operates with a gas mixture of 75% propane and 25% ethylene at 4 atm pressure and presents a sensitive area of $10 \times 10 \text{ cm}^2$. The proportional wires (spaced 1.3 mm) are arranged in 6 horizontal planes, the cathode wires in parallel planes, creating 12 drift spaces 8 mm high and 50 mm deep, and one central insensitive space for a high-intensity beam (Fig. 11.42a). The achieved accuracy was $23 \,\mu\text{m}$ per wire after eliminating or calibrating the inhomogeneous drift regions near the wires (18% of the volume). This accuracy was obtained with a fast gas (drift velocity 5 cm/µs) and correspondingly fast electronics (rise time 0.8 ns) on 60 channels. The mechanical accuracy is based on ceramic spacers for the wires, ground to a precision of a few microns. The variation of the achieved measuring accuracy with gas pressure is seen in Fig. 11.42b.

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Chapter 12 Drift-Chamber Gases

Gas is the medium in which the processes of ionization, drift and amplification develop. We have discussed these processes in previous parts of this book. Here we want to present some additional practical information relevant to the choice of gas mixtures and their pressure, and relevant to the impurities that can be tolerated in the gas.

12.1 General Considerations Concerning the Choice of Drift-Chamber Gases

There are many gas mixtures that are successfully used in drift chambers. The tables in Chap. 11 contain a representative collection. Often we find the noble gas argon mixed with some quenching organic molecular gas. But purely organic mixtures are also in use. These gases fulfil the basic requirement that the electron lifetime is sufficiently long and that a stable amplification process exists.

An important choice has to be made with regard to the drift velocity and its dependence on the electric field. A highly preferable situation arises if the drift velocity varies little with the field, for then the coordinate measurement is less dependent on the unavoidable field gradients, and on the pressure and temperature variations of the gas. This happens at the maximum of the velocity–field relation ('saturated drift velocity'). Figure 12.1 shows the drift velocity of argon–isobutane mixtures, which have this desirable property over a relatively long range of E field.

At these high velocities – typically $5 \text{ cm/}\mu\text{s}$ – a fast time measurement is a necessity. If one wants to relax this requirement, one can reduce the drift field, and the drift velocity is no longer saturated, with the consequence that it depends on space charge and other changes of the drift field, thus requiring very careful calibrations.

The 'dilemma of the Lorentz angle' comes into sight here (see Sect. 11.3.2). If the electric and magnetic fields are orthogonal one may wish to achieve a small drift velocity at a high E field in order to keep the Lorentz angle small, cf. (2.7), (2.11).



Fig. 12.1. Drift velocity as a function of the drift field, for various argon-isobutane mixtures [BRE 74]

A high E field at small electron energy must be the goal in the interest of a low diffusion width; cf. the discussion following (2.63). The last two requirements combine well in the 'cold' gas mixtures based on carbon dioxide or dimethylether. In these, the random electron velocities and the drift velocity are much lower than in the 'hot' gases at the same field strength. The cold gases have the disadvantage that an operating point must be found in the unsaturated situation. High E fields are more difficult to handle, since spurious discharges are a threat to the reliability of a chamber. High E fields also cause electrostatic wire displacements; these are larger for greater wire lengths.

In order to give an overview of achievable diffusion limits we reproduce in Fig. 12.2 the characteristic electron energies calculated by Paladino and Sadoulet [PAL 75] for the pure gases Ar, CH_4 and CO_2 , and for various argon–isobutane mixtures. The width of the diffusion after 1 cm of drift, calculated according to (2.63), is shown in Fig. 12.3.

In TPCs, where the *E* and *B* fields are parallel, there is an advantage in having a high value of $\omega \tau$, or a high product of the *B* field and the mobility (cf. Sect. 2.1). One reason is the enormous suppression factor for the transverse diffusion constant (2.72), another has to do with the track distortions caused by imperfections in the uniformity of the magnetic field. Since in a good solenoid the inhomogeneities are predominantly radial (not azimuthal), the distortions of the curvature of radial tracks are suppressed by one power of $\omega \tau$; see (2.6).

Argon–methane mixtures with small CH₄ concentrations can be used in the saturated situation of the drift velocity, and there they exhibit large values of τ . It can be seen in Table 11.4 that such gas mixtures have actually been chosen for all the large TPCs.



Fig. 12.2. Characteristic electron energies calculated and reported by [PAL 75]. (a) for various mixtures of argon–isobutane; (b) argon, carbon dioxide and methane



Fig. 12.3 Diffusion width after 1 cm of drift, according to (2.63), using calculated electron energies [PAL 75]

12.2 Inflammable Gas Mixtures

Most of the quenching gases used in drift chambers can burn in air. Thus in large systems they may represent a security risk. We would like to know under what circumstances and in what concentrations they are dangerous.

A gas mixture that contains some oxygen is 'inflammable' if a flame can exist and propagate in it. (Confusingly enough, this same mixture is also called 'flammable' in the field.) The fact is established in a standardized vertical tube with ignition from below. Whether a flame develops or not depends on the nature of the gas components, their temperature and pressure, and in particular on their concentrations. By varying the concentrations of a gas mixture, one finds non-inflammable combinations whose content of combustible or oxygen is not enough to make a flame. Therefore there are lower and upper limits of concentration which mark the region of inflammability.

The simplest mixture is a two-component gas, e.g., methane in air. At normal temperature and pressure it is inflammable between approx. 5 and 15% CH_4 by volume in the total, whilst the stoichiometric ratio for complete combustion is 9.5%. There is no simple principle from which to derive such limits: they depend on details of the flame dynamics. Let us note that these limits are markedly different when the
flame proceeds with the ignition on top rather than at the bottom. The monograph by Lewis and von Elbe [LEW 61] may be consulted concerning this subject. More recent determinations of the limits of inflammability such as the ones conducted at CERN [CER 96] resulted in more conservative limits. This 'progress' is achieved by a new judgement about the development of the test flame, which may appear in a variety of forms – from a flame that propagates clearly to the top end of the test tube to flames that do not clearly detach from the spark or do so but burn out halfway up. Also, one is now more careful about gas purity as even small contaminations may influence the result. In Table 12.1 we present the classical inflammability limits as well as the new limits from [CER 96] for comparison.

When an inert gas is added to the previous mixture, we have a three-component mixture, e.g., methane, argon, and air. Now the inflammability limits also depend on the argon concentration. If there is too much argon, then there will be no flame, irrespective of the methane/air ratio. The three-component gas mixtures are conveniently described by the diagrams in Fig. 12.4: a particular mixture is given by the three volume concentrations c_1, c_2 , and c_3 in the total mixture, which add up to unity; they are represented by a point in the unilateral triangle whose three coordinates are measured parallel to its sides (the sum of the three coordinates is always equal to the length of one side).

Results of flame tests are now recorded in a diagram that delineates the region of inflammability. Examples from measurements by the Physikalisch-Technische Bundesanstalt, made at the request of CERN, are shown in Fig. 12.4.

Chamber gas does not contain oxygen, and inflammable mixtures will come about by unintentional contact with air. A safe chamber gas is one that produces

Compound	Formula	Limits of inflammability of gas or vapour			
		[LEW 61]		[CER 96]	
		Lower	Upper	Lower	Upper
Methane	CH ₄	5.3	15.0	4.4	16.9
Ethane	C_2H_6	3.0	12.5	2.4	14.6
Propane	C_3H_8	2.2	9.5	1.8	10.4
Butane	$C_{4}H_{10}$	1.9	8.5	1.4	8.9
Isobutane	i-C4H10	1.8	8.4	1.55	8.4
Pentane	$C_{5}H_{12}$	1.4	7.8		
Isopentane	i-C5H12	1.4	7.6		
2,2-dimethylpropane	C_5H_{12}	1.4	7.5		
Hexane	$C_{6}H_{14}$	1.2	7.5		
Ethylene	C_2H_4	3.1	32.0		
Propylene	C_3H_6	2.4	10.3		
Methylalcohol	CH ₃ OH	7.3	36.0		
Isopropylalcohol	C ₃ H ₇ OH	2.0	12.0		
Diethylether	$C_4H_{10}O$	1.9	48.0		

Table 12.1 Limits of inflammability of some gases and vapours in air that are of interest for particle detectors, from two different sources (vol. % of total mixture)



Fig. 12.4a–d Diagrams to describe three-component gas mixtures by their volume concentrations c_1, c_2 and c_3 (see text). Limits of inflammability for four different mixtures containing air

a non-inflammable mixture with any amount of air. Looking, for example, at Fig. 12.4a, we see that all the combinations of methane–argon–air concentrations that have this property lie below the tangent that connects the region of inflammability with the point \mathbf{P} ($c_1 = 0, c_2 = 0$, and $c_3 = 1$). All mixtures with a fixed concentration ratio c_1/c_2 lie on a straight line through \mathbf{P} , which intersects the opposite side at the value c_2 – the methane-argon mixture is safe in this sense if the methane concentration is not greater than 9% (or 6%, see later). Some safe concentrations of combustible gases are listed in Table 12.2.

In Table 12.3 we also list the new limiting safe mixtures recognized by the CERN safety code, which are based on the more recent measurements from [CER 96]. A comparison of the last two columns indicates a very small difference between the behaviour of butane with different impurities, surely not very important in practical applications.

A special point of interest is the tip of the region of inflammability that belongs to the smallest air concentration. One might expect that it always represents the stoichiometric concentrations. But this is not so – it is often displaced from the stoichiometric ratio towards lower concentrations of the component that has the higher diffusion [LEW 61]. Here is one more hint that no simple theory will predict the safe concentrations.

concentrations c ₂ are also given						
Combustible gas	<i>c</i> ₁ (%)	Inert gas	<i>c</i> ₂ (%)	Reference ^a		
CH ₄	13/9	He	87/91	[BUR 48, ZAB 65]		
i-C ₄ H ₁₀	2.7	Ne	97.3	[SCH 92]		
CH ₄	9	Ar	91	[BUR 48]		
C_2H_6	2	Ar	98	[SCH 92]		
<i>n</i> -C ₅ H ₁₂	2	Ar	98	[SCH 92]		
CH ₄	23	CO_2	77	[BUR 48, ZAB 65]		
C_2H_6	12	CO_2	88	[BUR 48, ZAB 65]		
C ₃ H ₈	11	CO_2	89	[BUR 48, ZAB 65]		
<i>n</i> -C ₄ H ₁₀	9.7	CO_2	90.3	[BUR 48, ZAB 65]		
i-C ₄ H ₁₀	9.3	CO_2	90.7	[BUR 48]		
$n-C_5H_{12}$	7.5	CO_2	92.5	[BUR 48, ZAB 65]		
<i>n</i> -C ₆ H ₁₄	6.6	CO_2	93.4	[BUR 48, ZAB 65]		

Table 12.2 Standard limiting safe mixtures in air. A mixture of a combustible gas (component 1) and an inert gas (component 2) is considered inflammable in air if, with a suitably chosen admixture of air (component 3), the three-component mixture can be ignited. The table quotes concentrations c_1 of component 1 at and below which no admixture of air can make a flame. The corresponding concentrations c_2 are also given

^aWhere two references are given they are in agreement, except for CH₄/He.

Inflammable gas mixtures have been used in numerous particle experiments. The required safety precautions may be a burden on the operation of the experiment, and it is advantageous to avoid such mixtures. However, for streamer chambers in particular this does not seem to be possible, because most mixtures with the required absorption power for the ultraviolet light are also inflammable. Special studies of this problem have been undertaken by Benvenuti et al. [BEN 89] and several other groups cited there.

	Inflammab	Inflammable gas (per cent purity)						
Inert gas (% purity)	CH ₄ (99.95)	C ₂ H ₆ (99.4)	C ₃ H ₈ (99.95)	iC ₄ H ₁₀ (99.5)	nC ₄ H ₁₀ (99.90)	nC ₄ H ₁₀ (99.5)		
N ₂ (99.995)	9.9	4.94	4.25	4.1	3.55	3.26		
CO ₂ (99.9)	22.45	9.09	7.95	7.95	6.52	6.45		
He (99.996)	11.86	5.45	4.41	4.15	3.58	3.55		
Ne (99.990)	9.2	4.37	3.45	3.26	2.74	2.70		
Ar (99.996)	6.15	3.05	2.76	2.4	2.28	2.16		
SF ₆ (99.90)	50.4	20.4	20.4	19.43	16.97			
CF ₄ (99.7)	33.4	13.0	11.76	9.5	9.28	9.1		
C ₂ H ₂ F ₄ (99.7)	11.98	7.14	6.7	5.75	5.8			

Table 12.3 Official limiting safe mixtures between inflammable and inert gases in air, according to [CER 96]. The table shows volume per cent of the inflammable gas in the total, below which the two component mixture is considered non-inflammable

12.3 Gas Purity, and Some Practical Measurements of Electron Attachment

Together with the gases intended to serve in a chamber, there will always be some contamination, by impurities in the bottles delivered from industry, from outgassing construction materials in the gas stream or produced in operation, or arriving from the outside world through membranes that are not entirely tight.

Even minor contamination may have adverse effects on the chamber operation. It can change the drift velocity (a drastic example is reported in Sect. 12.3.3), or they may remove drifting electrons by attachment (see Sects. 12.3.1 and 12.3.2). They are a cause of chamber ageing (Sect. 12.6). But they can also have a beneficial effect: ionization tracks produced by pulsed UV lasers often depend on some unknown molecular compound that happens to be in the chamber gas (cf. Sect. 12.4).

We have described in Chap. 2 various mechanisms of negative-ion formation which may lead to a loss of electrons drifting through a chamber. It is chiefly by varying the partial pressures of two clean gases that the two-body and three-body processes can be experimentally distinguished. The values reported in Figs. 2.11 and 2.12a-d were obtained in this way, mostly by workers engaged in atomic-physics research.

For the purposes of drift chambers it is not always necessary to isolate the exact process or to know the electron energy. On the other hand one wants to have electron attachment rates for the multi-component gas mixtures and for drift fields typical for applications in particle experiments. We collect here some measurements of this kind, keeping in mind that the detailed interpretation of the attachment process is not always required.

12.3.1 Three-Body Attachment to O_2 , Mediated by CH_4 , i- C_4H_{10} and H_2O

Electron loss rates were measured in various drift-chamber gases with additions of oxygen, water or methanol, by Huk, Igo-Kemenes and Wagner [HUK 88].

Working initially at 4 bar with Ar (88%) + CH₄ (10%) + i-C₄H₁₀ (2%) and with O₂ concentrations up to 440 ppm, they varied the total gas pressure and the hydrocarbon and O₂ concentrations. They were able to show that the measured electron attenuation rate R_{tot} associated with oxygen could be understood as a superposition of rates according to (2.77):

$$egin{aligned} R_{ ext{tot}} &= \sum R_i \ ; \ R_i &= k_1^{(i)} N(ext{O}_2) N(X_i) \end{aligned}$$

where $N(O_2)$ is the O_2 concentration and the $N(X_i)$ are the concentrations of the other gas components. (The rate proportional to the square of $N(O_2)$ is negligible at

<i>E/P</i>	$C(O_2, CH_4)$
(V/cm bar)	(µs ⁻¹ bar ⁻²)
100 138 163 200 250	$\begin{array}{c} 167 \pm 32 \\ 191 \pm 30 \\ 176 \pm 20 \\ 149 \pm 27 \\ 146 \pm 26 \end{array}$

Table 12.4 Three-body electron attachment coefficients for O₂ and third body CH₄ determined by [HUK 88] at fixed reduced drift fields E/P in drift-chamber gas composed of Ar(90%) + CH₄(10%) + O₂ (200 ppm) and Ar(80%) + CH₄(20%) + O₂ (200 ppm)

these low O_2 contaminations.) The various contributions could be separated, and the three-body rate coefficients of CH₄, i-C₄H₁₀ and Ar were determined for a practical range of drift fields. The contribution of Ar was zero inside the errors, as expected. The results are quoted in Tables 12.4 and 12.5. The coefficient C(O_2 , X), measured in units of (μ s⁻¹ bar⁻²), is related to k_1 of (2.77), measured in units of (cm⁶ s⁻¹), by the relation

$$C(O_2, X) = \left(\frac{6.02 \times 10^{20}}{22.4}\right)^2 \left(\frac{bar^{-2}}{cm^6}\right) 10^{-6} k_1$$

at N.T.P.

It should be noted that the three-body rate coefficients $C(O_2, CH_4)$ and $C(O_2, i-C_4H_{10})$ given in Tables 12.4 and 12.5 for specific values of the reduced electric field represent averages over the electron energies in the range of the gas mixtures used. For details the reader is referred to the article by Huk et al. [HUK 88], which is also an excellent entry point to the literature.

The authors then investigated the influence of water and methanol. In the absence of oxygen, neither 0.3% H₂O nor 0.1% CH₃OH in Ar(90%) + CH₄(10%) caused any electron absorption outside the errors. But the situation changed when a small amount (200 ppm) of O₂ was added to the argon–methane mixture. It turned out that 0.1% of H₂O is as efficient as 10% of CH₄ to mediate electron attachment to oxygen under the operating conditions investigated. 500 ppm of methanol did not change the attachment rate to oxygen inside the errors.

<i>E/P</i> (V/cm bar)	$C(O_2, i-C_4H_{10})$ (µs ⁻¹ bar ⁻²)
100	3240 ± 350
138	2819 ± 300
163	2490 ± 300
200	1970 ± 300
250	1570 ± 250

Table 12.5 Three-body electron attachment coefficients as in Table 12.4, but for O_2 and $i-C_4H_{10}$ in gas composed of $Ar(90\%) + CH_4(10\%) + O_2$ (200 ppm) + $i-C_4H_{10}$ (0 to 4%)

12.3.2 'Poisoning' of the Gas by Construction Materials, Causing Electron Attachment

A long lifetime of electrons, which is essential for the functioning of drift chambers with long drift paths, is not yet guaranteed when the chamber has been filled with extremely clean gas. The very material of the chamber itself and of its gas distribution system may contaminate the gas with electronegative (i.e. electron-absorbing) impurities which emanate from the surface or the volume of these materials. As we discussed in Sect. 2.2.7, the two-body attachment rates of some halogen-containing compounds are so large that even at concentrations as low as 10^{-8} they will absorb a sizeable fraction of the electrons that have to drift over a distance of one metre.

In practice, every piece of material that will come into contact with the gas stream of a long-drift chamber has to be controlled with respect to outgassing before it is built in. Test facilities for this purpose have been in use at Berkeley, CERN and probably other laboratories. Basically, a long drift tube is connected to a gas distribution system which comprises a receptacle for the material in question. In Berkeley the 'poisoning time' T_p was measured for which the test piece has to be in contact with the 6 m³ of the TPC volume before the attenuation of electrons over 1 m of drift increases by 1%. At CERN the results of the measurements were expressed in terms of the percentage electron loss A over 1 m of drift after the test piece had been in contact with 1 m³ of gas for 24 h.

The drift tubes were operated under the conditions of the large chamber that was being built in the respective laboratory (PEP-4 TPC at Berkeley: $Ar(80\%) + CH_4(20\%)$ at 10 bar; ALEPH TPC at CERN: $Ar(90\%) + CH_4(10\%)$ at 1 bar; cf. Table 11.4). The results of these technical measurements cannot be directly compared because the various contributing 2-body and 3-body attachment rates behave differently with respect to gas composition, pressure and electric field.

The results of these tests are documented in two lists [BRO 79] and [LEH 89] containing about a hundred items each. We present in Tables 12.6 and 12.7 some examples in order to show that many common construction materials do not poison the gas, whereas a number of other materials, especially certain cleaning agents, paints and seals, have been found to be disastrous.

12.3.3 The Effect of Minor H₂O Contamination on the Drift Velocity

We present in Fig. 12.5 drift velocities for two argon-methane mixtures, typical TPC gases, which in addition contain some very low concentrations of water vapour. These measurements from the DELPHI group are basically in agreement with calculations of Biagi [BIA 89] and of Schmidt [SCH 86]. Let us note that for some, especially low, values of the electric field, one tenth of a per cent of water vapour

Table 12.6 List of poisoning times T_p of some selected materials measured in the Berkeley Materials Test Chamber. T_p is the time it takes for one unit of the indicated material to increase the attenuation rate of electrons travelling over a drift distance of 1 m by 1%, when in contact with 6 m³ of the gas mixture, which was Ar(80%) + CH₄(20%) at 10 bar; the drift field was 1.5 kV/cm [BRO 79]

Material	Unit	<i>T</i> _p (best estimate) (h)	<i>T</i> _p (lower limit) (h)
Epoxy Versamid 140 and Epon 826	1 m ²	360	310
Teflon 'TFE'	$1 {\rm m}^2$	(1)	210
Etched copper-clad Kapton	$1 {\rm m}^2$	(1)	1500
Mylar	$1 {\rm m}^2$	(1)	680
G-10(Westinghouse)	$1 {\rm m}^2$	660	600
Tufftane polyuretane film	$1 {\rm m}^2$	(1)	910
Nylon connectors (3M)	1 piece	750	740
Glass-filled polyester connectors (Amp)	1 piece	160	75
Neoprene seal (Victaulic)	1 piece	100	99
White Nitrile seal (Victaulic)	1 piece	7.1	7
Tygon tubing (Xorton plastics R 3603)	1 ft	28	26
Spirex paint	$1 m^2$	87	80

1. Data consistent with infinite T_p .

changes the drift velocity almost by a factor of 2. This drastic behaviour is due to the properties of the water molecule with its static electric dipole moment, which causes the inelastic scattering cross-section for low-energy electrons to be exceedingly large, thus reducing the drift velocity according to (2.19).

Table 12.7 List of electron attenuations *A* caused by some selected materials in the ALEPH Materials Test Facility. *A* is the percentage electron loss over a drift distance of 1 m, caused by 1 m^2 of the indicated material in contact for 24 h with 1 m^3 of the gas mixture, which was Ar(90%) + CH₄(10%) at 1 bar; the drift field was 110 V/cm. *A* has been scaled linearly from smaller test pieces [LEH 89]

Material	$A (\% \text{ m}^2)$	$\pm \Delta A \ (\%/\mathrm{m}^2)$
Aluminium plate	0.0	0.02
Mylar foil, 25 mm thick	0.00	0.005
Delrin (polyacetal/polyoxymethylen) ('POM')	0.25	0.10
Plexiglas (PMMA)	0.7	0.1
Stesalit with copper back plane, cleaned with isopropyl-alcohol	0.3	0.2
Same, cleaned in ultrasonic bath containing freon	${\sim}40$	
Same as above, 4 months later	20	5
HT anti-corona coating SL 1300 (Peters, Kempten)	40	15
HT anti-corona coating Plastic 70 (Kontakt-Chemie)	0.1	0.1
Natural rubber (cleaned in hot water, 70°C, 2 h)	25	5
Viton vacuum seals (uncleaned)	70	20
Araldite AW 106 glue (1-week-old)	0.21	0.06
Same as above, but 5-weeks-old	0.06	0.03
Same as above, but 14-weeks-old	0.01	0.02



Fig. 12.5a,b Drift velocities measured by [CAT 89] for two argon-methane mixtures containing a small additional amount of water vapour. (a) $Ar(91\%) + CH_4(9\%)$; (b) $Ar(80\%) + CH_4(20\%)$. The measurement errors are estimated to be 1% or less; the lines are drawn to connect the measured points

12.4 Chemical Compounds Used for Laser Ionization

The most often employed technique of creating ionization tracks in the gas of a drift chamber relies on the presence of molecules in the chamber gas that can be ionized in a two-step process as discussed in Sect. 1.3. In many chambers the gas has sufficient impurities, owing to the outgassing of materials or as remnants from the production process. If the concentration is not large enough for the available laser power, or if it is not stable, a suitable compound has to be added to the chamber gas. We can look for candidates among the organic vapours with ionization potentials below twice the laser photon energy. A good number of them are known to produce ionizable tracks, but definitive measurements of the second-order cross-section equivalent (see Sect. 1.3.1) do not yet exist. Fig. 12.6 Measured ionization density as a function of the energy density of the laser at $\lambda = 266$ nm in Ar + CH₄ (uncleaned), doped with 5 ppm TMA, and with 2 ppm TMPD. The slopes of the curves are 1.99 ± 0.06 (Ar + CH₄), 1.9 ± 0.1 (TMA) and 1.9 ± 0.2 (TMPD)



A typical measurement is shown in Fig. 12.6 [HUB 85]. The ionization density is seen to follow the quadratic dependence of the laser flux. In Tables 12.8 and 12.9 we present linear ionization densities achieved with single laser shots in various vapours. Laser tracks imitating particle tracks can obviously be created with vapour partial pressures in the range of 10^{-3} to 10^{-6} Torr and with laser power densities of 1 μ J/mm². The reader is referred to a review article by Hilke [HIL 86] for further discussion.

As we know from Sect. 1.3.1 and (1.93), the yield of one shot at a given energy depends on the space and time structure of the laser pulse. Once these are determined

Substance	Ionization potential (eV)	Vapour pressure at 20°C (Torr)	Linear ionization density (el./cm)	Reference
α -naphthylamine α -C ₁₀ H ₇ NH ₂	7.3	$2.7 imes 10^{-4}$	4×10^3	[GUS 84]
N, N-dimethylaniline (DMA) C ₆ H ₅ N (CH ₃) ₂	7.14	0.25	0.05	[LED 84]
N, N-dipropylaniline (DPA)C ₆ H ₅ N(C ₃ H ₇) ₂	7.1	1.2×10^{-2}	130	[GUS 84]
Diethyl ferrocene	6.6	$5.4 imes 10^{-2}$	10	[GUS 84]
N,N,N',N'-tetramethyl- <i>p</i> -phenylenediamine (TMPD)	6.18	2.3×10^{-3}	$7 imes 10^4$	[GUS 84]

Table 12.8 Linear ionization densities achieved in various organic vapours with one shot of the N₂ laser ($\lambda = 337 \text{ nm}$, $E_{\gamma} = 3.66 \text{ eV}$). The results are rescaled to a beam cross-section of 1 mm², an energy of 1 μ J, and a partial pressure of 10⁻³ Torr

Substance	Ionization potential (eV)	Vapour pressure at 20°C (Torr)	Linear ionization density (el./cm)	Reference
Toluene C7H8	8.82	22	7×10^3	[DRY 86]
Trimethylamine (TMA)	8.5; 7.82	-	60	[LED 85]
(CH ₃) ₃ N			70	[HUB 85]
Phenol C ₆ H ₅ OH	8.51; 8.3	-	>250	[HUB 86]
Naphthalene C ₁₀ H ₈	8.12	-	500	[HUB 86]
Triethylamine (TEA) (CH ₃ CH ₂) ₃ N	7.5	50	200	[LED 85]
N, N-dimethylaniline (DMA) C ₆ H ₅ N(CH ₃) ₂	7.14	0.25	10 ⁴	[LED 85]
N, N, N', N'-tetramethyl- <i>p</i> -phenylenediamine (TMPD)	6.18	2.3×10^{-3}	$4 imes 10^4$	[HUB 85]

Table 12.9 Linear ionization densities achieved in various organic vapours with one shot of the frequency-quadrupled Nd: YAG laser ($\lambda = 266 \text{ nm}, E_{\gamma} = 4.64 \text{ eV}$). The results are rescaled to a beam cross-section of 1 mm², an energy of 1 µJ, and a partial pressure of 10⁻³ Torr

together with the ionization, definitive measurements of the second-order crosssection will become possible. Not all ionizable substances are suitable for doping the gas of a chamber. For example, the vapour tetrakis(dimethylamine)ethylene (TMAE) is a highly ionizable agent because of its low ionization potential of 5.5 eV. But it quickly deposits on metal surfaces, rendering them photosensitive, and it is difficult to remove [LED 85]. The authors quoted in Tables 12.8 and 12.9 have devoted much work to this problem of vapour sticking to the surfaces of their chambers.

Another aspect of doping is the observation of deposits on the anode or cathode of wires. Even modest concentrations of ionizable organic vapours may accelerate the process of 'ageing'. Such studies, made with the UA1 detector, are reported by Beingessner et al. [BEI 88a]. The effects of ageing are discussed in more detail in Sect. 12.6.

Finally, we mention that under conditions of heavy irradiation, Beingessner et al. [BEI 88b] observe that tetramethyl-*p*-phenylenediamine (TMPD) vapour disappears from the detector, presumably owing to charge transfer from the avalanche-produced heavy ions that are in the drift region; when they have ionized and cracked the TMPD molecules, the ionized TMPD molecules and crack products drift away to the cathode.

12.5 Choice of the Gas Pressure

In the design of a drift chamber, one of the first important decisions must be taken on the gas pressure, because it determines to a large extent the over-all construction. The technical inconvenience of a pressure vessel and the increase of matter in the path of the particles are balanced to a certain degree by some advantages in the measuring accuracy, and we want to review them here. We note in passing that the wall thickness of a vessel must increase in proportion to the over-pressure it has to hold.

We have stated in (2.85) that for the mobility tensor the electric and magnetic fields scale with the gas density. One would therefore like to discuss the gas density always in connection with the corresponding change of the electric and magnetic field strengths, thus keeping the drift-velocity vector constant. But in practice an increase of the relevant field strength is easy in the electric and difficult in the magnetic case. Therefore, we proceed by specifying the magnetic field first, the gas density is discussed next, and then the electric fields are adjusted accordingly. The gas density is varied by changing the pressure, since one usually works at room temperature.

Let us consider the various consequences of a change of the gas pressure by a factor p > 1, say from 1 bar to p bar. Table 12.10 contains a summary of the most important effects.

12.5.1 Point-Measuring Accuracy

In measurement accuracy, insofar as it is limited by diffusion, one gains by increasing the pressure – unless the limitation is in the diffusion transverse to the magnetic field, and $\omega \tau \gg 1$. Therefore, we distinguish between the following:

- (a) Longitudinal diffusion or ωτ ≪ 1: For the width of the diffusion cloud one gains a factor l/√p (2.61, 63), and in the accuracy to find the centre of the cloud one gains another factor 1/√p, because the statistical fluctuations vary with 1/√N_{tot}, where N_{tot} is the total number of electrons in the diffusion cloud. Therefore, the over-all gain is a factor 1/p.
- (b) Transverse diffusion with $\omega \tau \gg 1$: For the width of the diffusion cloud one *loses* a factor \sqrt{p} according to (2.61, 63, 72). The statistical fluctuations compensate this; therefore, the over-all factor is 1.

The contributions to the measurement accuracy that arise from the driftpath variations have statistical fluctuations that vary with $1/\sqrt{N_{\text{eff}}}$ (see (1.73) and Sect. 7.2.3). As the pressure is increased, N_{eff} increases as well, but only slowly. For the purpose of the present estimates we take N_{eff} proportional to \sqrt{p} (Figs. 1.22 and 1.23). The situation would change where declustering occurred in any important measure. The drift-path variations are partly due to the wire geometry, i.e. constant when p varies, but partly they have a pressure dependence of their own. This is the case for the wire $E \times B$ effect. Here we refer to the angle at which the electrons approach the wires in their immediate neighbourhood (Sect. 7.3.1). The tangent of the effective Lorentz angle ψ will decrease roughly proportional to 1/p, as p increases. A smaller angle ψ will reduce the drift-path variations. Depending on how important the wire $E \times B$ effect is in comparison to the other drift-path variations, we may say in summary that the contributions to the measurement accuracy that arise from the drift-path variations decrease as a function of p which is somewhere between 1/p and $1/p^{0.25}$.

change by the factor indicated in the fast column		
Mean free path between collisions Mean time between collisions (at constant		1/p 1/p
electron energy)	•0	- ' P
Electron attachment:		
2-body rate	R_2	p
3-body rate	R_3	p^2
Diffusion constant:		
without magnetic field	D(0)	1/p
parallel to B	$D_{ m L}(\omega)$	1/p
orthogonal to $B(\omega \tau \gg 1)$	$D_{\rm T}(\omega)$	р
orthogonal to $B(\omega \tau \ll 1)$	$D_{ m T}(oldsymbol{\omega})$	1/p
Electric and magnetic fields:		
(adjustment for constant electron energy	E	р
and drift field)	В	р
Synchrotron radiation background:		
rate of charge directly produced	B_s	р
by the radiation		
amount of charge from the amplification	Q	1
process in the volume at any given time	_ /_	
ratio of disturbing to ordinary drift field	$E_{\rm s}/E$	1/p
Ionization:		
mean distance between clusters	λ	1/p
total ionization	N _{tot}	p
ionization effective for coordinate	$N_{ m eff}$	$\sim \sqrt{p}$
measurement		
most probable ionization	$I_{\rm mp}$	$pf(p)^{a}$
variance of most probable value	$\Delta I_{\rm mp}$	$p^{-0.320}$
ratio between minimum and maximum	$I_{\rm Fermi}/I_{\rm min}$	decreasing
velocity saturation point	γ^{r}	$\frac{1}{\sqrt{p}}$
Radiation effects (Coulomb scattering,	A _{rad}	1/p
radiation length		

Table 12.10 Influence of the gas pressure on various parameters relevant for drift chambers. If the gas pressure is changed by a factor p, then, in a first approximation, the particular parameter will change by the factor indicated in the last column

^a The increase does not follow a simple law because the atomic structure is involved, but it is essentially proportional to p times a logarithmic term of p. A curve for argon is shown in Fig. 1.11. ^b [ALL 80].

^c See discussion in Chap. 10.

12.5.2 Lorentz Angle

Here we refer to the direction Ψ under which the electrons travel in the main drift space. For a drift chamber of type 2 it is imperative to keep Ψ low. One way to achieve this is to increase the gas pressure. For a first orientation it is enough to work in the approximation of one electron energy. Referring to Sect. 2.2,

12.6 Deterioration of Chamber Performance with Usage ('Ageing')

$$\tan \Psi = \omega \tau$$
.

Since $\omega \tau = (e/m)B$, at a given magnetic field one seeks a small τ . The mean time between collisions is related to the density *N* and the collision cross-section σ by

$$\tau = \frac{1}{N\sigma c}$$

An increase of the density N by a factor p will reduce τ to τ/p if the electric field E is also increased to Ep, because the electron velocity c is a function of E/N and then stays the same. In the presence of a constant and strong magnetic field B, this is not strictly true because c is also a function of B/N, but the dependence is not very strong, as can be seen from (2.49). In conclusion we may say that an increase of the gas pressure and the electric field by a factor p reduces the tangent of the Lorentz angle approximately by the same factor.

12.5.3 Drift-Field Distortions from Space Charge

In drift chambers with long drift distances like TPCs one always has to beware of the adverse effect of any space charge that may exist in the drift volume. Such a charge may arise from some background such as synchrotron radiation in e^+e^- colliders. It will distort the uniform drift field. The effect of an increase of the gas pressure in such a situation is the following.

The background B_s increases proportional to p, and since the wire gain G is assumed to be adjusted to produce the same signal level as before, we have B_sG = constant. If the drift potential has been increased in proportion to the pressure, the ion drift velocity remains the same, and the amount of positive ion charge that flows back into the drift volume (assuming constant effectiveness of any ion shutter) produces the same amount of total charge Q inside the drift volume as before. The adverse electric field it creates there is the same, but relative to the increased drift field it is *smaller* by the factor by which the pressure has been increased.

12.6 Deterioration of Chamber Performance with Usage ('Ageing')

Drift and proportional chambers that have been in use for some time have a tendency to malfunction sooner or later - an increase in the dark current, a lowering of the gain, and a loss of pulse-height resolution are the typical symptoms. Once it has started, the problem seems to become worse and to spread from a few wires to many, until finally the chamber may no longer hold the operating voltage.

This behaviour is intimately associated with the gas mixture in the chamber and with certain contaminants. However, the material properties of the anodes and cathodes as well as their size also play a role in this area which is far from being clearly understood. Given the practical importance of the subject and that the new accelerators will produce extremely high levels of radiation, efforts towards better understanding are under way. Workshops held at Berkeley [WOR 86] and Hamburg [WOR 01] summarized the experience. A comparison of the reports at the two proceedings shows that during the 15 years between them there was much progress towards mastering the high particle fluxes of modern times. On the other hand, there is still no fundamental understanding of ageing. Nobody can calculate the lifetime of a chamber to be built, and in most cases one cannot even calculate what the result will be when some parameter is changed in a given chamber and its gas supply system.

12.6.1 General Observations in Particle Experiments

The wires of degraded chambers carry deposits of various kinds, either as spots or as complete coatings of the anode or cathode wires, smooth or hairy, white or black or oily, in the region of the strongest exposure. One quantifies the lifetime of a wire by adding up the charge that it has collected during its lifetime; it is calculated as the total charge that has drifted towards it times the avalanche gain. Lifetimes at which performance losses have been reported are in the range $10^{-4} - 1$ Coulomb per cm of wire length. It appears that the lower limit of 10^{-4} C/cm has become rather uncommon since the problems with the particular gas mixture consisting of Ar (75%), isobutane (24.5%), and freon (0.5%) have become understood [SAU 86]. (This mixture was employed in the very first proportional chamber systems and, among experts, went under the name 'magic gas'; it was used for very high avalanche gain factors beyond the proportional mode.) Most often, lifetimes are reported to be above 10^{-2} C/cm before deterioration sets in. With special precautions such lifetimes may be extended by an order of magnitude or more. Table 12.11 contains a collection of particle experiments with details about the behaviour of ageing chambers and some special precautions.

12.6.2 Dark Currents

The build up of a dark current drawn by the anode wire of a deteriorated chamber even in the absence of radiation can be explained by the 'thin-field emission effect', or Malter effect [MAL 36]. In his experiment, Malter showed that a positive surface charge deposited on a thin insulating film that covers a cathode can provoke the emission of electrons from the cathode through the film. A very high electric field may be created in the film between the deposited charge and the countercharges accumulated on the metallic cathode on the opposite side. Electrons are extracted from the metal through field emission and may find their way through the film into

Chamber	Reference	Basic gas mixture (percentages)	Additional measures (concentrations in %)	Accumulated charge density (C/cm)	Observed effects ^a
TASSO central detector	[BIN 86]	Ar(50) +C ₂ H ₆ (50)	C ₂ H ₅ OH (1.6) + oil in ethane removed gas filters inserted	0.2–0.4	None
TASSO vertex chamber	[BIN 86]	$Ar(95)+CO_2(5)$ + C_2H_5OH (0.12)(3.bar)	H ₂ O(1)	0.25	Some
Split field magnet chambers	[ULL 86]	$\begin{array}{c} (0.12)(3.041) \\ \text{Ar}(53) \\ +\text{i-}C_4\text{H}_{10}(40) \\ +(\text{CH}_2\text{OH})_2 \\ \text{CH}_2(7) \end{array}$	-	0.3	Anode wire coating, thickness 1 μm
ACCMOR drift chambers	[TUR 86]	Ar(50) +C ₂ H ₆ (50)	(CH ₃) ₂ CHOH(0.2) Ar(60)+C ₂ H ₆ (40)	0.02	None
ARGUS drift chamber	[DAN 89]	$C_{3}H_{8}(97)$ +(CH ₂ OH) ₂ CH ₂ (3)	H ₂ O(0.2)	0.005	None
BNL hyper- nuclear spec- trometer DC	[PIL 86]	$Ar(50) + C_2H_6(50)$	covering soft urethane adhesive	0.2	None
FNAL tagged photon spec- rometer	[EST 86]	$Ar(50) \\ C_2H_6(50)$	C ₂ H ₅ OH wire cleaning	0.1–0.2	Efficiency loss
UA1 central chamber	[YVE 86]	Ar(40) +C ₂ H ₆ (60)	-	0.01	None
Argonne ZGS beam chambers	[SPI 86]	Ar(65) +CO ₂ (35) +CBrF ₃ (0,5)	new bubbler oil, new plastic tubes, new wires	0.1–1	Efficiency loss, deposits (Si) on anodes, cathodes
EMC muon chambers	[HIL 86]	(0.5) Ar(79.5) +CH ₄ (19.5)	_	0.15 after 0.25:	Anode deposits, efficiency loss 30% End of
					operation
J-Spectrometer, BNL (1974), front proportional chambers	[BEC 92]	$\begin{matrix} [Ar+\\ (CH_2OH)_2\\ CH_2](0^\circ C)^b \end{matrix}$	_	0.1–1	Deposits on flat cathode, chambers still efficient

^aAfter the additional measures

^bArgon saturated with methylal at 0°C

the space between the anode and the cathode. In Malter's experiment the positive surface charges were produced by an external beam of particles; when this beam was removed, the field emission was not immediately interrupted, but decayed slowly because the surface charge took an appreciable time to leak away.

In a wire chamber, some thin insulating coating on the cathodes is charged up by the positive ions that are produced in the avalanches and drift to the cathodes. The surface charge density depends on the balance between the neutralisation rate and the ion collection rate, the latter being proportional to the rate of charge multiplication on the anode. If the surface charge density increases above some critical value, secondary electron emission from the cathode into the gas via the Malter effect becomes possible. The secondary electrons reach the anode and produce avalanches, thus increasing the positive-ion production rate. If the secondary-electron emission rate is sufficiently high, the process becomes self-sustaining and the dark current remains, even if the source of the primary radiation is removed from the chamber.

If one stops the avalanches by turning down the anode voltage, the dark current is obviously interrupted, but it does not immediately reappear when the anode voltage is subsequently turned up again. A certain intensity of radiation on the area in question is required to reestablish the current.

An efficient way of preventing the development of cathode deposits is to keep the electric field at the cathode surfaces low. Plane cathodes and wires with larger diameters show smaller deposits.

In chambers with appreciable standing currents, the addition of a small amount of water in the gas has often been found to suppress the currents [WOR 86, DAN 89]. An explanation is that the cathode deposits are made conductive so as to increase the ion leakage rate through the insulating film. It is also generally known that small amounts of alcohol have a tendency to prevent or delay the appearance of dark currents.

Another cause of standing currents and of the breakdown of chambers is the socalled whiskers, fine strands of material growing on the cathode or the anode. Glow discharges may appear owing to the large fields they create.

The growth of whiskers is primarily a question of the gas composition. For example, a change from the gas composition 1 (Ar(89%) + CO₂(10%) + CH₄(1%)) to the similar gas composition 2 (Ar(90%) + CO₂(5%) + CH₄(5%)) produced whiskers which grew from the cathode wires in the field direction, according to a test by the JADE group [KAD 86]. Upon going back to composition 1, the whiskers shrank and finally disappeared. In another test [FOS 86] it was shown that whisker growth on cathode wires is supported by gas mixtures containing the lower alkanes, which presumably form (CH₂)_n-type polymers. On the other hand, no mixtures of carbon dioxide and argon support whisker growth; rather they make existing whiskers retreat and disappear. Table 12.12 summarises these tests, which were done under the extreme conditions of glow discharge. Although such extreme conditions do not usually apply to chambers that are working well, they may develop temporarily at some imperfect spot in a chamber.

Let us add to this list of causes of dark currents the photoeffect discussed in Sect. 4.1. Depending on the photoabsorption properties of the gas, photons emitted

Gas mixture (percentages)	Whisker growth allowed?	Comments
Argon (50) + ethane (50)	Yes	Whiskers grow down to concentrations of ethane of 5% or more
Argon (48) + ethane (48) + ethanol (4)	Yes	Growth is suppressed by adding ethanol
Argon (40) + ethane (40) + carbon dioxide (20)	Yes	
Argon + carbon dioxide	No	No mixture of Ar and CO ₂ supports whisker growth
Argon (70) + carbon dioxide(25) + ethanol (5)	No	
Argon (90) + methane (10)	Yes	
Argon (95) + methane (5)	Yes	
Argon (50) + isobutane (50)	Yes	Threshold for whisker growth about
Argon (60) + isobutane (40)		twice as high as with argon-ethane
Argon (92) + isobutane (8)		mixtures

Table 12.12 Whisker growth measured in glow discharges produced on a cathode wire [FOS 86]

in an avalanche may create electrons in the gas or on the cathode which produce new avalanches. Whether this feedback situation can lead to limited dark currents depends on the presence of some damping mechanism.

12.6.3 Ageing Tests in the Lower-Flux Regime

The process of ageing has been investigated in numerous laboratory experiments. With the help of intense radioactive sources, the ageing process occurs within shorter periods of time. Although it is established that the measured fatal dose is not independent of this intensity (it comes out larger at intensities that are too high [VAV 86]), the method is useful for the comparison of different factors that influence the ageing process. A list complete up to 1985 is contained in [WOR 86]. Later work may be followed by consulting [ATA 87] and [KAD 90].

A first line of investigation concerns the nature of the quenching agent, which, either alone or in combination with a noble gas (typically Ar), would serve as the counting gas. Perhaps some quenching agents age later than others? One often measures the spectrum of an Fe-55 source and observes its peak and width as functions of the charge collected on the sense wires. Figure 12.7 shows the results of Turala and co-workers [TUR 86]; the relative pulse height as well as the peak of the Fe-55 signal began to deteriorate at lifetimes (total charge collected) that were different by an order of magnitude or more as isopentane was exchanged for carbon dioxide or nitrogen.



Fig. 12.7 Energy resolution and peak position of the ⁵⁵Fe signal in various gas mixtures as functions of the total collected charge, measured by [TUR 86]

It is generally reported that the addition of a small percentage of some alcohol (CH_3CH_2OH , (CH_2OH)₂ CH_2 , (CH_3)₂CHOH) to the counting gas extends the lifetime of chambers significantly, even if it does not prevent the development of deposits.

Another line of enquiry starts from the observation that chemical elements found in the wire deposits are occasionally foreign to the chemical compounds of the gas or the wires. Silicon, a dominant signal in X-ray fluorescence or Auger-electronspectrometry analyses of some wire deposits could only have been contained in the gas at the low concentrations that are permitted by the tight tolerances of the gas-purity specifications. In addition there may have been some parts of the chamber installation where silicon-containing compounds reached the gas at very low vapour pressure. In one instance, some silicon oil present in the counting gas with a vapour pressure of 10^{-9} Torr was observed to cause rapid growth of polymers on the anode [HIL 86]. This implies a surprisingly high silicon collection efficiency of the avalanche process. Could it be that other substances 'poison' the gas in a similar manner? And if so, under what circumstances? In Fig. 12.8, the surprising results of a test performed by Kotthaus are depicted. The input gas stream of argon-ethane was conducted through clean steel tubes; when the integrated collected charge reached a certain value marked in the figure, a 10-m-long hose of soft PVC was introduced into the input gas stream, resulting in an immediate deterioration of the test-tube performance, as measured by the pulse height and the resolution of the Fe-55 spectrum. When the hose was removed, the performance did not return



Fig. 12.8 Effect of a soft, 10-m-long, PVC gas hose. *Dots* (referring to the left-hand-side scale) indicate the position of the ⁵⁵Fe peak relative to the (unaged) reference position. The *crosses* (referring to the right-hand-side scale) show the width of the ⁵⁵Fe distribution relative to its peak position in the radiation damaged wire region. The lower drawn-out curve (referring to the right-hand scale) represents the same quantity, but measured at the (unaged) reference position. The period of time in which the PVC hose was put into the input gas stream is also indicated [KOT 86]

to its original values, but the loss of gain persisted. It is also remarkable that the resolution changed quite significantly on a piece of wire that had not aged (outside the area of exposure), but only when in the presence of the PVC hose. Such observations support the idea that the process of polymerisation, which later continues on its own, is started by certain dangerous substances, in this case perhaps one of the organic softening agents that are mixed into the PVC giving it its characteristic odour. In his summary [VAV 86], Va'vra makes a list of contaminations that, according to experience, should be avoided in order to achieve extended chamber lifetimes; the list includes halogens, oil traces (also from bubblers), rubber (especially silicon rubber), polyurethane adhesive, PVC and teflon tubing, soft epoxies and adhesives, aggressive solder, any unknown organic materials, and large amounts of G10 (glass-fibre-enforced material containing Si). Cold traps have a beneficial effect [HIL 86].

12.6.4 Ageing Tests in the High-Flux Regime

Here we refer to the new high-rate experiments (HERA-B, LHC-experiments) in which the entire charge collected on the sense wires will probably go up to 10 Coulomb per cm of wire length or more, two or three orders of magnitude higher than in the experiments of the previous generation. Here one comes into a new regime of ageing.

The consequences are clear: all hydrocarbons as quenchers are out of the question because of their tendency to polymerise; compare Table 4.1 in which only CO₂ is useable. Even the slightest contamination, especially of silicon compounds, has to be excluded, requiring extremely clean gas supply systems and well-planned validation tests for the materials of all components in contact with the gas. Lists of materials and their outgassing rates exist [NASA], [BOU96], [CAP01].

At the high-charge doses studied, new phenomena became apparent and a new quench gas, CF_4 , was introduced. Carbon tetrafluoride is non-flammable, non-polymerising and in gas mixtures with a noble gas makes fast counters even at moderate fields. The reaction products formed in avalanches are quite aggressive towards materials such as electrodes and gas filters, but also against previously existing polymer deposits, which they seem to be able to remove. There are the two competing processes caused by the radicals formed in avalanches: polymerisation and etching. This competition was demonstrated in an experiment by Openshaw et al. [OPE 91]. Working with a gas consisting of a mixture of CF_4 and isobutane, they were able to shift the balance between the two processes towards more polymerisation or towards more etching by changing the relative gas concentrations.

As a modern example we note the tubes of the ATLAS transition radiation tracker (TRT) [AKE 03], which have perhaps the most heavily irradiated proportional counters among the modern experiments, as their sense wires will draw up to 0.15 μ A/cm of wire length, corresponding to approx. 10 C/cm in 10 years of LHC operation. Based on the experience described above, the first prototypes were operated with a gas containing CF₄: 70%Xe + 20%CF₄ + 10%CO₂, the xenon being required for the transition radiation photon conversion. The presence of CF₄ proved in the end to be too aggressive against some chamber components, notably glass. The commercial price of xenon necessitates a closed gas circulation system. The group has developed certification methods for cleaning components and has demonstrated that the deterioration caused by the unavoidable presence of minute traces of silicon –



Fig. 12.9 Anode wire after only 0.08 C/cm accumulated charge. The deposits were caused by traces of Si from a lubricant used in the early straw production; they lead to a gas gain drop of about 30%



Fig. 12.10 Surface of a wire observed after 0.5 C/cm of accumulated charge, for the TRT standard gas (see text) with 1.2% of water and 1.5% of oxygen added. Amorphous deposits of WO are observed on top of the gold-plated tungsten wire. An energy dispersive X-ray (EDX) spectrum reveals the presence of tungsten and oxygen

an example is shown in Fig. 12.9 - can be healed by etching away the deposits, a process which will occur automatically during the experiment.

High charge doses on the wire can cause a new phenomenon even more disastrous than whisker growth: the gold plating on the tungsten wire may peel off (Fig. 12.12) under the influence of gas components such as H_2O or O_2 . Also the wire may swell to twice its diameter forming tungsten oxide, (Fig. 12.10). Under similar circumstances, crystalline tungsten oxide layers form deposits on the wire (Fig. 12.11).

An excellent summary of the state of the art of ageing is the article the editors of the DESY workshop [WOR 01] wrote for the *IEEE Transactions on Nuclear Science* [TIT02].



Fig. 12.11 Surface of a wire carrying crystalline deposits of WO under experimental conditions similar to those of Fig. 12.10



Fig. 12.12 Various manifestations of damage to the gold-plating after 2-6 C/cm of accumulated charge for different current densities (1-4 μ A/cm). No gold-plating damage was observed when the water content was below 0.1%. All photographs from [AKE 03]

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The requirement to eliminate all hydrocarbons from the gas of proportional chambers dedicated to very-high-rate experiments changes the situation in a drastic way. Whereas previously we carefully optimised the gas properties by choosing the right gas composition from a good variety of possible components, now there are only a few left. Important gas properties such as the drift velocity and its dependence on electric and magnetic fields, diffusion, Lorentz angle, quenching strength, etc. (cf. Sects. 12.1, 12.5) must be taken as they come, if the chambers are to survive the high dose awaiting them in the new experiments. If, for example, the drift velocity cannot be made insensitive to the electric field, any space charge in the drift region will limit the measurement accuracy and open a new frontier for the control and, perhaps, correction of such effects.

A thorough understanding of the ageing process must involve the chemical processes in the plasma of the avalanches. There are certainly several competing mechanisms at work; this is also apparent from the wide variety of manifestations of the deposits as well as from the fact that drastically different element abundances are measured in different spots along the wires [KOT 86].

At present we do not even know whether a better understanding of the plasma polymerisation on our wires will give us the means to substantially prolong the lifetime of the chambers. Thus for the time being we are left with a few rules – to keep the gas and the wires extremely clean, to add some alcohol or water if necessary, and to keep the cathode wires thick. Since it is the total collected charge which destroys the wire, it is useful to keep the amplification low.

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